

TECHNICAL & EXHIBITOR PROGRAM



Technical & Exhibitor Program • AVS 65th International Symposium & Exhibition • 2018



Start using the AVS 65 App

To login, please enter your Registration ID* and Last Name to access messaging, enable the synchronization of notes, favorites, and scheduled items between devices and the online planner.

*Your Registration ID can be found on your AVS 65 Confirmation/Receipt near the barcode.

AVS 65th International Symposium & Exhibition

OCTOBER 21-26, 2018 • EXHIBITS: OCTOBER 23-25, 2018
LONG BEACH CONVENTION CENTER, LONG BEACH, CA

EXHIBIT HOURS:

Tuesday, October 23: 10:00 a.m. - 5:00 p.m.
Wednesday, October 24: 10:00 a.m. - 4:30 p.m.
Thursday, October 25: 10:00 a.m. - 2:30 p.m.



palladium catalysts thin film nickel foam glassy carbon buckyballs

european phosphors diamond micropowder III-IV semiconductors

alternative energy additive manufacturing mischmetal gallium lump

organic materials zeolites surface functionalized nanoparticles nanodispersions macromolecules

nano materials 99.999% ruthenium spheres anode yttrium stabilized zirconia silver nanoparticles

ceramic set ultralight aerospace alloys epitaxial crystal growth

3D graphene foam chalcogenides osmium MOFs

copper palladium catalysts quantum dots superconductors

CIGS

MOCVD

YBCO

ultra high purity materials 99.99999% mercury

li-ion battery electrolytes dysprosium pellets

dielectrics

solar energy

sputtering targets

graphene oxide

additive manufacturing

lithium niobate

Ti-6Al-4V

AuNPs

CVD precursors

silver nanoparticles

The Next Generation of Material Science Catalogs

Over 15,000 certified high purity laboratory chemicals, metals, & advanced materials and a

state-of-the-art Research Center. Printable GHS-compliant Safety Data Sheets. Thousands of new products. And much more. All on a secure multi-language "Mobile Responsive" platform.

American Elements opens a world of possibilities so you can Now Invent!

www.americanelements.com

© 2001-2018. American Elements is a U.S. Registered Trademark

125 MAIDEN LANE, 15B, NEW YORK, NY 10038
WWW.AVS.ORG

LEADING SURFACE ANALYSIS

AXIS SUPRA™



AXIS NOVA



Angle resolved X-ray photoelectron spectroscopy (ARXPS) can be extremely surface sensitive, probing the outermost 1 -3 nm of a material. By contrast using higher energy X-ray excitation sources, such as our Ag L α (2984.2 eV) monochromatic source can generate information from the near surface region (up to 20 nm), while sputter depth profiling using Ar $_n^+$ gas clusters can provide XPS data from several microns into the 'bulk' material.

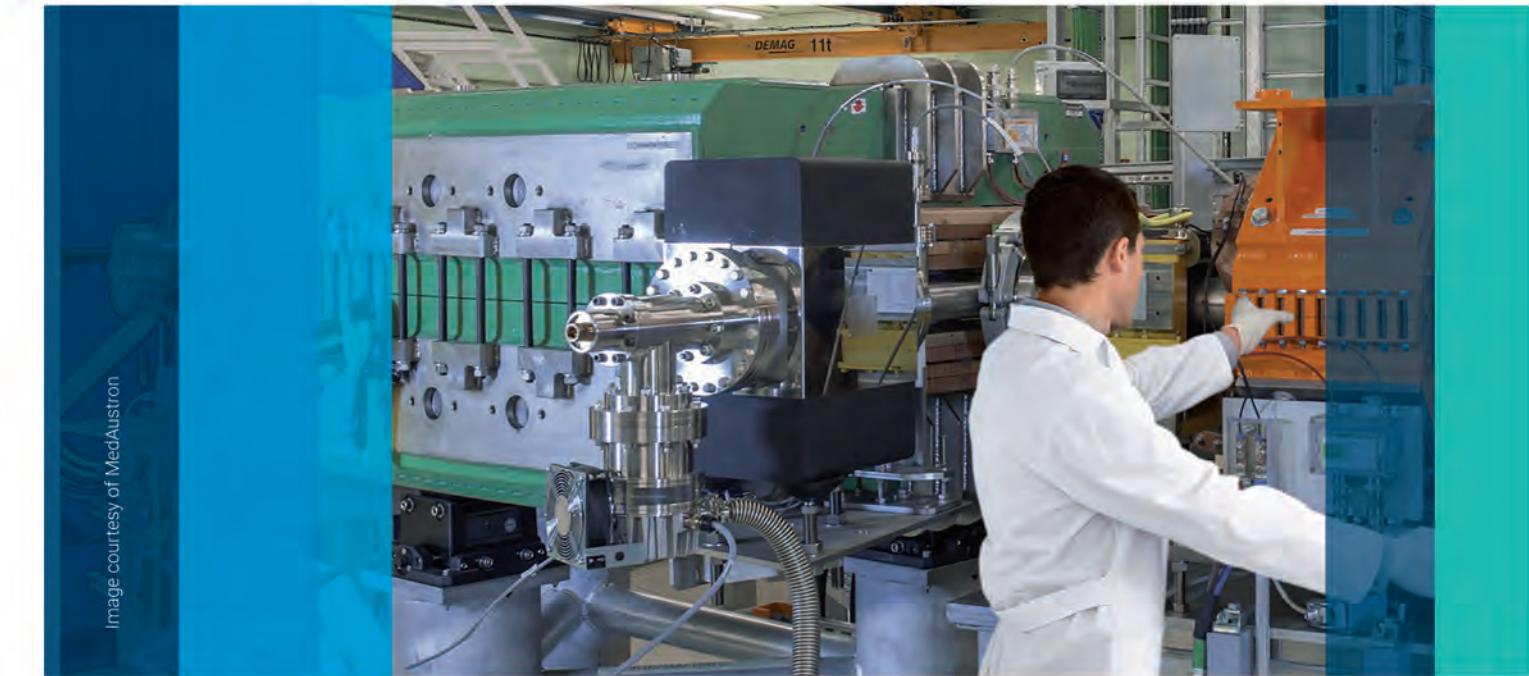
Learn how Kratos have combined these acquisition modes with accessories for in-situ sample processing such as a high temperature/pressure gas reaction cell or evaporation sources at our exhibitor workshop.

For live demonstrations of the AXIS Supra or AXIS Nova controlled by ESCApe software visit STAND 227

www.kratos.com

COME SEE US AT BOOTH 413

Agilent
Trusted Answers



Vacuum Beyond Specifications

Agilent understands the difference between simply installing a component, and implementing a vacuum solution that delivers long-term performance and confidence.

The family grows:

Agilent TwisTorr FS Turbo Pump Family,
from 70 to 800 L/s



TwisTorr FS
Turbo Pumps

Innovation Expands:

Agilent VacIon Pump 200 and IPCMini
The first ion pumps with optimized pumping speed
at low pressure and the newest state of the art
single channel controller



VIP Ion Pumps
IPCMini Controller

Market needs transform - the product evolves:

Agilent IDP Dry Scroll Pumps
Sustainable, quiet, oil-free vacuum



IDP Dry
Scroll Pumps

Learn more: www.agilent.com/chem/vacuum
© Agilent Technologies, Inc. 2018

Greetings

On behalf of the entire AVS community, we welcome you to the AVS 65th International Symposium and Exhibition (AVS 65) in beautiful Long Beach, California. We have an exciting slate of programming planned and wish you a productive and exciting week filled with discussions, new insights, and networking opportunities as you enjoy both the technical program and related activities.

This year's Symposium features a variety of topics, both time-honored and novel, across sixteen parallel sessions. The theme for this year is **“Materials, Interfaces and Process Technology for the IoT Era”** based on the predicted explosion of Internet of Things (IoT) devices in the coming years and promises to be more exciting and forward-looking than ever. We are very fortunate to have **Dr. Kim Chaffin**, Distinguished Scientist and Bakken Fellow in Strategic and Scientific Operations at Medtronic, plc, presenting the Plenary Lecture Monday evening on **“The Internet of Things: Shaping the Future of the Medical Device Industry.”** New for this year, we will also have a Plenary Panel, immediately following the Plenary Lecture to discuss the potential impact of IoT and areas of AVS engagement. Panelists include: **Dr. Scott Miller** – NextFlex, **Prof. Subu Iyer** – UCLA, **Dr. Enid Kivuti** – Multek Corp., **Prof. Michael Cima** – MIT, and **Prof. Gary Rubloff** – UMD, who will join Dr. Chaffin to field questions and engage with the AVS community.

Featured throughout the week, the IoT theme is also captured across nineteen different sessions programmed by our many Divisions, Groups and Focus Topics. An example of these sessions includes: **“Challenges of Sensor Manufacturing for the IoT,”** **“MEMS for IoT: Chemical and Biological Sensing,”** **“Thin Films for Flexible Electronics and IoT,”** **“CMOS, Beyond the Roadmap and Over the Cliff,”** **“Biofabrication, Bioanalytics, Biosensors and Diagnostics,”** **“Flexible Electronics,”** and **“Vacuum System Design and Automation.”** We are sure that you will gain new insights and knowledge as you enjoy these sessions.

In addition, the Symposium Program will include several special features. For example, the Plasma Science and Technology Division in collaboration with the Plasma Biology, Agriculture and Environment Focus Topic, will hold a special all-invited session on Monday afternoon titled **‘Plasma and Polymers: The Legacy of Riccardo d’Agostino and Beyond’** commemorating the Life and Career of Riccardo d’Agostino. On Tuesday Morning, the Applied Surface Science Division will host a special session celebrating Nicholas Winograd titled **“Applied Surface Science: From Electrochemistry to Cell Imaging, a Celebration of the Career of Nicholas Winograd,”** while the Thin Film Division will host a special session in honor of Paul Holloway titled **“Special Session in Honor of Paul Holloway: Luminescent Materials Growth, Synthesis and Characterization.”** Also on Tuesday Afternoon, the Applied Surface Science Division program will feature another special session in celebration of Barbara Garrison, titled **“The Impact of Modeling (Ion, Electron)**

and Data Analysis on Applied Surface Science, a Celebration of the Career of Barbara Garrison.” On Wednesday, there will be two special all-invited sessions (morning and afternoon) titled **“Current and Future Stars of the AVS Symposium”** and will feature presentations from **David G. Castner**, our AVS **Medard Welch Award** winner and **Peter Bruggeman**, our AVS **Peter Mark Award winner**, along with invited talks given by peer nominated ‘Future Stars’ of the AVS community. Moreover, we are honored to host the AIP sponsored **Industrial Physics Forum (IPF)** once again this year and have programming closely planned alongside the Biomaterial Interfaces Division beginning Sunday afternoon with the Bio Plenary session, and continuing throughout the week.

Finally, we also feature programming on cutting edge topical areas. Focus Topics that will be featured at this meeting include 2D Materials; Actinides and Rare Earths (2D); Fundamental Discoveries in Heterogeneous Catalysis (HC); Advanced Ion Microscopy (HI); Novel Trends in Synchrotron and FEL-Based Analysis (SA); Plasma Biology, Agriculture, and Environment (PB); Spectroscopic Ellipsometry (EL); and Tribology (TR). New Focus Topics include In-situ Microscopy, Spectroscopy and Microfluidics (MM); Processing and Characterization of Air-Liquid, Solid-Liquid and Air-Solid Interfaces (PC); Extending Additive Manufacturing to the Atomic Scale (AM); Reconfigurable Materials and Devices for Neuromorphic Computing (RM); Advanced Nanophotonics Metrology (AN), and Materials and Processes for Quantum Computing (MP). Lastly, all week there will be sessions across multiple divisions on Atomic Layer Processing, which highlight ongoing work in areas pertaining to the processing of materials with atomic scale precision, employing techniques such as Atomic Layer Deposition (ALD), Selective Deposition, and Atomic Layer Etching (ALE).

The result is an exciting program that has ~165 sessions, ~1,100 talks and ~270 invited speakers complemented by lively poster sessions on Tuesday and Thursday evenings (which include various poster presentation prizes). You will also be able to visit our extensive equipment and product exhibition, where the latest technology that enables cutting-edge research will be displayed.

Whether this is your first time at the AVS Symposium and Exhibition or you are returning, we invite you to take advantage of the many networking, professional development and recruitment events, as well as our AVS Member Center in Room 103C, where a variety of special AVS engagement activities and talks are planned. Thank you for participating in AVS 65 and being part of the AVS community!

Finally, we extend special thanks to all the dedicated volunteers and to the exceptional AVS Staff who worked long hours to create this exciting, world-class technical program and exhibition.

ENJOY THE WEEK!



Eric A. Joseph
2018 Program Chair
IBM Research Division, T.J. Watson Research Center



Mariadriana Creatore
2018 Program Vice-Chair
Eindhoven University of Technology, The Netherlands

TABLE OF CONTENTS

5K Run Information.....	24
Ask the Experts.....	49
AVS Sponsored/Endorsed 2019 Topical Conferences	239
AVS Member Center	18-22
AVS Store	25
AVS Membership Information	15
AVS Publication Information	61-65
ASTM E-42/ASSD Workshop.....	31
Author Index.....	170-192
AVS Awardees List – Past and Present.....	36-37
AVS Awardees – Current	39-41
AVS Corporate Members	34
AVS Officers and Directors.....	12
AVS Sponsors.....	32-33
AVS Staff.....	13
Biomaterial Interfaces Division Plenary Session & Reception	30
Career Center Information	29
Division Awards	42-43
Division, Group, & Focus Topic Chairs and Champions	8-9
Exhibit Hall Events and Exhibiting Companies	46-47
Exhibitor Technology Spotlight Sessions.....	48
EXHIBIT PROGRAM	193-236
Flash Networking Sessions.....	17
Floor Plan – Long Beach Convention Center.....	3, 72, 238
Floor Plan – Hyatt Regency Long Beach	69
Future Symposia Locations	239
Manuscript Publication Information	15
Meeting and Special Events.....	70-71
Mobile App Information	4-5, 14
Morton M. Traum Presentation	31
PacSurf 2019 Information.....	27
Plenary Lecture – Symposium	52
Past Presidents' Panel	50-51
Program Committee	10-11
Recording/Photo Policy	15-16
Code of Conduct	16
Session Overview	58-60
Symposium Registration, Cancellation, Lost Badge Procedures	15
Travel Information: Hotel, Cancellation Policies	16
TECHNICAL SESSIONS	76-169
Technical Program Description	53-57
Authors Index	170-192
Daily Special Events.....	77, 80, 98, 123, 143
Key to Session Codes	73
Program-at-a-Glance.....	6-7, 74-75
Sunday, Oct. 21.....	77-78
Monday morning, Oct. 22.....	81
Monday afternoon, Oct. 22	89
Tuesday morning, Oct. 23.....	99
Tuesday afternoon, Oct. 23	108
Wednesday morning, Oct. 24	124
Wednesday afternoon, Oct. 24.....	133
Thursday morning, Oct. 25	144
Thursday afternoon, Oct. 25	152
Friday morning, Oct. 26.....	166

Wi-Fi Login

Wi-Fi is available throughout the Convention Center



SSID: AVS

Username: AVS65

Password: longbeach

**** Username and Password are case sensitive. ****

SYMPORIUM

Long Beach Convention Center
300 E. Ocean Blvd.
Long Beach, CA 90802

HQ HOTEL

Hyatt Regency Long Beach
200 South Pine Avenue
Long Beach, CA 90802

AVS NATIONAL OFFICE

125 Maiden Lane, 15th Floor, 15B
New York, NY 10038
212-248-0200 FAX: 212-248-0245
avsnyc@avs.org www.avs.org

SYMPORIUM REGISTRATION HOURS

Sun. 2:00 p.m. to 6:00 p.m. Wed. 7:30 a.m. to 5:00 p.m.
Mon. 7:30 a.m. to 5:00 p.m. Thurs. 7:30 a.m. to 5:00 p.m.
Tues. 7:00 a.m. to 5:00 p.m. Fri. 7:30 a.m. to 10:00 a.m.

SYMPORIUM REGISTRATION FEES

	Pre-registration (Pre-Paid)	Registration (On-Site)
Member***	\$700.00	\$845.00
Non-Member**	\$825.00	\$995.00
Student Member*** *	\$230.00	\$280.00
Student Non-Member** *	\$270.00	\$330.00
Early Career Member*** *	\$350.00	\$425.00
Early Career Non-Member** *	\$415.00	\$505.00
Technical Specialist Member	\$330.00	\$400.00
Technical Specialist Non-Mem	\$375.00	\$455.00
One Day	\$415.00	\$505.00
Two Day	\$715.00	\$890.00
Exhibits Only	FREE	FREE

Pre-registration deadline: October 1, 2018

AVS tax ID Number: 04-2392373

*A bona fide full-time university student must present student I.D. Part-time students don't qualify for a student rate. If your highest degree is within 5 years, you may register as an Early Career.

**Non-member registration includes a complimentary 2019 AVS membership – stop by the AVS Member Center – Room 103C.

***Full Week, Student, Early Career & Technical Specialist member registration fee INCLUDES your 2019 membership renewal dues. For more information stop by the AVS Member Center – Room 103C.

EXHIBIT HOURS

Tuesday, October 23	10:00 a.m. to 5:00 p.m.
Wednesday, October 24	10:00 a.m. to 4:30 p.m.
Thursday, October 25	10:00 a.m. to 2:30 p.m.

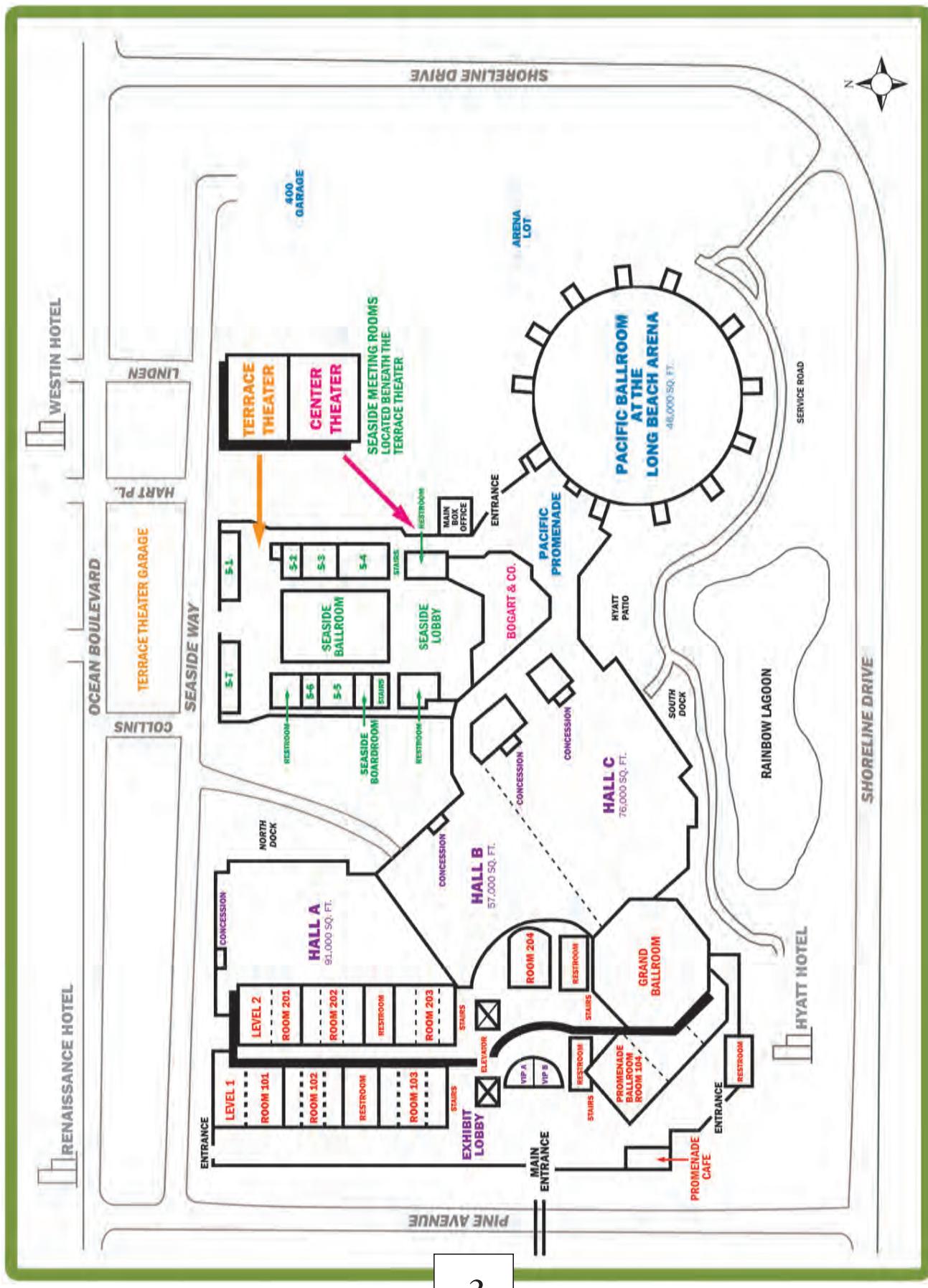
OFFICE LOCATIONS

AVS Publications	Booth #445
AVS Store	Booth #559
Presenters Preview Room	Room 103B
Staff Office & Press Room	Room 103A
Member Center	Room 103C
Program Office	Room 103A

Registration Area – Lobby

Exhibitor – Symposium – 5K Run

LONG BEACH CONVENTION CENTER



Download the AVS Events & Activities App

That Provides Year-round Access to AVS Publications, Technical Library, and Professional Development Activities and Contains Several AVS sponsored Conferences Event Apps



****From the AVS Events & Activities App
You May Download the AVS 65 App by
Choosing Select Your Event****



The AVS 65 Event App Allows Users to:

- ▶ Build your personal daily schedule
- ▶ Receive reminders and updates
- ▶ Engage and network with peers
- ▶ Find what you are looking for
- ▶ Take notes, bookmark, and filter
- ▶ Synchronize across your devices
- ▶ Access the conference program, schedule, or animated maps without WiFi
- ▶ Vote for your Favorite Poster in the PSTD Student Poster Award Competition



Start using the AVS 65 App

To login, please enter your Registration ID* and Last Name to access messaging, enable the synchronization of notes, favorites, and scheduled items between devices and the online planner.

*Your Registration ID can be found on your AVS 65 Confirmation/Receipt near the barcode.



**Get Your Game On...
Play the AVS 65 Scavenger Hunt Today!**



Login in using your reg ID and last name, check out the Hunt rules and task list. Complete as many tasks as possible throughout the week for the chance to earn points and **WIN GREAT PRIZES!**

Be sure to **CHECK THE LEADERBOARD** near the Member Center throughout the week to see how you are stacking up against the competition...

AVS 65 Technical Program

Room/ Day	101A	101B	102A	102B	103C MEMBER CTR/ PROF. DEV.	104A	104B	104C	201A
SuA		BP AVS BIP & AIP IPF Forum Plenary Session							
MoM	EM+ IoT Session: CMOS, Beyond the Roadmap and Over the Cliff	IPF+ Biofabrication: From Tissue to Organ	TF1 Precursors and Surface Reactions	NS+ IoT Session: Nanostructured Devices and Sensors	7:00 am Member Coffee 10:20 Demo: AVS Mobile Ap	PS+ Plasma-Surface Interactions	TF2 IoT Session: Thin Film Processes for Energy Storage	PS+ Plasma Deposition and Plasma- Enhanced ALD	TR+ Tribology Focus Session
MoA	EM+ ALP: Selective- Area Patterning (Assembly/Dep osition/Etching)	BI+ Advanced Imaging and Structure Determination of Biomaterials Research	TF+ Thin Films for Advanced Memory Apps and Magnetics	NS+ SPM - New Imaging and Spectroscopy Methodologies	12:15 Welcome to AVS/3:00 pm Speed Networking for Young Professionals	PS+ Plasma and Polymers: 'The Legacy of Riccardo d'Agostino and Beyond'	TF IoT Session: Thin Films for Photovoltaics		MI+ IoT Session: Symp. on new Mag. Mtls, Devices & Concepts for the Info Society
TuM	TF Emerging Applications for ALD	IPF+ Advanced Imaging and Structure Determination of Biomaterials	TF+ Special Session in Honor of Paul Holloway: Luminescent Materials	NS+ Nanophotonics, Plasmonics, and Metamaterials	7:00 am Member Coffee 9:00 Demo: eSpectra	PS+ Plasma Processing of Challenging Materials - I	TF+ Atomic Layer Processing: Area Selective Deposition	PS+ Plasma Medicine	HC+ Nanochemistry in Heterogeneous Catalysis
TuB					10:00 am MS Working with Government Labs and other User Facilities				
TuL					12:30 pm Job Information Forum & Lunch				
TuA	EM+ Solar/Energy Harvesting and Quantum Materials and Applications	BI+ IoT Session: Biofabrication, Bioanalytic, Biosensors and Diagnostics & Flash Session	TF+ Organic/ Inorganic Materials and Interfaces	NS+ SPM – Probing & Manipulating Nanoscale Structures	6:45 pm EMPD Forum "Careers at Lam Research"	PS+ Plasma Processing of Challenging Materials - II	TF+ ALP: Chemistry & Surface Reactions for ALP	PS+ Atmospheric Pressure Plasmas	HC+ A Tale of Two Scales: Catalytic Processes and Surface Science
TuP									
WeM	EM+ Surface and Interface Challenges in Electronics and Photonics	IPF+ IoT Session: Bioanalytic, Biosensors and Diagnostics	TF+ Thin Film Processes for Electronics and Optics I	AM+ Nanofabricatio n with Focused Electron Beams Atomic Scale Manipulation	7:00 am Member Coffee 10:00 am "Inclusion & Diversity at the Workplace"	PS+ Advanced Patterning	PS+ Current and Future Stars of the AVS Symposium I	PS+ IoT Session: Enabling IoT Era	HC+ Mech & React. Pathways of Heterogeneo. Catal. Reactions
WeL					12:30 pm Lunch & Learn "XPS for the Non-Analyst"				
WeA	EM+ Wide and Ultra-Bandgap Mtls for Elect Devices: Growth Modeling and Properties	BI Microbes and Fouling at Surfaces	TF+ Thin Film Processes for Electronics and Optics II	AM+ Atomic Scale Manipulation with SPM	3:00 pm Get Involved: Tips on How to Moderate & Lead Sessions	PB+ Plasma Agriculture & Environmental Applications	BI+ Current and Future Stars of the AVS Symposium II	PS+ Advanced BEOL/Interconn Etching	HC+ Theory & Dynamics of Heterogeneo. Catalyzed Reactions
ThM	EM+ Nanostructures for Electronic and Photonic Devices	BI Biomolecules and Biophysics at Interfaces	TF+ In-situ Charact. & Modeling of Thin Film Processes	NS+ Nanopatterning and Nano- fabrication	7:00 am Member Coffee 12:30pm "Improving Work-Life Satisfaction"	PS Plasma Sources	TF+ Deposition Processes for 3D and Extreme Geometries	PS+ Atomic Layer Processing: Atomic Layer Etching	HC+ In-situ Analysis of Heterogen. Catalyzed Reactions
ThA	EM+ IoT Session: Flexible Electronics & Flash Session	BI Biolubrication and Wear / Women in Bio- surface Science	SS+ Deposition, Etching and Growth at Surfaces	NS+ SPM – Probing Electronic and Transport Properties		PS Plasma Diagnostics, Sensors and Controls	TF+ IoT Session: Thin Films for Flexible Electronics and IoT	PS+ Atomic Layer Processing: Integration of ALD and ALE	HC+ Bridging Gaps in Hetero- geneously Catal. Reactions
ThP									
FrM		BI+ Characteriz. of Biological and Biomaterial Surfaces		NS+ SPM – Probing Chemical Reactions at the Nanoscale		PS Plasma Modeling			

at a Glance

201B	202A	202B	202C	203A	203B	203C	204	Hall A	Hall B
2D+ 2D Materials Growth and Fabrication	EL+ Application of SE for the Charact of Thin Films and Nanostructures	MM+ Mech, Elec Ther. Opt Syst for In situ TEMam/ Beam Ind Eff & Proc in Liquid/Gas	SE+ Nanostructure d Thin Films and Coatings	MP+ Systems and Devices for Quantum Computing I	VT Vacuum Measurement	SS+ Dynamical Processes at Surfaces	AS Quantitative Surface Analysis		
2D+ 2D Materials Characterizatio n including Microscopy and	EL+ Spectroscopic Ellipsometry: Novel Applications and	MM+ X-ray and Electron Spectrom. in Liquids & Gases & Flash Session	SE New Challenges and Opportunities in Surface Engineering	MP+ Systems and Devices for Quantum Computing II	VT Pumping and Outgassing	SS+ Theory and Modeling of Surfaces and Reactions	AS Multitechnique Applications- When More techniques are Better than		
2D+ Properties of 2D Materials including Elect, Mag, Mech, Optical, and Thermal	PC+ Solid-Liquid & Gas-Liquid Interfacial Proc & Charact.	MS+ IoT Session: Challenges of Neuromorphic Computing and Memristor	SE+ Plasma- assisted Surf. Modif & Dep. Processes	MP+ High Coherence Qubits for Quantum Computing	VT Large Vacuum Systems and Accelerator Vac Tech	SS+ Controlling Mechanisms of Surf. Chemical Reactions	AS+ From Electro to Cell Imaging, A Celeb of Nicholas Winograd		
								EW Exhibitor Technology Spotlight Session I	
								EW Exhibitor Technology Spotlight Session II	
2D+ 2D Device Physics and Applications	PC+ Progress in Industrial Proc. & Charact. of Int. and Gas- Solid Inter Proc & Char.	MS+ IoT Session: Challenges of Sensor Manufacturing for the IoT	SE Wear, Oxidation and Corrosion Protective Coatings	RM+ IoT Session: Reconfig. Mtls & Devices for Neuromorphic Computing	VT IoT Session: Vacuum Syst. Design & Autom. & Flash Session	SS+ Oxides/ Chalcogenides: Structures and Reactions	AS Impact of Mod (Ion, Elect Data Anal. on App Surf Sci a Celebration of B. Garrison	EW Exhibitor Technology Spotlight Session III	
									POSTER SESSIONS: AM, BI, EL, MM, MS, PB, PC, PS, RM, SE, SS, TR, VT
2D+ Dopants, Defects, and Interfaces in 2D Materials	PC+ Novel Approaches and Challenges of Interfaces	MN+ IoT Session: Multiscale Mfg: Enabling Mtls and Processes	AC+ Mag., Complexity, & Supercond in the Actinides & Rare Earths	NS+ Micro, Nano and Opto Mechanics	VT Vacuum Technology Developments	SS+ Catalytic Alloys: Understanding Heterogeneity	AS+ Beyond Traditional Surface Analysis	EW Exhibitor Technology Spotlight Session IV	
								EW Exhibitor Technology Spotlight Session V	
2D+ IoT Session: Surface Chemistry, Function, Bio and Sensor	SA+ Hard X- Ray Photoemission for Probing Buried Interfaces	MN+ IoT Session: MEMS for IoT: Chemical and Biological Sensing	AC+ Chemistry and Physics of the Actinides and Rare Earths	NS+ IoT Session: Bio at the Nanoscale	HI Novel Beam Induced Material Eng & Nano- Patterning	SS+ Semiconductin g Surfaces	AS+ Industrial and Practical App. of Surface Analysis		
2D+ Novel 2D Materials	SA+ Ultra- fast Dynamics for Magnetic and Quantum Systems	MN+ Opto- mechanics and 2D NEMS	AC+ Nuclear Power, Forensics, and Other Applications	MI+ Magnetism at the Nanoscale	HI+ Advanced Ion Microscopy & Surface Analysis	SS+ Defects in and Functionalizati on of 2D Materials	AS+ Applied Surf. Analysis of Novel, Complex or Challenging Materials		
2D+ Novel Quantum Phenomena in 2D Materials	SA+ IoT Session: Multi- modal Char. Energy Mtls & Device Processing	MN+ Nonlinear and Thermal Resonators	AC Early Career Scientists	MI+ Inter- disciplinary Magnetism	HI Emerging Ion Sources, Optics, and Applications	SS+ Organic/ Inorganic Surfaces, Interfaces and Nanostructures	AS+ Profiling, Imaging and Other Multi- dimensional Pursuits		
									POSTER SESSIONS: 2D, AC, AS, EM, HC, HI, MI, MN, NS, SA, TF
2D+ Nanostructures including Heterostruct. and Patterning of 2D Materials			AC+ AC & Rare Earth Theory & Related Measure	MI+ Magnetism and Spin-Orbit Coupling at Surf., Int., & Thin Films		SS+ Near/Ambient Pressure and Bridging Gaps bet Surface Sci & Catalysis			

DIVISION, GROUP, & FOCUS TOPIC CHAIRS & CHAMPIONS



Robert Franz
Advanced Surface Engineering (SE)



Michaeleen Pacholski
Applied Surface Science (AS)



Joe Baio
Biomaterial Interfaces & Biomater Plenary (BI/BP)



Rachael Myers-Ward
Electronic Materials & Photonics (EM)



Hendrik Ohldag
Magnetic Interfaces & Nanostructures (MI)



Sushma Kotru
MEMS/NEMS



Bridget Rogers
Manufacturing Science & Technology (MS)



Robert Ilic
Nanometer-scale Science & Technology (NS)



Ankur Agarwal
Plasma Science & Technology (PS)



Charlie Sykes
Surface Science (SS)



Paul Poodt
Thin Films (TF)



Gerardo Bruker
Vacuum Technology (VT)



Ivan Oleynik and Daniel Gunlycke
2D Materials



David Shuh and Jim Tobin
Actinides and Rare Earths (AC)



Dan Killelea and Ashleigh Baber
Fundamental Discoveries in Heterogeneous Catalysis (HC)



David Shuh and Jim Tobin
Actinides and Rare Earths (AC)

DIVISION, GROUP, & FOCUS TOPIC CHAIRS & CHAMPIONS



Maya Kiskinova, Olivier Renault and Zahid Hussain
Novel Trends in Synchrotron and FEL-Based Analysis (SA)

Tino Hofmann
Spectroscopic Ellipsometry (EL)

Rick Livengood
Advanced Ion Microscopy (HI)



Filippo Mangolini and David Schall
Tribology (TR)

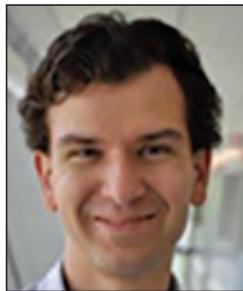
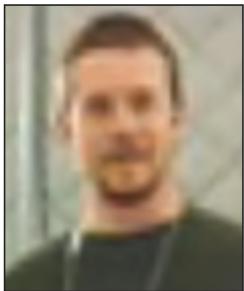
Hongxuan Guo, Alex Liddle and Andrei Kolmakov
In-situ Microscopy, Spectroscopy and Microfluidics (MM)



Xiao Ying Su and Stephen Nonnenmann
Processing and Characterization of Air-Liquid, Solid-Liquid and Air-Solid Interfaces (PC)

Rudy Ludeke and Sally McArthur
Industrial Physics Form

Deborah O'Connell
Plasma Biology, Agriculture, and Environment (PB)



Joshua Ballard and Ondrej Dyckoe
Extending Additive Manufacturing to the Atomic Scale (AM)

Nikolai Klimov
Advanced Nanophotonics Metrology (AN)

Brian Hoskins
Reconfigurable Materials and Devices for Neuromorphic Computing (RM)

Vivek Adiga
Materials and Processes for Quantum Computing (MP)

2018 PROGRAM COMMITTEE

ERIC A. JOSEPH, Program Chair

IBM Research Division, T.J. Watson Research Center
eric_joseph@avs.org

MARIADRIANA CREATORE, Program Vice-Chair

Eindhoven University of Technology, The Netherlands
mariadriana_creatore@avs.org

Della Miller, AVS Marcom & Events Manager

Yvonne Towse, AVS Managing Director/
Registration Coordinator

Angela Klink, AVS Program Editor/Member
Services Administrator

2D Materials

Co-Chair: Gunlycke, Daniel, Naval Research Lab.

Co-Chair: Oleynik, Ivan, University of South Florida

Batzill, Matthias, Univ. of South Florida

Chuang, Tien-Ming, Academia Sinica, Taiwan

Jauho, Antti-Pekka, Technical University of Denmark,
Denmark

Mo, Sung-Kwan, Lawrence Berkeley Lab, University of
California, Berkeley

Qian, Xiaofeng, Texas A&M University

Warner, Jamie, University of Oxford, UK

Xiao, Kai, Oak Ridge National Laboratory

Actinides and Rare Earths

Co-Chair: Shuh, David, Lawrence Berkeley National Lab.

Co-Chair: Tobin, James G., Univ. of Wisconsin-Oshkosh

Bagus, Paul, University of North Texas

Denecke, Melissa, University of Manchester, UK

Durakiewicz, Tomasz, Los Alamos National Laboratory

Geeson, David, AWE, UK

Havela, Ladislav, Charles Univ., Prague, Czech Republic

Nelson, Art, Lawrence Livermore National Laboratory

Rosa, Priscila, Los Alamos National Lab.

Vitova, Tonya, Karlsruhe Institute of Technology, Germany

Advanced Ion Microscopy

Chair: Livingood, Richard, Intel Corporation, USA

Götzhäuser, Armin, Bielefeld University, Germany

Hlawacek, Gregor, Helmholtz Zentrum Dresden-Rossendorf,
Germany

Notte, John A., Carl Zeiss Microscopy, LLC

Ogawa, Shinichi, National Institute of Advanced
Industrial Science and Technology (AIST), Japan

Ovchinkova, Olga, Oak Ridge National Laboratory

Advanced Nanophotonics Metrology

Chair: Klimov, Nikolai, National Institute of Standards
and Technology

Ahmed, Zeehan, National Institute of Standards and
Technology

Goldsmith, Randall, University of Wisconsin-Madison

Ilic, Robert, NIST

Advanced Surface Engineering

Chair: Franz, Robert, Montanuniversität Leoben, Austria

Klemberg-Sapieha, Jolanta, Ecole Polytechnique de
Montreal, Canada

Kodambaka, Suneel, University of California at Los Angeles

Lin, Jianliang, Southwest Research Institute

Panjan, Matjaz, Jozef Stefan Institute, Slovenia

Voevodin, Andrey, University of North Texas

Applied Surface Science

Chair: Pacholski, Michael, The Dow Chemical Co.

Co-Chair: Artyushkova, Kateryna, University of New

Mexico

Brumbach, Michael, Sandia National Labs.

Engelhard, Mark, Pacific Northwest National Laboratory

Fenton, Jeffrey, Medtronic

Fisher, Gregory L., Physical Electronics

Gaskell, Karen, University of Maryland, College Park

Grehl, Thomas, IONTOF GmbH, Germany

Haasch, Richard, Frederick Seitz Materials Research Lab.

Lerach, Jordan, The Pennsylvania State University

Matthews, Tamlin, Two Pore Guys, Inc.
Nunney, Tim, Thermo Fisher Scientific, UK
Ohlhausen, James, Sandia National Labs
Pylypenko, Svitlana, Colorado School of Mines
Spool, Alan, Western Digital Corporation

Biomaterial Interfaces

Chair: Baio, Joe, Oregon State University
Carroll, Nick, University of New Mexico
Graham, Dan, University of Washington
Howell, Caitlin, University of Maine
Leggett, Graham, University of Sheffield, UK
Rosenhahn, Axel, Ruhr-University Bochum, Germany
Theilacker, Bill, Medtronic
Valtiner, Markus, Vienna University of Technology, Austria
Weidner, Tobias, Aarhus University, Denmark

Biomaterials Plenary Session

Chair: Baio, Joe, Oregon State University

Electronic Materials & Photonics

Chair: Myers-Ward, Rachael, U.S. Naval Research Lab.
Abate, Yohannes, Georgia State University
Antonelli, Andy, Nanometrics
Biyikli, Necmi, University of Connecticut
Dietz, Nikolaus, Georgia State University
Douglas, Erica, Sandia National Laboratories
Filler, Michael, Georgia Institute of Technology
Gupta, Shalini, Northrop Grumman ES
Han, Sang M., University of New Mexico
Hanbicki, Aubrey, Naval Research Laboratory
Hilton, Jessica, RHK Technology
Kapadia, Rehan, University of Southern California
Kawasaki, Jason, University of Wisconsin – Madison
Kim, Hyun Jung, NASA Langley
King, Sean, Intel Corporation
King, Seth, University of Wisconsin – La Crosse
Kummel, Andrew, University of California at San Diego
Paquette, Michelle, University of Missouri-Kansas City
Rockett, Angus, Colorado School of Mines
Strandwitz, Nicholas, Lehigh University
Tischler, Joseph, U.S. Naval Research Laboratory
Tsai, Wilman, Taiwan Semiconductor Manufacturing
Company (TSMC)

Extending Additive Manufacturing to the Atomic Scale

Co-Chair: Ballard, Joshua, Zvex Labs
Co-Chair: Dyckoe, Ondrej, Oak Ridge National Lab.
Felts, Jonathan, Texas A&M University
Namboodiri, Pradeep, National Institute of Standards and
Technology
Rack, Philip, Univ. of Tennessee Knoxville
Ramassee, Quentin, University of Leeds, UK, United
Kingdom of Great Britain and Northern Ireland
Susi, Toma, University of Vienna, Austria

Fundamental Discoveries in Heterogeneous Catalysis

Co-Chair: Baber, Ashleigh, James Madison University
Co-Chair: Killelea, Daniel, Loyola University Chicago
Chen, Donna, University of South Carolina
Jackson, Bret, University of Massachusetts – Amherst
Kimmel, Greg, Pacific Northwest National Laboratory
Roy, Sharani, University of Tennessee
Sykes, E. Charles, Tufts University
Utz, Arthur, Tufts University
Weaver, Jason, University of Florida

Industrial Physics Forum

Co-Chair: Ludeke, Rudy, IBM Emeritus
Co-Chair: McArthur, Sally, Swinburne University of
Technology and CSIRO, Australia
Alexander, Morgan, University of Nottingham
Bardi, Jason, American Institute of Physics
Belu, Anna, Medtronic
Bentley, William, University of Maryland College Park
Castner, David, University of Washington

Graham, Dan, University of Washington
Hammer, Bo, American Institute of Physics
Hollenhorst, Jim, Agilent Technologies

In-Situ Microscopy, Spectroscopy, and Microfluidics

Co-Chair: Guo, Hongxuan, National Institute of Standards
and Technology
Co-Chair: Kolmakov, Andrei, NIST Center for Nanoscale
Science and Technology
Co-Chair: Liddle, Alexander, National Institute of
Standards and Technology
Damiano, John, Protochips Inc.
Hitchcock, Adam, McMaster University
Kelly, Deborah, Virginia Tech Carilion Research Inst.
Mølhave, Kristian, Technical University of Denmark
Stach, Eric, University of Pennsylvania

Magnetic Interfaces and Nanostructures

Chair: Ohldag, Hendrik, SLAC National Accelerator Lab.
Baio, Joe, Oregon State University
Donath, Markus, Westfälische Wilhelms-Universität
Münster, Germany
Enders, Axel, University of Bayreuth, Germany
Hanbicki, Aubrey, Naval Research Laboratory
Hoffmann, Axel, Argonne National Laboratory
Kukreja, Roopal, University of California at Davis
Lauter, Valeria, Oak Ridge National Lab.
Lukaszew, Ale, College of William and Mary
Mueller, Martina, Forschungszentrum Juelich GmbH,
Germany
Myers-Ward, Rachael, U.S. Naval Research Lab.
Oleynik, Ivan, University of South Florida
Woltersdorf, Georg, Martin Luther University Halle-
Wittenberg, Germany
Wu, Ruqian, Univ. of California Irvine

Manufacturing Science and Technology

Chair: Rogers, Bridget, Vanderbilt University
Diebold, Alain C., Colleges of Nanoscale Science and
Engineering, SUNY Polytechnic Institute
Lad, Robert, University of Maine
Rubloff, Gary, University of Maryland, College Park
Seebauer, Edmund, University of Illinois at Urbana-
Champaign
Smentkowski, Vincent, General Electric Global Research
Center
Svedberg, Erik B., The National Academies

Materials and Processes for Quantum Computing

Chair: Adiga, Vivekananda, IBM Research Division,
T.J. Watson Research Center
Brink, Markus, IBM Research Division, T.J. Watson
Research Center
Ilic, Bojan, Robert, NIST
Mutus, Josh, Google Inc
Paik, Hanhee, IBM Research Division, T.J. Watson
Research Center
Sandberg, Martin, IBM Research Division, T.J. Watson
Research Center
Yoder, Jonilyn, MIT Lincoln Laboratory

MEMS and NEMS

Chair: Kotru, Sushma, The University of Alabama
Co-Chair: Davis, Robert, Brigham Young University
Blain, Matthew, Sandia National Laboratory
Burkett, Susan, The University of Alabama
Dhayal, Marshal, CSIR Centre for Cellular and Molecular
Biology (CCMB), India
Diao, Zhu, Halmstad University/Stockholm University,
Sweden
Feng, Philip, Case Western Reserve University
Ghodssi, Reza, University of Maryland, College Park
Gousev, Evgeni, Qualcomm MEMS Technologies, Inc.
Hanay, Selim, Bilkent University, Turkey
Hentz, Sébastien, Cea Leti, France

2018 PROGRAM COMMITTEE

Hiebert, Wayne, National Institute for Nanotechnology, Canada

Ilic, Robert, NIST

Krylov, Slava, Tel Aviv University, Israel

Maboudian, Roya, University of California at Berkeley

Metzler, Meredith, University of Pennsylvania

Naik, Akshay, Indian Institute of Science, India

Ng, Tse Nga (Tina), University of California at San Diego

Suman, Anirudha, Argonne National Lab.

Thundat, Thomas, Univ. of Alberta, The National Institute for Nanotechnology, Canada

Tian, Wei-Cheng, National Taiwan University, Taiwan, Republic of China

Wang, Max Zenghui, University of Electronic Science and Technology of China

Zorman, Christian, Case Western Reserve University

Nanometer-scale Science and Technology

Chair: Ilic, Robert, NIST

Chair: Kalinin, Sergei, Oak Ridge National Laboratory

Co-Chair: Cohen, Sidney, Weizmann Institute of Science, Israel

Ballard, Joshua, Zyvex Labs

Borovsky, Brian, St. Olaf College

Burnham, Nancy, Worcester Polytechnic Institute

Czaplewski, David, Center for Nanoscale Materials,

Argonne National Lab.

First, Phillip, Georgia Institute of Technology

Hanbicki, Aubrey, Naval Research Laboratory

Kim, Tae-Hwan, Pohang University of Science and Technology, Republic of Korea

Li, An-Ping, Oak Ridge National Laboratory

Seshadri, Indira, IBM Research Division, Albany, NY

Sharma, Renu, NIST

Ventrice, Jr., Carl, SUNY Polytechnic Inst.

Novel Trends in Synchrotron and FEL-Based Analysis

Co-Chair: Hussain, Zahid, Advanced Light Source, Lawrence Berkeley National Laboratory

Co-Chair: Kiskinova, Maya, Elettra-Sincrotrone Trieste, Italy

Co-Chair: Renault, Olivier, CEA/LETI-University Grenoble Alpes, France

Carla, Francesco, ESRF

Fadley, Charles, Univ. of California, Davis

Liu, Zhi, ShanghaiTech University, China

Molodtsov, Serguei, XFEL, Germany

Rossnagel, Kai, Kiel University, Germany

Schneider, Claus Michael, Peter Gruenberg Institute, Forschungszentrum Juelich GmbH, Juelich, Germany

Ueda, Shigenori, NIMS

Plasma Biology, Agriculture, and Environment

Chair: O'Connell, Deborah, University of York, UK

Agarwal, Ankur, KLA-Tencor

Graves, David, University of California at Berkeley

Hamaguchi, Satoshi, Osaka University, Japan

Mededovic Thagard, Selma, Clarkson University

Park, Gyungsoon, Kwangwoon Univ., Republic of Korea

Reniers, Francois, Université Libre de Bruxelles

Plasma Science and Technology

Chair: Agarwal, Ankur, KLA-Tencor

Agarwal, Sumit, Colorado School of Mines

Despiau-Pujo, Emilie, LTM, Univ. Grenoble Alpes, CEA-LETI, France

George, Steven, University of Colorado at Boulder

Gordon, Michael, Univ. of California at Santa Barbara

Hayashi, Hisataka, Toshiba, Japan

Johnson, Erik V., LPICM, Ecole Polytechnique, France

Kanarik, Keren, Lam Research

Koga, Kazunori, Kyushu University, Japan

Lishan, David, Plasma-Therm LLC

Maeda, Kenji, Hitachi High Technologies America Inc.

O'Connell, Deborah, University of York, UK

Pargon, Erwine, CNRS-LTM, Université Grenoble Alpes, France

Ranjan, Alok, Tokyo Electron Miyagi Limited, Japan

Reniers, Francois, Université Libre de Bruxelles

Samukawa, Seiji, Tohoku University, AIST, Japan

Sankaran, Mohan, Case Western Reserve University

Shearer, Jeffrey, IBM Research Division, Albany, NY

Sriraman, Saravanapriyan, Lam Research Corporation

Tatsumi, Tetsuya, Sony Semiconductor Solutions

Corporation, Japan

Van de Sanden, Richard, DIFFER, Netherlands

Vasquez Jr., Magdaleno, University of the Philippines, Philippines

Vitale, Steven, MIT Lincoln Laboratory

Walton, Scott, Naval Research Laboratory

Wang, Mingmei, TEL Technology Center, America, LLC

Yeom, GeunYoung, Sungkyunkwan University, Republic of Korea

Processing and Characterization of Air-Liquid, Solid-Liquid and Air-Solid Interfaces

Co-Chair: Kolmakov, Andrei, NIST Center for Nanoscale Science and Technology

Co-Chair: Nonnenmann, Stephen, University of Massachusetts – Amherst

Co-Chair: Yu, Xiao-Ying, Pacific Northwest National Laboratory

Baer, Donald, Pacific Northwest National Laboratory

Pacholski, Michaeleen, The Dow Chemical Company

Reconfigurable Materials and Devices for Neuromorphic Computing

Chair: Hoskins, Brian, NIST Center for Nanoscale Science and Technology

Adam, Gina, Institute for Microtechnologies, Romania

Ilic, Bojan Robert, NIST

Madhavan, Advait, National Institute of Standards and Technology, Center for Nanoscale Science and Technology

Skowronski, Marek, Carnegie Mellon University

Spectroscopic Ellipsometry

Chair: Hofmann, Tino, University of North Carolina at Charlotte

Co-Chair: Diebold, Alain C., Colleges of Nanoscale Science and Engineering, SUNY Polytechnic Institute

Co-Chair: Zollner, Stefan, New Mexico State University

Aspnes, David, North Carolina State University

Creatore, Mariadriana, Eindhoven University of Technology, The Netherlands

Hilfiker, James, J.A. Woolam Co., Inc.

Hingerl, Kurt, University Linz, Austria

Liu, Shiyuan, Huazhong University of Science and Technology, China

Surface Science

Chair: Sykes, Charles, Tufts University

Arnadottir, Liney, Oregon State University

Bartynski, Robert, Rutgers, The State Univ. of New Jersey

Chen, Donna, University of South Carolina

Juurlink, Ludo, Leiden Institute of Chemistry, The Netherlands

Kay, Bruce D., Pacific Northwest National Lab.

Koel, Bruce, Princeton University

Mullins, David, Oak Ridge National Laboratory

Parkinson, Gareth, TU Wien, Austria

Reinke, Petra, University of Virginia

Tait, Steven, Indiana University

Teplyakov, Andrew, University of Delaware

Utz, Arthur, Tufts University

Thin Film

Chair: Poot, Paul, Holst Centre / TNO, Netherlands

Adams, David, Sandia National Laboratories

Akyildiz, Halil, Uludag University, Turkey

Allred, David, Brigham Young University

Becker, Joe, Kurt J. Lesker Company

Cansizoglu, Hilal, University of California, Davis

Cavanagh, Andrew, University of Colorado Boulder

Conley, John, Oregon State University

Creatore, Mariadriana, Eindhoven University of Technology, The Netherlands

Fitz-Gerald, James, University of Virginia

George, Steven, University of Colorado at Boulder

Grubbs, Robert, Micron Technology

Guisinger, Nathan, Argonne National Lab.

Gupta, Subhadra, University of Alabama

Jur, Jesse, North Carolina State University

Kachian, Jessica, Applied Materials

Kalanyan, Berc, National Institute of Standards and Technology

Kessels, Erwin, Eindhoven University of Technology, The Netherlands

Kumah, Divine, North Carolina State University

Lewis, Jay, RTI International

Linford, Matthew, Brigham Young University

Loeggering, Mark, Georgia Institute of Technology

Mei, Antonio, University of Illinois at Urbana-Champaign

Muscat, Anthony, University of Arizona

Nejati, Siamak, University of Nebraska-Lincoln

Owen, Allen, University of Alabama

Parsons, Gregory, North Carolina State University

Pedersen, Henrik, Linköping University, Sweden

Peng, Qing, University of Alabama

Rieth, Loren, University of Utah

Scarel, Giovanna, James Madison University

Sobczak, Cathy, Sandia National Labs

Stiff-Roberts, Adrienne, Duke University

Vallee, Christophe, LTM, Univ. Grenoble Alpes, CEA-LETI, France

Vanfleet, Richard, Brigham Young Univ.

Wang, Xudong, University of Wisconsin-Madison

Wheeler, Virginia, U.S. Naval Research Laboratory

Yanguas-Gil, Angel, Argonne National Laboratory

Yu, Cunjiang, University of Houston

Zuijhof, Han, Wageningen University, Netherlands

Tribology

Co-Chair: Mangolini, Filippo, The University of Texas at Austin

Co-Chair: Schall, J. David, Oakland University

Vacuum Technology

Chair: Brucker, Gerardo, MKS Instruments, Inc., Pressure and Vacuum Measurement Group

Co-Chair: Borichevsky, Steve, Applied Materials, Varian Semiconductor Equipment

Carter, Jason, Argonne National Laboratory

Hendricks, Jay, National Institute of Standards and Technology

Fedchak, James, National Institute of Standards and Technology

Lanza, Giulia, SLAC National Accelerator Laboratory

Li, Yulin, Cornell University

Lushtak, Yevgeniy, SAES Getters USA

Peacock, Neil, Consultant

Ricker, Jacob, National Institute of Standards and Technology

Scherschligt, Julia, NIST

Stutzman, Marc, Thomas Jefferson National Accelerator Facility

Valente Feliciano, Anne Marie, Thomas Jefferson National Accelerator Facility

Van Drie, Alan, Tri Alpha Energy, Inc.

Wüest, Martin, INFICON Ltd., Liechtenstein

Exhibitor Technology Spotlight

Chair: DeGennaro, Jeannette, AVS Exhibition Sales Manager

2018 OFFICERS AND DIRECTORS



PRESIDENT

Lisa M. Porter
Carnegie Mellon University
Materials Science & Eng
5000 Forbes Avenue
Pittsburgh, PA 15213
Tel: 412-268-4047
E-mail: lisa_porter@avs.org

PRESIDENT-ELECT

Peter Sheldon
National Renewable Energy Laboratory
15013 Denver West Parkway
Golden, CO 80401
Tel: 303-384-6533
E-mail: peter_sheldon@avs.org



Joe Greene, Clerk/Secretary
University of Illinois,
Urbana-Champaign



Gregory J. Exarhos, Treasurer
Pacific Northwest
National Laboratory



Charles R. "Chip" Eddy, Jr.,
Immediate Past-President
U.S. Naval Research Laboratory



Anna Corinne D'Ambrosio
VON ARDENNE North America, Inc.



Lara Gamble, Director
University of Washington



Richard T. Haasch, Director
University of Illinois



Jay Hendricks, Director
NIST



Eric A. Joseph, Director
IBM TJ Watson Research Center



Sean L. Jones, Director
National Science Foundation

AVS STAFF



Yvonne Towse
Managing Director
NY Office



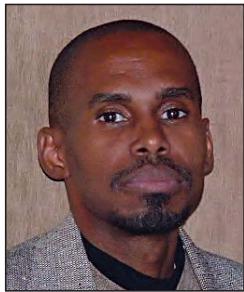
Jeannette DeGennaro
Exhibition & Sales
Manager - NY Office



Ricky Baldeo
Office Services Coordinator
NY Office



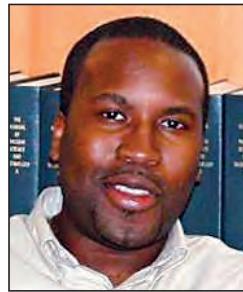
Teddy Bhabikhan
Web Content Coordinator
NY Office



Peter Burke
Financial Administrator
NY Office



Angela Klink
Member Services
Administrator - NY Office



Keith Mitchell
IT Systems/Web
Administrator - NY Office



Della Miller
Marketing Communications /
Events Manager - CA Office



Heather Korff
Events / Office
Coordinator - CA Office



Nancy Schultheis
Publications Office
Manager - NC Office



April Power
Editorial Assistant
NC Office



Rachel Smith
Editorial Assistant
NC Office



Tonya Yandle
SSS Editorial Assistant
NC Office



Jennifer Schreiner
Biointerphases
Editorial Assistant
NC Office

GENERAL INFORMATION



Credit: Beach and Skyline-6-29-08 by Bob Magenin

AVS 65 Mobile App!

The AVS 65 Event mobile app serves as your all-in-one event guide – giving you everything you need to know in the palm of your hand. To login, please enter your Registration ID and Last Name to access messaging, enable the synchronization of notes, favorites, and scheduled items between devices and the online planner. Please contact AVS65app@avs.org should you need any assistance using the App. You can also stop by the Registration desk and be sure to visit the Member Center for a Mobile App demo on Monday 22, 2018 October at 10:20 a.m.

Be sure to use the app to play the AVS65 Scavenger Hunt and vote for your favorite PSTD Student Poster (see more info on the next page).

Wi-Fi Login

Wi-Fi is available throughout the Convention Center



SSID: AVS

Username: AVS65

Password: longbeach

**** Username and Password are case sensitive ****

Stay Connected Year Around on Social Media

Did you know that AVS has several social media pages? We encourage you to expand your network and share your experiences or check regularly to stay abreast of the latest AVS activities and benefits—read the latest trending articles or learn more about AVS publications. Use #AVS65 in your Tweets this week to share your favorite parts of the meeting or to further scientific discussions. Links to the AVS social media pages can be found on the AVS 65 Mobile app or here are the links:

Twitter: @AVS_Members – @JVSTAB – @biointerphases – @AVSALD

Facebook: www.facebook.com/AVS-143182759040976/

Linked in: <https://www.linkedin.com/groups/1309457>

Instagram: https://www.instagram.com/avs_events/

EXCITING 2018 EVENTS

Plenary Lecture & Panel Discussion

“The Internet of Things: Shaping the Future of the Medical Device Industry,” by Dr. Kim Chaffin – Distinguished Scientist and Bakken Fellow in Strategic and Scientific Operations at Medtronic, plc., Monday, October 22, 5:00–6:00 pm, Grand Ballroom, followed by a special Plenary Panel Discussion from 6:15–7:00 p.m.

Welcome Mixer for Attendees & Exhibitors

The Welcome Mixer will immediately follow the Plenary Panel Discussion on Monday, October 22, from 7:00 p.m.–8:30 p.m. The Mixer is a casual gathering where attendees and exhibitors can enjoy some refreshments and spend time together prior to the opening of the Exhibit Hall.

AVS Member Center – Room #103C

Stop by the Member Center throughout the week to participate in professional development activities, diversity and educational events. Learn about the advantages and benefits of AVS membership and find out how to get more involved in Society events and activities. We will also be showcasing and demonstrating various membership benefits and all attendees are welcome to stop in to participate in our scheduled events, ask questions, or just have a place to meet and network with other attendees. 2018 Members, remember to bring your membership card.

AVS Store – Booth #559, Exhibit Hall

Official AVS logo items including graphic tees and other merchandise will be available for purchase throughout the week.

AVS Career Center – Booth #162, Exhibit Hall:

Looking for a position or seeking qualified candidates for a job opening? If so, please register at the AVS Career Center located in the Exhibit Hall.

Publications Booth – Booth #445, Exhibit Hall

Come meet with the AVS Journal editors, find out how to submit a manuscript, learn about exciting developments in all AVS Journals, and new Journal products and features coming soon.

Art Zone – Booth #543, Exhibit Hall

See the entries into the 2018 art contest and vote for your favorites. Winners will take home cash prizes!

Exhibit Hall Refreshment Breaks

Visit the Exhibit Hall during the morning and afternoon technical session breaks. There will always be something special being offered in the Hall.

Complimentary Lunches in the Exhibit Hall

Full week attendees who pay for a full week registration (Full, Student, Early Career, Technical Specialist and Exhibitors) will receive three free lunch vouchers redeemable on Tuesday, Wednesday, and Thursday for lunch located in the Exhibit Hall. Stop by the Exhibit Hall between 12:20–2:20 p.m. to grab a bite to eat and network with exhibitors and fellow colleagues. Come to the Exhibit Finale on Thursday for your free lunch!

AVS Raffle Zone – Booth #563, Exhibit Hall

Be sure to enter your raffle tickets to participate in the daily raffles being held Tuesday-Thursday in the Exhibit Hall Raffle Zone! Thanks to our generous sponsors we have some really exciting prizes this year!

Special Events Booth – Booth #427, Exhibit Hall

Visit the special events booth for special treats and giveaways.

E-Mail Pavilion – Booth #146

Check your e-mail, confirm your flights, print your boarding passes.

AVS 65 Scavenger Hunt – (Mobile App Event)

While attending AVS 65, be sure to join our AVS 65 Scavenger Hunt where you will have the opportunity to earn points and win Great prizes for participating in various AVS 65 events and completing special tasks. Keep your eye on the app for more details.

PSTD Student Poster Award Competition – (Mobile App Event)

Use the Mobile App to vote for your favorite PSTD Student Poster during the Tuesday, 10/23/18, 6:30–8:30 pm Poster Session in Hall B. Look for posted instructions on all eligible posters and help your favorite poster win \$200!

Symposium Registration Cancellation Policy

All cancellations must be sent in writing to Yvonne Towse by **October 1, 2018** (yvonne@avs.org) for a full refund less \$100 or \$50 for Students/Early Career/Technical Specialist/One Day cancellation fee. After that date AVS will only issue credits for AVS 66 with a valid reason. No refunds or credits for no shows. Please note that all refunds will be processed within 30 days following the meeting.

Terms & Conditions

- You will be charged for all registrations received.
- A \$20 fee will be charged for all returned checks.
- No Purchase Orders will be accepted.
- All registration fees are **NON-TRANSFERABLE**.
- Children must be accompanied by a parent or a guardian during exhibit hours. Under no circumstances are children under the age of 12 (including infants and toddlers) permitted on the exhibit floor.

Symposium Lost Badge Policy

Please note that we will be imposing a \$20 fee for replacement badges so please remember to bring your badge and keep it in a safe place throughout the week.

YOU MUST HAVE YOUR BADGE AND BADGE HOLDER TO GAIN ADMISSION TO THE TECHNICAL SESSIONS AND EXHIBITION.

AVS Membership Renewal Feature

The 2019 membership renewal dues will be included within the symposium registration fees for all Full, Student, Early Career, and Technical Specialist members. No further action will be required and 2019 membership will take effect on January 1, 2019. Any questions, see Angela Klink at the AVS Member Center (Room 103C).

Manuscript Publication Information

Journal of Vacuum Science & Technology A & B

Biointerphases

Authors are invited to submit an article to **JVST A**, **JVST B** or **Biointerphases** on the topic of their presentation/poster given at the AVS International Symposium. **You can choose either JVST A, JVST B or Biointerphases depending on the topic.** You can find easy to use templates and instructions for authors at <http://avs.scitation.org/jva/authors/manuscript>, <http://avs.scitation.org/jvb/authors/manuscript> and <http://avs.scitation.org/bip/authors/manuscript>. For more information, stop by the AVS Publications Booth 445 in the Exhibit Hall during the week of the Symposium or contact:

Nancy Schultheis
AVS Publications Office
51 Kilmayne Drive, Suite 104
Cary, NC 27511
Phone: 919-361-2787
Email: publications@avs.org

Complimentary AVS Membership Offer

If you have paid the Full, Student, Early Career, or Technical non-member registration fee, you will receive a complimentary AVS electronic membership for 2019. For more information, see Angela Klink at the AVS Member Center (Room 103C).

Recording/Photo Policy

RECORDING OF PRESENTATIONS IS STRICTLY PROHIBITED.

No individual or entity—including a presenting author—may electronically record or broadcast any portion of the AVS Meeting without prior written consent of AVS. Unauthorized recording (audio, video, still photography, etc.) of presentations during sessions, posters, workshops, etcetera, without the express written consent of AVS and individual authors is strictly prohibited. Press representatives must receive a Press Pass and photo/recording permission from AVS. AVS reserves the rights to any approved audio and video production of presentations at all AVS events.

PHOTO POLICY

Attendees or exhibitors are encouraged to network and enjoy the meeting experience. As such, capturing memories of casual meeting activities and networking is permitted with the permission of those being prominently photographed. Photographing formal

GENERAL INFORMATION

meeting presentations, posters, or displays is forbidden without permission of AVS and the presenter.

VIDEOS AND PHOTOS FOR AVS USE

AVS Meeting attendance implies your consent to be photographed, filmed and/or otherwise recorded for use on the AVS website or news publications. Please note that no technical presentations will be recorded without prior consent of AVS and the authors.

***Those who do not comply with the AVS Recording Equipment/Photo policy may be asked to leave the premises.**

Additional Notes for Presenters

AVS will provide Windows laptop computers running Windows 10 Pro and MS Office 2013, screens, microphones, and projectors in all session rooms, as well as an HDMI connection from podium to projector. **We encourage you to use the system and to test your presentation on our equipment in our Presenter's Preview Room 103B at the Long Beach Convention Center prior to your talk.** Please allow ample time for this; preferably the day before you are scheduled to present – not immediately before your talk. If you are using the AVS-provided computer, please load your presentation on to this computer at least five minutes prior to the start of the session or during a session break. The Preview Room will be open on Sunday, for those of you with Sunday afternoon or Monday presentations. In deference to all our presenters, it is important that personal computer/projector compatibility issues be worked out well in advance of your presentation. Please note that PowerPoint is the recommended presentation software and the preferred format is 16:9, wide format screens. The projector is expected to be compatible with both PCs and MACs; however, please bring any necessary adapters/dongles as well as a copy of your presentation on a flash drive as a back-up.

Code of Conduct for AVS Meetings

It is the policy of the American Vacuum Society (AVS) that all participants, including attendees, vendors, AVS staff, volunteers, and all other stakeholders at AVS meetings will conduct themselves in a professional manner that is welcoming to all participants and free from any form of discrimination, harassment, or retaliation. Participants will treat each other with respect and consideration to create a collegial, inclusive, and professional environment at AVS Meetings. Creating a supportive environment to enable scientific disclosure at AVS meetings is the responsibility of all participants.

Participants will avoid any inappropriate actions or statements based on individual characteristics such as age, race, ethnicity, sexual orientation, gender identity, gender expression, marital status, nationality, political affiliation, ability status, educational background, or any other characteristic protected by law. Disruptive or harassing behavior of any kind will not be tolerated. Harassment includes but is not limited to inappropriate or intimidating behavior and language, unwelcome jokes or comments, unwanted touching or attention, offensive images, photography without permission (see recording and photo policy), and stalking.

Violations of this code of conduct policy should be reported to the AVS Manager Director (Registration Area) or Events Manager (Staff Office 103A). Sanctions may range from verbal warning, to

ejection from the meeting without refund, to notifying appropriate authorities. Retaliation for complaints of inappropriate conduct will not be tolerated. If a participant observes inappropriate comments or actions and personal intervention seems appropriate and safe, they should be considerate of all parties before intervening.

Hotel Reservations

Reservations (Opens: July 6, 2018; Closes: September 27, 2018)

Hotel	Room Rates	Parking
Hyatt Regency Long Beach (Headquarters) 200 South Pine Avenue Long Beach, CA 90802	Single/Double: \$210-\$220	Parking: \$29 overnight valet \$26 self-parking overnight
Renaissance Long Beach 111 East Ocean Boulevard Long Beach, CA 90802	Single/Double: \$220	Parking: \$30 overnight valet \$24 self-parking overnight
Hilton Long Beach 701 W. Ocean Blvd. Long Beach, CA 90831	Single/Double: \$199	Parking: \$28 overnight valet \$22 self-parking overnight
Courtyard Long Beach 500 East First Street Long Beach, CA 90802	Single/Double: \$199	Parking: \$29 overnight valet \$25 self-parking overnight

Reservation Cancellation for Attendees

Reservations can be cancelled without penalty up to 72 hours prior to the day of arrival. Failure to arrive on your confirmed arrival date will result in one night's room & tax charged to the credit card provided and your entire reservation will be cancelled. A credit card is required to guarantee your reservation. Cancellations can be made via the website or via e-mail, avs@experient-inc.com until 11:00 pm EST on September 27, 2018. Please contact the hotel directly after October 10, 2018, for all cancellations and changes. Please do not call the hotel prior to October 10, 2018, as the hotel may not have record of your reservation.

Reservation Cancellation for Exhibitors

Due to hotel stipulations, a minimum number of blocked rooms must be utilized by the AVS; therefore, the FINAL day to cancel your reservation without penalty is 5:00 p.m. EST on August 31, 2018. Reservations cancelled AFTER 5:00 p.m. EST on August 31, 2018, will be assessed a cancellation fee equal to one night's room and tax per reservation. NOTE: The reservation cancellation fee is in addition to any hotel charges you may incur. If you cancel directly with the hotel, you will still be charged the cancellation fee. You are also subject to your individual hotel's cancellation policy. Hotel requires cancellation of 72 hours prior to the day of arrival. Failure to arrive on your confirmed arrival date will result in one night's room and tax charged by the hotel to the credit card provided and your entire reservation will be cancelled.

A credit card is required to guarantee your reservation. Changes to your reservation can be made via the website or via e-mail, avs@experient-inc.com until 11:00 pm EST on September 27, 2018. Please contact the hotel directly after October 10, 2018, for all cancellations and changes. Please do not call the hotel prior to October 10, 2018, as the hotel may not have record of your reservation.

FLASH NETWORKING SESSIONS

IN-SITU MICROSCOPY, SPECTROSCOPY, AND MICROFLUIDICS

Tuesday, October 22, 2018, 2:40-3:00 pm, Room 202B

2:40 pm	<u>PRESENTERS TO BE DETERMINED</u>
6:30 pm	IN-SITU MICROSCOPY, SPECTROSCOPY, AND MICROFLUIDICS POSTER SESSION, TUESDAY, OCTOBER 23 RD , 6:30-8:30 PM, HALL B

BIOMATERIAL INTERFACES DIVISION

Tuesday, October 23, 2018, 6:15 pm-6:30 pm, Room 101B

6:15 pm	BI-TuP3 Stimuli-responsive Thin Films made from Highly Methoxylated Citrus Pectin, <u>ZEINAB VEISI</u> , N. ALCANTAR, R. TOOMEY, University of South Florida
6:19 pm	BI-TuP7 Vapor-Deposited Porous Polymers for the Fabrication of Giant Lipid Vesicles, <u>NAREH MOVSESIAN</u> , M.T. MATTHEW TITTENSOR, G. DIANAT, N.M. MALMSTADT, M. GUPTA, University of Southern California
6:23 pm	BI-TuP8 Developing a pH Responsive Hydrogel for the Encapsulation of Poly(ethylene glycol) 3350, <u>PHUONG ANH NGUYEN</u> , B. MATHESON, D. CUYLEAR, H.E. CANAVAN, University of New Mexico
6:27 pm	BI-TuP9 Hemocompatibility of the Endexo™ Fluoro-oligomeric Surface, <u>BILL THEILACKER</u> , Medtronic; J. HO, J. SWENOR, Interface Biologics; M.F. WOLF, J.L. KALSCHEUE, S. THINAMANY, Medtronic; S. UBL, medtronic
6:30 pm	BIOMATERIAL INTERFACES POSTER SESSION, TUESDAY, OCTOBER 23 RD , 6:30-8:30 PM, HALL B

VACUUM TECHNOLOGY DIVISION

Tuesday, October 23, 2018, 6:00-6:30 pm, Room 203B

6:15 pm	<u>PRESENTERS TO BE DETERMINED</u>
6:30 pm	VACUUM TECHNOLOGY POSTER SESSION, TUESDAY, OCTOBER 23 RD , 6:30-8:30 PM, HALL B

ELECTRONIC MATERIALS & PHOTONICS DIVISION

Thursday, October 25, 2018, 4:00 pm-4:30 pm, Room 101A

4:00 pm	EM-ThP3 Thermal Engineering for High-Power, Flexible Electronics, <u>KATHERINE BURZYNSKI</u> , University of Dayton and Air Force Research Laboratory, Materials and Manufacturing Directorate; E.W. BLANTON, N.R. GLAVIN, E.R. HELLER, M. SNURE, E.M. HECKMAN, Air Force Research Laboratory; C. MURATORE, University of Dayton
4:05 pm	EM-ThP6 NH ₄ OH Solution Wet Etching for Silicon Channel Thinning of Junctionless-FET, <u>LUCAS STUCCHI-ZUCCHI</u> , A.R. SILVA, J.A. DINIZ, University of Campinas, Brazil
4:10 pm	EM-ThP10 Incorporation of Ferroelectric HfO ₂ into Magnetoelectric Random-Access Memory (MeRAM) Devices, K. FITZELL, <u>JEFFREY CHANG</u> , A. ACOSTA, H. MA, X. LI, K.L. WANG, J.P. CHANG, University of California, Los Angeles
4:15 pm	EM-ThP14 High-mobility Helical Tellurium Field Effect Transistors Enabled by Transfer-free, Low-temperature Direct Growth, <u>GUANYU ZHOU</u> , R. ADDOU, Q. WANG, S. HONARI, C.R. CORMIER, L. CHENG, R. YUE, C.M. SMYTH, A. LATURIA, J. KIM, W.G. VANDENBERGHE, M.J. KIM, R.M. WALLACE, C.L. HINKLE, University of Texas at Dallas
4:20 pm	EM-ThP17 Photoemission under Different Mechanisms from Single- and Dual-gate Carbon Nanotubes Field Effect Transistors, S. YANG, <u>BO WANG</u> , S.B. CRONIN, University of Southern California
4:25 pm	EM-ThP18 100 keV Proton Irradiation Effects on AlGaN/GaN Epistructures, <u>MIN KHANAL</u> , S. UPRETY, K. YAPABANDARA, V. MIRKHANI, S. WANG, B. SCHOENECK, T. ISAACS-SMITH, A. AHYI, M.J. BOZACK, M. PARK, Auburn University
6:30 pm	ELECTRONIC MATERIALS & PHOTONICS POSTER SESSION, THURSDAY, OCTOBER 25 TH , 6:00-8:00 PM, HALL B

AVS MEMBER CENTER

About: The AVS Member Center will showcase membership benefits, professional development activities, diversity and educational events, and provide networking opportunities to all attendees throughout the week. It will be a one-stop-shop, where attendees can stop in at any time to participate in our scheduled events, ask questions, or just have a place where they will be made to feel welcome.



Location: Long Beach Convention Center, Room 103C

Agenda

Monday

7:00 a.m.	Member Giveaway – FREE Beverages for 2018 Members
10:20 a.m.	Demo Hour – AVS Events and Activities/AVS 65 Mobile App
12:15 p.m.	Professional Development – “Welcome to AVS Overview” Lunch*
3:00 p.m.	Professional Development – Speed Networking for Young Professionals

Tuesday

7:00 a.m.	Member Giveaway – FREE Beverages for 2018 Members
9:00 a.m.	Demo Hour – <i>eSpectra: Surface Science</i>
10:00 a.m.	Professional Development – Working with National Labs and Other User Facilities
12:30 p.m.	Professional Development – Job Information Forum and Lunch*
4:00 p.m.	Professional Development – SCCAVS/NCCAVS Hospitality Hour (Invitation Only)
6:45 p.m.	Professional Development – Electronic Materials and Photonics Division Forum: “Careers at LAM Research”

Wednesday

7:00 a.m.	Member Giveaway – FREE Beverages for 2018 Members
10:00 a.m.	Diversity and Inclusion – “Inclusion and Diversity at the Workplace: Your Suggestions for Best Practices”
12:30 p.m.	Professional Development – Lunch* and Learn: “XPS for the Non-Analyst”
3:00 p.m.	Professional Development – “Get Involved: Tips on How to Moderate and Lead Conference Sessions”

Thursday

7:00 a.m.	Member Giveaway –FREE Beverages for 2018 Members
12:30 p.m.	Professional Development and Diversity and Inclusion – “Improving Work-Life Satisfaction” and Lunch*

*Lunch While Supplies Last

[View Descriptions](#)

Demos

Monday

10:20 a.m.

Demo Hour – AVS Events and Activities/AVS 65 Mobile App (Room 103C)

Moderator: Keith Mitchell, AVS IT Systems/Web Administrator

Want to see all the really cool features available on the AVS Events and Activities and AVS 65 Mobile App. Need help downloading the app? Stop by to find out what all the buttons can do for you. AVS is here to answer your questions.

Tuesday

9:00 a.m.

Demo Hour – eSpectra: Surface Science (Room 103C)

Moderator: Jessica Hoy, Journal Manager, AIP Publishing

Do you like coffee? Are you looking for an easier way to analyze spectral data and share your results with your collaborators? Join us for 3 chances to win a \$25 Starbucks® gift card and learn more about eSpectra, the new online platform where you can plot, compare and share your data in just a few clicks. Brought to you by AVS and AIP Publishing, eSpectra is the only interactive tool of its kind that lets you easily plot your data against peer-reviewed data, public data, or your team's data to better understand, analyze, and validate your results. Download and print plotted graphs, or save, share, and store your graphs and data in a secure environment. It includes XPS, AES, and UPS experimental techniques, with additional techniques planned for Fall 2018. Our Free and Individual or Team Premium Access options support a range of research needs from academic to corporate. When you register for Free, you receive a 30-day free trial of Premium Access. Can't wait for the demo? Sign up for free today at eSpectra.aip.org.

Diversity and Inclusion

Wednesday

10:00 a.m.

Diversity and Inclusion – “Inclusion and Diversity at the Workplace: Your Suggestions for Best Practices” (Room 103C)

Moderator: Talat Rahman, University of Central Florida

Attend this highly interactive one-hour session to hear from various speakers on how diversity and inclusion is in the workplace. We will start with a speaker who will lead the discussion on this topic and then we will break off into round tables with a speaker at each table to facilitate a 20 minute discussion. Afterward each table will present their suggestions followed by a group discussion. Speakers and table participants include:

- Pat Thiel, Iowa State University
- Stefan Zollner, New Mexico State University
- Mauro Sardela, University of Illinois
- Talat Rahman, University of Central Florida
- Sean Jones, NSF
- Michael Williams, Clark Atlanta University



Professional Development

Monday

12:15 p.m.

Professional Development – “Welcome to AVS Overview” Lunch* (Room 103C)

Moderator: Charles R. “Chip”, Jr., Naval Research Lab

Wonder about the Mission and Vision of AVS?

Want to know how to get involved?

Would you like to hear from AVS members and leaders?

Then, come learn about the benefits and opportunities of YOUR newest Professional Society! This “Welcome to AVS!” event will introduce you to the mission, vision and organization of AVS as well as highlight its major activities

- **Publications Editor-in-Chief:** Eray Aydil
- **Symposia and Conferences Chair:** Jim Fitz-Gerald
- **Education Chair:** Tim Gessert
- **Membership Chair:** Susan Burkett
- **Chapters, Divisions and Groups Chair:** Vin Smentkowski
- **Professional Development Chair:** Bridget Rogers

Come hear about the benefits now available to you as an AVS member – both at the symposium this week and throughout the whole year! Meet with key leaders in AVS and find out how you can get involved!

Welcome! We’re really glad you’re here and we want you to stay!

3:00 p.m.

Professional Development – Speed Networking for Young Professionals (Room 103C)

Moderator: Angela Klink, AVS Member Services Administrator

First time attending an AVS event?

Need to polish up your elevator speech?

Come join us for this fun and fast-paced networking event designed to provide you with a unique and fun opportunity to share your goals for this symposium and get to know your fellow conference attendees. During this session, you will move from table to table and discuss your technical and personal interests. After the initial meet and greet, you will have the opportunity to network with those who have similar interests or career paths. The speed networking dynamic this creates also helps attendees, including introverts, break the ice more easily. Don’t miss out on this chance to make new contacts and turn it into a lasting connection.

MyAVS Stories

Would you like to share your AVS story with us? Stop by the Member Center to record your message that relates to your experience at an AVS event or to tell an inspiring tale that is relevant to the AVS membership.



Tuesday

10:00 a.m.

Professional Development – Working with National Labs and Other User Facilities
(Room 103C)**Moderators:** Bridget Rogers, Vanderbilt University**Sponsors:** AVS Professional Leadership Committee & the Manufacturing Science & Technology Group

Researchers at government labs and in the NSF supported National Nanotechnology Coordinated Infrastructure (NNCI) labs perform cutting edge research with really cool tools. During this hour a representative from the DOE and from the NNCI will give 20-minute presentations about research at their labs, their capabilities, facilities, and how to gain access to them. After the presentations there will be extended time for questions and discussion. Interactions will continue at the Tuesday Poster session where attendees can engage in extended discussions with the presenters at their posters. Speakers are:

- **NNCI:** Michael Skvarla, Cornell University: Joining the Research Community at the Cornell NanoScale Science and Technology Facility
- **DOE:** Arthur Baddorf, Oak Ridge National Labs

12:30 p.m.

Professional Development – Job Information Forum and Lunch* (Room 103C)**Moderators:** Susan Burkett, The University of Alabama

Panelists provide an overview of their career pathways, what they look for when evaluating job applicants, how they made their career choices, and what it takes to succeed. Speakers include:

- **Industry:** Steve Pachuta, Lead Research Scientist, 3M
- **Academia:** Winny Dong, Professor and Dept. Head, Materials Science Department, Cal Poly Pomona
- **National Laboratory:** Matthew Jordan, Electrical Engineer, Mesa III-V and Heterogeneous Integration, Sandia National Laboratories
- **Technical Publishing:** Phillip Szuromi, Deputy Editor, *Science*

4:00 p.m.

Professional Development – SCCAVS/NCCAVS Hospitality Hour (Invite Only)**Moderator:** Anna Corinne D'Ambrosio

The AVS Southern California Chapter has joined forces with the Northern California AVS to offer “happy hour” for our West Coast AVS members and supporters. Please join us for drinks and light appetizers as our way of saying THANK YOU to our local Chapter supporters, members-at-large, and leadership.

6:45 p.m.

Professional Development – Electronic Materials and Photonics Division Forum:
“Careers at LAM Research” (Room 103C)**Moderator:** Shalini Gupta, PhD, Fellow Engineer and R&D Program Manager, Northrup Grumman Corporation

This Forum will provide an open dialogue between an industrial liaison and young scientists and engineers. A representative from LAM Research will describe Lam Research Corporation, its technical thrusts as well as challenges, its products, future directions, and career opportunities.



Wednesday

12:30 p.m.

Professional Development – Lunch* and Learn: “XPS for the Non-analyst”
(Room 103C)

Moderator: Jeffrey Fenton, Medtronic

Surface characterization methods, such as XPS, are becoming more commonly used in multidisciplinary environments where researchers use information from multiple technologies, but are not experts in all of them. This new “Lunch and Learn” session is targeted to the XPS non-expert. It will provide an overview of key factors that affect XPS analyses, important information about your samples that you will need to provide your analyst, and how samples must be handled before analysis. You will also learn what information needs to be reported along with analytical results when publishing your data to enable readers of your article to evaluate your XPS data and conclusions based on it. Additionally, sources for additional data and information related to XPS will be identified. Speakers include:

- Kateryna Artyushkova, Research Associate Professor, University of New Mexico
- Mark Engelhard, Sr. Research Scientist, Pacific Northwest National Laboratory

3:00 p.m.

Professional Development – Get Involved: Tips on How to Moderate and Lead Conference Sessions (Room 103C)

Moderator: Amy Walker, University of Texas, Dallas

Ever wonder how to get involved in a technical conference? In this one hour session hear from past symposia program chairs on what it takes to get your foot in the door, tips on how to interact with speakers, and how to meet and network with key people in the organization. In addition they will share their insights on what program chairs are looking for in session leaders. Come join us for this interactive session.

Panelists:

- Tino Hofmann, University of North Carolina Charlotte
- Bridget Rogers, Vanderbilt University
- Marcy Stutzman, Jefferson Lab

Thursday

12:30 p.m.

Professional Development and Diversity and Inclusion – “Improving Work-Life Satisfaction” and Lunch* (Room 103C)

Moderator: Micky Holcomb, West Virginia University

Sponsors: AVS Professional Leadership, Diversity and Inclusion Committees

Everyone, from students to faculty members, engineers and scientists, administrators, and CEOs, will experience times when they struggle with maintaining a happy work-life balance. This workshop will go over some tips and strategies for improving your own work-life satisfaction. The workshop leader is a funded tenured faculty member, mother of two young children and prior coach for the National Center for Faculty Development and Diversity.

*This program was originally developed by the Association for Women in Science (AWIS) through a grant from the Elsevier Foundation.



AVS Technical Library



The AVS Technical Library provides members with complimentary online access to technical and educational resources in the fields related to materials, processing, and interfaces:

Presentations on Demand
Recommended Practices • Books • Monographs
Videos • Webinars • Virtual Programs
Conference Articles & Proceedings

Login at www.av.org

Stop by the AVS Member Center in Room 103 C
to learn more about the AVS Technical Library portal.

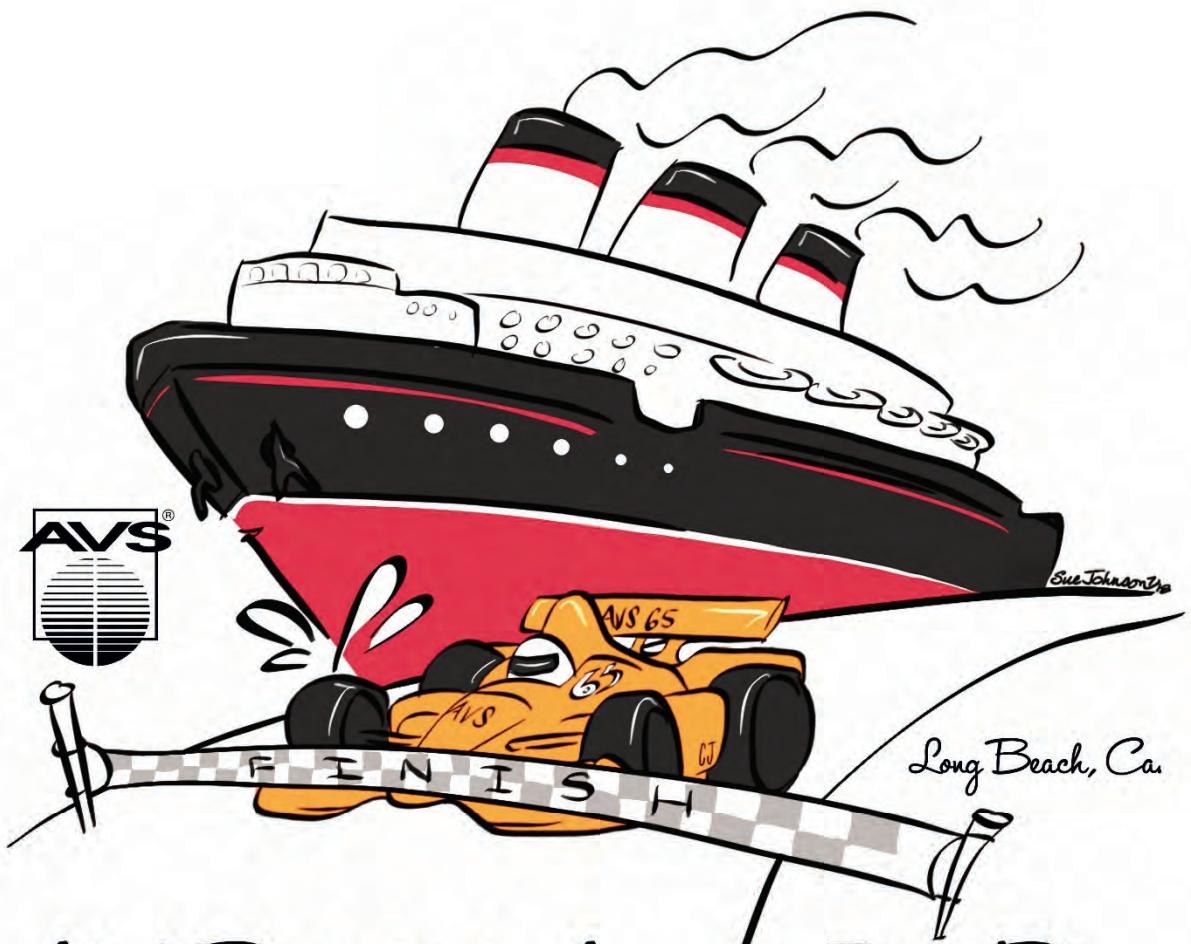
How Members Use the Technical Library...

"Presentations on Demand provides the ability to view talks I could not attend at the symposium, it also allows me to go back and capture details I missed. Colleagues who were not able to attend the symposium are viewing the presentations at their convenience!"

–Vincent S. Smentkowski, General Electric GRC

"As a Professor, I find this a great way to share cutting edge research on a variety of topics with both students and colleagues on the fly. Given the use of electronic classrooms today, this has been a seamless partnership to a live lecture experience. The quality of the talks and the ability to tailor your selection, when you want to view it is a great feature."

–James Fitz-Gerald, Univ. of Virginia



AVS 38th Annual 5K Run

Wednesday, October 24th
2018

When: Wed., October 24, 2018, 6:30 a.m.

Registration: \$30 (\$45 onsite) entry fee includes run t-shirt, race number, map of the course, and awards. Stop by the Run Registration Booth in the Long Beach Convention Center by Tuesday, October 23 to register and/or pick up your materials and schedule.

Details and Awards: This year's race will take place along Pacific Coastline. Come on out and enjoy the sunrise on the beach! The start and finish is within walking distance of the Long Beach Convention Center. With your entry fee you will receive a run t-shirt, race number, and awards. RaceWire Timing will professionally time this year's race. The awards ceremony will be held at the Run Registration area on Wednesday at noon.

Don't forget to put together a team to compete in our **CORPORATE RACE AND DIVISIONS AND GROUPS RACE**

Each team representing a corporate entity (university, unemployed, research organization, manufacturer, etc.) or Division/Group must have three team members to qualify. Times are handicapped by age and sex.

To enter your team, please e-mail your roster, team name, and affiliation to the Run Director before noon on Tuesday, October 23—make sure each team member has registered for the run.

Run Director:
Bridget Rogers, bridget.rogers@avs.org



Visit the AVS STORE



Selling AVS Apparel and
Logo Items Year Round



AVS Apparel & Logo Items

Visit the AVS Store at **Booth 559**

Tuesday: 10:00 a.m. - 5:00 p.m.

Wednesday: 10:00 a.m. - 4:30 p.m.

Thursday: 10:00 a.m. - 2:30 p.m.

NEW! AVS Zip Hoodie & AVS Pullover

► **Shop Online at www.avs.org**

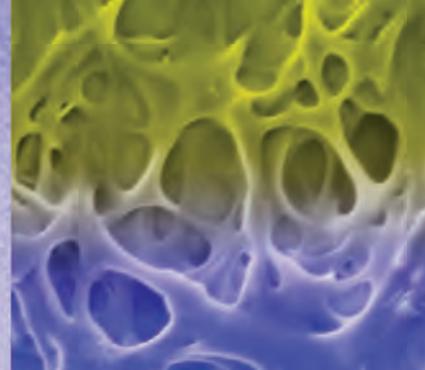




ICMCTF

46th International Conference on Metallurgical Coatings and Thin Films

May 19-24, 2019 | San Diego, CA, USA



ICMCTF 46th International Conference on Metallurgical Coatings and Thin Films

May 19-24, 2019 • San Diego, CA, USA

Town & Country Hotel and Convention Center

Sponsored by the AVS Advanced Surface Engineering Division: <http://www2.avs.org/conferences/icmctf>

CONFERENCE OVERVIEW

The International Conference on Metallurgical Coatings and Thin Films (ICMCTF) is the premier international conference in the field of **thin-film deposition, characterization, and advanced surface engineering** promoting global exchange of ideas and information among **scientists, technologists, and manufacturers**. The Conference includes more than 60 high-profile invited speakers, in over 50 sessions, across twelve technical and topical symposia, several featured **lectures**, as well as focused **topic sessions, short courses, an equipment exhibition, an awards program, and daily social networking events**.

Technical Symposia

- A - Coatings for Use at High Temperatures
- B - Hard Coatings and Vapor Deposition Technologies
- C - Fundamentals and Technology of Multifunctional Materials and Devices
- D - Coatings for Biomedical and Healthcare Applications
- E - Tribology and Mechanical Behavior of Coatings and Engineered Surfaces
- F - New Horizons in Coatings and Thin Films
- G - Surface Engineering - Applied Research and Industrial Applications
- H - Advanced Characterization Techniques for Coatings, Thin Films, and Small Volumes

Topical Symposia

- TS1 - High Entropy and Other Multi-principal-element Materials
- TS2 - Icophobic Surface Engineering
- TS3 - Surface Engineering for Lightweight Materials
- TS4 - Thin Film Materials for Flexible Electronics



PLENARY LECTURE

► May 20, 2019, 8:00 a.m.

"Soft Electronics for the Body"

- Prof. John Rogers, Louis Simpson and Kimberly Querrey Professor of Materials Science and Engineering, Biomedical Engineering and Neurological Surgery, Northwestern University



EXHIBITION KEYNOTE LECTURE

► May 21, 2019, 11:00 a.m.

"Advanced Performance of Tools in Sheet-metal Forming - The Synergy of Surface Technology and Tooling Material Selection"

- Dr. Farwah Nahif, voestalpine eifeler Vacotec, Germany

Special Interest Talks

"Advanced Monitoring of Thin Film Growth from Real-time Diagnostics"

- Gregory Abadias, Université de Poitiers, France

"Linking Intrinsic Plasma Characteristics to the Microstructure and Properties of Diverse Thin Film"

- Ivan Petrov, University of Illinois, USA, Linköping University, Sweden, USA

Upcoming Deadlines

► **Early Registration: April 8, 2019**

(Presenting authors, you must register by April 8, to remain in the Program Book)

► **Manuscript Submission: April 8, 2019**

General Chair:

Michael Stüber
Karlsruhe Institute of Technology
michael.stueber@kit.edu

Program Chair:

Christopher Muratore
University of Dayton
cmuratore1@udayton.edu

Conference Management:

Yvonne Towse
Della Miller
Jeannette DeGennaro
Heather Korff
icmctf@icmctf.org





pacsurf 2018

Pacific Rim Symposium on Surfaces, Coatings & Interfaces

December 2-6, 2018, Waikoloa Beach, Hawaii
Waikoloa Beach Marriott Resort & Spa

This Conference is being organized by AVS (United States) with a Steering Committee composed of representatives from Australia, Canada, China, Japan, Korea, Mexico, New Zealand, Philippines, Singapore, and Taiwan. Symposium attendees will interact during morning and evening sessions that will include plenary, invited, and contributed presentations. We will have morning and evening technical sessions with the afternoons free for other activities and discussions.

General Chair: Dave Castner,
University of Washington, USA

Program Chair: Alberto Herrera-Gomez,
CINVESTAV, Mexico

KEY DATES

Early Registration & Hotel Deadline:

► **November 9, 2018**

Manuscript Deadline:

► **April 20, 2019**

Biomaterial Surfaces & Interfaces (BI)

- BI1: Soft Surface and Biofunctional Coatings
- BI2: Bioimaging and Bionanotechnology
- BI3: Biomolecule/Material Interactions
- BI4: Medical Applications
- BI5: 35 Years of NESAC/BIO
- BI6: Biomaterial Surfaces and Interfaces Poster Session

Energy Harvesting & Storage (EH)

- EH1: Surfaces and Interfaces for Environmental Processes
- EH2: Surfaces and Interfaces for Solar Cells and Solar Fuels
- EH3: Battery/Supercapacitor Coatings, egs., Li⁺ Batteries & Thermo-/Piezo-electrics
- EH4: Surfaces and Interfaces for Efficient Power Conversion
- EH5: Energy Harvesting and Storage Poster Session

Nanomaterials (NM)

- NM1: Magnetic Properties
- NM2: Nanocatalysis
- NM3: Nanofabrication and Nanodevices
- NM4: Nanocharacterization
- NM5: Nanocomposites
- NM6: Nanomaterials Poster Session

Plasma Processing (PS)

- PS1: Plasma Modification of Surfaces and Materials
- PS2: Practical Applications of Plasma
- PS3: Plasma-material Interactions
- PS4: Plasma Processing Poster Session

Thin Films (TF)

- TF1: Nanostructured Surfaces and Thin Films: Synthesis and Characterization
- TF2: Innovations in the Development of Multifunctional Thin Films
- TF3: Next-generation Protective Coatings and Tribological Applications
- TF4: Nanostructural and Surface Morphological Evolution: Experiment and Theory
- TF5: Emerging Topics: Growth and Properties of Electronic Materials, 2D Layers, and Metallic-glass Thin Films
- TF6: Thin Films Poster Session





Contact us for details at
heather@av.org
530-896-0477

AVS Onsite Training Offers

- **Customized** course program that includes only those topics most valuable to your group
- **Convenient** course scheduling that lets you decide when and where your courses will be presented
- **Cost-effective and convenient training** by eliminating attendee travel expenses and individual attendee course fees. Taught at a location you choose.
- **Technical experts** selected for their knowledge of the subject, proven teaching ability, and communication skills in:

Vacuum and Equipment Technology - vacuum and processing equipment design, operation, and maintenance

Materials and Interface Characterization - chemical, physical, and electrical characterization of films, surfaces, particles, and interfaces

Materials Processing - materials processing, modification, and integration



AVS 65 Career Center and Job Fair

Looking for qualified candidates to interview and fill positions?

Looking for an employer who needs your skills and qualifications?



**Check out the AVS Career Center and Job Fair
Exhibit Hall – Booth #162**

Sunday	Oct. 21	2:00 p.m. – 6:00 p.m.	Career Center Registration Area (Submit Job Openings/Résumés)
Monday	Oct. 22	7:30 a.m. – 5:00 p.m.	Career Center Registration Area (Submit Job Openings/Résumés)
Tuesday	Oct. 23	10:00 a.m. – 5:00 p.m.	Exhibit Hall, Booth #162 – Job Fair Open
Wednesday	Oct. 24	10:00 a.m. – 4:30 p.m.	Exhibit Hall, Booth #162 – Job Fair Open
Thursday	Oct. 25	10:00 a.m. – 2:30 p.m.	Exhibit Hall, Booth #162 – Job Fair Open
Thursday	Oct. 25	2:30 p.m. – 5:00 p.m.	Career Center Registration Area

EMPLOYERS

Post Job Openings



JOB SEEKERS

Submit Résumé/CV

Review Résumés

Review Job Openings

Interview Onsite

Interview Onsite



SPECIAL SESSIONS/WORKSHOPS

Biomaterial Interfaces Division Plenary Session and Reception

Sunday, October 21, 2018, 3:00–5:30 p.m., Room 101B, Long Beach Convention Center

The Biomaterials Interfaces and AIP's Industrial Physics Forum program kicks off with the now traditional Biomaterials Plenary Session. This year we are pleased to have presentations from two eminent scientists who have made significant contributions to the fields of BioImaging and DNA Based Algorithms. The session will close with the opportunity for further discussions at our traditional Plenary Reception.

MIND Special Symposium: “Symposium on New Magnetic Materials, Devices and Concepts for the Information Society”

Monday, October 22, 2018; 1:20 p.m., Room 201A, Long Beach Convention Center

The symposium will feature four invited talks by renowned speakers from academia and industry who will discuss how we got to where we are today and where to go from here. Magnetic materials and magnetism in general have always been linked very closely to the area of sensing, information processing and storage, owing to its ability to provide long range order at the nanoscale that can be affected not only with magnetic fields but also with electric currents, external pressure etc. The program will address different aspects of how magnetism has played a role in the information society and how it will play a role in the future.

Thin Film Division Panel Discussion of Student Opportunities and the TFD Harper Award TED-Talk Competition (Student-Oriented Event)

Monday, October 22, 2018, 7:30 p.m., Room 102A, Long Beach Convention Center

This special session is an opportunity for the finalist for the Thin Film Division's Harper Award to present their work along the lines of a TED-talk, with 15 minute presentations. A panel of TFD members, in the role of execs and potential employers, will judge and critique these talks in real time for both content as well as presentation quality and originality. Following the talks, the Harper Award winner for the best overall presentation will be announced. This unique session is open to all students who are authors on an abstract presented in a TFD sponsored or TFD co-sponsored session. Prior to the TED-talks the Thin Film Division will host a panel discussion on opportunities for student involvement within the division. We encourage students to use session to inquire about AVS, Thin Film Division, or professional opportunities and jobs based in thin film fields of study. Food and drinks will be provided.

2018 Harper Award Finalists:

1. Devendra Khatiwada, *University of Houston*
2. Dibyashree Koushik, *Eindhoven University of Technology*
3. Jasmine Wallas, *University of Colorado at Boulder*
4. Timothy N. Walter, *The Pennsylvania State University*

SPECIAL SESSIONS/WORKSHOPS

Applied Surface Science Division Memorial Reception

Sunday, October 21, 2018, 6:30 p.m., Regency EF, Hyatt Regency Long Beach

Over the course of the last year we have lost several founding contributors to the field of applied surface science. At this year's meeting we come together to remember their contributions, friendship and leadership to our field, careers and instrumentation. Please join us for a reception as we give tribute to these important people and hear about their lives and achievements from key colleagues and peers.

Alfred Benninghoven

David Briggs

Drew Evans

Klaus Wittmaack

ASTM-E42/ASSD Joint Workshop: “A Tribute to the Careers of Barbara Garrison and Nicholas Winograd”

Tuesday, October 23, 2018, 8:00 p.m., Regency DE, Hyatt Regency Long Beach Hotel

This special session aims to recognize the esteemed careers of Barbara Garrison and Nicholas Winograd and their contributions to applied surface science. Barbara and Nick spent several decades researching the fundamentals and applications of ion/solid and neutral/solid interactions, resulting in hundreds of publications apiece and tens of thousands of combined citations. The extent of their reach will never be replicated and their work will always be remembered for its impact on our community.

Barbara and Nick will each provide a short presentation of their career highlights and Christopher Szakal, a former student of Nick's (also known as a 'Winograduate'), will lead a lighthearted tribute to Barbara and Nick. Audience participation will be paramount to the success of this endeavor, so all are invited to come to this celebratory event!

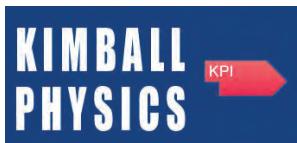
Surface Science Morton M. Traum Presentation

Thursday, October 25, 2018, 12:20 p.m., Room 203 C, Long Beach Convention Center

The Tuesday Evening Poster Session features presentations by the Mort Traum Student Award Finalists. The Morton M. Traum Surface Science Student Award will be presented for the best student poster presented in the poster session sponsored or jointly sponsored by the Surface Science (SS) Division at the AVS International Symposia. The 2018 Winner will be announced in the Traum Student Award Ceremony.

AVS 65 SPONSORS

AVS would like to acknowledge the following companies who have generously provided support for AVS 65 events.



AVS 65 SPONSORS

AVS would like to acknowledge the following companies who have generously provided support for AVS 65 events.



American Institute
of Physics



AIP | The Journal of
Chemical Physics

IONOPTIKA
ion beam technology

scientaOMICRON

HEIDELBERG
INSTRUMENTS

 **Protochips**
Quantifiably Better™

 **NT-MDT**
Spectrum Instruments

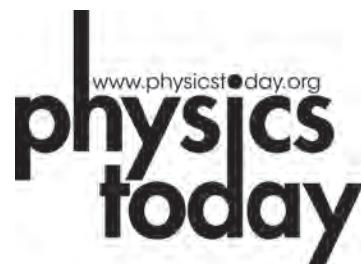
 **McAllister** TECHNICAL
SERVICES

physicsworld

 **Lam**[®]
RESEARCH

 **HIDEN**
ANALYTICAL

THE JOURNAL OF
PHYSICAL
CHEMISTRY 

 www.physicstoday.org
physics
today

 **vacuum** TECHNOLOGY
& **coating**


STAIB
INSTRUMENTS

AVS CORPORATE MEMBERS

AVS wishes to thank the following Corporate Members for their support. For information on benefits or to become a corporate member please contact Angela Klink; angela@avs.org or refer to the AVS website: www.av.org

- ABBESS Instruments
- AJA International, Inc.
- American Institute of Physics
- Applied Vacuum Technology, LLC
- Busch Vacuum Pumps and Systems
- CeramTec North America
- Challentech International Corp.
- COSMOTEC, Inc.
- Denton Vacuum LLC
- Duniway Stockroom Corp.
- Edwards Vacuum, Inc.
- EP Laboratories, Inc.
- FMG Enterprises, Inc.
- Gamma Vacuum
- Helium Leak Testing, Inc.
- Hiden Analytical, Inc.
- HIS Vacuum Solutions
- Horiba Instruments
- HVA, LLC
- ION-TOF USA Inc.
- Kratos Analytical
- Kurt J. Lesker Company
- Mack Vacuum Technologies, Inc.
- MDC Vacuum Products, LLC
- MKS Instruments Inc.
- Nor-Cal Products
- Nordiko Technical Services Limited
- Pfeiffer Vacuum Technology
- Physical Electronics
- Plasmaterials Inc
- Plasma-Therm
- Precision Plus Vacuum Parts
- Process Materials Inc
- Quantum Innovations, Inc.
- R.D. Mathis Company
- RBD Instruments, Inc.
- Reynard Corporation
- RF VII Inc.
- SAES Getters USA, Inc.
- SPI Supplies
- Staib Instruments, Inc.
- Sumitomo (SHI) Cryogenics of America, Inc.
- Super Conductor Materials Inc
- SynSysCo
- Thermo Fisher Scientific
- UC Components Inc
- Vacuum Plus Manufacturing Inc.
- Vacuum Research Corp.
- XEI Scientific, Inc.

Media Sponsor

physicsworld

vacuum^{TECHNOLOGY}
&coating

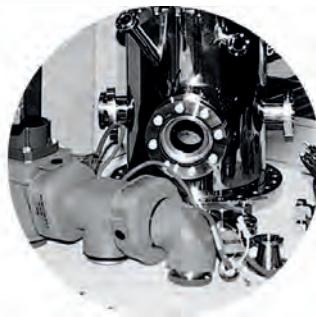
AVS CONNECTS

AVS Online Buyer's Guide

Whether you are seeking new lab equipment, testing devices, deposition technologies, or business services the buyer's guide is your source to locate new vendors, products, services, and service providers easily and quickly.

Locate the Products and Services You Need

www.avsbuyersguide.org



AVS AWARD WINNERS

MEDARD W. WELCH AWARDEES

1970	Erwin W. Mueller	1988	Peter Sigmund	2004	Rudolf M. Tromp
1971	Gottfried K. Wehner	1989	Robert Gomer	2005	Charles S. Fadley
1972	Kenneth C.D. Hickman	1990	Jerry M. Woodall	2006	John C. Hemminger
1973	Lawrence A. Harris	1991	Max Lagally	2007	Jerry Tersoff
1974	Homer D. Hagstrum	1992	Ernst Bauer	2008	Miquel Salmeron
1975	Paul A. Redhead	1993	George Comsa	2009	Robert J. Hamers
1976	Leslie Holland	1994	John Yates, Jr.	2010	Mark J. Kushner
1977	Charles B. Duke	1995	Gerhard Ertl	2011	Wilson Ho
1978	Georg H. Hass	1996	Peter J. Feibelman	2012	Yves Chabal
1979	Gert Ehrlich	1997	Phaedon Avouris	2013	Chris G. Van de Walle
1981	Harrison E. Farnsworth	1998	David E. Apsones	2014	Patricia A. Thiel
1983	H.H. Wieder	1999	John H. Weaver	2015	Charles T. Campbell
1984	William S. Spicer	2000	D. Phillip Woodruff	2016	Maki Kawai
1985	Theodore E. Madey	2001	E. Ward Plummer	2017	Hans-Peter Steinrück
1986	Harald Ibach	2002	Buddy Ratner	2018	David Castner
1987	Mark J. Cardillo	2003	Matthias Scheffler		

GAEDE-LANGMUIR AWARDEES

1978	Pierre V. Auger	1992	Russell D. Young	2006	Leonard J. Brillson
1980	Daniel Alpert	1994	Robert J. Celotta	2008	Daniel Auerbach
1982	Alfred H. Sommer	1994	Daniel T. Pierce	2010	Gerald Lucovsky
1984	Alfred Benninghoven	1996	Gerald J. Lapeyre	2012	Dietrich Menzel
1986	Rointan F. Bunshah	1998	Paul D. Palmberg	2014	Hans-Joachim Freund
1988	Alfred Y. Cho	2000	Gary W. Rubloff	2016	Paul S. Bagus
1988	John R. Arthur, Jr.	2002	Cristoforo Benvenuti	2018	Michael Grunze
1990	Francois M. d'Heurle	2004	Kunio Takayanagi		

ALBERT NERKEN AWARDEES

1985	John L. Vossen	1995	Donald Mattox	2006	Siegfried Hofmann
1986	Donald J. Santeler	1996	William R. Wheeler	2007	Richard J. Colton
1987	Marsbed Hablanian	1997	John C. Helmer	2008	Seizo Morita
1988	Stanley L. Milora	1998	Peter J. Clarke	2009	Donald R. Baer
1989	Charles D. Wagner	1999	Paul Holloway	2010	Fan Ren
1989	Martin P. Seah	2000	John T. Grant	2011	John E. Rowe
1990	J. Peter Hobson	2001	Cedric Powell	2012	Sven Tougaard
1991	Harold R. Kaufman	2002	David J. Harra	2013	Howard A. Padmore
1992	Paolo della Porta	2003	Peter B. Barna	2014	Gary E. McGuire
1993	John O'Hanlon	2004	Johan K. Fremerey	2014	Olga A. Shenderova
1994	Hajime Ishimaru	2005	Christopher R. Brundle		

JOHN A. THORNTON MEMORIAL AWARDEES AND LECTURES

1989	Eric Kay	1995	Jan-Eric Sundgren	2009	Frances A. Houle
1990	Maurice Francombe	1997	James M.E. Harper	2011	Vincent M. Donnelly
1991	Joseph E. Greene	1999	Timothy Coutts	2013	Ivan Petrov
1992	Thomas R. Anthony	2001	Samuel D. Bader	2015	Alfred Grill
1993	John W. Coburn	2003	William D. Sproul	2017	Steven George
1993	Harold F. Winters	2005	Stan Veprek		
1994	David Hoffman	2007	Stephen J. Pearton		

PETER MARK AWARDEES

1980	Christopher R. Brundle	1994	Marjorie Olmstead	2007	W.M.M. Kessels
1981	Lawrence L. Kazmerski	1995	Emily Carter	2008	Sergei Kalinin
1982	Charles M. Magee	1996	Brian E. Bent	2009	Beatriz Roldan Cuenya
1983	D. James Chadi	1997	Brian Swartzentruber	2010	Arutin Ehiasarian
1984	Barbara J. Garrison	1998	David G. Cahill	2011	Mohan Sankaran
1985	Franz J. Himpel	1999	Eray S. Aydil	2012	E. Charles H. Sykes
1986	Richard A. Gottscho	2000	Stacey F. Bent	2013	Daniel Gunlycke
1987	Raymond T. Tung	2001	Eli Rotenberg	2014	Joshua Zide
1988	Jerry D. Tersoff	2002	Rachel S. Goldman	2015	Petro Maksymovych
1989	Randall M. Feenstra	2003	Charles H. Ahn	2017	Markus Valtiner
1990	Stephen M. Rossnagel	2004	Kathryn W. Guarini	2018	Peter Bruggeman
1991	William J. Kaiser	2005	Jane P. Chang		
1993	Robert Hamers	2006	Mark C. Hersam		

AVS AWARD WINNERS

HONORARY MEMBERSHIP

1959	Rudy A. Koehler	1996	Howard Patton	2006	Alvin Czanderna
1963	Benjamin B. Dayton	1997	Paul Holloway	2007	Paula J. Grunthaner
1981	Leonard C. Beavis	1997	William D. Westwood	2008	Eric Kay
1981	N. Rey Whetten	1999	Donna Bakale Sherwin	2009	Rudolf Ludeke
1982	Charles B. Duke	1999	James S. Murday	2009	William D. Sproul
1984	J. Roger Young	2000	Lawrence L. Kazmerski	2011	Robert A. Childs
1985	Kai Siegbahn	2001	Robert Willis	2012	Cedric Powell
1986	Manfred S. Kaminsky	2003	H. Frederick Dylla	2013	David Castner
1988	Jack H. Singleton	2003	Gary E. McGuire	2013	Stephen M. Rossnagel
1991	John W. Coburn	2004	Arthur O. Fuente, Jr.	2014	John N. Russell, Jr.
1991	J. Lyn Provo	2004	J.W. Rogers, Jr.	2016	Dawn Bonnell
1992	Marsbed Hablanian	2005	Gerald Lucovsky		

JOHN L. VOSSEN MEMORIAL AWARDEES

1997	Robert Shaner	2001	Paul Lulai
1998	Hasan Fakhruddin	2002	Toni L. Evans
1999	Chris Ann Slye	2004	Jacqueline G. Kane
2000	Charles J. Miltenberger		

GEORGE T. HANYO AWARDEES

1997	Mark Engelhard	2011	Jonathan Koch
1998	David A. Lubelski	2012	Percy Zahl
1999	Robert A. Childs	2013	Steven R. Blankenship
2001	John E. Bultman	2014	Ewald E. Chaban
2003	Ernest A. Sammann	2015	Marc D. Landry
2004	Richard E. Muller	2016	Stanley B. Christman
2006	Jeffrey D. Kelley	2017	Mark C. Reuter
2010	Arthur W. Ellis		

DOROTHY M. AND EARL S. HOFFMAN AWARDEES

2003	Kenneth Bratland (Univ. of Illinois at Urbana-Champaign)
2004	Michael Filler (Stanford University)
2005	Michael Zellner (University of Delaware)
2006	Xingyi Deng (Harvard University)
2007	Thomas Mullen (Pennsylvania State University)
2008	Gregory Rutter (Georgia Institute of Technology)
2009	Juan Carlos Rodriguez-Reyes (University of Delaware)
2010	Esther Amstad (ETH Zurich, Switzerland)

2011	Kangkang Wang(Ohio University)
2012	Davide Sangiovanni (Linkoping University)
2013	Zhu Liang (University of Illinois at Chicago)
2014	Jingjing Qiu (University of Florida)
2015	Jiayu Wan (University of Maryland, College Park)
2016	Andrew Mannix (Northwestern University)
2017	Xiaolong Liu (Northwestern University)

NELLIE YEOH WHETTEN AWARDEES

1990	Jani C. Ingram (University of Arizona)
1991	Lucia Markert (University of Illinois)
1992	Hope Michelson (IBM Almaden Research Center)
1993	Laura Tedder (University of California, San Diego)
1994	Monica Katiyar (University of Illinois)
1995	Cynthia Kelchner (Iowa State University)
1996	Tracey E. Caldwell (University of California, Davis)
1997	Catherine Labelle (Massachusetts Institute of Technology)
1998	Jennifer S. Hovis (University of Wisconsin)
1999	Nerissa Taylor (University of Illinois)
2000	Jennifer E. Gerbi (University of Illinois)
2001	Tanhong Cai (Iowa State University)
2002	Lyudmila Goncharova (Rutgers University)
2003	Meredith L. Anderson (Carnegie Mellon University)

2004	Wensha Yang (University of Wisconsin, Madison)
2005	Natalia Farkas (University of Akron)
2006	Jessica Hilton (University of Minnesota)
2007	Andrea Munro (University of Washington)
2008	Brittany Nelson-Cheeseman (University of California, Berkeley)
2009	Sarah Bishop (University of California, San Diego)
2010	Xiaoyu Wang (University of Wisconsin, Madison)
2011	Sondra Hellstrom (Stanford University)
2012	Nour Nijem (University of Texas, Dallas)
2013	Indira Seshadri (Rensselaer Polytechnic Institute)
2014	Jiechang Hou (University of Pennsylvania)
2015	Leeya Engel (Tel Aviv University)
2016	Debalaya Sarker (Indian Institute of Technology)
2017	Rachael Farber (Loyola University Chicago)

AVS RUSSELL AND SIGURD VARIAN AWARDEES

1983	J.S. Villarubia (Cornell University)
1984	Kenneth T.Y. Kung (MIT)
1985	Anne L. Testoni (Northwestern University)
1986	Jingguang G. Chen (University of Pittsburgh)
1987	Joanne R. Levine (Northwestern University)
1988	Christopher E. Aumann (University of Wisconsin)
1989	Brian S. Swartzentruber (University of Wisconsin)
1990	Guangquan Lu (University of California, San Diego)
1991	Michael Flatte (University of California, Santa Barbara)
1992	Rex Ramsier (University of Pittsburgh)
1993	Daniel Kelly (University of California, Santa Barbara)
1994	Britt Turkot (University of Illinois)
1995	Robert Carpick (University of California, Berkeley)
1996	Kevin Robbie (University of Alberta)
1997	Kimberly S. Turner (Cornell University)
1998	John S. Lewis, III (University of Florida)
1999	Sanjit Singh Dang (University of Illinois, Chicago)
2000	Michelle L. Steen (Colorado State University)

2001	Jianwei Dong (University of Minnesota)
2002	Wei Tan (University of Illinois)
2003	John R. Kitchin (University of Delaware)
2004	Vassil Antonov (Univ. of Illinois at Urbana-Champaign)
2005	Liam Pingree (Northwestern University)
2006	Gregory Ten Eyck (Rensselaer Polytechnic Institute)
2007	H. Lee Mosbacher (Ohio State University)
2008	Erik Wallen (Linkoping University)
2009	Sudhakar Shet (New Jersey Institute of Technology/NREL)
2010	Christine Tan (Cornell University)
2011	David A. Siegel (University of California, Berkeley)
2012	April Jewell (Tufts University)
2013	Jason Kawasaki (University of California, Santa Barbara)
2014	Deep Jariwala (Northwestern University)
2015	Andrada-Oana Mandru (Ohio University)
2016	Thomas Winkler (University of Maryland, College Park)
2017	Tania E. Sandoval (Stanford University)



Awards Ceremony & Reception

AVS 65th Annual Awards

*Celebrate with AVS awardees
in the Grand Ballroom of the
Long Beach Convention Center,
Long Beach, California*

**Wednesday, October 24, 2018
at 6:30 p.m.**



AVS AWARDS

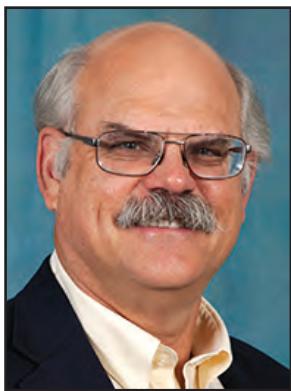
AWARDS CEREMONY & RECEPTION

The AVS Awards Ceremony will be held on Wednesday, October 24, 2018, at 6:30 pm in Grand Ballroom within the Long Beach Convention Center to be followed immediately by an Awards Reception. This year, AVS honors the following awardees:

David Castner, Medard W. Welch Award
Michael Grunze, Gaede Langmuir Award
Peter Bruggeman, Peter Mark Memorial Award
The newly elected AVS Fellows
The 2018 AVS National Student Award Finalists

MEDARD W. WELCH AWARD

The Medard W. Welch Award was established in 1969 to commemorate the pioneering efforts of M.W. Welch in founding and supporting AVS. It is presented to recognize and encourage outstanding research in the fields of interest to AVS. The award consists of a cash award, a medal, a plaque, and an honorary lectureship at a regular session of the International Symposium.



DAVID CASTNER

Medard W. Welch Award Lecture:
“A Surface Scientist’s Journey
from Small Molecules to
Biomolecules and Biomaterials”
Wednesday, 2:20 pm, Room 104B

David Castner, University of Washington “for leading advances in rigorous and state-of-the-art surface analysis methods applied to organic and biological samples”

David G. Castner is a Professor of Bioengineering and Chemical Engineering, the Director of the National ESCA and Surface Analysis Center for Biomedical Problems (NESAC/Bio), and the Director of the Molecular Analysis Facility at the University of Washington (UW). Prof. Castner received his Ph.D. in Physical Chemistry from University of California at

Berkeley in 1979, where he studied small molecule chemisorption and reactivity on rhodium single crystal surfaces. He then spent seven years as a Research Chemist at the Chevron Research Company developing XPS and XAS methods for characterizing heterogeneous catalysts before moving to the UW in 1986 to pursue research in biomedical surface analysis. He was also the Director of the UW Center for Nanotechnology (2004–2005) and the Associate Dean of Engineering for Infrastructure (2009–2012). He has been a Guest Professor at the University of Paris since 2003. Prof. Castner is a Fellow of AVS, Biomaterials Science and Engineering, and American Institute for Medical & Biological Engineering. Prof. Castner received the 2003 Excellence in Surface Science Award from the Surfaces in Biomaterials Foundation, the 2004 Clemson Award for Basic Research from the Society of Biomaterials, the 2014 Rivière Prize from the UK Surface Analysis Forum, and the 2017 ECASIA Award. He was AVS President in 2010 and became an AVS Honorary Member in 2013.

Prof. Castner has an active research program in the areas of surface analysis, surface modification, biomaterials, nanomaterials and organic thin films, co-authoring more than 250 refereed publications and giving more than 220 invited presentations. Over the past 40+ years his surface science/analysis research has covered a wide range of surface modification and characterization topics. Since arriving at the UW in 1986 his research has focused developing new surface analysis methods and using a multi-technique approach to provide detailed characterization of biomedical materials, ranging from implanted biomaterials to diagnostic devices, with a special emphasis on characterizing the interactions of biomolecules (peptides, proteins, DNA, etc.) and cells with biologically relevant surfaces and interfaces. His research has included numerous research collaborations at the UW and around the world, as well as managing multi-disciplinary research projects and teams. He has also been the general chair and program chair for international conferences such as SIMS and PacSurf.

In the 1990s his research focused on using a complementary, multi-technique approach (XPS, ToF-SIMS, NEXAFS, etc.) to determine the composition and structure of organic surfaces ranging from SAMs to RF glow discharge deposited films and relating that information to their biological performance. Since 2000 a major thrust of his research program has been to develop methods for characterizing surface bound proteins and peptides to determine their identity, amount, conformation, orientation and spatial distribution. This research has shown combining ToF-SIMS, multivariate analysis, XPS, NEXAFS, SFG, etc. with molecular dynamics and Monte Carlo simulations is a powerful approach for investigating the struc-

ture of surface bound proteins and peptides. In the past 10 years another major research thrust has been the development of surface analysis methods using XPS and TEM measurements in combination with Monte Carlo simulations to characterize the composition and structure of nanoparticles.

GAEDE-LANGMUIR AWARD

The Gaede-Langmuir Award was established in 1977 by an endowing grant from Dr. Kenneth C.D. Hickman. It is presented to recognize and encourage outstanding discoveries and inventions in the sciences and technologies of interest to AVS. The award is conferred biennially as a suitable candidate may be identified. It consists of a cash award, a commemorative plaque stating the nature of the award, and an honorary lectureship at a regular session of the International Symposium.



MICHAEL GRUNZE

“Gaede Langmuir Award Lecture:
“From Description to Prediction
of Biointerphase Reactions”

Wednesday, 3:00 pm, Room 101B

Michael Grunze, Ruprecht-Karls-University of Heidelberg, Germany, “taking surface science beyond small molecules at surfaces to complex liquid/surface interactions, including polymers, biointerphases, and biomedical applications, through development of novel experimental approaches, theoretical simulations, and inventions”

Michael Grunze received his Ph.D. in Physical Chemistry in 1974 from the Freie Universität Berlin on the reduction of ZnO with reactive gases. Under the supervision of Wolfgang Hirschwald, he used thermogravimetric methods to derive a kinetic model for the orientation dependence of the reduction of ZnO single crystals. Subsequently, he joined the research group of G. Ertl in Munich as a post-doc and was involved in the first iron single crystal experiments to study the mechanism of nitrogen

adsorption and nitrogen and ammonia dissociation in view of unsolved mechanistic questions related to the Haber Bosch Process. After a short stay with John Pritchard at Queen Mary College in London, he continued his work on catalytic surface reactions at the Fritz Haber Institute of the Max Planck Society in Berlin. The kinetic formalism he derived for nitrogen dissociation on Fe (111) surfaces provided the input for the modelling of the industrial Haber Bosch process. In 1983 he accepted a position as full professor of Physics at the University of Maine, where he developed strategies for the characterization of polymer/metal interfaces and the mechanism of adhesion in these technically important systems. During his tenure at the University of Maine, he also designed and build an x-ray photoelectron spectrometer capable to study adsorption and catalytic reactions on solid surfaces up into the mbar pressure range, a technique which is nowadays employed in several laboratories.

In 1987 M. Grunze accepted the Chair for Applied Physical Chemistry at the University of Heidelberg, where he kept his position until his retirement in 2012. His work continued to be focussed on the static and dynamic properties and applications of thin organic films, e.g. self-assembled monolayers, polymer brushes, and inorganic polymers for medical applications (polyphosphazenes). His group was the first to employ synchrotron-based methods and non-linear optical methods (SHG and SFG) to study the molecular conformation and orientation in adsorbed organic films in air and different solvents. These experiments led to an extended interest of his group in the properties of interfacial water and the forces between objects in an aqueous environment. The experimental work was complemented by collaborative theoretical and modelling work with Hans-Jürgen Kreuzer and Alexander Pertsin, respectively. In these studies, it was shown that the conformational changes of ethylene oxide oligomers in water explain the “inertness” of the respective SAM surfaces, and that by quantitative modelling of solvation forces and their range the forces between experimentally verifiable phospholipid layers and different SAM surfaces in water can be predicted. Over the last 15 years, and ongoing, Michael Grunze’s main research activity is on environmentally benign non-fouling surfaces for marine applications, which resulted in novel strategies and experimental methods to quantify the interaction of unicellular organisms with surfaces.

Michael Grunze’s advances in surface and interface science in research areas ranging from catalysis (e.g., ammonia synthesis) to organic films (e.g., polyimide films and self-assembled monolayers) to biological applications (e.g. non-fouling surfaces and medical implants) led to several national and international awards and

honorary lectures and professorships. Together with his students (he supervised 180 graduate students during his academic career), post docs and coworkers he published over 430 publications and filed over 120 patents. Michael Grunze founded and cofounded four companies during his tenure at the Fritz Haber Institute, the University of Maine, the University of Heidelberg, and after his retirement.

PETER MARK MEMORIAL AWARD

The Peter Mark Memorial Award was established in 1979 in memory of Dr. Peter Mark who served as Editor of the *Journal of Vacuum Science and Technology* from 1975 to 1979. The award is presented to a young scientist or engineer (35 years of age or under) for outstanding theoretical or experimental work, at least part of which must have been published in an AVS Journal. The award consists of a cash award, a plaque, and an honorary lectureship at a regular session of the International Symposium.



PETER BRUGGEMAN

Peter Mark Memorial Award Lecture:
“Plasma-bio Interactions: Investigating Mechanisms to Enable New Applications”

Wednesday, 11:40 am, Room 104B

Peter Bruggeman, University of Minnesota, “for studies that have provided fundamental insights into nonequilibrium atmospheric-pressure discharges and the underlying mechanisms enabling biomedical applications”

Dr. Peter Bruggeman is currently Professor of Mechanical Engineering and director of the High Temperature and Plasma Laboratory (HTPL) at the University of Minnesota. HTPL was founded in 1964 by Professor Emil Pfender and the lab has been a well-known center of plasma research for many decades. Peter obtained his PhD from Ghent University, Belgium, in 2008 and was an Assistant Professor of Applied Physics at the Eindhoven University of Technology, the Netherlands, from 2009 until

he joined the University of Minnesota in 2013 as an Associate Professor. He was promoted to Full Professor in 2017.

His primary research interests are plasma-liquid interactions and non-equilibrium plasma kinetics and chemistry applied to plasma processes for environmental, biomedical and renewable energy technologies. A significant part of his research is focused on the fundamental physical and chemical processes of atmospheric pressure non-equilibrium plasmas enabling these applications. Peter has intensively worked on innovative diagnostics methods required due to the complex high collisional and non-equilibrium conditions of atmospheric pressure plasmas.

He has published over 95 papers in peer-reviewed journals of which 12 have been selected as journal highlights. He has delivered invited and keynote lectures at over 60 international meetings and was a lecturer at several summer schools in Germany, USA, Canada and Brazil. His research has been recognized by several awards including the 2012 Hershkowitz Early Career Award, the 2013 Institute of Pure and Applied Physics Young Scientist Medal and Prize in Plasma Physics and the 2016 US Department of Energy Early Career Award.

Peter is an active member of his research community. He is currently the section editor for Plasmas and Plasma-Surface Interactions of the *Journal of Physics D: Applied Physics* (Institute of Physics Publishing) and serves as an editorial board member of several other journals. He also co-edited the prestigious “2017 Plasma Roadmap” giving directions for the future development of the field of low temperature plasma. Peter is also an elected member of the board of directors of the International Society of Plasma Chemistry and was a member of the management committee of the European COST action MP1101 from 2011 until he relocated to the United States in 2013.

He has been a member of more than a dozen international scientific and organizing committees of meetings in his research field. He is the elected chair of the 2018 Gordon Research Conference on Plasma Processing Science that will take place this summer and organized the conference “Frontiers in Low Temperature Plasma Diagnostics X” in 2013 in the Netherlands. He has been for several years involved in the organization of the International Conference on Plasma Science (ICOPS) as organizing session chair or technical area coordinator and was a co-organizer of a session at the Material Research Symposium in 2015 and 2016. He was also a member of the program committee and session co-chair of the session “Plasma diagnostic and growth processes” at the “International Conference on Metallurgical Coatings and Thin Films” in 2017 organized by AVS.

AVS GRADUATE STUDENT AWARDS

2018 NATIONAL STUDENT AWARD FINALISTS

There are five (5) top-level named Graduate Student Awards and three (3) Graduate Research Awards, described below. The recipients of these awards are determined after a general competition with all the graduate research applicants and a presentation to the Awards Committee at the International Symposium.

The finalists are:

William DeBenedetti, Cornell University

Ryan Hackler, Northwestern University

Angela Hanna, Colorado State University

Zahra Hooshmand, University of Central Florida

Ann Lii-Rosales, Iowa State University

Monu Mishra, CSIR-National Physical Laboratory

Phuong Anh Nguyen, University of New Mexico

Jiancheng Yang, University of Florida

RUSSELL AND SIGURD VARIAN AWARD

The Russell and Sigurd Varian Award was established in 1982 to commemorate the pioneering work of Russell and Sigurd

Varian. It is presented to recognize and encourage excellence in graduate studies in the sciences and technologies of interest to AVS. The award is supported by Varian, Inc. It consists of a cash award, a certificate, and reimbursed travel support to attend the International Symposium.

NELLIE YEOH WHETTEN AWARD

The Nellie Yeoh Whetten Award was established in 1989, in the spirit of Nellie Yeoh Whetten, to recognize and encourage excellence by women in graduate studies in the sciences and technologies of interest to AVS. A fund to support the award was established by Timothy J. Whetten, friends and family of Nellie Yeoh Whetten, and AVS. The award consists of a cash award, a certificate, and reimbursed travel support to attend the International Symposium.

DOROTHY M. AND EARL S. HOFFMAN AWARD

The Dorothy M. and Earl S. Hoffman Award was established in 2002 to recognize and encourage excellence in graduate studies in the sciences and technologies of interest to AVS. It is funded by a bequest from Dorothy M. Hoffman. The scholarships consist of a cash award, a certificate, and reimbursed travel support to attend the International Symposium.

president of AVS in 1974 and held other positions of responsibility in the Society. The award consists of a cash award, a certificate, and reimbursed travel support to attend the International Symposium.

DOROTHY M. AND EARL S. HOFFMAN SCHOLARSHIPS

The Dorothy M. and Earl S. Hoffman Scholarships were established in 2002 to recognize and encourage excellence in graduate studies in the sciences and technologies of interest to AVS. They are funded by a bequest from Dorothy M. Hoffman. The scholarships consist of a cash award, a certificate, and reimbursed travel support to attend the International Symposium.

GRADUATE RESEARCH AWARDS

The Graduate Research Awards were established in 1984 to recognize and encourage excellence in graduate studies in the sciences and technologies of interest to AVS. Each consists of a cash award, a certificate, and reimbursed travel support to attend the International Symposium.

AVS FELLOWS

The membership level designated “Fellow of the Society” was established in 1993 to recognize members who have made sustained and outstanding scientific and technical contributions in areas of interest to AVS. These contributions can be in research, engineering, technical advancement, academic education or managerial leadership. This is a prestigious membership level to which members are elected. AVS Fellows receive a certificate.

2018 AVS FELLOWS

Heather Canavan, University of New Mexico

Donna Chen, University of South Carolina

Jeffrey W. Elam, Argonne National Laboratory

Daniel Gall, Rensselaer Polytechnic Institute

Grzegorz (Greg) Greczynski, Linköping University, Sweden

Subhadra Gupta, University of Alabama

Jeffrey Hopwood, Tufts University

Robert J. Madix, Harvard University

Paul Mayrhofer, Technische Universität Wien (TU Wien), Austria

Leonidas E. Ocola, IBM T.J. Watson Research Center

Philip Rack, University of Tennessee

François Reniers, Université libre de Bruxelles, Belgium

E. Charles Sykes, Tufts University

DIVISION AWARDS

Morton M. Traum Surface Science Division Student Award

The Surface Science Student Award was initiated in 1981. Morton M. Traum, then chair of the Surface Science Division, was the prime motivator in establishing the award. After Mort's untimely death on 1 December 1982, the Executive Committee of the Surface Science Division renamed the award in his memory. The Morton M. Traum Surface Science Division Student Award is presented annually for the best student paper based on work leading to a Ph.D thesis. The papers are judged on technical content and quality of presentation.

The 2018 winner will be announced in the Traum Student Award Ceremony, to be held on Thursday, October 25, at 12:30 pm in Room 203C of the Long Beach Convention Center.

Past Winners:

1981	Eric Stuve	1991	David Peale	2001	Jeppe Vang Lauritsen	2011	David Siegel
1982	Steven Gates	1992	Chaochin Su	2002	Seth B. Darling	2012	April Jewell
1983	Ann Smith	1993	Anna Swan	2003	Marcel A. Wall	2013	Xiaofeng Feng
1984	Hans Gossman	1994	Bert M. Müller	2004	Emrah Ozensoy	2014	Feng Zhang
1985	Duane Outka	1995	Frank Zimmermann	2005	Jan Haubrich	2015	Holly Walen
1986	Greg Sitz	1996	Joseph Carpinelli	2006	Petro Maksymovych	2016	Andrew Therrien
1987	Michael Henderson	1997	Barry Stipe	2007	Bogdan Diaconescu	2017	Rachael Farber
1988	Jeff Hanson	1998	Alexander Bogicevic	2008	Jeibin Sun		
1989	Yunong (Neal) Yang	1999	Jongin Hahn	2009	Qing Hua		
1990	Benjamin Wiegand	2000	Anders Carlsson	2010	Heather Tierney		

John Coburn and Harold Winters Student Award in Plasma Science and Technology

In 1994, the Plasma Science and Technology Division established the Coburn and Winters Award in honor of John Coburn and Harold Winters. Coburn and Winters have made pioneering contributions to the field of plasma science, especially in plasma processing and plasma-surface interactions. Their work has provided inspiration for countless students entering the field of plasma science and enhanced the experiences of students by both example and mentorship. The 2018 winner will be announced in the Traum Student Award Ceremony, to be held on Thursday, October 25, at 12:30 pm in Room 104A of the Long Beach Convention Center.

Past Winners:

1994	Bruce Kellerman	2001	Nicholas Fuller	2008	Emile Despiau-Pujo	2014	Paul Rumbach
1995	Not Given	2002	Lin Sha	2009	Yang Yang	2015	Hu Li
1996	Jane Chang	2003	Jan Benedikt	2010	Bhavin Jariwala	2016	Souvik Ghosh
1997	Mikhail Malyshev	2004	Jun Belen	2011	Harald B. Profijt	2017	Hyun-Jwon Roh
1998	Catherine Labelle	2005	Joseph Végh	2012	Joe Lee		
1999	Erwin Kessels	2006	Lin Xu	2013	Rohan Chaukulkar		
2000	Siva Kanakasabapathy	2007	Joydeep Guha	2014	Bastien Bruneau		

Leo M. Falicov Student Award

The Leo M. Falicov Student Award has been established in memory of Prof. Leo M. Falicov to recognize outstanding research performed by a graduate student in areas of interest to the Magnetic Interfaces and Nanostructures Division. Finalists will be selected on the basis of abstract submission, and will each receive an award upon attending the AVS 65th International Symposium and Exhibition and presenting their paper in an oral session. The Best Student Paper Award winner will be selected on the basis of the oral presentation, considering quality of research and clarity of presentation.

Past Winners:

1999	W.H. Rippard	2004	Maria Torija	2008	Zhuhua Cai	2013	Jason Kawasaki
2000	R.D. Portugal	2005	Jessica Hilton	2009	Wei Han	2013	Kaida Yang
2001	D.B. Schultz	2006	Randy Dumas	2010	Kangkang Wang	2014	Henry Wortelen
2002	E.L. Biizdaca	2007	David Wisbey	2011	Juan Colon-Santana	2015	Andrade-Oana Mandru
2003	Tiffany Kaspar	2007	John Strachan	2012	Chloe Baldasseroni	2017	Oren Ben Dor

DIVISION AWARDS

Paul H. Holloway Young Investigator Award

The Thin Film Division is pleased to announce Jason Kawasaki, University of Wisconsin, as the 2018 awardee of the Paul H. Holloway Young Investigator Award. Dr. Kawasaki has been given the award for epitaxial growth and elucidation of electronic structure of low-dimensional quantum materials, including Heusler compounds, transition metal oxides, and rare-earth compounds.

This award is named after Professor Paul H. Holloway of the University of Florida who has a distinguished and continuing career of scholarship and service to AVS. The nominee is a young scientist or engineer who has contributed outstanding theoretical and/or experimental work in an area important to the Thin Film Division of AVS. The nominee's Ph.D. or equivalent degree must have been earned less than 7 years prior to January 1 of the award year. The award consists of a cash prize, a certificate citing the accomplishment of the recipient, and an honorary lecture at one of the TFD sessions at the International Symposium.

Past Winners:

2009	Suneel Kodambaka, UCLA	2014	Andrea Illiberi, Dutch Inst for Applied Scientific Res (TNO)
2010	O. Martin Ntwaaborwa, Univ. of the Free State, South Africa	2015	Cunjian Yu, University of Houston
2011	Sumit Agarwal, Colorado School of Mines	2016	Neil Dasgupta, University of Michigan
2012	Franklin Tao, University of Notre Dame	2017	Bharat Jalan, University of Minnesota
2013	Per Eklund, Linköping University		

Nanometer-scale Science and Technology Division Awards Competition for Graduate Students and Postdocs

The Nanometer-scale Science and Technology Division (NSTD) Graduate Student and Postdoctoral Awards bring recognition to outstanding work by early-career scientists giving oral presentations in NSTD sessions at AVS International Symposia. In addition to presenting their work in the standard NSTD sessions, finalists also make brief presentations at the NSTD Awards Competition. This public special event is held at noon on Wednesday of the symposium in the same room as the standard NSTD sessions. The winners will be selected based on the quality of the talk, the responses to questions, and the level of the research. Winners in the graduate student and postdoctoral categories are announced at the close of the competition.

Graduate Student Award Winners:

2002	Jeremy Steinshinder	2007	Jacob Palmer	2013	Cédric Barroo
2003	Cheol-Soo Yang	2008	Qing Hua Wang	2014	Deep Jariwala
2004	Qiguang Li	2009	Mehmet Baykara	2015	Wei Bao
2005	Kiu-Yuen Tse	2010	Farzad Behafarid	2016	Alma Perez-Perinno
2006	Tracie Colburn	2011	Justice Alaboson	2017	Xiaolong Liu
2006	Dirk Weber	2012	David Reid		

Nanotechnology Recognition Award

The Nanotechnology Recognition Award recognizes members of NSTD for outstanding scientific and technical contributions in the science of nanometer-scale structures, technology transfer involving nanometer-scale structures, and/or the promotion and dissemination of knowledge and development in these areas. The Award will be presented before the recipient's talk at the AVS International Symposium. The 2018 Awardee is Chennupati Jagadish, Australian National University

Past Winners:

2001	Nancy Burnham, Worcester Polytechnic Institute	2013	Joseph Lyding, University of Illinois
2004	Harold Craighead, Cornell University	2014	Dawn A. Bonnell, University of Pennsylvania
2009	Joseph Stroscio, NIST	2015	Meyya Meyyapan, NASA Ames Research Center
2010	Roland Wiesendanger, University of Hamburg	2016	Ricardo Garcia, CSIC
2011	Phaedon Avouris, IBM Yorktown Heights	2017	Mark Hersam, Northwestern University
2012	Fleming Besenbacher, Aarhus University		

TFD Distinguished Technologist Award

The Thin Film Division is pleased to announce Chris Tasker from Oregon State University as the 2018 awardee of the Distinguished Technologist Award.

This award was established to recognize individuals who have provided exceptional technical support for thin film research or related development activities, without whose support many advancements in thin film research would not be possible. Nominees must have provided significant technical support to a laboratory research or development program in an area of interest to the Thin Film Division. Nominations are expected to come from an active AVS member. This award was created and endowed in 2015 by the New Mexico Chapter of AVS to honor its founders and their many contributions. The award consists of a cash prize, travel support for the AVS International Symposium, and a plaque citing the accomplishments of the recipient.

Past Winners:

2015	Catherine Sobczak, Sandia National Labs	2017	Janneke Zeebregts, Eindhoven University of Technology
2016	Michael Lopez, Sandia National Labs		

AVS Student Activities

Did you know that 25% of AVS membership is comprised of students? You represent the future of AVS and we encourage you to take advantage of the following opportunities and services:

Student Chapters

Meet future colleagues and employers and form friendships while sharing common interests in a range of science and technology topics during various chapter activities.

Student Awards

Apply for both a **National and Divisional Level Award**. National Student Awards include **five top-level awards and multiple Graduate Research Awards**. All AVS National Student Awards are presented during the Awards Ceremony at the International Symposium and **include travel support as well as a cash award**.

Career Services

Connect with the finest job seekers and companies in physics, engineering, vacuum science, and technology using the **AVS Online Career Center** which partners with the Physics Today, American Association of Physics Teachers, American Physical Society, and IEEE Computer Society.

Attend our annual **Onsite Career Center/Mini Job Fair** at the AVS International Symposium and Exhibition and **meet with potential employers and gain interviewing skills during the conference**.

Short Courses

Broaden your knowledge and develop new job skills by attending an **AVS Short Course**. Courses offer basic and advanced training in vacuum, materials, processing, and interfaces.

AVS Publications and Technical Libraries

Delve into our **four journals that cover a variety of materials, processing, and interfaces topics**—access is easy using the online **AVS Publications Digital Library** or **iAVS**.

No time to attend a talk? Discover our newest benefit in the **AVS Technical Library, Presentations on Demand** featuring recorded talks from AVS Symposia. The Technical Library also provides access to books, monographs, and other scientific resource materials.

Stay Connected



212-248-0200



Join Us on
LinkedIn!



Like Us on
Facebook!



Follow Us
on Twitter





Spectra Simplified



LEARN MORE:

AVS Member Center Demo:

Tuesday, October 23rd @ 9am

Exhibitor Technology Spotlight Session:

Tuesday, October 23rd @ 4pm

AIP Publishing Booth 318

espectra.aip.org

Looking for an easier way
to analyze spectral data
and share your results with
your collaborators?

eSpectra lets you plot, compare
and share your data in just a
few clicks.

eSpectra



EXHIBIT HALL EVENTS



The AVS 65 Exhibits provides you with the opportunity to visit the companies who offer the products and services which enable you to perform your research. Come learn about the most innovative technology and services available in the industry. Technology Spotlight Sessions take place during session breaks and will showcase new products and services.

EXHIBIT HALL SPECIAL ATTRACTIONS & EVENTS

Ask The Experts - *Hosted by the AVS Vacuum Technology Division*

AVS Career Center

Exhibitor Technology Spotlight Sessions

AVS Membership & Education Booth

AVS Store: Gifts & Souvenirs

Free Morning Coffee • Lunch • Afternoon Refreshments

Art Zone Display & Competition

Daily Raffle Drawings

E-Mail Pavilion with Laptops, Printing and Charging Station

Caricatures & Foosball Tournament

Competitions & Networking Events

EXHIBIT HALL SCHEDULE

Oct. 23 Tuesday 10am - 5:00pm
Oct. 24 Wednesday 10am - 4:30pm
Oct. 25 Thursday 10am - 2:30pm

Exhibitors displaying their latest products



Media, Editors & Publications



Foosball Tournament



Art Zone/Contest

EXHIBIT FINALE

THURSDAY, OCTOBER 25

EVENTS:

- Lunch & Refreshments
- Art Contest Prize Winners
- Raffle Drawings
- Grand Prize Raffle Drawing
- Foosball Championship
- Caricatures

Long Beach Convention Center • Hall A



AVS-65 International Symposium & Exhibition

Long Beach Convention Center • Long Beach, California • October 21 - 26, 2018

AVS-65 EXHIBITING COMPANIES

Entrance to the Exhibits is Free and Open to the Public October 23 - 25, 2018 • www.avs.org

Across International

AdValue Technology
Advanced HiVac Application Co.,LTD
Agilent Technologies, Vacuum Products Div.
AIP Publishing
Air Liquide Electronics-Balazs NanoAnalysis
AJA International, Inc.
American Institute of Physics
Amuneal Mfg Corporation
ANCORP
Anderson Dahlen-APPLIED VACUUM DIV.
Anton Paar USA
Applied Surface Technologies
Atlas Technologies
Attocube Systems, Inc.
AVS Ask The Experts - Vacuum Tech.
AVS Art Zone & Contest
AVS Career Center
AVS E-Mail Pavilion & Charging Station
AVS Exhibitor Technology Sessions
AVS Foosball Tournament
AVS Future Sites
AVS Publications
AVS Raffle Zone
AVS Special Events - Caricaturists
AVS Store & Membership
BellowsTech, LLC
BihurCrystal S.L.
Bruker Nano Surfaces
Centrotherm Clean Solutions
Cosmotec, Inc.
CryoWorks, Inc.
CS Clean Solutions, Inc.
Delcom Instruments
Denton Vacuum LLC
Duniway Stockroom Corp.
Ebara Technologies
Edwards Vacuum
EP Laboratories, Inc.
Extrel
Ferrovac GmbH
Fischer Technology, Inc.
Gamma Vacuum
GNB KL Corporation

HeatWave Labs Inc.
Heidelberg Instruments, Inc.
Helium Leak Testing, Inc.
Hiden Analytical, Inc.
Hine Automation
HS-Group GmbH
HVA, LLC
INFICON
InRedox LLC
Instrument Technology Research Center, NARLabs
InstruTech, Inc.
Intel Corporation
ION-TOF USA
J.A. Woollam Co., Inc.
Kashiyama-USA Inc.
Kaufman & Robinson, Inc.
Kimball Physics Inc.
Kratos Analytical, Inc.
Kurt J. Lesker Company
Kurdex Corporation
Kyungwon Tech Co., Ltd.
LAWRENCE LIVERMORE NATIONAL LABS
Leybold USA Inc.
MANTIS-SIGMA
Matheson Tri-Gas, Inc.
McAllister Technical Services, Inc.
MDC Vacuum Products, LLC
MeiVac, Inc.
Micro Photonics
MKS Instruments
MODION®
Neaspec GmbH
NIST
Nonsequitur Technologies
Nor-Cal Products, Inc.
Omley Industries, Inc.
Osaka Vacuum USA, Inc.
Park Systems, Inc.
Pfeiffer Vacuum Technology, Inc.
PHPK Technologies
Physical Electronics

Physics Today Exhibitor Lounge
Picosun USA, LLC
Plasma Process Group, Inc.
Precision Plus Vacuum Parts
Prevac sp. z o.o.
QEI Corporation
R.D. Mathis Company
RASIRC
RBD Instruments, Inc.
Refining Systems
RF VII Inc.
RHK Technology Inc.
SAES Group
ScientaOmicron, Inc.
Scientific Instrument Services, Inc.
Semilab
Solberg Manufacturing
Solecon Laboratories, Inc.
Solid Sealing Technology, Inc.
SPECS-TII, Inc.
SPI Supplies
Staib Instruments
Strem Chemicals, Inc.
Surface Science Integration
Super Conductor Materials
SynSysCo
TDK-Lambda Americas HP Division
Technetics Group
Tech-X Corporation
Teledyne Hastings Instruments
Thermionics Laboratory, Inc.
Thermo Fisher Scientific
Torreyvac Inc.
UC Components
UHV Design Ltd.
ULVAC, Technologies, Inc.
United Mineral and Chemical Corp.
VACGEN Ltd.
Vacuum Research Corporation
VAT
Veeco Instruments
Williamsburg Scientific Instruments LLC
Yugyokuen Ceramics Co., Ltd.
zeroK NanoTech

EXHIBITOR TECHNOLOGY SPOTLIGHT SESSIONS

Stage Area of Exhibit Hall (Booth 168) • Long Beach Convention Center

20-minute interactive presentations scheduled during the technical session breaks in the Stage Area of the exhibit hall. Gain insight to the latest products and services offered by the exhibitors that benefit everyone including technicians, engineers and scientists as well as fellow manufacturers.

FREE ADMISSION

TUESDAY, OCTOBER 23

10:20am Kurt J. Lesker Company

IMPULSE HIPIMS Power Supply with Positive Pulse Option Advantages

Presenter: Jason Hrebik

10:40am Across International

Choosing the Proper Equipment for Vacuum Heat Treatment

Presenter: Rachael Stene

12:40pm Thermo Fischer Scientific UK

In this presentation we will highlight how the multi-technique capabilities of the Thermo Scientific Nexsa system can be used to analyse samples from a range of application areas.

Presenter: Tim Nunney

1:00pm Kratos Analytical

Exploring the Capabilities of a Modern XPS Spectrometer: In-situ Surface Preparation & Modification

Presenter: Adam Roberts

1:20pm Prevac

Design and Characterization of Nanomaterials using PREVAC's Research Platforms

Presenter: Lukasz Walczak

1:40pm Agilent, Vacuum Products Division

Agilent's New Helium Leak Detector

Presenter: John McLaren

2:00pm Physical Electronics

Auger Multi-Technique: EDS, EBSD, BSE, FIB

Presenter: John Newman

4:00pm AIP Publishing

eSpectra, your Data, and your Collaborations

An easier way to analyze spectral data and share your results with your collaborators. eSpectra lets you plot, compare and share your data in just a few clicks.

Presenter: Jessica Hoy

WEDNESDAY, OCTOBER 24

10:20am Scienta Omicron

HAXPES-Lab: A Laboratory Based System for HAXPES Measurements

Presenter: Susanna Eriksson

10:40am Fischer Scientific

Coatings Characterization Solution from Fischer Technology - XRF, Nanoindentation and Progressive Load Scratch

Presenter: Rahul Nair

12:40pm Scienta Omicron GmbH, Germany

The TESLA JT SPM

Presenter: Markus Maier

1:00pm MKS Instruments

Wide-Range Cold Cathode Transducer: Applications and Market Update

Presenter: David Kelly

THURSDAY, OCTOBER 25

10:00 AVS Presidential Panel

A special panel comprised of past AVS presidents discussing the evolution and direction of AVS as a Society and each president's initiatives, issues, and highlights of their Presidential years.

Joe Greene; Gary McGuire; Rudy Ludeke; John Russell; Alison Baski; Steve George



ASK THE EXPERTS !!!!!

Troubleshooting Mysteries? Contamination Problems?
System Configuration Questions? Just want to make your vacuum better?

What's the best gauge
for the
1e-10 Torr range ?

How do I
detect a
Virtual Leak ?

What is my
RGA
telling me?

How do I
control/eliminate
water outgassing?

Are you having problems with troubleshooting, process control? Maybe all our years of experience, successes and failures can help point you in the right direction or spark an idea! An unbiased, open forum with the desire to solve vacuum related issues. Come chat with us at Booth 362.

Who are we? We are volunteers from the AVS Vacuum Technology Division and our goals are to understand the intricacies of vacuum technology and to help you solve problems.

PUT US TO THE TEST !

Whether you're new to vacuum technology or have 30 years of experience, stop by the Ask the Experts booth to discuss your vacuum concerns... maybe you can even provide us with some new tips and suggestions or maybe you would like join our team of experts!!

Come challenge our experts and receive a UL Listed Power Bank (while supplies last) and join the A.T.E. raffle for an iPad!



Ask the Experts!... Exhibit Hall Booth #362

Sponsored by Duniway Stockroom Corporation and SAES Getters
Hosted by the AVS Vacuum Technology Division



Archives and online discussion forum
year round at www.avs.org/forum.aspx

Exhibit Hall • Booth 362

HISTORICAL PERSPECTIVES OF THE AVS: PAST PRESIDENTS' PANEL

Thursday, October 25, 2018, 10:00 a.m.–12:00 noon
Exhibit Hall A, Stage Area Booth 168, Long Beach Convention Center

Please join us as some of our Past Presidents share some highlights of their respective Presidencies as well as the scientific climate of that time. Their brief presentations will be followed by a Panel Discussion where questions from the audience will be welcome.



AVS 1989 President

Dr. Joe Greene is the D.B. Willett Professor of Materials Science at the University of Illinois, the Tage Erlander Professor of Materials Physics at Linköping University, Sweden, and a Chaired Professor at the National Taiwan University of Science and Technology. The focus of his research has been the development of an atomic-level understanding of adatom/surface interactions during the dynamic process of vapor-

phase crystal growth in order to controllably manipulate nanochemistry, nanostructure, and, hence, physical properties. His work has involved film growth by all forms of sputter deposition, solid and gas-source MBE, UHV-CVD, MOCVD, and ALE. Joe has published more than 625 papers and review articles, 29 book chapters, and co-edited four books in the general areas of crystal growth, thin-film physics, and surface science.

He is currently Editor-in-Chief of *Thin Solid Films* and Past Editor of *CRC Critical Reviews in Solid State and Materials Sciences*. He is active in AVS where he has served as a Trustee, Chair of the Thin Film and Advanced Surface Engineering Divisions, member of the Board of Directors, President of the Society, and is currently Clerk. He has also chaired the Thin Film Division, the Education Committee, and the Emerging Countries Committee of the International Union for Vacuum Science, Technique, and Applications (IUVSTA) and served on the Governing Board of the American Institute of Physics and the Executive Committee of the Materials Physics Division of APS. He is presently the AVS representative to IUVSTA.

Major awards include the AVS John A. Thornton Memorial Award (1991); the Tage Erlander Award (1991) from the Swedish Natural Science Research Council; Senior University of Illinois Scholar (1991); an Honorary Doctor of Science Degree (1992) from Linköping University; Fellow of AVS (1993); the Technical Excellence Award from the Semiconductor Research Corporation (1994); the 1996 DOE Award for Sustained Outstanding Research; the 1998 David Adler Award in Materials Physics from the American Physical Society; Fellow of the American Physical Society (1998); the 1998 Aristotle Award from SRC; the D.B. Willett Professor of Engineering; the 1999 MRS David Turnbull Award; the 2001 International Scientist of the Year, election to the U.S. National Academy of Engineering in 2003; Fellow of the Materials Research Society (2013); Lifetime Achievement Award (2013) from the Taiwan Association for Coatings and Thin Film Technology; the SVC Mentor Award (2015); the 2016 World Expert Lecturer Award, University of the Philippines; the Sarton International History of Science Award from the History of Science Society (2016); elected in 2017 as a member of the EU Academy of Sciences, and received the Nathaniel Sugarman Award from SVC in 2018.



AVS 1997 President

Dr. Gary E. McGuire is the President and Chief Technical Officer of the **International Technology Center**, a non-profit research corporation which has fostered two spin-off small businesses, **Adámas Nanotechnologies, Inc.** and **Rivis, Inc.** Dr. McGuire received his Ph.D. from the University of Tennessee

and conducted Post-doctoral studies at Oak Ridge National Laboratory before joining Texas Instruments where he conducted research on surfaces of semiconductor materials. Later after joining Tektronix he held several management positions directing research in electronic, display and color copier materials. He joined the Microelectronics Center of North Carolina in 1987 and was initially the Director of Electronic Materials and Devices and later Director of Business Development.

Dr. McGuire has over 130 publications plus 35 books and book chapters. He was Series Editor for *Electronic Materials and Processing* (48 text) for William-Andrews Publishers, an imprint of Elsevier. He has served as Editor of the *Journal of Vacuum Science and Technology B*, the *Journal of Electron Spectroscopy, Surface Science Spectra*, and served on the Editorial Boards of *Critical Reviews in Solid State and Materials Science* and the *Journal of Surface and Interface Analysis*.

He has served in a number of AVS capacities including President, member of Board of Directors, Board of Trustees and Chair of the Electronic and Photonics Division. He is an AVS Fellow and Honorary Member. He is recipient of the Nerkin Award jointly with Olga A. Shenderova for contributions to the development of nanodiamond synthesis, processing, science, and applications.



AVS 2002 President

Dr. Rudolf (Rudy) Ludeke is an Emeritus Research Staff Member of the **IBM Thomas J. Watson Research Center** in Yorktown Heights, NY. He studied electrical engineering at the University of Cincinnati and received an M.A. and Ph.D. degrees in applied physics from Harvard University in 1968. At IBM his research focused on the physics of semiconductors, specifically surface and interface characterization of heterostructures and Schottky barriers. He has published over 130 papers in the open literature and 3 book chapters. Among research highlights are the co-invention of the man-made semiconductor superlattice and the characterization of surface states using core level spectroscopies; both were recognized with IBM Corporate Outstanding Innovation Awards. External recognitions include an Alexander von Humboldt Fellowship in 1977–78 at the Max Planck Institute for Solid State Physics, Stuttgart, Germany, and election to Fellow of the American Physical Society. At IBM he has held a number of management positions.

For AVS, Rudy has served as chair of EMPD and the Constitution and By-Laws Committee. He was elected to the AVS Board of Directors in 1997, served as AVS President in 2002 and subsequently as Trustee. Rudy was presented with an AVS Honorary Membership award in 2009. Presently he serves on the Outreach/Governance/ Public Science committee and coordinates AVS's annual participation in the Congressional Visits Day. He was also the lead organizer of 7 American Institute of Physics (AIP) co-sponsored Industrial Physics Forums held at AVS International Symposia.

Rudy is the AVS designated director on the Board of Directors of AIP. He was elected interim Chair of the AIP Board and of the AIP Publishing Board of Managers, serving for 9 months in 2016.

HISTORICAL PERSPECTIVES OF THE AVS: PAST PRESIDENTS' PANEL



AVS 2008 President

Dr. John N. Russell, Jr. is the Superintendent of the Chemistry Division at the **U.S. Naval Research Laboratory (NRL)**. As a member of the Senior Executive Service (SES), he provides executive and technical leadership to approximately 250 government scientists and engineers, military officers, contractors, postdoctoral associates, and students engaged in a materials chemistry program comprised of basic research, applied research, development, and evaluation, which leads to the creation, adoption, and application of new concepts, principles, methods, and techniques that meet the materials and analytical needs of the Navy.

Russell earned a Bachelor of Science (cum laude) in chemistry in 1981 from Dickinson College, and a doctorate in physical chemistry from the University of Pittsburgh in 1987. After a postdoctoral fellowship at the Corporate Research Laboratory of Exxon Research and Engineering Company, he joined the research staff at NRL in 1989. Since 1999, he has held successive roles of greater scope, leading the Functional Materials Section until 2005, and the Surface Chemistry Branch from 2005 to 2018; Russell was selected to the SES and his current position leading the Chemistry Division in June 2018.

As a researcher, he has authored more than 80 peer-reviewed scientific research papers, which have been cited more than 4,600 times with an h-index of 30 (Google Scholar), and holds one U.S. patent. He has given numerous invited and plenary presentations at universities, and international conferences, and from 2013–15 he was detailed part-time to the Chemical and Biological Defense Department (J9CB) of the Defense Threat Reduction Agency where he developed programs within the chemical defense portfolio focused on in operando surface science and plasmonically-assisted photo-catalysis.

Dr. Russell was recognized in 2006 as a Fellow of the American Vacuum Society (AVS). He served as AVS president in 2008, and is a recipient of the AVS Honorary Membership Award, the society's highest honor. He was selected in 2010 as a Fellow of the American Chemical Society (ACS), and is a member of the editorial board of Chemical and Engineering News. He also serves on the ACS Joint-Board Council Committee on Publications, which oversees all ACS journals and editors. As a member of the NRL research staff, Dr. Russell received the Navy Meritorious Unit Commendation Award in 1996 and 2006, and an NRL Research Publication (Berman) Award in 1997.



AVS 2012 President

Dr. Alison A. Baski is Dean of the **College of Science** and Professor of Physics at **California State Polytechnic University, Pomona**. Prior to her arrival at Cal Poly Pomona in 2016, she spent 20 years at Virginia Commonwealth University and served as department chair (2006–2011), executive associate dean (2011–2015) and interim dean (2015–2016) in the College of Humanities and Sciences. Alison earned a B.S. in engineering physics from the University of Colorado-Boulder (1987) and a Ph.D. in applied physics from Stanford University (1991), followed by postdocs at BASF (1991–1993) and the Naval Research Laboratory (1993–1996). She has authored 110 publications in peer reviewed journals and proceedings and has given numerous invited and conference talks on her research. Alison was recognized as an AAAS Fellow in 2010 and

as an AVS Fellow in 2015 for her “contributions to the fundamental investigation of semiconductor surfaces using scanning probe techniques and for STEM leadership with the university, community and profession.” Since 1990, Alison has been an active member of AVS and has served in a variety of capacities, including as Program Chair (2005–2006) and Chair (2006–2007) of the Surface Science Division, as a member of the Board of Directors (2008–2010), President (2012), chair of the Governance Committee (2014–2015), member of the Publications Committee (2015–present) and as the AVS Member Society representative to AIP (2015–present). For more than a decade, she has also helped represent AVS during its annual participation in STEM Congressional Visits Day to highlight the importance of STEM research and education to our congressional representatives. This event is organized by ASTRA (Alliance for Science and Technology Research in America) and in 2018 Alison joined their Board of Directors to provide her perspective as a STEM researcher/educator and as a member of AVS for nearly three decades.



AVS 2014 President

Dr. Steven M. George is a Professor in the Department of Chemistry at the **University of Colorado at Boulder**. He received his B.S. in Chemistry from Yale University (1977) and his Ph.D. in Chemistry from the University of California at Berkeley (1983). Dr. George is directing a research effort focusing on atomic layer deposition (ALD), atomic layer etching (ALE) and molecular layer deposition (MLD). This research is examining new surface chemistry, measuring thin film growth and etching rates, and developing new applications and reactors for ALD, ALE and MLD. Dr. George has more than 400 publications in the areas of thin film growth and etching, surface science, and physical chemistry. He has over 24,000 total citations and his H-index is 78 (September 2018). In addition, he currently has 19 issued U.S. or PCT patents and 11 U.S. or PCT patent applications undergoing review.

Dr. George has been active in the AVS. He was a Trustee (2007–2009), Chair of the Trustees (2009) and on the Board of Directors (2010–2012). He also served as President-Elect (2013), President (2014) and Past-President (2015). Dr. George was also Program Chair for the AVS-52 International Symposium in Boston, Massachusetts (2005). He was Vice Chair (2001) and Chair (2002) of the Thin Film Division (TFD). In addition, he has been on the TFD Program Committee since 1999 and the PSTD Program Committee since 2016. He was also a member of the Executive Committee of the Electronic Materials and Processing Division (1996–1997). Dr. George is currently on the AVS Steering Committees for the International Conference on Atomic Layer Deposition and the International Atomic Layer Etching Workshop. He also teaches a one-day short course on ALD and introduced a half-day webinar on ALE in 2018.

Dr. George has received a number of awards including the AVS John A. Thornton Memorial Award (2017) and the ALD Innovation Award from the AVS International Conference on Atomic Layer Deposition (2013). He also received an R&D 100 Award for Particle-ALD™ (2004), an NSF Creativity Award (2002–2004), an NSF Presidential Young Investigator Award (1988–1993), and an Alfred P. Sloan Foundation Fellowship (1988). Dr. George is a Fellow of the AVS (2000) and the APS (1997). He is also a co-founder of ALD NanoSolutions, Inc., a company that is working to commercialize ALD technology.

SYMPOSIUM PLENARY LECTURE

“The Internet of Things: Shaping the Future of the Medical Device Industry”

**Monday, October 22, 2018, 5:00 p.m., Grand Ballroom
Long Beach Convention Center**



Dr. Kim Chaffin

Distinguished Scientist and Bakken Fellow in Strategic and Scientific Operations at Medtronic, plc.

The internet has irreversibly changed the way humans interact with each other. Now, we are faced with the Internet of THINGS (IoT). Not only are people connected through a digital network, so are our THINGS. THINGS include our cell phones, our houses and even our medical devices. These THINGS have the capability to store and track data. Prediction is the next evolutionary step of our connected THINGS. Sensors are key enablers to a future where patients are online, and their medical devices are predictive. There are several technical challenges facing sensors development in the medical device industry, which include long term material stability, recharge, integrated data streams, and improved assimilation at biological-device interface. The unique location of these sensors living within the human body make technical solutions particularly challenging. In addition, sensors integration is made more difficult

because of our high reliability requirements and regulated medical device industry where the ecosystem creation lags the technology advancements of IoT. We need to define how IoT will impact the Medical Device industry and improve patient outcomes. Who should have access to onboard medical device data streams? How should these data streams be repackaged to change patient behavior? Innovation in this space will change the role of medical devices in patient management, setting us on a new trajectory, perhaps where healthy people are implanted as a preventative measure. Imagine a future where a medical device not only reacts to a medical event after it has occurred but proactively alerts, providing critical instructions for self-intervention and offering an opportunity to avoid the event entirely.

Plenary Panel

“Potential Impact of IoT and Areas of AVS Engagement” (Immediately following Plenary Lecture), 6:15–7:00 p.m.

Panelists:

Dr. Kim Chaffin – *Medtronic, plc* • Prof. Michael Cima – *MIT* • Prof. Subu Iyer – *UCLA* • Dr. Enid Kivuti – *Multek Corp.*
• Gary W. Rubloff, *University of Maryland* • Dr. Art Wall – *NextFlex*

Panelists will field questions and engage with the AVS community.

Kim Chaffin has responsibility for leading the enterprise wide technology forecasting effort as well as directing research projects within the Corporate research organization. In her technology forecasting role, Kim works with the four business groups to predict the technology areas that will be critical to the future of the enterprise. Recently, Kim has lead a deep dive into the medical sensors space assessing technology gaps that need to be filled to meet a future where patients will be online through their sensor data and as a result they will expect prediction algorithms to prevent hospitalization. Currently, Kim is leading a technology deep dive into the regenerative medicine space to help assess the scalability of academic discoveries to the large patient population that is served by Medtronic. Kim is an expert in polymer thermodynamics and characterization, especially as it relates to structure-property relationships that govern the long-term stability of and performance copolymers, the bio-resorbable properties of scaffold materials, the strength of adhesives and associated cure kinetics, diffusion and drug delivery, polymer processing, and accelerated testing. Kim is frequently consulted for her technical problem-solving expertise (both within and external to Medtronic) and participates on numerous technical review boards and maintains active research collaborations with her academic colleagues. Kim actively teaches both inside and outside of Medtronic, where her focus includes polymer mechanics, adhesion, and medical device reliability. Kim has a strong track record for mentoring in both the Medtronic technical community and in the community at large, where her outside focus is science outreach for young people. Kim has a Ph.D. in Chemical Engineering from the University of Minnesota and master's and bachelor's degrees in Chemical Engineering from the University of Michigan. She is a licensed Professional Engineer in the state of Minnesota. Prior to joining Medtronic in 1999, Kim worked in the automotive industry (Ford Motor Company) on the design and use of adhesives in both product development and manufacturing roles. She is an inventor on 15 issued patents and an author on many peer reviewed publications. Kim recently returned to Minneapolis after a three-and-a-half-year assignment in Switzerland.

TECHNICAL PROGRAM

Brief summaries of each program theme are provided below. Symposium presenters represent the best and brightest from academia, industry, & government research labs around the world. Start filling your week's schedule with must-see, career enhancing sessions.

2D MATERIALS FOCUS TOPIC (2D):

The 2D materials focus topic will review the world-wide effort exploring 2D materials, including their synthesis, characterization, properties, and applications. More specifically, the presentations will cover growth and fabrication; properties including electronic, magnetic, optical, mechanical, thermal properties; characterization including microscopy and spectroscopy; surface chemistry, functionalization, bio and sensor applications; dopants, defects, and interfaces; nanostructures including heterostructures; device physics and applications; novel 2D materials; and novel quantum phenomena in 2D materials.

ACTINIDES AND RARE EARTHS FOCUS TOPIC (AC):

Actinides and rare earths exhibit many unique and diverse physical, chemical and magnetic properties resulting in large part to the complexity of their 5f and 4f electronic structure. The Actinide and Rare Earth Focus Topic Sessions focus on the chemistry, physics and materials science of f-electron materials. Emphasis will be placed upon the 4f/5f electronic and magnetic structure, surface science, thin film properties, and applications to energy-related issues. The role of fundamental f-electron science in resolving technical challenges posed by actinide materials will be stressed, particularly with regard to energy applications, including energy generation, novel nuclear fuels, and structural materials. Both basic and applied experimental approaches, including synchrotron-radiation-based and neutron-based investigations, as well as theoretical modeling computational simulations, will be featured to reconcile the observed behavior in these complex materials. Of particular importance are the issues important to nuclear energy and security, including fuel synthesis, oxidation, corrosion, intermixing, stability in extreme environments, prediction of properties via bench-marked simulations, separation science, and forensics. Specific sessions will be devoted to a continued, focused emphasis on the advances in the theory and measurements of core-level spectroscopies for the study of actinides and rare earths. Focus Topic emphasis will address advances in chemistry/materials sciences for environmental management and the participation of early career scientists. The shared sessions will be with Applied Surface Science, Magnetic Interfaces/Nanostructures, and the Synchrotron Radiation and FEL Focus Area.

EXTENDING ADDITIVE MANUFACTURING TO THE ATOMIC SCALE FOCUS TOPIC (AM):

This Focus Topic will highlight progress in nanometer and atomic scale fabrication processes leveraging focused electron beams and scanned probe techniques as manipulation tools. Topics will include 3D nanoprinting, single atom manipulation, feedback control and automation, and atomic-scale device fabrication.

As the cutting edge of manufacturing edges into sub ten-nanometer length scales, subtractive processes such as lithography will become inadequate for many applications, motivating nanoscale additive processes. Analogous to macroscopic Additive Manufacturing, micro- and nanoscale additive manufacturing is becoming commonplace with E-beam/ion-beam induced deposition (E/IBID) used routinely in dual beam systems as a miniaturized "welding" method for sample preparation. Additionally, scanned probe techniques have shown demonstrations of additive manufacturing by various methods. Controlled movement of single atoms and construction of materials/

molecules atom-by-atom hold great promise for future nanotechnology and miniaturization, both with scanned probe as well as electron beam techniques. Here, we will highlight the recent progress in this field and provide a forum for researchers to push the boundaries of additive manufacturing to the ultimate precision at the atomic level.

ADVANCED NANOPHOTONICS METROLOGY FOCUS TOPIC (AN):

The newly emerged field of nanophotonics have recently brought considerable interest in developing photonics-based nanodevices for various metrology solutions, which have the potential to outperform and replace legacy based metrology. The "Advances in Nanophotonics Metrology" (AN) focus topic will highlight the challenges and the latest development in nanophotonics metrology. It will cover various sensing application such as metrology of physical, chemical and biological properties, frequency synthesis on a photonic chip, and cold-atom based nanophotonic sensors.

APPLIED SURFACE SCIENCE DIVISION (AS):

The Applied Surface Science Division (ASSD) provides a forum for research in the preparation, modification, characterization, and utilization of surfaces in practical applications. Areas of interest range from nanoscience, polymers, and semiconductor processing to forensic science and biotechnology. The Division has long been the premier gathering place for the global surface analysis community, with historical concentrations in techniques such as SIMS and XPS/Auger spectroscopies, including presentations representing a mixture of cutting-edge applications and fundamentals supporting measurement science. We also encourage contributions from other techniques such as Atom Probe Tomography. The Division is constantly striving to provide a forum for current and mature interests (with sessions such as Quantitative Surface Analysis and Practical Surface Analysis) while identifying key areas for future development. This year we are celebrating the careers of Nicholas Winograd and Barbara Garrison from Penn State with two special sessions dedicated to them. Several special sessions this year are designed to showcase industrial and novel applications of surface analysis.

BIOMATERIAL INTERFACES DIVISION (BI):

The Biomaterials Interfaces Division program begins with the traditional Sunday afternoon Plenary Session with presentations by top scientists in biomaterials and bio-related research. The BI program will then continue with a series of sessions throughout the week to provide an interdisciplinary forum for the presentation and discussion of fundamental aspects of bio-interface science and engineering. The BI program brings together recent advances made in materials science and molecular biology with sophisticated surface and interface analysis methods, and theoretical and modeling approaches for biological systems. This year the BI division is cosponsoring the Industrial Physics Forum (IPF) with the American Institute of Physics. The IPF will showcase exciting, upcoming fields of interest related to biosciences including imaging, sensing, diagnostics, and biomaterial assembly. The IPF will complement our BI sessions with invited speakers representing the leaders in these fields. Areas of interest are: Microbes and Fouling at Surfaces, including control of microbes and fouling, biofilms, biofouling, attachment and adhesion of microbes, assessment of antifouling and fouling release function, antifouling coatings, motility at interfaces, colonization analysis, biofilms and EPS; Biomolecules and Biophysics at Interfaces, including proteins at surfaces, nucleic acids, polysaccharides, adsorption, blood-contacting materials, bioadhesion, and infection and immunity; Characterization of Biological and Biomaterials Surfaces, including spectroscopy, imaging, microscopy, optical and mechanical methods

of thin film analysis, characterization in biological media, quantification, chemometrics, microfluidics, time- and spatial resolution measurements, and scanning probe techniques; Bioanalytics, Biosensors and Diagnostics, including biological membranes, vesicles, membrane processes, forces, recognition, signaling, biosensors, microfluidics, point-of-care devices, paper based sensors, and electrochemistry; Biomaterials and Nanomaterials fabrication, including organic thin films, polymer coatings, hybrid coatings, biologically inspired materials, plasma produced biomaterials, patterning, nanofabrication, rapid prototyping, additive manufacturing, 3D structures, tissue formation, implant integration, artificial organs, 3D biofilm structures; Advanced 3D Imaging of Biological Materials, 3D chemical analysis, 3D tomographic analysis, microscopy, 3D tracking. The BI division is also hosting a special session to honor the contributions of Women in Bio-surface Science. We also invite submissions of Flash/Poster Presentations, to be made in a dedicated session with an accompanying Networking Session involving associated poster presentations. Joint BID/Biointerphases prizes will be awarded for the best student Flash/Poster presentations.

Biomaterials Plenary Session (BP):

The Biomaterials Interfaces and AIP's Industrial Physics Forum program kicks off with the now traditional Biomaterials Plenary Session. This year we are pleased to have presentations from two eminent scientists who have made significant contributions to the fields of BioImaging and DNA Based Algorithms.

Spectroscopic Ellipsometry Focus Topic (EL):

The Spectroscopic Ellipsometry Focus Topic integrates themes ranging from classical material science and thin film characterization to nanometer scale science and novel optical sensing concepts. We will host two oral sessions dedicated to traditional applications of spectroscopic ellipsometry in optical materials and thin film characterization as well as new and emerging topics. The first session will focus on classical research topics of ellipsometry as for instance optical coatings and inorganic thin films characterization. Furthermore, presentations on the ellipsometric investigation of novel optical and electronic materials and materials with subwavelength structures will be included. In the second oral session, we will host presentations on novel experimental and theoretical approaches including for instance imaging ellipsometry or optical critical dimension analysis techniques. The oral sessions will be anchored by two outstanding invited speakers Prof. Mathias Schubert, University of Nebraska-Lincoln and Prof. Vanya Darakchieva, University of Linköping, Sweden. As a highlight of our Spectroscopic Ellipsometry focus topic, the best student paper, which is selected based on the quality of the research, its presentation, and the discussion during the symposium, will be awarded with the Spectroscopic Ellipsometry Focus Topic student award. Spectroscopic Ellipsometry will also host a poster session. Past recipients of the award and rules for entering the competition can be found at <http://www.av.org/Awards-Recognition/Focus-Topic-Awards/Spectroscopic-Ellipsometry-Focus-Topic>.

Electronic Materials and Photonics Division (EM):

The Electronic Materials and Photonics Division (EMPD) encompasses the science and engineering of materials, interfaces, and processing that advance electronic, photonic, or optoelectronic device technologies. AVS 65 will include sessions on emerging topics such as quantum information, nanophotonics, and ultra-wide band gap materials, in addition to core topics such as beyond CMOS, III-V materials and their heterostructures, nanostructures, and more. EMPD consistently attracts distinguished invited speakers from around the

globe. We will host 12 invited speakers this year including: Inge Asselberghs (IMEC), Robert Clark (TEL Technology Center), James Enstrom (Cornell University), Suzanne Mohney (Pennsylvania State University), Jelena Vuckovic (Stanford University), Deidre O'Carroll (Rutgers, the State University of New Jersey), Jay Switzer (Missouri University of Science and Technology), Christopher Muratore (University of Dayton), Parag Banerjee (Washington University in St. Louis), Srabanti Chowdhury (UC Davics), Maiken Mikkelsen (Duke University) and Jim Schuck (Columbia University). A poster competition will again be held at AVS 65 with winning presenters receiving a \$500 cash prize. The EMPD industrial forum will also return and provide an intimate opportunity for students to meet with company representatives.

Fundamental Discoveries in Heterogeneous Catalysis Focus Topic (HC):

The "Fundamental Discoveries in Heterogeneous Catalysis" (HC) focus topic highlights recent advances in the understanding of the atomic and molecular basis for heterogeneously catalyzed reactions on solid surfaces. This will be the third time the HC focus topic has been organized, and is coordinated with the Surface Science Division (SSD). Emphasis this year will be on facilitating dialogue between surface science-based and more applied communities studying heterogeneously catalyzed systems. Session topics include theoretical models, nanoscale structures, gas-surface dynamics, and other novel studies of active surfaces. The symposium will highlight connections among theoretical and experimental approaches with the goal of revealing key details of the fundamental chemistry and physics underlying heterogeneous catalysis. Of particular interest are developments in chemical understanding, atomic-level details, and predictive models of reactions catalyzed by metal surfaces.

Advanced Ion Microscopy Focus Topic (HI):

AVS 65 will again be host to the Advanced Ion Microscopy & Beam Induced Nano Engineering Focus Topic, targeting research in focused ion beam technologies including: Nano-engineering; Nano-patterning/ machining; Surface analysis (SIMS), Ion microscopy (HIM, Ga FIB); and Emerging ion beam source technologies (GFIS, LMIS, Neutral Beam, Cold beams), as well as other emerging ion beam microscopy applications. This year's sessions will kick off Wednesday afternoon with the Novel Beam Induced Material Engineering & Nano-Patterning session, featuring invited talks from Francis Allen (UC, Berkeley); Yuichi Naitou (AIST, Japan), and Shida Tan (Intel Corp.). The sessions will continue all day Thursday with the Advanced Ion Microscopy & Surface Analysis session in the morning, Emerging Ion Sources, Optics, and Applications session in the afternoon, and Advanced Ion Microscopy Poster session in the evening. Thursday's invited speakers list includes Alex Belianinov (Oakridge NL), Ilari Maasilta (U. of Jyvaskyla, Finland), Shinichi Matsubara (Hitachi, Japan), and Greg Schwind (Thermal Fisher Scientific). These talks from academia, national labs, and industry, along with many more novel talks on advances ion beam microscopy applications, will continue the tradition of making this a must attend for researchers in the field of ion beam technology and novel ion beam applications.

Industrial Physics Forum (IPF):

The IPFs, scientific gatherings sponsored by the American Institute of Physics and hosted by its member societies, are unique, topic-specific conferences addressing application-focused research in the physical sciences emerging from academia and the private sector. They consist solely of invited talks grouped around several subtopics. The present Forum, the seventh at AVS since 2006, focuses for the first time exclusively on the biophysical/medical sciences and is

co-hosted by the Biomaterials Interfaces Division (BID). The program was designed to broaden the interest and perspective of the BID community through talks partially overlapping research areas of their interest, yet not routinely covered at prior AVS Symposia. The program focuses on innovations in three sub-topics of the biosciences: imaging and structural determination, bioanalytic sensing and diagnostics, and biomaterial assembly. Each topic is covered by five invited speakers in three consecutive morning sessions starting Monday October 22. The afternoons are set aside for contributed talks on topics related to the respective morning sessions. The event is preceded by the traditional BID Plenary session on Sunday afternoon October 21, with topics complementary to those of the IPF.

The session on imaging and structural determination highlights diverse experimental approaches based on infrared, visible, X-ray and mass spectrometric technologies, and encompasses advanced nonlinear optical, fluorescence and Raman spectroscopy, as well as synchrotron and X-ray free electron laser (XFEL) studies for dynamic and 3D imaging of biomolecules and sub-cellular structures at nanoscale resolution. The bioanalytic, biosensor and diagnostic session covers diverse sensing approaches from activated surfaces to discreet nano-sized biomolecular and patterned structures. Topics include advances in in-vitro and in-vivo approaches to disease detection, nanoparticles for monitoring biomolecular functions in their biological environment, subcellular sensors to probe biological processes in live cells, and sensitized surfaces acting as pressure and tunable photo-responsive sensors. The biofabrication session encompasses a structured build-up from basic tissue assembly to the prospects of full organ fabrication. The intermediary steps of vascular co-assembly and its accompanying challenges of supplying life sustaining nutrients and oxygen to the living cells will be amply covered. In addition, the scaffolding required to maintain the integrity of the assembling organ will be discussed, as well as the different approaches and challenges in 3D printing.

MAGNETIC INTERFACES AND NANOSTRUCTURES DIVISION (MI):

This years' MIND program will cover a wide area of topics ranging from chiral magnetism over magnetism and spin orbit effects at interfaces to magnetism in organic system. The focus of the program is to cover areas of magnetism that are fascinating from a fundamental point of view but which carry significance for future applications. In detail, the MI program will feature pioneering, controversial, introductory and emerging results in topical areas related to magnetic interfaces and nanostructures. The program will highlight the synergy of our division with other groups within the AVS by featuring magnetic systems that rely on atomic control of surfaces and interfaces. Topics include: (1) Spin-orbit Coupling at Surfaces, Interfaces and Thin Films; (2) Magnetism at the Nanoscale and (3) Interdisciplinary Magnetism. In particular the session on interdisciplinary magnetism will focus on the intersection between magnetism, life sciences and chemistry, highlighting the role of chirality in chemistry and magnetic nanostructures in biology. In addition, we would like to especially focus on the synergy between the research areas covered by MI and their role for the development of new materials and devices for the information society this year. For this reason the program will feature a special symposium on "New Magnetic Materials, Devices and Concepts for the Information Society".

The Magnetic Interfaces and Nanostructures Division will be selecting the best graduate student presentation from finalists for the Leo Falicov Award. MI will also offer an award for postdoctoral fellows who will be presenting papers at this International Symposium. The winners of both awards will be announced towards the end of the meeting.

MIND will also present a special symposium on "New Magnetic Materials, Devices and Concepts for the Information Society" that

will be held Monday afternoon in room 201A. The symposium will feature four invited talks by renowned speakers from academia and industry who will discuss how we got to where we are today and where to go from here. Magnetic materials and magnetism in general have always been linked very closely to the area of sensing, information processing and storage, owing to its ability to provide long range order at the nanoscale that can be affected not only with magnetic fields but also with electric currents, external pressure etc. The program will address different aspects of how magnetism has played a role in the information society and how it will play a role in the future.

IN-SITU MICROSCOPY, SPECTROSCOPY, AND MICROFLUIDICS FOCUS TOPIC (MM):

Transmission and scanning electron and X-ray microscopes provide exceptional spatial and spectroscopic resolution through many different signals, and have resulted in countless advances in materials science, electrochemistry, biomedical and environmental research. The MEMS and Microfluidics for In Situ TEM, SEM and X-ray Microscopy Focus Topic session will feature devices that allow the application of different stimuli during imaging: mechanical, electrical, optical etc. – under controlled environmental conditions – gaseous, liquid, high/low-temperature, high-pressure. The session will emphasize the design, fabrication and application of these devices, and will include liquid/gas cells for TEM, SEM and X-ray microscopes, as well as mechanical and electrical test devices and their combinations. We will host prominent invited speakers this year from academia, national labs and industry including: Frances Ross (MIT/IBM), Ray Unocic (ORNL), Luca Gregoratti (ELETTRA), Daan Hein Alsem (Hummingbird Scientific).

MEMS AND NEMS GROUP (MN):

The MEMS and NEMS Technology Group (MN) program will highlight recent advances in the broad areas of micro/nanoelectromechanical systems (MEMS/NEMS), especially latest fundamental studies of novel materials, processes, devices, and emerging functions and applications of MEMS/NEMS, in various areas. This AVS65 MN program will include a focus on sensing, communication, and energy scavenging for internet of things (IoT). Another highlight will be multiscale manufacturing of systems including microfluidics systems and bioMEMS with applications to chemical analytics and healthcare. Our program will include resonant low-dimensional materials and parametric and nonlinear MEMS/NEMS resonators which create intriguing possibilities of integrating these devices with existing fluidic, electronic and optical on-chip networks. The program continues to embrace latest progresses in optical MEMS/NEMS, micro/nanophotonics, optomechanics, quantum MEMS/NEMS, resonant systems, CMOS-MEMS, mesoscopic dynamics and dissipation processes, inertial sensors, harsh-environment transducers, and MEMS/NEMS-enabled energy technologies, etc. It also aims to capture some of the latest advances in soft materials, flexible and implantable MEMS/NEMS for biosensing, bio-inspired microsystems, wearable and wireless healthcare.

MATERIALS AND PROCESSES FOR QUANTUM COMPUTING FOCUS TOPIC (MP):

Materials and processes for quantum computing will highlight the recent advances and challenges in quantum computing. Sessions will cover devices, materials and systems that enable quantum computing. These include single photon amplifiers, ion traps, multiplexers, and advances in cryogenic systems, vacuum technology, microwave to optical conversion schemes etc. Topics will include technological advances in accessing isolated qubits (TSV's, Airbridges, Bump bonds, Pogo pins etc.), materials and processes used to achieve high coherence devices. Apart from the oral sessions, we will have a poster

session, which will provide an opportunity for researchers to interact with their peers in the field.

MANUFACTURING SCIENCE AND TECHNOLOGY GROUP (MS):

The MSTG sessions bring together invited speakers to highlight the challenges needing to be addressed for successful manufacturing of next generation devices and technologies. Our sessions are meant to bring together people working across the spectrum of these technologies, including basic science research, metrology, processing, and development, to encourage everyone to keep these manufacturing challenges in mind as they move the technologies forward. This year we are highlighting the areas of Sensor Manufacturing for the IoT and Neuromorphic Computing and Memristor Manufacturing.

NANOMETER-SCALE SCIENCE AND TECHNOLOGY DIVISION (NS):

At the most inclusive level, nanotechnology is anything that involves materials that have structure 100 nm or smaller. Many of the most interesting areas of nanotechnology involve materials or systems whose properties change dramatically as they decrease in size from the bulk, or as surfaces become dominant. Nanoscience and Nanotechnology have become ubiquitous throughout the scientific community as can be attested by the multiple sessions addressing their different aspects at the AVS Symposium.

At the NSTD sessions, researchers from around the globe will present their work on topics such as nanoscale devices and quantum systems, exploiting nanomaterials for applications in photonics, plasmonics, catalysis, surface chemistry, sensors, biomechanics, imaging, and energy, including nanoscale characterization and spectroscopy. This year the program will highlight the following:

(a) Nanoscale chemical and biological studies; (b) Advances in fabrication and manufacturing at the nanoscale; (c) Recent developments in the characterization of materials at the nanometer scale, transport, and recent advances in scanned probe microscopy; (d) Areas of convergence between nanotechnology and electrical, magnetic, mechanical, and optical devices and phenomena.

PLASMA BIOLOGY, AGRICULTURE, AND ENVIRONMENT FOCUS TOPIC (PB):

This Focus Topic will address the latest advances and innovations in plasma technology related to biological, agriculture and environment. Topics that this program highlights include: Plasma medicine and therapeutics e.g. wound healing and cancer treatment, microbe inactivation, biomaterials, plasma fertilizer and ammonia production, nitrogen fixation, seed germination, plant and crop treatment, soil treatment, chemical degradation, environmental remediation, waste and water treatment, reduction of greenhouse gas emissions, air and exhaust cleaning, electrostatic precipitation, VOC removal, biofilm and bio-fouling treatments, plasma chemical reactors, hydrogen production, CO production, CO₂ conversion and renewable energy applications. In addition to collaboration of this Focus Topic with the 'Biointerfaces (BI)' and 'Plasma Science and Technology (PS)' Division program, this AVS offers new links with the 'Processing and Characterization of Air-Liquid, Solid-Liquid and Air-Solid Interfaces (PC)' Focus Topic. In commemoration of Prof. Riccardo d'Agostino and his outstanding scientific contributions and service to our community we are also hosting a session 'Plasma and Polymers: the legacy of Riccardo d'Agostino and beyond.'

PROCESSING AND CHARACTERIZATION OF AIR-LIQUID, SOLID-LIQUID AND AIR-SOLID INTERFACES FOCUS TOPIC (PC):

Chemical and physical processes occurring in the surface and interface including the gas-liquid, solid-liquid, and gas-solid interface are important in many applications yet represent grand scientific and engineering challenges. This symposium aims to promote the latest developments of emerging techniques and scientific understanding using *in situ*/*ex situ*/*non situ*/*operando* imaging, spectroscopy and microscopy to investigate challenging surfaces and interfaces with diverse applications in biology, catalysis, energy storage, environment, and material sciences. Contributions are invited including but not limited to fundamental research, industrial applications, novel approaches, and metrology of surface and interfacial phenomena.

PLASMA SCIENCE AND TECHNOLOGY DIVISION (PS):

The 2018 Plasma Science & Technology Division (PSTD) program highlights state-of-the-art advances in plasma research, ranging from fundamental studies of plasma physics and chemistry to new applications such as IoT, Atomic Layer Processing in semiconductor fabrication, II-VI/III-V, enabling nanomaterials/nanoparticles and plasmas for environmental and medicinal applications. The core PSTD program features fifteen oral sessions and a poster session, as well as joint sessions with the "Applied Surface Science", "Electronic Materials", "Nanometer-scale Science and Tech" divisions and "2D Materials", and "Plasma Biology, Agriculture, and Environment" focus topics. With the "Thin Films Division", a new session track of "Atomic Layer Processing" is also featured illustrating the synergy between ALD and ALE. The session on AVS65 theme of IoT features talks by 2018 Plasma Prize Winner, Dr. Meyya Meyyappan (NASA) in addition to Prof. Iyer (UCLA), Dr. Seddon (ON Semi) and Dr. Meyya Meyyappan, the 2018 Plasma Prize Winner. A special highlight for 2018 is a session to commemorate the Life and Legacy of Riccardo d'Agostino.

RECONFIGURABLE MATERIALS AND DEVICES FOR NEUROMORPHIC COMPUTING FOCUS TOPIC (RM):

Since traditional computing systems have begun to reach the theoretical limits of their performance, alternative, biologically inspired approaches to computing have become increasingly important. These neuromorphic computer systems often require new devices and materials beyond those typically available in traditional CMOS and semiconductor foundries and have both reconfigurable and continuously tunable properties. This Focus Topic will explore both the new materials used in these next generation systems as well as nanoscale, integrated demonstrations of next generation computing systems.

NOVEL TRENDS IN SYNCHROTRON AND FEL-BASED ANALYSIS FOCUS TOPIC (SA):

Advanced scattering, diffraction, spectroscopic and imaging techniques developed at electron accelerator based X-ray light sources have made revolutionary contributions to understanding of structure-dynamic-function relationships in various complex functional materials where interfaces are an inherent feature. At AVS 65th dedicated to processing and interfaces for the IoT era this topical session will provide a forum for communicating the latest research paradigm in exploration of complex interfacial systems that have allowed to go beyond periodic and equilibrium structures for obtaining unprecedented insights into the relationships between synthesis, processing and properties that enable the desired functionality. The selected topical presentations will

illustrate the unique opportunities, opened by several novel tools for in-situ studies, to uncover peculiar atomic arrangements and composition profiles across the interfaces and explore how the interfacial structure and functionality respond to external stimuli such as temperature, electric or magnetic field, light and changes in the chemical composition by exposing to various environments.

ADVANCED SURFACE ENGINEERING DIVISION (SE):

The program of the Advanced Surface Engineering Division (SE) focuses on all topics related to engineering the properties and functionalities of surfaces of all kinds. Both fundamental scientific and application-oriented contributions presenting experimental and/or theoretical and computational results are included. The session “Plasma-assisted Surface Modification and Deposition Processes” presents contributions aimed at understanding or further developing techniques and processes to alter the appearance of surfaces or to synthesize thin films and coatings on surfaces of interest. Topics related to analysis and characterization of such modified surfaces are covered by the session “Nanostructured Thin Films and Coatings.” This includes also contributions on new and advanced characterization techniques in order to gain further details. A frequent application of coatings is to protect the underlying surface from environmental influences. The session “Wear, Oxidation and Corrosion Protective Coatings” deals with all different kinds of protective coatings in academic research, but also in industrial and ‘real-world’ applications. Last but not least the session “New Challenges and Opportunities in Surface Engineering” serves as a forum to gather new ideas and developments in the field and to show its broadness. The main focus is on topics and contributions that show how surface engineering can assist to solve present-day and future problems. All invited lectures review and highlight the state-of-the-art and latest findings in the respective topic. Academic, industry and national laboratory scientists, technicians and especially junior researchers and PhD students from various disciplines and all countries contribute to our diverse and interesting technical program including four oral sessions and one poster session.

SURFACE SCIENCE DIVISION (SS):

The program of the Surface Science Division (SS) provides a forum for cutting-edge and foundational research that involves solid surfaces and interfaces. Phenomena that take place at the gas-solid and liquid-solid interfaces are prominent within the SS Division programs. Technical sessions address atomistic, structural, electronic, and chemical phenomena at surfaces and interfaces, their impact on materials properties, and their implication for technological and environmental processes. Surface chemistry is an important divisional theme, encompassing the kinetics and dynamics of surface processes and chemical events from adsorption and reaction to catalysis. Film and nanostructure growth is another key theme, explored from a fundamental perspective, through the development of new growth and processing methods for materials preparation. Surface chemical modification and photon-driven chemistry at surfaces are important concentrations. Lively sessions are devoted to the surface science of metallic, semiconductor, oxide and organic surfaces that support unique chemical activity and electronic properties. Surface science applications in high-impact areas, including energy science, microelectronics, nanotechnology, and environmental science, are highlighted in the program. This Division’s overarching goal is to provide the atomistic insights on solid surfaces and interfaces needed to advance our understanding of materials systems and benefit society. This year’s Surface Science Division sessions are listed below. Many of the sessions are co-sponsored with other Divisions, Groups, and Focus Topics and should be of broad interest to attendees. In particular several SS sessions complement the Fundamental Discoveries in Heterogeneous Catalysis Focus Topic (HC) sessions beginning on Tuesday afternoon

and running throughout the rest of the week. Tuesday’s SS poster session features the finalists for the Morton M. Traum Surface Science Division Student Award.

THIN FILMS DIVISION (TF):

The Thin Film Division offers several core oral sessions and one poster session. A broad range of outstanding invited speakers will touch on topics across the breadth of thin film science, technology and applications. There are several sessions dedicated to thin film deposition and processing, including energy conversion and storage, electronics, photovoltaics, 3D and extreme geometries, precursors, surface reactions, memory, magnetics and organic-inorganic hybrid materials. These sessions highlight basic science and the pursuit of applications. Furthermore, we offer sessions on in-situ diagnostics for CVD and ALD processes, organic-inorganic interface engineering and modeling of thin film processes. There will also be new sessions around emerging applications and thin film processes for flexible electronics and IoT. We are also excited to announce, in collaboration with the Plasma Science & Technology Division, a new session track on Atomic Layer Processing (ALP), to highlight the synergy between ALD and ALE. Abstracts are solicited on topics ranging from atomic layer etching (plasma or thermal), area selective deposition, chemistry and surface reactions for ALP and integration of ALD and ALE. Other relevant ALP topics also include area selective patterning, plasma-enhanced ALD, emerging applications, diagnostics and high volume manufacturing of ALP. Again this year, we will host a student-focused session to highlight the Harper Award candidates in which the student finalists will present their work in an interactive “TEDTalk” type of forum. Finally, we will host a special session in honor of Paul Holloway to celebrate his contributions to the AVS: Luminescent Materials Growth, Synthesis and Characterization.

TRIBOLOGY FOCUS TOPIC (TR):

The Tribology Focus Topic will feature talks on nanoscale wear with applications in nano-metrology and nano-manufacturing, molecular origins of friction, lubricants and coatings, and friction in biological systems. This focus session is jointly sponsored by the Applied Surface Science (ASSD) Division, Thin Films (TF), Nanometer-scale Science and Technology (NSTD), and Biointerfaces (BI). Particular emphasis is given to scientific advancements in our understanding of the links between nanoscale information (either simulations or experiments, but preferably both) and macroscale observations. Presentations will carry a materials focus in areas such as thin film deposition, solid lubricants, nanocomposites designed for tribological function, self-healing interfaces, wear-resistant polymers, and biomaterials. Contributions will consider advances in in-situ, molecularly specific, spatially resolved approaches to the quantitative characterization of tribological interfaces as well as accounts of numerical computation and molecular modeling of tribological materials and biomaterials.

VACUUM TECHNOLOGY DIVISION (VT):

The Vacuum Technology Division (VTD) provides a forum for research in achieving, maintaining, measuring, and analyzing vacuum across a wide range of pressures, gas compositions and applications. The 2018 VT oral program topics include: (1) Vacuum Measurement,(2) Vacuum Pumping and Outgassing,(3) Large Vacuum System and Accelerator Vacuum Technology and(4) Vacuum System Design and Automation. The VTD Poster session Tuesday evening features the VT Student Poster Competition, with a first place award of up to \$500, where students of any discipline are invited to share their innovative solutions to vacuum equipment challenges. Student presenter awards will also be given for the best oral presentations. To be eligible for a student prize, the presenter must be registered as a student and present the work in a VTD poster or oral session.

SESSION OVERVIEW

Symposium Plenary Lecture

Mon. 5:00 PM, Grand Ballroom (CC)

“The Internet of Things: Shaping the Future of the Medical Device Industry”
Dr. Kim Chaffin – Distinguished Scientist and Bakken Fellow in Strategic & Scientific Operations at Medtronic, plc.

Advanced Surface Engineering

Mon. AM Room 202C	Nanostructured Thin Films and Coatings
Mon. PM Room 202C	New Challenges and Opportunities in Surface Engineering
Tue. AM Room 202C	Plasma-assisted Surface Modification and Deposition Processes
Tue. PM Room 202C	Wear, Oxidation and Corrosion Protective Coatings
Tue. PM Room Hall B	Advanced Surface Engineering Division Poster Session

Applied Surface Science

Mon. AM Room 204	Quantitative Surface Analysis
Mon. PM Room 204	Multitechnique Applications – When More Techniques are Better than One
Tue. AM Room 204	Applied Surface Science: From Electrochemistry to Cell Imaging, a Celebration of the Career of Nicholas Winograd
Tue. PM Room 204	The Impact of Modeling (Ion, Electron) and Data Analysis on Applied Surface Science, a Celebration of the Career of Barbara Garrison
Wed. AM Room 204	Beyond Traditional Surface Analysis
Wed. PM Room 204	Industrial and Practical Applications of Surface Analysis
Thu. AM Room 204	Applied Surface Analysis of Novel, Complex or Challenging Materials
Thu. PM Room 204	Profiling, Imaging and Other Multidimensional Pursuits
Thu. PM Room Hall B	Applied Surface Science Division Poster Session

Biomaterial Interfaces

Mon. PM Room 101B	Advanced Imaging and Structure Determination of Biomaterials Research
Tue. PM Room 101B	IoT Session: Biofabrication, Bioanalytic, Biosensors and Diagnostics
Tue. PM Room Hall B	Biomaterial Interfaces Division Flash Poster Session
Wed. PM Room 104B	Current and Future Stars of the AVS Symposium II
Wed. PM Room 101B	Microbes and Fouling at Surfaces
Thu. AM Room 101B	Biomolecules and Biophysics at Interfaces
Thu. PM Room 101B	Biolubrication and Wear / Women in Bio-surface Science
Fri. AM Room 101B	Characterization of Biological and Biomaterial Surfaces

Biomaterials Plenary

Sun. PM Room 101B AVS BIP & AIP IPF Forum Plenary Session

Electronic Materials and Photonics

Mon. AM Room 101A	IoT Session: CMOS, Beyond the Roadmap and Over the Cliff
Mon. PM Room 101A	Atomic Layer Processing: Selective-Area Patterning (Assembly/Deposition/Etching)

Tue. PM Room 101A	Solar/Energy Harvesting and Quantum Materials and Applications
Wed. AM Room 101A	Surface and Interface Challenges in Electronics and Photonics
Wed. PM Room 101A	Wide and Ultra-Wide Bandgap Materials for Electronic Devices: Growth, Modeling and Properties
Thu. AM Room 101A	Nanostructures for Electronic and Photonic Devices
Thu. PM Room 101A	IoT Session: Flexible Electronics & Flash Networking Session
Thu. PM Room Hall B	Electronic Materials and Photonics Division Poster Session

Industrial Physics Forum

Mon. AM Room 101B	Biofabrication: From Tissue to Organ
Tue. AM Room 101B	Advanced Imaging and Structure Determination of Biomaterials
Wed. AM Room 101B	IoT Session: Bioanalytic, Biosensors and Diagnostics

Magnetic Interfaces and Nanostructures

Mon. PM Room 201A	IoT Session: Symposium on New Magnetic Materials, Devices and Concepts for the Information Society
Thu. AM Room 203A	Magnetism at the Nanoscale
Thu. PM Room 203A	Interdisciplinary Magnetism
Thu. PM Room Hall B	Magnetic Interfaces and Nanostructures Division Poster Session
Fri. AM Room 203A	Magnetism and Spin-Orbit Coupling at Surfaces, Interfaces and Thin Films

Manufacturing Science and Technology

Tue. AM Room 202B	IoT Session: Challenges of Neuromorphic Computing and Memristor Manufacturing
Tue. AM Room 103C	Working with Government Labs and other User Facilities
Tue. PM Room 202B	IoT Session: Challenges of Sensor Manufacturing for the IoT
Tue. PM Room Hall B	Topics in Manufacturing Science and Technology Poster Session

MEMS and NEMS

Wed. AM Room 202B	IoT Session: Multiscale Manufacturing: Enabling Materials and Processes
Wed. PM Room 202B	IoT Session: MEMS for IoT: Chemical and Biological Sensing
Thu. AM Room 202B	Optomechanics and 2 D NEMS
Thu. PM Room 202B	Nonlinear and Thermal Resonators
Thu. PM Room Hall B	MEMS and NEMS Group Poster Session

Nanometer-scale Science and Technology

Mon. PM Room 102B	SPM – New Imaging and Spectroscopy Methodologies
Tue. PM Room 102B	SPM – Probing and Manipulating Nanoscale Structures
Wed. PM Room 203A	IoT Session: Bio at the Nanoscale
Thu. PM Room 102B	SPM – Probing Electronic and Transport Properties
Thu. PM Room Hall B	Nanometer-scale Science and Technology Division Poster Session
Fri. AM Room 102B	SPM – Probing Chemical Reactions at the Nanoscale

SESSION OVERVIEW

Plasma Science and Technology

Mon. AM Room 104A	Plasma-Surface Interactions
Mon. AM Room 104C	Plasma Deposition and Plasma-Enhanced ALD
Mon. PM Room 104A	Plasma and Polymers: The Legacy of Riccardo d'Agostino and Beyond
Tue. AM Room 104A	Plasma Processing of Challenging Materials – I
Tue. AM Room 104C	Plasma Medicine
Tue. PM Room 104A	Plasma Processing of Challenging Materials – II
Tue. PM Room 104C	Atmospheric Pressure Plasmas
Tue. PM Room Hall B	Plasma Science and Technology Division Poster Session
Wed. AM Room 104B	Current and Future Stars of the AVS Symposium I
Wed. AM Room 104A	Advanced Patterning
Wed. AM Room 104C	IoT Session: Enabling IoT Era
Wed. PM Room 104C	Advanced BEOL/Interconnect Etching
Thu. AM Room 104C	Atomic Layer Processing: Atomic Layer Etching
Thu. AM Room 104A	Plasma Sources
Thu. PM Room 104C	Atomic Layer Processing: Integration of ALD and ALE
Thu. PM Room 104A	Plasma Diagnostics, Sensors and Controls
Fri. AM Room 104A	Plasma Modeling

Surface Science

Mon. AM Room 203C	Dynamical Processes at Surfaces
Mon. PM Room 203C	Theory and Modeling of Surfaces and Reactions
Tue. AM Room 203C	Controlling Mechanisms of Surface Chemical Reactions
Tue. PM Room 203C	Oxides/Chalcogenides: Structures and Reactions
Tue. PM Room Hall B	Surface Science Division Poster Session
Wed. AM Room 203C	Catalytic Alloys: Understanding Heterogeneity
Wed. PM Room 203C	Semiconducting Surfaces
Thu. AM Room 203C	Defects in and Functionalization of 2D Materials
Thu. PM Room 203C	Organic/Inorganic Surfaces, Interfaces and Nanostructures
Thu. PM Room 102A	Deposition, Etching and Growth at Surfaces
Fri. AM Room 203C	Near/Ambient Pressure and Bridging Gaps between Surface Science and Catalysis

Thin Films

Mon. AM Room 102A	Precursors and Surface Reactions
Mon. AM Room 104B	IoT Session: Thin Film Processes for Energy Storage
Mon. PM Room 102A	Thin Films for Advanced Memory Applications and Magnetics
Mon. PM Room 104B	IoT Session: Thin Films for Photovoltaics
Tue. AM Room 104B	Atomic Layer Processing: Area Selective Deposition
Tue. AM Room 102A	Special Session in Honor of Paul Holloway: Luminescent Materials Growth, Synthesis and Characterization
Tue. AM Room 101A	Emerging Applications for ALD
Tue. PM Room 104B	Atomic Layer Processing: Chemistry & Surface Reactions for Atomic Layer Processing

Tue. PM Room 102A	Organic/Inorganic Materials and Interfaces
Wed. AM Room 102A	Thin Film Processes for Electronics and Optics I
Wed. PM Room 102A	Thin Film Processes for Electronics and Optics II
Thu. AM Room 102A	In-situ Characterization and Modeling of Thin Film Processes
Thu. AM Room 104B	Deposition Processes for 3D and Extreme Geometries
Thu. PM Room 104B	IoT Session: Thin Films for Flexible Electronics and IoT
Thu. PM Room Hall B	Thin Film Poster Session

Vacuum Technology

Mon. AM Room 203B	Vacuum Measurement
Mon. PM Room 203B	Pumping and Outgassing
Tue. AM Room 203B	Large Vacuum Systems and Accelerator Vacuum Technology
Tue. PM Room 203B	IoT Session: Vacuum System Design and Automation & Flash Networking Session
Tue. PM Room Hall B	Vacuum Technology Division – Poster Session
Wed. AM Room 203B	Vacuum Technology Developments

Exhibitor Technology Spotlight Workshops

EW-TuB	Exhibitor Technology Spotlight Session I
EW-TuL	Exhibitor Technology Spotlight Session II
EW-TuAB	Exhibitor Technology Spotlight Session III
EW-WeB	Exhibitor Technology Spotlight Session IV
EW-WeL	Exhibitor Technology Spotlight Session V

2D Materials Focus Topic

Mon. AM Room 201B	2D Materials Growth and Fabrication
Mon. PM Room 201B	2D Materials Characterization including Microscopy and Spectroscopy
Tue. AM Room 201B	Properties of 2D Materials including Electronic, Magnetic, Mechanical, Optical, and Thermal Properties
Tue. PM Room 201B	2D Device Physics and Applications
Wed. AM Room 201B	Dopants, Defects, and Interfaces in 2D Materials
Wed. PM Room 201B	IoT Session: Surface Chemistry, Functionalization, Bio and Sensor Applications
Thu. AM Room 201B	Novel 2D Materials
Thu. PM Room 201B	Novel Quantum Phenomena in 2D Materials
Thu. PM Room Hall B	2D Materials Poster Session
Fri. AM Room 201B	Nanostructures including Heterostructures and Patterning of 2D Materials

Actinides and Rare Earths Focus Topic

Wed. AM Room 202C	Magnetism, Complexity, and Superconductivity in the Actinides and Rare Earths
Wed. PM Room 202C	Chemistry and Physics of the Actinides and Rare Earths
Thu. AM Room 202C	Nuclear Power, Forensics, and Other Applications
Thu. PM Room 202C	Early Career Scientists
Thu. PM Room Hall B	Actinides and Rare Earths Poster Session

SESSION OVERVIEW

Fri. AM Room 202C Actinide and Rare Earth Theory and Related Measurements

Advanced Ion Microscopy Focus Topic

Wed. PM Room 7 & 8 Emerging Ion Sources and Optics
Thu. AM Room 7 & 8 Advanced Ion Microscopy Applications
Thu. PM Room 7 & 8 Novel Beam Induced Surface Analysis and Nano-Patterning
Thu. PM Central Hall Advances in Ion Microscopy Poster Session

Advanced Nanophotonics Metrology Focus Topic (within NS)

Mon. AM Room 102B IoT Session: Nanostructured Devices and Sensors
Tue. AM Room 102B Nanophotonics, Plasmonics, and Metamaterials
Wed. AM Room 203A Micro, Nano and Opto Mechanics
Thu. AM Room 102B Nanopatterning and Nanofabrication

Extending Additive Manufacturing to the Atomic Scale Focus Topic

Tue. PM Room Hall B Extending Additive Manufacturing to the Atomic Scale Poster Session
Wed. AM Room 102B Nanofabrication with Focused Electron Beams (8:00–10:00 am)/Atomic Scale Manipulation with Focused Electron Beams (11:00 am–12:20 pm)
Wed. PM Room 102B Atomic Scale Manipulation with SPM

Fundamental Discoveries in Heterogeneous Catalysis Focus Topic

Tue. AM Room 201A Nanochemistry in Heterogeneous Catalysis
Tue. PM Room 201A A Tale of Two Scales: Catalytic Processes and Surface Science
Wed. AM Room 201A Mechanisms and Reaction Pathways of Heterogeneously Catalyzed Reactions
Wed. PM Room 201A Theory and Dynamics of Heterogeneously Catalyzed Reactions
Thu. AM Room 201A In-situ Analysis of Heterogeneously Catalyzed Reactions
Thu. PM Room 201A Bridging Gaps in Heterogeneously Catalyzed Reactions
Thu. PM Room Hall B Fundamental Discoveries in Heterogeneous Catalysis Focus Topic Poster Session

In-situ Microscopy, Spectroscopy, and Microfluidics Focus Topic

Mon. AM Room 202B Mechanical, Electrical, Thermal and Optical Systems for In situ TEM (9:00–10:10 am)/Beam Induced Effects and Processing in Liquid/Gas Cells for TEM/SEM (10:40–11:40 am)
Mon. PM Room 202B X-ray and Electron Spectromicroscopy in Liquids and Gases & Flash Networking Session
Tue. PM Room Hall B In-situ Microscopy, Spectroscopy, and Microfluidics Focus Topic Poster Session

Materials and Processes for Quantum Computing Focus Topic

Mon. AM Room 203A Systems and Devices for Quantum Computing I
Mon. PM Room 203A Systems and Devices for Quantum Computing II
Tue. AM Room 203A High Coherence Qubits for Quantum Computing

Novel Trends in Synchrotron and FEL-Based Analysis Focus Topic

Wed. PM Room 202A Hard X-Ray Photoemission for Probing Buried Interfaces
Thu. AM Room 202A Ultra-fast Dynamics for Magnetic and Quantum Systems
Thu. PM Room 202A IoT Session: Multi-modal Characterization of Energy Materials & Device Processing
Thu. PM Room Hall B Novel Trends in Synchrotron and FEL-Based Analysis Focus Topic Poster Session

Plasma Biology, Agriculture, and Environment Focus Topic

Tue. PM Room Hall B Plasma Biology, Agriculture, and Environment Focus Topic Poster Session
Wed. PM Room 104A Plasma Agriculture & Environmental Applications

Processing and Characterization of Air-Liquid, Solid-Liquid and Air-Solid Interfaces Focus Topic

Tue. AM Room 202A Solid-Liquid and Gas-Liquid Interfacial Processes and Characterization
Tue. PM Room 202A Progress in Industrial Processes and Characterization of Interfaces and Gas-Solid Interfacial Processes and Characterization
Tue. PM Room Hall B Processing and Characterization of Gas-Liquid, Solid-Liquid, and Gas-Solid Interfaces
Wed. AM Room 202A Novel Approaches and Challenges of Interfaces

Reconfigurable Materials and Devices for Neuromorphic Computing Focus Topic

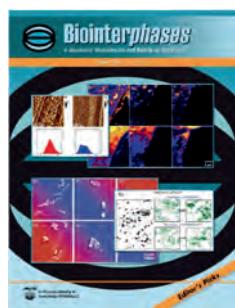
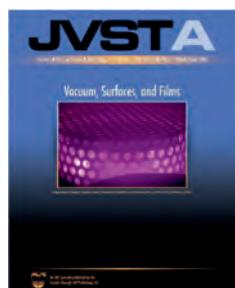
Tue. PM Room 203A IoT Session: Reconfigurable Materials and Devices for Neuromorphic Computing
Tue. PM Room Hall B Reconfigurable Materials and Devices for Neuromorphic Computing Poster Session

Spectroscopic Ellipsometry Focus Topic

Mon. AM Room 202A Application of SE for the Characterization of Thin Films and Nanostructures
Mon. PM Room 202A Spectroscopic Ellipsometry: Novel Applications and Theoretical Approaches
Tue. PM Room Hall B Spectroscopic Ellipsometry Focus Topic Poster Session

Tribology Focus Topic

Mon. AM Room 201A Tribology Focus Session
Tue. PM Room Hall B Tribology Focus Topic Poster Session



Call for Research Articles

Based on Your AVS 65 Presentation

You May Submit Your
Articles/Letters Anytime to:

JVSTA - JVST B - Biointerphases

- ▶ Your article/letter will be peer reviewed rigorously as a regular submission and, if accepted, will be published quickly online.
- ▶ Your article/letter will get either an article or letter designation on online data bases such as ISI; it will NOT be designated as a proceedings paper.
- ▶ There are no length limitations and your manuscript can be as long as it needs to be to convey your ideas and results in the most succinct way.

JVSTA, JVST B and Biointerphases have many new additions. The journal web pages utilize quick links and advanced search capabilities. Articles are fully citable as soon as published online.

Please go to the journal websites for easy to use templates, instructions, and to login to the submission site.

If you have any questions, please do not hesitate to contact the AVS Publications Office or the Editors. Please stop by the Publications Booth in the AVS 65 Exhibit Hall during the Symposium to visit and chat with the Editors and AVS Publications staff.

**Manuscript
Instructions &
Templates:**

www.jvsta.org
www.jvstb.org
www.biointerphases.org

AVS Publications

Aydil@umn.edu
Biointerphases_Editor@avs.org
publications@avs.org

Eray Aydil, AVS Editor-in-Chief
Sally McArthur, Biointerphases Editor

JVSTA

Journal of Vacuum Science & Technology A

- Surfaces
- Films
- Vacuum

www.jvsta.org   

Understanding interfaces and surfaces at a fundamental level and using this understanding to advance the state-of-the-art in various technological applications defines the scope of the *Journal of Vacuum Science and Technology A*. This journal is devoted to publishing reports of original research, letters, and review articles.



Website Features Editor's Picks, Most Cited, and Most Read

Topics include but are not limited to:

- Applied and fundamental surface science
- Atomic layer deposition
- Electronic and photonic materials and their processing
- Magnetic thin films and interfaces
- Materials and thin films for energy conversion and storage
- Photovoltaics including thin-film solar cells and organic and hybrid solar cells
- Plasma science and technology including plasma surface interactions, plasma diagnostics plasma deposition and etching and applications of plasmas to micro- and nanoelectronics

- Surface Engineering
- Thin film deposition, etching, properties and characterization
- Transmission electron microscopy including *in situ* methods
- Tribology
- Vacuum science and technology

JVSTA January/February Annual Special Issue Features:

- Atomic Layer Deposition
- Atomic Layer Etching

Editor-in-Chief: Eray S. Aydil, New York University



AVS Publications Office

51 Kilmayne Drive, Suite 104
Cary, NC 27511

919-361-2787 • Fax 919-234-0051 • publications@avs.org

Visit us online at www.avspubs.org



JVSTB

Journal of Vacuum Science & Technology B

- Nanotechnology
- Microelectronics
- Processing, Measurement, Phenomena

www.jvstb.org   

The *Journal of Vacuum Science and Technology B* is devoted to publishing reports of original research, letters, and review articles on microelectronics and nanometer structures and devices. The emphasis is on processing, measurement and phenomena associated with micrometer and nanometer structures and devices. Processing may include vacuum processing, plasma processing and microlithography among others, while measurement refers to a wide range of materials and device characterization methods for understanding the physics and chemistry of submicron and nanometer structures and devices.



Website Features Editor's Picks, Most Cited, and Most Read

Topics include but are not limited to:

- Compound semiconductor electronics and optoelectronics
- Devices for energy conversion and storage
- Dielectrics in micro- and nanoelectronics
- Graphene, carbon nanotubes and fullerenes: materials & devices
- Group IV semiconductor microelectronics
- Lithography
- Microelectromechanical and nanoelectromechanical systems and devices (MEMS & NEMS)

- Nanometer science and technology
- Nanostructured materials and devices including nanowires, nanoparticles and quantum dots,
- Organic and molecular electronics
- Photovoltaics based on nanostructured materials, dye-sensitized and other excitonic solar cells
- Plasmonics
- Spintronics and magnetic devices
- Vacuum nanoelectronics

Editor-in-Chief: Eray S. Aydil, New York University



AVS Publications Office

51 Kilmayne Drive, Suite 104
Cary, NC 27511

919-361-2787 • Fax 919-234-0051 • publications@avs.org

Visit us online at www.avspubs.org



SSS

SURFACE SCIENCE SPECTRA

Journal and Database for Individuals or Analytical Laboratories

- Reference Spectra
- Spectra from Technological Materials
- Comparison Spectra from Well-Defined Materials

www.sss.org    

Surface Science Spectra is an international journal devoted to archiving spectra from surfaces and interfaces. Data records are peer-reviewed and technically edited. Spectral descriptions include much more detail - instrument description, calibration, and raw spectral data - than traditional journals. SSS offers XPS, Auger, UPS, SIMS, EELS/HREELS and Spectroscopic Ellipsometry spectra from a wide range of materials.

Add a cost-effective tool to your lab or library.
SSS Online **FREE** to AVS Members.

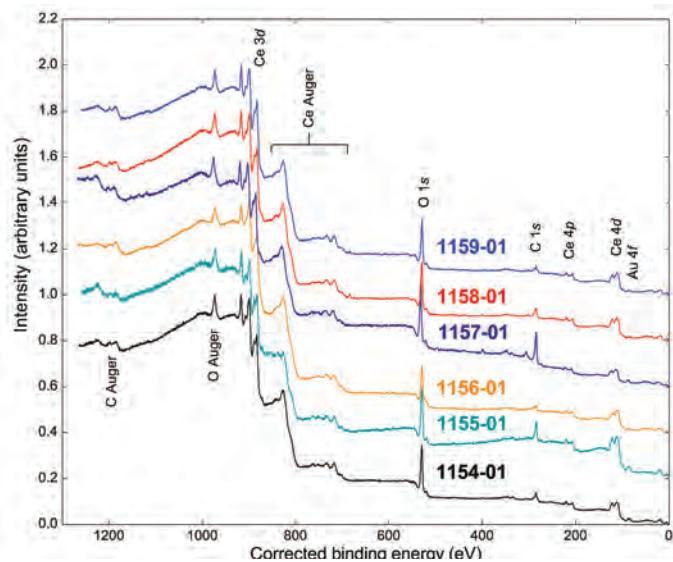
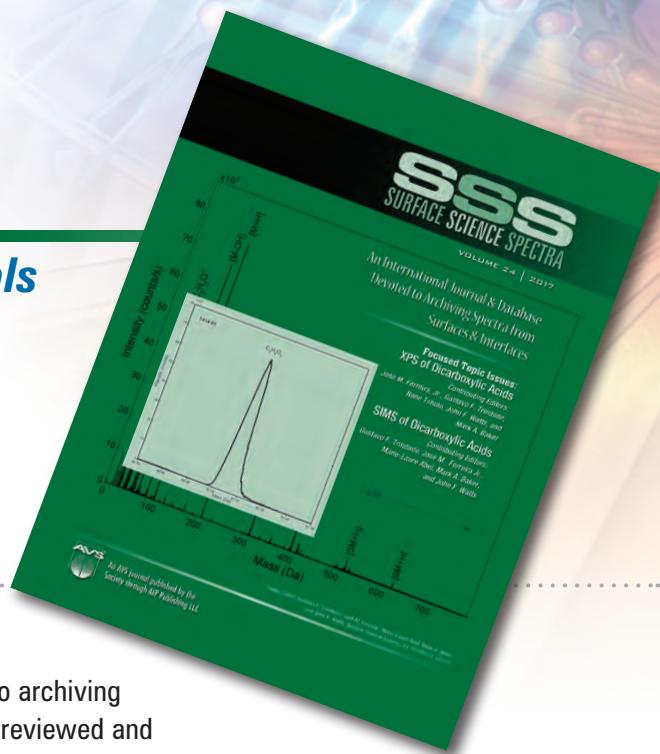
SSS features:

- Data from over 130 labs worldwide
- Contributions from over 600 authors
- 5,800 individual spectra from more than 1,000 different materials

Editors: James E. Castle, University of Surrey and Richard T. Haasch, University of Illinois

"SSS is a valuable database for all the community working on the XPS of organic and inorganic Materials."

— Dr. Davide Barreca, U. Padova



AVS Publications Office

51 Kilmayne Drive, Suite 104
Cary, NC 27511

919-361-2787 • Fax 919-234-0051 • sss@avs.org

Visit us online at www.av.org



Biointerphases

A Journal of Biomaterials and Biological Interfaces

- Quantitative Characterization of Biointerfaces
- Experiments, Modeling, Theory and Applications
- Expert Editors and Rapid Publication
- Open Access Option

www.biointerphases.org   

twitter@Biointerphases

#AVSBIP

#Biointerphases

Biointerphases is the leading journal for quantitative characterization of biomaterials and biological interfaces. As an interdisciplinary journal, a strong foundation of chemistry, physics, biology, engineering, theory, and/or modeling are incorporated into originated articles, reviews, and opinionated essays. Topics covered include bio-surface modification, interface spectroscopy, protein-surface interactions, cell-surface interactions, interface modeling, adhesion phenomena, biotribology / biorheology, ambient diagnostic methods, and *in vivo* and *in vitro* systems. Biointerphases is an international journal with excellence in scientific peer-review. Researchers have open access options for their publications. Works are published rapidly online and advertised through several venues for high visibility.

Recent and Upcoming In Focus Collections

- Protein Structures at Biointerfaces
- Biointerface Science & Engineered Biomaterials, Honoring Buddy Ratner
- Bacterial-Surface Interactions
- SIMS XXI
- Biomedical Surface Analysis: In Celebration of NESAC/Bio's 35th Anniversary
- Women in Biointerface Science

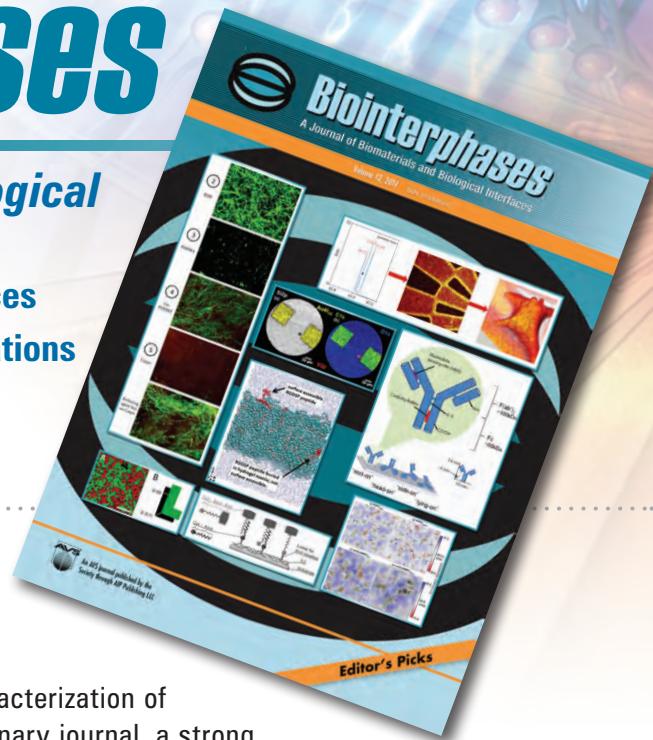
Editor: Dr. Sally L. McArthur, Swinburne University of Technology and CSIRO Manufacturing

“Biointerphases is an excellent information source for research in the field of cell adhesion and mechanics with growing importance.”

— Dr. Joachim Spatz, MPI Intelligent Systems & University of Heidelberg

“The themed issues of Biointerphases provide valuable, in-depth accounts of the current state of research in specific topic areas of biointerface science.”

— Dr. Stefan Zauscher, Duke University



AVS Publications Office

51 Kilmayne Drive, Suite 104

Cary, NC 27511

919-361-2787 • Fax 919-234-0051 • publications@avs.org

Visit us online at www.avspubs.org





TechCon 2019

Long Beach

Long Beach Convention Center April 27 – May 2, 2019

Call for Papers

**Deadline for Abstracts:
October 5, 2018**

Now Accepting Abstracts for the 2019 Technical Conference

Featuring a Symposium on:

**Enabling Sustainability — Next-Generation Technologies
for Coatings, Surface Engineering and Smart Manufacturing**

Technical Program: April 29 – May 2

- Technical Sessions
- Interactive Networking Forums
+ Breakfast Discussion Groups

Education Program: April 27 – May 2

- Problem-Solving Tutorial Courses

Together with:

- High-Powered Electron Beam Technology — **NEW Session!**
- Joint Session of Emerging Technologies and Plasma Processes focused on Atomic Layer Processes (ALP) — **NEW Session!**
- Coatings for Energy Conversion and Related Processes
- Protective, Tribological and Decorative Coatings
- Coatings and Processes for Biomedical Applications
- Optical Coatings

- Plasma Processing
- Large Area Coatings
- WebTech Roll-to-Roll Coatings
- Fundamental Aspects of Coatings
- HIPIMS and Emerging Technologies
- Heureka! Post-Deadline Recent Developments
- Technical Poster Session
- Vendor Innovator Showcase

The SVC is pleased to announce that a new session on High-Powered Electron Beam Technology has been added to the TechCon program for 2019. High-Powered Electron Beam Technology is well established for thermal barrier coating, titanium and refractory metal melting and welding. New applications are emerging in the fields of electron beam evaporation for photovoltaics, concentrated solar, energy production (fuel cells), energy storage (batteries) and high efficiency lighting.

Technology Exhibit: April 30 – May 1

Over 150 Exhibitors + Free Admission

The Largest Expo Dedicated to Vacuum Coating Technologies & Materials

To submit an abstract, go to www.svc.org/2019TechCon. For more information, contact the SVC at 505-897-7743 or send an email to svcinfo@svc.org

www.svc.org

APSIT GROUP INSURANCE PROGRAM: SEE WHAT IT HAS TO OFFER!

Because you belong to a society that participates in the APSIT Group Insurance Program, you can leverage the buying power of APSIT and have a single resource for your personal and professional needs.

After 40 years in operation, APSIT continues to sponsor affordable, comprehensive protection for you and your family.

APSIT represents over 500,000 members, and as we continue to grow, we will continue to be here for you.

Visit apsitinsurance.com/plans3 today to learn more about the valuable coverages available to you through the APSIT Group Insurance Program.

**GROUP TERM LIFE
INSURANCE**

**GROUP 10-YEAR LEVEL
TERM LIFE INSURANCE**

**GROUP DISABILITY
INCOME INSURANCE**

**GROUP PERSONAL
ACCIDENT INSURANCE**



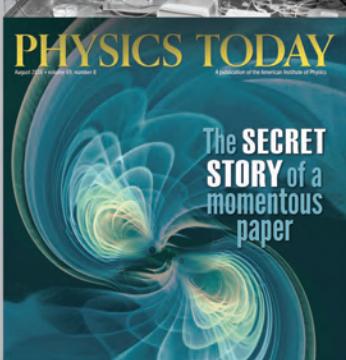
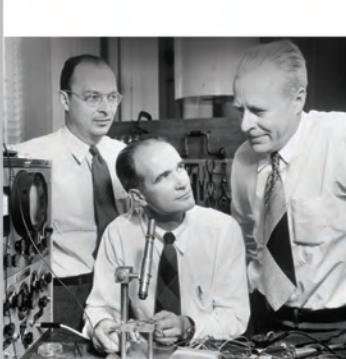
AMERICAN PHYSICAL SOCIETY INSURANCE TRUST

Contact an APSIT Group Insurance Program Specialist today!
800.272.1637 | customerservice@apsitinsurance.com

The APSIT Group Insurance Program is administered by Pearl Insurance. License: CA#0F76076, AR#1322. The APSIT Group Insurance Plans are underwritten by New York Life Insurance Company, 51 Madison Avenue, New York, New York, 10010 on Group Policy GMR, G-29068-1/FACE, G-29068-0/FACE, G-29068-2/FACE, G-29134-0/FACE. Additional information including features, costs, eligibility, renewability, limitations and exclusions is contained in the Certificate of Insurance, which is issued to the person insured under the plan.

Not Intended for New Mexico residents

Sign up for AIP's free email alerts at aip.org/aip/subscribe



FYI: The AIP Bulletin of Science Policy News

An objective, authoritative digest of science policy developments in Washington, DC.

aip.org/fyi

AIP Statistics e-Updates

The latest data on education and employment in the physical sciences.

aip.org/statistics

Inside Science Alerts

Science news articles and videos for mainstream audiences.

insidescience.org

AIP History Center Newsletter

Information for history buffs of all ages.

aip.org/history-programs

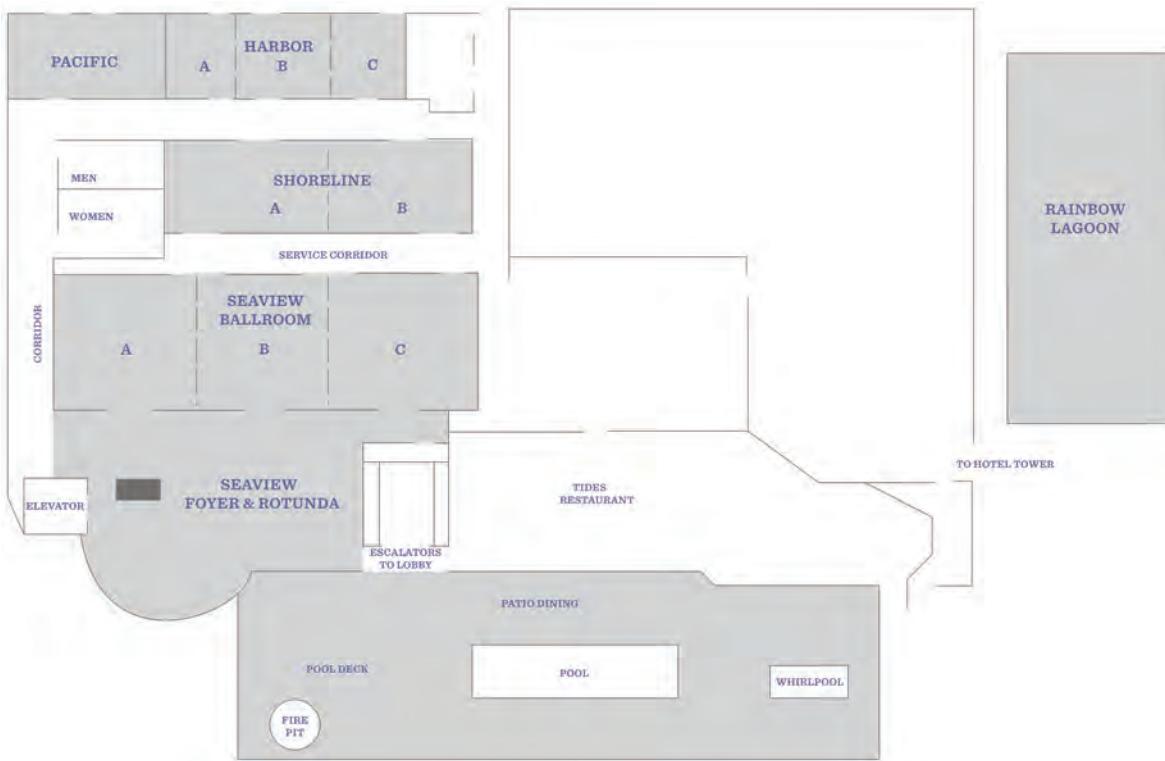
Physics Today Online Alerts

The latest Physics Today content comes straight to you.

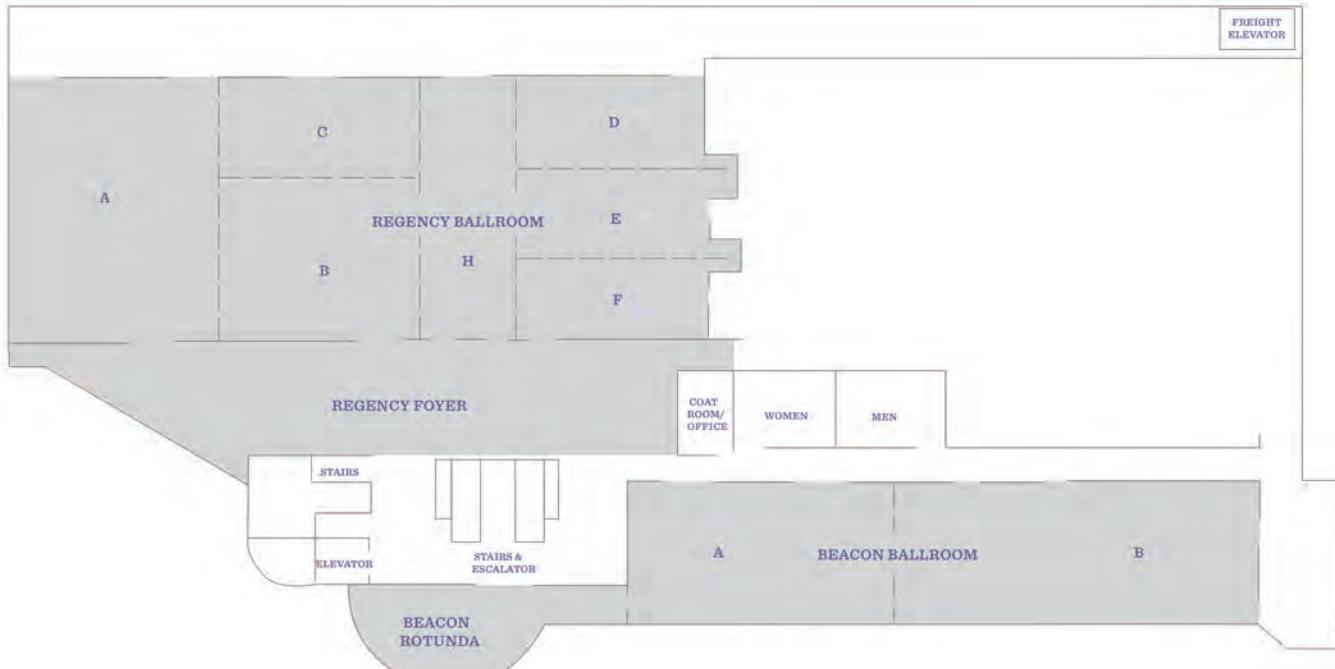
physicstoday.org

HYATT REGENCY LONG BEACH

Lower Level (First Floor)



Upper Level (Fourth Floor)



MEETINGS AND SPECIAL EVENTS

SATURDAY, OCTOBER 20, 2018

2:00 p.m.	Educational Materials & Outreach Committee Meeting	Regency Club Boardroom (H)
6:30 p.m.	Education Committee Dinner	TBD (Offsite)

SUNDAY, OCTOBER 21, 2018

7:30 a.m.	Seventeenth Topical Conference on Quantitative Surface Analysis (QSA17): "Data Reproducibility"	101A (CC)
8:00 a.m.	AVS Board of Directors' Meeting Executive Session (Closed Session-Board Only)	Seaview AB (H)
9:00 a.m.	AVS Board of Directors' Meeting.....	Seaview AB (H)
1:15 p.m.	AVS Board of Directors' Lunch.....	Seaview C (H)
3:00 p.m.	Biomaterials Plenary Session and Reception.....	101B (CC)
3:00 p.m.	JVST Associate Editors' Meeting.....	Harbor (H)
5:30 p.m.	ASTM E-42 Business Meeting	Regency D (H)
6:00 p.m.	Science Educators' Workshop Teachers' Reception	Seaview Rotunda (H)
6:00 p.m.	Vacuum Technology Division Executive Committee Meeting and Dinner	Shoreline A (H)
6:30 p.m.	Applied Surface Science Division Memorial Reception	Regency EF (H)
7:00 p.m.	International Dignitaries & Chapter Chairs Reception (Invitation Only).....	Tides Restaurant (H)
7:00 p.m.	Short Course Executive Committee Meeting and Dinner	Shoreline B (H)

MONDAY, OCTOBER 22, 2018

7:00 a.m.	Professional Leadership Committee Meeting and Breakfast.....	Tides Restraunt (H)
8:00 a.m.	Science Educators' Workshop	Seaview (H)
10:20 a.m.	AVS Member Center: Demo Hour-AVS Events and Activities/AVS 65 Mobile App	103C (CC)
12:00 p.m.	Science Educators' Workshop Lunch.....	Shoreline A (H)
12:05 p.m.	Magnetic Interfaces and Nanostructures Division Business Meeting	201A (CC)
12:15 p.m.	2019 AVS Program Committee Meeting and Lunch.....	Regency A (H)
12:15 p.m.	AVS Member Center: Professional Development—"Welcome to AVS Overview" Lunch	103C (CC)
12:15 p.m.	Recommended Practices Committee Meeting and Lunch.....	Pacific (H)
1:20 p.m.	Symposium on New Magnetic Materials, Devices and Concepts for the Information Society	201A (CC)
3:00 p.m.	AVS Member Center: Professional Development-Speed Networking for Young Professionals	103C (CC)
4:00 p.m.	Publications Committee Meeting	Shoreline A (H)
4:45 p.m.	Vacuum Technology Division Business Meeting	203B (CC)
5:00 p.m.	Plenary Lecture: Kim Chaffin - Distinguished Scientist and Bakken Fellow in Strategic and Scientific Operations at Medtronic, plc., "The Internet of Things: Shaping the Future of the Medical Device Industry"	Grand Ballroom (CC)
6:15 p.m.	AVS Symposium Plenary Panel	Grand Ballroom (CC)
7:00 p.m.	Applied Surface Science Division Executive Committee Meeting and Dinner	Pacific (H)
7:00 p.m.	Welcome Mixer	Hall B (CC)
7:30 p.m.	Thin Film Division Panel Discussion of Student Opportunities and the Thin Film Division Harper Award TED-Talk Competition.....	102A (CC)
7:45 p.m.	Magnetic Interfaces and Nanostructures Division Executive Committee Meeting and Dinner	Shoreline A (H)
7:45 p.m.	Publications Committee Meeting and Dinner (Invitation Only)	Parker's Lighthouse (Offsite)
8:30 a.m.-5:00 p.m.	Short Course Program.....	Various Rooms (H)

TUESDAY, OCTOBER 23, 2018

7:30 a.m.	Awards Committee Meeting and Lunch.....	Pacific (H)
8:00 a.m.	Science Educators' Workshop	Seaview (H)
9:00 a.m.	AVS Member Center: Professional Development- <i>eSpectra</i> : Surface Science	103C (CC)
10:00 a.m.	AVS Member Center: Professional Development-Working with National Labs and Other User Facilities	103C (CC)
10:00 a.m.	Session Coffee Break.....	Hall A (CC)
11:40 a.m.	Professional Development- Federal Funding Town Hall	202B (CC)
12:00 p.m.	Science Educators' Workshop Lunch.....	Shoreline A (H)
12:20 p.m.	Exhibit Hall Lunch	Hall A (CC)
12:30 p.m.	AVS Member Center: Professional Development-Job Information Forum and Lunch	103C (CC)
12:30 p.m.	Chapters, Divisions, and Groups Meeting and Lunch (Invitation Only).....	Regency D (H)
12:30 p.m.	Manufacturing Science and Technology Group Committee Meeting and Lunch	Tides Restraunt (H)
3:40 p.m.	Biointerphases Reception (Invitation Only)	Shoreline A (H)
3:40 p.m.	Session Refreshment Break	Hall A (CC)
4:00 p.m.	AVS Member Center: Professional Development-SCCAVS/NCCAVS Members Hospitality Hour (Invitation Only)	103C (CC)
6:05 p.m.	Biomaterial Interfaces Division Business Meeting	101B (CC)
6:25 p.m.	Electronic Materials and Photonics Division Business Meeting	101A (CC)
6:25 p.m.	Nanometer-scale Science and Technology Division Business Meeting.....	102B (CC)
6:25 p.m.	Plasma Science and Technology Division Business Meeting and 2018 Plasma Prize Award Announcement	104A (CC)

CC = Long Beach Convention Center
H = Hyatt Regency Long Beach

 = New Attendee Networking Events

MEETINGS AND SPECIAL EVENTS

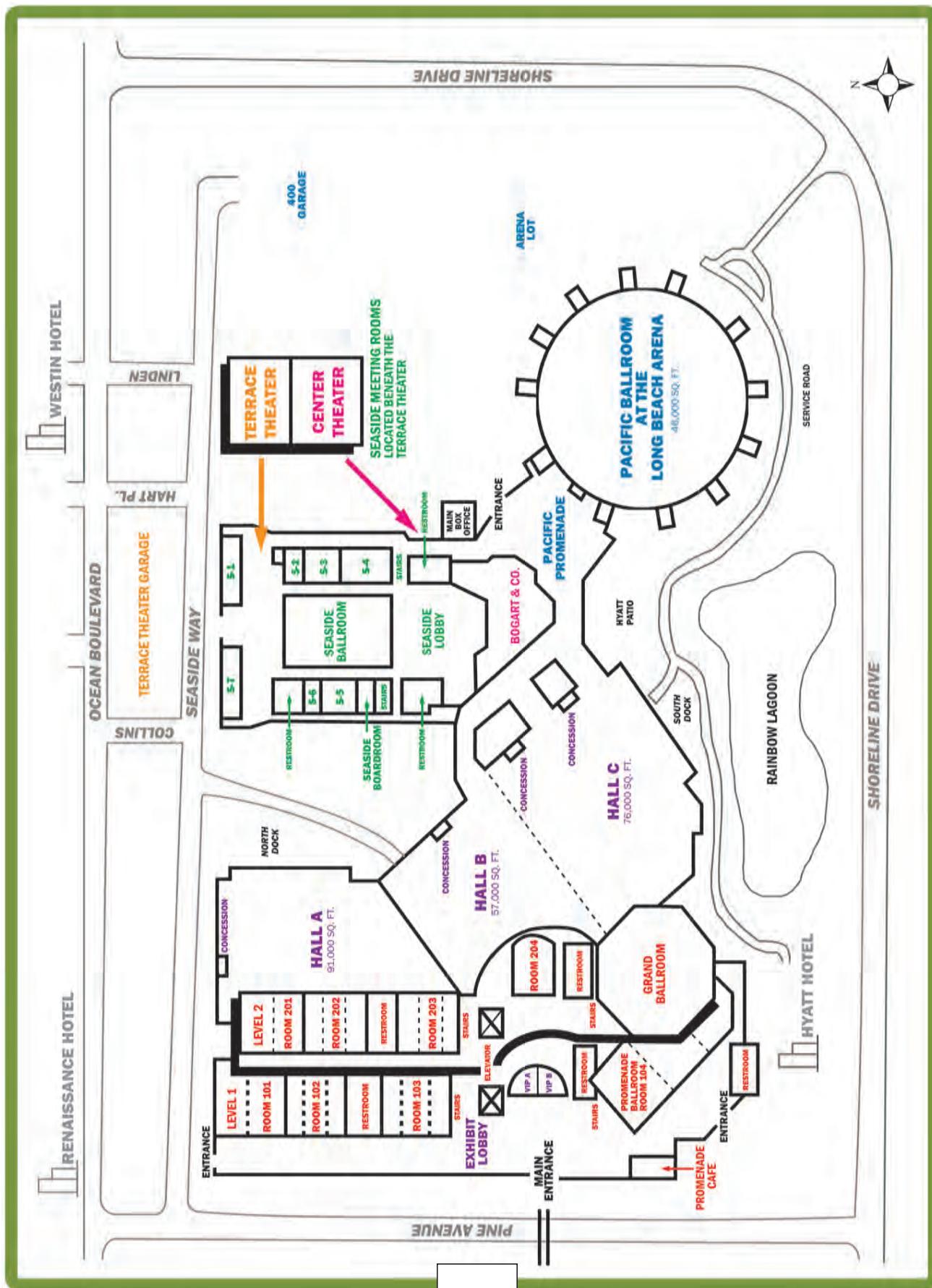
6:25 p.m.	Surface Science Division Business Meeting	203C (CC)
6:25 p.m.	Thin Film Division Business Meeting	102A (CC)
6:30 p.m.	Poster Session and Refreshments	Hall B (CC)
6:45 p.m.	AVS Member Center: Professional Development-Electronic Materials and Photonics Division Forum: "Careers at LAM Research"	103C (CC)
7:00 p.m.	MEMS and NEMS Technical Group Executive Committee Meeting and Dinner	Regency F (H)
7:00 p.m.	Nanometer-scale Science and Technology Division Executive Committee Meeting and Dinner	Seaview A (H)
7:00 p.m.	Surface Science Division Executive Committee Meeting and Dinner	Regency C (H)
7:30 p.m.	Applied Surface Science Division Business Meeting	Regency DE (H)
7:30 p.m.	Plasma Science and Technology Division Executive Committee Meeting and Dinner	Seaview C (H)
7:30 p.m.	Thin Film Division Executive Committee Meeting and Dinner	Seaview B (H)
7:45 p.m.	Biomaterial Interfaces Division Executive Committee Meeting and Dinner	Pacific (H)
7:45 p.m.	Electronic Materials and Photonics Division Executive Committee Meeting and Dinner	Regency B (H)
8:00 p.m.	ASTM E-42 and Applied Surface Science Division Joint Workshop: "A Tribute to the Careers of Barbara Garrison and Nicholas Winograd"	Regency DE (H)
8:30 a.m.-5:00 p.m.	<i>Short Course Program</i>	Various Rooms (H)
10:00 a.m.-5:00 p.m.	<i>Equipment Exhibition</i>	Hall A (CC)
WEDNESDAY, OCTOBER 24, 2018		
6:15 a.m.	38th Annual AVS Run (Register at Run Booth before Wednesday in the Convention Center) ..	TBD
7:30 a.m.	AVS Diversity & Inclusion Committee Breakfast	Tides Restraunt (H)
8:00 a.m.	Advanced Surface Engineering Division Business Meeting	Shoreline (H)
8:15 a.m.	Advanced Surface Engineering Division Executive Committee Meeting (Lunch Offsite)....	Shoreline (H)
8:20 a.m.	Current and Future Stars of the AVS Symposium I	104B (CC)
10:00 a.m.	AVS Member Center: Diversity and Inclusion- "Inclusion and Diversity at the Workplace: Your Suggestions for Best Practices"	103C (CC)
10:00 a.m.	Session Coffee Break	Hall A (CC)
11:40 a.m.	Peter Mark Memorial Award: "Plasma-bio Interactions: Investigating Mechanisms to Enable New Applications," Peter Bruggeman, Univ. of Minnesota	104B (CC)
12:20 p.m.	Exhibit Hall Lunch	Hall A (CC)
12:20 p.m.	Nanometer-scale Science and Technology Division Graduate Student and Postdoc Award Competitions	102B (CC)
12:20 p.m.	Plasma Science and Technology Division Coburn and Winters Adjudication Session (Closed Session)	104A (CC)
12:30 p.m.	AVS Member Center: Professional Development-Lunch and Learn: "XPS for the Non-Analyst"	103C (CC)
12:30 p.m.	Governance Committee Meeting and Lunch	Tides Restraunt (H)
12:30 p.m.	PacSurf Committee Meeting and Lunch	Tides Restraunt (H)
1:00 p.m.	Biointerphases Strategic Planning Meeting	Seaview A (H)
2:20 p.m.	Current and Future Stars of the AVS Symposium II	104B (CC)
2:20 p.m.	Medard W. Welch Award Lecture: "A Surface Scientist's Journey from Small Molecules to Biomolecules and Biomaterials," David G. Castner, Univ. of Washington ..	104B (CC)
3:00 p.m.	AVS Member Center: Professional Development- "Get Involved: How to Moderate and Lead Conference Sessions"	103C (CC)
3:00 p.m.	Gaede-Langmuir Award Lecture: "From Description to Prediction of Biointerphase Reactions," Michael Grunze, Max Planck Institute for Medical Research, Germany ..	101B (CC)
3:40 p.m.	Session Refreshment Break	Hall A (CC)
4:30 p.m.	E&M Reception (Invitation Only)	Hall A (CC)
5:30 p.m.	Heterogeneous Catalysis Graduate Student Presentation Award Reception	201A (CC)
6:30 p.m.	AVS Awards Ceremony and Reception	Grand Ballroom (CC)
8:30 a.m.-5:00 p.m.	<i>Short Course Program</i>	Various Rooms (H)
10:00 a.m.-4:30 p.m.	<i>Equipment Exhibition</i>	Hall A (CC)
THURSDAY, OCTOBER 25, 2018		
10:00 a.m.	AVS Presidents Panel	Hall A (CC)
10:00 a.m.	Session Coffee Break	Hall A (CC)
12:20 p.m.	Exhibit Hall Lunch/Final	Hall A (CC)
12:20 p.m.	Plasma Science and Technology Division Coburn and Winters Award Ceremony	104A (CC)
12:20 p.m.	Surface Science Division Mort Traum Awards Ceremony	203C (CC)
12:30 p.m.	2019 AVS Program Committee Chairs' Meeting and Lunch	Seaview (H)
12:30 p.m.	AVS Member Center: Professional Development- "Improving Work-Life Satisfaction" and Lunch	103C (CC)
12:30 p.m.	AVS Business Meeting	101A (CC)
3:30 p.m.	History Committee Meeting	Shoreline B (H)
6:00 p.m.	Poster Session and Refreshments	Hall B (CC)
6:30 p.m.	2018/2019 Program Committee Reception and Dinner	Seaview (H)
7:00 p.m.	Surface Science Spectra Editorial Board Dinner	Shoreline A (H)
8:30 a.m.-5:00 p.m.	<i>Short Course Program</i>	Various Rooms (H)
10:00 a.m.-2:30 p.m.	<i>Equipment Exhibition</i>	Hall A (CC)

CC = Long Beach Convention Center

H = Hyatt Regency Long Beach

 = New Attendee Networking Events

LONG BEACH CONVENTION CENTER



Program Key

AVS 65 SYMPOSIUM TOPICS

2D	2D Materials Focus Topic
AC	Actinides and Rare Earths Focus Topic
AM	Extending Additive Manufacturing to the Atomic Scale Focus Topic
AS	Applied Surface Science Division
BI	Biomaterial Interfaces Division
BP	Biomaterials Plenary Session
EL	Spectroscopic Ellipsometry Focus Topic
EM	Electronic Materials and Photonics Division
EW	Exhibitor Technology Spotlight Workshops
HC	Fundamental Discoveries in Heterogeneous Catalysis Focus Topic
HI	Advanced Ion Microscopy Focus Topic
IPF	Industrial Physics Forum
MI	Magnetic Interfaces and Nanostructures Division
MM	In-situ Microscopy, Spectroscopy, and Microfluidics Focus Topic
MN	MEMS and NEMS Group
MP	Materials and Processes for Quantum Computing Focus Topic
MS	Manufacturing Science and Technology Group
NS	Nanometer-scale Science and Technology Division
PB	Plasma Biology, Agriculture, and Environment Focus Topic
PC	Processing and Characterization of Air-Liquid, Solid-Liquid and Air-Solid Interfaces Focus Topic
PS	Plasma Science and Technology Division
RM	Reconfigurable Materials and Devices for Neuromorphic Computing Focus Topic
SA	Novel Trends in Synchrotron and FEL-Based Analysis Focus Topic
SE	Advanced Surface Engineering Division
SS	Surface Science Division
TF	Thin Films Division
TR	Tribology Focus Topic
VT	Vacuum Technology Division

KEY TO SESSION/ABSTRACT NUMBERS

Sessions sponsored by multiple topics are labeled with all acronyms (e.g. **AC+EM+SS**), then a number to indicate simultaneous sessions sponsored by the same topic(s) (e.g. **SS1, SS2**), then a dash followed by the first two characters of the day of the week:

Monday, Tuesday, Wednesday, Thursday, Friday,

then a single letter for **Morning, Afternoon, Poster,**

and finally a number indicating the starting time slot for the paper.

Example: **SS1-MoM9** (Surface Science, Monday morning, 11:00 am).

AVS 65 Technical Program

Room/ Day	101A	101B	102A	102B	103C MEMBER CTR/ PROF. DEV.	104A	104B	104C	201A
SuA		BP AVS BIP & AIP IPF Forum Plenary Session							
MoM	EM+ IoT Session: CMOS, Beyond the Roadmap and Over the Cliff	IPF+ Biofabrication: From Tissue to Organ	TF1 Precursors and Surface Reactions	NS+ IoT Session: Nanostructured Devices and Sensors	7:00 am Member Coffee 10:20 Demo: AVS Mobile Ap	PS+ Plasma-Surface Interactions	TF2 IoT Session: Thin Film Processes for Energy Storage	PS+ Plasma Deposition and Plasma- Enhanced ALD	TR+ Tribology Focus Session
MoA	EM+ ALP: Selective- Area Patterning (Assembly/Dep osition/Etching)	BI+ Advanced Imaging and Structure Determination of Biomaterials Research	TF+ Thin Films for Advanced Memory Apps and Magnetics	NS+ SPM - New Imaging and Spectroscopy Methodologies	12:15 Welcome to AVS/3:00 pm Speed Networking for Young Professionals	PS+ Plasma and Polymers: 'The Legacy of Riccardo d'Agostino and Beyond'	TF IoT Session: Thin Films for Photovoltaics		MI+ IoT Session: Symp. on new Mag. Mtls, Devices & Concepts for the Info Society
TuM	TF Emerging Applications for ALD	IPF+ Advanced Imaging and Structure Determination of Biomaterials	TF+ Special Session in Honor of Paul Holloway: Luminescent Materials	NS+ Nanophotonics, Plasmonics, and Metamaterials	7:00 am Member Coffee 9:00 Demo: eSpectra	PS+ Plasma Processing of Challenging Materials - I	TF+ Atomic Layer Processing: Area Selective Deposition	PS+ Plasma Medicine	HC+ Nanochemistry in Heterogeneous Catalysis
TuB					10:00 am MS Working with Government Labs and other User Facilities				
TuL					12:30 pm Job Information Forum & Lunch				
TuA	EM+ Solar/Energy Harvesting and Quantum Materials and Applications	BI+ IoT Session: Biofabrication, Bioanalytic, Biosensors and Diagnostics & Flash Session	TF+ Organic/ Inorganic Materials and Interfaces	NS+ SPM – Probing & Manipulating Nanoscale Structures	6:45 pm EMPD Forum "Careers at Lam Research"	PS+ Plasma Processing of Challenging Materials - II	TF+ ALP: Chemistry & Surface Reactions for ALP	PS+ Atmospheric Pressure Plasmas	HC+ A Tale of Two Scales: Catalytic Processes and Surface Science
TuP									
WeM	EM+ Surface and Interface Challenges in Electronics and Photonics	IPF+ IoT Session: Bioanalytic, Biosensors and Diagnostics	TF+ Thin Film Processes for Electronics and Optics I	AM+ Nanofabricatio n with Focused Electron Beams Atomic Scale Manipulation	7:00 am Member Coffee 10:00 am "Inclusion & Diversity at the Workplace"	PS+ Advanced Patterning	PS+ Current and Future Stars of the AVS Symposium I	PS+ IoT Session: Enabling IoT Era	HC+ Mech & React. Pathways of Heterogeneo. Catal. Reactions
WeL					12:30 pm Lunch & Learn "XPS for the Non-Analyst"				
WeA	EM+ Wide and Ultra-Bandgap Mtls for Elect Devices: Growth Modeling and Properties	BI Microbes and Fouling at Surfaces	TF+ Thin Film Processes for Electronics and Optics II	AM+ Atomic Scale Manipulation with SPM	3:00 pm Get Involved: Tips on How to Moderate & Lead Sessions	PB+ Plasma Agriculture & Environmental Applications	BI+ Current and Future Stars of the AVS Symposium II	PS+ Advanced BEOL/Interconn Etching	HC+ Theory & Dynamics of Heterogeneo. Catalyzed Reactions
ThM	EM+ Nanostructures for Electronic and Photonic Devices	BI Biomolecules and Biophysics at Interfaces	TF+ In-situ Charact. & Modeling of Thin Film Processes	NS+ Nanopatterning and Nano- fabrication	7:00 am Member Coffee 12:30pm "Improving Work-Life Satisfaction"	PS Plasma Sources	TF+ Deposition Processes for 3D and Extreme Geometries	PS+ Atomic Layer Processing: Atomic Layer Etching	HC+ In-situ Analysis of Heterogen. Catalyzed Reactions
ThA	EM+ IoT Session: Flexible Electronics & Flash Session	BI Biolubrication and Wear / Women in Bio- surface Science	SS+ Deposition, Etching and Growth at Surfaces	NS+ SPM – Probing Electronic and Transport Properties		PS Plasma Diagnostics, Sensors and Controls	TF+ IoT Session: Thin Films for Flexible Electronics and IoT	PS+ Atomic Layer Processing: Integration of ALD and ALE	HC+ Bridging Gaps in Hetero- geneously Catal. Reactions
ThP									
FrM		BI+ Characteriz. of Biological and Biomaterial Surfaces		NS+ SPM – Probing Chemical Reactions at the Nanoscale		PS Plasma Modeling			

at a Glance

201B	202A	202B	202C	203A	203B	203C	204	Hall A	Hall B
2D+ 2D Materials Growth and Fabrication	EL+ Application of SE for the Charact of Thin Films and Nanostructures	MM+ Mech, Elec Ther. Opt Syst for In situ TEMam/ Beam Ind Eff & Proc in Liquid/Gas	SE+ Nanostructure d Thin Films and Coatings	MP+ Systems and Devices for Quantum Computing I	VT Vacuum Measurement	SS+ Dynamical Processes at Surfaces	AS Quantitative Surface Analysis		
2D+ 2D Materials Characterizatio n including Microscopy and	EL+ Spectroscopic Ellipsometry: Novel Applications and	MM+ X-ray and Electron Spectrom. in Liquids & Gases & Flash Session	SE New Challenges and Opportunities in Surface Engineering	MP+ Systems and Devices for Quantum Computing II	VT Pumping and Outgassing	SS+ Theory and Modeling of Surfaces and Reactions	AS Multitechnique Applications- When More techniques are Better than		
2D+ Properties of 2D Materials including Elect, Mag, Mech, Optical, and Thermal	PC+ Solid-Liquid & Gas-Liquid Interfacial Proc & Charact.	MS+ IoT Session: Challenges of Neuromorphic Computing and Memristor	SE+ Plasma- assisted Surf. Modif & Dep. Processes	MP+ High Coherence Qubits for Quantum Computing	VT Large Vacuum Systems and Accelerator Vac Tech	SS+ Controlling Mechanisms of Surf. Chemical Reactions	AS+ From Electro to Cell Imaging, A Celeb of Nicholas Winograd		
								EW Exhibitor Technology Spotlight Session I	
								EW Exhibitor Technology Spotlight Session II	
2D+ 2D Device Physics and Applications	PC+ Progress in Industrial Proc. & Charact. of Int. and Gas- Solid Inter Proc & Char.	MS+ IoT Session: Challenges of Sensor Manufacturing for the IoT	SE Wear, Oxidation and Corrosion Protective Coatings	RM+ IoT Session: Reconfig. Mtls & Devices for Neuromorphic Computing	VT IoT Session: Vacuum Syst. Design & Autom. & Flash Session	SS+ Oxides/ Chalcogenides: Structures and Reactions	AS Impact of Mod (Ion, Elect Data Anal. on App Surf Sci a Celebration of B. Garrison	EW Exhibitor Technology Spotlight Session III	
									POSTER SESSIONS: AM, BI, EL, MM, MS, PB, PC, PS, RM, SE, SS, TR, VT
2D+ Dopants, Defects, and Interfaces in 2D Materials	PC+ Novel Approaches and Challenges of Interfaces	MN+ IoT Session: Multiscale Mfg: Enabling Mtls and Processes	AC+ Mag., Complexity, & Supercond in the Actinides & Rare Earths	NS+ Micro, Nano and Opto Mechanics	VT Vacuum Technology Developments	SS+ Catalytic Alloys: Understanding Heterogeneity	AS+ Beyond Traditional Surface Analysis	EW Exhibitor Technology Spotlight Session IV	
								EW Exhibitor Technology Spotlight Session V	
2D+ IoT Session: Surface Chemistry, Bio, Function, and Sensor	SA+ Hard X- Ray Photoemission for Probing Buried Interfaces	MN+ IoT Session: MEMS for IoT: Chemical and Biological Sensing	AC+ Chemistry and Physics of the Actinides and Rare Earths	NS+ IoT Session: Bio at the Nanoscale	HI Novel Beam Induced Material Eng & Nano- Patterning	SS+ Semiconductin g Surfaces	AS+ Industrial and Practical App. of Surface Analysis		
2D+ Novel 2D Materials	SA+ Ultra- fast Dynamics for Magnetic and Quantum Systems	MN+ Opto- mechanics and 2D NEMS	AC+ Nuclear Power, Forensics, and Other Applications	MI+ Magnetism at the Nanoscale	HI+ Advanced Ion Microscopy & Surface Analysis	SS+ Defects in and Functionalizati on of 2D Materials	AS+ Applied Surf. Analysis of Novel, Complex or Challenging Materials		
2D+ Novel Quantum Phenomena in 2D Materials	SA+ IoT Session: Multi- modal Char. Energy Mtls & Device Processing	MN+ Nonlinear and Thermal Resonators	AC Early Career Scientists	MI+ Inter- disciplinary Magnetism	HI Emerging Ion Sources, Optics, and Applications	SS+ Organic/ Inorganic Surfaces, Interfaces and Nanostructures	AS+ Profiling, Imaging and Other Multi- dimensional Pursuits		
									POSTER SESSIONS: 2D, AC, AS, EM, HC, HI, MI, MN, NS, SA, TF
2D+ Nanostructures including Heterostruct. and Patterning of 2D Materials			AC+ AC & Rare Earth Theory & Related Measure	MI+ Magnetism and Spin-Orbit Coupling at Surf., Int., & Thin Films		SS+ Near/Ambient Pressure and Bridging Gaps bet Surface Sci & Catalysis			

Anticipated Schedule Sunday, October 21, 2018

Anticipated Schedule Sunday Lunch, October 21

When _____

Where _____

With _____

Anticipated Schedule Sunday Afternoon, October 21

1:00 PM _____

1:20 PM _____

1:40 PM _____

2:00 PM _____

2:20 PM _____

2:40 PM _____

3:00 PM _____

3:20 PM _____

3:40 PM _____

Special Events Sunday

Special Events Sunday

7:30 AM	QSA 17 "Data Reproducibility"/101A
8:00 AM	AVS Board of Directors' Executive Session (CLOSED SESSION)/Seaview AB-Hyatt Regency (by invitation)
9:00 AM	AVS Board of Directors' Meeting/Seaview AB-Hyatt Regency
3:00 PM	JVST Associate Editors' Meeting/Harbor-Hyatt Regency (by invitation)
5:30 PM	ASTM E-42 Business Meeting/Regency D-Hyatt Regency
6:00 PM	Science Educators' Workshop Teachers' Reception/Seaview Rotunda-Hyatt Regency (by invitation)
6:00 PM	Vacuum Technology Division Executive Committee Meeting & Dinner/Shoreline A-Hyatt Regency (by invitation)
6:30 PM	Applied Surface Science Division Memorial Reception/Regency EF-Hyatt Regency
7:00 PM	International Dignitaries & Chapter Chairs Reception/Tides Restaurant-Hyatt Regency (by invitation)
7:00 PM	Short Course Executive Committee Meeting/Shoreline B-Hyatt Regency (by invitation)

Sunday Afternoon, October 21, 2018

Biomaterials Plenary Session

Room 101B - Session BP-SuA

AVS BIP & AIP IPF Forum Plenary Session

Moderator: Joe Baio, Oregon State University

3:00pm	INVITED: BP-SuA1 Integrating Single Molecule Devices with Conventional Microfabrication using DNA Origami, <i>Paul Rothemund</i> , California Institute of Technology	
3:20pm	Invited talk continues.	
3:40pm	INVITED: BP-SuA3 High Resolution Cryo-EM Structures of Macromolecular Complexes, <i>Wah Chiu</i> , Stanford University	
4:00pm	Invited talk continues.	
4:20pm		
4:40pm		
5:00pm		
5:20pm		
5:40pm		

Anticipated Schedule Monday, October 22, 2018

Anticipated Schedule Monday Morning, October 22

8:20 AM	_____
8:40 AM	_____
9:00 AM	_____
9:20 AM	_____
9:40 AM	_____
10:00 AM	_____
10:20 AM	_____
10:40 AM	_____
11:00 AM	_____
11:20 AM	_____
11:40 AM	_____
12:00 PM	_____

Anticipated Schedule Monday Lunch, October 22

When	_____
Where	_____
With	_____

Anticipated Schedule Monday Afternoon, October 22

1:00 PM	_____
1:20 PM	_____
1:40 PM	_____
2:00 PM	_____
2:20 PM	_____
2:40 PM	_____
3:00 PM	_____
3:20 PM	_____
3:40 PM	_____
4:00 PM	_____
4:20 PM	_____

Special Events Monday

Special Events Monday

7:00 AM Professional Leadership Committee Meeting & Breakfast/Tides Restaurant-Hyatt Regency (by invitation)
8:00 AM Science Educators' Workshop/Seaview-Hyatt Regency (by invitation)
10:20 AM AVS Member Center: Demo Hour--AVS Events & Activities/AVS 65 Mobile App/103C
12:05 PM MIND Business Meeting/201A
12:15 PM 2019 AVS Program Committee Meeting and Lunch/Regency A-Hyatt Regency (by invitation)
12:15 PM AVS Member Center: Professional Development--"Welcome to AVS Overview & Lunch**/103C
12:15 PM Recommended Practices Committee Meeting & Lunch/Pacific-Hyatt Regency (by invitation)
3:00 PM AVS Member Center: Professional Development--"Speed Networking for Young Professionals"/103C
4:00 PM Publications Committee Meeting/Shoreline A-Hyatt Regency (by invitation)
4:45 PM VTD Business Meeting/203B
5:00 PM Plenary Lecture: Kim Chaffin, Distinguished Scientist & Bakken Fellow in Strategic and Scientific Operations, Medtronic, plc, "The Internet of Things: Shaping the Future of the Medical Device Industry"/Grand Ballroom
6:15 PM AVS Symposium Plenary Panel/Grand Ballroom
7:00 PM ASSD Executive Committee Meeting & Dinner/Pacific-Hyatt Regency (by invitation)
7:00 PM Welcome Mixer/Hall B
7:30 PM Thin Film Division/Harper Award TED-Talk Competition/102A
7:45 PM MIND Executive Committee Meeting and Dinner/Shoreline A-Hyatt Regency (by invitation)
7:45 PM Publications Committee Meeting & Dinner/Offsite (by invitation)
8:30 AM-5:00 PM Short Course Program/Various Rooms

Monday Morning, October 22, 2018

2D Materials Focus Topic		Applied Surface Science Division
Room 201B - Session 2D+EM+MI+NS+TF-MoM		Room 204 - Session AS-MoM
2D Materials Growth and Fabrication		Quantitative Surface Analysis
Moderator: Jing Xia, University of California Irvine		Moderators: Kateryna Artyushkova, University of New Mexico, Tim Nunney, Thermo Fisher Scientific, UK
8:20am	2D+EM+MI+NS+TF-MoM1 Wafer Scale Epitaxial Growth of Monolayer and Few-Layer WS ₂ by Gas Source Chemical Vapor Deposition, <i>Mikhail Chubarov, T.H. Choudhury, J.M. Redwing</i> , The Pennsylvania State University	INVITED: AS-MoM1 A Fistful of Data: The Good, the Bad and the Ugly of Quantitative Surface Analysis, <i>Alexander Shard</i> , National Physical Laboratory, UK
8:40am	2D+EM+MI+NS+TF-MoM2 Wafer Scale Deposition of Monolayer Transition Metal Dichalcogenides, <i>Kortney Almeida, M. Wurch, G. Stecklein, L. Bartels</i> , University of California, Riverside	Invited talk continues.
9:00am	INVITED: 2D+EM+MI+NS+TF-MoM3 Crystal Growth of 2D Materials: From Model Systems to Integrated Manufacturing, <i>Stephan Hofmann</i> , University of Cambridge, UK	AS-MoM3 XPS and the Reproducibility Crisis, <i>Donald Baer, M.H. Engelhard</i> , Pacific Northwest National Laboratory
9:20am	Invited talk continues.	AS-MoM4 Rapid Calculation Method of the Voigt Function for Use in the Analysis of Photoelectron Spectroscopic Data, <i>Peter Sherwood</i> , University of Washington
9:40am	2D+EM+MI+NS+TF-MoM5 Understanding the Edge-Controlled Growth and Etching in Two-Dimensional Materials, <i>Kai Xiao, X. Li, X. Sang</i> , Center for Nanophase Materials Sciences, Oak Ridge National Laboratory; <i>W. Zhao, J. Dong</i> , Center for Multidimensional Carbon Materials (CMCM), Institute for Basic Science (IBS), Ulsan,44919, South Korea; <i>A. Purektyz</i> , Center for Nanophase Materials Sciences, Oak Ridge National Laboratory; <i>C. Rouleau</i> , Center for Functional Nanomaterials Brookhaven National Laboratory; <i>F. Ding</i> , Center for Multidimensional Carbon Materials (CMCM), Institute for Basic Science (IBS), Ulsan,44919, South Korea; <i>R.R. Unocic, D.B. Geohegan</i> , Center for Nanophase Materials Sciences, Oak Ridge National Laboratory	AS-MoM5 Statistical Analysis and Peak Fitting of X-ray Photoelectron Spectroscopy Data. Good Practices and Procedures for Working up this Information., <i>Matthew Richard Linford, V. Jain</i> , Brigham Young University
10:00am	2D+EM+MI+NS+TF-MoM6 Synthesis and Characterization of 1T, 1T', and 2H MoTe ₂ Thin Films, <i>Thomas Empante</i> , University of California, Riverside; <i>Y. Zhou</i> , Stanford University; <i>S.A. Naghibi Alvillar</i> , El Camino College; <i>E.J. Reed</i> , Stanford University; <i>L. Bartels</i> , University of California, Riverside	AS-MoM6 Modeling the Shirley Background, <i>Alberto Herrera-Gomez, D. Mulato-Gomez</i> , Cinvestav-Unidad Queretaro, Mexico; <i>A.D. Dutoi</i> , University of the Pacific
10:20am	BREAK	BREAK
10:40am	INVITED: 2D+EM+MI+NS+TF-MoM8 2D Anisotropic Semiconductors: Competing Phases by Alloys Engineering, <i>Sefaattin Tongay</i> , Arizona State University	AS-MoM8 XPS Spectra and Bonding In Ionic Transition Metal Compounds, <i>C. Richard Brundle</i> , C. R. Brundle and Associates; <i>P.S. Bagus</i> , University of North Texas
11:00am	Invited talk continues.	AS-MoM9 Combinatorial Group XPS Analysis of Novel Material Systems, <i>Sarah Coulter</i> , Kratos Analytical Ltd, UK; <i>J.D.P. Counsell</i> , Kratos Analytical Limited, UK; <i>C. Moffitt</i> , Kratos Analytical Inc.; <i>C.J. Blomfield, A.J. Roberts</i> , Kratos Analytical Limited, UK
11:20am	2D+EM+MI+NS+TF-MoM10 Low-Defect, High-Uniformity Transfer-Free Graphene on SiO ₂ by Thermal Chemical Vapor Deposition, <i>Leslie Chan, D.S. Tsai, Z. Wang, C. Carraro, R. Maboudian</i> , University of California, Berkeley	AS-MoM10 Towards Spatially Resolved Quantification of Gold Nanoparticles Embedded in an Organic Matrix using Secondary Ion Mass Spectrometry, <i>Shin Muramoto, J. Bennett</i> , National Institute of Standards and Technology (NIST)
11:40am	2D+EM+MI+NS+TF-MoM11 Barrier Based Approach to Modify Vapor Phase Concentrations for High Quality MoS ₂ Growth, <i>Dongzhi Chi, S.L. Wong</i> , Institute of Materials Research and Engineering, Agency for Science Technology and Research, Singapore	AS-MoM11 Correction-Free Analysis of SIMS Data at High Mass Resolution in the Presence of Detector Saturation, <i>Lev Gelb, A.V. Walker</i> , University of Texas at Dallas

Monday Morning, October 22, 2018

Spectroscopic Ellipsometry Focus Topic Room 202A - Session EL+AS+EM-MoM Application of SE for the Characterization of Thin Films and Nanostructures Moderators: Alain C. Diebold, SUNY Polytechnic Institute, Mathias Schubert, University of Nebraska-Lincoln		Electronic Materials and Photonics Division Room 101A - Session EM+MP+PS-MoM IoT Session: CMOS, Beyond the Roadmap and Over the Cliff Moderators: Sean King, Intel Corporation, Wilman Tsai, Taiwan Semiconductor Manufacturing Co. (TSMC)
8:20am	INVITED: EL+AS+EM-MoM1 Stealth Technology-based Terahertz Frequency-domain Ellipsometry, <i>Vanya Darakchieva</i> , Linköping University, Sweden	EM+MP+PS-MoM1 Aluminum Gettering Gate for Improving Defect Density in SiGe MOSCAP Devices, <i>Emily Thomson, M. Kavrik, A.C. Kummel</i> , University of California at San Diego
8:40am	Invited talk continues.	EM+MP+PS-MoM2 Direct Growth of Single Crystal Compound Semiconductor Materials on Diverse Substrates for Beyond the Roadmap Multifunctional Integrated Circuits, <i>Debarghya Sarkar, R. Kapadia</i> , University of Southern California
9:00am	EL+AS+EM-MoM3 Spectroscopic Ellipsometry and Finite Element Modeling based Optical Characterization of Highly Coherent Au-Si Slanted Columnar Periodic Nanostructures, <i>Ufuk Kılıç</i> , University of Nebraska-Lincoln; <i>A. Mock</i> , Linköping University, Sweden; <i>R. Feder</i> , Fraunhofer IMWS, Germany; <i>D. Sekora, M. Hilfiker, R. Korlacki, E. Schubert, C. Argyropoulos, M. Schubert</i> , University of Nebraska-Lincoln	INVITED: EM+MP+PS-MoM3 Going Beyond Traditional CMOS, <i>Inge Asselberghs, I. Radu</i> , IMEC, Belgium
9:20am	EL+AS+EM-MoM4 Temperature Dependent Dielectric Function and Critical Point Comparison of bulk Ge and α -Sn on InSb, <i>Rigo Carrasco, C. Emminger, N. Samarasinha, F. Abadizaman, S. Zollner</i> , New Mexico State University	Invited talk continues.
9:40am	EL+AS+EM-MoM5 Elastomer Thin Films and Conducting Nanostructures for Soft Electronics and Dielectric Elastomer Transducers, <i>Bert Müller, B. Osmani, T. Töpper</i> , University of Basel, Switzerland	EM+MP+PS-MoM5 Suppression of Electronic Defects at HfO ₂ -SiGe Interface with Selective Surface Oxidation Using Ozone, <i>Mahmut Sami Kavrik</i> , University of California at San Diego; <i>V. Hou</i> , TSMC, Taiwan, Republic of China; <i>E. Thomson</i> , University of California at San Diego; <i>K. Tang</i> , Stanford University; <i>Y. Taur</i> , University of California at San Diego; <i>P.C. McIntyre</i> , Stanford University; <i>A.C. Kummel</i> , University of California at San Diego
10:00am	EL+AS+EM-MoM6 Spectroscopic Ellipsometry Investigation of Temperature Effects in Heated Self-organized 2D Arrays of Au Nanoparticles, <i>Michele Magnozzi, M. Ferrara, M. Canepa</i> , Università di Genova, Italy; <i>F. Bisio</i> , CNR-SPIN, Italy	EM+MP+PS-MoM6 Surface Free Energy and Interfacial Strain in HfO ₂ and HZO Ferroelectric Formation, <i>Andrew Kummel, E. Chagarov, M. Kavrik</i> , University of California at San Diego; <i>M. Katz, N. Sanford, A. Davydov</i> , National Institute of Standards and Technology (NIST); <i>M. Lee</i> , National Taiwan University
10:20am	BREAK	BREAK
10:40am	EL+AS+EM-MoM8 Spectroscopic Ellipsometry of 2D WSe ₂ Films, <i>Baokun Song, H.G. Gu, M.S. Fang</i> , Huazhong University of Science & Technology, China; <i>Y.L. Hong, W.C. Ren</i> , Shenyang National Laboratory for Materials Science Institute of Metal Research Chinese Academy of Sciences, China; <i>X.G. Chen, S.Y. Liu</i> , Huazhong University of Science & Technology, China	INVITED: EM+MP+PS-MoM8 The Role of Selective Processes in the Atomic Scale Era, <i>Robert Clark, J. Smith, K.-H. Yu, K. Tapiy, G. Pattanaik, S. Consiglio, T. Hakamata, C.S. Wajda, A. Raley, G.J. Leusink</i> , TEL Technology Center, America, LLC
11:00am	EL+AS+EM-MoM9 Thermal Evolution Process of MnPb_3 Film Based on Spectroscopic Ellipsometry, <i>X.Q. Wang, X.Y. Shan, H. Siddique, Rucheng Dai, Z.P. Wang, Z.J. Ding, Z.M. Zhang</i> , University of Science and Technology of China	Invited talk continues.
11:20am	EL+AS+EM-MoM10 a-Si as a Protective Layer to Block the Oxidization of Al mirrors, <i>Yoshua Wu</i> , University of California at Los Angeles; <i>D.D. Allred, R.S. Turley</i> , Brigham Young University	EM+MP+PS-MoM10 Selective Patterning of Silicon/Germanium Surfaces and Nanostructures via Surface Initiated Polymerization, <i>Amar Mohabir, T. Weiss, G. Tutuncuoglu, E.M. Vogel, M.A. Filler</i> , Georgia Institute of Technology
11:40am	EL+AS+EM-MoM11 Terahertz to Mid-infrared Dielectric Response of Poly-methacrylates for Stereolithographic Single Layer Assembly, <i>D.B. Fullager, Serang Park, Y. Li, J. Reese</i> , University of North Carolina at Charlotte; <i>E. Sharma, S. Lee</i> , Harris Corporation; <i>S. Schöche, C.M. Herzinger, J.A. Woollam Co. Inc; G.D. Boreman, T. Hofmann</i> , University of North Carolina at Charlotte	EM+MP+PS-MoM11 Chemically Selective Imaging of Sequential Infiltration Synthesis with nm-scale Spatial Resolution, <i>D. Nowak, Tom Albrecht</i> , Molecular Vista

Monday Morning, October 22, 2018

Industrial Physics Forum Room 101B - Session IPF+AS+BI+NS-MoM Biofabrication: From Tissue to Organ Moderators: Jason Bardi, American Institute of Physics, Jim Hollenhorst, Agilent Technologies		In-situ Microscopy, Spectroscopy, and Microfluidics Focus Topic Room 202B - Session MM+AS+NS+PC-MoM Mechanical, Electrical, Thermal and Optical Systems for In situ TEM (9:00-10:100 am)/ Beam Induced Effects and Processing in Liquid/Gas Cells for TEM/SEM (10:40-11:40 am) Moderators: Suneel Kodambaka, Univ. of California, Los Angeles, Olga Ovchinnikova, Oak Ridge National Laboratory
8:20am	INVITED: IPF+AS+BI+NS-MoM1 Strategic Thinking on the Architecture and Design of Scaffolds for Regenerative Medicine, <i>Buddy D. Ratner</i> , University of Washington, Seattle	
8:40am	Invited talk continues.	
9:00am	INVITED: IPF+AS+BI+NS-MoM3 Sequential Bottom-up Assembly of Synthetic Cells, <i>Joachim Spatz</i> , Max Planck Institute for Medical Research, Germany	INVITED: MM+AS+NS+PC-MoM3 Cantilever Substrates for Quantitative Growth Experiments in the Environmental Transmission Electron Microscope, <i>Frances Ross</i> , IBM T. J. Watson Research Center, MIT
9:20am	Invited talk continues.	Invited talk continues.
9:40am	INVITED: IPF+AS+BI+NS-MoM5 Activation of Inkjet Printed Cells Enhances Microvasculature Formation in Host Tissues, <i>Thomas Boland, B. Oropeza, L.H. Solis</i> , University of Texas at El Paso; <i>M. Yanez</i> , University of South Carolina	MM+AS+NS+PC-MoM5 In Situ Laser Heating and Excitation in the Transmission Electron Microscope: Recrystallization, Grain Growth, Phase Separation and Dewetting in $\text{Ag}_{0.5}\text{Ni}_{0.5}$ Thin Films, <i>Philip D. Rack</i> , University of Tennessee Knoxville; <i>Y. Wu</i> , University of Notre Dame; <i>C. Liu</i> , University of Tennessee Knoxville; <i>T.M. Moore, G.A. Magel</i> , Waviks Inc.; <i>D. Garfinkel</i> , University of Tennessee Knoxville; <i>J.P. Camden</i> , University of Notre Dame; <i>M.G. Stanford, G. Duscher</i> , University of Tennessee Knoxville
10:00am	Invited talk continues.	MIM+AS+NS+PC-MoM6 In situ Transmission Electron Microscopy Study of the Mechanical and Electrical Properties of Single III-V Semiconductor Nanowires, <i>Lunjie Zeng</i> , Chalmers University of Technology, Gothenburg, Sweden; <i>C. Gammer</i> , Austrian Academy of Sciences, Austria; <i>B. Ozdol</i> , Lawrence Berkeley National Laboratory; <i>T. Nordqvist, P. Krogstrup</i> , University of Copenhagen, Denmark; <i>A.M. Minor</i> , Lawrence Berkeley National Laboratory; <i>W. Jäger, E. Olsson</i> , Chalmers University of Technology, Gothenburg, Sweden
10:20am	BREAK	BREAK
10:40am	INVITED: IPF+AS+BI+NS-MoM8 Challenges in Organ-specific Vascular Engineering and Tissue Assembly, <i>Ying Zheng</i> , University of Washington	INVITED: MM+AS+NS+PC-MoM8 Radiolytic Synthesis of Nanostructured Materials using <i>In situ</i> Liquid Cell Microscopy, <i>Raymond Unocic, X. Sang, A. Belianinov, O.S. Ovchinnikova, K. More, S. Jesse</i> , Oak Ridge National Laboratory
11:00am	Invited talk continues.	Invited talk continues.
11:20am	INVITED: IPF+AS+BI+NS-MoM10 Bioprinting for Translational Applications: <i>The Quest for Whole Organ Fabrication</i> , <i>James J. Yoo</i> , Wake Forest School of Medicine	MM+AS+NS+PC-MoM10 Electron Beam Induced Cross-Linking in Liquid Hydrogels, <i>Tanya Gupta, A. Kolmakov</i> , National Institute of Standards and Technology (NIST)
11:40am	Invited talk continues.	MM+AS+NS+PC-MoM11 Nanoscale Chemical Reactor Based on Localized Surface Plasmon Energy in Environmental Transmission Electron Microscope, <i>Canhui Wang¹, W.-C. Yang</i> , UMD/NIST; <i>R. Sharma</i> , National Institute of Standards and Technology

¹ NSTD Postdoc Finalist

Monday Morning, October 22, 2018

Materials and Processes for Quantum Computing Focus Topic Room 203A - Session MP+EM+MN+NS-MoM Systems and Devices for Quantum Computing I Moderator: Vivekananda Adiga, IBM, T.J. Watson Research Center		Nanometer-scale Science and Technology Division Room 102B - Session NS+2D+AN+EM+MN+MP+PC+RM-MoM IoT Session: Nanostructured Devices and Sensors Moderators: David Czaplewski, Argonne National Laboratory, Liya Yu, NIST Center for Nanoscale Science and Technology
8:20am		INVITED: NS+2D+AN+EM+MN+MP+PC+RM-MoM1 Integrating Nanodiamonds with Augmented Artificial Intelligence and Digital Health to Optimize Combination Therapy, <i>Dean Ho</i> , UCLA
8:40am		Invited talk continues.
9:00am	INVITED: MP+EM+MN+NS-MoM3 Quantum Supremacy: Checking a Quantum Computer with a Classical Supercomputer, <i>John Martinis</i> , Google Inc	NS+2D+AN+EM+MN+MP+PC+RM-MoM3 Morphology-Controlled Large-Scale Tin Oxide Nanostructures for Highly Sensitive Room Temperature Gas Sensor, <i>Amrit Sharma</i> , Norfolk State University
9:20am	Invited talk continues.	NS+2D+AN+EM+MN+MP+PC+RM-MoM4 Improving the Localized Surface Plasmonic Resonance Sensing Properties by Composite Metal/Dielectric Mixtures, <i>Steven Larson</i> ¹ , Y. Zhao, University of Georgia
9:40am	MP+EM+MN+NS-MoM5 Active Protection of a Superconducting Qubit against Josephson Amplifier Backaction, <i>Baleegh Abdo</i> , N.T. Brann, O. Jinka, S.B. Olivadese, A. Corcoles, M. Brink, IBM T. J. Watson Research Center; R. Lake, D.P. Pappas, National Institute of Standards and Technology; J.M. Chow, IBM T. J. Watson Research Center	NS+2D+AN+EM+MN+MP+PC+RM-MoM5 Improving the Selectivity of Tin (IV) Oxide Paper Based Gas Sensors with Plasma Surface Modification, <i>Kimberly Hiyoto</i> , E.R. Fisher, Colorado State University
10:00am	MP+EM+MN+NS-MoM6 Nonlinear Light-matter Interaction: From Superconducting Qubits to Spins in Diamond, <i>Eyal Buks</i> , Israel Institute of Technology, Israel	NS+2D+AN+EM+MN+MP+PC+RM-MoM6 TiN@Si ₃ N ₄ Core-shell Heterostructures as Nanoantennas for Photocatalytic Reforming of Methanol, <i>Alejandro Alvarez Barragan</i> , L. Mangolini, University of California, Riverside
10:20am	BREAK	BREAK
10:40am	MP+EM+MN+NS-MoM8 Variations in Surface Dipole-Moment Density with Coverage for C/Au(110) – (2 × 1) and Electroplated Au Ion-trap Electrodes, <i>Dustin Hite</i> , K.S. McKay, National Institute of Standards and Technology (NIST); H.Z. Jooya, ITAMP, Harvard-Smithsonian Center for Astrophysics; E. Kim, University of Nevada, Las Vegas; P.F. Week, Sandia National Laboratories; H.R. Sadeghpour, ITAMP, Harvard-Smithsonian Center for Astrophysics; D.P. Pappas, National Institute of Standards and Technology (NIST)	INVITED: NS+2D+AN+EM+MN+MP+PC+RM-MoM8 Nanostructured Sensor and Device Applications of Infiltrated Zinc Oxide, <i>Leonidas Ocola</i> , Argonne National Laboratory; Y. Wang, J. Chen, University of Wisconsin-Milwaukee; P. Blaisdell-Pijuan, California State University-Fullerton; R. Divan, Argonne National Laboratory
11:00am	MP+EM+MN+NS-MoM9 A Compact Cryogenic Setup for Quantum Computing with Trapped Atomic Ions, <i>Ismail Inlek</i> , R. Spivey, G. Vrijen, Z. Jia, J. Kim, Duke University	Invited talk continues.
11:20am	INVITED: MP+EM+MN+NS-MoM10 Advances in Trapped Ion Quantum Computing, <i>Jungsang Kim</i> , Duke University	NS+2D+AN+EM+MN+MP+PC+RM-MoM10 Templates for the Investigation of Size-Selected Nanocluster Networks, <i>Patrick Edwards</i> , V.V. Kresin, University of Southern California
11:40am	Invited talk continues.	NS+2D+AN+EM+MN+MP+PC+RM-MoM11 High Performance Detection for X-ray and g-ray with MAPbX ₃ Perovskite Single Crystals, X. Wang, Z. Zhu, Q. Li, J. Wu, X. Zhang, B. Wang, <i>Wei Lei</i> , Southeast University

¹ NSTD Student Award Finalist

Monday Morning, October 22, 2018

Plasma Science and Technology Division Room 104A - Session PS+AS+EM+SS-MoM Plasma-Surface Interactions Moderators: Yohei Ishii, Hitachi High Technologies America Inc., Erik V. Johnson, LPICM, CNRS, Ecole polytechnique, Université Paris-Saclay		Plasma Science and Technology Division Room 104C - Session PS+TF-MoM Plasma Deposition and Plasma-Enhanced ALD Moderators: Kazunori Koga, Kyushu University, Japan, Erwine Pargon, LTM, Univ. Grenoble Alpes, CEA-LETI, France
8:20am	PS+AS+EM+SS-MoM1 Atomic-scale Numerical Simulation of a Nanometer-Scale Hole Etching of SiO ₂ with a Carbon Mask, <i>Charisse Marie Cagomoc, M. Isobe, S. Hamaguchi</i> , Osaka University, Japan	PS+TF-MoM1 ZrO ₂ Deposition using a 2.45 GHz Atmospheric Pressure Plasma Torch, <i>Dhruv Patel, L. Bonova, C. Ahn, D.V. Krogstad, D.N. Ruzic</i> , University of Illinois at Urbana-Champaign; <i>S. Chaudhuri</i> , University of Illinois at Chicago
8:40am	PS+AS+EM+SS-MoM2 SF ₆ /O ₂ Plasma Nanotexturing of Silicon: Decoupling How Ion Flux and Ion Energy Matter, <i>Guillaume Fischer</i> ¹ , Institut Photovoltaïque d'Ile-de-France (IPVF), France; <i>E. DRAHI, S.A. FILONOVICH</i> , Total SA Renewables, France; <i>E.V. Johnson</i> , LPICM, CNRS, Ecole polytechnique, Université Paris-Saclay, France	PS+TF-MoM2 Ion Energy Characteristics during Plasma-Enhanced Atomic Layer Deposition and their Role in Tailoring Material Properties, <i>Tahsin Faraz</i> ¹ , <i>K. Arts, S. Karwal, M.C. Creatore</i> , Eindhoven University of Technology, The Netherlands; <i>H.C.M. Knoops</i> , Oxford Instruments, The Netherlands; <i>W.M.M. Kessels</i> , Eindhoven University of Technology, The Netherlands
9:00am	PS+AS+EM+SS-MoM3 Corrosion Resistance to F and Cl plasma of Yttrium Oxyfluoride (YOF) formed by Sintering, <i>Akinobu Teramoto, Y. Shiba, T. Goto</i> , Tohoku University, Japan; <i>Y. Kishi</i> , Nippon Yttrium Co., Ltd, Japan; <i>S. Sugawa</i> , Tohoku University, Japan	INVITED: PS+TF-MoM3 Plasma Deposition of Functional, Nanostructured Coatings on Materials and Nanomaterials Derived from the Wood Biomass, <i>Luc Stafford</i> , Université de Montréal, Canada
9:20am	PS+AS+EM+SS-MoM4 Decay of Hydrogen in NF ₃ /Ar and O ₂ /Ar Cleaning Process by Optical Emission Spectroscopy, <i>Hanyang Li, Y. Zhou, V.M. Donnelly</i> , University of Houston; <i>J. Chiu, X. Chen</i> , MKS	Invited talk continues.
9:40am	INVITED: PS+AS+EM+SS-MoM5 Plasma-surface Interactions in the Strongly Coupled Regime, <i>Thomas Morgan</i> , DIFFER, Netherlands	PS+TF-MoM5 Mechanisms of Halogenated Silane Decomposition on an N-rich Surface during Atomic Layer Deposition of Silicon Nitride, <i>Gregory Hartmann</i> , University of Texas at Austin; <i>P.L.G. Ventzek</i> , Tokyo Electron America, Inc.; <i>K. Ishibashi, T. Iwao</i> , Tokyo Electron Technology Solutions Ltd., Japan; <i>G.S. Hwang</i> , University of Texas at Austin
10:00am	Invited talk continues.	PS+TF-MoM6 Characterization of Inductively Coupled Plasma Source for Plasma Enhanced Atomic Layer Deposition, <i>Premkumar Panneerchelvam, A. Agarwal</i> , KLA-Tencor; <i>D.R. Boris, S.G. Walton</i> , Naval Research Laboratory
10:20am	BREAK	BREAK
10:40am	PS+AS+EM+SS-MoM8 Tailoring the Surface Properties of Porous Zeolite Constructs using Plasma Processing, <i>Angela Hanna</i> ² , <i>E.R. Fisher</i> , Colorado State University	PS+TF-MoM8 Structural, Optical, and Electrical Properties of Plasma-Enhanced Atomic Layer Deposited ZnO: Influence of Substrate Temperature, <i>Julian Pilz, A. Perrotta, A.M. Coelte</i> , Graz University of Technology, Austria
11:00am	PS+AS+EM+SS-MoM9 Generation Kinetics of Plasma-induced Electronic Defects in Semiconductor Materials, <i>Shota Nunomura, I. Sakata, K. Matsubara</i> , National Institute of Advanced Industrial Science and Technology (AIST), Japan	PS+TF-MoM9 Critical Effect of the Presence and Position of Double Bonds in the Atmospheric Plasma Synthesis of Organic Coatings, <i>Jérémie Mertens</i> ¹ , <i>J. Baneton, A. Ozkan, F. Reniers</i> , Université Libre de Bruxelles, Belgium
11:20am	PS+AS+EM+SS-MoM10 Evolution of Photoresist Layer Structure and Surface Morphology under Fluorocarbon-Based Plasma Exposure, <i>Adam Pranda, S.A. Gutierrez Razo, J.T. Fourkas, G.S. Oehrlein</i> , University of Maryland, College Park	PS+TF-MoM10 Capacitively Coupled DC/RF Discharges for PEALD Process of Titanium Dioxide Films, <i>Shinya Iwashita, A. Suzuki, T. Shindo, T. Kikuchi, T. Matsudo, Y. Morita, T. Moriya</i> , Tokyo Electron Technology Solutions Ltd., Japan; <i>A. Uedono</i> , University of Tsukuba, Japan
11:40am	PS+AS+EM+SS-MoM11 Fundamental Studies of Plasma Species with Organic Materials of Varying Hydrogen and Oxygen Composition by Computational and Experimental Approaches, <i>Yusuke Fukunaga</i> , Nagoya University, Japan; <i>P.L.G. Ventzek, B. Lane</i> , Tokyo Electron America, Inc.; <i>A. Ranjan, TEL Technology Center America, LLC; M. Sekine, T. Tsutsumi, H. Kondo, K. Ishikawa</i> , Plasma Nanotechnology Research Center, Japan; <i>R. Upadhyay</i> , Esgee Technologies; <i>L. L. Raja</i> , The University of Texas at Austin; <i>G. Hartmann</i> , McKetta Department of Chemical Engineering, The University of Texas at Austin; <i>G. S. Hwang</i> , The University of Texas at Austin; <i>M. Hori</i> , Institute of innovation for future society, Japan	PS+TF-MoM11 The effects of Varying Plasma Conditions on Plasma Enhanced Atomic Layer Epitaxy, <i>D.R. Boris, V.D. Wheeler</i> , U.S. Naval Research Laboratory; <i>V.R. Anderson</i> , Kennesaw State University; <i>N. Nepal</i> , U.S. Naval Research Laboratory; <i>S.G. Rosenberg, A.C. Kozen</i> , ASEE Postdoctoral Fellow; <i>S.G. Walton, Charles Eddy</i> , U.S. Naval Research Laboratory

¹ Coburn & Winters Student Award Finalist

² National Student Award Finalist

Monday Morning, October 22, 2018

Advanced Surface Engineering Division Room 202C - Session SE+NS+TF-MoM Nanostructured Thin Films and Coatings Moderators: Jianliang Lin, Southwest Research Institute, Matjaz Panjan, Jozef Stefan Institute, Slovenia		Surface Science Division Room 203C - Session SS+HC+MI-MoM Dynamical Processes at Surfaces Moderator: Gareth Parkinson, TU Wien
8:20am	SE+NS+TF-MoM1 The Role of Mechanical and Chemical Bonding Mechanisms in Adhesion of Nanoporous Anodic Aluminium Oxides (AAO), <i>Shoshan Abrahami</i> , Vrije Universiteit Brussel (VUB), Belgium; <i>V.C. Gudla</i> , Technical University of Denmark; <i>K. Marcoen</i> , Vrije Universiteit Brussel, Belgium; <i>J.M.M. de Kok</i> , Fokker Aerostructures; <i>T. Hauffman</i> , Vrije Universiteit Brussel, Belgium; <i>R. Ambat</i> , Technical University of Denmark; <i>J.M.C. Mol</i> , Technical University Delft, Netherlands; <i>H. Terryn</i> , Vrije Universiteit Brussel, Belgium	INVITED: SS+HC+MI-MoM1 Light Induced Single-Molecule Dynamics at Surfaces, <i>Wilson Ho</i> , University of California, Irvine
8:40am	SE+NS+TF-MoM2 Tuning Surface States of Nanocrystalline ZnO Films by Atomic Layer Deposited TiO _x , <i>C. Yi</i> , <i>Ich Tran</i> , <i>M. Law</i> , University of California, Irvine	Invited talk continues.
9:00am	SE+NS+TF-MoM3 Two-dimensional Hexagonal Boron Nitride (hBN) Layer Promoted Growth of Highly-oriented, Trigonal-structured Ta ₂ C(0001) Thin Films via Ultra-high Vacuum Sputter-deposition on Al ₂ O ₃ (0001), <i>Koichi Tanaka</i> , <i>P. Arias</i> , <i>M.E. Liao</i> , <i>Y. Wang</i> , <i>H. Zaid</i> , <i>A. Aleman</i> , <i>M.S. Goorsky</i> , <i>S. Kodambaka</i> , University of California, Los Angeles	SS+HC+MI-MoM3 Probing the Effects of Surface Structure on the Dissociative Chemisorption of Methane, <i>Eric High¹</i> , <i>D.G. Tinney</i> , <i>A.L. Utz</i> , Tufts University
9:20am	SE+NS+TF-MoM4 Nitride High Entropy Alloy Thin Films Deposited by Magnetron Sputtering and Cathodic Arc on Polymer Substrates: Structure and Electro-Mechanical Properties, <i>Ao Xia</i> , Montanuniversität Leoben, Austria; <i>R. Dedoncker</i> , Ghent University, Belgium; <i>M.J. Cordill</i> , Erich Schmid Institute of Materials Science, Austria; <i>D.J.M.G. Depla</i> , Ghent University, Belgium; <i>R. Franz</i> , Montanuniversität Leoben, Austria	SS+HC+MI-MoM4 Adsorption and Diffusion of NH ₃ on Anatase-TiO ₂ (101), <i>Kræn Christoffer Adamsen</i> , <i>S. Koust</i> , <i>E.L. Kolsbjerg</i> , <i>B. Hammer</i> , <i>S. Wendt</i> , <i>J.V. Lauritsen</i> , Aarhus University, Denmark
9:40am	SE+NS+TF-MoM5 Isomeric Phase Composition and Mechanical Properties of NbN Nanocomposite Coatings Deposited by Modulated Pulsed Power Magnetron Sputtering, <i>Y.G. Li</i> , <i>H. Yuan</i> , <i>Z.T. Jiang</i> , <i>N. Pan</i> , <i>M.K. Lei</i> , Dalian University of Technology, China	SS+HC+MI-MoM5 Non-equilibrium Growth of Metastable Clusters as a Means of Controlling Supramolecular Structure., <i>Ryan Brown</i> , Clarkson University; <i>A.S.A. Kandel</i> , University of Notre Dame
10:00am	SE+NS+TF-MoM6 Ab initio Guided Development of Ternary Borides: A Case Study of Ti-B-N, Ti-Zr-B, Ti-W-B, Ta-W-B, and V-W-B Systems, <i>V. Moraes</i> , <i>R. Hahn</i> , <i>M. Bartosik</i> , <i>H. Riedl</i> , TU Wien, Austria; <i>H. Euchner</i> , Ulm University, Austria; <i>D. Holec</i> , Montanuniversität Leoben, Austria; <i>Paul Heinz Mayrhofer</i> , TU Wien, Austria	SS+HC+MI-MoM6 Ultrafast Dynamics of Reaction Pathways on Metal Surfaces, <i>Jerry LaRue</i> , Chapman University
10:20am	BREAK	BREAK
10:40am	INVITED: SE+NS+TF-MoM8 Toughness Enhancement in Hard Ceramic Films by Alloy Design, <i>Hanna Kindlund</i> , Department of Mechanical and Aerospace Engineering, University of California Los Angeles (UCLA)	INVITED: SS+HC+MI-MoM8 Designer Solids via Multi-Heteroepitaxy: Layer-by-Layer Deposition of Molecular Frameworks on Solid Substrates, <i>Christof Wöll</i> , Karlsruhe Institute of Technology, Germany
11:00am	Invited talk continues.	Invited talk continues.
11:20am	SE+NS+TF-MoM10 From Ab-Initio Design to Synthesis of Multifunctional Coatings with Enhanced Hardness and Toughness, <i>D. Edström</i> , <i>D. Sangiovanni</i> , <i>L. Hultman</i> , Linköping University, Sweden; <i>I. Petrov</i> , <i>J. Greene</i> , University of Illinois at Urbana Champaign; <i>Valeriu Chirita</i> , Linköping University, Sweden	SS+HC+MI-MoM10 Isotope Enrichment via Non-Equilibrium Differential Condensation and Reflection using Supersonic Beam Gas-Surface Scattering, <i>Jacob Graham</i> , <i>A. McMillan</i> , <i>K. Nihill</i> , <i>S.J. Sibener</i> , University of Chicago
11:40am	SE+NS+TF-MoM11 Mechanical Properties of V _{0.5} Mo _{0.5} N _{1-x} O _x Thin Films, <i>Daniel Edström</i> , <i>D. Sangiovanni</i> , Linköping University, Sweden; <i>L. Landålv</i> , Linköping University, Sandvik Coromant AB, Sweden; <i>L. Hultman</i> , Linköping University, Sweden; <i>I. Petrov</i> , <i>J. Greene</i> , University of Illinois at Urbana Champaign, Linköping University, Sweden; <i>P. Eklund</i> , <i>V. Chirita</i> , Linköping University, Sweden	SS+HC+MI-MoM11 Structural Reorganization of Sequentially Adsorbed Two-component Self-assembled Monolayers after Soft Ultraviolet Irradiation, <i>C. Gerber</i> , <i>Rebecca Guardokus</i> , University of Connecticut

¹ Morton S. Traum Award Finalist

Monday Morning, October 22, 2018

Thin Films Division		Thin Films Division
Room 102A - Session TF1-MoM		Room 104B - Session TF2-MoM
Precursors and Surface Reactions		IoT Session: Thin Film Processes for Energy Storage
Moderators: Cathleen Cruden, Queen's University, Canada, Markku Leskela, University of Helsinki, Finland		Moderators: Virginia Wheeler, U.S. Naval Research Laboratory, Paul Poodt, Holst Centre / TNO, The Netherlands
8:20am	TF1-MoM1 Monitoring the Transient Surface Species during TiO ₂ Atomic Layer Deposition using Surface-Enhanced Raman Spectroscopy, <i>Ryan Hackler^a, G. Kang, G.C. Schatz, P.C. Stair, R.P. Van Duyne</i> , Northwestern University	INVITED: TF2-MoM1 Thin Films for Next Generation Batteries, <i>Brecht Put, Imec, Belgium; S. Hollevoet, N. Labyedh, KULeuven & Imec, Belgium; M. Debucquoy, Imec, Belgium; W.M.M. Kessels, M.C. Creatore, Eindhoven University of Technology, The Netherlands; P.M. Vereecken, KULeuven & Imec, Belgium</i>
8:40am	TF1-MoM2 Theoretical Study on the Effect of Precursor Ligand in Atomic Layer Deposition of Al ₂ O ₃ on SiO ₂ , <i>Tania Sandoval</i> , Universidad Técnica Federico Santa María; <i>T-L. Liu</i> , Stanford University; <i>R. Tonner</i> , Philipps-Universität Marburg; <i>S.F. Bent</i> , Stanford University	Invited talk continues.
9:00am	TF1-MoM3 Relevance of Dimeric and Tetrameric Structures to the Surface Chemistry of Metal Amidinate Atomic Layer Deposition Precursors, <i>Bo Chen, Y. Yao, Q. Ma, F. Zaera</i> , University of California, Riverside; <i>Y. Duan, A.V. Teplyakov</i> , University of Delaware; <i>J. Coyle, S. Barry</i> , Carleton University	TF2-MoM3 Radical Enhanced Atomic Layer Deposition of Cobalt Oxide Based Electrodes for 3D Lithium-ion Battery Applications, <i>Ryan Sheila, J. Lau, B. Dunn, J.P. Chang</i> , University of California at Los Angeles
9:20am	TF1-MoM4 Low Temperature Dielectric ALD with the use of Hydrogen Peroxide: Comparison of Growth and Film Characteristics for Anhydrous H ₂ O ₂ , H ₂ O ₂ /H ₂ O Mixtures and H ₂ O, <i>Daniel Alvarez, K. Andachi, J. Spiegelman</i> , RASIRC	TF2-MoM4 Fast-charging 3D Battery Electrodes with High-Capacity Materials Using Large Area Atmospheric Pressure Spatial ALD, <i>Lucas Havarkate, S. Unnikrishnan, D. Hermes</i> , Holst Centre / TNO, The Netherlands; <i>F. Roozeboom</i> , Eindhoven University of Technology, The Netherlands; <i>F. Zorro, F. Grob, E. Balder</i> , Holst Centre / TNO, The Netherlands; <i>P. Poodt</i> , Holst Centre / TNO and SALDtech B.V., Netherlands; <i>M. Tulodziecki</i> , Holst Centre / TNO, The Netherlands
9:40am	INVITED: TF1-MoM5 Putting More Chemistry into CVD. Precursors, Superconformality, and Selectivity, <i>Gregory Girolami, J.R. Abelson</i> , University of Illinois at Urbana-Champaign	INVITED: TF2-MoM5 Thin Film Technology - Opening New Frontiers for Solid State Batteries, <i>Gary Rubloff, K. Gregorczyk</i> , University of Maryland, College Park; <i>A. Pearse</i> , Control Electron; <i>S.B. Lee</i> , University of Maryland, College Park; <i>A.A. Talin</i> , Sandia National Laboratories, Livermore
10:00am	Invited talk continues.	Invited talk continues.
10:20am	BREAK	BREAK
10:40am	TF1-MoM8 Insight into the "Residual Methyls" during ALD of Al ₂ O ₃ from TMA/H ₂ O using <i>in situ</i> RAIRS, <i>Brent Sperling, B. Kalanyan, J.E. Maslar</i> , National Institute of Standards and Technology (NIST)	INVITED: TF2-MoM8 Atomic Layer Deposition: A Scalable Process for Enabling the Next Generation of High Performance Materials, <i>Arrelaine Dameron</i> , Forge Nano
11:00am	TF1-MoM9 Low Temperature Atomic Layer Deposition of Silicon Nitride using Hexachlorodisilane and Ultra-High Purity Hydrazine, <i>Aswin Kondusamy, A.T. Lucero, S. Hwang, X. Meng, H.S. Kim</i> , University of Texas at Dallas; <i>D. Alvarez Jr., J. Spiegelman</i> , RASIRC; <i>J. Kim</i> , University of Texas at Dallas	Invited talk continues.
11:20am	TF1-MoM10 Investigating Low-Temperature Atomic Layer Deposition of Nickel Oxide using Ni(^t Bu ₂ DAD) ₂ and Ozone, <i>Konner Holden, J.F. Conley, Jr.</i> , Oregon State University; <i>C.L. Dezela</i> , EMD Performance Materials	TF2-MoM10 A Facile CVD Route for the Large-scale Fabrication of Silicon-graphite Core-shell Composites, <i>Giorgio Nava, J. Schwan, L. Mangolini</i> , University of California, Riverside
11:40am		

¹ National Student Award Finalist

Monday Morning, October 22, 2018

Tribology Focus Topic Room 201A - Session TR+AS+NS+SS-MoM Tribology Focus Session Moderator: Filippo Mangolini, University of Texas at Austin		Vacuum Technology Division Room 203B - Session VT-MoM Vacuum Measurement Moderators: Marcy Stutzman, Thomas Jefferson National Accelerator Facility; Alan Van Drie, TAE Technologies
8:20am	INVITED: TR+AS+NS+SS-MoM1 Structural Superlubricity: History, Breakthroughs, and Challenges, <i>Mehmet Z. Baykara</i> , University of California, Merced	INVITED: VT-MoM1 Pharmaceutical Freeze-Drying and Vacuum-Drying: Challenges and Opportunities, <i>Evgenyi Shalaev</i> , Allergan
8:40am	Invited talk continues.	Invited talk continues.
9:00am	INVITED: TR+AS+NS+SS-MoM3 An Examination of the Nature of Bonding during Indentation and Sliding using MD and in-situ Nanoindentation, <i>Judith Harrison</i> , United States Naval Academy	VT-MoM3 Fixed Length Optical Cavities for Primary Traceability to the Pascal, <i>Jay Hendricks, J.E. Ricker, K.O. Douglass</i> , National Institute of Standards and Technology; <i>G. Brucker, E. Fuchs, A. Ocepek, P. Sullivan, S. Venkatesan, MKS Instruments, Inc.</i> , Pressure and Vacuum Measurement Group
9:20am	Invited talk continues.	VT-MoM4 Fundamental Quantum-based Vacuum Metrology at NIST, <i>Julia Scherschligt</i> , National Institute of Standards and Technology
9:40am	INVITED: TR+AS+NS+SS-MoM5 The Chemistry of Friction, Wear, and Tribofilm Growth on 2D Materials, <i>Jonathan Felts</i> , Texas A&M University	VT-MoM5 Moving the FLOC to the Telecom, <i>Kevin Douglass, J.E. Ricker</i> , National Institute of Standards and Technology; <i>J. Hendricks</i> , National Institute of Standards and Technology (NIST)
10:00am	Invited talk continues.	VT-MoM6 Transient Method of Permeability Measurements for Microporous Media, <i>M.V. Johansson</i> , Aix Marseille University, France; <i>M. Wuest</i> , INFICON, Liechtenstein; <i>P. Perrier, Irina Graur Martin</i> , Aix Marseille University, France
10:20am	BREAK	BREAK
10:40am	INVITED: TR+AS+NS+SS-MoM8 Nanomechanics of Soft, Hierarchical Polymer- and Biological-Networks, <i>Prathima Nalam</i> , University at Buffalo – SUNY	INVITED: VT-MoM8 Beamline Technology and Current Modeling Capabilities for Ion Implantation, <i>Svetlana Radovanov</i> , Applied Materials, Varian Semiconductor Equipment
11:00am	Invited talk continues.	Invited talk continues.
11:20am	INVITED: TR+AS+NS+SS-MoM10 Mechanisms for Controlling Friction and New Approaches for Achieving Superlubricity Regime in 2D Materials, <i>Diana Berman</i> , University of North Texas; <i>A. Erdemir, A.V. Sumant</i> , Argonne National Laboratory	VT-MoM10 Design of a New Thermal Vacuum Chamber for Space instrument Calibration, <i>Freek Molkenboer, R. Jansen, R.G. Veraar, G.C.J. Otter, W.P. van Werkhoven, N.B. Koster, F.P.G. Driessens</i> , TNO, Netherlands
11:40am	Invited talk continues.	VT-MoM11 Pressure Measurements from Combining Non-evaporable Getter Pumps and a Novel Extreme High Vacuum Cryopump, <i>Marcy Stutzman</i> , Thomas Jefferson National Accelerator Facility; <i>A. Segovia Miranda</i> , Universidad Autónoma de Zacatecas; <i>P.A. Adderley, M. Poelker</i> , Thomas Jefferson National Accelerator Facility
12:05pm	MIND BUSINESS MEETING	

Monday Afternoon, October 22, 2018

2D Materials Focus Topic Room 201B - Session 2D+MI+NS-MoA 2D Materials Characterization including Microscopy and Spectroscopy Moderators: Stephan Hofmann, University of Cambridge, UK, Richard Vanfleet, Brigham Young University		Applied Surface Science Division Room 204 - Session AS-MoA Multitechnique Applications-When More techniques are Better than One Moderator: Karen Gaskell, University of Maryland, College Park
1:20pm	INVITED: 2D+MI+NS-MoA1 Observing the Mechanisms of Graphene Growth during Chemical Vapor Deposition: Routes to Controlling Layer Number and Domain Size, <i>Robert Weatherup</i> , University of Manchester, UK	AS-MoA1 Overcoming Obstacles in Surface and Interface Characterization of All Solid-State Lithium Battery Materials, <i>Natalie Seitzman</i> , Colorado School of Mines; <i>H. Guthrey, D. Sulias, S. Johnston</i> , National Renewable Energy Laboratory; <i>J. Nelson Weker</i> , SLAC National Accelerator Laboratory; <i>H. Platt</i> , Solid Power, Inc.; <i>M. Al-Jassim</i> , National Renewable Energy Laboratory; <i>S. Pylypenko</i> , Colorado School of Mines
1:40pm	Invited talk continues.	AS-MoA2 <i>In-situ</i> Complementary XPS and Raman Analysis of Technologically Important Materials, <i>Paul Mack</i> , Thermo Fisher Scientific, UK
2:00pm	2D+MI+NS-MoA3 Band Alignment of 2-D Materials by Internal Photoemission, <i>Q. Zhang, S. Zhang</i> , Theiss Research & National Institute of Standards and Technology; <i>B. Sperling, Nhan Nguyen</i> , National Institute of Standards and Technology	INVITED: AS-MoA3 Integration of Laboratory Experiments, Spectroscopy, and Microscopy to Investigate the Reactivity of Metals in Mine Wastes, <i>José Cerrato</i> , University of New Mexico
2:20pm	2D+MI+NS-MoA4 Visible to mid-IR Nanoscale Characterization of 2D Materials via Photo-induced Force Microscopy, <i>Padraig O'Reilly, D. Nowak, S. Park</i> , Molecular Vista	Invited talk continues.
2:40pm	INVITED: 2D+MI+NS-MoA5 Polymorphic Structures and Diversified Properties of Low-dimensional Materials Investigated by In situ Electron Microscopy, <i>Kazu Suenaga</i> , National Institute of Advanced Industrial Science and Technology (AIST), Japan	AS-MoA5 Degradation Methodology of Reinforced Concrete in South Asia analyzed using Surface Analysis and other Techniques, <i>Nirmalya Karar</i> , CSIR-National Physical Laboratory, India; <i>S.K. Singh</i> , CSIR-CBRI Roorkee India
3:00pm	Invited talk continues.	AS-MoA6 Surface Phase, Morphology, and Charge Distribution Transitions on Vacuum and Ambient Annealed Perovskites: A Case Study on SrTiO ₃ (100), <i>Omur Dagdeviren¹, G. Simon, K. Zou, C. Ahn, F.J. Walker, E.I. Altman, U.D. Schwarz</i> , Yale University
3:20pm	BREAK	BREAK
3:40pm	INVITED: 2D+MI+NS-MoA8 Probing Interlayer Interaction in van der Waals Materials by Low-energy Electron Microscopy (LEEM), <i>Johannes Jobst, D. Geelen</i> , Leiden University, Netherlands; <i>R.M. Tromp</i> , IBM, T.J. Watson Research Center; <i>S.J. van der Molen</i> , Huygens-Kamerlingh Onnes Laboratory, Netherlands	AS-MoA8 In-situ Characterisation of Graphene using combined XPS and Raman Spectroscopy: Removal of Polymer Residue by Ar Gas Cluster Ion Beams, <i>Barry Brennan</i> , National Physical Laboratory, UK; <i>P. Mack</i> , Thermo Fisher Scientific, UK; <i>A. Centeno, A. Zurutuza</i> , Graphenea, Spain; <i>A.J. Pollard</i> , National Physical Laboratory, UK
4:00pm	Invited talk continues.	AS-MoA9 Topography-corrected TOF-SIMS Chemical Imaging of Chip Interconnect Surfaces, <i>Conor Thomas, B. Singh, R. Wang</i> , IBM Systems Division
4:20pm	2D+MI+NS-MoA10 Fast Full Wafer Analysis for Graphene and 2D-materials by Imaging Ellipsometry, <i>Sebastian Funke</i> , Accurion GmbH, Germany; <i>P. Braueniger-Weimer, S. Hofmann</i> , University of Cambridge, UK; <i>P.H. Thiesen</i> , Accurion GmbH, Germany	AS-MoA10 Combining the Benefits of GCIB-ToF-SIMS, MALDI-FTICR-MS and LC-MS/MS for Location specific Lipid Identification in Planarian Flatworm Tissue Sections, <i>Tina Angerer</i> , University of Washington; <i>D. Velickovic, C. Nicora, C.R. Anderton</i> , Pacific Northwest National Laboratory; <i>D.J. Graham, L.J. Gamble</i> , University of Washington
4:40pm		

¹ NSTD Student Award Finalist

Monday Afternoon, October 22, 2018

Biomaterial Interfaces Division Room 101B - Session BI+AS+IPF+MN-MoA Advanced Imaging and Structure Determination of Biomaterials Research Moderators: Dan Graham, University of Washington, Axel Rosenhahn, Ruhr-University Bochum, Germany		Spectroscopic Ellipsometry Focus Topic Room 202A - Session EL+EM-MoA Spectroscopic Ellipsometry: Novel Applications and Theoretical Approaches Moderators: Vanya Darakchieva, Stefan Zollner, New Mexico State University,
1:20pm	INVITED: BI+AS+IPF+MN-MoA1 NMR Relaxometry as a Medical Diagnostic, <i>Michael J. Cima</i> , Massachusetts Institute of Technology	INVITED: EL+EM-MoA1 The Physics of Low Symmetry Metal Oxides with Special Attention to Phonons, Plasmons and Excitons and their Potential for Uses in Power Electronics and Quantum Technologies, <i>Mathias Schubert</i> , University of Nebraska - Lincoln, Linköping University, Sweden, Leibniz Institute for Polymer Research, Dresden, Germany; <i>A. Mock, R. Korlacki, S. Knight</i> , University of Nebraska - Lincoln; <i>V. Darakchieva</i> , Linköping University, Sweden; <i>B. Monemar</i> , Linköping University, Sweden, Tokyo University of Agriculture and Tech., Japan; <i>H. Murakami, Y. Kumagai</i> , Tokyo University of Agriculture and Technology, Japan; <i>K. Goto</i> , Tokyo University of Agriculture and Technology, Tamura Corporation, Japan; <i>M. Higashiwaki</i> , National Institute of Information and Communications Technology, Japan
1:40pm	Invited talk continues.	Invited talk continues.
2:00pm	BI+AS+IPF+MN-MoA3 Direct Observation of Cell Signaling Proteins Interacting with a Model Cell Membrane by Sum Frequency Generation Vibrational Spectroscopy, <i>T.W. Golbek</i> , Oregon State University; <i>T. Weidner</i> , Aarhus University, Denmark; <i>C.P. Johnson, Joe Baio</i> , Oregon State University	EL+EM-MoA3 Mueller Matrix Spectroscopic Ellipsometry Based Scatterometry of Nanowire Gate-All-Around (GAA) Transistor Structures, <i>M. Korde, Alain C. Diebold</i> , SUNY Polytechnic Institute
2:20pm	BI+AS+IPF+MN-MoA4 Vibrational Sum-frequency Scattering Spectroscopy for the Characterization of Protein Fiber Structures and their Surface Interactions in Biological Environments, <i>Patrik K. Johansson, D.G. Castner</i> , University of Washington	EL+EM-MoA4 Anomaly in the Optical Constants of Ni near the Curie Temperature, <i>Farzin Abadizaman, S. Zollner</i> , New Mexico State University
2:40pm	BI+AS+IPF+MN-MoA5 How Proteins Grow Calcium Carbonates – The Mechanism of Vaterite Bioprecipitation Studied at the Molecular Level by Sum Frequency Generation Spectroscopy, <i>H. Lu</i> , Max Planck Institute for Polymer Research, Germany; <i>S. Roeters</i> , Aarhus University, Denmark; <i>H. Lutz, M. Hood, A. Schäfer</i> , Max Planck Institute for Polymer Research, Germany; <i>R. Muñoz-Espi</i> , Universidad de Valencia, Spain; <i>M. Bonn</i> , Max Planck Institute for Polymer Research, Germany; <i>Tobias Weidner</i> , Aarhus University, Denmark	EL+EM-MoA5 Phonon Confinement and Excitonic Absorption in the Optical Properties of ZnO Films, <i>Nuwanjula Samarasinha, S. Zollner</i> , New Mexico State University; <i>D. Pal, A. Mathur, A. Singh, R. Singh, S. Chattopadhyay</i> , Indian Institute of Technology Indore, India
3:00pm	BI+AS+IPF+MN-MoA6 ToF-SIMS Imaging of Chemical Modifications in Topographically Challenging Materials, <i>Michael Taylor, D.J. Graham, L.J. Gamble</i> , University of Washington	EL+EM-MoA6 High Aspect Ratio Etch Tilt Detection with Full 4x4 Mueller Matrix Spectroscopic Ellipsometry and Its Application to 3DNAND Channel Hole Etch Process and Chamber Monitoring, <i>Peilin Ong</i> , Micron Semiconductor Asia Pte. Ltd., Singapore; <i>S. Ng</i> , Nanometrics Incorporated; <i>G.B. Chu</i> , Micron Semiconductor Asia Pte. Ltd., Singapore; <i>P. Murphy</i> , Nanometrics Incorporated; <i>L.C. Liong, W. Fu</i> , Micron Semiconductor Asia Pte. Ltd., Singapore; <i>Y. Wen</i> , Nanometrics Incorporated; <i>L.W. Ho</i> , Micron Semiconductor Asia Pte. Ltd., Singapore
3:20pm	BREAK	BREAK
3:40pm	BI+AS+IPF+MN-MoA8 Imaging Plant and Plant Growth-Promoting Bacteria Interactions Using Time-of-Flight Secondary Ion Mass Spectrometry, <i>Xiao-Ying Yu, R. Komorek, Z.H. Zhu, C.J. Jansson</i> , Pacific Northwest National Laboratory	EL+EM-MoA8 Ultra-High-Speed Spectroscopic Ellipsometry and its Applications, <i>Gai Chin</i> , ULVAC Inc., Japan
4:00pm	BI+AS+IPF+MN-MoA9 Imaging of Cells and Tissues with Helium Ion Microscopy, <i>J.A. Notte, D. Wei, Chuong Huynh</i> , Carl Zeiss Microscopy, LLC	EL+EM-MoA9 Use of Ellipsometry to Monitor Implant Damage in Methane Plasma Implant, <i>Nicholas Bateman</i> , Varian Semiconductor Equipment, Applied Materials
4:20pm	BI+AS+IPF+MN-MoA10 Quantitative Analysis of Electrolytes in Microliter-size Blood Drops Coagulated via HemaDrop™ using Ion Beam Analysis and SIMNRA, <i>Harshini Thinakaran, S.R. Narayan, J.M. Day, N. Herbots, F.J. Ark, B. Wilkens, M. Mangus, R.J. Culbertson</i> , Arizona State University	EL+EM-MoA10 Study of the Thickness-dependent Optical Constants of Metallic Thin Films based on Ellipsometry and Reflectivity, <i>Jiamin Liu, H. Jiang, S.Y. Liu</i> , Huazhong University of Science and Technology, China
4:40pm		

Monday Afternoon, October 22, 2018

Electronic Materials and Photonics Division Room 101A - Session EM+AM+NS+PS-MoA Atomic Layer Processing: Selective-Area Patterning (Assembly/Deposition/Etching) Moderators: Michael Filler, Georgia Institute of Technology, Jessica Hilton, RHK Technology		Magnetic Interfaces and Nanostructures Division Room 201A - Session MI+2D+EM+NS-MoA IoT Session: Symposium on new Magnetic Materials, Devices and Concepts for the Information Society Moderator: Hendrik Ohldag, SLAC National Accelerator Laboratory
1:20pm	EM+AM+NS+PS-MoA1 Area-Selective Deposition of Crystalline Perovskites, <i>E. Lin, Brennan Coffey, Z. Zhang, P.Y. Chen, B. Edmondson, J.G. Ekerdt</i> , University of Texas at Austin	INVITED: MI+2D+EM+NS-MoA1 "ZOOMING in on Data Storage and the Superb HDD", <i>Roger Wood</i> , Western Digital Invited talk continues.
1:40pm	EM+AM+NS+PS-MoA2 A Dry NF_3/NH_3 Plasma Clean for Removing Si Native Oxide and Leaving a Smooth Si Surface, <i>Christopher Ahles, J.Y. Choi</i> , University of California, San Diego; <i>A.C. Kummel</i> , University of California at San Diego	
2:00pm	INVITED: EM+AM+NS+PS-MoA3 Probing Strategies for Selective Deposition that Exploit Competitive Interactions, <i>James Engstrom</i> , Cornell University	INVITED: MI+2D+EM+NS-MoA3 Physics and Applications of Spin-transfer Torques, <i>Andrew Kent</i> , New York University
2:20pm	Invited talk continues.	Invited talk continues.
2:40pm	EM+AM+NS+PS-MoA5 The Interconnect Resistivity Bottleneck, <i>Daniel Gall, T. Zhou, E. Milosevic</i> , Rensselaer Polytechnic Institute; <i>P.Y. Zheng</i> , Micron Technology	INVITED: MI+2D+EM+NS-MoA5 Hybrid Magnetic Heterostructures, <i>Ivan K. Schuller, A. Basaran</i> , University of California, San Diego; <i>J. de la Venta</i> , Colorado State University; <i>J.G. Ramirez</i> , Universidad de los Andes, Colombia; <i>T. Saerbeck</i> , Institute Laue-Langevin, France; <i>I. Valmianski</i> , University of California, San Diego; <i>X. Battle</i> , University of Barcelona, Spain
3:00pm	EM+AM+NS+PS-MoA6 Sub 0.3 micrometer Copper Patterns Etched with a Plasma-Based Process and Pattern Dependent Electromigration Failure Mechanism, <i>Yue Kuo</i> , Texas A&M University	Invited talk continues.
3:20pm	BREAK	BREAK
3:40pm	INVITED: EM+AM+NS+PS-MoA8 The Effect of Metal Diffusion on Contacts to Semiconducting Chalcogenides: Examples for 2D and 3D Materials, <i>Suzanne E. Mohney, K.A. Cooley, M. Abraham, A.C. Domask, H. Simchi, L. Kerstetter, C. Lawrence, T.N. Walter</i> , The Pennsylvania State University	INVITED: MI+2D+EM+NS-MoA8 Organismic Materials and Intelligence, <i>Shriram Ramanathan</i> , Purdue University
4:00pm	Invited talk continues.	Invited talk continues.
4:20pm	EM+AM+NS+PS-MoA10 TiN_x and TaN_x Films via Low-T Thermal ALD using Anhydrous N_2H_4 , <i>Steven Wolf, M. Breeden, M. Kavrik</i> , University of California at San Diego; <i>D. Alvarez, J. Spiegelman</i> , RASIRC; <i>M. Naik</i> , Applied Materials; <i>A.C. Kummel</i> , University of California at San Diego	
4:40pm		

Monday Afternoon, October 22, 2018

In-situ Microscopy, Spectroscopy, and Microfluidics Focus Topic Room 202B - Session MM+AS+NS+PC+SS-MoA X-ray and Electron Spectromicroscopy in Liquids and Gases & Flash Networking Session Moderator: Piran Kidambi, Vanderbilt University		Materials and Processes for Quantum Computing Focus Topic Room 203A - Session MP+AM+EM+NS-MoA Systems and Devices for Quantum Computing II Moderator: Josh Mutus, Google Inc
1:20pm	INVITED: MM+AS+NS+PC+SS-MoA1 Bridging the Material and Pressure Gap in Synchrotron based Photoelectron in Situ/Operando Studies, <i>Luca Gregoratti, M. Amati, P. Zeller, Elettra-Sincrotrone Trieste, Italy</i>	INVITED: MP+AM+EM+NS-MoA1 Quantum Engineering of Superconducting Qubits, <i>William Oliver, MIT Lincoln Laboratory</i>
1:40pm	Invited talk continues.	Invited talk continues.
2:00pm	MM+AS+NS+PC+SS-MoA3 Transition Metal Complexes in Aqueous Solutions Characterized by Liquid Jet Ambient Pressure X – ray Photoelectron Spectroscopy, <i>Jared Bruce, J.C. Hemminger, University of California, Irvine</i>	INVITED: MP+AM+EM+NS-MoA3 The Quantum Socket: A Wiring Method for Superconducting Quantum Computing, <i>Matteo Mariantoni, University of Waterloo, Canada</i>
2:20pm	MM+AS+NS+PC+SS-MoA4 Interfacial Electrochemistry in Liquids Probed with Photoemission Electron Microscopy, <i>S. Nemsak, Forschungszentrum Juelich GmbH, Germany; E. Strelcov, NIST Center for Nanoscale Science and Technology; Tomas Duchon, Forschungszentrum Juelich GmbH, Germany; H.X. Guo, National Institute of Standards and Technology; J. Hackl, Forschungszentrum Juelich GmbH, Germany; A. Yualev, NIST Center for Nanoscale Science and Technology; I. Vlassiouk, Oak Ridge National Laboratory; D.N. Mueller, C.M. Schneider, Forschungszentrum Juelich GmbH, Germany; A. Kolmakov, NIST Center for Nanoscale Science and Technology</i>	Invited talk continues.
2:40pm	MM FLASH NETWORKING SESSION	MP+AM+EM+NS-MoA5 Pogo Pin Packaging for High Coherence Qubits, <i>Nicholas Bronn, V.P. Adiga, S.B. Olivadese, O. Jinka, IBM, T.J. Watson Research Center; X. Wu, National Institute of Standards and Technology; J.M. Chow, IBM, T.J. Watson Research Center; D.P. Pappas, National Institute of Standards and Technology</i>
3:00pm		MP+AM+EM+NS-MoA6 50 Ohm Superconducting Kinetic Inductance Traveling-Wave Amplifier with flexible pump frequency for Four Wave Mixing and Three Wave Mixing, <i>Xian Wu, M. Bal, J. Long, H.S. Ku, R. Lake, D.P. Pappas, National Institute of Standards and Technology</i>
3:20pm	BREAK	BREAK
3:40pm	INVITED: MM+AS+NS+PC+SS-MoA8 Practical Liquid Cell Microscopy - Opportunities and Challenges, <i>Daan Hein Alsem, K. Karki, Hummingbird Scientific; J.T. Mefford, W.C. Chueh, Stanford University; N.J. Salmon, Hummingbird Scientific</i>	INVITED: MP+AM+EM+NS-MoA8 Near Term Development of Short Depth Quantum Processors, <i>Jerry Chow, IBM Research Division, T.J. Watson Research Center</i>
4:00pm	Invited talk continues.	Invited talk continues.
4:20pm	MM+AS+NS+PC+SS-MoA10 Observation of Electric Double Layer under Graphene by Scanning Electron Microscopy, <i>Hongxuan Guo, A. Yualev, E. Strelcov, National Institute of Standards and Technology (NIST)/ University of Maryland, College Park; A. Tselev, CICECO and Department of Physics, University of Aveiro, Portugal; A. Kolmakov, National Institute of Standards and Technology</i>	MP+AM+EM+NS-MoA10 Frequency Crowding in Lattices of Transmon Qubits, <i>Sami Rosenblatt, J.B. Hertzberg, J. Chavez-Garcia, N.T. Bronn, H. Paik, M.O. Sandberg, E. Magesan, J. Smolin, J.B. Yau, V.P. Adiga, M. Brink, J.M. Chow, IBM, T.J. Watson Research Center</i>
4:40pm		

Monday Afternoon, October 22, 2018

Nanometer-scale Science and Technology Division Room 102B - Session NS+2D+AS+PC-MoA SPM - New Imaging and Spectroscopy Methodologies Moderators: Aubrey Hanbicki, Naval Research Laboratory, Sidney Cohen, Weizmann Institute of Science, Israel		Plasma Science and Technology Division Room 104A - Session PS+PB-MoA Plasma and Polymers: 'The Legacy of Riccardo d'Agostino and Beyond' Moderators: Ankur Agarwal, KLA-Tencor, Mohan Sankaran, Case Western Reserve University
1:20pm	INVITED: NS+2D+AS+PC-MoA1 A Connection Between Stability of STM Control System and Local Barrier Height: Implications on Imaging and Lithography, <i>S.O. Reza Moheimani</i> , University of Texas at Dallas	PS+PB-MoA1 Foreword/introduction to the session: "Reflections on the Legacy of Riccardo d'Agostino", <i>P. Favia</i> , University of Bari, Italy
1:40pm	Invited talk continues.	PS+PB-MoA2 Atmospheric Pressure PE-CVD of Drug-containing Nanometric Capsules, <i>Pietro Favia, C. Lo Porto, A. Treglia</i> , University of Bari, Italy; <i>F. Palumbo</i> , CNR Institute of Nanotechnology NANOTEC, Italy
2:00pm	NS+2D+AS+PC-MoA3 Distinctive Microstructures in a Complex Polymer Evolve with Time and Composition, <i>x. Yu</i> , Worcester Polytechnic Institute; <i>S. Granados-Focil</i> , Clark University; <i>M. Tao, Nancy Burnham</i> , Worcester Polytechnic Institute	PS+PB-MoA3 Ultrathin Metal-Organic Covalent Networks by initiated Plasma Enhanced Chemical Vapor Deposition (iPECVD) for Gas Separation Membranes, <i>Karen Gleason, M. Wang</i> , MIT; <i>N.D. Boscher</i> , Luxembourg Institute of Science and Technology (LIST), Luxembourg; <i>M.C. Creatore, A. Perrotta</i> , Eindhoven University of Technology, The Netherlands; <i>K. Heinze</i> , Johannes Gutenberg-Universität, Mainz, Germany
2:20pm	NS+2D+AS+PC-MoA4 Offering new Characterization Capabilities at the XTIP beamline by Combining Scanning Tunneling Microscopy with Synchrotron Radiation, <i>Volker Rose, H. Chang, M. Fisher, S.W. Hla, N. Shirato</i> , Argonne National Laboratory	PS+PB-MoA4 Influence of Energetic Conditions on the Plasma Polymerization of Cyclopropylamine in Capacitively Coupled Discharges, <i>Lenka Zajickova, M. Michlcek</i> , Masaryk University, Czech Republic; <i>S. Hamaguchi</i> , Osaka University, Japan
2:40pm	INVITED: NS+2D+AS+PC-MoA5 Scanning Probe Microscopy Based Spectroscopy Measurement for Nanoscale Chemical Identification, <i>Chanmin Su</i> , Bruker-Nano, Inc.	PS+PB-MoA5 Electrochromic Investigation of PEDOT Film Deposited by Plasma Radicals Assisted Polymerization <i>via</i> CVD, <i>Bianca Rita Pistillo, G. Lamblin, J. Polesel-Maris</i> , Luxembourg Institute of Science and Technology (LIST), Luxembourg; <i>K. Mengueti</i> , Luxembourg Institute of Science and Technology (LIST); <i>D. Arl, D. Lenoble</i> , Luxembourg Institute of Science and Technology (LIST), Luxembourg
3:00pm	Invited talk continues.	PS+PB-MoA6 Initial ZnO Crystallite Formation by Plasma Enhanced ALD, <i>Alberto Perrotta, J. Pilz, A.M. Coclitte</i> , Graz University of Technology, Austria
3:20pm	BREAK	BREAK
3:40pm	NS+2D+AS+PC-MoA8 Quantifying Tip-Sample Interactions in Vacuum Using Cantilever-based Sensors: An Analysis, <i>O.E. Dagdeviren, C. Zhou, E.I. Altman, Udo D. Schwarz</i> , Yale University	PS+PB-MoA8 On Fluorocarbons and Fish: Creating a Global Impact on Generations of Plasma Chemists, <i>Ellen Fisher</i> , Colorado State University
4:00pm	NS+2D+AS+PC-MoA9 AFM + Nanoscale Vis-IR Spectroscopy via Photo-induced Force Microscopy, <i>Derek Nowak, T. Albrecht, S. Park</i> , Molecular Vista	PS+PB-MoA9 DIRECT and Remote Surface Functionalization using Atmospheric Pressure Dielectric Barrier Discharges, <i>Francesco Fracassi</i> , University of Bari, Institute of Nanotechnology (NANOTEC), NRC, Italy, Italy; <i>F. Fanelli</i> , Institute of Nanotechnology (NANOTEC), NRC, Italy, Italy; <i>V. Armenise, A. Uricchio, R. d'Agostino</i> , University of Bari, Italy, Italy
4:20pm		PS+PB-MoA10 Quest for Durable Low-index Optical Coatings: From Plasma Polymerized Fluorocarbons to Hybrid Organic-inorganic and Nanostructured Films, <i>Martini, Jolanta Klemberg-Sapieha, O. Zabeida</i> , Ecole Polytechnique de Montreal, Canada
4:40pm		

Monday Afternoon, October 22, 2018

Advanced Surface Engineering Division Room 202C - Session SE-MoA New Challenges and Opportunities in Surface Engineering Moderators: Robert Franz, Montanuniversität Leoben, Austria, Jianliang Lin, Southwest Research Institute		Surface Science Division Room 203C - Session SS+HC-MoA Theory and Modeling of Surfaces and Reactions Moderators: Liney Arnadottir, Oregon State University, Petra Reinke, University of Virginia
1:20pm	INVITED: SE-MoA1 From Passive to Active Optical Coatings - Challenges and Opportunities for Pulsed Plasma Deposition Processes, <i>Ludvik Martinu</i> , Ecole Polytechnique de Montreal, Canada	INVITED: SS+HC-MoA1 Elucidating the Chemical Nature of Single-Site Catalysts from First Principles, <i>A.J.R. Hensley</i> , Washington State University; <i>A.J. Therrien</i> , Tufts University; <i>R. Zhang</i> , Washington State University; <i>A.C. Schilling</i> , Tufts University; <i>K. Groden</i> , Washington State University; <i>E.C.H. Sykes</i> , Tufts University; <i>Jean-Sabin McEwen</i> , Washington State University
1:40pm	Invited talk continues.	Invited talk continues.
2:00pm	SE-MoA3 Anomalous Orientation-dependent Slip during Uniaxial Compression of TaC Crystals, <i>M. Chen</i> , ETH Zurich, Switzerland; <i>D.G. Sangiovanni</i> , Ruhr-University Bochum, Germany and Linköping University, Sweden; <i>A. Aleman, H. Zaid</i> , University of California at Los Angeles; <i>J.M. Wheeler</i> , ETH Zurich, Switzerland; <i>G. Po, Suneel Kodambaka</i> , University of California at Los Angeles	SS+HC-MoA3 Unravelling the Complex Features in STM Images of O/Ag(110) System, <i>Takat B. Rawal</i> , University of Central Florida; <i>M. Smerieri</i> , IMEM-CNR, UOS Genova, Italy; <i>J. Pal</i> , University of Genova, Italy; <i>S. Hong</i> , Brewton-Parker College; <i>M. Alatalo</i> , University of Oulu, Finland; <i>L. Savio, L. Vattuone</i> , University of Genova, Italy; <i>T.S. Rahman</i> , University of Central Florida; <i>M. Rocca</i> , University of Genova, Italy
2:20pm	SE-MoA4 Selectable Phase Formation in Al-based Transition Metal Nitride Films by Controlling Al ⁺ Subplantation depth during HIPIMS Deposition, <i>Grzegorz Greczynski</i> , Linköping University, Sweden; <i>S. Mraz, M. Hans</i> , RWTH Aachen University; <i>J. Lu, L. Hultman</i> , Linköping University, Sweden; <i>J.M. Schneider</i> , RWTH Aachen University, Germany	SS+HC-MoA4 First Principles Investigations on CO ₂ Adsorption and Dissociation on Cu _{cluster} / Cu(111) Surfaces: Influence of Co-adsorbed CO Molecule, <i>Allan Abraham Padama</i> , University of the Philippines Los Baños, Philippines; <i>H. Nakanishi, H. Kasai</i> , National Institute of Technology, Akashi College, Japan; <i>J.D. Ocon</i> , University of the Philippines Diliman, Philippines
2:40pm	INVITED: SE-MoA5 Metallic-Glass Nanotube Arrays: A Novel Device for Various Applications, <i>Jinn P. Chu, J.K. Chen, C.C. Yu</i> , National Taiwan University of Science and Technology, Taiwan, Republic of China	SS+HC-MoA5 Step-Spacing Distributions Revisited: New Motivations from Curved Crystals and Other Systems, <i>Theodore L. Einstein</i> , University of Maryland, College Park
3:00pm	Invited talk continues.	SS+HC-MoA6 Small Molecule Activation Using Computational Catalysis and Machine Learning, <i>Yousung Jung</i> , Korea Advanced Institute of Science and Technology (KAIST), Republic of Korea
3:20pm	BREAK	BREAK
3:40pm	SE-MoA8 Biocompatibility and Antibacterial Behaviors of TaON(porous)/TaN/TaN-Ag/Ta Multi-layered Thin Films, <i>Joe. H. Hsieh</i> , Ming Chi University of Technology, Taiwan, Republic of China; <i>C. Li</i> , National Yang Ming University, Taiwan, Republic of China; <i>C.C. Hsu</i> , Ming Chi University of Technology, Taiwan, Republic of China	SS+HC-MoA8 Elucidating Mechanisms of Alkanol Catalysis on SrTiO ₃ Perovskite Surfaces using Density Functional Theory, <i>Robert Chapeski, S. Roy</i> , University of Tennessee Knoxville
4:00pm	SE-MoA9 Electrochemically Deposited Coating with Antibacterial Properties against the Spread of Health Care-associated Infections, <i>Nicole Ciacotich</i> , Technical University of Denmark, Denmark; <i>J.B. Rasmussen</i> , Elplatek A/S, Denmark; <i>K.N. Kragh</i> , University of Copenhagen, Denmark; <i>P. Møller, L. Gram</i> , Technical University of Denmark, Denmark	
4:20pm	SE-MoA10 Tunable Self-Healing Thermal Barrier Coatings, <i>S.S. Joshi, J.J. Gu, Y.-S. Ho, B.W. Wei, T.Y. Hung, Y.Y. Liu, N.B. Dahotre, S.M. Aouadi</i> , University of North Texas	
4:40pm		

Monday Afternoon, October 22, 2018

Thin Films Division Room 102A - Session TF+EM+MI+PS-MoA Thin Films for Advanced Memory Applications and Magnetics Moderator: Robert Grubbs, Micron Technology		Thin Films Division Room 104B - Session TF-MoA IoT Session: Thin Films for Photovoltaics Moderators: Matthew Richard Linford, Brigham Young Univ., Mark Losego, Georgia Institute of Technology
1:20pm		INVITED: TF-MoA1 Atomic Layer Deposition for Organic and Perovskite Solar Cells, <i>Thomas Riedl</i> , University of Wuppertal, Germany
1:40pm	TF+EM+MI+PS-MoA2 ---Multiferroic Integration of Undoped Ferroelectric HfO ₂ and Ferrimagnetic CoFe ₂ O ₄ Thin films by Radical-Enhanced Atomic Layer Deposition, <i>J. Chang, Adrian Acosta, J.P. Chang</i> , University of California at Los Angeles	Invited talk continues.
2:00pm	TF+EM+MI+PS-MoA3 Growth and Characterization of BeO Thin Films Grown by Atomic Layer Deposition using H ₂ O and O ₃ as Oxygen Sources, <i>Lee Woo Chul, C. Cheol Jin</i> , Center for Electronic Materials, Korea Institute of Science and Technology, Korea; <i>K. Sangtae</i> , Center for Electronic Materials, Korea Institute of Science and Technology, Korea; <i>L. Eric S., Y. Jung Hwan</i> , Center for Multidimensional Carbon Materials (CMCM), Institute for Basic Science (IBS), South Korea; <i>H. Cheol Seong</i> , Department of Materials Science and Engineering, and Inter-University Semiconductor Research Center, College of Engineering, Seoul National University, South Korea; <i>B. Christopher W.</i> , Center for Multidimensional Carbon Materials (CMCM), Institute for Basic Science (IBS), South Korea; <i>K. Seong Keun</i> , Center for Electronic Materials, Korea Institute of Science and Technology, Korea	TF-MoA3 Insights into ALD Al ₂ O ₃ Growth on Hybrid Organic-Inorganic Perovskite, <i>Dibyashree Koushik¹, L. Hazendonk</i> , Eindhoven University of Technology, The Netherlands; <i>V. Zardetto</i> , TNO-Solliance, The Netherlands; <i>W.M.M. Kessels, M.C. Creatore</i> , Eindhoven University of Technology, The Netherlands
2:20pm	TF+EM+MI+PS-MoA4 Atomic Layer Deposition of Magnetic Films and Patterned Features with Tunable Magnetic Properties, <i>Z. Zhang, John Ekerdt</i> , University of Texas at Austin	TF-MoA4 Single Junction GaAs Thin Film Solar Cells on Flexible Metal Tapes for Low Cost Photovoltaics, <i>Devendra Khatiwada¹, M. Rathi, P. Dutta, S. Sun, Y. Yao, Y. Gao, Y. Li, S. Pouladi, J.-H. Ryou, V. Selvamanickam</i> , University of Houston
2:40pm	INVITED: TF+EM+MI+PS-MoA5 Tuning of the Magnetic and Electronic Properties of Epitaxial Heusler Compound Heterostructures, <i>Christopher Palmstrøm</i> , University of California, Santa Barbara	TF-MoA5 New Insights into the Microstructure and Composition of New Generation CdSeTe/CdTe/MZO Photovoltaic Devices, <i>T.A.M. Fiducia, A. Abbas</i> , Loughborough University, UK; <i>K. Li, C.R.M. Grovenor</i> , University of Oxford, UK; <i>A. Munshi, K.L. Barth, W.S. Sampath</i> , Colorado State University; <i>John Walls</i> , Loughborough University, UK
3:00pm	Invited talk continues.	TF-MoA6 Schottky Barrier Metal-Insulator-Silicon Photovoltaics: Influence of Fixed Charge and Dipoles in Atomic Layer Deposited Alumina, <i>Nicholas Strandwitz</i> , Lehigh University
3:20pm	BREAK	BREAK
3:40pm	TF+EM+MI+PS-MoA8 Stabilization of Ferroelectric Phase of Hf _{0.5} Zr _{0.5} O ₂ on NbN at 4 K, <i>Michael David Henry, S. Smith, R. Lewis</i> , Sandia National Laboratories; <i>J. Ihlefeld</i> , University of Virginia	TF-MoA8 Sulfur Vacancies as the Origin of <i>n</i> -type Doping in Pyrite FeS ₂ Single Crystals, <i>B. Voigt, W. Moore, J. Walter, D. Ray, M. Manno</i> , University of Minnesota; <i>J.D. Jeremiason</i> , Gustavus Adolphus College; <i>L. Gagliardi, Eray Aydil, C. Leighton</i> , University of Minnesota
4:00pm	TF+EM+MI+PS-MoA9 Atomic Layer Deposition of Co/Pt Multilayer films for Perpendicular Magnetic Anisotropy, <i>Devika Choudhury, A.U. Mane, C.M. Phatak, A.K. Petford Long, J.W. Elam</i> , Argonne National Laboratory	TF-MoA9 Strong Effect of Reaction Temperature on the Nucleation of Atomic Layer Deposition of Al ₂ O ₃ on Methylamine Lead Perovskite, <i>Xiaozhou Yu, H.M. Yan, Q. Peng</i> , University of Alabama
4:20pm		TF-MoA10 Synthesis of Gas Barrier Coatings for Hybrid Halide Perovskites by Atomic Layer Deposition, <i>X.Z. Yu, H.M. Yan, Qing Peng</i> , University of Alabama
4:40pm		

¹ TFD James Harper Award Finalist

Monday Afternoon, October 22, 2018

Vacuum Technology Division

Room 203B - Session VT-MoA

Pumping and Outgassing

Moderators: James Fedchak, NIST,
Giulia Lanza, SLAC National Accelerator Laboratory

1:20pm	INVITED: VT-MoA1 Gas Adsorption and Desorption Properties of 3D Printed Objects, <i>Matt Hartings</i> , American University; <i>J. Scherschligt, J.A. Fedchak, Z. Ahmed</i> , National Institute of Standards and Technology	
1:40pm	Invited talk continues.	
2:00pm	VT-MoA3 Outgassing, Desorption, and Gas Uptake of 3D-Printed Materials, <i>James Fedchak</i> , NIST; <i>J. Scherschligt, Z. Ahmed</i> , National Institute of Standards and Technology; <i>M. Hartings</i> , American University	
2:20pm	VT-MoA4 Performance Prediction Approaches for Liquid Ring Vacuum Pumps with Mercury as Working Fluid, <i>Santiago Ochoa Guaman, T. Giegerich</i> , Karlsruhe Institute of Technology, Germany; <i>C. Dahlke</i> , HERMETIC-Pumpen GmbH, Germany; <i>C. Day</i> , Karlsruhe Institut of Technology (KIT), Germany	
2:40pm	VT-MoA5 Particle Emission from Ion Pumps: Optimized Shielding without Severe Conductance Limitation, <i>Mauro Audi, C. Paolini</i> , Agilent Technologies, Italy; <i>P. Manassero</i> , Agilent Technologies	
3:00pm	VT-MoA6 Extension of the Range of Primary Vacuum Calibration Methods with the Use of Non-evaporable Getters, <i>Sefer Avdaj</i> , University of Prishtina, Albania	
3:20pm	BREAK	
3:40pm	INVITED: VT-MoA8 VTD Early Career Award Invited Talk: The Development of the Spacecraft Atmosphere Monitor, <i>Steven Schowalter¹</i> , Jet Propulsion Laboratory	
4:00pm	Invited talk continues.	
4:20pm	VT-MoA10 Surface Modification to Reduce Species Retention and Outgassing Rate from Vacuum Components, <i>Quirinius Grindstaff, J. Peak, C. Miracle</i> , CNS, LLC	
4:40pm	4:45 PM VTD BUSINESS MEETING	

¹ VTD Early Career Award

Anticipated Schedule Tuesday, October 23, 2018

Anticipated Schedule Tuesday Morning, October 23

8:00 AM	_____
8:20 AM	_____
8:40 AM	_____
9:00 AM	_____
9:20 AM	_____
9:40 AM	_____
10:00 AM	_____
10:20 AM	_____
10:40 AM	_____
11:00 AM	_____
11:20 AM	_____
11:40 AM	_____
12:00 PM	_____

Anticipated Schedule Tuesday Lunch, October 23

When	_____
Where	_____
With	_____

Anticipated Schedule Tuesday Afternoon, October 23

1:00 PM	_____
1:20 PM	_____
1:40 PM	_____
2:00 PM	_____
2:20 PM	_____
2:40 PM	_____
3:00 PM	_____
3:20 PM	_____
3:40 PM	_____
4:00 PM	_____
4:20 PM	_____
4:40 PM	_____
5:00 PM	_____
5:20 PM	_____
5:40 PM	_____
6:00 PM	_____

Special Events Tuesday

Special Events Tuesday

7:30 AM Awards Committee Meeting and Lunch/Pacific-Hyatt Regency (by invitation)
8:00 AM Science Educators' Workshop/Seaview-Hyatt Regency (by invitation)
9:00 AM AVS Member Center: eSpectra: Surface Science/103C
10:00 AM AVS Member Center: Professional Development--Working with National Labs and Other User Facilities/103C
10:00 AM Session Coffee Break/Hall A
11:40 AM Federal Funding Town Hall/202C
12:20 PM Exhibit Hall Lunch/Hall A
12:30 PM AVS Member Center: Professional Development--Job Information Forum and Lunch/103C
12:30 PM Chapters, Divisions, and Groups Meeting and Lunch/Regency D-Hyatt Regency (by invitation)
12:30 PM MSTG Technical Group Executive Committee Meeting and Lunch/Tides Restaurant-Hyatt Regency (by invitation)
3:40 PM Biointerphases Reception/Shoreline A-Hyatt Regency (by invitation)
3:40 PM Session Refreshment Break/Hall A
4:00 PM AVS Member Center: Professional Development--SCCAVS/NCCAVS Members Hospitality Hour/103C (by invitation)
6:05 PM BID Business Meeting/101B
6:25 PM EMPD Business Meeting/101A
6:25 PM NSTD Business Meeting/102B
6:25 PM PSTD Business Meeting & 2018 Plasma Prize Award Announcement/104A
6:25 PM SSD Business Meeting/203C
6:25 PM TFD Business Meeting/102A
6:30 PM Tuesday Poster Session & Refreshments/Hall B
6:45 PM AVS Member Center: Professional Development--EMPD Forum: "Careers at LAM Research"/103C
7:00 PM MEMS/NEMS Executive Committee Meeting and Dinner/Regency F-Hyatt Regency (by invitation)
7:00 PM NSTD Executive Committee Meeting and Dinner/Seaview A-Hyatt Regency (by invitation)
7:00 PM SSD Executive Committee Meeting and Dinner/Regency C-Hyatt Regency (by invitation)
7:30 PM ASSD Business Meeting/Regency DE-Hyatt Regency
7:30 PM PSTD Executive Committee Meeting and Dinner/Seaview C-Hyatt Regency (by invitation)
7:30 PM TFD Executive Committee Meeting and Dinner/Seaview B-Hyatt Regency (by invitation)
7:45 PM BID Executive Committee Meeting and Dinner/Pacific-Hyatt Regency (by invitation)
7:45 PM EMPD Executive Committee Meeting and Dinner/Regency B-Hyatt Regency (by invitation)
8:00 PM ASTM E-42 and Applied Surface Science Joint Workshop: "A Tribute to the Careers of Barbara Garrison and Nicholas Winograd"/Regency DE-Hyatt Regency
8:30 AM–5:00 PM Short Course Program/Various Rooms

Tuesday Morning, October 23, 2018

2D Materials Focus Topic Room 201B - Session 2D+EM+MI+NS-TuM Properties of 2D Materials including Electronic, Magnetic, Mechanical, Optical, and Thermal Properties Moderator: Johannes Jobst, Leiden University		Applied Surface Science Division Room 204 - Session AS+BI-TuM Applied Surface Science: From Electrochemistry to Cell Imaging, a Celebration of the Career of Nicholas Winograd Moderators: Arnaud Delcorte, Université Catholique de Louvain, Belgium, Michaelaen Pacholski, The Dow Chemical Company
8:00am	2D+EM+MI+NS-TuM1 Effect of Lattice Stacking Orientation and Local Thickness Variation on the Mechanical Behavior of Few Layer Graphene Oxide, <i>Teng Cui, S. Mukherjee, C.H. Cao, P.M. Sudeep, J. Tam</i> , University of Toronto, Canada; <i>P.M. Ajayan</i> , Rice University; <i>C.V. Singh, Y. Sun, T. Filleter</i> , University of Toronto, Canada	INVITED: AS+BI-TuM1 Surface Analysis and Beyond, Using Ion Beams and Lasers, <i>Nicholas Lockyer, J.C. Vickerman</i> , University of Manchester, UK Invited talk continues.
8:20am	2D+EM+MI+NS-TuM2 Out-of-Plane Mechanical Properties of 2D Hybrid Organic-Inorganic Perovskites by Nanoindentation, <i>Qing Tu, I. Spanopoulos, S. Hao, C. Wolverton, M. Kanatzidis, G. Shekharawat, V. Dravid</i> , Northwestern University	
8:40am	2D+EM+MI+NS-TuM3 Mechanical Properties of Many-layer CVD Graphene, <i>Kyle Larsen, S. Lehnhardt, J.T. Rowley, B. Anderson, R.R. Vanfleet, R.C. Davis</i> , Brigham Young University	AS+BI-TuM3 A High Resolution Tandem MS Imaging Method to Probe the Composition of Organelles in Single Cells, <i>Gregory L. Fisher</i> , Physical Electronics; <i>C.E. Chini</i> , University of Illinois at Urbana-Champaign; <i>B. Johnson, M.M. Tamkun</i> , Colorado State University; <i>M.L. Kraft</i> , University of Illinois at Urbana-Champaign
9:00am	2D+EM+MI+NS-TuM4 Electronic Structure and Magneto-transport Properties of Nanostructured Graphene on SiC(001), <i>Victor Aristov</i> , DESY Hamburg, Germany; <i>H.-C. Wu</i> , BIT, Beijing, China; <i>O.V. Molodtsova</i> , DESY Hamburg, Germany; <i>N. Chaika</i> , ISSP RAS, Russia	AS+BI-TuM4 SIMS and MALDI-MS. Competitive, Complimentary or Complementary Techniques for Bio-imaging?, <i>John Stephen Fletcher, I. Kaya</i> , University of Gothenburg, Sweden
9:20am	INVITED: 2D+EM+MI+NS-TuM5 Discovering and Visualizing Ferromagnetism in Intrinsic Two Dimensional Materials, <i>Jing Xia</i> , University of California Irvine	AS+BI-TuM5 High Spatial Resolution Metabolic Imaging using the 3D OrbiSIMS - Fundamentals of Metabolite Fragmentation and Biological Applications, <i>C. Newell, Y. Panina</i> , Francis Crick Institute, UK; <i>L. Matjacic, V. Cristaudo</i> , National Physical Laboratory, UK; <i>A.P. Bailey</i> , Francis Crick Institute, UK; <i>R. Havelund</i> , National Physical Laboratory, UK; <i>M. Yuneva, A.P. Gould</i> , Francis Crick Institute, UK; <i>Ian S. Gilmore</i> , National Physical Laboratory, UK
9:40am	Invited talk continues.	AS+BI-TuM6 Small Molecule Imaging in Single Frozen-Hydrated Cells using High-Resolution Gas Cluster Ion Beam Secondary Ion Mass Spectrometry (GCIB-SIMS), <i>Hua Tian, N. Winograd</i> , Pennsylvania State University
10:00am		
10:20am	BREAK - Complimentary Coffee in Exhibit Hall – Technology Spotlight Sessions in Booth #168, Exhibit Hall	
10:40am		
11:00am	2D+EM+MI+NS-TuM10 Onset of Buckling Folding and Slipping Instabilities in 2D Materials under Compressive Strain, <i>Jaehyung Yu, E. Ertekin, A.M. van der Zande</i> , University of Illinois at Urbana-Champaign	INVITED: AS+BI-TuM10 Pushing the Limits of Measurement Science with SIMS, <i>Christopher Szakal, D.S. Simons, J.D. Fassett, T.P. Forbes</i> , National Institute of Standards and Technology (NIST)
11:20am	2D+EM+MI+NS-TuM11 Title: Spatially-Resolved Contact-Free Electrical Characterization of Transition Metal Dichalcogenide Films Grown by Chemical Vapor Deposition., <i>Miguel Isarraraz, L. Bartels</i> , University of California, Riverside	Invited talk continues.
11:40am	INVITED: 2D+EM+MI+NS-TuM12 Electronic, Thermal, and Unconventional Applications of 2D Materials, <i>Eric Pop, E. Yalon, C. McClellan, K. Smith, C. English, M. Mleczko, M. Muñoz Rojo, N. Wang, S. Suryavanshi, I. Datye, C. Bailey, A. Gabourie, M. Chen, V. Chen, K. Schauble, R. Grady</i> , Stanford University	AS+BI-TuM12 Multiplexed Ion Beam Imaging: Cell and Tissue Imaging using Secondary Ion Mass Spectrometry for Pathology, <i>Jay Tarolli, R. Finck, M. Aksoy, D. Stumbo</i> , Ionpath, Inc.
12:00pm	Invited talk continues.	AS+BI-TuM13 Combined ToF-SIMS and AFM Protocol for Accurate 3D Chemical Analysis and Data Visualization, <i>Maiglid Andreina Moreno Villavicencio, N. Chevalier, J.-P. Barnes, I. Mouton</i> , Univ. Grenoble Alpes, CEA, LETI, France; <i>F. Bassani</i> , Univ. Grenoble Alpes, CNRS, LTM, France; <i>B. Gautier</i> , Université de Lyon, INSA Lyon, Institut des Nanotechnologies de Lyon, UMR CNRS 5270, F-69621 Villeurbanne cedex, France

Tuesday Morning, October 23, 2018

Fundamental Discoveries in Heterogeneous Catalysis Focus Topic Room 201A - Session HC+SS-TuM Nanochemistry in Heterogeneous Catalysis Moderator: Matthew Marcinkowski, Pacific Northwest National Laboratory		Industrial Physics Forum Room 101B - Session IPF+AS+BI+MN-TuM Advanced Imaging and Structure Determination of Biomaterials Moderators: David G. Castner, University of Washington, Michael Grunze, Max Planck Institute for Medical Research
8:00am HC+SS-TuM1 Probing Oxide Supported Single Rh Atoms as Model Catalysts for CO Oxidation, <i>Alex C. Schilling, E.C.H. Sykes</i> , Tufts University		INVITED: IPF+AS+BI+MN-TuM1 Chemical Imaging as a Tool to asses Molecular and Morphologic Content in Natural Tissues and Fabricated Models, <i>Rohit Bhargava, T. Comi, M. Gryka</i> , University of Illinois at Urbana-Champaign Invited talk continues.
8:20am HC+SS-TuM2 Methanol Partial Oxidation Mechanisms on a Single-site Catalyst Pt _x ZnO ₁₀ (10-10): A First-principles Study, <i>Tao Jiang</i> , University of Central Florida; <i>T.B. Rawal</i> , Oak Ridge National Laboratory; <i>D. Le, T.S. Rahman</i> , University of Central Florida		
8:40am HC+SS-TuM3 Imaging the Ordering of Weakly Adsorbed CO ₂ Molecules on Rutile Titania using Ambient Pressure Microscopy and Spectroscopy, <i>Rebecca Hamlyn¹</i> , Brookhaven National Lab; <i>J.A. Rodriguez, S. Senanayake, M. Mahapatra, F. Xu, D. Grinter, S. Luo, P. Liu, R. Palomino, I. Waluyo, S. Kattel, D.J. Staciola</i> , Brookhaven National Laboratory		INVITED: IPF+AS+BI+MN-TuM3 Fluorescence Dynamics and Nonlinear Optical Imaging Methods for Biomedical Applications, <i>Alba Alfonso Garcia, L. Marcu</i> , University of California at Davis Invited talk continues.
9:00am HC+SS-TuM4 Using Sn Atomic Layer Deposition to Tune the Coking Resistance of Size-selected Pt Model Catalysts, <i>Timothy Gorey¹, E. Baxter, A. Cass, S. Anderson</i> , University of Utah; <i>B. Zandkarimi, A. Alexandrova</i> , University of California at Los Angeles		
9:20am HC+SS-TuM5 Synergistic Effects of Pd and PdO Domains on Thin Film TbOx(111)/Pt(111), <i>Christopher Lee¹, J.F. Weaver</i> , University of Florida		INVITED: IPF+AS+BI+MN-TuM5 Single Molecule Imaging of Receptor Signalling, <i>Katharina Gaus</i> , University of New South Wales, Australia Invited talk continues.
9:40am HC+SS-TuM6 Copper Vapor Adsorption Calorimetry on HCa ₂ Nb ₃ O ₁₀ (001) Nanosheets: Energetics and Adsorbate Structure, <i>Wei Zhang¹, J.E. Eichler</i> , University of Washington; <i>R. Uppuluri, T.E. Mallouk</i> , The Pennsylvania State University; <i>C.T. Campbell</i> , University of Washington		
10:00am 10:20am BREAK - Complimentary Coffee in Exhibit Hall – Technology Spotlight Sessions in Booth #168, Exhibit Hall 10:40am		
11:00am HC+SS-TuM10 Adsorption and Adhesion of Ni on MgO(100) at 300 and 100 K by Calorimetry, <i>Zhongtian Mao, W. Zhao, Z. Almualem, C.T. Campbell</i> , University of Washington		INVITED: IPF+AS+BI+MN-TuM10 Developing a Google-earth View of Tumour Metabolism through Multiscale Molecular Imaging, <i>J. Bunch, Rory T. Steven</i> , National Physical Laboratory, UK Invited talk continues.
11:20am HC+SS-TuM11 The atomic-scale Structure of the Active CoO(OH)/Au Interface in Electrochemical Water Splitting, <i>J. Fester, Z. Sun, J. Rodriguez-Fernandez</i> , Aarhus University, Denmark; <i>R. Gutzler</i> , Max Planck Institute for Solid State Research, Germany; <i>D. Grumelli</i> , Universidad Nacional de La Plata, Argentina; <i>K. Kern</i> , Max Planck Institute for Solid State Research, Germany; <i>Jeppe Vang Lauritsen</i> , Aarhus University, Denmark		
11:40am INVITED: HC+SS-TuM12 <i>In situ</i> Microscopy of Oxide Growth and Transformation under Reaction Conditions, <i>Jan Ingo Flege</i> , University of Bremen, Germany		INVITED: IPF+AS+BI+MN-TuM12 X-ray Diffraction and Coherent Imaging with Nano-focused Radiation: A Multi-scale Approach from Biomolecular Assembly to Cell, Tissue and Organ, <i>Jan-David Nicolas, T. Salditt</i> , University of Göttingen, Germany Invited talk continues.
12:00pm Invited talk continues.		

¹ Heterogeneous Catalysis Graduate Student Presentation Award Finalist

Tuesday Morning, October 23, 2018

Materials and Processes for Quantum Computing Focus Topic Room 203A - Session MP+EM+NS-TuM High Coherence Qubits for Quantum Computing Moderator: Robert Ilic, National Institute of Standards and Technology		Manufacturing Science and Technology Group Room 202B - Session MS+MI+RM-TuM IoT Session: Challenges of Neuromorphic Computing and Memristor Manufacturing (8:00-10:00 am)/Federal Funding Opportunities (11:40 am-12:20 pm) Moderators: Christopher L. Hinkle, Univ. of Texas at Dallas, Sean Jones, National Science Foundation (NSF), Alain C. Diebold, SUNY Polytechnic Institute
8:00am	MP+EM+NS-TuM1 MBE Grown Nitride Superconductors for Quantum Circuits, <i>Christopher Richardson, A. Alexander, C. Weddle</i> , Laboratory for Physical Sciences	INVITED: MS+MI+RM-TuM1 ReRAM – Fabrication, Characterization, and Radiation Effects, <i>David Hughart, R.B. Jacobs-Gedrim, K.E. Knisely, N.J. Martinez, C.D. James, B.L. Draper, E.S. Bielejec, G. Vizkelethy, S. Agarwal</i> , Sandia National Laboratories; <i>H.J. Barnaby</i> , Arizona State University; <i>M.J. Marinella</i> , Sandia National Laboratories
8:20am	MP+EM+NS-TuM2 Towards Improved Coherence Times in Transmon Qubits, <i>Sam Stanwyck</i> , Rigetti Computing	Invited talk continues.
8:40am	INVITED: MP+EM+NS-TuM3 Design and Fabrication for High Coherence Quantum Circuits, <i>David Pappas, X. Wu, R. Lake, M. Bal, J. Long, C.R. McRae, H.S. Ku</i> , National Institute of Standards and Technology (NIST)	INVITED: MS+MI+RM-TuM3 Memristive Synapses – Tuning Memristors for Performance and CMOS Integration, <i>Nathaniel Cady</i> , SUNY Polytechnic Institute
9:00am	Invited talk continues.	Invited talk continues.
9:20am	MP+EM+NS-TuM5 Effect of Surface Treatment on Superconducting Qubit Coherence, <i>Bradley Christensen</i> , University of Wisconsin-Madison; <i>P. Kumar</i> , University of Wisconsin - Madison; <i>J.J. Nelson, Y. Liu, A. Ballard, B.L.T. Plourde</i> , Syracuse University; <i>R. McDermott</i> , University of Wisconsin - Madison	INVITED: MS+MI+RM-TuM5 Analog In-Memory Computing for Deep Neural Network Acceleration, <i>Hsinyu Tsai, S. Ambrogio, P. Narayanan, R.M. Shelby, G.W. Burr</i> , IBM Almaden Research Center
9:40am	MP+EM+NS-TuM6 Metrology of Dielectric Loss using Lumped-Element Microwave Resonators, <i>Corey Rae McRae, X. Wu, M. Bal, J. Long, H.S. Ku, D.P. Pappas, R. Lake</i> , National Institute of Standards and Technology	Invited talk continues.
10:00am		
10:20am	BREAK - Complimentary Coffee in Exhibit Hall – Technology Spotlight Sessions in Booth #168, Exhibit Hall	
10:40am		
11:00am	INVITED: MP+EM+NS-TuM10 Direct Observation of Atomic Structure of Ultra Thin AlO _x Barriers in Al/AlO _x /Al Josephson Junctions for Quantum Devices, <i>Eva Olsson</i> , Chalmers University of Technology, Gothenburg, Sweden	INVITED: MS+MI+RM-TuM10 Computation Immersed in Memory: Integrating 3D vertical RRAM in the N3XT Architecture, <i>Weier Wan, W. Hwang, H. Li, T.F. Wu, Y.H. Malviya</i> , Stanford University; <i>M.M.S. Aly</i> , Nanyang Technological University, Singapore; <i>S. Mitra, H.-S.P. Wong</i> , Stanford University
11:20am	Invited talk continues.	Invited talk continues.
11:40am	MP+EM+NS-TuM12 Metrology of Tunnel Junctions for Superconducting Qubits, <i>Russell Lake</i> , National Institute of Standards and Technology (NIST); <i>X. Wu, H.S. Ku, J. Long, M. Bal, C.R. McRae</i> , National Institute of Standards and Technology (NIST) and University of Colorado Boulder; <i>D.P. Pappas</i> , National Institute of Standards and Technology (NIST)	MS+MI+RM-TuM12 Materials for the Second Quantum Revolution, <i>Tomasz Durakiewicz</i> , Los Alamos National Laboratory
12:00pm		MS+MI+RM-TuM13 SynBio(medicine): The Intersection Biomaterials and Living Systems, <i>David Rampulla</i> , National Institute of Health

Tuesday Morning, October 23, 2018

Nanometer-scale Science and Technology Division Room 102B - Session NS+AN+EM+MN+MP+RM-TuM Nanophotonics, Plasmonics, and Metamaterials Moderators: Alokik Kanwal, NIST Center for Nanoscale Science and Technology, Nikolai Klimov, National Institute of Standards and Technology		Processing and Characterization of Air-Liquid, Solid-Liquid and Air-Solid Interfaces Focus Topic Room 202A - Session PC+AS+BI+NS+PB+SS-TuM Solid-Liquid and Gas-Liquid Interfacial Processes and Characterization Moderators: Stephen Nonnenmann, University of Massachusetts - Amherst, Juan Yao, Pacific Northwest National Laboratory
8:00am	INVITED: NS+AN+EM+MN+MP+RM-TuM1 Parametric Nonlinear Interactions in Nanofabricated Silicon-based Photonics, <i>Amy Foster</i> , Johns Hopkins University	INVITED: PC+AS+BI+NS+PB+SS-TuM1 Liquefied Gas Electrolytes for Electrochemical Energy Storage Devices, <i>Y. Shirley Meng</i> , University of California San Diego; <i>Y. Yang</i> , University of California at San Diego
8:20am	Invited talk continues.	Invited talk continues.
8:40am	INVITED: NS+AN+EM+MN+MP+RM-TuM3 Ultrafast Optical Pulse Shaping using Dielectric Metasurfaces, <i>Amit Agrawal</i> , <i>S. Divitt</i> , <i>W. Zhu</i> , <i>C. Zhang</i> , <i>H.J. Lezec</i> , NIST Center for Nanoscale Science and Technology	INVITED: PC+AS+BI+NS+PB+SS-TuM3 An <i>In situ</i> Molecular-scale View of Nucleation and Self-assembly at Solid-liquid Interfaces, <i>James De Yoreo</i> , Pacific Northwest National Laboratory
9:00am	Invited talk continues.	Invited talk continues.
9:20am	INVITED: NS+AN+EM+MN+MP+RM-TuM5 Single-Particle Nanophotonics and Materials Investigations with Optical Microresonator Spectrometers, <i>Erik Horak</i> , University of Wisconsin - Madison; <i>K.D. Heylman</i> , <i>K.A. Knapper</i> , <i>M.T. Rea</i> , <i>F. Pan</i> , <i>L.T. Hogan</i> , <i>R.H. Goldsmith</i> , University of Wisconsin-Madison	INVITED: PC+AS+BI+NS+PB+SS-TuM5 Non-linear Surface Spectroscopy at the Aerosol Particle/Gas Interface, <i>Geiger</i> , <i>Ariana Gray Be</i> , Northwestern University
9:40am	Invited talk continues.	Invited talk continues.
10:00am	BREAK - Complimentary Coffee in Exhibit Hall – Technology Spotlight Sessions in Booth #168, Exhibit Hall	
10:20am	BREAK - Complimentary Coffee in Exhibit Hall – Technology Spotlight Sessions in Booth #168, Exhibit Hall	
10:40am	BREAK - Complimentary Coffee in Exhibit Hall – Technology Spotlight Sessions in Booth #168, Exhibit Hall	
11:00am	INVITED: NS+AN+EM+MN+MP+RM-TuM10 Optomechanical Interactions for Metrology and Signal Processing, <i>Karen Grutter</i> , The Laboratory for Physical Sciences	PC+AS+BI+NS+PB+SS-TuM10 The Influence of Electrochemical Potential and Water Vapor on Ionic Liquid Binding Energy Shifts Examined by AP-XPS, <i>Meng Jia</i> , University of Delaware; <i>A. Broderick</i> , <i>J.T. Newberg</i> , University of Delaware
11:20am	Invited talk continues.	PC+AS+BI+NS+PB+SS-TuM11 Role of Air Gas at the Interface between Water and Graphite Surfaces, <i>Ing-Shouh Hwang</i> , Institute of Physics, Academia Sinica, Taiwan, Republic of China; <i>C.W. Yang</i> , <i>C.K. Fang</i> , Institute of Physics, Academia Sinica, Taiwan, Republic of China; <i>Y.H. Lu</i> , Institute of Physics, Academia Sinica, Taiwan, Republic of China; <i>H.C. Ko</i> , Institute of Physics, Academia Sinica, Taiwan, Republic of China
11:40am	INVITED: NS+AN+EM+MN+MP+RM-TuM12 Cold-atom based Sensors and Standards, <i>Stephen Eckel</i> , <i>D.S. Barker</i> , <i>J.A. Fedchak</i> , <i>N.N. Klimov</i> , <i>E. Norrgard</i> , <i>J. Scherschligt</i> , National Institute of Standards and Technology	INVITED: PC+AS+BI+NS+PB+SS-TuM12 Probing Cluster and Nanoparticle Growth Processes with X-Ray Spectroscopy and Mass Spectrometry, <i>Musahid Ahmed</i> , <i>O. Kostko</i> , Lawrence Berkeley National Laboratory
12:00pm	Invited talk continues.	Invited talk continues.

Tuesday Morning, October 23, 2018

Plasma Science and Technology Division Room 104A - Session PS+EM+SE-TuM Plasma Processing of Challenging Materials - I Moderators: Necmi Biyikli, University of Connecticut, Jun-Chieh Wang, Applied Materials		Plasma Science and Technology Division Room 104C - Session PS+PB-TuM Plasma Medicine Moderator: Deborah O'Connell, University of York, UK
8:00am	PS+EM+SE-TuM1 Development and Understanding of Isotropic Etching Process of Si Selectively to $\text{Si}_{0.7}\text{Ge}_{0.3}$, <i>Sana Rachidi, A. Campo, V. Loup, CEA-LETI, France; N. Posseme, CEA, LETI, France; J.M. Hartmann, S. Barnola, CEA-LETI, France</i>	PS+PB-TuM1 Lessons from Tesla for Plasma Medicine, <i>David Graves, University of California at Berkeley</i>
8:20am	PS+EM+SE-TuM2 III-V/Ge Heterostructure Etching for Through Cell Via Contact Multijunction Solar Cell, <i>Mathieu de Lafontaine, G. Gay, C. Petit-Etienne, E. Pargon, LTM, Univ. Grenoble Alpes, CEA-LETI, France; M. Darnon, A. Jaouad, M. Volatier, S. Fafard, V. Aimez, 3IT, Univ. de Sherbrooke, Canada</i>	PS+PB-TuM2 Characterization of a Helium Atmospheric Pressure Plasma Jet by Measuring the Total Yield of Reactive Species in Real Time, <i>Ek Adhikari, V. Samara, S. Ptasinska, University of Notre Dame</i>
8:40am	PS+EM+SE-TuM3 Feature Scale Modeling of Etching of High Aspect Ratio Silicon Structures in Pulsed Plasmas, <i>Wei Tian, J.-C. Wang, S. Sadighi, J. Kenny, S. Rauf, Applied Materials</i>	PS+PB-TuM3 Dry Etching of Patterned Medical Grade Titanium Alloys, <i>Eitan Barlaz, J. Mettler, D.N. Ruzic, University of Illinois at Urbana-Champaign</i>
9:00am	PS+EM+SE-TuM4 Plasma Etching of High Aspect Ratio Oxide-Nitride-Oxide Stacks, <i>S. Huang, C. Hurard, University of Michigan; S. Nam, S. Shim, W. Ko, Samsung Electronics Co., Ltd., Republic of Korea; Mark Kushner, University of Michigan</i>	PS+PB-TuM4 Electron Temperature And Plasma Density Of Ar Plasma In Atmospheric Pressure Micro-DBD, <i>Pradoong Suanpoot, J. Sornsakdanuphap, Maejo University Phrae Campus, Thailand; B. Ghimire, Y.J. Hong, Plasma Bioscience Research Center, Republic of Korea; G. Cho, Charged Particle Beam and Plasma Laboratory, Republic of Korea; E.H. Choi, Plasma Bioscience Research Center, Republic of Korea</i>
9:20am	PS+EM+SE-TuM5 Etch Profile Evolution in Poly-silicon using Halogen Containing Plasmas for Next Generation Device Fabrication, <i>Shyam Sridhar, S.A. Voronin, P. Biolsi, A. Ranjan, TEL Technology Center, America, LLC</i>	INVITED: PS+PB-TuM5 Plasma Immunotherapy of Cancers, <i>Vandana Miller, A. Lin, P. Ranieri, Drexel University; A. Snook, Thomas Jefferson University; A. Fridman, Drexel University</i> Invited talk continues.
9:40am	PS+EM+SE-TuM6 Flux and Energy of Reactive Species Arriving at the Etch Front in High Aspect Ratio Features During Plasma Etching of SiO_2 in $\text{Ar}/\text{CF}_4/\text{CHF}_3$ Mixtures, <i>Soheila Mohades, University of Michigan; M. Wang, A. Mosden, TEL Technology Center America, LLC; M.J. Kushner, University of Michigan</i>	
10:00am		
10:20am	BREAK - Complimentary Coffee in Exhibit Hall – Technology Spotlight Sessions in Booth #168, Exhibit Hall	
10:40am		
11:00am	INVITED: PS+EM+SE-TuM10 Wafer-scale Fabrication of Suspended Graphene Nanoribbon Arrays -from Growth Dynamics to Optoelectrical Applications-, <i>Toshiaki Kato, T. Kaneko, Tohoku University, Japan</i>	PS+PB-TuM10 Hydroxyl Radical Footprinting with Plasma-Induced Modification of Biomolecules (PLIMB): A Novel Tool for Protein Structural Analysis, <i>Faraz Choudhury, D.I. Benjamin, B.B. Minkoff, J. Blatz, M.R. Sussman, J.L. Shohet, University of Wisconsin-Madison</i>
11:20am	Invited talk continues.	PS+PB-TuM11 Biological Effects of Plasma-Irradiated Organic Molecules in Plasma- Treated Liquids, <i>Kenji Ishikawa, Y. Hosoi, D. Kanno, Y. Kurokawa, H. Tanaka, M. Mizuno, F. Kikkawa, M. Hori, Nagoya University, Japan</i>
11:40am	PS+EM+SE-TuM12 Investigation of Surface Reactions for GeSbTe-based Phase Change Material: From Etching to Final Sealing Process, <i>Yann Canvel, S. Lagrasta, STMicroelectronics, France; C. Boixaderas, S. Barnola, CEA-LETI, France; E. Martinez, CEA/LETI-University Grenoble Alpes, France</i>	PS+PB-TuM12 OH-Radical Generation in an Atmospheric-Pressure Plasma Discharge for use in Three-Dimensional Protein Structural Analysis, <i>Joshua Blatz, B.B. Minkoff, F.A. Choudhury, D.I. Benjamin, J.L. Shohet, M.R. Sussman, University of Wisconsin-Madison</i>
12:00pm	PS+EM+SE-TuM13 Behaviors of Charged Species in Afterglow of Dual Frequency Pulsed Capacitively Coupled Plasma with a Synchronous Negative DC-bias, <i>Takayoshi Tsutsumi, T. Ueyama, K. Ishikawa, H. Kondo, M. Sekine, Nagoya University, Japan; Y. Ohya, Tokyo Electron Miyagi Limited; M. Hori, Nagoya University, Japan</i>	PS+PB-TuM13 Plasma-Surface Interaction at Atmospheric Pressure: From Mechanisms with Model Polymers to Applications for Sterilization, <i>Pingshan Luan¹, G.S. Oehrlein, University of Maryland, College Park</i>

¹ Coburn & Winters Student Award Finalist

Tuesday Morning, October 23, 2018

Advanced Surface Engineering Division Room 202C - Session SE+PS-TuM Plasma-assisted Surface Modification and Deposition Processes Moderators: Jolanta Klemborg-Sapieha, Ecole Polytechnique de Montreal, Canada, Matjaz Panjan, Jozef Stefan Institute, Slovenia		Surface Science Division Room 203C - Session SS+HC+NS+PS-TuM Controlling Mechanisms of Surface Chemical Reactions Moderators: Bruce D. Kay, Pacific Northwest National Laboratory, Arthur Utz, Tufts University
8:00am	SE+PS-TuM1 Surface Modification of 304 Stainless Steel by Neutral Nitriding, <i>Petros Abraha</i> , Meijo University, Japan	INVITED: SS+HC+NS+PS-TuM1 Bond Making and Bond Breaking at Wet and Dry Surfaces, <i>Angelos Michaelides</i> , University College London, UK
8:20am	SE+PS-TuM2 Plasma Cratering and Hardening for Friction Reduction and Wear Resistance of Cast Iron, <i>Wei Zha</i> , University of Windsor, Canada; <i>C. Zhao</i> , <i>X. Nie</i> , University of Windsor, Canada	Invited talk continues.
8:40am	SE+PS-TuM3 Area-selective Deposition by Surface Engineering for Applications in Nanoelectronics. From Blanket to Confined Dimensions, <i>Silvia Armini</i> , IMEC, Belgium	SS+HC+NS+PS-TuM3 Stability and Reactivity of Isolated Rh ₁ Atoms on Fe ₃ O ₄ (001), <i>Gareth Parkinson</i> , TU Wien, Austria
9:00am	SE+PS-TuM4 Experimental and Numerical Evaluation of Cohesive and Adhesive Failure Modes during Indentation of TiAlN Coatings on Si(100) Deposited by MPPMS, <i>Z.T. Jiang</i> , <i>M.K. Lei</i> , Dalian University of Technology, China	SS+HC+NS+PS-TuM4 The Mechanism of Glaser Coupling Reactions on Ag(111) and Cu(111) Surfaces: a Case for Halogen Substituted Terminal Alkyne, <i>T. Wang</i> , <i>H.F. Lv</i> , <i>L. Feng</i> , <i>J.M. Huang</i> , <i>X.J. Wu</i> , University of Science and Technology of China; <i>Junfa Zhu</i> , National Synchrotron Radiation Laboratory and Department of Chemical Physics, University of Science and Technology of China
9:20am	SE+PS-TuM5 Growth of TiB _x Thin Films by DC Magnetron Sputtering and High-Power Impulse Magnetron Sputtering: Effect of Pressure and Substrate Temperature, <i>Niklas Hellgren</i> , Messiah College; <i>J. Thörnberg</i> , <i>I. Zhirkov</i> , Linköping University, Sweden; <i>G. Greczynski</i> , Linköping University, Sweden; <i>J.P. Palisaitis</i> , Linköping University, Sweden; <i>M. Sortica</i> , Uppsala University, Sweden; <i>P.O.A. Persson</i> , Linköping University, Sweden; <i>I. Petrov</i> , <i>J.E. Greene</i> , University of Illinois at Urbana-Champaign; <i>L. Hultman</i> , <i>J. Rosen</i> , Linköping University, Sweden	SS+HC+NS+PS-TuM5 Sulfur-driven Switching of the Ullmann Coupling on Au(111), <i>Jonathan Rodríguez-Fernández</i> , <i>S.B. Schmidt</i> , <i>J.V. Lauritsen</i> , Aarhus University, Denmark
9:40am	SE+PS-TuM6 Time-resolved Analysis of the Cathodic Arc Plasma from Nb-Al Cathodes, <i>S. Zöhrer</i> , Montanuniversität Leoben, Austria; <i>A. Anders</i> , Lawrence Berkeley National Laboratory, Leibniz Institute of Surface Engineering (IOM), Leipzig, Germany; <i>D. Holec</i> , <i>Robert Franz</i> , Montanuniversität Leoben, Austria	SS+HC+NS+PS-TuM6 The Step Sites of Ultrathin ZnO Promote Methanol Oxidation to Formaldehyde, <i>Xingyi Deng</i> , <i>D.C. Sorescu</i> , <i>J. Lee</i> , National Energy Technology Laboratory
10:00am	BREAK - Complimentary Coffee in Exhibit Hall - Technology Spotlight Sessions in Booth #168, Exhibit Hall	
10:20am	BREAK - Complimentary Coffee in Exhibit Hall - Technology Spotlight Sessions in Booth #168, Exhibit Hall	
10:40am	BREAK - Complimentary Coffee in Exhibit Hall - Technology Spotlight Sessions in Booth #168, Exhibit Hall	
11:00am	INVITED: SE+PS-TuM10 Dedicated Experiments to Challenge a Model for Reactive Magnetron Sputtering, <i>Diederik Depla</i> , Ghent University, Belgium	SS+HC+NS+PS-TuM10 Investigation of Configuration Change in Water Clusters on a Bilayer ZnO Surface, <i>Junseok Lee</i> , <i>D.C. Sorescu</i> , <i>X. Deng</i> , National Energy Technology Laboratory
11:20am	Invited talk continues.	SS+HC+NS+PS-TuM11 Oxygen Reduction Reaction on Fullerene, <i>Yosuke Kikuchi</i> , <i>J.N. Nakamura</i> , The University of Electro-Communications (UEC-Tokyo), Japan
11:40am	SE+PS-TuM12 Current-voltage-time Characteristics of HiPIMS Discharges Revisited, <i>André Anders</i> , Leibniz Institute of Surface Engineering (IOM), Germany	SS+HC+NS+PS-TuM12 Surface Structure and Reactivity of Ni-Cu Single-Atom Alloys, <i>Dipna Patel</i> , <i>E.C.H. Sykes</i> , Tufts University
12:00pm	SE+PS-TuM13 Advantages Associated with Applying a Positive Pulse Option to a HiPIMS Power Supply, <i>Jason Hrebik</i> , Kurt J. Lesker Company	SS+HC+NS+PS-TuM13 Effective Local Structure for Bottom-up Designed ORR Catalyst Using Pyridinic Nitrogen Containing Molecules, <i>Kotarou Takeyasu</i> , <i>Y. Shimoyama</i> , <i>M. Furukawa</i> , <i>S. Singh</i> , <i>J. Nakamura</i> , University of Tsukuba, Japan

Tuesday Morning, October 23, 2018

Thin Films Division Room 104B - Session TF+AM+EM+PS-TuM Atomic Layer Processing: Area Selective Deposition Moderators: Christophe Vallee, LTM, Univ. Grenoble Alpes, CEA-LETI, France, Steven George, University of Colorado at Boulder		Thin Films Division Room 102A - Session TF+AS-TuM Special Session in Honor of Paul Holloway: Luminescent Materials Growth, Synthesis and Characterization Moderators: Sean Jones, National Science Foundation (NSF), Jay Lewis, Defense Advanced Research Projects Agency
8:00am	INVITED: TF+AM+EM+PS-TuM1 New Approaches for Area-Selective Atomic Layer Deposition: Inspiration from Etching, <i>Adrie Mackus</i> , Eindhoven University of Technology, The Netherlands, Nederland	TF+AS-TuM1 INTRO: Special Session Honoring Professor Paul H. Holloway, <i>Gary McGuire</i> , Adamas Nanotechnologies
8:20am	Invited talk continues.	TF+AS-TuM2 Harnessing Disorder in Detectors, <i>Jay Lewis</i> , Defense Advanced Research Projects Agency
8:40am	TF+AM+EM+PS-TuM3 Nucleation of HfO ₂ on Si, SiO ₂ and TiN Substrates in PE-ALD Processes Investigated by In situ Ellipsometry and Optical Emission Spectroscopy (OES), <i>Marceline Bonvalot</i> , <i>S. belahcen</i> , <i>V. Pesce</i> , <i>A. Chaker</i> , <i>P. Gonon</i> , <i>C. Vallée</i> , <i>A. Bsiesy</i> , LTM, Univ. Grenoble Alpes, CEA-LETI, France	INVITED: TF+AS-TuM3 Luminescent Materials for Solid State Lighting and Solar Cell Applications, <i>Hendrik C Swart</i> , <i>J.J. Terblans</i> , <i>R.E. Kroon</i> , <i>E. Coetsee</i> , <i>M.M. Duvenhage</i> , <i>E. Hasabeldaim</i> , <i>A. Balakrishna</i> , <i>A. Kumar</i> , University of the Free State, Republic of South Africa; <i>P.H. Holloway</i> , University of Florida
9:00am	TF+AM+EM+PS-TuM4 Topographical Selectivity with BN Electron-Enhanced ALD, <i>Jaclyn Sprenger</i> , <i>A.S. Cavanagh</i> , <i>H. Sun</i> , University of Colorado at Boulder; <i>A. Roshko</i> , <i>P. Blanchard</i> , National Institute of Standards and Technology; <i>S.M. George</i> , University of Colorado at Boulder	Invited talk continues.
9:20am	TF+AM+EM+PS-TuM5 Optimization by In situ Ellipsometry of ALD and ALE Successive Steps for the Selective Atomic Layer Deposition of Ta ₂ O ₅ on TiN and Si., <i>Vincent Pesce</i> , <i>C. Vallée</i> , LTM, Univ. Grenoble Alpes, CEA-LETI, France; <i>R. Gassilloud</i> , Cea Leti, France; <i>A. Chaker</i> , <i>M. Bonvalot</i> , <i>B. Pelissier</i> , LTM, Univ. Grenoble Alpes, CEA-LETI, France; <i>N. Nicolas</i> , Cea, France; <i>A. Bsiesy</i> , LTM, Univ. Grenoble Alpes, CEA-LETI, France	INVITED: TF+AS-TuM5 Fluorescent Nanodiamond for Applications in Whole Body Imaging, <i>Olga Shenderova</i> , <i>M.D. Torelli</i> , Adamas Nanotechnologies; <i>A. Rickard</i> , Duke University; <i>N.J. Nunn</i> , Adamas Nanotechnologies; <i>M. Backer</i> , SibTech; <i>G.M. Palmer</i> , Duke University; <i>G. McGuire</i> , Adamas Nanotechnologies
9:40am	TF+AM+EM+PS-TuM6 ALD and PEALD of ZnO on MoS ₂ and WSe ₂ , <i>Timothy N. Walter</i> ¹ , <i>S. Lee</i> , The Pennsylvania State University; <i>M. Chubarov</i> , The Pennsylvania State University; <i>X. Zhang</i> , The Pennsylvania State University; <i>T.H. Choudhury</i> , <i>J.M. Redwing</i> , The Pennsylvania State University; <i>T.N. Jackson</i> , <i>S.E. Mohney</i> , The Pennsylvania State University	Invited talk continues.
10:00am		
10:20am	BREAK - Complimentary Coffee in Exhibit Hall - Technology Spotlight Sessions in Booth #168, Exhibit Hall	
10:40am		
11:00am	INVITED: TF+AM+EM+PS-TuM10 From Fundamental Insights into Growth and Nucleation Mechanisms to Area-selective Deposition, <i>Annelies Delabie</i> , IMEC & KU Leuven, Belgium; <i>J. Soethoudt</i> , KU Leuven, Belgium; <i>G. Pourtois</i> , <i>S. Van Elshocht</i> , <i>K. Barla</i> , Imec, Belgium; <i>F. Grillo</i> , <i>E. Marques</i> , <i>J.R. van Ommen</i> , TU Delft, Netherlands	INVITED: TF+AS-TuM10 The Apple does not Fall Far from the Tree: A Serendipitous Journey from Luminescent Materials to Nanoscale Focused Electron (and Ion) Beam Induced Processing, <i>Philip D. Rack</i> , University of Tennessee Knoxville
11:20am	Invited talk continues.	Invited talk continues.
11:40am	TF+AM+EM+PS-TuM12 DETA SAMs as ALD Ru Inhibitor for Area-selective Bottom-up Interconnects, <i>Ivan Zyulkov</i> , IMEC & KU Leuven; <i>S. Armini</i> , IMEC, Belgium; <i>S. De Gendt</i> , IMEC, KU Leuven, Belgium	INVITED: TF+AS-TuM12 Atomic Layer Deposition of Optoelectronic Materials, <i>Markku Leskela</i> , <i>M.K. Ritala</i> , University of Helsinki, Finland
12:00pm		

¹ TFD James Harper Award Finalist

Tuesday Morning, October 23, 2018

Thin Films Division Room 101A - Session TF-TuM Emerging Applications for ALD Moderators: Arrelaine Dameron, Forge Nano, Qing Peng, University of Alabama		Vacuum Technology Division Room 203B - Session VT-TuM Large Vacuum Systems and Accelerator Vacuum Technology Moderator: Yevgeniy Lushtak, SAES Getters USA
8:00am	TF-TuM1 Atomic Layer Deposition of the Metal Pyrites FeS ₂ , CoS ₂ , and NiS ₂ , <i>Xinwei Wang</i> , Shenzhen Graduate School, Peking University, China	INVITED: VT-TuM1 Design of Vacuum Control System for the Linac Coherent Light Source II (LCLS-II) at SLAC National Accelerator Laboratory, <i>Shweta Saraf, S. Kwon, G. Lanza, D. Gill</i> , SLAC National Accelerator Laboratory Invited talk continues.
8:20am	TF-TuM2 Atomic Layer Deposition of Yttrium Fluoride and Yttrium Oxyfluoride Films with Tunable Stoichiometry, <i>Jasmine Wallas¹, J.A. Murdzek, D.K. Lancaster, A.S. Cavanagh, S.M. George</i> , University of Colorado at Boulder	
8:40am	TF-TuM3 Synthesis of Single Phase Two-dimensional SnS ₂ by Plasma-enhanced Atomic Layer Deposition, <i>J.J. Pyeon, I.-H. Baek</i> , Korea Institute of Science and Technology; <i>T.-M. Chung</i> , Korea Research Institute of Chemical Technology; <i>J.H. Han</i> , Seoul National University of Science and Technology; <i>C.-Y. Kang, SeongKeun Kim</i> , Korea Institute of Science and Technology, Republic of Korea	VT-TuM3 Vacuum System Design for Advanced Light Source Upgrade (ALS-U), <i>Sol Omolayo</i> , Lawrence Berkeley Lab, University of California, Berkeley
9:00am	TF-TuM4 Phase Selective, Low Temperature Growth of TiO ₂ by Atomic Layer Epitaxy, <i>Jason Avila, D.R. Boris, S.B. Qadri, J.A. Freitas, S.G. Walton, C.R. Eddy Jr., V.D. Wheeler</i> , U.S. Naval Research Laboratory	VT-TuM4 Vacuum System for CHESS-U: Design, Manufacturing, and Installation, <i>X. Liu, D.C. Burke, A.T. Holc, Yulin Li, A. Lyndaker</i> , Cornell University
9:20am	TF-TuM5 Substrate Biasing During Plasma Atomic Layer Deposition: From Stress-controlled Oxides to Low-resistivity Nitrides, <i>Harm Knoops</i> , Oxford Instruments, The Netherlands; <i>T.F. Faraz, K. Arts, S. Karwal, M.C. Creatore, W.M.M. Kessels</i> , Eindhoven University of Technology, The Netherlands	VT-TuM5 Design and Fabrication of CHESS-U Crotch Absorbers, <i>Y. Li, Xianghong Liu, A. Lyndaker, K. Smolenski, A. Woll, L. Smieska</i> , Cornell Laboratory of Accelerator-based Sciences and Education
9:40am	TF-TuM6 Development of Novel Superconducting ALD Films for Astronomy Applications, <i>Frank Greer, P. Day, B. Eom, H. Leduc</i> , Jet Propulsion Laboratory, California Institute of Technology	VT-TuM6 Simulation and Measurement of the Tritium Retention in the Beamline of the KATRIN Experiment, <i>Joachim Wolf</i> , Karlsruhe Institute of Technology, Germany
10:00am		
10:20am	BREAK - Complimentary Coffee in Exhibit Hall - Technology Spotlight Sessions in Booth #168, Exhibit Hall	
10:40am		
11:00am	TF-TuM10 Atomic Layer Deposition of Cobalt Nanoparticles, <i>Gerben van Straaten, W.M.M. Kessels, M.C. Creatore</i> , Eindhoven University of Technology, The Netherlands	VT-TuM10 NSLS-II Beamline Vacuum Challenges: Design, Commissioning, and Operations, <i>Robert Todd, C. Hetzel</i> , Brookhaven National Laboratory
11:20am	TF-TuM11 Atomic Layer Deposition of Ni-Al-O Catalysts for Water Oxidation, <i>Jon Baker, J.R. Schneider, J.A. Singh, A.J. Mackus, S.F. Bent</i> , Stanford University	VT-TuM11 Thin film Heterostructures for Superconducting Photocathode Applications, <i>Mark Warren</i> , Illinois Institute of Technology
11:40am	TF-TuM12 Atomic Layer Deposition of Bismuth Vanadate Photoanodes, <i>Sudarat Lee, A.R. Bielinski, S.L. Esarey, J.J. Bracho</i> , University of Michigan, Ann Arbor; <i>B.M. Bartlett</i> , University of Michigan, Ann Arbor; <i>N.P. Dasgupta</i> , University of Michigan, Ann Arbor	VT-TuM12 TPD Results on Electrode Materials for Pulsed Power Vacuum Environments, <i>Ronald Goeke, S.C. Simpson, K.R. Coombes, M.K. Alam, D.P. Adams</i> , Sandia National Laboratories
12:00pm	TF-TuM13 ALD of Cobalt Phosphate Electro-catalyst for Oxygen Evolution Reaction, <i>Valerio Di Palma</i> , Eindhoven University of Technology, The Netherlands; <i>G. Zafeiropoulos, M.N. Tsampas</i> , DIFFER; <i>W.M.M. Kessels, M.C. Creatore</i> , Eindhoven University of Technology, The Netherlands	VT-TuM13 Radio Frequency Surface Resistance Measurement of Metals for Accelerator Vacuum Chamber, <i>Omid Seify</i> , STFC/DL/ASTeC, Daresbury, Cheshire, UK

¹ TFD James Harper Award Finalist

Tuesday Morning, October 23, 2018

Exhibitor Technology Spotlight Workshops Room Hall A - Session EW-TuB Exhibitor Technology Spotlight Session I Moderator: Christopher Moffitt, Kratos Analytical Inc		Manufacturing Science and Technology Group Room 103C - Session MS-TuB Working with Government Labs and other User Facilities Moderator: Bridget Rogers, Vanderbilt University
10:00am		MS-TuB1 Joining the Research Community at the Cornell NanoScale Science and Technology Facility, <i>Michael Skvarla</i> , Cornell University
10:20am	EW-TuB2 IMPULSE HIPIMS Power Supply with Positive Pulse Option Advantages, <i>Jason Hrebik</i> , Kurt J. Lesker Company	MS-TuB2 Opportunities at DOE Nanoscale Science Research Centers, <i>Arthur Baddorf</i> , Oak Ridge National Laboratory
10:40am	EW-TuB3 Choosing the Proper Equipment for Vacuum Heat Treatment, <i>Rachael Stene</i> , Across International	
11:00am		

Tuesday Lunch, October 23, 2018

Exhibitor Technology Spotlight Workshops
Room Hall A - Session EW-TuL
Exhibitor Technology Spotlight Session II
Moderator: Christopher Moffitt, Kratos Analytical Inc

12:00pm		
12:20pm	<p>FREE LUNCH IN EXHIBIT HALL* (See Registration Tickets)</p> <p>*while supplies last</p>	
12:40pm	EW-TuL3 Correlative Spectroscopy with the Thermo Scientific Nexsa, <i>Tim Nunney, P. Mack, R.E. Simpson</i> , Thermo Fisher Scientific, UK	
1:00pm	EW-TuL4 Exploring the Capabilities of a Modern XPS Spectrometer: In-situ Surface Preparation & Modification, <i>Adam Roberts</i> , Kratos Analytical Limited, UK; <i>D. Surman, C. Moffitt</i> , Kratos Analytical Inc; <i>J.D.P. Counsell</i> , Kratos Analytical Ltd, UK	
1:20pm	EW-TuL5 Design and Characterization of Nanomaterials using PREVAC's Research Platforms, <i>Lukasz Walczak</i> , PREVAC sp. z o.o., Poland	
1:40pm	EW-TuL6 Agilent's New Helium Leak Detector, <i>John McLaren</i> , Agilent	
2:00pm	EW-TuL7 Auger Multi-Technique: EDS, EBSD, BSE, FIB, <i>John Newman</i> , Physical Electronics	

Tuesday Afternoon, October 23, 2018

2D Materials Focus Topic Room 201B - Session 2D+EM+MI+MN+NS-TuA 2D Device Physics and Applications Moderator: Roland Kawakami, The Ohio State University		Applied Surface Science Division Room 204 - Session AS-TuA The Impact of Modeling (Ion, Electron) and Data Analysis on Applied Surface Science, a Celebration of the Career of Barbara Garrison Moderators: Gregory L. Fisher, Physical Electronics, Alexander Shard, National Physical Laboratory, UK
2:20pm 2D+EM+MI+MN+NS-TuA1 Spin Relaxation and Proximity Effect in WS ₂ /Graphene/Fluorographene Non-local Spin Valves, <i>Adam Friedman</i> , Laboratory for Physical Sciences; <i>K.M. McCreary, J.T. Robinson, O.M.J. van 't Erve, B.T. Jonker</i> , US Naval Research Laboratory		INVITED: AS-TuA1 Collective Action, the Key to Soft Molecule Desorption under Particle Bombardment, <i>Arnaud Delcorde</i> , Université catholique de Louvain, Belgium
2:40pm 2D+EM+MI+MN+NS-TuA2 Two-dimensional Field-effect Light Emitting Transistors, <i>Junyoung Kwon, H. Ryu</i> , Yonsei University, Republic of Korea; <i>J.Y. Lee, C.H. Lee</i> , Korea University, Republic of Korea; <i>G.H. Lee</i> , Yonsei University, Republic of Korea		Invited talk continues.
3:00pm INVITED: 2D+EM+MI+MN+NS-TuA3 Quantum Devices with 2D Materials, <i>H. Overweg, M. Eich, R. Pisoni, T. Ihn, P. Rickhaus</i> , ETH Zurich, Switzerland; <i>Klaus Ensslin</i> , ETH Zürich, Switzerland		AS-TuA3 Mechanisms of the Generation of Nanoparticles and Surface Modification in Short Pulse Laser Ablation of Metal Targets in Liquids, <i>Leonid Zhigilei, C.-Y. Shih, M. Shugaev</i> , University of Virginia
3:20pm Invited talk continues.		AS-TuA4 First Principles Thermodynamics and Molecular Modeling of Surfaces in Aqueous Environments, <i>Donald Brenner, Z. Rak, L. Su, J. Krim</i> , North Carolina State University
3:40pm BREAK - Complimentary Refreshments in Exhibit Hall - Technology Spotlight Sessions in Booth #168, Exhibit Hall		
4:00pm		
4:20pm 2D+EM+MI+MN+NS-TuA7 GaN Microdisk Light-emitting Diode Display Fabricated on Graphene, <i>Youngbin Tchoe, K. Chung, K. Lee, M.S. Song, J.B. Park, H. Kim, J.Y. Park, G.-C. Yi</i> , Seoul National University, Republic of Korea		INVITED: AS-TuA7 Computer Modeling of Cluster Projectile Impacts for SIMS Applications, <i>Zbigniew Postawa</i> , Jagiellonian University, Krakow, Poland
4:40pm 2D+EM+MI+MN+NS-TuA8 Room Temperature Magnetron Sputtering and Laser Annealing of Ultrathin MoS ₂ for Transistor Device Fabrication on Flexible Polymer Substrates, <i>Benjamin Sirota</i> , University of North Texas; <i>N.R. Glavin</i> , Air Force Research Laboratory; <i>C. Arnold, A.A. Voevodin</i> , University of North Texas		Invited talk continues.
5:00pm INVITED: 2D+EM+MI+MN+NS-TuA9 Black Phosphorus: Fundamental Properties and Emerging Applications, <i>Han Wang</i> , University of Southern California		AS-TuA9 Use of Ion-Solid Interactions Modeling and Theory for Real Applications in FIB Milling, <i>Lucille Giannuzzi</i> , L.A. Giannuzzi & Associates LLC
5:20pm Invited talk continues.		AS-TuA10 The Influence of the Projectile Cluster on the Molecular Ionization Probability in SIMS, <i>Lars Breuer, A. Wucher</i> , Universitat Duisburg-Essen, Germany; <i>N. Winograd</i> , The Pennsylvania State University
5:40pm 2D+EM+MI+MN+NS-TuA11 Patterned Growth of Hybrid Bulk-2D Tungsten Diselenide for Transistor Applications, <i>Quinten Yurek, I. Liao, D. Barroso, A.E. Nguyen, N. Duong, G. Stecklein, L. Bartels</i> , University of California, Riverside		INVITED: AS-TuA11 In Situ Liquid SIMS, a Molecular Eye for Examination of Liquids and Liquid Interfaces, <i>Zihua Zhu¹, Y. Zhang</i> , Pacific Northwest National Laboratory
6:00pm 2D+EM+MI+MN+NS-TuA12 Enhanced Ionic Sensitivity in Solution-Gated Graphene-Hexagonal Boron Nitride Heterostructure Field-Effect Transistors, <i>A.D. Radadia, Nowzesh Hasan, B. Hou, A.L. Moore</i> , Louisiana Tech University		Invited talk continues.

¹ ASSD Peter Sherwood Award

Tuesday Afternoon, October 23, 2018

Biomaterial Interfaces Division Room 101B - Session BI+AS+IPF+NS-TuA IoT Session: Biofabrication, Bioanalytics, Biosensors and Diagnostics and Flash Networking Session Moderators: Graham Leggett, University of Sheffield, UK, Tobias Weidner, Aarhus University, Denmark		Electronic Materials and Photonics Division Room 101A - Session EM+2D+AN+MI+MP+NS-TuA Solar/Energy Harvesting and Quantum Materials and Applications Moderators: Yohannes Abate, Georgia State University, Nicholas Strandwitz, Lehigh University
2:20pm	BI+AS+IPF+NS-TuA1 Functionalization of Silica Materials via Click Reaction of Surface Silanol Groups with Vinyl Sulfones, <i>Fang Cheng, H. Wang, W. He, B. Sun, J. Qu</i> , Dalian University of Technology, China	INVITED: EM+2D+AN+MI+MP+NS-TuA1 Plasmonic Metasurface Electrodes for Excitonic Solar Cells., <i>Deirdre O'Carroll</i> , Rutgers, the State University of New Jersey Invited talk continues.
2:40pm	BI+AS+IPF+NS-TuA2 Organosilica pH Nanosensors Applied to Realtime Metabolite Monitoring, <i>Kye Robinson</i> , Monash University, Australia; <i>K. Thurecht</i> , University of Queensland, Australia; <i>S. Corrie</i> , Monash University, Australia	
3:00pm	BI+AS+IPF+NS-TuA3 Impact of Different Receptor Binding Modes on Surface Morphology and Electrochemical Properties of PNA-based Sensing Platforms, <i>Johannes Daniel Bartl</i> , Walter Schottky Institut (WSI) and Physics Department, Technische Universität München, Germany; <i>P. Scarbo</i> , Dipartimento Politecnico di Ingegneria e Architettura (DPIA), Università degli Studi di Udine, Italy; <i>S. Gremmo, G. Rziga, M. Stutzmann</i> , Walter Schottky Institut (WSI) and Physics Department, Technische Universität München, Germany; <i>M. Tornow</i> , Molecular Electronics Group and Department of Electrical and Computer Engineering, Technische Universität München, Germany; <i>L. Selmi</i> , Dipartimento di Ingegneria "Enzo Ferrari" (DIEF), Università di Modena e Reggio Emilia, Italy; <i>A. Cattani-Scholz</i> , Walter Schottky Institut (WSI) and Physics Department, Technische Universität München, Germany	EM+2D+AN+MI+MP+NS-TuA3 Photoemission Electron Microscopy as a New Tool to Study the Electronic Properties of an Inhomogeneous Semiconductor for Photovoltaics, <i>M. Berg</i> , Sandia National Laboratories; <i>J. Kephart, A. Munshi, W.S. Sampath</i> , Colorado State University; <i>Taisuke Ohta, C. Chan</i> , Sandia National Laboratories
3:20pm	BI+AS+IPF+NS-TuA4 Biosensor for Detection of Gasotransmitter from Living Cells Employing Silver Nanorods Array, <i>Shashank Gahlaut, C. Sharan, J.P. Singh</i> , Indian Institute of Technology Delhi, India	EM+2D+AN+MI+MP+NS-TuA4 Modification of Bandgap for Lead-Free Double Perovskite $\text{Cs}_2\text{AgInCl}_6$ with Bi Doping, <i>Hassan Siddique, H. Da, X.Q. Wang, R.C. Dai, Z.P. Wang, Z.J. Ding, Z.M. Zhang</i> , University of Science and Technology of China
3:40pm	BREAK - Complimentary Refreshments in Exhibit Hall - Technology Spotlight Sessions in Booth #168, Exhibit Hall	
4:00pm	BREAK - Complimentary Refreshments in Exhibit Hall - Technology Spotlight Sessions in Booth #168, Exhibit Hall	
4:20pm	BI+AS+IPF+NS-TuA7 Conversion of Human Stem Cells into Insulin Producing Cells Through 2D Platforms for Enhanced in-vitro Insulin Production, <i>S.K. Vishwakarma, A.A. Khan</i> , Central Laboratory for Stem Cell Research and Translational Medicine, Centre for Liver Research and Diagnostics, Deccan College of Medical Sciences, India; <i>Marshal Dhayal</i> , IIT (BHU), Varanasi, India	INVITED: EM+2D+AN+MI+MP+NS-TuA7 Optimized (Quantum) Photonics, <i>Jelena Vuckovic</i> , Stanford University Invited talk continues.
4:40pm	BI+AS+IPF+NS-TuA8 Polyzwitterion-modified Nanoparticles for Selective Antibody Separation, <i>F. Cheng, C. Zhu, Wei He, B. Sun, J. Qu</i> , Dalian University of Technology, China	
5:00pm	BI+AS+IPF+NS-TuA9 Orienting Proteins on Surfaces with Site-specific Bioorthogonal Ligations, <i>Riley Bednar, R.A. Mehl</i> , Department of Biochemistry and Biophysics, Oregon State University	EM+2D+AN+MI+MP+NS-TuA9 Optical Properties of Single Silicon Vacancies in 4H-SiC, <i>H.B. Banks</i> , National Research Council Postdoc residing at the Naval Research Laboratory; <i>O. Soysal</i> , Sotera Defense Solutions, Inc, residing at the Naval Research Laboratory; <i>S.P. Pavunny, R.L. Myers-Ward, D.K. Gaskill, Samuel Carter</i> , U.S. Naval Research Laboratory
5:20pm	BI+AS+IPF+NS-TuA10 High-throughput Study of the Role of Spatial Organization on the Activity of Surface-Bound Enzymes, <i>Nourin Alsharif, T. Lawton, J. Uzarski</i> , Natick Soldier Research, Development and Engineering Center; <i>K.A. Brown</i> , Boston University	EM+2D+AN+MI+MP+NS-TuA10 Photoluminescence Studies on Patterned Silicon Vacancy Defects in Li Ion Implanted 4H-SiC for Scalable Quantum Device Applications, <i>Shojan Pavunny</i> , U.S. Naval Research Laboratory; <i>S.G. Carter, H.B. Banks, R.L. Myers-Ward, P. Klein</i> , U.S. Naval Research Laboratory; <i>E.S. Bielejec</i> , Sandia National Laboratories; <i>M.T. DeJarl, A.S. Bracker, E.R. Glaser, D.K. Gaskill</i> , U.S. Naval Research Laboratory
5:40pm	BI+AS+IPF+NS-TuA11 Fabrication of Amino acid Contained Poly-lactic Acid Nanofibers by Electrospinning, <i>C. Li</i> , National Yang Ming University, Taiwan, Republic of China; <i>J.H. Hsieh</i> , Ming Chi University of Technology, Taiwan, Republic of China; <i>P.H. Lin</i> , National Yang Ming University, Taiwan, Republic of China	EM+2D+AN+MI+MP+NS-TuA11 Processing of Cavities in SiC Material for Quantum Technologies, <i>Rachael Myers-Ward, K. Hobart, K.M. Daniels, A.J. Giles, M.J. Tadjer, L.E. Luna, F.J. Kub, S.P. Pavunny, S.G. Carter, H.B. Banks, E.R. Glaser</i> , U.S. Naval Research Laboratory; <i>P.B. Klein</i> , Sotera Defense Solutions; <i>K. Qiao, Y. Kim, J. Kim</i> , Massachusetts Institute of Technology; <i>D.K. Gaskill</i> , U.S. Naval Research Laboratory
6:00pm	6:05pm BID BUSINESS MEETING; 6:15pm BID FLASH SESSION: ZEINAB VEISI , Univ. of S. Florida (BI-TuP3); NAREH MOVSESIAN , Univ. of Southern CA (BI-TuP7); PHUONG ANH NGUYEN , Univ. of New Mexico (BI-TuP8); BILL THEILACKER , Medtronic(BI-TuP9)	EM+2D+AN+MI+MP+NS-TuA12 Investigation of Localized Electronic structures of PbSe Quantum Dot Superlattice on a Highly Oriented Pyrolytic Graphite (HOPG), <i>Il Jo Kwak, S. Ueda</i> , University of California at San Diego; <i>A. Abelson, C. Qian, M. Law</i> , University of California, Irvine; <i>A.C. Kummel</i> , University of California at San Diego

Tuesday Afternoon, October 23, 2018

Fundamental Discoveries in Heterogeneous Catalysis Focus Topic Room 201A - Session HC+SS-TuA A Tale of Two Scales: Catalytic Processes and Surface Science Moderator: Ashleigh Baber, James Madison University		Manufacturing Science and Technology Group Room 202B - Session MS+MN-TuA IoT Session: Challenges of Sensor Manufacturing for the IoT Moderator: Robert Lad, University of Maine
2:20pm	HC+SS-TuA1 CO ₂ Reduction on the Surface of Cu/TiO ₂ NPs Supported on Graphite Studied using Ambient Pressure-XPS and Differential Electrochemical Mass Spectrometer, <i>Djawhar Ferrah, A. Haines, R.P. Galhenage</i> , University of California at Irvine; <i>A. Javier</i> , California Institute of Technology; <i>J.P. Bruce</i> , University of California at Irvine; <i>M. Soriaga</i> , California Institute of Technology; <i>J.C. Hemminger</i> , University of California at Irvine	INVITED: MS+MN-TuA1 Manufacturing Strategies for Flexible Hybrid Electronics, <i>Scott Miller</i> , NextFlex Invited talk continues.
2:40pm	HC+SS-TuA2 Influence of Bi and Sb on the Structure of Pd-based Catalysts, <i>Joo Kang, W.-S. Lee, P.R. Vlasak</i> , The Dow Chemical Company; <i>A.V. Kirilin</i> , The Dow Chemical Company, Netherlands; <i>H. Clements, C. Menzies, S. Yusuf</i> , The Dow Chemical Company	
3:00pm	INVITED: HC+SS-TuA3 The Molecular Surface Chemistry Approach to Heterogeneous Catalysts, <i>Peter Stair</i> , Northwestern University	INVITED: MS+MN-TuA3 Enabling Smart and Connected Living through High Volume Roll to Roll Manufacturing, <i>Enid Kivuti</i> , Sheldahl Flexible Technologies
3:20pm	Invited talk continues.	Invited talk continues.
3:40pm		
BREAK - Complimentary Refreshments in Exhibit Hall - Technology Spotlight Sessions in Booth #168, Exhibit Hall		
4:00pm		
4:20pm	HC+SS-TuA7 Formation and Stability of Subsurface Oxygen on Ag(111), <i>Marie Turano</i> , Loyola University Chicago; <i>S. Isbill, S. Roy</i> , University of Tennessee Knoxville; <i>R.G. Farber</i> , Loyola University Chicago; <i>E.V. Iski</i> , University of Tulsa; <i>D.R. Killelea</i> , Loyola University Chicago	INVITED: MS+MN-TuA7 New Generation Chemical and Biological Sensors: From New Ideas to Manufacturable Products in the era of Internet of Things and Industrial Internet, <i>Radislav Potyrailo</i> , General Electric Global Research Center
4:40pm	HC+SS-TuA8 Mechanistic Insights into Catalytic Transfer Hydrogenation and Decarbonylation of Aromatic Aldehydes on P _x -Ru(0001), <i>Abinaya Sampath, D.W. Flaherty</i> , University of Illinois at Urbana-Champaign	Invited talk continues.
5:00pm	HC+SS-TuA9 Hot Electron Flux under Methanol Oxidation on Pt/TiO ₂ Catalytic Nanodiode; Intrinsic Relation between Selectivity and Chemicurrent, <i>Si Woo Lee, S. Lee</i> , Korea Advanced Institute of Science and Technology (KAIST), Republic of Korea; <i>H. Lee</i> , Institute for Basic Science (IBS), Republic of Korea; <i>W. Park, Y. Jung, J.Y. Park</i> , Korea Advanced Institute of Science and Technology (KAIST), Republic of Korea	INVITED: MS+MN-TuA9 The Unique Challenges Implantable Sensor Manufacture, <i>Kimberly Chaffin, S. Terry</i> , Medtronic plc
5:20pm	HC+SS-TuA10 Online Kinetics Study of Oxidative Coupling of Methane over La ₂ O ₃ for C ₂ Activation: What is Behind the Distinguished Light-off Temperatures, <i>Yong Yang, Z. Liu, E.I. Vovk, X. Zhou, C. Guan</i> , ShanghaiTech University, China	Invited talk continues.
5:40pm	INVITED: HC+SS-TuA11 Non-Innocent Solvents, Hydrogen Transfer, Oxygen Dissociation on Nanoparticles during the Direct Synthesis of H ₂ O ₂ , <i>David W. Flaherty</i> , University of Illinois, Urbana-Champaign	
6:00pm	Invited talk continues.	

Tuesday Afternoon, October 23, 2018

Nanometer-scale Science and Technology Division Room 102B - Session NS+AM+MI+MN+SS+TR-TuA SPM – Probing and Manipulating Nanoscale Structures Moderators: Renu Sharma, NIST Center for Nanoscale Science and Technology, Carl Ventrice, Jr., SUNY Polytechnic Institute		Processing and Characterization of Air-Liquid, Solid-Liquid and Air-Solid Interfaces Focus Topic Room 202A - Session PC+AS+BI+EM+NS+PB+SS-TuA Progress in Industrial Processes and Characterization of Interfaces and Gas-Solid Interfacial Processes and Characterization Moderators: Jeffrey Fenton, Medtronic, Xiao-Ying Yu, Pacific Northwest National Laboratory
2:20pm	INVITED: NS+AM+MI+MN+SS+TR-TuA1 Building Artificial Quantum Matter with Dopant Atoms, <i>Sven Rogge</i> , University of New South Wales, Australia	INVITED: PC+AS+BI+EM+NS+PB+SS-TuA1 Near Ambient Pressure XPS as a Standard Tool for True Non-destructive High-throughput Surface Chemical Analysis in Industrial Applications, <i>Andreas Thissen, P. Dietrich, SPECS Surface Nano Analysis GmbH, Germany; M. Kjaervik, W.E.S. Unger, Bundesanstalt für Materialforschung und -prüfung (BAM), Germany</i>
2:40pm	Invited talk continues.	Invited talk continues.
3:00pm	NS+AM+MI+MN+SS+TR-TuA3 Scanning Tunneling Microscopy Study of Structure Control of a Nanocarbon Catalyst through a Surface-Activated coupling Reaction, <i>Jeremy Schultz, P. Whiteman, N. Jiang</i> , University of Illinois at Chicago	INVITED: PC+AS+BI+EM+NS+PB+SS-TuA3 Surface Modifications in the Medical Device Field – Understanding of Methods to Control Adhesion and Reactions That Materials Undergo, <i>Jeffrey Fenton, B. Theilacker, A. Belu, B. Tischendorf</i> , Medtronic
3:20pm	NS+AM+MI+MN+SS+TR-TuA4 Detecting the Tip Shape Dependence of the Plasmonic Photon Emission under STM, <i>Songbin Cui</i> , Pohang University of Science and Technology, Republic of Korea; <i>U. Ham</i> , Institute for Basic Science (IBS), Republic of Korea; <i>T.-H. Kim</i> , Pohang University of Science and Technology, Republic of Korea	Invited talk continues.
3:40pm	BREAK - Complimentary Refreshments in Exhibit Hall - Technology Spotlight Sessions in Booth #168, Exhibit Hall	
4:00pm	BREAK - Complimentary Refreshments in Exhibit Hall - Technology Spotlight Sessions in Booth #168, Exhibit Hall	
4:20pm	INVITED: NS+AM+MI+MN+SS+TR-TuA7 Advances in SPM Methods for Energy-relevant Materials, <i>Marina Leite</i> , University of Maryland College Park	INVITED: PC+AS+BI+EM+NS+PB+SS-TuA7 Ambient Pressure X-Ray Photoelectron Spectroscopy Studies of Catalytically Active Interfaces using Electron Transparent Graphene Membranes, <i>R. Mom, L. Frevel, Fritz-Haber Institute of the Max Planck Society, Germany; J.J. Velasco-Velez, MPI CEC Mülheim, Germany; T.E. Jones, M. Plodinec, Fritz-Haber Institute of the Max Planck Society, Germany; R. Schlögl, MPI CEC Mülheim, Germany; Axel Knop-Gericke, Fritz Haber Institute of the Max Planck Society, Germany</i>
4:40pm	Invited talk continues.	Invited talk continues.
5:00pm	NS+AM+MI+MN+SS+TR-TuA9 Coherent Electrical Contact to Semiconducting Graphene Nanoribbon, <i>Chuanxu Ma, L. Liang</i> , Oak Ridge National Laboratory; <i>Z. Xiao</i> , North Carolina State University; <i>A.A. Puretzky, K. Hong</i> , Oak Ridge National Laboratory; <i>W. Lu, J. Bernholc</i> , North Carolina State University; <i>A.-P. Li</i> , Oak Ridge National Laboratory	INVITED: PC+AS+BI+EM+NS+PB+SS-TuA9 The Influence of Density and Chemical Bonding on Atomic and Molecular Structures of Alcohols, Water and Oxides, <i>Gabor A. Somorjai</i> , University of California at Berkeley
5:20pm	NS+AM+MI+MN+SS+TR-TuA10 Visualizing Coordination Structures of Small Gas Molecules to Metallo-porphyrin on Au(111) Using Scanning Tunneling Microscopy, <i>MinHui Chang</i> , Korea University, Republic of Korea; <i>Y.H. Chang, N.Y. Kim</i> , Korea Advanced Institute of Science and Technology (KAIST); <i>U.S. Jeon, H. Kim</i> , Korea University, Republic of Korea; <i>Y.-H. Kim</i> , Korea Advanced Institute of Science and Technology (KAIST), Republic of Korea; <i>S.-J. Kahng</i> , Korea University, Republic of Korea	Invited talk continues.
5:40pm	NS+AM+MI+MN+SS+TR-TuA11 Effects of Dimensionality on the Reactivity of Carboxylic-Acid-Terminated Monolayers, <i>Dominic Goronzy¹, E. Avery, N.M. Gallup</i> , University of California, Los Angeles; <i>J. Staněk, J. Macháček, T. Baše</i> , Institute of Inorganic Chemistry, Academy of Sciences of the Czech Republic; <i>K.N. Houk</i> , Chemistry and Biochemistry, University of California, Los Angeles; <i>P.S. Weiss</i> , University of California at Los Angeles	PC+AS+BI+EM+NS+PB+SS-TuA11 Atomic Scale Observation of Oxidation and Reduction of Palladium Surface, <i>Takehiro Tamaoka, H. Yoshida, S. Takeda</i> , Osaka University, Japan
6:00pm		PC+AS+BI+EM+NS+PB+SS-TuA12 Polymorphism of Hydrogen-Bonded Clusters at the Vacuum-Solid Interface, <i>Angela Silski, J. Petersen</i> , University of Notre Dame; <i>R.D. Brown</i> , Clarkson University; <i>S. Corcelli, S.A. Kandel</i> , University of Notre Dame

¹ NSTD Student Award Finalist

Tuesday Afternoon, October 23, 2018

Plasma Science and Technology Division Room 104A - Session PS+EM+NS+SS-TuA Plasma Processing of Challenging Materials - II Moderators: Michael Gordon, University of California at Santa Barbara, Wei Tian, Applied Materials Inc.		Plasma Science and Technology Division Room 104C - Session PS+PB+SE-TuA Atmospheric Pressure Plasmas Moderators: Francois Reniers, Université Libre de Bruxelles, Steven Vitale, MIT Lincoln Laboratory
2:20pm	INVITED: PS+EM+NS+SS-TuA1 Self-limiting Growth of III-nitride Materials via Hollow-cathode Plasma-ALD: Structural and Chemical Analysis, <i>Necmi Biyikli, A. Mohammad, D. Shukla</i> , University of Connecticut	PS+PB+SE-TuA1 Compact, Low Cost Atmospheric Pressure Plasma Jets Driven by Piezoelectric Transformers, <i>Michael Johnson</i> , National Research Council; <i>D.R. Boris, L. Petrova, S.G. Walton</i> , Naval Research Laboratory
2:40pm	Invited talk continues.	PS+PB+SE-TuA2 Process Regimes of Atmospheric Pressure Plasma-enhanced Chemical Vapor Deposition with Source Materials Highly Diluted in Inert Gases, <i>Seungjae Baik, J. Jang</i> , Hankyong National University, Republic of Korea; <i>H.-J. Oh</i> , Yonsei University, Republic of Korea
3:00pm	PS+EM+NS+SS-TuA3 Electrostatic Charge of Solution-droplet in Plasma-coupled Micro Reactor, <i>Tae Hwan Kim, SW. Lee</i> , National Fusion Research Institute, Republic of Korea	PS+PB+SE-TuA3 Plasma-enhanced Chemical Film Conversion (PECFC): Direct, Low-temperature Growth of Solution-processible and Printable Layered Thin Films, <i>T. Liu, R. Mohan Sankaran</i> , Case Western Reserve University
3:20pm	PS+EM+NS+SS-TuA4 Surfactant-free and Stable Colloidal Metal Oxide Ultra-small Quantum Dots via Plasma-liquid Electrochemistry, <i>Dillibabu Padmanabhan, D. Carolan, R. McGlynn, T. Velusamy, P. Maguire, D. Mariotti</i> , Nanotechnology & Integrated Bio-Engineering Centre, Ulster University, UK	PS+PB+SE-TuA4 Plasma-based Remediation of Nanoscale Particulate Matter in Charbroiler Smoke Emissions, <i>Sisi Yang, S. Subramanian</i> , University of Southern California, Los Angeles; <i>D. Singleton</i> , Transient Plasma Systems; <i>C. Schroeder, W. Schroeder, M. Gundersen, S.B. Cronin</i> , University of Southern California, Los Angeles
3:40pm	BREAK - Complimentary Refreshments in Exhibit Hall - Technology Spotlight Sessions in Booth #168, Exhibit Hall	
4:00pm	BREAK - Complimentary Refreshments in Exhibit Hall - Technology Spotlight Sessions in Booth #168, Exhibit Hall	
4:20pm	PS+EM+NS+SS-TuA7 From Organometallic Precursors to Bimetallic Nanocatalysts using Atmospheric-pressure Plasma Processes, <i>Jeffrey Baneton, J. Mertens, M. Smiljanic, S. Cauchies, T. Segato</i> , Université Libre de Bruxelles, Belgium; <i>Y. Busby</i> , Université de Namur, Belgium; <i>G. Caldarella</i> , Université de Liège, Belgium; <i>V. Debaillé, S. Godet</i> , Université Libre de Bruxelles, Belgium; <i>J.-J. Pireaux</i> , Université de Namur, Belgium; <i>N. Job</i> , Université de Liège, Belgium; <i>M.J. Gordon</i> , University of California at Santa Barbara; <i>R.M. Sankaran</i> , Case Western Reserve University; <i>F. Reniers</i> , Université Libre de Bruxelles, Belgium	PS+PB+SE-TuA7 The Interactions of Atmospheric Pressure Plasma Jets with Surfaces: <i>In situ</i> Measurements of Electron Heating in Materials, <i>Scott Walton</i> , U.S. Naval Research Laboratory; <i>J. Tomko, B.M. Foley</i> , University of Virginia; <i>D.R. Boris</i> , U.S. Naval Research Laboratory; <i>M.J. Johnson</i> , National Research Council; <i>Tz.B. Petrova</i> , U.S. Naval Research Laboratory; <i>A. Giri, P.E. Hopkins</i> , University of Virginia
4:40pm	PS+EM+NS+SS-TuA8 Synthesis of Hydrogenated Amorphous Carbon Nanoparticles using High-Pressure CH ₄ +Ar Plasmas and Their Deposition, <i>Kazunori Koga, S.H. Hwang, K. Kamataki, N. Itagaki</i> , Kyushu University, Japan; <i>T. Nakatani</i> , Okayama University of Science, Japan; <i>M. Shiratani</i> , Kyushu University, Japan	PS+PB+SE-TuA8 Surface Activation by Atmospheric Plasma: the Right Technology for the Right Application, <i>A. Ozkan, D. Merche, Francois Reniers</i> , Université Libre de Bruxelles, Belgium
5:00pm	PS+EM+NS+SS-TuA9 Antimony-doped Tin Oxide Nanocrystals Synthesized by Low Temperature Plasma, <i>Qinyi Chen, E. Thimsen</i> , Washington University in St. Louis	PS+PB+SE-TuA9 Aluminum Alloy Surface Cleaning by Atmospheric Pressure Microwave Discharge, <i>Lucia Bonova, W. Zhu, A. Farrokhpour, D.V. Krogstad, Z.K. Jeckell, S. Chaudhuri, D.N. Ruzic</i> , University of Illinois at Urbana-Champaign
5:20pm	PS+EM+NS+SS-TuA10 Femtosecond Laser Texturing of Plasma-immersed Ti to Create TiN, <i>Chisung Ahn, E. Barlaz, D.N. Ruzic</i> , University of Illinois at Urbana-Champaign	PS+PB+SE-TuA10 Temporal and Spatial Study of a Parallel pin-plate Plasma Reactor, <i>Vladimir Milosavljević, M. Gulan, L. Scally, P.J. Cullen</i> , BioPlasma Research Group, Dublin Institute of Technology, Dublin, Ireland
5:40pm	PS+EM+NS+SS-TuA11 Modeling Chemical Reactions in Contact Glow Discharge Electrolysis, <i>Bocong Zheng, M. Shrestha, K.L. Wang, T. Schuelke, Q.H. Fan</i> , Michigan State University	PS+PB+SE-TuA11 Plasma-modulated Metamaterials and Photonic Crystals, <i>Jeffrey Hopwood, H. Kim</i> , Tufts University
6:00pm	PS+EM+NS+SS-TuA12 Effects of Light Ion Beam Irradiation in Plasma Etching Processes, <i>Kazuhiro Karahashi, T. Ito, H. Li, M. Isobe, K. Mizotani, S. Shigeno</i> , Osaka University, Japan; <i>M. Fukasawa, A. Hirata, T. Tatsumi</i> , Sony Semiconductor Solutions Corporation, Japan; <i>S. Hamaguchi</i> , Osaka University, Japan	PS+PB+SE-TuA12 Generation of Large-Volume Transient Glow Discharge Plasma by an External Fast Ionization Wave (FIW) from a Plasma Jet, <i>Hamid Razavi, M. Laroussi</i> , Old Dominion University

Tuesday Afternoon, October 23, 2018

Reconfigurable Materials and Devices for Neuromorphic Computing Focus Topic Room 203A - Session RM+EM+NS-TuA IoT Session: Reconfigurable Materials and Devices for Neuromorphic Computing Moderators: Gina Adam, National Institute for R&D in Microtechnologies (IMT Bucharest), Brian Hoskins, National Institute of Standards and Technology (NIST)		Advanced Surface Engineering Division Room 202C - Session SE-TuA Wear, Oxidation and Corrosion Protective Coatings Moderators: Suneel Kodambaka, University of California, Los Angeles, Andrey Voevodin, University of North Texas
2:20pm	INVITED: RM+EM+NS-TuA1 Non-volatile Memories for Neuromorphic Computing, <i>Alec Talin</i> , Sandia National Laboratories	INVITED: SE-TuA1 Dissociative Extraction of Carbon-based Tribofilms from Hydrocarbon Molecules on Catalytically Active Nanocomposite Coatings, <i>Ali Erdemir, G. Ramirez, O.L. Eryilmaz</i> , Argonne National Laboratory
2:40pm	Invited talk continues.	Invited talk continues.
3:00pm	INVITED: RM+EM+NS-TuA3 Anionic and Protonic Transfer Materials for ReRAM and Neuromorphic Computing, <i>Jennifer Rupp</i> , Massachusetts Institute of Technology	SE-TuA3 Use of Carbon Nanotube-Silver Metal Matrix Composite Thin Films to Enhance Mechanical Properties of Grid Fingers and Busbars on Photovoltaic Cells, <i>Cayla Nelson</i> , University of New Mexico; <i>O.K. Abudayyeh, Osazda Energy, LLC; Y. Shen, S.M. Han</i> , University of New Mexico
3:20pm	Invited talk continues.	SE-TuA4 Study of Effects of Synergistic Environmental Exposures on Fiber-Reinforce Polymer Composites Protected by Metallic Coatings, <i>Arash Afshar, D. Mihut, S. Hill</i> , Mercer University School of Engineering
3:40pm	BREAK - Complimentary Refreshments in Exhibit Hall - Technology Spotlight Sessions in Booth #168, Exhibit Hall	
4:00pm	BREAK - Complimentary Refreshments in Exhibit Hall - Technology Spotlight Sessions in Booth #168, Exhibit Hall	
4:20pm	INVITED: RM+EM+NS-TuA7 Memristor Neural Networks for Brain-Inspired Computing, <i>Qiangfei Xia</i> , University of Massachusetts Amherst	SE-TuA7 Atomistic View of Mg Metal Corrosion Using <i>in-situ</i> cryo-XPS and <i>ab initio</i> Computation, <i>Vaithiyalingam Shuththanandan, A. Martinez, P.V. Sushko, A. Devaraj, E. Stevens, O.A. Marina, V. Joshi, S. Thevuthasan, V. Murugesan</i> , Pacific Northwest National Laboratory
4:40pm	Invited talk continues.	SE-TuA8 Scratch Behavior and Modelling of Cu/Si(100) Thin Films Deposited by Modulated Pulsed Power Magnetron Sputtering, <i>D. Meng, Y.G. Li, M.K. Lei</i> , Dalian University of Technology, China
5:00pm	RM+EM+NS-TuA9 Indium Phosphide Synaptic Device on Silicon for Scalable Neuromorphic Computing, <i>Jun Tao, D. Sarkar, R. Kapadia</i> , University of Southern California	INVITED: SE-TuA9 Corrosion Resistance of Mechanically Reinforced Aluminium based Coatings obtained by PVD Techniques, <i>Frederic Sanchezette</i> , UTT - Université de Technologie de Troyes, France; <i>J. Creus</i> , Université de La Rochelle, France; <i>A. Billard</i> , FEMTO-ST, France
5:20pm	RM+EM+NS-TuA10 Ultra-low Power Microwave Oscillators based on Phase Change Oxides as Solid-State Neurons, <i>Boyang Zhao, J. Ravichandran</i> , University of Southern California	Invited talk continues.
5:40pm	INVITED: RM+EM+NS-TuA11 Leveraging Nanodevice Volatility for Low Energy Computing Inspired from Nature, <i>Alice Mizrahi</i> , NIST/University of Maryland; <i>T. Hirtzlin</i> , Centre de Nanosciences et Nanotechnologies; <i>B. Hoskins</i> , NIST Center for Nanoscale Science and Technology; <i>A. Fukushima</i> , AIST; <i>A. Madhavan</i> , NIST Center for Nanoscale Science and Technology; <i>H. Kubota, S. Yuasa</i> , AIST; <i>N.B. Zhitenev, J. McClelland, M.D. Stiles</i> , NIST Center for Nanoscale Science and Technology; <i>D. Querlioz</i> , Centre de Nanosciences et Nanotechnologies, France; <i>J. Grollier</i> , UMR CNRS/Thales	SE-TuA11 High Temperature Mechanical Properties of CrAlN and CrAlSiN Hard Coatings, <i>Aljaž Drnovšek, M. Rebelo de Figueiredo, A. Xia, Montanuniversität Leoben, Austria; S. Kolozsvári, Plansee Composite Materials GmbH, Germany; H. Vo, P. Hosemann, University of California Berkeley; R. Franz, Montanuniversität Leoben, Austria</i>
6:00pm	Invited talk continues.	SE-TuA12 Thick CrN/AlN Superlattice Coatings for Solid Particle Erosion and High Temperature Wear Resistant Applications, <i>Jianliang Lin</i> , Southwest Research Institute

Tuesday Afternoon, October 23, 2018

Surface Science Division Room 203C - Session SS+HC+MI-TuA Oxides/Chalcogenides: Structures and Reactions Moderator: Andrew Teplyakov, University of Delaware		Thin Films Division Room 104B - Session TF+PS-TuA Atomic Layer Processing: Chemistry & Surface Reactions for Atomic Layer Processing Moderators: Jessica Kachian, Intel Corporation, Keren Kanarik, Lam Research Corporation
2:20pm	INVITED: SS+HC+MI-TuA1 New Eyes for Nanocatalysis: Atomic Scale Investigations of TiO ₂ Chemistry, <i>Melissa Hines</i> , Cornell University	INVITED: TF+PS-TuA1 N-heterocyclic Carbenes on Au and Cu Surfaces, <i>Cathleen Cruden</i> , Queen's University, Canada
2:40pm	Invited talk continues.	Invited talk continues.
3:00pm	SS+HC+MI-TuA3 Coverage-dependent Water Agglomerates on Fe ₃ O ₄ Surfaces, <i>Zdenek Jakub</i> , Vienna University of Technology, Austria; <i>M. Meier</i> , University of Vienna, Austria; <i>J. Hulva, J. Pavelec, M. Setvin, M. Schmid, U. Diebold</i> , Vienna University of Technology, Austria; <i>C. Franchini</i> , University of Vienna, Austria; <i>G.S. Parkinson</i> , Vienna University of Technology, Austria	TF+PS-TuA3 Enhancing Nucleation in Platinum Atomic Layer Deposition by Surface Pre-Treatment with Small Organometallic Molecules, <i>Camila de Paula, L. Zeng, S.F. Bent</i> , Stanford University
3:20pm	SS+HC+MI-TuA4 Reversible Structural Evolution and Identification of the Catalytically Active Phase of NiCo _{0.8} H _y During the Oxygen Evolution Reaction (OER), <i>Bruce E. Koel</i> , Princeton University	TF+PS-TuA4 Mass Spectrometer Studies of Volatile Etch Products Produced by Ligand-Exchange Reactions During Thermal Atomic Layer Etching, <i>Joel Clancey, A.S. Cavanagh, S.M. George</i> , University of Colorado Boulder
3:40pm	BREAK - Complimentary Refreshments in Exhibit Hall - Technology Spotlight Sessions in Booth #168, Exhibit Hall	
4:00pm		
4:20pm	SS+HC+MI-TuA7 Understanding the Growth and Chemical Activity of Titania-Supported MoS _x Clusters, <i>Donna Chen</i> , University of South Carolina; <i>R.P. Galhenage</i> , University of California at Irvine; <i>H. Yan</i> , University of Louisiana Lafayette; <i>D. Le, T.B. Rawal, T.S. Rahman</i> , University of Central Florida	INVITED: TF+PS-TuA7 Beyond Conventional Lithography – Using Self-assembly to Create Patterns for New Device Fabrication Techniques, <i>Michael Morris</i> , Trinity College Dublin, Ireland
4:40pm	SS+HC+MI-TuA8 Analyzing Single Atom Catalysts using Low Energy Ion Scattering (LEIS), <i>Thomas Grehl</i> , IONTOF GmbH, Germany; <i>R. ter Veen</i> , Tascon GmbH, Germany; <i>D. Kunwar, A. Dotye</i> , University of New Mexico; <i>H.H. Brongersma</i> , IONTOF GmbH and Tascon GmbH, Germany	Invited talk continues.
5:00pm	SS+HC+MI-TuA9 Synthesis and Characterization of Metals Supported on ZnO Nanoparticles, <i>Amanda Haines, D.F. Ferrah, J.C. Hemminger</i> , University of California at Irvine	TF+PS-TuA9 Calculations of Etch Products from Thermal Atomic Layer Etching Using Fluorination and Ligand-Exchange Reactions, <i>Andrew Cavanagh, J.W. Clancey, S. Sharma, S.M. George</i> , University of Colorado at Boulder
5:20pm	SS+HC+MI-TuA10 Molecular Water Adsorption and Reactions on α -Al ₂ O ₃ (0001) and α -Alumina Particles, <i>Greg Kimmel, N.G. Petrik</i> , Pacific Northwest National Laboratory; <i>P.L. Huestis, J.A. LaVerne</i> , University of Notre Dame; <i>A.B. Aleksandrov, T.M. Orlando</i> , Georgia Institute of Technology	TF+PS-TuA10 Formation of Monolayers and Multilayers During the Vapor-Phase Deposition of Dodecanethiols on Copper Oxide, <i>David Bergsman, T-L. Liu, R.G. Closser, S.F. Bent</i> , Stanford University
5:40pm	SS+HC+MI-TuA11 Applying Low Temperature Titration for Determination of Metallic Sites on Active Oxide Supported Catalysts, <i>Jerry Pui Ho Li, Z. Liu, Y. Yang</i> , ShanghaiTech University, China	TF+PS-TuA11 Exchange Reactions During Atomic Layer Deposition: ZnO Conversion to Al ₂ O ₃ by Trimethylaluminum, <i>Tyler Myers, A.M. Cano, J.W. Clancey, D.K. Lancaster, S.M. George</i> , University of Colorado at Boulder
6:00pm	SS+HC+MI-TuA12 Giant Optical Anisotropy in Hexagonal Perovskite Chalcogenides with Quasi-1D Structures, <i>Shanyuan Niu</i> , University of Southern California; <i>G. Joe</i> , University of Wisconsin - Madison; <i>H. Zhao, M. Mecklenburg</i> , University of Southern California; <i>T. Tiwald, J.A. Woollam Co. Inc</i> ; <i>K. Mahalingam</i> , Air Force Research Laboratory; <i>H. Wang</i> , University of Southern California; <i>M. Kats</i> , University of Wisconsin - Madison; <i>J. Ravichandran</i> , University of Southern California	TF+PS-TuA12 3D Feature Profile Simulation Coupled with Realistic Plasma Surface Reaction Model for ALE Process, <i>YeongGeun Yook, H.S. You, J.H. Park</i> , Chonbuk National University, Republic of Korea; <i>D.H. You, KW Tech, Republic of Korea</i> ; <i>K.S. Choi</i> , Chonbuk National University, Republic of Korea; <i>W.S. Chang</i> , National Fusion Research Institute, Republic of Korea

Tuesday Afternoon, October 23, 2018

Thin Films Division Room 102A - Session TF+SS-TuA Organic/Inorganic Materials and Interfaces Moderator: Matthew Richard Linford, Brigham Young University		Vacuum Technology Division Room 203B - Session VT-TuA IoT Session: Vacuum System Design and Automation & Flash Networking Session Moderators: Julia Scherschligt, National Institute of Standards and Technology, Martin Wuest, INFICON
2:20pm	TF+SS-TuA1 Chemical Interactions at Hybrid Interfaces: An In Situ Investigation of Organic/Inorganic Systems, <i>Sven Pletinck</i> , Vrije Universiteit Brussel, Belgium; <i>L. Trotochaud</i> , Lawrence Berkeley Lab, University of California, Berkeley; <i>L.-L. Fockaert, M. Meusen, J.M.C. Mol</i> , Technical University Delft, Netherlands; <i>H. Bluhm</i> , Lawrence Berkeley Lab, University of California, Berkeley; <i>H. Terryn, T. Hauffman</i> , Vrije Universiteit Brussel, Belgium	INVITED: VT-TuA1 The Importance of Vacuum Cleanliness in Semiconductor Process Control SEM Tools, <i>Irit Ruach Nir</i> , Applied Materials, Israel; <i>M. Eilon, K. Luria, G. Eytan</i> , Applied Materials
2:40pm	TF+SS-TuA2 Microscopic and Spectroscopic evidence of Odd-Even Effect in Self-Assembled Monolayers of Biphenyl-Substituted Fatty Acid on Ag(111), <i>Anna Krzykawska</i> , Jagiellonian University, Polska; <i>P. Cyganik, M. Szwed, J. Ossowski</i> , Jagiellonian University, Poland	Invited talk continues.
3:00pm	INVITED: TF+SS-TuA3 CVD of Thin Polymer Films for Engineered Material Properties, <i>AnnaMaria Coclite</i> , Graz University of Technology, Austria	INVITED: VT-TuA3 Vacuum Chamber Design and Fabrication., <i>Steve Greuel</i> , Nor-Cal Products
3:20pm	Invited talk continues.	Invited talk continues.
3:40pm	BREAK - Complimentary Refreshments in Exhibit Hall - Technology Spotlight Sessions in Booth #168, Exhibit Hall	
4:00pm		
4:20pm	TF+SS-TuA7 Organosilicon Functionally Nanostructured Films as Engineered Interlayers for Hybrid Materials, <i>Vladimir Cech</i> , Brno University of Technology, Czech Republic; <i>J. Houdkova</i> , Institute of Physics, Academy of Sciences of the Czech Republic; <i>M. Branecky, T. Plichta</i> , Brno University of Technology; <i>J. Zemek</i> , Institute of Physics, Academy of Sciences of the Czech Republic	INVITED: VT-TuA7 Compact Ultra High Vacuum Systems for Applications of Cold Matter, <i>Evan Salim, S. Hughes, M.A. Perez, D.Z. Anderson</i> , ColdQuanta Inc.
4:40pm	TF+SS-TuA8 Studying Electron Induced Chemical Changes of Hafnium Oxide-Methacrylate EUV Photoresists with <i>In Situ</i> IR Spectroscopy and Model Flat Surfaces, <i>Yasiel Cabrera, E. Mattson, K. Oyekan, Y. Wang, Y.J. Chabal</i> , University of Texas at Dallas	Invited talk continues.
5:00pm	TF+SS-TuA9 Photoactivated Molecular Layer Deposition of Fluoropolymer Thin Films, <i>Richard Closser</i> , Stanford University; <i>M. Lillethorup, Radisurf Aps</i> , Denmark; <i>D.S. Bergsman, J. Shi, S.F. Bent</i> , Stanford University	INVITED: VT-TuA9 Plasma Window as Vacuum Atmosphere Interface for Various Applications, <i>Ady Hershcovitch</i> , Brookhaven National Laboratory
5:20pm	TF+SS-TuA10 Sputter-Deposited Porous Coatings for Solid Phase Microextraction, <i>Tuhin Roychowdhury, D.I. Patel, M.R. Linford</i> , Brigham Young University	Invited talk continues.
5:40pm	TF+SS-TuA11 Interfacial Electron Transfer of Ferrocene Immobilized onto Indium Tin Oxide through Noncovalent Interactions, <i>Caitlin Hanna, J. Yang</i> , University of California, Irvine	VT-TuA11 Applications of IoT in Vacuum Technology, <i>Jacob Ricker, J. Hendricks</i> , NIST
6:00pm	TF+SS-TuA12 Vapor Phase Infiltration of Polymers with Intrinsic Microporosity: Structure and Chemical Separation Performance, <i>Mark Losego, E.K. McGuinness, F. Zhang, R. Lively</i> , Georgia Institute of Technology	VTD FLASH NETWORKING SESSION

Tuesday Afternoon, October 23, 2018

Exhibitor Technology Spotlight Workshops
Room Hall A - Session EW-TuAB
Exhibitor Technology Spotlight Session III
Moderator: Christopher Moffitt, Kratos Analytical Inc

3:40pm	
4:00pm	EW-TuAB2 eSpectra, your Data, and your Collaborations, <i>Jessica Hoy</i> , AIPP/AVS

Tuesday Evening Poster Sessions, October 23, 2018

Extending Additive Manufacturing to the Atomic Scale

Focus Topic

Room Hall B - Session AM-TuP

Extending Additive Manufacturing to the Atomic Scale

Poster Session

6:30pm

AM-TuP1 Direct-Write Fabrication of 3D Nano-Probes for Thermal Microscopy, *J. Sattelkow, J. Froeh, R. Winkler*, Graz University of Technology, Austria; *C. Schwalb, E.J. Fantner*, GETec Microscopy Inc., Austria; *Harald Plank*, Graz University of Technology, Austria

AM-TuP2 Laser Induced Formation of Eutectic Nanostructures in Al-Cu Powder for Additive Manufacturing, *Jonathan Skelton, C.V. Headley, J.A. Floro, J.M. Fitz-Gerald*, University of Virginia

Biomaterial Interfaces Division

Room Hall B - Session BI-TuP

Biomaterial Interfaces Division Poster Session

Moderator: Joe Baio, Oregon State University

6:30pm

BI-TuP1 An Ultrasensitive, Selective, Multiplexed Superbioelectronic NoseThat Mimics the Human Sense of Smell, *Sungeun Seo, O.S. Kwon*, Korea Research Institute of Bioscience & Biotechnology(KRIBB), Republic of Korea

BI-TuP2 Graphene Field-effect Transistor Microfluidics Sensor for Real-time Bacteria Detection, *KyungHo Kim, J.Y. Lee*, Korea Research Institute of Bioscience & Biotechnology(KRIBB), Republic of Korea

BI-TuP3 Stimuli-responsive Thin Films made from Highly Methoxylated Citrus Pectin, *Zeinab Veisi, N. Alcantar, R. Toomey*, University of South Florida

BI-TuP4 Fluorescent DNA Nanosphere Barcdoe System by Rolling Circle Amplification for Tumor Cells Detection, *SW. Han, JongBum Lee*, University of Seoul, Republic of Korea

BI-TuP5 Conducting Polymer Nanotubes-based Field Effect Transistor Dopamine sensor, *Jyeon Lee, S.Y. Park*, Korea Research Institute of Bioscience & Biotechnology(KRIBB), Republic of Korea

BI-TuP6 A study of Dopamine Receptor D1 Agonism and Antagonism Using GPCR-based FET biosensor, *Sanghyuck Lee*, Korea Research Institute of Bioscience and Biotechnology (KRIBB), Republic of Korea; *S.J. Park*, Korea Research Institute of Bioscience & Biotechnology(KRIBB), Republic of Korea

BI-TuP7 Vapor-Deposited Porous Polymers for the Fabrication of Giant Lipid Vesicles, *Nareh Movsesian, M.T. Matthew Tittensor, G. Dianat, N.M. Malmstadt, M. Gupta*, University of Southern California

BI-TuP8 Developing a pH Responsive Hydrogel for the Encapsulation of Poly(ethylene glycol) 3350, *Phuong Anh Nguyen¹, B. Matheson, D. Cuylear, H.E. Canavan*, University of New Mexico

BI-TuP9 Hemocompatibility of the Endexo™ Fluoro-oligomeric Surface, *Bill Theilacker*, Medtronic; *J. Ho, J. Swenor*, Interface Biologics; *M.F. Wolf, J.L. Kalscheuer, S. Thinamany*, Medtronic; *S. Ubl*, medtronic

BI-TuP10 High Performance Dopamine Sensor Based on Field-Effect Transistor (FET) with Human Dopamine Receptor Integrated Multidimensional Conducting Polymer Nanofiber, *JinYeong Kim, S.J. Park*, Korea Research Institute of Bioscience and Biotechnology (KRIBB), Republic of Korea

BI-TuP11 Detection of B-type Natriuretic Peptide in Human Serum Based on Flexible Biosensors and Data Analysis Methodology, *Xinruo Yi, A. Khalaf, R. Gunasekeran, M.H. Yun, M. Akcakaya*, University of Pittsburgh; *Y.Z. Zhang, S. Marc, N. Petroni*, UPMC

BI-TuP12 Characterizing Hetero-oligomer of Amyloid-beta and Alpha-synuclein with Bio-AFM, *Eun Ji Shin, J.W. Park*, Pohang University of Science and Technology, Republic of Korea

BI-TuP13 Creation of de novo Nucleic Acid Binding Disordered Proteins using the Thermally Responsive Behavior of Elastin-like Polypeptides, *Telmo Diez, G.P. Lopez, N.J. Carroll*, University of New Mexico

Spectroscopic Ellipsometry Focus Topic

Room Hall B - Session EL-TuP

Spectroscopic Ellipsometry Focus Topic Poster Session

Moderator: Tino Hofmann, University of North Carolina at Charlotte

6:30pm

EL-TuP1 An In situ Spectroscopic Ellipsometry Study of Cerium Oxidation, *Wayne Lake, P. Roussel*, AWE, UK

EL-TuP2 In-situ Multi-wavelength Ellipsometric Monitoring of the Reactive Sputter Deposition of WO_x Films, *Ned Ianno, G. Kaufman, C. Luth*, University of Nebraska-Lincoln; *C. Exstrom, S.A. Darveau*, University of Nebraska at Kearney; *B. Johs*, Film Sense

EL-TuP3 Mid-infrared Optical Constants of InAsSb Alloys and Bulk GaSb, *Pablo Paradis, S. Zollner, R. Carrasco*, New Mexico State University, Department of Physics; *J. Carlin, V. Dahiya, A. Kazemi, S. Krishna*, The Ohio State University, Department of Electrical and Computer Engineering

EL-TuP4 Temperature-dependent Ellipsometry and Thermal Stability of $Ge2Sb2Te5:C$ Phase Change Memory Alloys, *Cesy Zamarripa, N. Samarasingha, F. Abadizaman, R. Carrasco, S. Zollner*, New Mexico State University

In-situ Microscopy, Spectroscopy, and Microfluidics Focus Topic

Room Hall B - Session MM-TuP

In-situ Microscopy, Spectroscopy, and Microfluidics Focus Topic Poster Session

6:30pm

MM-TuP1 In-situ Low Energy Electron Microscopy at Near Ambient Pressures, *Thomas Schulmeyer*, SPECS Surface Nano Analysis GmbH

MM-TuP2 NanoESCA III: Recent Progress and Applications, *M. Merkel, N.B. Weber, M. Escher, T.-J. Kühn*, FOCUS GmbH, Germany; *Marten Patt*, Scienta Omicron GmbH, Germany

Manufacturing Science and Technology Group

Room Hall B - Session MS-TuP

Topics in Manufacturing Science and Technology Poster Session

6:30pm

MS-TuP1 Formation of High Entropy Film for Cutting Tool by Magnetron Sputtering, *Ki Buem Kim*, Sejong University, Republic of Korea; *T. Choi, Sejong university, Korea, Republic of Korea; H.Y. Lee*, Korea Institute of Industrial Technology, Republic of Korea; *J.K. Lee*, Kongju National University, Republic of Korea; *Y.S. Kim*, Sejong University, Republic of Korea; *Y.K. Park, K.S. Kim, S.I. Jeong*, YG-1 Co. LTD, Republic of Korea

MS-TuP2 Plasma Diagnostics Technique using Floating Harmonic Method for Pulsed Plasma Monitoring, *Yusin Kim*, Samsung Electronics, Republic of Korea; *CW. Chung*, Hanyang University, Republic of Korea; *J. Kim*, Samsung Electronics, Republic of Korea

MS-TuP3 Trace Level Detection of Gas Impurities Using Atmospheric Pressure Ionization Mass Spectrometry, *Gregory Thier*, Extrel CMS

MS-TuP4 Novel Safe Approach to Process Gas Delivery, *Richard Elzer*, Entegris; *K.W. Olander*, Retired co-founder of ATMI Corp

MS-TuP5 Advanced Characterization to Support Development of Next Generation Phosphors, *Vincent Smentkowski, R. Davis, J. Murphy, A. Setlur, M. Butts, J. Lu*, General Electric Global Research Center; *W. Beers*, Current by GE

Plasma Biology, Agriculture, and Environment Focus Topic

Room Hall B - Session PB-TuP

Plasma Biology, Agriculture, and Environment Focus Topic Poster Session

6:30pm

PB-TuP1 Detection of Metallic Ions in Solution Using Optical Emission Spectroscopy of Plasma Driven by Bipolar Pulsed Power Sources, *Ching-Yu Wang, C.-C. Hsu*, National Taiwan University, Taiwan, Republic of China

¹ National Student Award Finalist

Tuesday Evening Poster Sessions, October 23, 2018

Processing and Characterization of Air-Liquid, Solid-Liquid and Air-Solid Interfaces Focus Topic

Room Hall B - Session PC+AS+BI+EM+NS+PB+SS-TuP

Processing and Characterization of Gas-Liquid, Solid-Liquid, and Gas-Solid Interfaces

6:30pm

PC+AS+BI+EM+NS+PB+SS-TuP1 Operando Photoelectron Spectroscopic Study of Copper-based Oxide Semiconductor Interface with Water, *Pitambar Sapkota, S. Ptasinska*, University of Notre Dame; *A. Cabrera*, Instituto de Física, Pontificia Universidad Católica de Chile

PC+AS+BI+EM+NS+PB+SS-TuP2 Interfacial Water in Silicon-based Catalytic Motors, *Jordi Fraxedas, K. Zhang, B. Sepulveda, M.J. Esplandiu*, Catalan Institute of Nanoscience and Nanotechnology (ICN2), CSIC and BIST, Spain; *X. Garcia, J. Llorca*, Institute of Energy Technologies, Department of Chemical Engineering and Barcelona Research Center in Multiscale Science and Engineering, Universitat Politècnica de Catalunya, Spain; *V. Perez-Dieste, C. Escudero*, Alba Synchrotron Light Source, Spain

PC+AS+BI+EM+NS+PB+SS-TuP3 Chiral Modification of Oxide-Supported Pt Surfaces: An in-situ ATR-IR Study, *Yufei Ni*, University of California, Riverside; *F. Zaera*, University of California, Riverside

PC+AS+BI+EM+NS+PB+SS-TuP4 Wettability Behaviour of Synthesized Carbon Nanospheres and its Application as a Photocatalyst, *Sonal Singhal, A.K. Shukla*, IIT Delhi, India

PC+AS+BI+EM+NS+PB+SS-TuP5 Thermally Driven Solid-solid Li⁺ Transfer into Nanostructured TiO₂, *Tiffany Kaspar, T. Varga*, Pacific Northwest National Laboratory; *D.A. Shapiro*, Advanced Light Source, Lawrence Berkeley National Laboratory; *A. Martinez, Y. Shin, K.S. Han, M.-S. Lee, S. Thevuthasan, V. Murugesan*, Pacific Northwest National Laboratory

Plasma Science and Technology Division

Room Hall B - Session PS-TuP

Plasma Science and Technology Division Poster Session

6:30pm

PS-TuP1 Surface Modification for the Enhancement of the Patterning Margin by Using Plasma Treatment, *Wanjae Park, L. Huli, S.D. Chae, A. Ko, P. Biolsi*, TEL Technology Center, America, LLC

PS-TuP2 N₂/H₂, O₂ and NF₃ Dissociation Percentages in a Remote, Low Frequency, High Density Plasma Source, *Yingliang Zhou, H. Li, V.M. Donnelly*, University of Houston; *J. Chiu, X. Chen*, MKS Instruments, Inc., Pressure and Vacuum Measurement Group

PS-TuP3 Thermal Atomic Layer Etching of Silicon and Silicon Nitride Using an Oxidation and "Conversion-Etch" Mechanism, *Aziz Abdulagatov, S.M. George*, University of Colorado at Boulder

PS-TuP4 Annihilation Kinetics of Plasma-induced Electronic Defects in Semiconductor Materials, *S. Nunomura, Isao Sakata, K. Matsubara*, National Institute of Advanced Industrial Science and Technology (AIST), Japan

PS-TuP5 High efficiency Magnetic Induction Plasma Source for Remote Plasma Removal Process, *TaeSeung Cho, S. Park, D. Lubomirsky*, Applied Materials

PS-TuP6 Aspect-ratio and Line-edge Fluctuation Controlled Nanolithography using Poly(styrene-*b*-Dimethylsiloxane) and Amorphous Carbon Layer, *Jisoo Oh, G.Y. Yeom*, Sungkyunkwan University, Republic of Korea

PS-TuP7 Development of A Low-Cost ZnO Nanorods-Based Gas Sensor with an Integerated Microplasma Generation Unit for Ethanol Sensing, *Sz-Yun Lin, F.-H. Huang, C.-C. Hsu*, National Taiwan University, Taiwan, Republic of China

PS-TuP8 Development of a Plasma Generation Device Integrated with a Piezoelectric Spray to Detect Metal Ions in Solution, *Ting-Ting Pan, S.-Y. Lin, C.-C. Hsu*, National Taiwan University, Taiwan, Republic of China

PS-TuP9 Development of a Light-weight System for Detection of Metal Ions in Solutions Using Plasma Spectroscopy, *Ching-Yu Su, S.-Y. Lin, C.-C. Hsu*, National Taiwan University, Taiwan, Republic of China

PS-TuP10 Inductively Coupled Plasma Reactive Ion Etching of Nanometer-scale Patterned Copper Thin Films using Alcohol-based Gases, *Jinsu Ryu, E.T. Lim, D.W. Park, C.W. Chung*, INHA University, Republic of Korea

PS-TuP11 Etch Characteristics of Nanometer-scale Patterned Cu Thin Film Using Pulse-modulated RF Source Plasma, *Euntaek Lim, J.S. Ryu, C.W. Chung*, INHA University, Republic of Korea

PS-TuP12 Etch Characteristics of Magnetic Tunneling Junction Materials by Using Noble Gas and Hydrogen, *SooGang Kim, K.C. Yang, Y.J. Shin, D.I. Sung, G.Y. Yeom*, Sungkyunkwan University, Republic of Korea

PS-TuP13 Particle Temperature Histories in a Tubular Low Temperature Plasma Reactor: Relevance to the Synthesis of Amorphous Metal Alloys, *N.B. Uner, Elijah Thimsen*, Washington University in St. Louis

PS-TuP14 Building Tailored Chemistry Sets for Plasma Modelling using a Statistical Approach Embedded in an Online Engine, *Sebastian Mohr, G. Evans, A. Dzoraso*, Quantemol Ltd., UK; *M. Virdee*, University College London, UK

PS-TuP15 Easy Synthesis of Hybrid Laterally or Vertically Patterned Hydrophobic/Hydrophilic Surfaces using a Dielectric Barrier Discharge, *Annaëlle Demaude*, Université Libre de Bruxelles, Belgique; *M.J. Gordon*, University of California at Santa Barbara; *F. Reniers*, Université Libre de Bruxelles, Belgum

PS-TuP16 Plasma-based Approach to Driving an Amorphous-To-Crystalline Phase Change in MoS₂ Grown on Polymers, *S.G. Walton, D.R. Boris*, U.S. Naval Research Laboratory; *A.C. Kozen*, American Society for Engineering Education; *Gary Kushta*, U.S. Naval Research Laboratory; *M.J. Johnson*, National Research Council; *R.H. Rai*, University of Dayton; *N.R. Glavin*, Air Force Research Laboratory; *C. Muratore*, University of Dayton

PS-TuP17 Atmospheric Plasma Deposition of Vanadium Oxide Thin Coatings on Cold and Heated Substrates, *Antoine Remy*, Université Libre de Bruxelles, Belgum; *M.J. Gordon*, University of California at Santa Barbara; *F. Reniers*, Université Libre de Bruxelles, Belgum

PS-TuP18 The Increased Efficiency Of The Amorphous/Silicon Heterojunction Solar Cells With Silicon Micro-Channels In Back Side Substrate, *Hugo Alvarez, G.L. Bertão, A.R. Silva, F.H. Ciodin, J.A. Diniz*, University of Campinas, Brazil

PS-TuP19 Effect of RF Plasma on H Radical Generation on DCMS Produced a-Si:H, *Jan Uhlig, E. Barlaz, D.N. Ruzic*, University of Illinois at Urbana-Champaign

PS-TuP20 Hardmasks of TiN and Al for Silicon Micro-Channel Definition via ICP Plasma Etching Process, *Camila Ruiz*, Plasma Nanotechnology Research Center, UNICAMP, Brazil; *J.A. Diniz, A.M. Rosa*, Plasma Nanotechnology Research Center, University of Campinas, Brazil

PS-TuP21 Time- and space-resolved Diagnostics of a Self-Neutralized Ion Beam Extracted from a Pulsed Plasma, *Ryan Sawadichai, Y.-M. Chen*, University of Houston; *S. Tian*, Lam Research Corporation; *V.M. Donnelly, P. Ruchhoeft, D.J. Economou*, University of Houston

PS-TuP22 Vacuum-ultraviolet-radiation Damage of Low-k Dielectrics, *J. Leon Shohet, S.-H. Kim, H.M. Nguyen, P. Xue, J. Blatz, H. Cheng*, University of Wisconsin-Madison; *Y.-H. Lin*, NSRRC, Taiwan; *J.-F. de Marneffe, M. Redzheb, S. Armini*, IMEC, Belgium; *C.-C. Chen*, NSRRC, Taiwan; *Y. Wu*, University of Wisconsin-Madison

PS-TuP23 Porous Alumina as a Vacuum Ultraviolet Transmission Window, *Yuting Wu, H. Cheng*, University of Wisconsin-Madison; *Y.-H. Lin, C.-C. Chen, H.-S. Fung*, NSRRC, Taiwan; *J.L. Shohet*, University of Wisconsin-Madison

PS-TuP24 Frequency Response of Microwave Excited Argon Microplasmas using Continuum Simulations, *Ayyaswamy Venkattraman, A.K. Verma*, University of California Merced

PS-TuP25 Development of an In-situ Plasma Enhanced Atomic Layer Etching System for III-group Nitride Device Process, *C.P. Lin, Y.H. Lin, C.C. Chen, M.K. Wang*, National Applied Research Laboratories, Taiwan, Republic of Korea; *C.N. Hsiao*, National applied research Laboratories, Taiwan, Republic of Korea; *F.Z. Chen*, National Applied Research Laboratories, Taiwan, Republic of Korea

PS-TuP26 Advances in the Spectroscopic Characterization of Ceramic Films and Coatings, *Fuhe Li, A. Tavakoli, J. Brim*, Air Liquide Electronics - Balazs NanoAnalysis

PS-TuP27 Effect of Plasma Configuration on Defect-free Functional Doping on Graphene Surface, *Goo-Hwan Jeong, S.-I. Jo*, Kangwon National University, Republic of Korea

PS-TuP28 Fluid Model Numerical Simulation Analysis of Microwave Plasma Discharges, *Wan-Ting Chiu*, National Tsing-Hua University, Taiwan, Taiwan, Republic of China; *I.N. Yeh, K.C. Leou*, National Tsing-Hua University, Taiwan, Republic of China

PS-TuP29 Evaluation of Simulation Tool for a Plasma Generation based on the Dual Property of Electrons, *Shinichiro Kitamoto, P. Abraha*, Meijo University, Japan

PS-TuP30 Plasma Nitriding of Highly Polished Metallic Surfaces, *Yoshiki Handa, P. Abraha*, Meijo University, Japan

Tuesday Evening Poster Sessions, October 23, 2018

Reconfigurable Materials and Devices for Neuromorphic

Computing Focus Topic Poster Session

Room Hall B - Session RM-TuP

6:30pm

RM-TuP1 Selector-less Crossbar Array through Self-rectifying Characteristic of Pt/HfO₂/Ti Memristor, **Yong Kim, S.Y. Ryu, W.H. Jeong**, Seoul National University of Science and Technology, Republic of Korea; **K.-S. Min**, Kookmin University, Republic of Korea; **B.J. Choi**, Seoul National University of Science and Technology, Republic of Korea

RM-TuP2 Electron Beam Induced Current Microscopy of Interfacial Barrier Effects in Al₂O₃/TiO_x Resistive Switches, **Brian Hoskins**, National Institute of Standards and Technology (NIST); **G. Adam**, National Institute for R&D in Microtechnologies (IMT Bucharest), Romania; **E. Strelcov**, National Institute of Standards and Technology (NIST)/University of Maryland; **A. Kolmakov, N.B. Zhitenev**, National Institute of Standards and Technology (NIST); **D. Strukov**, University of California at Santa Barbara; **J. McClelland**, National Institute of Standards and Technology (NIST)

RM-TuP3 Ion-insertion Electrodes for Brain Inspired Computing, **Elliot Fuller**, Sandia National Laboratories; **S.T. Keene**, Stanford University; **Z. Wang**, University of Massachusetts Amherst; **S. Agarwal, R.B. Jacobs-Gedrim, J. Niroula, C. Bayley, U. Sohi**, Sandia National Laboratories; **A. Melianas, Y. Tuchman**, Stanford University; **M.J. Marinella**, Sandia National Laboratories; **J.J. Yang**, University of Massachusetts Amherst; **A. Salleo**, Stanford University; **A. Talin**, Sandia National Laboratories

Advanced Surface Engineering Division

Room Hall B - Session SE-TuP

Advanced Surface Engineering Division Poster Session

6:30pm

SE-TuP1 Deposition and Characterization of Ga-doped TaON Thin Films, **J.H. Hsieh, Shi Jie Lin**, Ming Chi University of Technology, Taiwan, Republic of China

SE-TuP2 Fabrication of Porous Membranes of Controlled Porosity and Chemical Functionality, **Golnaz Dianat, M. Gupta, S. Seidel, M.M. Deluna**, University of Southern California

SE-TuP3 Plasma Treatment of Thiol-Carbon Self-Assembled Monolayers on Copper, **Michelle Paquette, R. Thapa, L. Dorsett, S. Malik, S. Wagner, A.N. Caruso**, University of Missouri-Kansas City; **D. Merrill, J.D. Bielefeld, S.W. King**, Intel Corporation

SE-TuP4 Improved Light Extraction Efficiency using Homeotropic Thin Films on SiO₂ Micro Pillars, **J.H. Lee, Y. Lin, G. Wu**, Chang Gung University, Taiwan

SE-TuP5 Investigating the Influence of Substrate Cleaning on the Solution Stability of Plasma Polymer Films, **Karyn Jarvis**, Swinburne University of Technology, Australia; **S.L. McArthur**, Swinburne University of Technology and CSIRO, Australia

SE-TuP6 Tribological Systems Solutions for Gas Turbine Engines, **Pantcho Stoyanov**, Pratt & Whitney

SE-TuP7 Effect of Laser Processing on the Atmospheric Corrosion Behavior of Mg Alloy AZ31B and Weldments, **M.A. Melia**, Sandia National Laboratories; **L. Agnew, J.M. Skelton, J.R. Scully, James Fitz-Gerald**, University of Virginia

Surface Science Division

Room Hall B - Session SS-TuP

Surface Science Division Poster Session

6:30pm

SS-TuP1 Encapsulation of Metallic Nanoparticles near the Surface of Graphite, **Ann Lii-Rosales¹², P.A. Thiel**, Iowa State University and Ames Laboratory

SS-TuP2 Uncovering the Mechanism of Thermal Dry Etching of Cobalt Thin Films Using Hexafluoroacetylacetone (hfacH), **Mahsa Konh, J. Zhao, A.V. Teplyakov**, University of Delaware

SS-TuP3 Revealing the Atomic Scale Insights for CO₂ Dissociation on the Rh(111) Surfaces at Ambient Pressure, **Won Hui Doh**, Institute for Basic Science (IBS), Republic of Korea; **J. Kim**, Institute for Basic Science (IBS), Republic of Korea; **J.Y. Park**, Institute for Basic Science (IBS), Republic of Korea

SS-TuP4 Study of Spin Dependent Electrochemical Charge Transfer Across the Ferromagnetic Electrode/Solution Interface, **Mika Tamski, F. Blumenschein, C. Roussel, J.-P. Ansermet**, Ecole Polytechnique Fédérale de Lausanne, Switzerland

SS-TuP5 Two-faced Steps: How Molecular Alignment does and does not Impacts O₂ Sticking Dynamics on Pt., **K. Cao**, Leiden University, Nederland; **M. Kurashiki**, National Institute for Materials Science, Japan; **Ludo Juurlink**, Leiden University, Nederland

SS-TuP6 Secondary Electron Emission from Borosilicate Glass Under Electron Impact, **C. Li**, University of Science and Technology of China; **L. Repetto**, Università di Genova, Italy; **Z.J. Ding**, University of Science and Technology of China, China; **Karoly Tokesi**, Institute for Nuclear Research, Hungarian Academy of Sciences (ATOMKI), Hungary

SS-TuP7 Crystallinity-Transport Investigations of Nanoscale Ru Conductors at Al₂O₃ and/or SiO₂ Interfaces, **Asim Khaniya, S. Ezzat, W.E. Kaden, K.R. Coffey**, University of Central Florida

SS-TuP8 Iron Oxide Surface Transformations Revealed by AP-XPS for Ammonia Synthesis, **Mikhail Trought**, Michigan Technological University; **E.J. Crumlin, S. Nemsak**, Advanced Light Source, Lawrence Berkeley National Laboratory; **K.A. Perrine**, Michigan Technological University

SS-TuP9 Surface Energies of Thin Oxides of Si(100) as Function of Thickness, Composition and Surface Processing, **Saaketh Narayan, J.M. Day, N. Herbots, A. Brimhall, A. Mascarenho**, Arizona State University; **A. Krishnan**, Harvard University; **S.D. Whaley**, Arizona State University; **R.B. Bennett-Kennett**, Stanford University; **K.L. Kavanagh**, Simon Fraser University, Canada

SS-TuP10 Space Weathering Effects at the Surface of Thin-Film Aluminosilicate Model Regolith, **Bijoya Dhar, W.E. Kaden**, University of Central Florida

SS-TuP11 Identification of Surface Processes in Individual Minerals of a Complex Ore through the Analysis of Polished Sections using Polarization Microscopy and X-ray Photoelectron Spectroscopy (XPS), **Dhamelyz Silva Quiñones**, UTEC, Perú; **C.H. He**, University of Delaware; **J.C. Rodriguez**, UTEC, Perú; **A.V. Teplyakov**, University of Delaware; **C. Benndorf**, UTEC, Perú

SS-TuP12 Effect of Surface Roughness, Etch Pits, and Adsorbates on the Surface Phonon Density of States of Graphite, **Krishnan Swaminathan-Gopalan, K. Stephani**, University of Illinois at Urbana-Champaign

SS-TuP13 Variation of Structure Colors of Copper with LIPSS(Laser-Induced Periodic Surface Structure) by Femtosecond Laser Irradiation, **TaeHoon Park, J.H. Kim, T.Y. Hwang, J.J. Kang**, Korea Institute of Industrial Technology (KITECH), Republic of Korea; **K.B. Kim**, Sejong University, Republic of Korea; **H.S. Lee**, Korea Institute of Industrial Technology (KITECH), Republic of Korea

SS-TuP14 Bio-synthesis of Finely Distributed Ag Nanoparticle-decorated TiO₂ Nanorods for Sunlight-induced Photoelectrochemical Water Splitting, **Moo Hwan Cho, S.Y. Sawant, M.S. Sayed, T.H. Han, J.-J. Shim**, Yeungnam University, Republic of Korea

SS-TuP15 Oxidation of Nb(100) and Kinetics of Surface to Bulk Transport and Extension to Nb₃Sn, **Rachael Farber, D.R. Veit, S.J. Sibener**, The University of Chicago

MORT TRAUM FINALISTS

SS-TuP1 Encapsulation of Metallic Nanoparticles near the Surface of Graphite, **Ann Lii-Rosales³⁴, P.A. Thiel**, Iowa State University and Ames Laboratory

SS+EM+PS+TF-ThA10 (SS-TuP16) Adsorption and Reactions on Topological Insulators Surfaces Probed by Low Energy Ion Scattering, **Haoshan Zhu⁵, W. Zhou, J.A. Yarmoff**, University of California – Riverside

SS+AS+EM-WeA10 (SS-TuP17) In-situ Characterization of Photon induced Chemistries in Organotin Clusters with Ambient Pressure XPS, **J. Trey Diulus⁶, R.T. Frederick**, Oregon State University; **M. Li**, Rutgers, the State University of New Jersey; **D.C. Hutchison, I. Lyubinetsky, L. Árnadóttir, M.R. Olsen**, Oregon State University; **E.L. Garfunkel**, Rutgers, the State University of New Jersey; **M. Nyman**, Oregon State University; **H. Ogasawara**, SLAC National Accelerator Laboratory; **G.S. Herman**, Oregon State University

SS+HC+MI-MoM3 (SS-TuP18) Probing the Effects of Surface Structure on the Dissociative Chemisorption of Methane, **Eric High⁷, D.G. Tinney, A.L. Utz**, Tufts University

HC-ThP3 (SS-TuP19) Activity of Bimetallic Pt-Re Surfaces and Influence of the Support for the Water-Gas Shift Reaction, **Amy Brandt⁸, T.D. Maddumapatabandi, D. Shakya, S. Farzandh, D.A. Chen**, University of South Carolina

¹ Morton S. Traum Award Finalist

² National Student Award Finalist

³ Morton S. Traum Award Finalist

⁴ National Student Award Finalist

⁵ Morton S. Traum Award Finalist

⁶ Morton S. Traum Award Finalist

⁷ Morton S. Traum Award Finalist

⁸ Morton S. Traum Award Finalist

Tuesday Evening Poster Sessions, October 23, 2018

Tribology Focus Topic

Room Hall B - Session TR-TuP

Tribology Focus Topic Poster Session

6:30pm

TR-TuP1 Measurements of Microscale Friction on Molybdenum Disulfide using an Integrated Quartz Crystal Microbalance and Nanoindentation System, *Brian Borovsky, G.R. McAndrews, R.J. Wieser, St. Olaf College*

TR-TuP2 Sliding Wear Behavior of Tool Steel Functionalized with Organic Monolayers Against Aluminum, *Stephan Prünte, D. Music, RWTH Aachen University, Germany; V.L. Terziyska, C. Mitterer, Montanuniversität Leoben, Austria; J.M. Schneider, RWTH Aachen University, Germany*

Vacuum Technology Division

Room Hall B - Session VT-TuP

Vacuum Technology Division - Poster Session

6:30pm

VT-TuP1 Characterization and Imaging of Surface Acoustic Waves on GaAs with Raman Spectroscopy, *Brian Rummel, University of New Mexico; M.D. Henry, Sandia National Laboratory; S.M. Han, University of New Mexico*

VT-TuP2 Sapphire MEMS based Capacitance Manometer for Vacuum Freeze-Drying Device, *Masashi Sekine, M. Soeda, T. Ishihara, M. Nagata, Azbil Corporation, Japan*

VT-TuP3 Development of Vacuum Equipment Trainer (VET) Systems for Off-site Students, *Delmer Smith, N. Louwagie, Normandale Community College*

VT-TuP4 Vacuum System of the SuperKEKB Main Ring in the Phase - 2 Commissioning, *Yusuke Suetsugu, K. Shibata, T. Ishibashi, M. Shirai, S. Terui, K. Kanazawa, H. Hisamatsu, KEK, Japan*

VT-TuP5 Smart Diagnostics for Dry Vacuum Pumps Running in Semiconductor Processes, *Won-Sup Cheung, J. Lim, KRISS, Republic of Korea; N.K. LEE, J.B. LEE, T.J. Park, T.H. Kim, SK Hynix, Republic of Korea*

VT-TuP6 Commissioning of Vacuum System for Positron Damping Ring for SuperKEKB, *Kyo Shibata, Y. Suetsugu, T. Ishibashi, M. Shirai, S. Terui, K. Kanazawa, H. Hisamatsu, KEK, Japan*

VT-TuP7 Development of a Measurement System for Pressures in Vacuum Regions using an Optical Method, *Yoshinori Takei, K. Arai, H. Yoshida, Y. Bitou, S. Telada, T. Kobata, National Institute of Advanced Industrial Science and Technology (AIST), Japan*

VT-TuP8 Study on a Performance of a Sniffer Leak Detector based on EN 14624, *Kenta Arai, H. Yoshida, National Institute of Advanced Industrial Science and Technology (AIST), Japan*

VT-TuP9 Elimination of Electron-Beam-Induced Carbonaceous Contamination in SEMs and the new RGM 10100 NIST Contamination Testing Artifact, *Andras Vlador, K. Purushotham, National Institute of Standards and Technology (NIST)*

VT-TuP10 PAL-XFEL Vacuum System, *Donghyun Na, Pohang Accelerator Laboratory, Republic of Korea*

VT-TuP11 Extreme 2 Million Liter/sec Hydrogen Pump Speed Measurements of C-2W Divertors, *Ernesto Barraza-Valdez, A. Van Drie, TAE Technologies*

VT-TuP12 KICT Dirty Thermal Vacuum Chamber: design, fabrication, and performance test, *T. Chung, Korea Institute of Civil Engineering and Building Technology, Republic of Korea; Jong Yeon Lim, Korea Research Institute of Standards and Science, Republic of Korea; Y. Yoo, hss. Shin, Korea Institute of Civil Engineering and Building Technology, Republic of Korea*

Anticipated Schedule Wednesday, October 24, 2018

Anticipated Schedule Wednesday Morning, October 24

8:00 AM	_____
8:20 AM	_____
8:40 AM	_____
9:00 AM	_____
9:20 AM	_____
9:40 AM	_____
10:00 AM	_____
10:20 AM	_____
10:40 AM	_____
11:00 AM	_____
11:20 AM	_____
11:40 AM	_____
12:00 PM	_____

Anticipated Schedule Wednesday Lunch, October 24

When	_____
Where	_____
With	_____

Anticipated Schedule Wednesday Afternoon, October 24

1:00 PM	_____
1:20 PM	_____
1:40 PM	_____
2:00 PM	_____
2:20 PM	_____
2:40 PM	_____
3:00 PM	_____
3:20 PM	_____
3:40 PM	_____
4:00 PM	_____
4:20 PM	_____
4:40 PM	_____
5:00 PM	_____
5:20 PM	_____
5:40 PM	_____
6:00 PM	_____

Special Events Wednesday

Special Events Wednesday

6:15 AM AVS 38th Annual 5 km Run (Register at the 5 km Booth before Wednesday)/TBD, Offsite
7:30 AM AVS Diversity & Inclusion Committee Breakfast/Tides Restaurant-Hyatt Regency (by invitation)
8:00 AM ASED Business Meeting/Shoreline-Hyatt Regency
8:15 AM ASED Executive Committee Meeting & Lunch/Shoreline-Hyatt Regency (by invitation)
10:00 AM AVS Member Center: Diversity and Inclusion--"Inclusion and Diversity at the Workplace: Your Suggestions for Best Practices"/103C
10:00 AM Session Coffee Break/Hall A
12:20 PM Exhibit Hall Lunch/Hall A
12:20 PM NSTD Graduate Student and Postdoc Award Competitions/102B
12:20 PM PSTD Coburn and Winters Adjudication Session (Closed Session)/104A (by invitation)
12:30 PM AVS Member Center: Professional Development--"XPS for the Non-Analyst" & Lunch/103C
12:30 PM Governance Committee Meeting and Lunch/Tides Restaurant-Hyatt Regency (by invitation)
12:30 PM PacSurf Committee Meeting & Lunch/Tides Restaurant-Hyatt Regency (by invitation)
1:00 PM Biointerphases Strategic Planning Meeting/Seaview A-Hyatt Regency (by invitation)
3:00 PM AVS Member Center: Professional Development--"Get Involved: How to Moderate and Lead Conference Sessions"/103C
3:40 PM Session Refreshment Break/Hall A
4:30 PM Exhibitors & Manufacturers' Reception (Invitation Only)/Hall A (by invitation)
5:30 PM Heterogeneous Catalysis Graduate Student Presentation Awards Reception/201A
6:30 PM AVS Awards Ceremony & Reception/Grand Ballroom
8:30 AM-5:00 PM Short Course Program/Various Rooms

Wednesday Morning, October 24, 2018

2D Materials Focus Topic Room 201B - Session 2D+AM+EM+NS-WeM Dopants, Defects, and Interfaces in 2D Materials Moderator: Eric Pop, Stanford University		Actinides and Rare Earths Focus Topic Room 202C - Session AC+MI+SA-WeM Magnetism, Complexity, and Superconductivity in the Actinides and Rare Earths Moderators: Melissa Denecke, University of Manchester, UK, David Geeson, AWE, UK, James Tobin, UW Oshkosh
8:00am	2D+AM+EM+NS-WeM1 Carbon Doping of 2D Transition Metal Dichalcogenides by Plasma Enhanced CVD, <i>Yanfu Lu, F. Zhang, S. Sinnott, M. Terrones</i> , The Pennsylvania State University	INVITED: AC+MI+SA-WeM1 Strong electron-electron Interactions in the Actinides: Using Organometallics to Probe Delocalization Effects, <i>Corwin Booth</i> , Lawrence Berkeley National Laboratory
8:20am	2D+AM+EM+NS-WeM2 Methoxy Formation Induced Defects on MoS ₂ *, <i>Duy Le</i> , University of Central Florida; <i>P. Evans</i> , University of Nebraska - Lincoln; <i>Z. Hooshmand</i> , University of Central Florida; <i>T.B. Rawal</i> , Oak Ridge National Laboratory; <i>L. Bartels</i> , University of California, Riverside; <i>P.A. Dowben</i> , University of Nebraska-Lincoln; <i>T.S. Rahman</i> , University of Central Florida	Invited talk continues.
8:40am	INVITED: 2D+AM+EM+NS-WeM3 Defect Engineering of 2D Materials for Advanced Electronic Devices, <i>Gwan-Hyoung Lee</i> , Yonsei University, Republic of Korea	INVITED: AC+MI+SA-WeM3 Structure and Magnetism of U-based Thin Films and Heterostructures, <i>Evgeniya Tereshina-Chitrova</i> , Institute of Physics, Academy of Sciences of the Czech Republic; <i>L. Havela</i> , Charles University, Prague, Czech Republic; <i>T. Gouder, Z. Bao</i> , Institute for Transuranium Elements, Germany; <i>M. Dopita</i> , Charles University, Prague, Czech Republic; <i>R. Caciuffo</i> , Institute for Transuranium Elements, Germany
9:00am	Invited talk continues.	Invited talk continues.
9:20am	2D+AM+EM+NS-WeM5 Modeling Defects and Electron-electron Interactions in Low-dimensional Materials, <i>Daniel Gunlycke, C.E. Ekuma</i> , U.S. Naval Research Laboratory	INVITED: AC+MI+SA-WeM5 Field Induced Lifshitz Transitions in URu ₂ Si ₂ , <i>E.J. Calegari</i> , Univ Federale Santa Maria, Brazil; <i>S.G. Magalhaes</i> , Universidade Federale Rio Grande do Sul, Brazil; <i>Peter Riseborough</i> , Temple University
9:40am	2D+AM+EM+NS-WeM6 Post-Synthesis Modifications of Two-Dimensional MoSe ₂ or MoTe ₂ by Incorporation of Excess Metal Atoms into the Crystal Structure, <i>Paula Mariel Coelho</i> , University of South Florida; <i>H. Komsa</i> , Aalto University, Finland; <i>H. Coy Diaz, Y. Ma</i> , University of South Florida; <i>A.V. Krasheninnikov</i> , Institute of Ion Beam Physics and Materials Research, Germany; <i>M. Batzill</i> , University of South Florida	Invited talk continues.
10:00am		
10:20am	BREAK - Complimentary Coffee in Exhibit Hall – Technology Spotlight Sessions in Booth #168, Exhibit Hall	
10:40am		
11:00am	2D+AM+EM+NS-WeM10 Dry Cleaning and Doping of MX ₂ for Contact Engineering, <i>Daniil Marinov</i> , IMEC, Belgium; <i>J. Ludwig</i> , IMEC & KU Leuven, Belgium; <i>D. Chiappe</i> , IMEC, Belgium; <i>E. Voronina, T. Rakhimova</i> , Skobeltsyn Institute of Nuclear Physics, Lomonosov Moscow State University; <i>J.-F. de Marneffe, I. Asselberghs</i> , IMEC, Belgium; <i>S. De Gendt</i> , IMEC, KU Leuven, Belgium	AC+MI+SA-WeM10 New Form of Uranium Hydride - UH ₂ , <i>Ladislav Havela, M. Paukov, M. Dopita, L. Horak, P. Minarik, M. Divis, I. Turek</i> , Charles University, Prague, Czech Republic; <i>D. Legut</i> , VSB-Technical University of Ostrava, Czech Republic; <i>T. Gouder, A. Seibert, F. Huber</i> , European Commission - Joint Research Centre; <i>E.A. Tereshina-Chitrova</i> , Institute of Physics, Academy of Sciences of the Czech Republic
11:20am	2D+AM+EM+NS-WeM11 Deep Learning for Atomically-Resolved Scanning Transmission Electron Microscopy Experiments on 2D Materials, <i>Maxim Ziatdinov, S.V. Kalinin</i> , Oak Ridge National Laboratory	AC+MI+SA-WeM11 Tuning of Electronic Properties of U- and RE-Metallic Systems by H Absorption, <i>Silvia Maskova</i> , Charles University, Prague, Czech Republic; <i>K. Miliyanchuk</i> , Ivan Franko National University of Lviv, Lviv, Ukraine; <i>A. Kolomiets</i> , Lviv Polytechnic National University, Lviv, Ukraine; <i>L. Havela</i> , Charles University, Prague, Czech Republic
11:40am	2D+AM+EM+NS-WeM12 Magnetic Doping in 2D MBE-grown-MoSe ₂ /graphene Heterostructures Studied by Photoelectron Spectroscopy and Band Structure Imaging, <i>Maxime Gay, O.J. Renault</i> , CEA-LETI, France; <i>MT. Dau, C. Vergnaud, M. Jamet</i> , CEA-INAC-SPINTEC, France	AC+MI+SA-WeM12 Magnetic Structures of U _n RhIn _{3n+2} Materials, <i>Attila Bartha, M. Klicpera</i> , Charles University, Prague, Czech Republic; <i>P. Cermak</i> , Forschungszentrum Juelich GmbH, Germany; <i>B. Ouladdiaf</i> , Institute Laue-Langevin, France; <i>J. Custers</i> , Charles University, Prague, Czech Republic
12:00pm		AC+MI+SA-WeM13 Insights into the Magnetic Dead Layer in La _{0.7} Sr _{0.3} MnO ₃ Thin Films from Temperature, Magnetic Field and Thickness Dependence of their Magnetization, <i>Navid Mottaghi, S. Seehra, R. Trappen, S. Kumari, C.-Y. Huang, S.F. Yousefi, G.B. Cabrera, A. Romero, M.B. Holcomb</i> , West Virginia University

Wednesday Morning, October 24, 2018

Extending Additive Manufacturing to the Atomic Scale Focus Topic Room 102B - Session AM+NS+SS-WeM Nanofabrication with Focused Electron Beams (8:00-10:00 am)/Atomic Scale Manipulation with Focused Electron Beams (11:00 am-12:20 pm) Moderator: Ondrej Dyck, Oak Ridge National Laboratory		Applied Surface Science Division Room 204 - Session AS+NS+SA-WeM Beyond Traditional Surface Analysis Moderators: Mark Engelhard, Pacific Northwest National Laboratory, Kathryn Lloyd, DuPont Corporate Center for Analytical Sciences
8:00am	INVITED: AM+NS+SS-WeM1 3D Nano-Printing via Focused Electron Beams: An Emerging Technology for Novel Applications, <i>Harald Plank, R. Winkler, J. Sattekow</i> , Graz University of Technology, Austria; <i>J.D. Fowlkes</i> , Oak Ridge National Laboratory; <i>P.D. Rack</i> , University of Tennessee Knoxville	AS+NS+SA-WeM1 Solar Wind Interaction with Carbonate Deposits on Asteroid (1) Ceres' Surface: The Role of Surface Analysis in Laboratory Planetary Science, <i>Catherine Dukes, G. Rodriguez Lopez, C. Bu</i> , University of Virginia
8:20am	Invited talk continues.	AS+NS+SA-WeM2 Looking Deeper and Smaller: Enhancing XPS by Hard X-ray Probes and High-resolution Imaging, <i>Olivier Renault</i> , CEA/LETI-University Grenoble Alpes, France; <i>C. Zborowski</i> , University of Southern Denmark; <i>J.-P. Rueff</i> , Synchrotron SOLEIL, L'orme des Merisiers, France; <i>Y. Yamashita, S. Ueda</i> , NIMS, Japan; <i>G.A. Gruen</i> , Lyon Institute of Nanotechnology, France; <i>S. Tougaard</i> , University of Southern Denmark
8:40am	INVITED: AM+NS+SS-WeM3 3D Nanoprinting using an Electron Beam: Simulations and Computer-aided Design, <i>Jason Fowlkes</i> , Oak Ridge National Laboratory; <i>R. Winkler</i> , Graz Centre for Electron Microscopy, Austria; <i>B.B. Lewis</i> , Carl Zeiss Microscopy, LLC; <i>A. Fernandez-Pacheco, L. Skoric, D. Sanz-Hernandez</i> , University of Cambridge; <i>M.G. Stanford, E. Mutunga, P.D. Rack</i> , University of Tennessee; <i>H. Plank</i> , Graz University of Technology, Austria	INVITED: AS+NS+SA-WeM3 Reenvisioning Amphiphilicity: Translating Cell Membrane Design Principles to Synthetic 2D Materials, <i>Shelley Clardige</i> , Purdue University
9:00am	Invited talk continues.	Invited talk continues.
9:20am	INVITED: AM+NS+SS-WeM5 2D/3D Nano-printed Functional Structures for Application and Device Development using Focused Electron Beams, <i>Michael Huth</i> , Institute of Physics, Goethe University, Frankfurt am Main, Germany	AS+NS+SA-WeM5 Microstructural Effects on Surface Potential of Amorphous Solid Water, <i>Caixia Bu, C.A. Dukes</i> , University of Virginia
9:40am	Invited talk continues.	AS+NS+SA-WeM6 Speciation and Reactivity of Organic Matter in Uranium Mine Wastes from Laguna- New Mexico: An Application of Surface Sciences in Environmental Systems., <i>Carmen A. Velasco, A.M. Ali</i> , University of New Mexico; <i>C. Osburn</i> , North Carolina State University; <i>K. Artyushkova, J.M. Cerrato</i> , University of New Mexico
10:00am		
10:20am	BREAK - Complimentary Coffee in Exhibit Hall – Technology Spotlight Sessions in Booth #168, Exhibit Hall	
10:40am		
11:00am	INVITED: AM+NS+SS-WeM10 Single Atom Scale Manipulation of Matter by Scanning Transmission Electron Microscopy, <i>Stephen Jesse, O. Dyck, S.V. Kalinin</i> , Oak Ridge National Laboratory	AS+NS+SA-WeM10 Optical Constants Measured for Iridium and Samarium by Reflection Electron Energy-loss Spectroscopy Spectra, <i>LiHao Yang, H. Xu</i> , University of Science and Technology of China; <i>A. Sulyok, M. Menyhard</i> , Institute for Technical Physics and Materials Science Centre for Energy Research, Hungarian Academy of Sciences (MTA); <i>K. Tokesi</i> , Institute for Nuclear Research, Hungarian Academy of Sciences (ATOMKI); <i>Z.J. Ding</i> , University of Science and Technology of China
11:20am	Invited talk continues.	AS+NS+SA-WeM11 X-Ray Photoelectron Spectroscopy and Electrical Modeling of Electrowetting on Dielectric Devices, <i>Pinar Aydogan Gokturk</i> , Bilkent University, Turkey; <i>B. Ulugut, S. Suzer</i> , Bilkent University, Turkey
11:40am	INVITED: AM+NS+SS-WeM12 Single Atom Modification of 2D Materials: Fabrication and Electronic Structure, <i>Demie Kepaptsoglou, F. Hage</i> , SuperSTEM Laboratory, UK; <i>T. Susi, J. Kotakoski, J. Meyer</i> , University of Vienna, Austria; <i>Y.C. Lin, K. Suenaga</i> , National Institute of Advanced Industrial Science and Technology (AIST), Japan; <i>T. Hardcastle</i> , University of Leeds, UK; <i>U. Bangert</i> , University of Limerick, Republic of Ireland; <i>J.A. Amani, H. Hofsaess</i> , University of Göttingen, Germany; <i>Q. Ramasse</i> , SuperSTEM Laboratory, UK, United Kingdom of Great Britain and Northern Ireland	AS+NS+SA-WeM12 Near Ambient Pressure XPS Study of Oxygen Binding to the Surface of Transition Metal-nitrogen-carbon Electrocatalysts for Oxygen Reduction, <i>K. Artyushkova, Yechuan Chen, P. Atanassov</i> , University of New Mexico
12:00pm	Invited talk continues.	AS+NS+SA-WeM13 Surface Chemistry of Scandium, <i>Michael Brumbach, D.A. Casalnuovo, E.V. Barnat, C. Winters, D. Robinson Brown, C.S. Snow, A.M. Grillet</i> , Sandia National Laboratories
12:20pm	NSTD Graduate Student and Postdoc Award Competitions	

Wednesday Morning, October 24, 2018

Electronic Materials and Photonics Division Room 101A - Session EM+AN+MI+SS-WeM Surface and Interface Challenges in Electronics and Photonics Moderators: Andy Antonelli, Nanometrics, Michael Filler, Georgia Institute of Technology		Fundamental Discoveries in Heterogeneous Catalysis Focus Topic Room 201A - Session HC+SS-WeM Mechanisms and Reaction Pathways of Heterogeneously Catalyzed Reactions Moderator: Johan Gustafson, Lund University
8:00am	INVITED: EM+AN+MI+SS-WeM1 Few Monolayer Atomic Layer Deposition (ALD) to Engineer New Surfaces and Interfaces, <i>Parag Banerjee</i> , Washington University in St. Louis	HC+SS-WeM1 Surface Reactions of Methanol on $\text{Fe}_3\text{O}_4(001)$ and $\text{Pd}/\text{Fe}_3\text{O}_4(001)$ Model Catalysts, <i>Matthew Marcinkowski, N. Doudin, R.S. Smith, B.D. Kay, Z. Dohnalek</i> , Pacific Northwest National Laboratory
8:20am	Invited talk continues.	HC+SS-WeM2 Hydrogen Activation and Spillover on Single Palladium Atoms Supported on $\text{Fe}_3\text{O}_4(001)$ Surface, <i>Nassar Doudin</i> , Pacific Northwest National Laboratory; <i>J. Cheng Liu</i> , Tsinghua University, China; <i>M.D. Marcinkowski, M.-T. Nguyen</i> , Pacific Northwest National Laboratory; <i>J. Li</i> , Tsinghua University, China; <i>V.-A. Glezakou</i> , Pacific Northwest National Laboratory; <i>G.S. Parkinson</i> , Vienna University of Technology, Austria; <i>R. Rousseau, Z. Dohnálek</i> , Pacific Northwest National Laboratory
8:40am	EM+AN+MI+SS-WeM3 Lattice-alignment mechanism of SiGe on Sapphire, <i>HyunJung Kim</i> , National Institute of Aerospace; <i>S. Choi</i> , NASA Langley Research Center	INVITED: HC+SS-WeM3 Model Studies on Ligand-assisted Heterogeneous Catalysis, <i>Swetlana Schauermann</i> , Christian-Albrechts-University Kiel, Germany
9:00am	EM+AN+MI+SS-WeM4 An Effort to Resolve Band Offset Anomalies in ZnO/GaN Heterostructures, <i>Monu Mishra</i> ¹ , <i>A. Gundimeda, V. Vandana, G. Gupta</i> , CSIR-National Physical Laboratory, India	Invited talk continues.
9:20am	EM+AN+MI+SS-WeM5 Stress Relaxation in the Si-SiO ₂ System and its Influence on the Interface Properties, <i>Daniel Kropman, T. Laas</i> , Tallinn University, Estonia; <i>A. Medvids</i> , Riga Technical University, Latvia	HC+SS-WeM5 <i>In situ</i> Structural Studies and Gas Phase Visualization of Model Catalysts at Work, <i>Sara Blomberg</i> ² , <i>J. Zetterberg, J. Zhou, J. Gustafson, E. Lundgren</i> , Lund University, Sweden
9:40am	EM+AN+MI+SS-WeM6 Unique Sensitivity to Deep Trap States Demonstrated by CREM of Broad Bandgap Dielectric Layers, <i>Hagai Cohen</i> , Weizmann Institute of Science, Israel; <i>K.X. Steirer</i> , Colorado School of Mines	HC+SS-WeM6 Adsorption, Thermal Stability, and Kinetics of Atomic Oxygen at $\text{Ag}(111)$ and $\text{Ag}(110)$ Surfaces, <i>Sara Isbill</i> ² , <i>S. Roy</i> , University of Tennessee Knoxville
10:00am	BREAK - Complimentary Coffee in Exhibit Hall – Technology Spotlight Sessions in Booth #168, Exhibit Hall	
10:20am	BREAK - Complimentary Coffee in Exhibit Hall – Technology Spotlight Sessions in Booth #168, Exhibit Hall	
10:40am	BREAK - Complimentary Coffee in Exhibit Hall – Technology Spotlight Sessions in Booth #168, Exhibit Hall	
11:00am	EM+AN+MI+SS-WeM10 Fabrication of Multilayered Optically Active Nanocrystal Solids by Surface Passivation using Metal Oxides: ALD vs CVD, <i>Riya Bose, A.D. Dangerfield</i> , University of Texas at Dallas; <i>S.M. Rupich</i> , University of Texas; <i>Y.J. Chabal, A.V. Malko</i> , University of Texas at Dallas	HC+SS-WeM10 Understanding the Intrinsic Surface Reactivity of Multilayer vs. Single-layer $\text{PdO}(101)$ on $\text{Pd}(100)$, <i>Jason Weaver, V. Mehar</i> , University of Florida; <i>M. Kim</i> , Ohio State University; <i>M. Shipilin</i> , Lund University, Sweden; <i>M. van den Bossche</i> , Chalmers University of Technology, Gothenburg, Sweden; <i>J. Gustafson</i> , Lund University, Sweden; <i>L. Merte</i> , Chalmers University of Technology, Gothenburg, Sweden; <i>U. Hejral</i> , Lund University, Sweden; <i>E. Lundgren</i> , Lund University, Sweden; <i>A. Asthagiri</i> , Ohio State University
11:20am	EM+AN+MI+SS-WeM11 The Role of Surface Oxides for the Optoelectronic Performance of III-V Semiconductor Nanowires, <i>J. Colvin, A. Troian, O. Persson, A. Mikkelsen, Rainer Timm</i> , Lund University, Sweden	HC+SS-WeM11 Simultaneous Study of Catalyst Structure, Gas Phase and Morphology, <i>Sebastian Pfaff, J. Zhou, S. Albertin</i> , Lund University, Sweden; <i>M. Shipilin</i> , Stockholm University, Sweden; <i>J. Gustafson, S. Blomberg, E. Lundgren, J. Zetterberg</i> , Lund University, Sweden
11:40am	EM+AN+MI+SS-WeM12 Photonic Annealing of 2D Transition Metal Dichalcogenides for Tailored Optical Properties, <i>Rachel Rai, K. Giesebe</i> , University of Dayton; Air Force Research Laboratory; <i>N.R. Glavin, R. Kim, A. Jawaid, R. Wheeler, L. Bissell</i> , Air Force Research Laboratory; <i>C. Muratore</i> , University of Dayton	INVITED: HC+SS-WeM12 New Catalysis for Light Alkanes – From Methane Functionalization to Light Akenes, <i>Johannes Lercher</i> , Pacific Northwest National Laboratory and TU München, United States of America/Germany
12:00pm	EM+AN+MI+SS-WeM13 Polarity Control of GaN Nanowires on Diamond: Experiment and Theory, <i>Karin Larsson</i> , Uppsala University, Sweden; <i>M. Hetzl, M. Kraut, T. Hoffmann, M. Stutzmann</i> , Technical University Munich, Germany	Invited talk continues.

¹ National Student Award Finalist

² Heterogeneous Catalysis Graduate Student Presentation Award Finalist

Wednesday Morning, October 24, 2018

Industrial Physics Forum Room 101B - Session IPF+AS+BI+NS-WeM IoT Session: Bioanalytics, Biosensors and Diagnostics Moderators: Anna Belu, Medtronic, Sally McArthur, Swinburne University of Technology and CSIRO, Australia		MEMS and NEMS Group Room 202B - Session MN+NS+PS-WeM IoT Session: Multiscale Manufacturing: Enabling Materials and Processes Moderators: Susan Burkett, The University of Alabama, Roya Maboudian, University of California, Berkeley
8:00am		INVITED: MN+NS+PS-WeM1 Miniaturizing 3D Printed Microfluidics: State-of-the-Art and Outlook, <i>Greg Nordin</i> , Brigham Young University
8:20am		Invited talk continues.
8:40am	INVITED: IPF+AS+BI+NS-WeM3 Harnessing Bacteria for Fabrication of Photoelectrodes and Pressure Sensors, <i>Y. Feng, K.E. Marusak, Y. Cao, E. Ngaboyamahina, J. Glass, L. You, Stefan Zauscher</i> , Duke University	MN+NS+PS-WeM3 A Novel Inkjet Printing Technology Based on Plasma Conversion of Metal-Salt Based Inks for the Fabrication of Microfabricated Sensors, <i>Y. Sui, R.M. Sankaran, Christian Zorman</i> , Case Western Reserve University
9:00am	Invited talk continues.	MN+NS+PS-WeM4 Full Wafer Thickness Through Silicon Vias for MEMS Devices, <i>Andrew Hollowell, E. Baca, D. Dagel, M.B. Jordan, L. Menk, K. Musick, T. Pluym, J. McClain</i> , Sandia National Laboratories
9:20am	INVITED: IPF+AS+BI+NS-WeM5 Surface Chemistry and Surface Analysis: Their Importance and Application in Industrial Genomics, <i>Fiona Black</i> , Illumina Inc.	MN+NS+PS-WeM5 Scaling from Die Level to Full 150 mm Wafer TSV Filling through Fluid Dynamics Modeling and Current Controlled Deposition, <i>Ehren Baca, M.B. Jordan, L. Menk, K. Musick, P. Yeh, A.E. Hollowell</i> , Sandia National Laboratories
9:40am	Invited talk continues.	MN+NS+PS-WeM6 Batch Level Electroless Under Bump Metallization for Singulated Semiconductor Die, <i>Matthew Jordan, E. Baca, J. Pillars, C. Michael, A.E. Hollowell</i> , Sandia National Laboratories
10:00am	BREAK - Complimentary Coffee in Exhibit Hall – Technology Spotlight Sessions in Booth #168, Exhibit Hall	
10:20am	BREAK - Complimentary Coffee in Exhibit Hall – Technology Spotlight Sessions in Booth #168, Exhibit Hall	
10:40am	BREAK - Complimentary Coffee in Exhibit Hall – Technology Spotlight Sessions in Booth #168, Exhibit Hall	
11:00am	INVITED: IPF+AS+BI+NS-WeM10 Design and Evaluation of Organosilica Nanosensors for Continuous Molecular Monitoring in Complex Biological Environments, <i>Simon Corrie</i> , Monash Univ., Melbourne AU	INVITED: MN+NS+PS-WeM10 MEMS-based Atomic Force Microscopy Probes: From Electromechanical to Optomechanical Vibrating Sensors, <i>Bernard Legrand</i> , LAAS-CNRS, France; <i>L. Schwab</i> , LAAS-CNRS, Univ Toulouse, France; <i>P. Allain, I. Favero</i> , MPQ, CNRS, Univ Paris Diderot, France; <i>M. Faucher, D. Théron</i> , IEMN, CNRS, Univ Lille, France; <i>B. Walter</i> , Vmicro SAS, France; <i>J.P. Salvetat</i> , CRPP, CNRS, Univ Bordeaux, France; <i>S. Hentz, G. Jourdan</i> , CEA-LETI, France
11:20am	Invited talk continues.	Invited talk continues.
11:40am	INVITED: IPF+AS+BI+NS-WeM12 Optoregulated Biointerfaces, <i>Aránzazu del Campo</i> , INM-Leibniz Institute for New Materials, Germany	MN+NS+PS-WeM12 Suppressing Secondary Grain Growth in $Sc_{0.125}Al_{0.875}N$ Using a CMOS Compatible Electrode, <i>Giovanni Esteves, M. Berg, M.D. Henry, B.A. Griffin, E.A. Douglas</i> , Sandia National Laboratories
12:00pm	Invited talk continues.	MN+NS+PS-WeM13 A Low Voltage NEMS Relay. Design, Fabrication and Challenges, <i>A. Solot, A. Dinescu</i> , National Institute for R&D in Microtechnologies (IMT), Bucharest, Romania; <i>M. Fernandez-Bolaños, A.M. Ionescu</i> , École Polytechnique Fédérale de Lausanne (EPFL), Lausanne, Switzerland; <i>Gina Adam</i> , National Institute for R&D in Microtechnologies (IMT Bucharest), Romania

Wednesday Morning, October 24, 2018

Nanometer-scale Science and Technology Division Room 203A - Session NS+2D+AN+MN+MP+SE-WeM Micro, Nano and Opto Mechanics Moderators: Robert Ilic, National Institute of Standards and Technology, Alokik Kanwal, NIST Center for Nanoscale Science and Technology		Processing and Characterization of Air-Liquid, Solid-Liquid and Air-Solid Interfaces Focus Topic Room 202A - Session PC+AS+BI+EM+PB+SS-WeM Novel Approaches and Challenges of Interfaces Moderators: Andrei Kolmakov, National Institute of Standards and Technology (NIST), Xiao-Ying Yu, Pacific Northwest National Laboratory
8:00am		INVITED: PC+AS+BI+EM+PB+SS-WeM1 Probing Chemical Species and Potential Profiles of Electrified Interfaces, <i>Ethan J. Crumlin</i> , Advanced Light Source, Lawrence Berkeley National Laboratory
8:20am	NS+2D+AN+MN+MP+SE-WeM2 The Collective Behavior of Large Ensembles of Coupled MEMS Cantilevers with Varying Natural Frequencies, <i>Christopher Wallin</i> , National Institute of Standards and Technology, Center for Nanoscale Science and Technology; <i>N. Dick</i> , Tel Aviv University, Israel; <i>R. De Alba, D.A. Westly</i> , National Institute of Standards and Technology, Center for Nanoscale Science and Technology; <i>S. Grutzik</i> , Sandia National Laboratories; <i>A.T. Zehnder, R.H. Rand</i> , Cornell University; <i>V.A. Aksyuk</i> , National Institute of Standards and Technology, Center for Nanoscale Science and Technology; <i>S. Krylov</i> , Tel Aviv University, Israel; <i>B.R. Ilic</i> , National Institute of Standards and Technology, Center for Nanoscale Science and Technology	Invited talk continues.
8:40am	INVITED: NS+2D+AN+MN+MP+SE-WeM3 Piezoelectric Optomechanical Systems, <i>Krishna Coimbatore Balram</i> , University of Bristol, UK	PC+AS+BI+EM+PB+SS-WeM3 Observation of Electron Transfer in Riboflavin Reduction by In Situ Liquid SIMS, <i>Rachel Komorek, X.F. Yu, Z.H. Zhu, X-Y. Yu</i> , Pacific Northwest National Laboratory
9:00am	Invited talk continues.	PC+AS+BI+EM+PB+SS-WeM4 Electrowetting of Liquid Drops Revisited by XPS, <i>Sefik Suzer, P. Gokturk, B. Ulugut</i> , Bilkent University, Turkey
9:20am	NS+2D+AN+MN+MP+SE-WeM5 Absolute Deflection Measurements in a MEMS/NEMS Fabry-Perot Interferometry System, <i>Roberto De Alba, C.B. Wallin, G. Holland</i> , National Institute of Standards and Technology; <i>S. Krylov</i> , Tel Aviv University, Israel; <i>B.R. Ilic</i> , National Institute of Standards and Technology	INVITED: PC+AS+BI+EM+PB+SS-WeM5 Probing Interfaces in Heterogeneous Catalysts at Atomic Scale: Current and Emerging STEM Techniques, <i>Miaofang Chi</i> , Oak Ridge National Laboratory
9:40am	NS+2D+AN+MN+MP+SE-WeM6 Silicon on Insulator Electrostatically Actuated Bistable Cantilevers for Resonant Displacement/Acceleration Sensing, <i>O. Halevy, E. Benjamin, N. Krakover, Y. Kessler, Slava Krylov</i> , Tel Aviv University, Israel	Invited talk continues.
10:00am		
10:20am	BREAK - Complimentary Coffee in Exhibit Hall – Technology Spotlight Sessions in Booth #168, Exhibit Hall	
10:40am		
11:00am	INVITED: NS+2D+AN+MN+MP+SE-WeM10 Electron-Photon-Phonon Hybrid Systems Based on Compound Semiconductor Mechanical Resonators, <i>Hiroshi Yamaguchi</i> , NTT Basic Research Laboratories, Nippon Telegraph and Telephone Corporation, Japan	PC+AS+BI+EM+PB+SS-WeM10 From 2D to Advanced 3D Surface Functionalization using Self-limiting Reactions in the Fluidized Bed Reactor Technology, <i>Didier Arl, T. Da Cunha, N. Adjeroud, K. Menguelti, M. Gerard, D. Lenoble</i> , Luxembourg Institute of Science and Technology (LIST), Luxembourg
11:20am	Invited talk continues.	
11:40am	NS+2D+AN+MN+MP+SE-WeM12 Size Dependent Mechanics of Elastomers, <i>Le Li, N. Alsharif, K.A. Brown</i> , Boston University	
12:00pm		

Wednesday Morning, October 24, 2018

Plasma Science and Technology Division Room 104B - Session PS+AS+EL+EM+SE-WeM Current and Future Stars of the AVS Symposium I Moderator: Eric A. Joseph, IBM Research Division, T.J. Watson Research		Plasma Science and Technology Division Room 104A - Session PS+EM-WeM Advanced Patterning Moderators: Jeffrey Shearer, IBM Research Division, Albany, NY, Yiting Zhang, KLA-Tencor
8:00am		PS+EM-WeM1 Study of High Selective Silicon Nitride Etching Mechanisms in Remote Plasmas: Impact of Wafer Temperature, <i>Emilie Prevost</i> , STMicroelectronics, France; <i>L. Vallier, G. Cunge</i> , LTM, Univ. Grenoble Alpes, CEA-LETI, France; <i>C. De Buttet</i> , CEA-LETI, France; <i>S. Lagrasta</i> , STMicroelectronics, France; <i>C. Petit-Etienne</i> , LTM, Univ. Grenoble Alpes, CEA-LETI, France
8:20am	PS+AS+EL+EM+SE-WeM2 Invited Talk-Future Stars of AVS Session: Ellipsometry at THz Frequencies: New Approaches for Metrology and Metamaterial-based Sensing, <i>Tino Hofmann</i> ¹ , University of North Carolina at Charlotte	PS+EM-WeM2 Mechanism of Highly Selective SiO ₂ Etching over Si ₃ N ₄ using a Cyclic Process with BC ₃ and Fluorocarbon Gas Chemistries, <i>Miyako Matsui</i> , Hitachi Ltd., Japan; <i>K. Kuwahara</i> , Hitachi High-Technologies Corp., Japan
8:40am	PS+AS+EL+EM+SE-WeM3 Invited Talk-Future Stars of AVS Session: Remote Epitaxy – The Future for Stackable SiC Electronics, <i>Rachael Myers-Ward</i> ² , U.S. Naval Research Laboratory; <i>J. Kim</i> , Massachusetts Institute of Technology; <i>M.T. DeJarlard</i> , US Naval Research Laboratory; <i>K. Qiao, Y. Kim</i> , Massachusetts Institute of Technology; <i>S.P. Pavunny, D.K. Gaskill</i> , U.S. Naval Research Laboratory	INVITED: PS+EM-WeM3 DSA Patterning for and Beyond CMOS, <i>Patricia Pimenta Barros</i> , CEA-LETI, France; <i>N. Posseme</i> , CEA, LETI, France; <i>S. Barnola</i> , CEA-LETI, France; <i>R. Tiron</i> , CEA-LETI, MINATEC, France; <i>A. Gharbi, M.A. Argoud, Z. Chalupa, M.-G. Gusmao-Cacho</i> , CEA-LETI, France; <i>A. Paquet</i> , Arkema, France; <i>F. Delachat</i> , CEA-LETI, France; <i>C. Nicolet, C. Navarro</i> , Arkema, France
9:00am	PS+AS+EL+EM+SE-WeM4 Invited Talk-Future Stars of AVS Session: Low-Temperature Growth for 3D Integration of van der Waals Materials, <i>Christopher L. Hinkle</i> ¹ , University of Texas at Dallas	Invited talk continues.
9:20am	PS+AS+EL+EM+SE-WeM5 Invited Talk-Future Stars of AVS Session: Engineering the Properties at Heusler Interfaces, <i>Jason Kawasaki</i> ¹ , University of Wisconsin - Madison	PS+EM-WeM5 Composition Modulation of SiGe for Si/SiGe Dual Channel Fin Application, <i>Yohhei Ishii</i> , Hitachi High Technologies America Inc.; <i>Y.-J. Lee</i> , National Nano Device Laboratories; <i>W.-F. Wu</i> , National Nano Device Laboratories; <i>K. Maeda</i> , Hitachi High Technologies America Inc.; <i>H. Ishimura</i> , Hitachi High-Technologies Taiwan Corp.; <i>M. Muira</i> , Hitachi High-Technologies Corp.
9:40am	PS+AS+EL+EM+SE-WeM6 Invited Talk-Future Star of AVS Session: Atom Probe Tomography for 3D Semiconductor Devices Applications, <i>Ajay Kumar Kambham</i> ¹ , GLOBALFOUNDRIES U.S. Inc.	PS+EM-WeM6 Etching Mechanisms of Si Containing Materials in Remote Plasma Source using NF ₃ based Gas Mixture, <i>Erwine Pargon, V. Renaud, C. Petit-Etienne, L. Vallier, G. Tomachot, G. Cunge, O. Joubert</i> , Univ. Grenoble Alpes, CNRS, LTM, Grenoble, France; <i>J.-P. Barnes, N. Rochat</i> , Univ. Grenoble Alpes, CEA, LETI, Grenoble , France
10:00am		
10:20am	BREAK - Complimentary Coffee in Exhibit Hall – Technology Spotlight Sessions in Booth #168, Exhibit Hall	
10:40am		
11:00am	PS+AS+EL+EM+SE-WeM10 Invited Talk-Future Stars of AVS Session: Three-Dimensional Imaging of Complex Oxide Interfaces, <i>Divine P. Kumah</i> ¹ , North Carolina State University	PS+EM-WeM10 Precise Control of Silicon Nitride Spacer Etching Selectively to Silicon for 3D CMOS Device, <i>V. Ah-Leung, N. Possémé, Olivier Pollet, S. Barnola</i> , CEA-LETI, France
11:20am	PS+AS+EL+EM+SE-WeM11 Invited Talk-Future Stars of AVS Session: Illuminating Physics of Magnetron Sputtering Discharges, <i>Matjaz Panjan</i> ¹ , Jozef Stefan Institute, Slovenia	PS+EM-WeM11 A Study on the Distortion of Poly Si Nano Hole Profile with High Aspect Ratio in sub X nm, <i>Jin Won Lee, J.Y. Lee, K.J. Seong, T.S. Kwon, H.H. Jeong, S.S. Hong, D.W. Han, B.R. Lim, A.R. Ji, Y.M. Oh, J.C. Park</i> , Samsung Electronics, Republic of Korea
11:40am	INVITED: PS+AS+EL+EM+SE-WeM12 Peter Mark Memorial Award: Plasma-bio Interactions: Investigating Mechanisms to Enable New Applications, <i>Peter Bruggeman</i> ² , University of Minnesota	INVITED: PS+EM-WeM12 Etching Recipe Optimization Using Machine Learning, <i>Takeshi Ohmori, H. Nakada, M. Ishikawa, N. Kofuji, T. Usui, M. Kurihara</i> , Hitachi, Ltd., Japan
12:00pm	Invited talk continues.	Invited talk continues.

¹ Future Stars of the AVS

² Peter Mark Memorial Award Winner

Wednesday Morning, October 24, 2018

Plasma Science and Technology Division Room 104C - Session PS+MN-WeM IoT Session: Enabling IoT Era Moderators: Ankur Agarwal, KLA-Tencor, David Lishan, Plasma-Therm LLC		Surface Science Division Room 203C - Session SS+HC-WeM Catalytic Alloys: Understanding Heterogeneity Moderators: April Jewell, Jet Propulsion Laboratory, Jean-Sabin McEwen, Washington State University
8:00am	INVITED: PS+MN-WeM1 A "Moore's Law" for Packaging, <i>Subramanian Iyer</i> , University of California at Los Angeles	INVITED: SS+HC-WeM1 Toward Surface Science-informed Design of Bifunctional Deoxygenation Catalysts, <i>J. Will Medlin</i> , University of Colorado Boulder
8:20am	Invited talk continues.	Invited talk continues.
8:40am	PS+MN-WeM3 Fabrication, Chemical Lift-Off and Optical Characterization of Nanoscale III-Nitride Light Emitters, <i>Lesley Chan¹, C.D. Pynn, P. Shapurenko, T. Margalith, S.P. DenBaars, M.J. Gordon</i> , University of California at Santa Barbara	SS+HC-WeM3 Computationally Assisted Correlative STEM and EXAFS Characterization for Multiscale Structure Determination of Tunable Rh/Au Bimetallic Nanoparticle Catalysts, <i>S. House, C.S. Bonifacio</i> , University of Pittsburgh; <i>J. Timoshenko</i> , Stony Brook University; <i>P. Kunal, H. Wan, Z. Duan, H. Li</i> , University of Texas at Austin; <i>Judith Yang</i> , University of Pittsburgh; <i>A.I. Frenkel</i> , Stony Brook University; <i>S. Humphrey, R. Crooks, G. Henkelman</i> , University of Texas at Austin
9:00am	PS+MN-WeM4 High Radical Flux, with Low Ion and Photon Flux, Plasma Source, for MEM'S Technology, <i>Marc Segers, Y. Pilloux, D. Lishan, S. FERRAND</i> , Plasma-Therm LLC	SS+HC-WeM4 Designing Heterogeneous Alloy Catalysts from First Principles and Surface Science, <i>Charles Sykes</i> , Tufts University
9:20am	INVITED: PS+MN-WeM5 Use of Plasma in Advanced Packaging, <i>Michael Seddon</i> , ON Semi	SS+HC-WeM5 Extracting Diffusing Parameters for Cu and S from Surface Segregation Data Recorded with AES on a Ni-Cu(S) Ternary Alloy, <i>Jacobus Terblans</i> , University of the Free State, South Africa; <i>X.-L. Yan</i> , University of the Free State, China; <i>J.Y. Wand</i> , Shantou University, China; <i>H.C. Swart</i> , University of the Free State, Republic of South Africa
9:40am	Invited talk continues.	SS+HC-WeM6 Atomic and Electronic Structure of CoO Nanoislands on Au(111), <i>Ana Sanchez-Grande</i> , IMDEA Nanoscience, Spain; <i>J. Rodriguez-Fernandez</i> , Aarhus University, Denmark; <i>E. Carrasco, B. Cirera, K. Lauwaet</i> , IMDEA Nanoscience, Spain; <i>J. Fester</i> , Aarhus University, Denmark; <i>R. Miranda</i> , Universidad Autonoma Madrid, Spain; <i>J.V. Lauritsen</i> , Aarhus University, Denmark; <i>D. Ecija</i> , IMDEA Nanoscience, Spain
10:00am	BREAK - Complimentary Coffee in Exhibit Hall – Technology Spotlight Sessions in Booth #168, Exhibit Hall	
10:20am	BREAK - Complimentary Coffee in Exhibit Hall – Technology Spotlight Sessions in Booth #168, Exhibit Hall	
10:40am	BREAK - Complimentary Coffee in Exhibit Hall – Technology Spotlight Sessions in Booth #168, Exhibit Hall	
11:00am	INVITED: PS+MN-WeM10 Low Temperature Plasmas in Nanotechnology Applications, <i>Meyya Meyyappan</i> , NASA Ames Research Center	INVITED: SS+HC-WeM10 Using Water as a Co-catalyst in Heterogeneous Catalysis to Improve Activity and Selectivity, <i>Lars Grabow</i> , University of Houston
11:20am	Invited talk continues.	Invited talk continues.
11:40am	PS+MN-WeM12 Gas Phase Synthesis of Pure III-V Semiconductor Nanoparticles from Bulk Metals by using Low Temperature Plasma, <i>Necip Berker Uner, E. Thimsen</i> , Washington University in St. Louis	SS+HC-WeM12 Experimental and Theoretical Evaluation of Water Chemistry on Two-dimensional Silica and Aluminosilicate, <i>Jin-Hao Jhang, G.S. Hutchings</i> , Yale University; <i>J.A. Boscoboinik</i> , Center for Functional Nanomaterials Brookhaven National Laboratory; <i>E.I. Altman</i> , Yale University
12:00pm	PS+MN-WeM13 Investigation of Fundamental Hydrocarbon Plasma Chemistry for Unraveling Film Deposition Processes on Nanomaterials, <i>Tara Van Surksum, E.R. Fisher</i> , Colorado State University	SS+HC-WeM13 Double Layer Formation of Water Molecules on Graphene, <i>A. Akaiishi, T. Yonemaru, Jun Nakamura</i> , The University of Electro-Communications (UEC-Tokyo), Japan

Wednesday Morning, October 24, 2018

Thin Films Division Room 102A - Session TF+EM+MI-WeM Thin Film Processes for Electronics and Optics I Moderators: Joe Becker, Kurt J. Lesker Company, Virginia Wheeler, U.S. Naval Research Laboratory		Vacuum Technology Division Room 203B - Session VT-WeM Vacuum Technology Developments Moderators: Jason Carter, Argonne National Laboratory, Yulin Li, Cornell University
8:00am	INVITED: TF+EM+MI-WeM1 Crystalline Conductors: Transition Metal Nitride Materials and Device Applications, <i>David Meyer, D.S. Katzer, N. Nepal, B.P. Downey, M.T. Hardy, D.F. Storm</i> , U.S. Naval Research Laboratory	VT-WeM1 Trace Helium Effects from High Pressure Swing Adsorption Nitrogen Generator on Semiconductor Capital Equipment Manufacturer, <i>William Johnson</i> , Applied Materials, Varian Semiconductor Equipment
8:20am	Invited talk continues.	VT-WeM2 Remote Handling Clamps for Flange Connections in Vacuum Service, <i>Ryan McCall</i> , Technetics Group
8:40am	TF+EM+MI-WeM3 Growth Mechanism and Characteristics of Hf-Si-O Film by PE-ALD using TDMAS and TDMAH Precursors and Oxygen Plasma Gas, <i>Toshihide Nabatame</i> , National Institute for Materials Science (NIMS), Japan; <i>M. Inoue</i> , National Institute for Materials Science (NIMS); <i>E. Maeda, K. Yuge, M. Hirose</i> , Shibaura Institute of Technology, Japan; <i>M. Takahashi, K. Ito</i> , Joining and Welding Research Institute, Osaka University, Japan; <i>N. Ikeda</i> , National Institute for Materials Science (NIMS), Japan; <i>T. Ohishi</i> , Shibaura Institute of Technology, Japan; <i>A. Ohi</i> , National Institute for Materials Science (NIMS), Japan	
9:00am	TF+EM+MI-WeM4 Atomic Layer Epitaxy of Ultra-wide Bandgap Ga ₂ O ₃ Films, <i>Virginia Wheeler, N. Nepal</i> , U.S. Naval Research Laboratory; <i>L.O. Nyakiti</i> , Texas A&M University; <i>D.R. Boris, S.G. Walton, B.P. Downey, D.J. Meyer, C.R. Eddy Jr.</i> , U.S. Naval Research Laboratory	VT-WeM4 Role of Rotor Surface Conditions on Calibration Constant of Spinning Rotor Gauges, <i>Tim Verbovsek</i> , Institute of Metals and Technology, Slovenia
9:20am	TF+EM+MI-WeM5 Effects of Process Gases and Gate TiN Electrode during the Post Deposition Anneal to ALD-Al ₂ O ₃ Dielectric Film, <i>Masaya Saito, A. Teramoto, T. Suwa, K. Nagumo, Y. Shiba, R. Kuroda, S. Sugawa</i> , Tohoku University, Japan	VT-WeM5 Condensation-based Low-grade Heat Powered Dual-chamber Vacuum Technology, <i>Tony Guo</i> , New Jersey Institute of Technology
9:40am	TF+EM+MI-WeM6 Controlling the NbO _x Materials System for Neuromorphic Computing, <i>Alexander C. Kozen</i> , U.S. Naval Research Laboratory; <i>Z.R. Robinson, A.H. Rowley</i> , The College at Brockport - SUNY; <i>T.J. Larrabee, M.E. Twigg, H.S. Cho, S.M. Prokes</i> , U.S. Naval Research Laboratory	VT-WeM6 Vacuum Design and Testing of the ARIEL Radio Frequency Quadrupole Buncher and Cooler (ARQB), <i>Geoff Hodgson, B. Barquist</i> , TRIUMF, Canada
10:00am		
10:20am	BREAK - Complimentary Coffee in Exhibit Hall – Technology Spotlight Sessions in Booth #168, Exhibit Hall	
10:40am		
11:00am	TF+EM+MI-WeM10 Sputtering Power Dependent on Switching Characteristics of ZnO-based Transparent Resistive Memory Devices, <i>Firman Mangasa Simanjuntak</i> , Tohoku University, Japan; <i>T. Ohno</i> , Oita University, Japan; <i>S. Samukawa</i> , Tohoku University, Japan	
11:20am	TF+EM+MI-WeM11 Influence of Intrinsic and Extrinsic Dopants in HfO _x Films for Resistive Switching Memory, <i>SungYeon Ryu, Y. Kim</i> , Seoul National University of Science and Technology, Republic of Korea; <i>W.Y. Park, S.G. Kim</i> , SK Hynix Inc., Republic of Korea; <i>B.J. Choi</i> , Seoul National University of Science and Technology, Republic of Korea	
11:40am	TF+EM+MI-WeM12 Scaling up of an Electrochemical Atomic Layer Deposition of Copper, <i>D. Dictus</i> , Lam Research Corporation, Belgium; <i>Aniruddha Jai</i> , Lam Research Corporation; <i>G. Alessio Verni</i> , Lam Research Corporation, Belgium; <i>K. Vandersmissen</i> , Imec, Belgium; <i>B. Frees</i> , Lam Research Corporation, Belgium; <i>Y. Yezdi</i> , Lam Research Corporation	
12:00pm	TF+EM+MI-WeM13 A Novel High-deposition-rate PECVD Process based on Hollow Cathode Plasma Technique, <i>S. Shayestehaminzadeh, N. Rivolta</i> , AGC Glass Europe, Belgium; <i>M. Datz</i> , Interpane E&B GmbH; <i>John Chambers</i> , AGC North America; <i>H. Wiame</i> , AGC Glass Europe, Belgium	

Wednesday Morning, October 24, 2018

Exhibitor Technology Spotlight Workshops
Room Hall A - Session EW-Web
Exhibitor Technology Spotlight Session IV
Moderator: Christopher Moffitt, Kratos Analytical Inc

10:00am		
10:20am	EW-Web2 HAXPES-Lab: A Laboratory Based System for HAXPES Measurements, <i>Susanna Eriksson</i> , Scienta Omicron	
10:40am	EW-Web3 Coatings Characterization Solution from Fischer Technology - XRF, Nanoindentation and Progressive Load Scratch, <i>Rahul Nair</i> , Fischer Scientific	
11:00am		

Wednesday Lunch, October 24, 2018

Exhibitor Technology Spotlight Workshops
Room Hall A - Session EW-WeL
Exhibitor Technology Spotlight Session V
Moderator: Christopher Moffitt, Kratos Analytical Inc

12:00pm		
12:20pm	<p>FREE LUNCH IN EXHIBIT HALL* (See Registration Tickets)</p> <p>*while supplies last</p>	
12:40pm	EW-WeL3 The TESLA JT SPM, <i>Markus Maier</i> , Scienta Omicron GmbH, Germany	
1:00pm	EW-WeL4 MKS Instruments, Inc., 523 Granville-Phillips® Wide-Range Cold Cathode Transducer: Applications and Market Update, <i>David Kelly</i> , MKS Instruments	
1:20pm		
1:40pm		
2:00pm		

Wednesday Afternoon, October 24, 2018

2D Materials Focus Topic Room 201B - Session 2D+MN+NS+SS-WeA IoT Session: Surface Chemistry, Functionalization, Bio and Sensor Applications Moderator: Daniel Walkup, National Institute of Standards and Technology (NIST)/ University of Maryland, College Park		Actinides and Rare Earths Focus Topic Room 202C - Session AC+AS+SA-WeA Chemistry and Physics of the Actinides and Rare Earths Moderators: Krzysztof Gofryk, Idaho National Laboratory, Ladislav Havela, Charles University, Prague, Czech Republic, David Shuh, Lawrence Berkeley National Laboratory
2:20pm	2D+MN+NS+SS-WeA1 Impact of Hydrogen on Graphene-based Materials: Atomistic Modeling and Simulation of HRSTEM Images, <i>C. Guedj</i> , Univ. Grenoble Alpes, CEA, LETI, France; <i>L. Jaillet, F. Rousse, Stéphane Redon</i> , Univ. Grenoble Alpes, CNRS, INRIA, Grenoble INP*, LJK, France	INVITED: AC+AS+SA-WeA1 New Directions in f-Block Separations Chemistry based on Metal and Ligand Redox Activity, <i>Eric Schelter, A. McSkimming</i> , University of Pennsylvania; <i>J. Su</i> , Los Alamos National Laboratory,; <i>T. Cheisson, H. Fang</i> , University of Pennsylvania; <i>L. Moreau</i> , Lawrence Berkeley National Laboratory, Berkeley; <i>B.E. Cole, B.C. Manor, M.R. Gau, P.J. Carroll</i> , University of Pennsylvania; <i>E.R. Batista, P. Yang</i> , Los Alamos National Laboratory; <i>C. Booth</i> , Lawrence Berkeley National Laboratory; <i>Y. Qiao, J.A. Bogart</i> , University of Pennsylvania
2:40pm	2D+MN+NS+SS-WeA2 High Density H2 and He Plasmas: Can They be used to Treat Graphene?, <i>Hasan-Al Mehedi</i> , Laboratoire des Technologies de la Microélectronique, CNRS-UJF, France; <i>D. Ferrah</i> , Cea, Leti, Minatec, France; <i>J. Dubois, C. Petit-Etienne</i> , Laboratoire des Technologies de la Microélectronique, CNRS-UJF; <i>H. Okuno</i> , Cea, Inac/sp2m/lemma; <i>V. Bouchiat</i> , Institut Néel, CNRS-UJF-INP; <i>O.J. Renault</i> , CEA/LETI-University Grenoble Alpes, France; <i>G. Cunge</i> , Laboratoire des Technologies de la Microélectronique, CNRS-UJF, France	Invited talk continues.
3:00pm	2D+MN+NS+SS-WeA3 Novel Binder-free Ag@Ni(OH) ₂ over Graphene/Ni Foam and Glucose Sensing, <i>Tong-Hyun Kang, J.-S. Yu</i> , DGIST, Republic of Korea	INVITED: AC+AS+SA-WeA3 Bond Distance Variations for Lanthanide and Actinide Compounds and its Implication, <i>Tsuyoshi Yaita</i> , Japan Atomic Energy Agency, Japan; <i>S. Suzuki, T. Kobayashi, H. Shiwaku</i> , Materials Sciences Research Center, Japan Atomic Energy Agency, Japan
3:20pm	2D+MN+NS+SS-WeA4 Surface Modification and Magnetization of Carbon Based Nanostructures, <i>Rina Tannenbaum</i> , University of Stony Brook; <i>I.T. Kim</i> , Gachon University, Korea; <i>S. Sharma</i> , University of Stony Brook	Invited talk continues.
3:40pm		
4:00pm	BREAK - Complimentary Refreshments in Exhibit Hall	
4:20pm	2D+MN+NS+SS-WeA7 Chemical Modification of Graphene and Carbon Nano Tubes as viewed by XPS and NEXAFS Spectroscopies underpinned by DFT Spectra Simulation, <i>C. Ehler, E. Donskyi</i> , Bundesanstalt für Materialforschung und -prüfung (BAM), Germany; <i>P.L. Girard-Lauriault</i> , McGill University, Canada; <i>R. Illgen</i> , Bundesanstalt für Materialforschung und -prüfung (BAM), Germany; <i>A. Lippitz</i> , Bundesanstalt für Materialforschung und -prüfung (BAM); <i>R. Haag, M. Adeli</i> , Freie Universität Berlin, Germany; <i>Wolfgang Unger</i> , Bundesanstalt für Materialforschung und -prüfung (BAM), Germany	INVITED: AC+AS+SA-WeA7 Spectroscopic Studies of Trivalent Actinide Coordination, <i>Benjamin Stein, M.G. Kerlin, A.L. Morgenstern, E. Batista, S.E. Bone, S.K. Cary</i> , Los Alamos National Laboratory; <i>J. Lezama Pacheco</i> , SLAC National Accelerator Laboratory; <i>S.A. Kozimor, P. Yang</i> , Los Alamos National Laboratory
4:40pm	2D+MN+NS+SS-WeA8 Elastic Spongy Graphene-Functionalized Silicon Anode with Excellent Cycle Stability in Li battery, <i>Byong-June Lee, J.-S. Yu</i> , DGIST, Republic of Korea	Invited talk continues.
5:00pm	2D+MN+NS+SS-WeA9 Electrical and Structural Changes of Multilayer WSe ₂ Transistors: Atmospheric Gas Adsorption and Long Term Aging, <i>Anna Hoffman, M.G. Stanford, C. Zhng</i> , University of Tennessee Knoxville; <i>I. Ivanov</i> , Oak Ridge National Laboratory; <i>A.D. Oyedele, D.G. Mandrus</i> , University of Tennessee Knoxville; <i>L. Liang, B.G. Sumpter, K. Xiao</i> , Oak Ridge National Laboratory; <i>P.D. Rack</i> , University of Tennessee Knoxville	AC+AS+SA-WeA9 Speciation of Rare Earth Elements in Coal Harvesting Byproducts, <i>Xu Feng, M. Council-Troche, J.R. Morris, A. Noble, R.-H. Yoon</i> , Virginia Polytechnic Institute and State University
5:20pm	2D+MN+NS+SS-WeA10 Ion Migration Studies in Exfoliated 2D Molybdenum Oxide via Ionic Liquid Gating for Neuromorphic Device Applications, <i>Cheng Zhang, P.R. Pudasaini, A.D. Oyedele</i> , University of Tennessee Knoxville; <i>A.V. Iveyev, K. Xiao, T.Z. Ward</i> , Oak Ridge National Laboratory; <i>D.G. Mandrus</i> , University of Tennessee Knoxville; <i>O.S. Ovchinnikova</i> , Oak Ridge National Laboratory; <i>P.D. Rack</i> , University of Tennessee Knoxville	AC+AS+SA-WeA10 Exotic Electronic Properties of Strongly Correlated Compounds NpPd ₃ and PuPd ₃ , <i>Krzysztof Gofryk</i> , Idaho National Laboratory; <i>J.-C. Griveau, E. Colineau</i> , Institute for Transuranium Elements; <i>K.A. McEwen</i> , University College London; <i>W.J. Nellis</i> , Harvard University; <i>J.L. Smith</i> , Los Alamos National Laboratory
5:40pm	2D+MN+NS+SS-WeA11 Infrared Absorption of Nanometer-scale Thermally Reduced Graphene Oxide, <i>Erin Cleveland, J. Nolde, G. Jernigan, E. Aifer</i> , U.S. Naval Research Laboratory	
6:00pm	2D+MN+NS+SS-WeA12 Dielectric Properties of Carbon Nanomembranes prepared from aromatic Self-Assembled Monolayers and their application in All-Carbon Capacitors, <i>Xianghui Zhang, P. Penner, E. Marschewski</i> , Bielefeld University, Germany; <i>T. Weimann, P. Hinze</i> , Physikalisch-Technische Bundesanstalt, Braunschweig, Germany; <i>A. Görlzhäuser</i> , Bielefeld University, Germany	

Wednesday Afternoon, October 24, 2018

Extending Additive Manufacturing to the Atomic Scale Focus Topic Room 102B - Session AM+MP+NS-WeA Atomic Scale Manipulation with SPM Moderator: Sven Rogge, University of New South Wales, Australia		Applied Surface Science Division Room 204 - Session AS+SE-WeA Industrial and Practical Applications of Surface Analysis Moderators: Jeffrey Fenton, Medtronic, Svitlana Pylypenko, Colorado School of Mines
2:20pm	INVITED: AM+MP+NS-WeA1 Advanced Scanning Probe Lithography: Processes, Nanopatterning and Nanoelectronics, <i>Ricardo Garcia</i> , Inst Ciencia Materiales Madrid, CSIC, Spain	AS+SE-WeA1 Identification of Unknown Contaminants in Industrial Applications Using MS/MS in Combination with High Resolution Mass Spectrometry, <i>A. Pirkli, Julia Zabel, D. Rading</i> , IONTOF GmbH, Germany; <i>N.J. Havercroft</i> , IONTOF USA; <i>S. Kayser, H. Arlinghaus, R. Moellers, E. Niehuis</i> , IONTOF GmbH, Germany
2:40pm	Invited talk continues.	AS+SE-WeA2 ToF-SIMS Analysis of Glass and Glass Coatings, <i>Christine Mahoney</i> , Corning Inc.
3:00pm	AM+MP+NS-WeA3 Integrated Devices made Using Atomically Precise Advanced Manufacturing, <i>D. Ward, D. Campbell, M. Marshall, T.-M. Lu, L. Tracy, L. Maurer, A. Baczweski, Shashank Misra</i> , Sandia National Laboratories	INVITED: AS+SE-WeA3 Problem Solving with Valence Band Spectroscopy and SIMS MS/MS, <i>Steven Pachuta, D.M. Poirier</i> , 3M Company
3:20pm		Invited talk continues.
3:40pm	BREAK - Complimentary Refreshments in Exhibit Hall	
4:00pm		
4:20pm	AM+MP+NS-WeA7 Electrical Transport Properties of Si:P δ-layer Devices, <i>Ranjit Kashid, X. Wang, Namboodiri, J. Hagmann</i> , National Institute of Standards and Technology (NIST); <i>S.W. Schmucker</i> , University of Maryland College Park; <i>J. Wyrick, C. Richter, R.M. Silver</i> , National Institute of Standards and Technology (NIST)	AS+SE-WeA7 Surface and In-depth XPS Characterization of Liquid and Cured Control Release Additives (CRAs) Used in Silicone-Based Release Coatings, <i>Brian Strohmeier, K. Rhodes, R. Munigeti, J. Orlowski</i> , Avery Dennison Corporation
4:40pm	AM+MP+NS-WeA8 Atomically Precise Tip Positioning for Automated Writing of Atomic-scale Devices, <i>James Owen, E. Fuchs, J.N. Randall, J.R. Von Ehr</i> , Zyvex Labs	AS+SE-WeA8 Differentiating Silicones Using SIMS, <i>Paul Vlasak, M.L. Pacholski</i> , The Dow Chemical Company
5:00pm	INVITED: AM+MP+NS-WeA9 Kilobyte Scale Data Storage through Autonomous Atom Assembly, <i>A.F. Otte, David Coffey</i> , Delft University of Technology, Netherlands	AS+SE-WeA9 Uranium Particles Analysis and Imaging Using ToF-SIMS for Source Identification, <i>Juan Yao, E. Krogstad, S. Shen, Z.H. Zhu, X-Y. Yu</i> , Pacific Northwest National Laboratory
5:20pm	Invited talk continues.	AS+SE-WeA10 XPS Depth Profiling of Organic Resins with Inorganic Inclusions, <i>Benjamin Schmidt, J. Newman, J.E. Mann, L. Swartz</i> , Physical Electronics
5:40pm	INVITED: AM+MP+NS-WeA11 Extending the Capabilities of STM-based Dopant Device Fabrication, <i>T. Skeren, N. Pascher, S.A. Köster, Andreas Fuhrer</i> , IBM Research - Zurich, Switzerland	AS+SE-WeA11 Application of X-ray Photoelectron Spectroscopy to Degradation Studies of Electrodes in Fuel Cells and Electrolyzers, <i>Kateryna Artyushkova</i> , University of New Mexico; <i>N. Danilovic</i> , Lawrence Berkeley Lab, University of California, Berkeley; <i>C. Capuano</i> , Proton on site; <i>A. Serov</i> , Pajarito Powder LLC; <i>P. Atanassov</i> , University of New Mexico
6:00pm	Invited talk continues.	AS+SE-WeA12 Application of X-ray Photoelectron Spectroscopy in Semiconductor Industry, <i>Yibin Zhang, Z. Bayindir, Z. Sun, M. Zhu, J. Gao, X. Wang, T. Han, J. Shu, D. Shao, J. Riendeau, J. Liu</i> , GLOBALFOUNDRIES

Wednesday Afternoon, October 24, 2018

Biomaterial Interfaces Division Room 104B - Session BI+AC+AS+HC+NS+SS+TF-WeA Current and Future Stars of the AVS Symposium II Moderator: David Boris, U.S. Naval Research Laboratory		Biomaterial Interfaces Division Room 101B - Session BI-WeA Microbes and Fouling at Surfaces Moderator: Caitlin Howell, University of Maine
2:20pm	INVITED: BI+AC+AS+HC+NS+SS+TF-WeA1 Medard W. Welch Award Lecture: A Surface Scientist's Journey from Small Molecules to Biomolecules and Biomaterials, <i>David G. Castner</i> ¹ , University of Washington	
2:40pm	Invited talk continues.	
3:00pm	BI+AC+AS+HC+NS+SS+TF-WeA3 Invited Talk-Future Stars of AVS Session: Making, Studying, and Designing Hierarchically Structured Soft Materials, <i>Keith A. Brown</i> ² , Boston University	INVITED: BI-WeA3 Gaede-Langmuir Award Lecture: From Description to Prediction of Biointerphase Reactions, <i>Michael Grunze</i> ³ , Max Planck Institute for Medical Research, Germany; <i>H.J. Kreuzer</i> , Dalhousie University, Canada
3:20pm	BI+AC+AS+HC+NS+SS+TF-WeA4 Invited Talk-Future Stars of AVS Session: Vapor Phase Infiltration for Transforming Polymers into Hybrid Materials: Processing Kinetics and Applications, <i>Mark Losego</i> ² , Georgia Institute of Technology	Invited talk continues.
3:40pm	BREAK - Complimentary Refreshments in Exhibit Hall	
4:00pm		
4:20pm	BI+AC+AS+HC+NS+SS+TF-WeA7 Invited Talk-Future Stars of AVS Session: Surface Preparation Methods for the Selective Oxidation of Ethanol to Acetaldehyde over TiO ₂ /Au(111), <i>Ashleigh Baber</i> ² , <i>D.T. Boyle</i> , <i>J. Wilke</i> , <i>V. Lam</i> , <i>D. Schlosser</i> , James Madison University	INVITED: BI-WeA7 Unraveling Complexities at the Adhesive Interface of Acorn Barnacles, <i>Kenan Fears</i> , <i>C.R. So</i> , <i>D.H. Leary</i> , <i>H. Ryou</i> , <i>J. Schultzhaus</i> , <i>C. Wang</i> , US Naval Research Laboratory; <i>B. Orihuela</i> , <i>D. Rittschof</i> , Duke University Marine Laboratory; <i>C.M. Spillmann</i> , <i>K.J. Wahl</i> , US Naval Research Laboratory
4:40pm	BI+AC+AS+HC+NS+SS+TF-WeA8 Invited Talk-Future Stars of AVS Session: Single Atom Catalysis: An Atomic-Scale View, <i>Gareth Parkinson</i> ² , TU Wien, Austria	Invited talk continues.
5:00pm	BI+AC+AS+HC+NS+SS+TF-WeA9 Invited Talk-Future Stars of AVS Session: Multimodal Chemical and Functional Imaging of Nanoscale Transformations Away from Equilibrium, <i>Olga Ovchinnikova</i> ² , Oak Ridge National Laboratory	BI-WeA9 Ultra Low Fouling Zwitterionic Coatings – Influence of Molecular Architecture on Fouling Inhibition, <i>Axel Rosenhahn</i> , <i>J. Koc</i> , Ruhr-University Bochum, Germany; <i>S. Bauer</i> , Ruhr-Universität Bochum, Germany; <i>J. Finlay</i> , <i>A.S. Clare</i> , Newcastle University; <i>E. Schoenemann</i> , University of Potsdam; <i>A. Laschewsky</i> , University of Potsdam
5:20pm	BI+AC+AS+HC+NS+SS+TF-WeA10 Invited Talk-Future Stars of AVS Session: Expanding the Structural Toolkit to Characterize Heavy Actinide Complexes, <i>Rebecca Abergele</i> ² , Lawrence Berkeley Lab, University of California, Berkeley; <i>G. Deblonde</i> , <i>A. Mueller</i> , <i>P. Ercius</i> , Lawrence Berkeley National Laboratory; <i>A.M. Minor</i> , Lawrence Berkeley Lab, University of California, Berkeley; <i>C.H. Booth</i> , <i>W.A. de Jong</i> , Lawrence Berkeley National Laboratory; <i>R. Strong</i> , Fred Hutchinson Cancer Research Center	BI-WeA10 Biomimetic Surfaces on Chitosan Membranes with Enhanced Antibacterial Properties Produced by Directed Plasma Nanosynthesis, <i>Camilo Jaramillo</i> , <i>A.F. Civantos</i> , <i>J.P. Allain</i> , University of Illinois at Urbana-Champaign
5:40pm	BI+AC+AS+HC+NS+SS+TF-WeA11 Invited Talk-Future Stars of AVS Session: Trends in Adsorbate Interactions with Bimetal Surfaces, <i>Liney Arnadottir</i> ² , <i>L.H. Sproul</i> , Oregon State University	BI-WeA11 How Do Geobacter Aggregates Communicate: New Understanding from In Situ Liquid SIMS, <i>Wenchoao Wei</i> , <i>R. Komorek</i> , Pacific Northwest National Laboratory; <i>C. Yang</i> , <i>F. Liu</i> , Yantai Institute of Coastal Zone Research; <i>Z.H. Zhu</i> , <i>X-Y. Yu</i> , Pacific Northwest National Laboratory
6:00pm		

¹ Medard W. Welch Award Winner

² Future Stars of the AVS

³ Gaede Langmuir Award Winner

Wednesday Afternoon, October 24, 2018

Electronic Materials and Photonics Division Room 101A - Session EM+2D+SS-WeA Wide and Ultra-Wide Bandgap Materials for Electronic Devices: Growth, Modeling and Properties Moderators: Erica Douglas, Sandia National Laboratories, Rachael Myers-Ward, U.S. Naval Research Laboratory		Fundamental Discoveries in Heterogeneous Catalysis Focus Topic Room 201A - Session HC+SS-WeA Theory and Dynamics of Heterogeneously Catalyzed Reactions Moderator: Erin Iski, University of Tulsa
2:20pm		HC+SS-WeA1 First-Principles Kinetic Monte Carlo Simulation of CO Oxidation on PdO(101): Role of Oxygen Vacancies, <i>Minkyu Kim</i> ¹ , A. Asthagiri, Ohio State University
2:40pm	EM+2D+SS-WeA2 2300 V Reverse Breakdown Voltage Ga ₂ O ₃ Schottky Rectifiers, <i>Jiancheng Yang</i> ² , F.R. Ren, University of Florida; M.J. Tadjer, U.S. Naval Research Laboratory; S.J. Pearton, University of Florida; A. Kuramata, Tamura Corporation and Novel Crystal Technology, Inc., Japan	HC+SS-WeA2 Surface Reactivity of Activated CO ₂ , <i>Richard van Lent</i> ³ , Leiden University, Netherlands; A.J. Walsh, M.A. Gleeson, DIFFER, Netherlands; L.B.F. Juurlink, Leiden University, Netherlands
3:00pm	EM+2D+SS-WeA3 Characterization of β -(Al,Ga,In) ₂ O ₃ Epitaxial Films for UV Photodetector Applications, <i>Luke Lyle</i> , L.M. Porter, R. Davis, Carnegie Mellon University; S. Okur, G.S. Tompa, Structured Materials Industries, Inc.; M. Chandrashekhar, V. Chava, J. Letton, University of South Carolina	INVITED: HC+SS-WeA3 Shining Light on Complexity: State- and Energy-Resolved Studies of Gas-Surface Reaction Dynamics and Mechanism, <i>Arthur Utz</i> , Tufts University
3:20pm	EM+2D+SS-WeA4 High Three-terminal Breakdown Voltage Quasi-two-dimensional β -Ga ₂ O ₃ Field-effect Transistors with a Dual Field Plate Structure, <i>Jinho Bae</i> , Korea University, Republic of Korea; H.W. Kim, I.H. Kang, Korea Electrotechnology Research Institute (KERI), Republic of Korea; G.S. Yang, S.Y. Oh, J.H. Kim, Korea University, Republic of Korea	Invited talk continues.
3:40pm	BREAK - Complimentary Refreshments in Exhibit Hall	
4:00pm		
4:20pm	INVITED: EM+2D+SS-WeA7 GaN Vertical Device Technology and its Future, <i>Srabanti Chowdhury</i> , UC Davis	HC+SS-WeA7 Vibration-driven Reaction of CO ₂ on Cu Surfaces via Eley-Rideal Type Mechanism, <i>Junji Nakamura</i> , J.M. Quan, T. Kozarashi, T. Mogi, T. Imabayashi, K. Takeyasu, T. Kondo, University of Tsukuba, Japan
4:40pm	Invited talk continues.	INVITED: HC+SS-WeA8 First Principles Reaction Kinetics over Metals, Oxides and Nanoparticles, <i>Henrik Grönbeck</i> , Chalmers University of Technology, Gothenburg, Sweden
5:00pm	EM+2D+SS-WeA9 Effects of Proton Irradiation Energy on SiN _x /AlGaN/GaN Metal-insulator-semiconductor High Electron Mobility Transistors, <i>Chaker Fares</i> , F.R. Ren, University of Florida; J.H. Kim, Korea University, Republic of Korea; S.J. Pearton, University of Florida; C.F. Lo, J.W. Johnson, IQE; G.S. Yang, Korea University, Republic of Korea	Invited talk continues.
5:20pm	EM+2D+SS-WeA10 Cesium-Free III-Nitride Photocathodes Based on Control of Polarization Charge, <i>Douglas Bell</i> , Jet Propulsion Laboratory, California Institute of Technology; E. Rocco, F. Shahedipour-Sandvik, SUNY Polytechnic Institute; S. Nikzad, Jet Propulsion Laboratory, California Institute of Technology	HC+SS-WeA10 Formation of Pd/Ag Sandwiches, a Stable PdAg Subsurface Alloy, and the Pd Segregation induced by CO and O ₂ , Studied with STM, Ambient-pressure XPS, and DFT, <i>Matthijs van Spronsen</i> , Lawrence Berkeley National Laboratory; K. Duanmu, UCLA; R. Madix, Harvard University; M.B. Salmeron, Lawrence Berkeley National Laboratory; P. Sautet, UCLA; C. Friend, Harvard University
5:40pm	EM+2D+SS-WeA11 Current Enhancement for Ultra-Wide Bandgap AlGaN High Electron Mobility Transistors by Regrowth Contact Design, <i>Erica Douglas</i> , B. Klein, S. Reza, A.A. Allerman, R.J. Kaplar, A.M. Armstrong, A.G. Baca, Sandia National Laboratories	5:30pm Heterogeneous Catalysis Graduate Student Presentation Awards Reception
6:00pm	EM+2D+SS-WeA12 Understanding Homoepitaxial GaN Growth, <i>Jennifer Hite</i> , T.J. Anderson, M.A. Mastro, L.E. Luna, J.C. Gallagher, J.A. Freitas, C.R. Eddy, U.S. Naval Research Laboratory	

¹ Heterogeneous Catalysis Graduate Student Presentation Award Finalist

² National Student Award Finalist

Wednesday Afternoon, October 24, 2018

Advanced Ion Microscopy Focus Topic Room 203B - Session HI-WeA Novel Beam Induced Material Engineering & Nano-Patterning Moderators: Armin Gölzhäuser, Bielefeld University, Germany, Olga Ovchinnikova, Oak Ridge National Laboratory		MEMS and NEMS Group Room 202B - Session MN+2D+AN+NS-WeA IoT Session: MEMS for IoT: Chemical and Biological Sensing Moderators: Robert Davis, Brigham Young University, Sushma Kotru, The University of Alabama
2:20pm	INVITED: HI-WeA1 Delving into the Finer Details of Helium FIBID, <i>Frances Allen</i> , University of California, Berkeley	INVITED: MN+2D+AN+NS-WeA1 BioMEMS for Eye Applications, <i>Yu-Chong Tai</i> , California Institute of Technology
2:40pm	Invited talk continues.	Invited talk continues.
3:00pm	INVITED: HI-WeA3 Anderson localization of Graphene by Helium Ion Irradiation, <i>Yuichi Naitou, S. Ogawa</i> , National Institute of Advanced Industrial Science and Technology (AIST), Japan	MN+2D+AN+NS-WeA3 Real-Time, Single Cell, Size Measurements using a Facile, Multimode Microwave Resonator, <i>Selim Hanay, H. Aydogmus, A. Secme, H.S. Pisheh, M. Kelleci</i> , Bilkent University, Turkey
3:20pm	Invited talk continues.	
3:40pm	BREAK - Complimentary Refreshments in Exhibit Hall	
4:00pm		
4:20pm	INVITED: HI-WeA7 The Frontiers of Focused Ion Beam in Semiconductor Applications, <i>Shida Tan</i> , Intel Corporation	INVITED: MN+2D+AN+NS-WeA7 Magnetic Microsystems for Communications, <i>Rob Candler</i> , University of California at Los Angeles
4:40pm	Invited talk continues.	Invited talk continues.
5:00pm	HI-WeA9 2D Materials Under Ion Irradiation: In-situ Experiments and the Role of the Substrate, <i>Gregor Hlawacek, S. Kretschmer</i> , Helmholtz Zentrum Dresden-Rossendorf, Germany; <i>M. Maslov</i> , Moscow Institute of Physics and Technology; <i>S. Ghaderzadeh, M. Ghorbani-Asl, A.V. Krasheninnikov</i> , Helmholtz Zentrum Dresden-Rossendorf, Germany	INVITED: MN+2D+AN+NS-WeA9 MEMS-Based Resonant Sensors for IoT Applications, <i>Oliver Brand, M. Kim, P. Getz</i> , Georgia Institute of Technology
5:20pm	HI-WeA10 Sample Heating Effects from Light Ions in Thin Films, <i>John A. Notte, B.B. Lewis</i> , Carl Zeiss Microscopy, LLC	Invited talk continues.
5:40pm	HI-WeA11 Helium Ion Direct Write Patterning of Superconducting Electronics, <i>Shane Cybart, E.Y. Cho, H. Li</i> , UC Riverside; <i>Y. Naitou, S. Ogawa</i> , National Institute of Advanced Industrial Science and Technology (AIST), Japan	MN+2D+AN+NS-WeA11 Etched Silicon Microcolumn For Tunable Thermal Gradient Gas Chromatography, <i>Aaron Davis, P. Schnepf, P.S. Ng, R.R. Vanfleet, R.C. Davis, B.D. Jensen</i> , Brigham Young University
6:00pm		

Wednesday Afternoon, October 24, 2018

Nanometer-scale Science and Technology Division Room 203A - Session NS+MN+PC+SS-WeA IoT Session: Bio at the Nanoscale Moderators: Juraj Topolancik, Roche Sequencing Solutions, Liya Yu, NIST Center for Nanoscale Science and Technology		Plasma Biology, Agriculture, and Environment Focus Topic Room 104A - Session PB+BI+PC+PS-WeA Plasma Agriculture & Environmental Applications Moderator: Deborah O'Connell, University of York, UK
2:20pm		INVITED: PB+BI+PC+PS-WeA1 Pulsed Power Applications for Farming and Food Processing, <i>Koichi Takaki</i> , Iwate University, Japan
2:40pm		Invited talk continues.
3:00pm	NS+MN+PC+SS-WeA3 Nanoscale Label-free Imaging of Protein Molecules via Photo-induced Force Microscopy, <i>D. Nowak, Sung Park</i> , Molecular Vista	INVITED: PB+BI+PC+PS-WeA3 Stimulus Control on Organisms Using Pulsed Power Technology, <i>Douyan Wang, T. Namihira</i> , Institute of Pulsed Power Science, Kumamoto University, Japan
3:20pm	NS+MN+PC+SS-WeA4 Evaluating Reaction-diffusion Immunoassays via High-resolution Imaging Techniques, <i>Imanda Jayawardena</i> , University of Queensland, Australia; <i>S. Corrie</i> , Monash University, Australia; <i>L. Grondahl</i> , University of Queensland, Australia	Invited talk continues.
3:40pm	BREAK - Complimentary Refreshments in Exhibit Hall	
4:00pm		
4:20pm	INVITED: NS+MN+PC+SS-WeA7 The Last Nanometer – Hydration Structure of DNA and Solid Surfaces Probed by Ultra-High Resolution AFM, <i>Uri Sivan, K. Kuchuk, I. Schlesinger</i> , Technion - Israel Institute of Technology, Israel	PB+BI+PC+PS-WeA7 Synthesis of Nitrates by Atmospheric Microplasma in Aqueous Solution, <i>Nicolas Maira, F. Reniers</i> , Université Libre de Bruxelles, Belgium
4:40pm	Invited talk continues.	
5:00pm	INVITED: NS+MN+PC+SS-WeA9 Open-hardware, High-speed Atomic Force Microscopy using Photothermal Off-resonance Tapping, <i>Georg Fantner</i> , École Polytechnique Fédéral de Lausanne, Switzerland	INVITED: PB+BI+PC+PS-WeA9 Design Considerations for Plasma-based Water Purification Reactor Scale-up, <i>John Foster, S.M. Mujovic, J.R. Groele, J.C.Y. Lai</i> , The University of Michigan-Ann Arbor
5:20pm	Invited talk continues.	Invited talk continues.
5:40pm	NS+MN+PC+SS-WeA11 Development of Multimodal Chemical Nano-Imaging for <i>in situ</i> Investigations of Microbial Systems, <i>A. Bhattarai, B.T. O'Callahan, P.Z. El Khoury, Scott Lea</i> , Pacific Northwest National Laboratory; <i>K.-D. Park, E.A. Muller, M.B. Raschke</i> , University of Colorado Boulder	PB+BI+PC+PS-WeA11 Radicals and Ozone Generated in Ar/He and Ar/He/H ₂ O Plasma by using Atmospheric Pressure Plasma Jet Systems and their use in Methylene Blue Degradation, <i>J.H. Hsieh, YJinWei Wei, Ming Chi University of Technology, Taiwan, Republic of China; C. Li, National Yang Ming University, Taiwan, Republic of China</i>
6:00pm		

Wednesday Afternoon, October 24, 2018

Plasma Science and Technology Division Room 104C - Session PS+EM-WeA Advanced BEOL/Interconnect Etching Moderators: Michael Morris, Trinity College Dublin, Tetsuya Tatsumi, Sony Semiconductor Solutions Corporation		Novel Trends in Synchrotron and FEL-Based Analysis Focus Topic Room 202A - Session SA+AS+MI-WeA Hard X-Ray Photoemission for Probing Buried Interfaces Moderators: Zahid Hussain, Advanced Light Source, Lawrence Berkeley National Laboratory, Olivier Renault, CEA-LETI, France
2:20pm	PS+EM-WeA1 Etch Strategies for Reducing Defects and Pattern Roughness in BEOL EUV Patterning, <i>Jeffrey Shearer</i> , IBM Research Division, Albany, NY; <i>A. Raley, Q. Lou, J. Kaminsky</i> , TEL Technology Center, America, LLC; <i>L. Meli</i> , IBM Research Division, Albany, NY	SA+AS+MI-WeA1 Element-resolved Electronic Band Structure of Ga(Mn)As Measured by Standing-wave Hard X-ray Angle-resolved Photoemission, <i>Slavomir Nemsak</i> , Advanced Light Source, Lawrence Berkeley National Laboratory; <i>M. Gehlmann, C.-T. Kuo</i> , University of California, Davis; <i>T.-L. Lee</i> , Diamond Light Source Diamond House, Harwell Science and Innovation Campus; <i>L. Plucinski</i> , Forschungszentrum Juelich GmbH, Germany; <i>J. Minar</i> , University of West Bohemia; <i>C.M. Schneider</i> , Forschungszentrum Juelich GmbH, Germany; <i>C.S. Fadley</i> , University of California, Davis
2:40pm	PS+EM-WeA2 Influence of Topological Constraints on the Ion Damage Resistance of Low- <i>k</i> Dielectrics, <i>Qing Su</i> , University of Nebraska-Lincoln; <i>T. Wang, J. Gigax, L. Shao</i> , Texas A&M University; <i>W. Lanford</i> , University at Albany; <i>M. Nastasi</i> , University of Nebraska-Lincoln; <i>L. Li</i> , Intel Corporation; <i>G. Bhattarai, M.M. Paquette</i> , University of Missouri-Kansas City; <i>S.W. King</i> , Intel Corporation	SA+AS+MI-WeA2 Probing Surface Band Bending of Polar GaN by Hard X-ray Photoemission Combined with X-ray Total Reflection, <i>Shigenori Ueda</i> , NIMS, Japan
3:00pm	INVITED: PS+EM-WeA3 BEOL Patterning Challenges for 14nm and Beyond High Volume Manufacturing, <i>Xiang Hu</i> , GLOBALFOUNDRIES; <i>Y. Ren</i> , GLOBALFOUNDRIES; <i>D. Medeiros, P. Lee</i> , GLOBALFOUNDRIES	INVITED: SA+AS+MI-WeA3 Interfaces in Cycled Battery Electrodes: Insights from HAXPES Studies, <i>Julia Maibach</i> , Karlsruhe Institut of Technology (KIT), Germany
3:20pm	Invited talk continues.	Invited talk continues.
3:40pm	BREAK - Complimentary Refreshments in Exhibit Hall	
4:00pm		
4:20pm	INVITED: PS+EM-WeA7 Innovative Approaches for Future Challenges in MOL/BEOL Etch, <i>Ryukichi Shimizu</i> , Tokyo Electron Miyagi Limited, Japan	INVITED: SA+AS+MI-WeA7 Development of Ambient Pressure HAXPES and other HAXPES Measurements at SPring-8 for Buried Interface, <i>Yasumasa Takagi</i> , Japan Synchrotron Radiation Research Institute (JASRI), Japan
4:40pm	Invited talk continues.	Invited talk continues.
5:00pm	PS+EM-WeA9 Gas-phase Pore Stuffing for Low-damage Patterning of Organo-silicate Glass Dielectric Materials, <i>Jean-Francois de Marneffe</i> , IMEC, Belgium; <i>M. Fujikama, T. Yamaguchi, S. Nozawa, R. Niino, N. Sato</i> , Tokyo Electron Technology Solutions Limited; <i>R. Chanson, K. Babaei Gavan</i> , IMEC, Belgium; <i>A. Rezvanov</i> , IMEC, Belgium/Moscow Institute of Physics and Technology; <i>F. Lazzarino, Z. Tokei</i> , IMEC, Belgium	SA+AS+MI-WeA9 Operando HAXPES Investigations of La Manganite-based Resistive Memories, <i>Eugénie Martinez</i> , CEA/LETI-University Grenoble Alpes, France; <i>BM. Meunier</i> , Univ. Grenoble Alpes, CEA, LETI & LMGP, CNRS, France; <i>DP. Pla</i> , Univ. Grenoble Alpes, LMGP, CNRS, France; <i>RRL. Rodriguez-Lamas</i> , Univ. Grenoble Alpes, LMGP, CNRS France; <i>MB. Burriel, CJ. Jimenez</i> , Univ. Grenoble Alpes, LMGP, CNRS, France; <i>JPR. Rueff</i> , Synchrotron SOLEIL, France; <i>Y. Yamashita, S. Ueda</i> , NIMS, Japan; <i>O.J. Renault</i> , CEA/LETI-University Grenoble Alpes, France
5:20pm	PS+EM-WeA10 ALD-Sequential Etch to Address Advanced BEOL Etch/Integration Challenges, <i>Xinghua Sun, Y.-T. Lu, K. Lutker-Lee, A. Raley</i> , TEL Technology Center, America, LLC; <i>D. O'Meara</i> , Tokyo Electron Miyagi Limited; <i>Y. Kikuchi</i> , TEL Technology Center, America, LLC	INVITED: SA+AS+MI-WeA10 Combining Hard and Soft X-ray Angle-resolved Photoemission to Probe the Bulk Electronic Structure of Engineered Quantum Solids, <i>Alexander Gray</i> , Temple University
5:40pm	PS+EM-WeA11 The Underlying Role of Mechanical Rigidity and Topological Constraints in Reactive Ion Etching of Amorphous Materials, <i>Gyanendra Bhattarai, S. Dhungana, B.J. Nordell, A.N. Caruso, M.M. Paquette</i> , University of Missouri-Kansas City; <i>W. Lanford</i> , University at Albany; <i>S.W. King</i> , Intel Corporation	Invited talk continues.
6:00pm	PS+EM-WeA12 Plasma Processing of Phase Change Materials for PCRAM, <i>N.D. Altieri, Ernest Chen, J.P. Chang</i> , University of California, Los Angeles; <i>S.W. Fong, C.M. Neumann, H.-S. Wong</i> , Stanford University; <i>M. Shen, T.B. Lill</i> , Lam Research Corporation	SA+AS+MI-WeA12 Surface/Interface Coupling in Buried Oxide Interfaces, <i>Conan Weiland</i> , National Institute of Standards and Technology (NIST); <i>A.K. Rumaiz</i> , Brookhaven National Laboratory; <i>G.E. Sterbinsky</i> , Argonne National Laboratory; <i>J.C. Woicik</i> , National Institute of Standards and Technology (NIST)

Wednesday Afternoon, October 24, 2018

Surface Science Division Room 203C - Session SS+AS+EM-WeA Semiconducting Surfaces Moderators: Melissa Hines, Cornell University, Ludo Juurlink, Leiden University		Thin Films Division Room 102A - Session TF+EM+MI-WeA Thin Film Processes for Electronics and Optics II Moderators: Hilal Cansizoglu, University of California, Davis, John F. Conley, Jr., Oregon State University	
2:20pm	INVITED: SS+AS+EM-WeA1 Functionalizing Semiconductor Surfaces and Interfaces, <i>Stacey Bent</i> , Stanford University	2:40pm	INVITED: TF+EM+MI-WeA1 What can we Benefit from Nanochemistry of Crystalline Silicon?, <i>Naoto Shirahata</i> , National Institute for Materials Science, Tsukuba, Japan
3:00pm	SS+AS+EM-WeA3 Atomic Structure of UHV-prepared GaP(111)A Surface and its Reactivity Towards Simple Molecules, <i>Denis Potapenko, X. Yang, B.E. Koel</i> , Princeton University	3:20pm	TF+EM+MI-WeA3 Low-temperature Homoepitaxial Growth of Two-dimensional Antimony Superlattices in Silicon, <i>April Jewell, M.E. Hoenk, A.G. Carver, S. Nikzad</i> , Jet Propulsion Laboratory
3:40pm	BREAK - Complimentary Refreshments in Exhibit Hall		
4:00pm			
4:20pm	SS+AS+EM-WeA7 Novel Pathways in Reaching Buried Interfaces of Organic/Inorganic Hybrid Systems: A Mechanistic Understanding of Polymer Adsorption on Passivated Metal Oxide Surfaces, <i>Tom Hauffman, S. Pletinckx, K. Marcoen, F. Cavezza</i> , Vrije Universiteit Brussel, Belgium; <i>L.-L. Fockaert, J.M.C. Mol</i> , Technical University Delft, Netherlands; <i>H. Terryn</i> , Vrije Universiteit Brussel, Belgium	4:40pm	TF+EM+MI-WeA7 Electron-Doped BaZrO ₃ Thin Films Prepared by Topochemical Reduction, <i>Thomas Orvis</i> , University of Southern California
5:00pm	SS+AS+EM-WeA8 Surface Modification of Metal Oxide Surfaces with Gas-Phase Propiolic Acid for Dye Sensitization by Click Reaction, <i>Chuan He, A.V. Teplyakov, B. Abraham, M. Konh, Z. Li, L. Gundlach, S. Bai</i> , University of Delaware; <i>E. Galoppini, H. Fan, R. Harmer</i> , Rutgers, the State University of New Jersey	5:20pm	TF+EM+MI-WeA8 Epitaxial Growth and Electrical Properties of VO ₂ Thin Films, <i>Yang Liu, S. Niu, T. Orvis, H. Zhang, H. Wang, J. Ravichandran</i> , University of Southern California
5:40pm	SS+AS+EM-WeA9 Solar Energy Storage in the Norbornadiene-quadracyclane System: From Surface Science to In-situ Photochemistry and photoscavetoelectrochemistry, <i>M. Schwarz, F. Waidhas, C. Schuschke</i> , Friedrich-Alexander-Universität Erlangen-Nürnberg, Germany; <i>S. Mohr</i> , Friedrich-Alexander-Universität Erlangen-Nürnberg; <i>O. Brummel, T. Döpper, C. Weiss, K. Civale</i> , Friedrich-Alexander-Universität Erlangen-Nürnberg, Germany; <i>M. Jevric</i> , Chalmers University of Technology, Gothenburg, Sweden; <i>J. Bachmann</i> , Friedrich-Alexander-Universität Erlangen-Nürnberg, Germany; <i>A. Görling, A. Hirsch</i> , Friedrich-Alexander-Universität Erlangen-Nürnberg, Germany; <i>K. Moth-Poulsen</i> , Chalmers University of Technology, Gothenburg, Sweden; <i>Jörg Libuda</i> , Friedrich-Alexander-Universität Erlangen-Nürnberg, Germany	6:00pm	TF+EM+MI-WeA9 A Novel Technique for the Growth of Gallium Oxide Nanowires for UV Detection, <i>Badriyah Alhalaili</i> , UC, Davis; <i>R.J. Bunk, H. Mao</i> , UC Davis; <i>R. Vidu</i> , UC, Davis; <i>H. Cansizoglu</i> , UC Davis; <i>M.S. Islam</i> , UC, Davis
5:40pm	SS+AS+EM-WeA10 In-situ Characterization of Photon induced Chemistries in Organotin Clusters with Ambient Pressure XPS, <i>J. Trey Diulus¹, R.T. Frederick</i> , Oregon State University; <i>M. Li</i> , Rutgers, the State University of New Jersey; <i>D.C. Hutchison, I. Lyubinetsky, L. Árnadóttir, M.R. Olsen</i> , Oregon State University; <i>E.L. Garfunkel</i> , Rutgers, the State University of New Jersey; <i>M. Nyman</i> , Oregon State University; <i>H. Ogasawara</i> , SLAC National Accelerator Laboratory; <i>G.S. Herman</i> , Oregon State University	6:00pm	TF+EM+MI-WeA10 Enhanced Efficiency in Photon-trapping Ge-on-Si Photodiodes for Optical Data Communication, <i>Hilal Cansizoglu, C. Bartolo Perez, Y. Gao, E. Ponizovskaya Devine, S. Ghandiparsi, K.G. Polat, H.H. Mamatz, M.F. Cansizoglu</i> , University of California, Davis; <i>T. Yamada</i> , University of California, Santa Cruz; <i>A.F. ElRefaei, S.Y. Wang</i> , W&WSens Devices, Inc.; <i>M.S. Islam</i> , University of California, Davis
6:00pm	SS+AS+EM-WeA11 Integrated Photonics Driven Electron Emission from LaB ₆ Nanoparticles, <i>Fatemeh Rezaeifar, R. Kapadia</i> , University of Southern California	6:00pm	TF+EM+MI-WeA11 Correlating Composition and Structure with Optical Properties of Combinatorial Sputtered Thin Film Au _x Al _{1-x} Alloys, <i>Robyn Collette</i> , University of Tennessee Knoxville; <i>Y. Wu, J.P. Camden</i> , University of Notre Dame; <i>P.D. Rack</i> , University of Tennessee Knoxville
6:00pm	SS+AS+EM-WeA12 Photon Stimulated Desorption and Diffusion of CO on TiO ₂ (110), <i>Nikolay Petrik, R. Mu, A. Dahal, Z.-T. Wang, Z. Dohnalek, I. Lyubinetsky, G.A. Kimmel</i> , Pacific Northwest National Laboratory	6:00pm	TF+EM+MI-WeA12 The Multifunctional TiO ₂ Thin Films Sensor, <i>Awais Ali, M. Alam, S. Nasser, N. Akbar, A. Saeed, A.S. Bhatti</i> , COMSATS Institute of Information Technology, Islamabad Pakistan

¹ Morton S. Traum Award Finalist

Anticipated Schedule Thursday, October 25, 2018

Anticipated Schedule Thursday Morning, October 25

8:00 AM	_____
8:20 AM	_____
8:40 AM	_____
9:00 AM	_____
9:20 AM	_____
9:40 AM	_____
10:00 AM	_____
10:20 AM	_____
10:40 AM	_____
11:00 AM	_____
11:20 AM	_____
11:40 AM	_____
12:00 PM	_____

Anticipated Schedule Thursday Lunch, October 25

When	_____
Where	_____
With	_____

Anticipated Schedule Thursday Afternoon, October 25

1:00 PM	_____
1:20 PM	_____
1:40 PM	_____
2:00 PM	_____
2:20 PM	_____
2:40 PM	_____
3:00 PM	_____
3:20 PM	_____
3:40 PM	_____
4:00 PM	_____
4:20 PM	_____
4:40 PM	_____
5:00 PM	_____
5:20 PM	_____
5:40 PM	_____

Special Events Thursday

Special Events Thursday

10:00 AM AVS Presidents Panel/Hall A
10:00 AM Session Coffee Break/Hall A
12:20 PM Exhibit Finale & Refreshments/Hall A
12:20 PM PSTD Coburn and Winters Award Ceremony/104A
12:20 PM Surface Science Division Mort Traum Awards Ceremony/203C
12:30 PM 2019 Program Committee Chairs' Meeting & Lunch/Seaview-Hyatt Regency (by invitation)
12:30 PM AVS Business Meeting/101A
12:30 PM AVS Member Center: Professional Development--"Work Life Satisfaction" & Lunch/103C
3:30 PM History Committee Meeting/Shoreline B-Hyatt Regency (by invitation)
6:00 PM Thursday Poster Session & Refreshments/Hall B
6:30 PM 2018/2019 Program Committee Reception and Dinner/Seaview-Hyatt Regency (by invitation)
7:00 PM SSS Editorial Board Dinner/Shoreline A-Hyatt Regency (by invitation)
8:30 AM-5:00 PM Short Course Program/Various Rooms

Thursday Morning, October 25, 2018

2D Materials Focus Topic Room 201B - Session 2D+EM+MI+MN+NS+SS-ThM Novel 2D Materials Moderator: Han Wang, University of Southern California		Actinides and Rare Earths Focus Topic Room 202C - Session AC+AS+SA-ThM Nuclear Power, Forensics, and Other Applications Moderator: Ladislav Havela, Charles University, Prague, Czech Republic
8:00am		INVITED: AC+AS+SA-ThM1 Electron Microscopy in Nuclear Forensics, <i>Edgar Buck, D.R. Reilly, J.M. Schwantes, J.A. Soltis, T.Q. Meadows, D.A. Meier, J.F. Corbey</i> , Pacific Northwest National Laboratory
8:20am	2D+EM+MI+MN+NS+SS-ThM2 Controlled Growth of 2D Ni-Silicate and Silica Films on Ni _x Pd _{1-x} (111) Substrates, <i>Chao Zhou, X. Liang, G.S. Hutchings, Z. Fishman, J.-H. Jhang, S. Hu, S. Ismail-Beigi, U.D. Schwarz, E.I. Altman</i> , Yale University	Invited talk continues.
8:40am	INVITED: 2D+EM+MI+MN+NS+SS-ThM3 Topological Materials, <i>Hsin Lin</i> , Institute of Physics, Academia Sinica	INVITED: AC+AS+SA-ThM3 New Frontiers with Fission Track Analysis and TOF-SIMS Techniques, <i>Itzhak Halevy</i> , Nrcn Israel; <i>R. Radus</i> , Ben Gurion University, Israel; <i>S. Maskova</i> , Charles University, Prague, Czech Republic; <i>A. Kogan, S. Samuha, D. Gridchin, E. Grinberg, E. Boblil, N. Haikin</i> , IAEC-NRCN, Israel; <i>I. Orion</i> , Ben-Gurion University -Negev, Israel; <i>A. Weiss</i> , Faculty of Engineering, Bar-Ilan University, Israel
9:00am	Invited talk continues.	Invited talk continues.
9:20am	2D+EM+MI+MN+NS+SS-ThM5 Few-Layer Rhenium Disulfide Synthesized Via Chemical Vapor Deposition, <i>Michael Valentin</i> , Army Research Laboratory; <i>A. Guan, A.E. Nguyen, I. Lu, C.S. Merida, M.J. Gomez</i> , University of California, Riverside; <i>R.A. Burke, M. Dubey</i> , Army Research Laboratory; <i>L. Bartels</i> , University of California, Riverside	INVITED: AC+AS+SA-ThM5 Predictive Nuclear Forensics: Fundamental Frameworks to Fill Missing Pieces, <i>Jenifer Shafer, M. Koehl, A. Baldwin, D. Wu</i> , Colorado School of Mines; <i>R. Rundberg</i> , Los Alamos National Laboratory; <i>M. Servis</i> , Washington State University; <i>T. Kawano</i> , Los Alamos National Laboratory
9:40am	2D+EM+MI+MN+NS+SS-ThM6 Dipolar Disorder of a van-der-Waals Surface Revealed by Direct Atomic Imaging, <i>M.A. Susner</i> , Air Force Research Laboratory; <i>M.A. McGuire, Petro Maksymovych</i> , Oak Ridge National Laboratory	Invited talk continues.
10:00am		
10:20am	BREAK - Complimentary Coffee in Exhibit Hall – AVS Presidents Panel, Booth #168, Exhibit Hall	
10:40am		
11:00am	2D+EM+MI+MN+NS+SS-ThM10 Advanced ARPES Analyzer and Momentum Microscope KREIOS 150 – Concepts and first results on layered materials and topological insulators, <i>Paul Dietrich, M. Wietstruk, T.U. Kampen, A. Thissen</i> , SPECS Surface Nano Analysis GmbH, Germany	AC+AS+SA-ThM10 Soft X-ray Synchrotron Radiation Spectromicroscopy Studies of Radioactive Materials, <i>David Shuh</i> , Lawrence Berkeley National Laboratory; <i>A. Altman</i> , Lawrence Berkeley National Laboratory and UC Berkeley; <i>A.L.D. Kilcoyne, S.G. Minasian, J.I. Pacold, D.E. Smiles, T. Tyliszczak, D. Vine</i> , Lawrence Berkeley National Laboratory; <i>L. He, J. Harp, M. Meyer</i> , Idaho National Laboratory; <i>C. Degueldre</i> , University of Lancaster, Switzerland
11:20am	2D+EM+MI+MN+NS+SS-ThM11 Carbon Nanomembranes with Sub-nanometer Channels: 2D Materials for Water Purification with High Selectivity and Highest Permeance, <i>Y. Yang, P. Dementyev, N. Biere, D. Emmrich, P. Stohmann, R. Korzetz, X.H. Zhang, A. Beyer, S. Koch, D. Anselmetti, Armin Gölzhäuser</i> , Bielefeld University, Germany	AC+AS+SA-ThM11 Comparison of the Oxidation Rates for Alpha Versus Delta Plutonium by X-ray Photoelectron Spectroscopy, <i>Art Nelson, S.B. Donald, D.J. Roberts, W. McLean</i> , Lawrence Livermore National Laboratory
11:40am	INVITED: 2D+EM+MI+MN+NS+SS-ThM12 Discovery of Dirac Monolayers and Elucidation of Functionalites by Advanced Soft X-ray Spectroscopy, <i>Iwao Matsuda</i> , University of Tokyo, Japan	AC+AS+SA-ThM12 A Single-Stage AMS Detector for Secondary Ion Mass Spectrometry and its Applications to Nuclear Materials Analyses, <i>David Willingham, E.E. Groopman, K.S. Grabowski</i> , U.S. Naval Research Laboratory; <i>L. Sangely</i> , International Atomic Energy Agency; <i>A.P. Meshik, O.V. Pravdivtseva</i> , Washington University in St. Louis; <i>D.G. Weisz, K.B. Knight</i> , Lawrence Livermore National Laboratory
12:00pm	Invited talk continues.	AC+AS+SA-ThM13 Physicochemical Properties of Ag in Annealed ZrN/SiC/Ag Heterostructures Used to Simulate TRISO Nuclear Fuels, <i>Jeff Terry, M. Warren, R. Seibert</i> , Illinois Institute of Technology

Thursday Morning, October 25, 2018

Applied Surface Science Division Room 204 - Session AS+SE-ThM Applied Surface Analysis of Novel, Complex or Challenging Materials Moderators: Michael Brumbach, Sandia National Laboratories, Thomas Grehl, IONTOF GmbH, Germany		Biomaterial Interfaces Division Room 101B - Session BI-ThM Biomolecules and Biophysics at Interfaces Moderator: Joe Baio, Oregon State University
8:00am	INVITED: AS+SE-ThM1 Understanding the Surface of Complex Oxides used in High Temperature Electrochemical Devices, <i>John Kilner</i> , Imperial College London, UK; <i>J.W. Druce</i> , International Institute for Carbon Neutral Energy Research (I2CNER), Japan; <i>H. Tellez, A. Staykov</i> , International Institute for Carbon Neutral Energy Research (I2CNER)	INVITED: BI-ThM1 Bioinspired Adaptive Reconfigurable Material Systems based on Smart Hydrogels, <i>Ximin He</i> , University of California, Los Angeles
8:20am	Invited talk continues.	Invited talk continues.
8:40am	AS+SE-ThM3 Vectorial Method used to Monitor a XPS Evolving System: Titanium Oxide Thin Films under UV Illumination, <i>S. Bechu</i> , Institut Photovoltaïque d'Ile-de-France; <i>N. Fairley</i> , Casa Software Ltd, UK; <i>L. Brohan</i> , Institut des materiaux Jean Rouxel, France; <i>Vincent Fernandez</i> , Université de Nantes, Institut des matériaux Jean Rouxel, France; <i>M. Richard-Plouet</i> , Institut des matériaux Jean Rouxel, France	BI-ThM3 Importance of a In Depth Characterisation for the Design of Functional Gold Nanoparticles for Bioapplications, <i>R. Capomaccio, I. Ojea-Jimenez, D. Mehn, P. Colpo, D. Gilliland</i> , European Commission - Joint Research Centre, Italy; <i>R. Hussain, G. Siligardi</i> , Diamond Light Source Diamond House, Harwell Science and Innovation Campus, UK; <i>L. Calzolai, Giacomo Ceccone</i> , European Commission - Joint Research Centre, Italy
9:00am	AS+SE-ThM4 XPS Characterization of Copper and Silver Nanostructures, <i>Tatyana Bendikov, M.D. Susman, F. Muench, A. Vaskevich, I. Rubinstein</i> , Weizmann Institute of Science, Israel	BI-ThM4 A Model Membrane Microsystem for Measurement of the Kinetics of Transmembrane Proton Transport, <i>J.P. Madsen, A. Johnson, M.L. Cartron, N.C. Hunter, S.P. Armes, Graham Leggett</i> , University of Sheffield, UK
9:20am	AS+SE-ThM5 Quantification of Hydroxyl, Major Element and Trace Element Concentrations in Oxide Glasses by Quadrupole SIMS., <i>Albert Fahey, A.R. Sarafian, T. Dimond</i> , Corning Inc.	BI-ThM5 Theranostics Gold Nanoparticles for Brain Cancer Applications, <i>I. Naletova, L.M. Cucci, F. D'Angel, C.D. Arfuso, G. Lupo</i> , University of Catania, Italy; <i>A. Magri</i> , National Council of Research (CNR), Italy; <i>C. Satriano</i> , University of Catania, Italy; <i>Diego La Mendola</i> , University of Pisa, Italy
9:40am	AS+SE-ThM6 Modification of Sputtered Carbon Surfaces in Biosensor Arrays, <i>Varun Jain, M.R. Linford</i> , Brigham Young University	BI-ThM6 Repeated Biorecognition Assays Based on Reversibly Biofunctionalized Surfaces, <i>A. Francesko</i> , University of Minho, Portugal; <i>S. Lanceros-Mendez</i> , IKERBASQUE, Basque Foundation for Science, Spain; <i>J.A.E. Määttö, V.P. Hytönen</i> , University of Tampere, Finland; <i>E. Fernandes</i> , International Iberian Nanotechnology Laboratory (INL), Portugal; <i>J.R. Guerreiro</i> , International Iberian Nanotechnology Laboratory (INL), Portugal; <i>Dmitri Petrovykh</i> , International Iberian Nanotechnology Laboratory, Portugal
10:00am	BREAK - Complimentary Coffee in Exhibit Hall – AVS Presidents Panel, Booth #168, Exhibit Hall	
10:20am	BREAK - Complimentary Coffee in Exhibit Hall – AVS Presidents Panel, Booth #168, Exhibit Hall	
10:40am	BREAK - Complimentary Coffee in Exhibit Hall – AVS Presidents Panel, Booth #168, Exhibit Hall	
11:00am	AS+SE-ThM10 The Role of Surface Analysis in Characterization of Synthetic Opioids: TOF-SIMS imaging of Fentanyl and Fentanyl Analogs for Forensics and First Responder Safety, <i>Greg Gillen, S. Muramoto, J. Verkouteren, E. Sisco</i> , National Institute of Standards and Technology (NIST)	BI-ThM10 Non-equilibrium Thermodynamic Model for DNA at Nanochannel Junctions, <i>Saroj Dangi</i> , North Carolina State University
11:20am	AS+SE-ThM11 3D TOF SIMS, Parallel Imaging MS/MS, and XPS Analysis of Glitterwing (<i>Chalcopteryx rutilans</i>) Damselfly Wings, <i>Ashley Ellsworth, D.M. Carr, G.L. Fisher, B.W. Schmidt</i> , Physical Electronics; <i>W.W. Valeriano, W.N. Rodrigues</i> , UFMG, Brazil	BI-ThM11 Dipeptide Nanocontainers Immobilised on Graphene Nanoplatforms for Drug-delivery Applications, <i>V.C.L. Caruso</i> , University of Catania, Italy; <i>G. Trapani</i> , University of Catania and Scuola Superiore di Catania, Italy; <i>L.M. Cucci, I. Naletova</i> , University of Catania, Italy; <i>D. La Mendola</i> , University of Pisa, Italy; <i>Cristina Satriano</i> , University of Catania, Italy
11:40am	AS+SE-ThM12 Characterization of Aniline Dyes in the Modern Colored Papers and the Prints of José Posada, <i>J.K. Hedlund, L.D. Gelb, Amy Walker</i> , University of Texas at Dallas	BI-ThM12 Seriatim Operando STM and FTIR Study of Phospholipid Membrane Phase Transition Driven by Electrochemical Potential Control, <i>Taro Yamada</i> , RIKEN, Japan; <i>S. Matsunaga, H. Shimizu</i> , The University of Tokyo; <i>T. Kobayashi</i> , RIKEN, Japan; <i>M. Kawai</i> , The University of Tokyo
12:00pm	AS+SE-ThM13 GaAs and Si Surface Energies derived from Three Liquid Contact Angle Analysis (3LCAA), as a Function of Oxygen Coverage for Heterogeneous Nano-Bonding™, <i>Sukesh Ram</i> , Arizona State University; <i>K.L. Kavanagh</i> , Simon Fraser University, Canada; <i>F.J. Ark, C.E. Cornejo, T.C. Diaz, M.E. Bertram, S.R. Narayan, J.M. Day, M. Mangus, R.J. Culbertson, N. Herbots</i> , Arizona State University; <i>R. Islam</i> , Cactus Materials, Inc.	BI-ThM13 Mitochondria Localized Polymerization for New Cancer Therapy, <i>Ja-Hyoung Ryu</i> , Ulsan National Institute of Science and Technology, Republic of Korea

Thursday Morning, October 25, 2018

Electronic Materials and Photonics Division Room 101A - Session EM+MI+MN+NS-ThM Nanostructures for Electronic and Photonic Devices Moderators: Sang M. Han, University of New Mexico, Jason Kawasaki, University of Wisconsin - Madison		Fundamental Discoveries in Heterogeneous Catalysis Focus Topic Room 201A - Session HC+SS-ThM In-situ Analysis of Heterogeneously Catalyzed Reactions Moderator: Sharani Roy, University of Tennessee Knoxville
8:00am	INVITED: EM+MI+MN+NS-ThM1 Extreme Nanophotonics from Ultrathin Metallic Junctions, <i>Maiken Mikkelsen</i> , Duke University	HC+SS-ThM1 Structural Characterization of ZnO on Cu(111) by using STM and XPS: Role of Cu-ZnO Interface in Methanol Synthesis, <i>Mausumi Mahapatra, J.A. Rodriguez</i> , Brookhaven National Laboratory
8:20am	Invited talk continues.	HC+SS-ThM2 Dissociative Adsorption of CO ₂ on Cu-surfaces, <i>Benjamin Hagman</i> , Lund University, Sweden; <i>A. Posada-Borbón, A. Schaefer</i> , Chalmers University of Technology, Gothenburg, Sweden; <i>C. Zhang</i> , Lund University, Sweden; <i>M. Shipilin</i> , Stockholm University, Sweden; <i>N.M. Martin</i> , Chalmers University of Technology, Gothenburg, Sweden; <i>E. Lundgren</i> , Lund University, Sweden; <i>H. Grönbeck</i> , Chalmers University of Technology, Gothenburg, Sweden; <i>J. Gustafson</i> , Lund University, Sweden
8:40am	EM+MI+MN+NS-ThM3 The Geode Process: A Route to the Large-Scale Manufacturing of Functionally-Encoded Semiconductor Nanostructures, <i>M. Mujica, G. Tutuncuoglu, V. Breedveld, S.H. Behrens, Michael Filler</i> , Georgia Institute of Technology	HC+SS-ThM3 Infrared Spectroscopy of Carbon Dioxide Hydrogenation over the Cu(111) Surface Under Ambient Pressure Conditions, <i>C.M. Kruppe, Michael Trenary</i> , University of Illinois at Chicago
9:00am	EM+MI+MN+NS-ThM4 Disordered Microsphere-Based Coatings for Effective Radiative Cooling under Direct Sunlight, <i>S. Atiganyanun, J. Plumley, K. Hsu</i> , University of New Mexico; <i>T.L. Peng</i> , Air Force Research Laboratory; <i>Sang M. Han, S.E. Han</i> , University of New Mexico	HC+SS-ThM4 Oxide Formation on Ir(100) Studied by in-Situ Surface X-ray-Diffraction, <i>Stefano Albertin, U. Hejral</i> , Lund University, Sweden; <i>R. Felici</i> , SPIN-CNR, Italy; <i>R. Martin</i> , University of Florida; <i>M. Jankowski</i> , ESRF, France; <i>J.F. Weaver</i> , University of Florida; <i>E. Lundgren</i> , Lund University, Sweden
9:20am	EM+MI+MN+NS-ThM5 Assessing Strain Relaxation in Nanostructured InGaN Multiple Quantum Wells Using X-Ray Diffraction Reciprocal Space Mapping and Photoluminescence Spectroscopy, <i>Ryan Ley, C.D. Pynn, M. Wong, S.P. DenBaars, M.J. Gordon</i> , University of California at Santa Barbara	INVITED: HC+SS-ThM5 Dynamic Nanocatalysts: Environmental Effects, <i>Beatriz Roldan Cuenya</i> , Fritz-Haber Institute of the Max Planck Society
9:40am	EM+MI+MN+NS-ThM6 Scalable, Tunable, and Polarization-Independent High Contrast Grating Reflectors for Integration into Resonant-Cavity micro-LEDs, <i>Pavel Shapurenska, S.P. DenBaars, M.J. Gordon</i> , University of California at Santa Barbara	Invited talk continues.
10:00am		
10:20am	BREAK - Complimentary Coffee in Exhibit Hall – AVS Presidents Panel, Booth #168, Exhibit Hall	
10:40am		
11:00am	INVITED: EM+MI+MN+NS-ThM10 Nano-optical Activation of Defect-bound Excitons in Monolayer WSe ₂ : Towards Room-temperature 2D Single-photon Optoelectronics, <i>Jim Schuck</i> , Columbia University	HC+SS-ThM10 Atomic Layer Deposition (ALD) Synthesis of Au/TiO ₂ /SBA-15 Catalysts, <i>W. Ke, X. Qin, Francisco Zaera</i> , University of California, Riverside
11:20am	Invited talk continues.	HC+SS-ThM11 Enhanced Stability of Pt/Cu Single-Atom Alloy Catalysts: In Situ Characterization of the Pt/Cu(111) Surface in an Ambient Pressure of CO, <i>Juan Pablo Simonovis Santamaria</i> , Brookhaven National Laboratory
11:40am	EM+MI+MN+NS-ThM12 Light Scattering Properties of Silver Nanoprisms in Different Environments, <i>Yuri Strzhemechny</i> , Texas Christian University; <i>S. Requena</i> , Harris Night Vision; <i>H. Doan</i> , Texas Christian University; <i>S. Raut</i> , University of North Texas Health Science Center; <i>Z. Gryczynski</i> , Texas Christian University; <i>I. Gryczynski</i> , University of North Texas Health Science Center	INVITED: HC+SS-ThM12 Multiscale Modelling of Metal Oxide Interfaces and Nanoparticles, <i>Kersti Hermansson, P. Mitev, J. Kullgren, P. Broqvist</i> , Dept of Chemistry-Ångström, Uppsala University, Sweden
12:00pm	EM+MI+MN+NS-ThM13 Core-Shell Processing of BTO Nanocomposites for Optimal Dielectric Properties, <i>Kimberly Cook-Chennault</i> , Rutgers University	Invited talk continues.

Thursday Morning, October 25, 2018

Advanced Ion Microscopy Focus Topic Room 203B - Session HI+AS-ThM Advanced Ion Microscopy & Surface Analysis Moderators: Gregor Hlawacek, Helmholtz Zentrum Dresden-Rossendorf, Germany, Shida Tan, Intel Corporation		Magnetic Interfaces and Nanostructures Division Room 203A - Session MI+2D-ThM Magnetism at the Nanoscale Moderators: Axel Enders, University of Bayreuth, Germany, Hendrik Ohldag, SLAC National Accelerator Laboratory
8:00am	INVITED: HI+AS-ThM1 Pushing the Limits: Secondary Ion Mass Spectrometry with Helium Ion Microscopy, <i>Alex Belianinov</i> , Oak Ridge National Laboratory; <i>S. Kim</i> , Pusan National University, South Korea; <i>M. Lorenz</i> , University of Tennessee Knoxville; <i>A.V. Ievlev</i> , <i>A. Trofimov</i> , <i>O.S. Ovchinnikova</i> , Oak Ridge National Laboratory	
8:20am	Invited talk continues.	MI+2D-ThM2 Magnetic Competition in $\text{La}_{0.7}\text{Sr}_{0.3}\text{MnO}_3$ Thin Films, <i>Mikel B. Holcomb</i> , West Virginia University
8:40am	HI+AS-ThM3 When HIM meets SIMS, <i>Tom Wirtz</i> , Luxembourg Institute of Science and Technology (LIST), Luxembourg; <i>O. De Castro</i> , <i>J. Lovric</i> , Luxembourg Institute of Science and Technology (LIST); <i>J.-N. Audinot</i> , Luxembourg Institute of Science and Technology (LIST), Luxembourg	INVITED: MI+2D-ThM3 Ferromagnetism in 2D Materials, <i>Jiabao Yi</i> , The University of New South Wales, Australia
9:00am	HI+AS-ThM4 Deciphering Chemical Nature of Ferroelastic Twin Domain in MAPbI_3 perovskite by Helium Ion Microscopy Secondary Ion Mass Spectrometry, <i>Yongtao Liu</i> , University of Tennessee; <i>L. Collins</i> , Oak Ridge National Laboratory; <i>R. Proksch</i> , Asylum Research an Oxford Instruments Company; <i>S. Kim</i> , Oak Ridge National Laboratory; <i>B.R. Watson</i> , University of Tennessee; <i>B.L. Doughty</i> , Oak Ridge National Laboratory; <i>T.R. Calhoun</i> , <i>M. Ahmadi</i> , University of Tennessee; <i>A.V. Ievlev</i> , <i>S. Jesse</i> , <i>S. Retterer</i> , <i>A. Belianinov</i> , <i>K. Xiao</i> , <i>J. Huang</i> , <i>B.G. Sumpter</i> , <i>S.V. Kalinin</i> , Oak Ridge National Laboratory; <i>B.H. Hu</i> , University of Tennessee; <i>O.S. Ovchinnikova</i> , Center for Nanophase Materials Sciences, Oak Ridge National Laboratory	Invited talk continues.
9:20am	INVITED: HI+AS-ThM5 Helium and Neon Ion Microscopy for Microbiological Applications, <i>Ilari Maasilita</i> , University of Jyvaskyla, Finland	INVITED: MI+2D-ThM5 New Insights into Nanomagnetism by Low-temperature Spin-polarized Scanning Tunneling Microscopy, <i>Dirk Sander</i> , Max Planck Institute of Microstructure Physics, Germany
9:40am	Invited talk continues.	Invited talk continues.
10:00am		
10:20am	BREAK - Complimentary Coffee in Exhibit Hall – AVS Presidents Panel, Booth #168, Exhibit Hall	
10:40am		
11:00am	HI+AS-ThM10 Characterization of Soot Particles by Helium Ion Microscopy, <i>André Beyer</i> , <i>D. Emmrich</i> , <i>M. Salamanca</i> , <i>L. Ruwe</i> , <i>H. Vieker</i> , <i>K. Kohse-Höinghaus</i> , <i>A. Gölzhäuser</i> , Bielefeld University, Germany	INVITED: MI+2D-ThM10 Materials Optimization to Form Skyrmiion and Skyrmiion Lattices, <i>Eric Fullerton</i> , University of California at San Diego
11:20am	HI+AS-ThM11 Development of a Surface Science Spectra Submission Form for Low Energy Ion Scattering (LEIS), <i>M.R. Linford</i> , <i>Tahereh Gholian Aval</i> , Brigham Young University; <i>H.H. Brongersma</i> , <i>T. Grehl</i> , IONTOF GmbH, Germany	Invited talk continues.
11:40am	HI+AS-ThM12 Time of Flight Backscatter and Secondary Ion Mass Spectrometry in the Helium Ion Microscope, <i>Nico Klingner</i> , <i>R. Heller</i> , <i>G. Hlawacek</i> , <i>J. von Borany</i> , <i>S. Fascko</i> , Helmholtz Zentrum Dresden-Rossendorf, Germany	MI+2D-ThM12 Giant Magnetostriction and Low Loss in FeGa/NiFe Nanolaminates for Strain-Mediated Multiferroic Micro-Antenna Applications, <i>Kevin Fitzell</i> ¹ , <i>C.R. Remerter</i> , University of California, Los Angeles; <i>N. Virushababossi</i> , University of Texas at Dallas; <i>M.E. Jamei</i> , National Institute of Standards and Technology (NIST); <i>A. Barra</i> , University of California, Los Angeles; <i>J.A. Borchers</i> , <i>B.J. Kirby</i> , National Institute of Standards and Technology (NIST); <i>G.P. Carman</i> , University of California, Los Angeles; <i>R.M. Henderson</i> , University of Texas at Dallas; <i>J.P. Chang</i> , University of California, Los Angeles
12:00pm	HI+AS-ThM13 Helium and Neon Focused Ion Beam Hard Mask Lithography on Atomic Layer Deposition Films, <i>Matthew Hunt</i> , California Institute of Technology; <i>J. Yang</i> , University of Texas at Austin; <i>S.A. Wood</i> , <i>O.J. Painter</i> , California Institute of Technology	MI+2D-ThM13 Structural and Electronic Origin of Stable Perpendicular Magnetic Anisotropy in $\text{Pt}/\text{Co}/\text{Pt}$ magnetic ultra-thin film with Ti Buffer Layer, <i>Bahaa Sakar</i> , Gebze Technical University, Turkey; <i>Z. Balogh-Michels</i> , <i>A. Neels</i> , Empa, Swiss Federal Laboratories for Materials Science and Technology, Switzerland; <i>O. Öztürk</i> , Gebze Technical University, Turkey

¹ Falicov Student Award Finalist

Thursday Morning, October 25, 2018

MEMS and NEMS Group Room 202B - Session MN+2D+AN+MP+NS-ThM Optomechanics and 2D NEMS Moderator: Max Zenghui Wang, University of Electronic Science and Technology of China		Nanometer-scale Science and Technology Division Room 102B - Session NS+AN+EM+MI+MN+MP+PS+RM-ThM Nanopatterning and Nanofabrication Moderators: Brian Hoskins, National Institute of Standards and Technology (NIST), Meredith Metzler, University of Pennsylvania, Leonidas Ocola, T.J. Watson Research Center
8:00am	INVITED: MN+2D+AN+MP+NS-ThM1 Towards Microwave to Telecom Wavelength Quantum Information Transfer using Cavity Optomechanics, <i>John Davis</i> , University of Alberta, Canada	NS+AN+EM+MI+MN+MP+PS+RM-ThM1 Femtosecond Laser Processing of Ceria-Based Micro Actuators, <i>Jenny Shklovsky</i> , Tel Aviv University, Israel; <i>E. Mishuk</i> , Weizmann Institute of Science, Israel; <i>Y. Berg</i> , Orbotech Ltd, Israel; <i>N. Vengerovsky</i> , <i>Y. Sverdlov</i> , Tel Aviv University, Israel; <i>I. Lubomirsky</i> , Weizmann Institute of Science, Israel; <i>Z. Kotler</i> , Orbotech Ltd; <i>S. Krylov</i> , <i>Y. Shacham-Diamond</i> , Tel Aviv University, Israel
8:20am	Invited talk continues.	NS+AN+EM+MI+MN+MP+PS+RM-ThM2 Synthesis of Functional Particles by Condensation and Polymerization of Monomer Droplets in Silicone Oils, <i>Prathamesh Karandikar</i> , <i>M. Gupta</i> , University of Southern California
8:40am	INVITED: MN+2D+AN+MP+NS-ThM3 1D/2D NEMS Quantum Information Processing, <i>Guangwei Deng</i> , Institute of Fundamental and Frontier Sciences, University of Electronic Science and Technology of China 610054, Chengdu, Sichuan, China.0	INVITED: NS+AN+EM+MI+MN+MP+PS+RM-ThM3 Competition Between Scale and Perfection in Self-assembling Structures, <i>James Liddle</i> , NIST Center for Nanoscale Science and Technology
9:00am	Invited talk continues.	Invited talk continues.
9:20am		NS+AN+EM+MI+MN+MP+PS+RM-ThM5 Polymer Templatized Annealing of DNA Patterned Gold Nanowires, <i>Tyler Westover</i> , <i>B. Aryal</i> , <i>R.C. Davis</i> , <i>A. Woolley</i> , <i>J. Harb</i> , Brigham Young University
9:40am		
10:00am		
10:20am	BREAK - Complimentary Coffee in Exhibit Hall – AVS Presidents Panel, Booth #168, Exhibit Hall	
10:40am		
11:00am		INVITED: NS+AN+EM+MI+MN+MP+PS+RM-ThM10 Directed Self-assembly of Block Copolymers for Applications in Nanolithography, <i>Paul Nealey</i> , University of Chicago
11:20am	MN+2D+AN+MP+NS-ThM11 Reconfigurable Resonant Responses in Atomic Layer 2D Nanoelectromechanical Systems (NEMS), <i>Zenghui Wang</i> , University of Electronic Science and Technology of China; <i>R. Yang</i> , <i>P.X.-L. Feng</i> , Case Western Reserve University	Invited talk continues.
11:40am	INVITED: MN+2D+AN+MP+NS-ThM12 Cavity Optomechanics: Dynamics and Applications, <i>Eyal Buks</i> , Israel Institute of Technology, Israel	NS+AN+EM+MI+MN+MP+PS+RM-ThM12 Three Dimensional Mesoporous Silicon Nanowire Network Fabricated by Metal-Assisted Chemical Etching, <i>Deepak Ganta</i> , <i>C. Guzman</i> , <i>R. Villanueva</i> , TAMIU
12:00pm	Invited talk continues.	NS+AN+EM+MI+MN+MP+PS+RM-ThM13 Enhancing Light Extraction from Free-standing InGaN/GaN light Emitters Using Bio-inspired Backside Surface Structuring, <i>L. Chan</i> , <i>C.D. Pynn</i> , <i>S.P. DenBaars</i> , <i>Michael Gordon</i> , University of California at Santa Barbara

Thursday Morning, October 25, 2018

Plasma Science and Technology Division Room 104C - Session PS+EM+TF-ThM Atomic Layer Processing: Atomic Layer Etching Moderators: Erwin Kessels, Eindhoven University of Technology, The Netherlands, Mingmei Wang, TEL Technology Center, America, LLC		Plasma Science and Technology Division Room 104A - Session PS-ThM Plasma Sources Moderators: TaeSeung Cho, Applied Materials, GeunYoung Yeom, Sungkyunkwan University, Republic of Korea
8:00am	INVITED: PS+EM+TF-ThM1 Precise Flux Control of Ions and Radicals using Electron Beam Generated Plasmas, <i>David Boris</i> , U.S. Naval Research Laboratory	PS-ThM1 Model of a Radio-Frequency Low Electron Temperature Plasma Source, <i>Shahid Rauf, L. Dorf, K.S. Collins</i> , Applied Materials
8:20am	Invited talk continues.	PS-ThM2 Electron-beam Sustained Plasma with Unique Characteristic of Low Electron Temperature at Very Low Pressure, <i>Zhiying Chen</i> , Tokyo Electron America, Inc.; <i>K. Nagaseki</i> , Tokyo Electron Miyagi, Ltd., Japan; <i>J. Blakeney, M. Doppel, P.L.G. Ventzek</i> , Tokyo Electron America, Inc.; <i>A. Ranjan</i> , TEL Technology Center, America, LLC.
8:40am	PS+EM+TF-ThM3 Demonstration of Self-limiting Nature and Selectivity Control in Annealing Procedures for Rapid Thermal-Cyclic ALE of W, TiN, and SiN, <i>Kazunori Shinoda, H. Kobayashi</i> , Hitachi, Japan; <i>N. Miyoshi, K. Kawamura, M. Izawa</i> , Hitachi High-Technologies, Japan; <i>K. Ishikawa, M. Hori</i> , Nagoya University, Japan	INVITED: PS-ThM3 Hydrid Plasma Source with Inductive and Capacitive Fields: Fundamental Understanding and Nano-applications, <i>Hyo-Chang Lee</i> , Korea Research Institute of Standards and Science (KRISS)
9:00am	PS+EM+TF-ThM4 Mechanisms for Atomic Layer Etching of Metal Films by the Formation of Beta-diketonate Metal Complexes, <i>Tomoko Ito, K. Karahashi, S. Hamaguchi</i> , Osaka University, Japan	Invited talk continues.
9:20am	INVITED: PS+EM+TF-ThM5 Thermal Atomic Layer Etching of Transition Metal Films, <i>Charles Winter</i> , Wayne State University	PS-ThM5 Improving RF Power Delivery for Pulsed Operation, <i>J. Brandon, C. Smith, K. Ford</i> , North Carolina State University; <i>S.K. Nam</i> , Samsung Electronics; <i>Steven Shannon</i> , North Carolina State University
9:40am	Invited talk continues.	PS-ThM6 Optimizing Transients Using Low-High Pulsed Power in Inductively Coupled Plasmas, <i>Chenhui Qu, S.J. Lanham</i> , University of Michigan; <i>T. Ma, T. List, P. Arora, V.M. Donnelly</i> , University of Houston; <i>M.J. Kushner</i> , University of Michigan
10:00am	BREAK - Complimentary Coffee in Exhibit Hall – AVS Presidents Panel, Booth #168, Exhibit Hall	
10:20am	BREAK - Complimentary Coffee in Exhibit Hall – AVS Presidents Panel, Booth #168, Exhibit Hall	
10:40am	BREAK - Complimentary Coffee in Exhibit Hall – AVS Presidents Panel, Booth #168, Exhibit Hall	
11:00am	INVITED: PS+EM+TF-ThM10 Gas Cluster Ion Beam Etching under Organic Vapor for Atomic Layer Etching, <i>Noriaki Toyoda</i> , University of Hyogo, Japan	PS-ThM10 Silicon Nitride Film Formations Using Magnetic-Mirror Confined New Plasma Source, <i>Tetsuya Goto</i> , Tohoku University, Japan; <i>S.K. Kobayashi</i> , Kotec Company, Ltd., Japan; <i>S. Sugawa</i> , Tohoku University, Japan
11:20am	Invited talk continues.	PS-ThM11 Resonant Element Microwave Plasma Source, <i>Barton Lane, P.L.G. Ventzek, A. Bhakta</i> , Tokyo Electron, America, Inc.; <i>K. Nagaseki</i> , Tokyo Electron Miyagi, Ltd.; <i>A. Ranjan</i> , Tokyo Technology Center America
11:40am	PS+EM+TF-ThM12 Utilizing Chemical Structure of Hydrofluorocarbon Precursors to Achieve Ultra-High Selective Material Removal in Atomic Layer Etching, <i>Kang-Yi Lin, C. Li</i> , University of Maryland, College Park; <i>S.U. Engelmann, R.L. Bruce, E.A. Joseph</i> , IBM Research Division, T.J. Watson Research Center; <i>D. Metzler</i> , IBM Research Division, Albany, NY; <i>G.S. Oehrlein</i> , University of Maryland, College Park	INVITED: PS-ThM12 Microwave Plasma Enabling Efficient Power-To-X Conversion, <i>Gerard van Rooij</i> , DIFFER, The Netherlands
12:00pm	PS+EM+TF-ThM13 Etch Selectivity Mechanisms of Implanted Over Pristine SiN Materials in NH ₃ /NF ₃ Remote Plasma for Quasi Atomic Layer Etching with the Smart Etch Concept, <i>Vincent Renaud, E. Pargon, C. Petit-Etienne, LTM, Univ. Grenoble Alpes, CEA-LETI</i> , France; <i>J.-P. Barnes, N. Rochat, Cea, Leti, Minatec, France; L. Vallier, G. Cunge, O. Joubert, LTM, Univ. Grenoble Alpes, CEA-LETI</i> , France	Invited talk continues.

Thursday Morning, October 25, 2018

Novel Trends in Synchrotron and FEL-Based Analysis Focus Topic Room 202A - Session SA+MI-ThM Ultra-fast Dynamics for Magnetic and Quantum Systems Moderator: Claus Michael Schneider, Forschungszentrum Juelich GmbH, Germany		Surface Science Division Room 203C - Session SS+EM+NS-ThM Defects in and Functionalization of 2D Materials Moderators: Lars Grabow, University of Houston, Greg Kimmel, Pacific Northwest National Laboratory
8:00am	SA+MI-ThM1 New Opportunities at the APS: Using Intermediate Energy X-rays to Investigate Collective Behavior in Interacting Electron Systems, <i>Jessica McChesney, F. Rodolakis</i> , Argonne National Laboratory	INVITED: SS+EM+NS-ThM1 Holes, Pinning Sites and Metallic Wires in Monolayers of 2D Materials, <i>Thomas Michely</i> , University of Cologne, Germany
8:20am	SA+MI-ThM2 Observation of Surface Recombination in Ultra-fast Carrier Dynamics of $\text{La}_{0.7}\text{Sr}_{0.3}\text{MnO}_3$ Thin Films, <i>Saeed Yousefi Sarraf, G.B. Cabrera, R. Trappen, N. Mottaghi, S. Kumari, C.-Y. Huang, A. Bristow, M.B. Holcomb</i> , West Virginia University	Invited talk continues.
8:40am	INVITED: SA+MI-ThM3 Non-equilibrium Control of Charge & Spin Motion in Quantum Materials, <i>Hermann Dürr</i> , Uppsala University, Sweden	SS+EM+NS-ThM3 CO Chemisorption at Pristine, Doped and Defect Sites on Graphene/Ni(111), <i>Mario Rocca, G. Carraro</i> , University of Genova, Italy; <i>M. Smerieri, L. Savio</i> , IMEM-CNR, UOS Genova, Italy; <i>E. Celasco, L. Vattuone</i> , University of Genova, Italy
9:00am	Invited talk continues.	SS+EM+NS-ThM4 Geometry of Cu Islands Buried Beneath the Surface of Graphite, <i>A. Li-Rosales</i> , Ames Laboratory and Iowa State University; <i>S. Julien</i> , Northeastern University; <i>Y. Han, J.W. Evans</i> , Ames Laboratory and Iowa State University; <i>K.-T. Wan</i> , Northeastern University; <i>Patricia A. Thiel</i> , Ames Laboratory and Iowa State University
9:20am	INVITED: SA+MI-ThM5 XUV-transient Grating: Probing Fundamental Excitations at the Nanoscale, <i>Laura Foglia, F. Capotondi, R. Mincigrucci, D. Naumenko, E. Pedersoli, A. Simoncig, G. Kurdi, M. Manfredda, L. Raimondi</i> , Elettra-Sincrotrone Trieste, Italy; <i>N. Mahne</i> , IOM-CNR, Italy; <i>M. Zangrando, C. Masciovecchio, F. Bencivenga</i> , Elettra-Sincrotrone Trieste, Italy	SS+EM+NS-ThM5 Intercalation of O_2 and CO between Graphene and Ru(0001) and the Role of Defects, <i>Jory Yarmoff, T. Li</i> , University of California, Riverside
9:40am	Invited talk continues.	SS+EM+NS-ThM6 Organic-2D Transition Metal Dichalcogenide van der Waals Heterostructures, <i>Yu Li Huang</i> , Institute of Materials Research & Engineering (IMRE), A*STAR, Singapore; <i>Z. Song</i> , National University of Singapore; <i>D. Chi</i> , Institute of Materials Research & Engineering (IMRE), A*STAR, Singapore; <i>A.T.S. Wee</i> , National University of Singapore
10:00am		
10:20am	BREAK - Complimentary Coffee in Exhibit Hall – AVS Presidents Panel, Booth #168, Exhibit Hall	
10:40am		
11:00am	INVITED: SA+MI-ThM10 Study of Photo-induced Dynamics in Quantum Materials using Femtosecond Time-resolved X-ray Scattering, <i>Wei-Sheng Lee</i> , SLAC National Accelerator Laboratory	SS+EM+NS-ThM10 Influence of Surface Functionalization on Surface Topography and Growth of Metal Oxide Structures on HOPG, <i>Kathryn Perrine, M. Trought, I. Wentworth, C. de Alwis, T.R. Leftwich</i> , Michigan Technological University
11:20am	Invited talk continues.	SS+EM+NS-ThM11 Impurity Induced Chemical Properties of BN on Rh(111) Studied by First Principle Calculations: A New Phase, <i>Zahra Hooshmand¹, D. Le, T.S. Rahman</i> , University of Central Florida
11:40am	SA+MI-ThM12 HAXPES Lab- A Home Lab System for HAXPES Measurements, <i>S. Eriksson</i> , Scienta Omicron; <i>Anna Regoutz</i> , Imperial College London, UK	SS+EM+NS-ThM12 Texture of Atomic-layer Deposited MoS: A polarized Raman Study, <i>Vincent Vandalon, A. Sharma, W.M.M. Kessels</i> , Eindhoven University of Technology, The Netherlands; <i>A.A. Bol</i> , Eindhoven University of Technology, Netherlands
12:00pm		

¹ National Student Award Finalist

Thursday Morning, October 25, 2018

Thin Films Division Room 102A - Session TF+AS+EL+PS-ThM In-situ Characterization and Modeling of Thin Film Processes Moderator: Thomas Riedl, University of Wuppertal		Thin Films Division Room 104B - Session TF+PS-ThM Deposition Processes for 3D and Extreme Geometries Moderators: Richard Vanfleet, Brigham Young University, AnnaMaria Coclite, Graz University of Technology
8:00am	INVITED: TF+AS+EL+PS-ThM1 Defects in Thin Films: A First Principles Perspective, <i>Douglas Irving, J.S. Harris, J.N. Baker, S. Washiyama, M.H. Breckenridge</i> , North Carolina State University; <i>P. Reddy</i> , Adroit Materials; <i>R. Collazo, Z. Sitar</i> , North Carolina State University	TF+PS-ThM1 ALD and Diffusion in High Aspect Ratio Carbon Nanotube Forests, <i>David Kane, R.C. Davis, R.R. Vanfleet</i> , Brigham Young University
8:20am	Invited talk continues.	TF+PS-ThM2 Nanoporous Reference Substrates for ALD on High Aspect Ratio High Surface Area Materials, <i>Dmitri Routkevitch</i> , InRedox
8:40am	TF+AS+EL+PS-ThM3 Advances in Numerical Simulation of SiN ALD, <i>Paul Moroz</i> , TEL Technology Center, America, LLC	TF+PS-ThM3 Fine-tuned Resistive Coatings for Detector Applications, <i>Maximilian Gebhard, A.U. Mane, D. Choudhury, S. Letourneau, D.J. Mandia, Y. Zhang, J.W. Elam</i> , Argonne National Laboratory
9:00am	TF+AS+EL+PS-ThM4 Diffusion Kinetics Study of Adatom Islands: Activation Energy Barriers Predicted using Data-driven Approaches, <i>ShreeRam Acharya, T.S. Rahman</i> , University of Central Florida	TF+PS-ThM4 Tungsten Atomic Layer Deposition on Vertically Aligned Carbon Nanotube Structures, <i>Ryan Vanfleet, R.C. Davis, D.D. Allred, R.R. Vanfleet</i> , Brigham Young University
9:20am	TF+AS+EL+PS-ThM5 Using Ellipsometry and XPS to Understand the Degradation of Thin-film Aluminum Mirrors Protected by Ultrathin Fluorides, <i>M.R. Linford, Brian I. Johnson, R.S. Turley, D.D. Allred</i> , Brigham Young University	INVITED: TF+PS-ThM5 ALD in Metal Organic Frameworks: Toward Single Site Synthesis and Sinter-Resistant Catalysts, <i>Alex Martinson</i> , Argonne National Laboratory
9:40am	TF+AS+EL+PS-ThM6 Model for Amorphous Thin Film Formation and Validation, <i>Rahul Basu</i> , VTU, India	Invited talk continues.
10:00am		
10:20am	BREAK - Complimentary Coffee in Exhibit Hall – AVS Presidents Panel, Booth #168, Exhibit Hall	
10:40am		
11:00am	INVITED: TF+AS+EL+PS-ThM10 2D TMD Monolayer of MoS ₂ BY ALD and Insight in the Mechanism by Surface Organometallic Chemistry, <i>Elsje Alessandra Quadrelli</i> , CNRS CPE Lyon, France	TF+PS-ThM10 Alumina Deposition by Atomic Layer Deposition (ALD) on Flat Surfaces and High Aspect Ratio Structures, <i>Dhruv Shah, D.I. Patel, D.J. Jacobsen, J.E. Erickson, M.R. Linford</i> , Brigham Young University
11:20am	Invited talk continues.	TF+PS-ThM11 Resistivity of the Alumina Diffusion Barrier in Catalytic Carbon Nanotube Growth, <i>Berg Dodson, G. Chen, R.C. Davis, R.R. Vanfleet</i> , Brigham Young University
11:40am	TF+AS+EL+PS-ThM12 A Novel Fourier Transform Ion Trap Mass Spectrometer for Semiconductor Processes, <i>Gennady Fedosenko, H.-Y. Chung, R. Reuter, A. Laue, V. Derpmann, L. Gorkhov, M. Aliman, M. Antoni, Carl Zeiss SMT GmbH</i> , Germany	TF+PS-ThM12 High Temperature Active CeO ₂ Nanorods Generated via Diffusion Limited Atomic Layer Deposition, <i>Haoming Yan, X.Z. Yu, Q. Peng</i> , University of Alabama
12:00pm	TF+AS+EL+PS-ThM13 Realization of Shifts in Threshold Voltage and Subthreshold Swing in Atomic Layer Deposited Zinc Oxide As Channel Layer through <i>in-situ</i> Half-Cycle Analysis, <i>Harrison Sejoon Kim, A.T. Lucero, S.J. Kim, J. Kim</i> , University of Texas at Dallas	12:20 pm FREE LUNCH IN EXHIBIT HALL* (See Registration Tickets) <small>*while supplies last</small>

Thursday Afternoon, October 25, 2018

2D Materials Focus Topic		Actinides and Rare Earths Focus Topic
Room 201B - Session 2D+EM+MN+NS-ThA		Room 202C - Session AC-ThA
Novel Quantum Phenomena in 2D Materials		Early Career Scientists
Moderator: Hsin Lin, Institute of Physics, Academia Sinica		Moderators: Tomasz Durakiewicz, National Science Foundation, David Shuh, Lawrence Berkeley National Laboratory
2:20pm	2D+EM+MN+NS-ThA1 Double Indirect Interlayer Exciton in a MoSe ₂ /WSe ₂ van der Waals Heterostructure, <i>Aubrey Hanbicki, H.-J. Chuang, M. Rosenberger, C.S. Hellberg, S.V. Sivaram, K.M. McCreary, I. Mazin, B.T. Jonker</i> , Naval Research Laboratory	INVITED: AC-ThA1 Complexation, Characterization and Separation of the Lanthanides and Actinides: Shedding Light to Subtle Differences within the f-element Series, <i>Gauthier Deblonde, C.H. Booth</i> , Lawrence Berkeley National Laboratory; <i>M. Kelley, J. Su, E. Batista, P. Yang</i> , Los Alamos National Laboratory; <i>A. Müller, P. Ercius, A.M. Minor, R.J. Abergel</i> , Lawrence Berkeley National Laboratory
2:40pm	2D+EM+MN+NS-ThA2 Comparison of A- and B-exciton Intensity and Polarization in Transition Metal Dichalcogenide Monolayers and Heterostructures, <i>Kathleen McCreary, A.T. Hanbicki, S.V. Sivaram, B.T. Jonker</i> , U.S. Naval Research Laboratory	Invited talk continues.
3:00pm	INVITED: 2D+EM+MN+NS-ThA3 Optospintrronics and Magnetism with 2D Materials and Heterostructures, <i>Roland Kawakami</i> , The Ohio State University	INVITED: AC-ThA3 Improving the Understanding of Actinides Through Spectroscopy, <i>Samantha Cary, J. Su</i> , Los Alamos National Laboratory; <i>S.S. Galley, T.E. Albrecht-Schmitt</i> , Florida State University; <i>E. Batista, M.G. Ferrier, S.A. Kozimor, V. Mocko, B.L. Scott, B.W. Stein</i> , Los Alamos National Laboratory; <i>F.D. White</i> , Florida State University; <i>P. Yang</i> , Los Alamos National Laboratory
3:20pm	Invited talk continues.	Invited talk continues.
3:40pm	BREAK	BREAK
4:00pm	2D+EM+MN+NS-ThA6 Giant Electromechanical Response in Van-der-Waals Layered Crystals, <i>Sabine Neumayer</i> , Center for Nanophase Materials Sciences, Oak Ridge National Laboratory; <i>E.A. Eliseev</i> , National Academy of Sciences of Ukraine; <i>A. Tselev</i> , CICECO and Department of Physics, University of Aveiro, Portugal; <i>A.N. Morozovska</i> , National Academy of Sciences of Ukraine; <i>M.A. Susner, M.A. McGuire</i> , Oak Ridge National Laboratory; <i>J. Brehm, S. Pantelides</i> , Vanderbilt University; <i>N. Balke, P. Maksymovych</i> , Center for Nanophase Materials Sciences, Oak Ridge National Laboratory	INVITED: AC-ThA6 Structural Chemistry of M(IV) (M = Ce, Th, and U) Complexes Isolated from Aqueous Solution, <i>Karah Knope</i> , Georgetown University
4:20pm	2D+EM+MN+NS-ThA7 A Universal Method for Measuring Valleytronic Quality of 2D Materials using Conventional Raman Spectroscopy, <i>Steven Vitale, J.O. Varghese, D.A. Nezich, M. Rothschild</i> , MIT Lincoln Laboratory	Invited talk continues.
4:40pm	INVITED: 2D+EM+MN+NS-ThA8 Discovery of Intrinsic Ferromagnetism in 2D van der Waals Crystals, <i>Xiang Zhang, C. Gong</i> , University of California, Berkeley	INVITED: AC-ThA8 Hundess, Coherence and Magnetism in URu ₂ Si ₂ - and USb ₂ -family Materials, <i>L. Andrew Wray, L. Miao, H. He</i> , New York University; <i>S. Ran</i> , University of Maryland, College Park; <i>N.P. Butch</i> , Nist / Umd; <i>J.D. Denlinger, Y.-D. Chuang</i> , Advanced Light Source, Lawrence Berkeley National Laboratory
5:00pm	Invited talk continues.	Invited talk continues.
5:20pm	2D+EM+MN+NS-ThA10 Spectroscopic Evidence of Pair-mediated Bosonic Modes in Superconductor FeSe/SrTiO ₃ (100) Film, <i>Minjun Lee</i> , Seoul National University, Republic of Korea; <i>M. Oh, H. Jeon, S. Yi, I. Zoh</i> , Seoul National University, Republic of Korea; <i>C. Zhang</i> , Seoul National University, Republic of Korea; <i>J. Chae, Y. Kuk</i> , Center for Quantum Nanoscience, Institute for Basic Science, Republic of Korea	
5:40pm		

Thursday Afternoon, October 25, 2018

Applied Surface Science Division Room 204 - Session AS+NS-ThA Profiling, Imaging and Other Multidimensional Pursuits Moderators: Ashley Ellsworth, Physical Electronics, Jordan Lerach, ImaBiotech Corp.		Biomaterial Interfaces Division Room 101B - Session BI-ThA Biolubrication and Wear / Women in Bio-surface Science Moderators: Anna Belu, Medtronic, Sally McArthur, Swinburne University of Technology and CSIRO, Australia
2:20pm	AS+NS-ThA1 Surface Science Study of Au/Ni/Cr/n-SiC and Au/Cr/Ni/n-SiC Thin Film Ohmic Contact Material, <i>Martyn Kibbel</i> , La Trobe University, Australia; <i>A.J. Barlow</i> , La Trobe University, Australia; <i>P.W. Leech</i> , RMIT University, Australia	INVITED: BI-ThA1 Super Lubrication and Extremewear Protection using Bioinspired Polymers, <i>Xavier Banquy</i> , <i>J. Faivre</i> , Universite de Montreal, Canada; <i>G. Xie</i> , <i>M. Olszewski</i> , Carnegie Mellon University; <i>L. David</i> , <i>T. Delair</i> , <i>G. Sudre</i> , <i>A. Montembault</i> , Univ. Claude Bernard Lyon I; <i>K. Matyjaszewski</i> , Carnegie Mellon University; <i>R. Shrestha</i> , Universite de Montreal, Canada
2:40pm	AS+NS-ThA2 3D Imaging of InGaN/GaN based Nanowires and Nanotubes using Time-of-flight Secondary Ion Mass Spectrometry, <i>Jean-Paul Barnes</i> , Univ. Grenoble Alpes, CEA, LETI, France; <i>A. Kapoor</i> , Univ. Grenoble Alpes, CEA, France; <i>C. Durand</i> , Univ. Grenoble Alpes, CEA, France; <i>C. Bougerol</i> , Univ. Grenoble Alpes, CNRS, France; <i>J. Eymeric</i> , Univ. Grenoble Alpes, CEA, France	Invited talk continues.
3:00pm	INVITED: AS+NS-ThA3 Atom Probe Tomography: Applications and Prospects for Surface and Interface Science, <i>Austin Akey</i> , <i>D.C. Bell</i> , Harvard University	BI-ThA3 A Billion Force Runs: The AFM/Single-molecule Version of the Pitch Drop Experiment, <i>Laila Moreno Ostertag</i> , Vienna University of Technology, Austria; <i>T. Utzig</i> , Max Planck Institute for Iron Research, Germany; <i>C. Klinger</i> , TU Bergakademie Freiberg, Germany; <i>M. Valtiner</i> , Vienna University of Technology, Austria
3:20pm	Invited talk continues.	BI-ThA4 Ionic Liquid Behaviour in Biologic Environments: Structuring and Lubrication at Aqueous Solid/liquid Interfaces, <i>H.-W. Cheng</i> , TU Wien, Germany; <i>H. Weiss</i> , <i>M. Mezger</i> , Max Planck Institute for Polymer Research, Germany; <i>Markus Valtiner</i> , Vienna University of Technology, Austria
3:40pm	BREAK	BREAK
4:00pm	AS+NS-ThA6 TOF-SIMS Analysis with High Lateral and High Mass Resolution in Parallel, <i>F. Kollmer</i> , IONTOF GmbH, Germany; <i>N.J. Havercroft</i> , IONTOF USA; <i>A. Henß</i> , Justus-Liebig University Giessen, Germany; <i>J. Zakei</i> , <i>D. Rading</i> , <i>H. Arlinghaus</i> , <i>Ewald Niehuis</i> , IONTOF GmbH, Germany	INVITED: BI-ThA6 Synergistic Mechanisms of Selenium and Tellurium based Nano-Alloys Towards Biofilm Inhibition, <i>Kelly Nash</i> , <i>S. Tek</i> , <i>B. Vincent</i> , <i>C. Smith</i> , <i>R. Robledo</i> , University of Texas at San Antonio
4:20pm	AS+NS-ThA7 Industrial Applications of Surface Analysis in Chemical Mechanical Planarization, <i>Hong Piao</i> , <i>Y.N. Liang</i> , <i>J. McDonough</i> , <i>C. Ballesteros</i> , FUJIFILM Planar Solutions, LLC, FUJIFILM Electronic materials USA., Inc.; <i>E. Turner</i> , FUJIFILM Planar Solutions, LLC, FUJIFILM Electronic materials USA., Inc; <i>A. Mishra</i> , <i>R. Wen</i> , FUJIFILM Planar Solutions, LLC, FUJIFILM Electronic materials USA., Inc.	Invited talk continues.
4:40pm	AS+NS-ThA8 Correlative Images of Microscopy Spectroscopy: Beyond the 3D Characterization in Surface Analysis, <i>Tanguy Terlier</i> , Korea Institute of Science and Technology, Republic of Korea; <i>R. Verduco</i> , Shared Equipment Authority, Rice University; <i>Y. Lee</i> , Korea Institute of Science and Technology, Republic of Korea	BI-ThA8 From Bedside Back to Bench: Combining Human Centered Design with Biointerfacial Research, <i>P.A. Nguyen</i> , <i>T. Martin</i> , <i>D. Cuylear</i> , <i>L. Mckenney</i> , <i>B. Matheson</i> , <i>A. Yingling</i> , <i>L. Ista</i> , <i>Heather Canavan</i> , University of New Mexico
5:00pm	AS+NS-ThA9 3D Structure of Atomically Dispersed Metal Species on an Oxide Single Crystal Surface Studied by Polarization-dependent Total Reflection Fluorescence (PTRF)-XAFS, <i>Satoru Takakusagi</i> , <i>K. Asakura</i> , Hokkaido University, Japan	BI-ThA9 Liquid-Infused Surfaces Coated on Paper Improve Bacteria Handling Efficiency and Detection, <i>D. Regan</i> , <i>C. Lilly</i> , <i>A. Weigang</i> , <i>H. Patanwala</i> , <i>Caitlin Howell</i> , University of Maine
5:20pm	AS+NS-ThA10 XPS Imaging and Spectromicroscopy Investigation of Extended Release Pharmaceutical Tablets, <i>Jonathan Counsell</i> , <i>S.J. Coulter</i> , <i>C.J. Blomfield</i> , Kratos Analytical Ltd, UK; <i>D.J. Scurr</i> , The University of Nottingham, UK; <i>L. Mason</i> , University of Nottingham, UK; <i>V. Ciarnelli</i> , <i>J.M. Garfitt</i> , <i>S. Rigby-Singleton</i> , Juniper Pharma Services Ltd, UK; <i>M.R. Alexander</i> , The University of Nottingham, UK; <i>M.C. Davies</i> , University of Nottingham, UK; <i>C. Moffitt</i> , Kratos Analytical Inc.; <i>S.J. Hutton</i> , Kratos Analytical Ltd, UK	BI-ThA10 Tailoring Interactions at the Nanoparticle-nucleic Acid Interface using Molecular Modelling, <i>M. Manning</i> , <i>J.A. Nash</i> , <i>Yaroslava Yingling</i> , North Carolina State University
5:40pm	AS+NS-ThA11 An experimental Guide to Conversion of Tof-SIMS Spectrum to BIG DATA: Application in Analysis of Ultrathin Coatings, <i>Kevin Abbasi</i> , <i>A.A. Avishai</i> , Swagelok Center for Surface Analysis of Materials, Case school of Engineering, Case Western Reserve University	BI-ThA11 Biomolecule Interaction with Polymer Thin Films Based on Zwitterions and Polymer Nanoparticles, <i>Eva Bittrich</i> , <i>C. Naas</i> , Leibniz-Institut für Polymerforschung Dresden e.V., Germany; <i>F. Mele</i> , Leibniz-Institut für Polymerforschung Dresden e.V. and Polytechnic University of Turin, Italy; <i>A. Münch</i> , Leibniz-Institut für Polymerforschung Dresden e.V., Germany; <i>P. Uhlmann</i> , Leibniz-Institut für Polymerforschung Dresden e.V., Germany; <i>D. Appelhans</i> , <i>K.-J. Eichhorn</i> , <i>B. Voit</i> , Leibniz-Institut für Polymerforschung Dresden e.V., Germany

Thursday Afternoon, October 25, 2018

Electronic Materials and Photonics Division Room 101A - Session EM+2D+NS+PS+RM+TF-ThA IoT Session: Flexible Electronics & Flash Networking Session Moderators: Shalini Gupta, Northrop Grumman ES, Sang M. Han, University of New Mexico		Fundamental Discoveries in Heterogeneous Catalysis Focus Topic Room 201A - Session HC+SS-ThA Bridging Gaps in Heterogeneously Catalyzed Reactions Moderator: Ryan Brown, Clarkson University
2:20pm	INVITED: EM+2D+NS+PS+RM+TF-ThA1 Epitaxial Electrodeposition of Electronic and Photonic Materials onto Wafer-size Single Crystal Gold Foils for Flexible Electronics, <i>Jay Switzer</i> , Missouri University of Science and Technology	HC+SS-ThA1 Hydrogen Adsorption and Reaction on RuO ₂ (110) Surface, <i>A. Dahal, I. Lyubinetsky, Zdenek Dohnalek</i> , Pacific Northwest National Laboratory
2:40pm	Invited talk continues.	HC+SS-ThA2 The Role of Oxides for CO Oxidation over Pd and Rh, and How to Deal with Oxygen Poisoning, <i>Johan Gustafson</i> , Lund University, Sweden; <i>O. Balmes</i> , MAX IV Laboratory, Sweden; <i>C. Zhang</i> , Lund University, Sweden; <i>M. Shipilin</i> , Stockholm University, Sweden; <i>A. Schaefer</i> , Chalmers University of Technology, Gothenburg, Sweden; <i>B. Hagman</i> , Lund University, Sweden; <i>L. Merte, N.M. Martin, P.-A. Carlsson</i> , Chalmers University of Technology, Gothenburg, Sweden; <i>M. Jankowski</i> , ESRF, France; <i>E.J. Crumlin</i> , Advanced Light Source, Lawrence Berkeley National Laboratory; <i>E. Lundgren</i> , Lund University, Sweden
3:00pm	EM+2D+NS+PS+RM+TF-ThA3 Flexible Electronic Devices Based on Two Dimensional Materials, <i>R. Kim, N.R. Glavin</i> , Air Force Research Laboratory; <i>R.H. Rai, K. Griebel, M. Beebe</i> , University of Dayton; Air Force Research Laboratory; <i>J. Leem, S. Nam</i> , University of Illinois at Urbana-Champaign; <i>R. Rao</i> , Air Force Research Laboratory; <i>Christopher Muratore, Katherine Burzynski</i> , University of Dayton	INVITED: HC+SS-ThA3 Simplifying the Relationships between Catalyst Structure and Reaction Rates for Complex Mechanisms, <i>Charles T. Campbell</i> , University of Washington
3:20pm	EM+2D+NS+PS+RM+TF-ThA4 Contact Resistances and Schottky Barrier Heights of Metal-SnS Interfaces, <i>Jenifer Hajzus, L. Porter</i> , Carnegie Mellon University; <i>A. Biacchi, S. Le, C. Richter, A. Hight Walker</i> , National Institute of Standards and Technology (NIST)	Invited talk continues.
3:40pm	BREAK	BREAK
4:00pm	EM FLASH SESSION: KATHERINE BURZYNSKI , Univ. of Dayton (EM-ThP3); LUCAS STUCCHI-ZUCCHI , Univ. of Campinas, Brazil (EM-ThP6); JEFFREY CHANG , UCLA (EM-ThP10); GUANYU ZHOU , Univ. of Texas at Dallas (EM-ThP14); BO WANG , Univ. of Southern California (EM-ThP17); MIN KHANAL , Auburn Univ. (EM-ThP18)	HC+SS-ThA6 Spectroscopic Techniques for Identifying Reactive Intermediate Structures during Decomposition of Formic Acid over Metals and Metal Oxides, <i>Megan Witzke, D.W. Flaherty</i> , University of Illinois at Urbana-Champaign
4:20pm		HC+SS-ThA7 Self-sustained Reaction Oscillations in a New Light, <i>Uta Hejral, S. Albertin, J. Zhou, S. Pfaff</i> , Lund University, Sweden; <i>M. Shipilin</i> , Stockholm University, Sweden; <i>S. Blomberg</i> , Lund University, Sweden; <i>O. Gutowski, A. Dippel</i> , Deutsches Elektronen-Synchrotron DESY, Germany; <i>J. Gustafson, J. Zetterberg, E. Lundgren</i> , Lund University, Sweden
4:40pm		INVITED: HC+SS-ThA8 Operando Catalysis--A First-Principles Perspective, <i>William Schneider</i> , University of Notre Dame
5:00pm		Invited talk continues.
5:20pm		HC+SS-ThA10 Chiral Selectivity in Heterogeneous Catalysis, <i>R. Chapleski, Sharani Roy</i> , University of Tennessee Knoxville
5:40pm		HC+SS-ThA11 Combining <i>in situ</i> Environmental TEM and Multiscale Simulations to Study the Dynamic Processes of Copper Oxidation, <i>Meng Li, M.T. Curnan, W.A. Saidi, J.C. Yang</i> , University of Pittsburgh

Thursday Afternoon, October 25, 2018

Advanced Ion Microscopy Focus Topic Room 203B - Session HI-ThA Emerging Ion Sources, Optics, and Applications Moderators: John A. Notte, Carl Zeiss Microscopy, LLC, Shinichi Ogawa, National Institute of Advanced Industrial Science and Technology (AIST)		Magnetic Interfaces and Nanostructures Division Room 203A - Session MI+BI-ThA Interdisciplinary Magnetism Moderator: Markus Donath, Westfälische Wilhelms-Universität Münster, Germany
2:20pm	INVITED: HI-ThA1 Development of Gas Field Ionization Source using Gas with Low Ionization Energy that Enables Sample Processing and Observation, <i>Shinichi Matsubara, H. Shichi, T. Hashizume</i> , Hitachi, Japan	
2:40pm	Invited talk continues.	MI+BI-ThA2 Chiral Induced Spin Selectivity in Molecular Bond Dissociation, <i>Richard Rosenberg</i> , Argonne National Laboratory
3:00pm	HI-ThA3 Development of Scanning Helium Microscopy (SHeM), <i>Susanne Schulze, D.J. Ward, M. Bergin, S. Lambrick, W. Allison, J. Ellis, A. Jardine</i> , University of Cambridge, UK	INVITED: MI+BI-ThA3 The Chiral Induced Spin Selectivity Effect- From Spintronics to Controlling Chemistry, <i>Ron Naaman</i> , Weizmann Institute of Science, Israel
3:20pm	HI-ThA4 Fabrication of Trimer/Single Atom Tip for GFIS by Field Evaporation without Tip Heating, <i>Kwang-Il Kim</i> , University of Science and Technology, Republic of Korea; <i>Y.H. Kim, T. Ogawa</i> , Korea Research Institute of Standards and Science (KRISS), Republic of Korea; <i>S.J. Choi</i> , Kyungpook National University, Republic of Korea; <i>B. Cho, S.J. Ahn, I.-Y. Park</i> , Korea Research Institute of Standards and Science (KRISS), Republic of Korea	Invited talk continues.
3:40pm	BREAK	BREAK
4:00pm	INVITED: HI-ThA6 Nano Aperture Ion Source, <i>Greg Schwind, A. Botman, S. Kellogg</i> , Thermal Fisher Scientific; <i>L. van Kouwen, P. Kruit</i> , Delft University of Technology, Netherlands	INVITED: MI+BI-ThA6 Multifunctional Ferromagnetic Disks for Life Sciences Applications, <i>Elena Rozhko, V. Novosad</i> , Argonne National Laboratory
4:20pm	Invited talk continues.	Invited talk continues.
4:40pm	HI-ThA8 Avoiding Amorphization Related Shape Changes of Nano-structures during Medium Fluence Ion Beam Irradiation of Semiconductor Materials, <i>Xiaomo Xu, G. Hlawacek, H.-J. Engelmann, K.-H. Heinig</i> , Helmholtz Zentrum Dresden-Rossendorf, Germany; <i>W. Möller</i> , Helmholtz-Zentrum Dresden-Rossendorf, Germany; <i>A. Gharbi</i> , CEA-LETI, France; <i>R. Tiron</i> , CEA-LETI, MINATEC, France; <i>L. Bischoff, T. Prüfer, R. Hübner, S. Fácsko, J. von Borany</i> , Helmholtz Zentrum Dresden-Rossendorf, Germany	INVITED: MI+BI-ThA8 Magnetic Nanoparticles in Biomedicine: Recent Developments in Imaging, Diagnostics and Therapy, <i>Kannan Krishnan</i> , University of Washington
5:00pm		Invited talk continues.
5:20pm		
5:40pm		

Thursday Afternoon, October 25, 2018

MEMS and NEMS Group Room 202B - Session MN+2D+AN+NS-ThA Nonlinear and Thermal Resonators Moderators: Meredith Metzler, University of Pennsylvania, Christian Zorman, Case Western Reserve University		Nanometer-scale Science and Technology Division Room 102B - Session NS+2D+AS+MN+PC-ThA SPM – Probing Electronic and Transport Properties Moderators: Ondrej Dyck, Oak Ridge National Laboratory, Sergei Kalinin, Oak Ridge National Laboratory, Indira Seshadri, IBM Research Division, Albany, NY
2:20pm	INVITED: MN+2D+AN+NS-ThA1 Embracing Nonlinearity and Thermal Fluctuations in Nanomechanics, <i>Daniel Lopez, D.A. Czaplewski, C. Chen, Argonne National Laboratory; D. Zanette, Centro Atomico Bariloche, Argentina; S. Shaw, Michigan State University</i>	INVITED: NS+2D+AS+MN+PC-ThA1 Imaging Currents in Two-dimensional Quantum Materials, <i>Katja Nowack, Cornell University</i>
2:40pm	Invited talk continues.	Invited talk continues.
3:00pm	MN+2D+AN+NS-ThA3 Probing Ion Radiation Effects in Silicon Crystals by 3D Integrated Resonating Thin Diaphragms, <i>Hailong Chen, H. Jia, V. Pashaei, Case Western Reserve University; W. Liao, C.N. Arutt, M.L. McCurdy, Vanderbilt University; P. Hung, The Aerospace Corporation; R.A. Reed, R.D. Schrimpf, M.L. Alles, Vanderbilt University; P.X.-L. Feng, Case Western Reserve University</i>	NS+2D+AS+MN+PC-ThA3 Side-gate Construct for Probing Active Energy Levels in Electron Transport through a Solid-state Surface-bound Protein Monolayer, <i>Sidney Cohen, B. Kayser, C. Gua, M. Sheves, I. Pecht, D. Cahen, Weizmann Institute of Science, Israel</i>
3:20pm	MN+2D+AN+NS-ThA4 An Array of Thermally-actuated Nanoresonators for Real-time Mass Spectrometry, <i>Martial Defoort, M. Sansa, M. Gély, G. Jourdan, S. Hentz, CEA/LETI-University Grenoble Alpes, France</i>	NS+2D+AS+MN+PC-ThA4 Adding Electrons One at a Time to Electrostatically Confined Graphene Quantum Dots, <i>Daniel Walkup, C. Gutierrez, F. Ghahari, National Institute of Standards and Technology (NIST)/University of Maryland, College Park; C. Lewandowski, MIT; J. Rodriguez-Nieva, Harvard University; T. Taniguchi, K. Watanabe, National Institute for Materials Science (NIMS), Japan; L. Levitov, MIT; N.B. Zhitenev, J.A. Stroscio, National Institute of Standards and Technology (NIST)</i>
3:40pm	BREAK	BREAK
4:00pm	INVITED: MN+2D+AN+NS-ThA6 Nonlinear and Noise Induced Dynamics of High Q Nanomechanical Resonators, <i>Jana Huber, E.M. Weig, University of Konstanz, Germany</i>	NS+2D+AS+MN+PC-ThA6 Bulk and Surface Contribution to the Charge and Spin Transport in Topological Insulators Observed with a Four-Probe Scanning Tunneling Microscope, <i>Wonhee Ko, G.D. Nguyen, Oak Ridge National Laboratory; H. Kim, J.S. Kim, Pohang University of Science and Technology, Republic of Korea; A.-P. Li, Oak Ridge National Laboratory</i>
4:20pm	Invited talk continues.	NS+2D+AS+MN+PC-ThA7 Modulation of Single-Walled Carbon Nanotube Electronic Structure by External Electronic Perturbations: Scanning Tunneling Spectroscopy and Density Functional Theory, <i>Benjamen Taber¹, G.V. Nazin, University of Oregon</i>
4:40pm	MN+2D+AN+NS-ThA8 SNIC Bifurcation Generated Mechanical Frequency Comb, <i>David Czaplewski, D. Lopez, Center for Nanoscale Materials, Argonne National Laboratory; O. Shoshani, Ben-Gurion University -Negev, Israel; A.M. Eriksson, Chalmers University of Technology, Gothenburg, Sweden; S.W. Shaw, Florida Institute of Technology</i>	NS+2D+AS+MN+PC-ThA8 Single Charge and Exciton Dynamics probed on the Molecular Scale, <i>Anna Roslawska, P. Merino, C. Grosse, C.C. Leon, O. Gunnarsson, M. Etzkorn, K. Kuhnke, K. Kern, Max Planck Institute for Solid State Research, Germany</i>
5:00pm	MN+2D+AN+NS-ThA9 A Buckling-based, DC Controlled, Non-volatile Nanoelectromechanical Logic Memory, <i>S.O. Erbil, U. Hatipoğlu, Bilkent University, Turkey; C. Yanik, Sabanci University; M. Ghavami, Mehmet Selim Hanay, Bilkent University, Turkey</i>	NS+2D+AS+MN+PC-ThA9 Microscopic Understanding of the Temperature-dependent Carrier Transport in Ge Nano - Crystal s Films, <i>Dan Shan, Yangzhou Polytechnic Institute, China; J. Xu, Nanjing Universityy, China</i>
5:20pm		
5:40pm		

¹ NSTD Postdoc Finalist

Thursday Afternoon, October 25, 2018

Plasma Science and Technology Division Room 104C - Session PS+EM+TF-ThA Atomic Layer Processing: Integration of ALD and ALE Moderator: Scott Walton, U.S. Naval Research Laboratory		Plasma Science and Technology Division Room 104A - Session PS-ThA Plasma Diagnostics, Sensors and Controls Moderator: Steven Shannon, North Carolina State University
2:20pm	PS+EM+TF-ThA1 Atomic-Layer Etching (ALE) of Nickel or Nickel Oxide Films by Hexafluoroacetylacetone (HFAC) Molecules, <i>Abdulrahman Basher, M. Isobe, T. Ito, K. Karahashi</i> , Osaka University, Japan; <i>M. Kiuchi</i> , National Institute of Advanced Industrial Science and Technology (AIST), Japan; <i>T. Takeuchi</i> , Nara Women's University, Japan; <i>S. Hamaguchi</i> , Osaka University, Japan	PS-ThA1 In-situ Measurement of Electron Emission and Electron Reflection Yields, <i>Mark Sobolewski</i> , National Institute of Standards and Technology (NIST)
2:40pm	PS+EM+TF-ThA2 Thermal Atomic Layer Etching of HfO ₂ Using HF for Fluorination and TiCl ₄ for Ligand-Exchange, <i>Y. Lee, Steven George</i> , University of Colorado at Boulder	PS-ThA2 Electron Energy Distribution Measurements in Dusty Non-thermal Plasmas, <i>Austin Woodard, L. Mangolini</i> , University of California, Riverside
3:00pm	PS+EM+TF-ThA3 Rapid thermal-cyclic Atomic Layer Etching of SiO ₂ Using Infrared Annealing, <i>Nobuya Miyoshi</i> , Hitachi High-Technologies, Japan; <i>H. Kobayashi, K. Shinoda, M. Kurihara</i> , Hitachi, Japan; <i>K. Kawamura, K. Ookuma, Y. Kouzuma, M. Izawa</i> , Hitachi High-Technologies, Japan	INVITED: PS-ThA3 The Surface Plasmon Energy and the Secondary Electron Emission on an Oxidized Aluminum Surface, <i>J.-T. Li, J. Qiu, Yi-Kang Pu</i> , Tsinghua University, China
3:20pm	PS+EM+TF-ThA4 The Smoothing Effect in Atomic Layer Etching (ALE), <i>Keren Kanarik, S. Tan, W. Yang, I.L. Berry, T.B. Lill, Y. Pan, R.A. Gottscho</i> , Lam Research Corporation	Invited talk continues.
3:40pm	BREAK	BREAK
4:00pm	INVITED: PS+EM+TF-ThA6 Prospects for Combining ALD and ALE in a Single Chamber, <i>Mike Cooke</i> , Oxford Instruments, UK	PS-ThA6 Transient Phenomena in Power Modulated Chlorine Plasma, <i>Priyanka Arora, T. List, T. Ma</i> , University of Houston; <i>S. Shannon</i> , North Carolina State University; <i>S. Nam</i> , Samsung Electronics Co., Ltd., Republic of Korea; <i>V.M. Donnelly</i> , University of Houston
4:20pm	Invited talk continues.	PS-ThA7 Measurements of RF Magnetic Fields and Plasma Current in Coupled Low and Very High Dual-Frequency Plasma Sources, <i>J.P. Zhao, P.L.G. Ventzek, B. Lane</i> , Tokyo Electron America, Inc.; <i>Toshihiko Iwao, K. Ishibashi</i> , Tokyo Electron Technology Solutions Ltd., Japan
4:40pm	PS+EM+TF-ThA8 Low Temperature Surface Preparation of GaN Substrates for Plasma Assisted-Atomic Layer Epitaxial Growth, <i>Samantha G. Rosenberg</i> , U.S. Naval Research Laboratory; <i>D.J. Pennachio</i> , University of California, Santa Barbara; <i>M. Munger</i> , SUNY Brockport; <i>C. Wagenbach</i> , Boston University; <i>V.R. Anderson</i> , U.S. Naval Research Laboratory; <i>S.D. Johnson</i> , U. S. Naval Research Laboratory; <i>N. Nepal, A.C. Kozen, J.M. Woodward</i> , U.S. Naval Research Laboratory; <i>Z.R. Robinson</i> , SUNY Brockport; <i>K.F. Ludwig</i> , Boston University; <i>C.J. Palmstrøm</i> , University of California, Santa Barbara; <i>C.R. Eddy, Jr.</i> , U. S. Naval Research Laboratory	PS-ThA8 Self-neutralized Nearly Monoenergetic Positive Ion Beam Extracted From a Pulsed Plasma, <i>Ya-Ming Chen, R. Sawadichai</i> , University of Houston; <i>S. Tian</i> , Lam Research Corporation; <i>V.M. Donnelly, D.J. Economou, P. Ruchhoeft</i> , University of Houston
5:00pm	PS+EM+TF-ThA9 Chemical Interactions with Alkali Compounds for Controlling the Transition between Thermal HF-based Atomic Layer Etching and Deposition, <i>John Hennessy</i> , Jet Propulsion Laboratory, California Institute of Technology	PS-ThA9 Diagnostics of Plasma Neutral Species in a Very High Frequency Oxygen Plasma with High Sensitivity Broadband Absorption Spectroscopy, <i>Jianping Zhao, P.L.G. Ventzek, B. Lane</i> , Tokyo Electron America, Inc.; <i>T. Iwao, K. Ishibashi</i> , Tokyo Electron Technology Solutions Ltd., Japan; <i>J.-P. Booth</i> , CNRS, Ecole Polytechnique, France
5:20pm	INVITED: PS+EM+TF-ThA10 Selective Processing to Enable High Fidelity Control for the 5 nm Node, <i>Benjamin Rathjens</i> , Tokyo Electron America, Inc.; <i>A. Ranjan</i> , TEL Technology Center, America, LLC.; <i>P.L.G. Ventzek</i> , Tokyo Electron America, Inc.; <i>H. Mochiki</i> , Tokyo Electron Miyagi, Ltd., Japan; <i>J. Bannister</i> , Tokyo Electron America, Inc.	PS-ThA10 Development of the Virtual Metrology Using a Plasma Information Variable (PI-VM) for Monitoring SiO ₂ Etch Depth, <i>Yunchang Jang, H.-J. Roh, S. Ryu, J.-W. Kwon, G.-H. Kim</i> , Seoul National University, Republic of Korea
5:40pm	Invited talk continues.	PS-ThA11 Model Predictive Control of Plasma Density in Ar/SF ₆ Capacitively Coupled Plasma Source, <i>Sangwon Ryu, H.-J. Roh, Y. Jang, D. Park, J. Koo, J.M. Lee, G.-H. Kim</i> , Seoul National University, Republic of Korea

Thursday Afternoon, October 25, 2018

Novel Trends in Synchrotron and FEL-Based Analysis Focus Topic Room 202A - Session SA+AS+HC+SS-ThA IoT Session: Multi-modal Characterization of Energy Materials & Device Processing Moderators: Maya Kiskinova, Elettra-Sincrotrone Trieste, Italy, Slavomir Nemsak, Advanced Light Source, Lawrence Berkeley National Laboratory		Surface Science Division Room 203C - Session SS+AS+BI+MI+NS-ThA Organic/Inorganic Surfaces, Interfaces and Nanostructures Moderator: Denis Potapenko, Princeton University
Moderators: Maya Kiskinova, Elettra-Sincrotrone Trieste, Italy, Slavomir Nemsak, Advanced Light Source, Lawrence Berkeley National Laboratory		
2:20pm	INVITED: SA+AS+HC+SS-ThA1 Revealing Structure-Function Correlations in Fuel-Cells and Batteries, <i>Klaus Attenkofer, E. Stavitski, M. Liu, D. Lu, M. Topsakal, D.J. Stacchiola, M.S. Hybertsen</i> , Brookhaven National Laboratory	SS+AS+BI+MI+NS-ThA1 Investigation of the Stability of Ag Monolayers on Au(111) as a Function of Metal Adatom Diffusion, <i>J.A. Phillips, L.K. Harville, H.R. Morgan, L.E. Jackson, G. LeBlanc, Erin Iski</i> , University of Tulsa
2:40pm	Invited talk continues.	SS+AS+BI+MI+NS-ThA2 Chain-Length Dependent Reactivity of Thiolate Self-Assembled Monolayers with Atomic Gas Species, <i>Jeffrey Sayler, S. Brown, S.J. Sibener</i> , University of Chicago
3:00pm	INVITED: SA+AS+HC+SS-ThA3 Soft X-ray Spectroscopy for High Pressure Liquid, <i>Ruimin Qiao, J.-H. Guo, W. Chao</i> , Lawrence Berkeley National Laboratory	INVITED: SS+AS+BI+MI+NS-ThA3 Scan Probe Studies of Lithium Transfer through Solid State Electrochemical Interfaces, <i>Janice Reutt-Robey</i> , University of Maryland College Park
3:20pm	Invited talk continues.	Invited talk continues.
3:40pm	BREAK	BREAK
4:00pm	SA+AS+HC+SS-ThA6 Surface Action Spectroscopy Using FHI FEL Infrared Radiation, <i>Zongfang Wu, H. Kuhlenbeck, W. Schöllkopf, H.J. Freund</i> , Fritz-Haber Institute of the Max Planck Society, Germany	SS+AS+BI+MI+NS-ThA6 Adsorption and Self-assembly of Halogenated Organic Molecules on the Si(111) $\sqrt{3}\times\sqrt{3}$ -Ag Surface, <i>Renjie Liu</i> , Lakehead University, Canada; <i>C. Fu, A.G. Moiseev, M.R. Rao, Y. Chen, D.F. Perepichka</i> , McGill University, Canada; <i>M.C. Gallagher</i> , Lakehead University, Canada
4:20pm	SA+AS+HC+SS-ThA7 Spectroscopic Insight into Resistive Switching Processes in Oxides, <i>C. Baeumer, C. Schmitz</i> , Forschungszentrum Juelich GmbH, Germany; <i>A. Kindsmüller</i> , RWTH Aachen University, Germany; <i>N. Raab, V. Feyer, D.N. Mueller, J. Hackl, S. Nemsak</i> , Forschungszentrum Juelich GmbH, Germany; <i>O.T. Mentes, A. Locatelli</i> , Elettra-Sincrotrone Trieste, Italy; <i>R. Waser, R. Dittmann, Claus Michael Schneider</i> , Forschungszentrum Juelich GmbH, Germany	SS+AS+BI+MI+NS-ThA7 Electron Interactions with Alkanethiol Self-assembled Monolayers on Au(111), <i>Jodi Grzeskowiak</i> , University at Albany-SUNY; <i>C.A. Ventrice, Jr.</i> , SUNY Polytechnic Institute
4:40pm	INVITED: SA+AS+HC+SS-ThA8 Visualizing Electronic Structures of Topological Quantum Materials by Synchrotron Based Photoemission Spectroscopy, <i>Yulin Chen</i> , Oxford University, UK	SS+AS+BI+MI+NS-ThA8 Measuring the Electronic Properties of Organic Single Crystals, <i>Sujitra Pookpanratana, E.G. Bittle, C.A. Hacker, S.W. Robey</i> , National Institute of Standards and Technology (NIST); <i>R. Ovsyannikov, E. Giangrisostomi</i> , Helmholtz-Zentrum Berlin, Germany
5:00pm	Invited talk continues.	SS+AS+BI+MI+NS-ThA9 Surface Functionalization of Porous Substrates via Initiated Chemical Vapor Deposition, <i>Christine Cheng, M. Gupta</i> , University of Southern California
5:20pm	SA+AS+HC+SS-ThA10 Electronic Structure of FeO, γ -Fe ₂ O ₃ and Fe ₃ O ₄ Epitaxial Films using High-energy Spectroscopies, <i>German Rafael Castro</i> , Spanish CRG BM25-SpLine Beamline at the ESRF, France; <i>J. Rubio Zuazo</i> , Spanish CRG BM25-SpLine at the ESRF, France; <i>A. Chainani</i> , Condensed Matter Physics Group, NSRRC, Taiwan, Republic of China; <i>M. Taguchi</i> , RIKEN Spring-8 centre, Japan; <i>D. Maiterre</i> , Institut Jean Lamour, Universite de Lorraine, France; <i>A. Serrano Rubio</i> , Spanish CRG BM25-SpLine Beamline at the ESRF, France	SS+AS+BI+MI+NS-ThA10 Atomic-Scale Understanding of Anatase Nanocatalyst Activation, <i>William DeBenedetti¹, E.S. Skibinski, M.A. Hines</i> , Cornell University
5:40pm	SA+AS+HC+SS-ThA11 Single-Bunch Imaging of Detonation Fronts Using Scattered Synchrotron Radiation, <i>M.H. Nielsen, J.A. Hammons, M. Bagge-Hansen, L.M. Lauderbach, R. Hodgin, K. Champlie, W. Shaw</i> , Lawrence Livermore National Laboratory; <i>N. Sinclair</i> , Washington State University; <i>Trevor Wiley</i> , Lawrence Livermore National Laboratory	SS+AS+BI+MI+NS-ThA11 Mechanistic view of Solid-Electrolyte Interphase Layer Evolution at Li-metal Anode, <i>Venkatesh Kumar Prabhakaran</i> , Physical Sciences Division, Pacific Northwest National Laboratory; <i>M.H. Engelhard, A. Martinez</i> , Environmental Molecular Science Laboratory, Pacific Northwest National Laboratory; <i>G.E. Johnson</i> , Physical Sciences Division, Pacific Northwest National Laboratory; <i>S. Thevuthasan</i> , Environmental Molecular Science Laboratory, Pacific Northwest National Laboratory; <i>V. Murugesan</i> , Physical Sciences Division, Pacific Northwest National Laboratory

¹ National Student Award Finalist

Thursday Afternoon, October 25, 2018

Surface Science Division Room 102A - Session SS+EM+PS+TF-ThA Deposition, Etching and Growth at Surfaces Moderator: Bruce E. Koel, Princeton University		Thin Films Division Room 104B - Session TF+AS+EL+EM+NS+PS+SS-ThA IoT Session: Thin Films for Flexible Electronics and IoT Moderators: Jesse Jur, North Carolina State University, Siamak Nejati, University of Nebraska-Lincoln
2:20pm	INVITED: SS+EM+PS+TF-ThA1 Controlled Deposition and High-Resolution Analysis of Functional Macromolecules in Ultrahigh Vacuum, <i>Giovanni Costantini</i> , University of Warwick, UK	INVITED: TF+AS+EL+EM+NS+PS+SS-ThA1 Ultraflexible Organic Electronics for Bio-medical Applications, <i>Tomoyuki Yokota, T. Someya</i> , The University of Tokyo, Japan
2:40pm	Invited talk continues.	Invited talk continues.
3:00pm	SS+EM+PS+TF-ThA3 Unconventional Nucleation and Growth Kinetics: <i>in situ</i> Variable-temperature Scanning Tunneling Microscopy Studies of Chemical Vapor Deposition of Inorganic Monolayers on Metallic Substrates, <i>Pedro Arias</i> , University of California, Los Angeles; <i>A. Abdulsalam</i> , Colorado School of Mines; <i>A. Ebnonnasir</i> , University of California at Los Angeles; <i>C.V. Ciobanu</i> , Colorado School of Mines; <i>S. Kodambaka</i> , University of California, Los Angeles	TF+AS+EL+EM+NS+PS+SS-ThA3 Molecular Surface Chemistry for Improved Interfaces in Organic Electronics, <i>Jacob W. Ciszek</i> , Loyola University Chicago
3:20pm	SS+EM+PS+TF-ThA4 Redox-Active Ligands for Single-Site Metal-Organic Complexes on Surfaces as Heterogeneous Catalysts, <i>Tobias Morris</i> , Indiana University; <i>D.L. Wisman</i> , Indiana University, NAVSEA Crane; <i>I.J. Huerfano, N.A. Maciullis, K.G. Caulton, S.L. Tait</i> , Indiana University	TF+AS+EL+EM+NS+PS+SS-ThA4 Investigation of Low Temperature ALD-deposited SnO ₂ Films Stability in a Microfabrication Environment, <i>Tony Maindrone, S.M. Sandrez, N.V. Vaxelaire</i> , CEA/LETI-University Grenoble Alpes, France
3:40pm	BREAK	BREAK
4:00pm	SS+EM+PS+TF-ThA6 Oxidation and Ablation of HOPG Using Supersonic Beams of Molecular Oxygen Combined with STM Visualization, <i>Ross Edel, T. Grabnic, B. Wiggins, S.J. Sibener</i> , University of Chicago	TF+AS+EL+EM+NS+PS+SS-ThA6 Dopant Distribution in Atomic Layer Deposited ZnO:Al and In ₂ O ₃ :H Films Studied by Atom Probe Tomography and Transmission Electron Microscopy, <i>Y. Wu, B. Macco</i> , Eindhoven University of Technology, The Netherlands; <i>A.D. Giddings, T.J. Prosa, D.J. Larson, CAMECA Instruments Inc.; S. Kölking, P.M. Koeraad, F. Roozeboom, Erwin Kessels, M.A. Verheijen</i> , Eindhoven University of Technology, The Netherlands
4:20pm	SS+EM+PS+TF-ThA7 Kinetically Trapped Molecular Growth during the Self-assembly of ZnTPP on Ag(100), <i>Sylvie Rangan, P.K. Kim, C. Ruggieri, R.A. Bartynski</i> , Rutgers, the State University of New Jersey; <i>S. Whitelam</i> , Lawrence Berkeley National Laboratory	TF+AS+EL+EM+NS+PS+SS-ThA7 Roll-to-Roll Processable OTFT Sensors and Amplifier, <i>Kai Zhang</i> , University of Oxford, Department of Materials, UK; <i>C.-M. Chen, B. Choubeiy, H.E. Assender</i> , University of Oxford, UK
4:40pm	SS+EM+PS+TF-ThA8 Early Stage Oxidation and Evolution of Surface Oxides in Ni(100) and Ni-Cr(100) Thin Films, <i>William H. Blades, P. Reinke</i> , University of Virginia	TF+AS+EL+EM+NS+PS+SS-ThA8 Functionalization of Indium Gallium Zinc Oxide Surfaces for Transparent Biosensors, <i>X. Du, S. John, J. Bergevin, Gregory Herman</i> , Oregon State University
5:00pm	SS+EM+PS+TF-ThA9 DLC Films by Modified HiPIMS with Effect from Pulse Parameters on Plasma Parameters and Film Quality, <i>David Ruzic, I. Haehnlein</i> , University of Illinois at Urbana-Champaign; <i>B. Wu</i> , Southwest Jiaotong University; <i>D. Barlaz</i> , University of Illinois at Urbana-Champaign; <i>B.E. Jurczyk</i> , Starfire Industries	TF+AS+EL+EM+NS+PS+SS-ThA9 Large Area Atmospheric Pressure Spatial ALD of IZO and IGZO Thin-film Transistors, <i>C. Frijters, I. Katsouras, A. Illiberi, G. Gelinck</i> , Holst Centre / TNO, Netherlands; <i>Paul Pootd</i> , Holst Centre / TNO and SALDtech B.V., Netherlands
5:20pm	SS+EM+PS+TF-ThA10 Adsorption and Reactions on Topological Insulators Surfaces Probed by Low Energy Ion Scattering, <i>Haoshan Zhu¹, W. Zhou, J.A. Yarmoff</i> , University of California - Riverside	TF+AS+EL+EM+NS+PS+SS-ThA10 Thin Film Ink-Jet Printing on Textiles for Flexible Electronics, <i>Jesse Jur, I. Kim, H. Shahriar</i> , North Carolina State University
5:40pm	SS+EM+PS+TF-ThA11 Atomically Controlled Metallation of Porphyrinoid Species with Lanthanides on Surfaces, <i>Borja Cirera</i> , IMDEA Nanoscience, Spain; <i>J. Björk</i> , Linköping University, Sweden; <i>G. Bottari, T. Torres</i> , Universidad Autonoma Madrid, Spain; <i>R. Miranda, D. Ecija</i> , IMDEA Nanoscience, Spain	TF+AS+EL+EM+NS+PS+SS-ThA11 Flexography Oil Patterning for In-line Metallization of Aluminium Electrodes onto Polymer Webs: Commercial Roll to Roll Manufacturing of Flexible and Wearable Electronics, <i>Bryan Stuart, T. Cosnahan, A.R. Watt, H.E. Assender</i> , University of Oxford, Department of Materials, UK

¹ Morton S. Traum Award Finalist

Thursday Evening Poster Sessions, October 25, 2018

2D Materials Focus Topic

Room Hall B - Session 2D-ThP

2D Materials Poster Session

6:00pm

2D-ThP1 Activated Reduction Plasma Assisted Sulfurization in Layered WS₂ Synthesis, *Chien-Pao Lin, C.-N. Hsiao, ITRC,NARL, Taiwan, Republic of China; P.-S. Chen, C.-A. Jong, No Matching Affiliation, Taiwan, Republic of China*

2D-ThP2 Quantized States, Berry Phases, and Quantum-Hall Wedding-Cake structures in Graphene Quantum Dots, *Fereshte Ghahari Kermani, D. Walkup, C. Gutierrez, National Institute of Standards and Technology (NIST)/ University of Maryland, College Park; C. Lewandowski, Department of Physics, Massachusetts Institute of Technology; J. Rodriguez-Nieva, Massachusetts Institute of Technology; K. Watanabe, T. Taniguchi, National Institute for Materials Science, Japan; L. Levitov, Massachusetts Institute of Technology; N.B. Zhitenev, J.A. Stroscio, National Institute of Standards and Technology (NIST)*

2D-ThP3 Growth Phenomena and Mechanism of MoS₂ Formed by Conventional Chemical Vapor Deposition, *Cheol-Min Hyun, J.H. Choi, S.W. Lee, J.-H. Ahn, Korea Maritime and Ocean University, Republic of Korea*

2D-ThP4 Graphene Micro Wires Defined by Photolithography and Plasma Etching for Field Effect Transistors, *F.C. Rufino, A.M. Pascon, University of Campinas, Brazil; D.G. Larrude, Mackenzie Presbyterian University, Brazil; W.C. Mariano, José Alexandre Diniz, University of Campinas, Brazil*

2D-ThP5 Elucidating the Influence of Chemical Functionalization and Structural Defects in 2D Material Properties, *Sanjini Nanayakkara, H. Zhang, National Renewable Energy Laboratory; M.A. Todt, J.B. Sambur, Colorado State University; J.L. Blackburn, E.M. Miller, National Renewable Energy Laboratory*

2D-ThP6 In-Operando AFM/STM and Transport Measurements of a Graphene Hall Bar Device, *Johannes Schwenk, National Institute of Standards and Technology (NIST)/ University of Maryland, College Park; S. Kim, National Institute of Standards and Technology (NIST) / Department of Physics and Astronomy, Seoul National University, Seoul, Korea; F. Ghahari, National Institute of Standards and Technology (NIST)/ University of Maryland, College Park; J. Berwanger, Institut für Experimentelle und Angewandte Physik, Universität Regensburg, Germany; W.G. Cullen, S.R. Blankenship, National Institute of Standards and Technology (NIST); Y. Kuk, Department of Physics and Astronomy, Seoul National University, Seoul, Korea; F.J. Giessibl, Institut für Experimentelle und Angewandte Physik, Universität Regensburg, Germany; N.B. Zhitenev, J.A. Stroscio, National Institute of Standards and Technology (NIST)*

2D-ThP7 Mechanical Properties of Graphynes under Tension and Shearing, *Te-Hua Fang, National Kaohsiung University of Science and Technology, Taiwan; C.-W. Hung, National Kaohsiung University of Science and Technology*

Actinides and Rare Earths Focus Topic

Room Hall B - Session AC-ThP

Actinides and Rare Earths Poster Session

Moderators: David Shuh, Lawrence Berkeley National Laboratory, James Tobin, UW Oshkosh

6:00pm

AC-ThP1 Upconversion Photoluminescence Efficiency Dependence of Yb ions in Gd_{0.91-x}NbO₄: Ybx3+, Er0.09, S.S. Yi, *Seung Gon Lee, Silla University, Republic of Korea*

AC-ThP2 Luminescence Characteristics of (Gd_{0.85-x}Yb_{0.15})NbO₄:Er³⁺ Phosphors, S.S. Yi, *DongGyu Lee, Silla University, Republic of Korea*

AC-ThP3 Exploring the Electronic Structure of Molecular Lanthanide Complexes in the +2 Oxidation State Using Photoelectron Spectroscopy, *Daniel Huh, J.P. Bruce, J.C. Hemminger, W. Evans, University of California, Irvine*

AC-ThP4 Effects of Cerium Content on Local Structure in U1-xCeO₂ Solid Solution, *H.J. Cao, Shanghai Institute of Applied Physics, Chinese Academy of Science, China; Yuying Huang, Shanghai Institute of Applied Physics, Chinese Academy of Science, China*

AC-ThP5 Magnetism of the (Nd,R)₂Fe₁₄B - H system with R = Er and Tm, *I. Tereshina, Lev Ivanov, M.V. Lomonosov Moscow State University, Russian Federation; D. Gorbunov, Helmholtz-Zentrum Dresden-Rossendorf, Germany; M. Paukov, Charles University, Prague, Czech Republic; E.A. Tereshina-Chitrova, Institute of Physics, Academy of Sciences of the Czech Republic; M. Doerr, Technische Universität Dresden, Germany; L. Havela, Charles University, Prague, Czech Republic; A.V. Andreev, Institute of Physics ASCR, Czech Republic*

Applied Surface Science Division

Room Hall B - Session AS-ThP

Applied Surface Science Division Poster Session

6:00pm

AS-ThP1 Toward an Improved Understanding of the role of soil organic matter in NO_x cycling through Investigation of Heterogeneous Reactions with NO₂⁺, *R. Hansen, Indiana University; Mark Engelhard, Pacific Northwest National Laboratory; J. Raff, Indiana University*

AS-ThP2 Measuring the Damage Depth and Recovery of PEMA Thin Films using Multiple Technique Analysis, *William Sgammato, R.E. Simpson, Thermo Fisher Scientific, UK*

AS-ThP3 Determination of Band Offsets in Semiconductor Heterostructures (2D/3D) by using XPS, *Mohamed Hedhili, King Abdullah University of Science and Technology (KAUST), Core Labs, Saudi Arabia; M. Tangi, P. Mishra, T.K. Ng, B. Janjua, C.C. Tseng, Photonics Laboratory, King Abdullah University of Science and Technology (KAUST), Saudi Arabia; D.H. Anjum, King Abdullah University of Science and Technology (KAUST), Core Labs, Saudi Arabia; M.S. Alias, Photonics Laboratory, King Abdullah University of Science and Technology (KAUST), Saudi Arabia; N. Wei, King Abdullah University of Science and Technology (KAUST), Core Labs, Saudi Arabia; L.J. Li, Physical Sciences and Engineering Division, King Abdullah University of Science and Technology (KAUST), Saudi Arabia; B.S. Ooi, Photonics Laboratory, King Abdullah University of Science and Technology (KAUST), Saudi Arabia*

AS-ThP4 Multi-technique Characterization of Nanowire-based Catalysts and Electrodes, *Sarah Zaccarini, C. Ngo, Colorado School of Mines; S. Shulda, S. Mauger, S.M. Alia, K.C. Neyerlin, B.S. Pivovar, National Renewable Energy Laboratory; S. Pylypenko, Colorado School of Mines*

AS-ThP5 Detailed Peak-Fitting Analysis of the Photoemission Spectra of the Early Oxidation Stages of Cobalt Thin Films, *Dagoberto Cabrera-German, Universidad de Sonora, México; O. Cortazar-Martinez, G. Vázquez, J.A. Torres-Ochoa, Cinvestav-Unidad Queretaro, Mexico; A. Herrera-Gomez, CINVESTAV-Unidad Queretaro, Mexico*

AS-ThP6 Characterization of Laser-Treated Ti-6Al-4V-Surfaces, *Harry Meyer, D. Leonard, A. Sabau, Oak Ridge National Laboratory*

AS-ThP7 Cross-Sectional Mapping vs. Depth Profiling Analysis: Is the Choice Always Clear?, *Kathryn Lloyd, J.R. Marsh, DuPont Corporate Center for Analytical Sciences*

AS-ThP8 Investigation on Human Evidences using ToF-SIMS Combined with Advanced Matching Recognition, *T. Terlier, Korea Institute of Science and Technology; J. Lee, M. Kang, Yeonhee Lee, Korea Institute of Science and Technology, Republic of Korea*

AS-ThP9 Calculation of Multiplet Structure in a Mixture of Copper Oxides, *Diego Fernando Mulato-Gómez, J.A. Torres Ochoa, Cinvestav-Unidad Queretaro, Mexico; D. Cabrera-German, Universidad de Sonora, México; A. Herrera-Gomez, CINVESTAV-Unidad Queretaro, Mexico*

AS-ThP10 Wafer Bonding Between LiTaO₃(100) and Alpha-quartz SiO₂(100) via Low Temperature (<220°C) NanoBonding™ Using Surface Energy Modification, *Brian Baker, J. Kintz, A. Yano, N. Herbots, Arizona State University; W.-L. Lee, Cactus Materials, Inc.; S.R. Narayan, J.M. Day, Arizona State University; R. Islam, Cactus Materials, Inc.; Y. Watznabe, TDC Corporation; M. Koury, M. Johnson, R.J. Culbertson, M. Magnus, Arizona State University*

AS-ThP11 Structural, Morphological and Electrical Properties of Multilayer Sequentially Sputtered Nb₃Sn Films for Different Layer Thicknesses, *Md. Nizam Sayeed, Old Dominion University; U. Pudasaini, College of William and Mary; H. E. Elsayed-Ali, Old Dominion University; G. Eremeev, Thomas Jefferson National Accelerator Facility*

AS-ThP12 Corrosive and Thermal Properties of ZrO₂- Y₂O₃ Thermal Barrier Coatings, *Byung-Koog Jang, Kyushu University, Japan; H.T. Kim, Korea Institute of Ceramic Engineering and Technology*

Electronic Materials and Photonics Division

Room Hall B - Session EM-ThP

Electronic Materials and Photonics Division Poster Session

6:00pm

EM-ThP1 Femtosecond-Pulsed Laser Deposition of Erbium-Doped Glass Nanoparticles in Polymer Layers for Hybrid Optical Waveguide Amplifiers., *Eric Barimah, University of Leeds, UK, United Kingdom of Great Britain and Northern Ireland; M.W. Ziarko, N.A. Bamiedakis, I.H. White, R.V. Penty, University of Cambridge, United Kingdom of Great Britain and Northern Ireland; G.J. Jose, University of Leeds, UK*

Thursday Evening Poster Sessions, October 25, 2018

EM-ThP2 Precisely Determining the Band Offset at GaN/AlGaN Interfaces by Effectively Control the Surface and Interface States, *Sunan Ding, H. Yang, SuZhou Institute of Nano-Tech and Nano-Bionics, CAS, China*

EM-ThP3 Thermal Engineering for High-Power, Flexible Electronics, *Katherine Burzynski, University of Dayton and Air Force Research Laboratory, Materials and Manufacturing Directorate; E.W. Blanton, N.R. Glavin, E.R. Heller, M. Snure, E.M. Heckman, Air Force Research Laboratory; C. Muratore, University of Dayton*

EM-ThP4 Growth and Magneto-optical Properties of ZnO/Zn_{1-x}Mn_xO Thin Films on Si Substrates, *Da-Ren Liu, ITRC,NARL,Taiwan, Republic of Korea; C.-J. Weng, ITRC,NARL, Taiwan, Republic of Korea*

EM-ThP5 The Formation of Stable GeO₂ Oxide on Germanium Epitaxial Layer using the High Pressure Oxidation, *Nakjun Choi, J.H. Bae, Sungkyunkwan University, Republic of Korea*

EM-ThP6 NH₄OH Solution Wet Etching for Silicon Channel Thinning of Junctionless-FET, *Lucas Stucchi-Zucchi, A.R. Silva, J.A. Diniz, University of Campinas, Brazil*

EM-ThP7 Fabrication of Highly-Efficient Nanoscale Multilayered Thin-Film Thermoelectric Devices, *Alandria Henderson, J. Kimbrough, Z. Duncan, K. Davis, M. Howard, J. Elke, T. Wimbley, M. Glenn, Z. Xiao, Alabama A&M University*

EM-ThP8 Plasmonic Studies of Metallic Nanostructures Fabricated by DNA Origami, *Enrique Samano, D. Ruiz, K.L. Cardos, Universidad Nacional Autónoma de México, Mexico*

EM-ThP9 Control of Randomness in Microsphere-Based Photonic Crystals Assembled by Langmuir-Blodgett Process, *Sarun Atiganyanun, O.K. Abudayyeh, S.M. Han, S.E. Han, University of New Mexico*

EM-ThP10 Incorporation of Ferroelectric HfO₂ into Magnetoelectric Random-Access Memory (MeRAM) Devices, *K. Fitzell, Jeffrey Chang, A. Acosta, H. Ma, X. Li, K.L. Wang, J.P. Chang, University of California, Los Angeles*

EM-ThP11 Extreme Environment Operation of Al_{0.85}Ga_{0.15}N/Al_{0.7}Ga_{0.3}N High Electron Mobility Transistors, *Patrick Carey, F.R. Ren, University of Florida; A.G. Baca, B. Klein, A.A. Allerman, A.M. Armstrong, E.A. Douglas, R.J. Kaplar, Sandia National Laboratories; S.J. Pearton, University of Florida*

EM-ThP12 Electrical Characterization of the Reduced Effective Schottky Barrier Height by Nanoscale Ge bi-layer of CZTSe Solar Cells, *Sanghyun Lee, Indiana State University*

EM-ThP13 Optimal Contact Photolithography Techniques For HEMT Substrates using I-line Photoresist, *Whitney Ingram, A. Jones, B. Klein, A.G. Baca, A.M. Armstrong, A.A. Allerman, E.A. Douglas, Sandia National Laboratories*

EM-ThP14 High-mobility Helical Tellurium Field Effect Transistors Enabled by Transfer-free, Low-temperature Direct Growth, *Guanyu Zhou, R. Addou, Q. Wang, S. Honari, C.R. Cormier, L. Cheng, R. Yue, C.M. Smyth, A. Laturia, J. Kim, W.G. Vandenberghe, M.J. Kim, R.M. Wallace, C.L. Hinkle, University of Texas at Dallas*

EM-ThP16 Investigation of Field Emission from Single ZnO Nanowire, *Yicong Chen, X. Song, Y. Wang, Z. Zhang, Z. Li, J. She, S. Deng, N. Xu, J. Chen, State Key Lab of Optoelectronic Materials and Technologies, Guangdong Province Key Lab of Display Material and Technology, Sun Yat-sen University*

EM-ThP17 Photoemission under Different Mechanisms from Single- and Dual-gate Carbon Nanotubes Field Effect Transistors, *S. Yang, Bo Wang, S.B. Cronin, University of Southern California*

EM-ThP18 100 keV Proton Irradiation Effects on AlGaN/GaN Epistructures, *Min Khanal, S. Upadhyay, K. Yapabandara, V. Mirkhani, S. Wang, B. Schoeneck, T. Isaacs-Smith, A. Ahly, M.J. Bozack, M. Park, Auburn University*

EM-ThP19 Properties of WSe₂ Thin Films Grown by Molecular Beam Epitaxy, *P. Litwin, K.M. Freedy, T. Zhu, M. Zebarjadi, Stephen McDonnell, University of Virginia*

EM-ThP20 Effects of O₂ Partial Pressure on Ga₂O₃ Thin-films, *Seth King, University of Wisconsin - La Crosse*

Fundamental Discoveries in Heterogeneous Catalysis Focus Topic

Room Hall B - Session HC-ThP

Fundamental Discoveries in Heterogeneous Catalysis Focus Topic Poster Session

6:00pm

HC-ThP1 Analyses of Nano-Crystalline Structure in Precipitated Iron-Based Catalysts for Fischer-Tropsch Synthesis, *Dong Hyun Chun, G.B. Rhim, J.C. Park, Korea Institute of Energy Research, Republic of Korea; C.S. Kim, Kookmin University, Republic of Korea; J.-S. Bae, M.H. Youn, H. Jeong, S.W. Kang, H.-T. Lee, J.-I. Yang, H. Jung, Korea Institute of Energy Research, Republic of Korea*

HC-ThP2 *In situ* Infrared and Catalytic Reaction Studies of Active Sites on Pt Nanoparticles Supported on Nanosponge Oxides under CO oxidation, *Sunyoung Oh, Korea Advanced Institute of Science and Technology (KAIST), Republic of Korea; C.H. Jung, Institute for Basic Science (IBS), Republic of Korea; H. Ha, Chungnam National University, Republic of Korea; C. Jo, Institute for Basic Science (IBS), Republic of Korea; S.Y. Moon, Y.K. Kim, Korea Advanced Institute of Science and Technology (KAIST), Republic of Korea; W.H. Doh, Institute for Basic Science (IBS), Republic of Korea; H.Y. Kim, Chungnam National University, Republic of Korea; R. Ryoo, J.Y. Park, Korea Advanced Institute of Science and Technology (KAIST), Republic of Korea*

HC-ThP3 Activity of Bimetallic Pt-Re Surfaces and Influence of the Support for the Water-Gas Shift Reaction, *Amy Brandt¹, T.D. Maddumapatabandi, D. Shakya, S. Farzandh, D.A. Chen, University of South Carolina*

HC-ThP4 In-Operando Photoluminescence Imaging of a Single-Layer Molybdenum Disulfide Catalyst, *Koichi Yamaguchi, University of California - Riverside; S. Naghibi, W. Coley, L. Bartels, University of California, Riverside*

HC-ThP5 Efficient Photoelectrochemical Water Splitting in Band Edge Engineered Metal Oxide Heterostructure Photoanode for Solar Fuel Production, *Nisha Kodan, Thin Film Laboratory, Department of Physics, IIT Delhi, India; A.P. Singh, Division of Chemical Physics, Department of Physics, Chalmers University of Technology, SE-412 96 Göteborg, Sweden; B.R. Mehta, Thin Film Laboratory, Department of Physics, IIT Delhi, India*

HC-ThP6 Comparative Reactivity of Oxide and Metallic Phases on Rh(111), *R.G. Farber, M.E. Turano, W. Walkosz, Christopher Smith, D.R. Killelea, Loyola University Chicago*

HC-ThP7 Hybrid Adsorbent Catalyst for Siloxane Removal: Fe-BEA Zeolites, *Alba Cabrera-Codony, University of Girona, Spain; E. Santos-Clotas, J. Martin, University of Girona*

Advanced Ion Microscopy Focus Topic

Room Hall B - Session HI-ThP

Advanced Ion Microscopy Poster Session

6:00pm

HI-ThP1 He+ and Ne+ Ion Beam Resolution Dependency on Beam Energy, *Waqas Ali, Intel Corporation, USA; S. Tan, Intel Corporation; R.M. Hallstein, R.H. Livengood, Intel Corporation, USA*

HI-ThP2 Focused Cs Ion Beam-Induced Deposition and Gas Assisted Etch Characterization Results for 10nm Circuit Edit Applications, *Roy Hallstein, R.H. Livengood, M.P. Ly, Intel Corporation, USA; Y. Greenzweig, Y. Drezner, Intel Corporation, Israel; B.J. Knuffman, A.V. Steele, A.B.J. Knuffman, zeroK NanoTech*

Magnetic Interfaces and Nanostructures Division

Room Hall B - Session MI-ThP

Magnetic Interfaces and Nanostructures Division Poster Session

6:00pm

MI-ThP1 Synthesis and Size Dependent Magnetic Properties of Iron Oxide Nanoparticles, *Jeremy Winsett, A. Moilanen, S. Neupane, Middle Tennessee State University*

¹ Morton S. Traum Award Finalist

Thursday Evening Poster Sessions, October 25, 2018

MEMS and NEMS Group

Room Hall B - Session MN-ThP

MEMS and NEMS Group Poster Session

6:00pm

MN-ThP1 The Ni-Co Micro-porous Array with High Dimensional Accuracy Control by Electroforming Process, *Yuhsin Lin, H.J. Wen, ITRC,NARL, Taiwan, Republic of China; C.J. Tsia, NCTU, Taiwan, Republic of China; M.-K. Wang, N.N. Chu, C.C. Chen, C.-N. Hsiao, ITRC,NARL, Taiwan, Republic of China*

MN-ThP2 Reactive Etching of AlGaN using BCl_3 and Ar/BCl_3 , *Meng-Kun Wang, Y.-H. Lin, C.-N. Hsiao, C.C. Chen, J.S. Su, N.C. Chu, C.-T. Lee, ITRC,NARL, Taiwan, Republic of China*

MN-ThP3 Self-Assembled Poly(Ethylene Glycol) Initiated Spatial And Temporal Profiling Of Micro Devices For Selectively Growing Human Liver Cancer Cells, *Juhu Jaiswal, M.D. Dhadayal, IIT (BHU), Varanasi, India*

MN-ThP4 III-V_Si Wafer Bonding using Silicon Oxide Interlayer, *WoongSun Lim, S.H. Jung, Korea Advanced Nano Fab Center, Republic of Korea; S.Y. Hwang, Korea Advanced Nano Fab Center, Republic of Korea; G.Y. Yeom, Sungkyunkwan University, Republic of Korea*

MN-ThP5 Flexible Nanocomposite Sensors for Biomedical and Energy Harvesting Applications, *A.K. Batra, Bir Bohara, Alabama A&M University; R. Currie, NASA*

MN-ThP6 Comparative Studies of Electrical Behavior of PLZT Thin Film Capacitors using Coplanar and Interplanar Configurations, *Vaishali Batra, R. Paul, S. Kotru, The University of Alabama*

MN-ThP7 Carbon Nanotube Yarn Based Strain Sensor, *Maeum Han, J.Y. Lee, J.K. Kim, J.H. Park, D. Jung, Korea Institute of Industrial Technology (KITECH), Republic of Korea*

MN-ThP8 Carbon Nanotube Yarn Based Gas Sensor, *J.Y. Lee, M. Han, J.K. Kim, Daewoong Jung, Korea Institute of Industrial Technology (KITECH), Republic of Korea*

Nanometer-scale Science and Technology Division

Room Hall B - Session NS-ThP

Nanometer-scale Science and Technology Division Poster Session, 6:00pm

NS-ThP1 Intermolecular Interactions in Self-Assembled Monolayers on Metal Surfaces Characterized by Ultrahigh Vacuum Tip-Enhanced Raman Spectroscopy, *J. Schultz, P. Whiteman, Nan Jiang, University of Illinois at Chicago*

NS-ThP2 Nanoscale Detection of Surface Plasmon-driven Hot Electron Flux on Au/TiO₂ Nanodiodes with Atomic Force Microscopy, *Hyunhwa Lee, Korea Advanced Institute of Science and Technology (KAIST), Republic of Korea; H. Lee, Institute for Basic Science (IBS), Republic of Korea; J.Y. Park, Korea Advanced Institute of Science and Technology (KAIST), Republic of Korea*

NS-ThP3 Surface Functionalization of 2D Mo₂C, *Yang Zeng, P.H. McBreen, T. Zhang, Laval University, Canada*

NS-ThP4 a-Si:H Spacer Lithography Using Different Mandrels (Al, SiN_x and Photoresist) and Etching Processes (RIE, ECR and ICP), *Andressa Rosa, J.A. Diniz, UNICAMP, Brazil*

NS-ThP5 Optimization of Stitching Multiple Fields of View for Large Scale Two Photon Lithography, *Steven Kooi, Massachusetts Institute of Technology*

NS-ThP6 Fabrication of Carbon Nanotube-Based Electronic Devices with the Dielectrophoresis Method, *Joevonte Kimbrough, S. Chance, B. Whitaker, Z. Duncan, K. Davis, A. Henderson, Q. Yuan, Z. Xiao, Alabama A&M University*

NS-ThP7 Fabrication and Electrical Characterization of a Flagella-Scaffolded Metallic Nanocluster Network, *Marko Chavez, P.J. Edwards, M.Y. El-Naggar, V.V. Kresin, University of Southern California*

NS-ThP8 High-contrast Infrared Polymer Photonic Crystals Fabricated by Direct Laser Writing, *Yanzeng Li, D.B. Fullager, S. Park, University of North Carolina at Charlotte; D. Childers, USC Conec, Ltd.; G.D. Boreman, T. Hofmann, University of North Carolina at Charlotte*

NS-ThP9 Controlled Water-repellent Behavior by Modulating the Density of Nanoscale Si Nanopillar Structure Fabricated with Bio-template and Neutral Beam Etching Technique, *Daisuke Ohori, S. Samukawa, Tohoku University, Japan*

NS-ThP10 An Empirical Model of Fences Formation during Ion Beam Processing, *Anthony De Luca, J. Guerrero, C. Ligaud, Cea, Leti, Minatec, France*

¹ **NSTD Postdoc Finalist**

Thursday Evening Poster Sessions, October 25, 2018

NS-ThP11 Towards Molecular-Level Control of Reactions on Organic Semiconductor Surfaces, *Gregory Deye, J.W. Ciszek, Loyola University Chicago; J. Chen, J. Vicente, Ohio University; S. Dalke, S. Piranej, Loyola University Chicago*

NS-ThP12 The TESLA JT SPM, *Markus Maier, D. Stahl, A. Piriou, M. Fenner, J. Koeble, K. Winkler, T. Roth, Scienta Omicron GmbH, Germany*

NS-ThP13 Recent Developments of Home-made UHV SPM Systems and their Applications, *Qing Huan, R.T. Wu, L.H. Yan, D.L. Bao, R.S. Ma, Z.B. Wu, Institute of Physics, CAS, China; Z.Y. Gao, X.Y. Chen, University of Chinese Academy of Sciences, China; J.H. Ren, Institute of Physics, CAS, China; L. Dong, A.W. Wang, H. Yang, Y.Q. Xing, L.M. Wu, J.H. Yan, Y.L. Wang, L.H. Bao, S.X. Du, H.J. Gao, Institute of Physics, CAS, China*

NS-ThP14 Novel *In-situ* Diagnostic tools to Analyze Chemical Composition and Energy Spectrum of Vapor in Thin Film Deposition Process, *Mikhail Strikovski, S.H. Kolagani, Neocera LLC*

NS-ThP15 Towards Automated High Throughput Drug Delivery with Plasmonic Nanopipettes, *Naihao Chiang, Y. Gong, L. Scarabelli, N. Wattanatorn, C. Zhao, J. Bellings, University of California at Los Angeles; N.-J. Cho, Nanyang Technological University; S. Jonas, P.S. Weiss, University of California at Los Angeles*

NS-ThP16 High Fidelity and Sustainable Anti-reflective Moth-eye Nanostructures and Large Area Sub-wavelength Applications, *Shuhao Si, Technische Universität Ilmenau, Germany; M. Hoffmann, Ruhr-Universität Bochum, Germany*

NS-ThP17 Fano Resonances at Interference of Electron Waves in Geometrically Inhomogeneous Semiconductor 2D Nanostructures, *Victor Petrov, Institute of Radio Engineering and Electronics, Russian Academy of Sciences, Moscow, Russia, Russian Federation*

NS-ThP18 Indirect Transition and Opposite Circular Polarization of Interlayer Exciton in a MoSe₂/WSe₂ van der Waals Heterostructure, *Hsun-Jen Chuang¹, A.T. Hanbicki, M. Rosenberger, C.S. Hellberg, S.V. Sivaram, K.M. McCreary, I. Mazin, B.T. Jonker, Naval Research Laboratory*

NS-ThP19 Pycroscopy – A Community-driven Approach for Analyzing and Storing Materials Imaging and Spectroscopy Data, *S. Somnath, C.R. Smith, R. Vasudevan, Sergei Kalinin, S. Jesse, Oak Ridge National Laboratory*

NS-ThP20 Auto-dispersing Cellulose Nanoparticles with High Uniformity via Self-assembly in Ionic Liquids, *Y. Ahn, Seung-Yeop Kwak, Seoul National University, Republic of Korea*

NS-ThP21 The Silicon Atomic Layer Etching by Two-step PEALD Consisting of Oxidation and $(\text{NH}_4)_2\text{SiF}_6$ formation, *E.-J. Song, Korea Institute of Materials Science, Republic of Korea; J.-H. Ahn, Korea Maritime and Ocean University, Republic of Korea; Jung-Dae (J.-D.) Kwon, Korea Institute of Materials Science, Republic of Korea; S.-H. Kwon, Pusan National University, Republic of Korea*

Novel Trends in Synchrotron and FEL-Based Analysis Focus Topic

Room Hall B - Session SA-ThP

Novel Trends in Synchrotron and FEL-Based Analysis Focus Topic Poster Session

6:00pm

SA-ThP1 Relative Sensitivity Factors in Hard X-ray Photoelectron Spectroscopy up to 10 keV for Quantitative Analysis, *Satoshi Yasuno, Japan Synchrotron Radiation Research Institute, Japan; N. Ikeno, Aichi Synchrotron Radiation Center, Japan; H. Oji, Nagoya University Synchrotron Radiation Research Center, Japan*

SA-ThP2 In Situ Characterization of Freeze-Cast Metal Nanowire Aerogels, *Tyler Fears, J.A. Hammons, F. Qian, T. Braun, A.L. Troksa, M.H. Nielsen, J.B. Forien, T.F. Baumann, T.Y. Han, S.O. Kucheyev, M. Bagge-Hansen, Lawrence Livermore National Laboratory*

SA-ThP3 In situ Probing of the Potential Distribution in a Thin Film All-solid-state Li-ion Battery, *Evgheni Strelcov, National Institute of Standards and Technology (NIST)/University of Maryland; E.J. Fuller, Sandia National Laboratories; W. McGehee, N.B. Zhitenev, J. McClelland, National Institute of Standards and Technology (NIST); A. Talin, Sandia National Laboratories*

SA-ThP4 A New Route for the Determination of Protein Structure in Physiological Environment through Coherent Diffraction Imaging., *Danny Fainozzi, university of Trieste / Elettra Synchrotron, Italy*

SA-ThP5 The League of European Accelerator-Based Photon Sources: New strategic partnerships in Europe and beyond, *Maya Kiskinova, Elettra-Sincrotrone Trieste, Italy*

Thursday Evening Poster Sessions, October 25, 2018

Thin Films Division

Room Hall B - Session TF-ThP

Thin Film Poster Session

6:00pm

TF-ThP2 Investigation of Target State by Plasma Emission and Target Voltage Measurements for Reactive Sputtering of Ni oxide thin films with water vapor injection, *Yuki Yokoiwa, Y. Abe, M. Kawamura, K.H. Kim, T. Kiba*, Kitami Institute of Technology, Japan

TF-ThP3 Rectification and Non-linearity in Ferroelectric Tunnel Junction based on BiFeO₃ Ultra-thin Film, *Taejib Choi*, Sejong University, Republic of Korea

TF-ThP7 Optical and Electrochemical Properties of Rhodium Oxide Thin Films prepared by Reactive Sputtering in O₂ or H₂O Atmosphere, *ChanYang Jeong, Y. Abe, M. Kawamura, K.H. Kim, T. Kiba*, Kitami Institute of Technology, Japan

TF-ThP8 Interfacial Self-assembled Monolayers as Copper Diffusion Barrier for IGZO Semiconductor Thin Film Transistor, *Sung-Eun Lee, K.-H. Lim, J. Park, J.-E. Huh, J. Lee, E.G. Lee, C.I. Im, Y.S. Kim*, Seoul National University, Republic of Korea

TF-ThP9 Atmospheric-pressure Plasma Treatment Effect of Solution-processed Aluminum Oxide Gate Insulator for Oxide Semiconductor Thin-film Transistors, *Jintaek Park, K.-H. Lim, S.-E. Lee, J.-E. Huh, J. Lee, E.G. Lee, C.I. Im, Y.S. Kim*, Seoul National University, Republic of Korea

TF-ThP10 Microstructural and Electrical Properties of Ni Stanogermanides formed on Ge_{0.92}Sn_{0.08} epi-layer Grown on Si(100) Substrate, *HanSoo Jang*, Semiconductor Physics Research Center(SPRC), Chonbuk National University, Republic of Korea

TF-ThP11 Radiation Effects on Al₂O₃ Thin Films, *H.P. Zhu, X. Chen, Zhong-Shan Zheng, D.L. Li, J.T. Gao, B. Li, J.J. Luo*, Institute of Microelectronics of Chinese Academy of Sciences, China

TF-ThP12 Comparative Study of Erosion on Various Polymers and Composites both Coated Using a DC Magnetron Sputtering Process and Uncoated, *S. Hill, Dorina Mihut, A. Afshar, K.J. Culp, Z. Grantham*, Mercer University School of Engineering

TF-ThP13 Plasma-enhanced Atomic Layer Deposition of Molybdenum Compounds Thin Films Using Mo(CO)₆ with Various Plasma Gases, *Jeong-Hun Choi, S.W. Lee, C.M. Hyun, J.-H. Ahn*, Korea Maritime and Ocean University, Republic of Korea

TF-ThP14 Development of Metal Linear Evaporator for OLED Panel Mass Production of Gen.6 half and Gen. 8 lines, *Jung Hyung Kim*, Korea Research Institute of Standards and Science (KRISS), Republic of Korea; *M.S. Kang, K.S. Shin, D.M. Lim*, Fineva Co., Republic of Korea

TF-ThP15 Study of W Film Properties on Various Treated TiN/AIO Underlayer, *Dong-Hoon Han, D. Lee, M. Park, J.Y. Bae, J. Lee, Y. Koo*, Samsung Electronics, Republic of Korea

TF-ThP16 Fabrication of Mo/B₄C Periodic Films on the High Reflective Mirror for Applications in Beyond Extreme Ultraviolet Lithography, *Chao-Te Lee, W.-C. Chen, H.-P. Chen, M.-K. Wang*, Instrument Technology Research Center, Taiwan, Republic of China

TF-ThP17 Effects of the Electric Field Application for the Photocatalytic Property of TiO₂/Ni Thin Films, *Taishi Segawa, I. Takano*, Kogakuin University, Japan

TF-ThP18 Crystallization Behavior and Thermal Stability of Zr-based Metallic Glasses, *J.S. Park, D.H. Song, JinKyu Lee*, Kongju National University, Republic of Korea

TF-ThP19 The Investigation of the Chemical State of the PTFE Surface Treated by Ar Plasma, *Koki Iesaka, I. Takano*, Kogakuin University, Japan

TF-ThP20 The Influence of ZnO Layers for Photovoltage of Cu₂O/ZnO/TiO₂ Thin Films Prepared by Reactive Sputtering, *Keisuke Ishizaka*, Kogakuin University, Japan; *I. Takano*, Kogakuin University, Japan

TF-ThP21 The Formation of Amorphous Carbon Thin Films by Ion Beam Mixing, *Kenji Iwasaki, I. Takano*, Kogakuin University, Japan

TF-ThP22 Enhancing Ultra-violet Optical Properties of Aluminum Mirrors with a Single Step Approach to Oxide Removal and Fluorine Passivation, *David Boris*, U.S. Naval Research Laboratory; *A.C. Kozen*, ASEE Postdoctoral Fellow; *J. del Hoyo, M.A. Quijada*, NASA Goddard Space Flight Center; *S.G. Walton*, U.S. Naval Research Laboratory

TF-ThP23 Cu Films on Thermoelectric ZnSb, *Terje Finstad, G. Song, H.G. Riis, O. Prytz*, University of Oslo, Norway

TF-ThP24 Using a Semitransparent Underlayer to Determine Optical Constants of a Mostly Opaque Layer by Thin Film Interference: Application to AlF₃ on Al in the Extreme Ultraviolet, *Gabriel Richardson, K.M. Wolfe, M.D. Barona, R.S. Turley, D.D. Allred*, Brigham Young University

TF-ThP25 Thermoelectric Properties of Sb₂Te₃ Thin Films, *Eshirdanya McGhee, B. Bohara, C. Payton, S. Gere, S. Budak*, Alabama A&M University

TF-ThP26 Thermal Annealing Effects on the Thermoelectric Properties of CoAg Thin Films, *Satilmis Budak, S. Gere, E. McGhee, E. Gamble*, Alabama A&M University

TF-ThP28 Interlayer Effect for Photocatalytic Properties of TiO₂/Cu₂O Thin Films Prepared by Reactive Sputtering, *Akihiro Joichi, I. Takano*, Kogakuin University, Japan

TF-ThP29 The effect of Proton Radiation on ALD HfO₂ Films and HfO₂ based RRAM, *Panpan Xue*, University of Wisconsin-Madison; *Z. Wang*, Stanford University; *T. Chang*, University of Wisconsin-Madison; *Y. Nishi*, Stanford University; *Z. Ma, J.L. Shohet*, University of Wisconsin-Madison

TF-ThP30 Comparison of Hafnium Oxide and Zirconium Oxide for Fabricating Electronic Devices, *Kenneth Davis, Z. Duncan, M. Howard, T. Wimbley, Z. Xiao*, Alabama A&M University

TF-ThP31 Development of the Synchrotron-based Capabilities for Direct, *In-situ* XANES/XAFS Measurements of Thermal ALD: Initial Proof-of-Concept Study Exploring ZrO₂ ALD, *David Mandia, B. Kucukgok, S. Letourneau, M.J. Ward, A. Yanguas-Gil, J.W. Elam*, Argonne National Laboratory

TF-ThP32 Nitridation of Transition Metal Oxide Films, *Li Chang, W.-L. Chen, K.A. Chiu, Y.S. Fang*, National Chiao Tung University, Hsinchu, Taiwan, Taiwan, Republic of China

TF-ThP33 The Evolution of Atomic Layer Processing as a Field: Atomic Layer Etching, and its Connections with Atomic Layer Deposition, *Elsa Alvaro*, Northwestern University; *A. Yanguas-Gil*, Argonne National Laboratory

TF-ThP34 Optical Characterization of SiC Thin Films on Si(111), *Kjeld Pedersen*, Aalborg University, Denmark; *R. Juluri*, Aarhus University, Denmark; *P. Kjaer Kristensen*, Aalborg University, Denmark; *J. Lundsgaard Hansen, B. Julsgaard*, Aarhus University, Denmark

TF-ThP35 Nanocarbon based Field Assisted Electron Emitter Arrays for Development of Electrical Propulsion for Nano Satellite, *Nirupama Prasad*, Jain University, Bangalore, India

TF-ThP36 Investigation of Synthesis Yield Variation of Single-Walled Carbon Nanotubes inside Horizontal Chemical Vapor Deposition Systems, *G.-H. Jeong, Sung-II Jo*, Kangwon National University, Republic of Korea

TF-ThP37 Optical and Mechanical Properties of Diamond-like Carbon Thin Film deposited by Filtered Cathodic Vacuum Arc Source for Durable Coating of Infrared Optics, *Jung-Hwan In, M.W. Seo, H.Y. Jung, S.H. Kim, J.H. Choi*, Korea Photonics Technology Institute, Republic of Korea

TF-ThP38 Influence of Temperature and Plasma Gas Chemistry on Atomic Layer Epitaxial Growth of InN on GaN Assessed with *In Situ* Grazing Incidence Small-Angle X-ray Scattering, *Jeffrey Woodward, S.G. Rosenberg*, American Society for Engineering Education (residing at U.S. Naval Research Laboratory); *N. Nepal, S.D. Johnson*, U.S. Naval Research Laboratory; *C. Wagenbach*, Boston University; *A.C. Kozen*, American Society for Engineering Education (residing at U.S. Naval Research Laboratory); *Z.R. Robinson*, The College at Brockport - SUNY; *D.R. Boris, S.G. Walton*, U.S. Naval Research Laboratory; *K.F. Ludwig*, Boston University; *C.R. Eddy*, U.S. Naval Research Laboratory

TF-ThP39 Water-based Superconcentrated Electrolytes as Gate Dielectric for High-performance Solution-processed Oxide Thin Film Transistors, *Eun Goo Lee, K.-H. Lim, J.T. Park, S.-E. Lee, J.H. Lee, C.I. Im, Y.S. Kim*, Seoul National University, Republic of Korea

TF-ThP40 Atomic Layered Deposition and Characterizations of HfO₂ for OLED Encapsulation, *Nak-Kwan Chung*, Korea Research Institute of Standards and Science (KRISS), Republic of Korea; *S. Kim, J.Y. Yun, J.T. Kim*, Korea Research Institute of Standards and Science (KRISS)

TF-ThP41 Reaction Mechanism Study on the Atomic Layer Deposition of Titanium Oxide Film using Heteroleptic Precursors, *Jaemin Kim, H.-L. Kim, J. Gu, S. Kim, H. Jung, R. Hidayat, Y. Myung, W.-J. Lee*, Sejong University, Korea

Anticipated Schedule Friday, October 26, 2018

Anticipated Schedule Friday Morning, October 26

8:20 AM	_____
8:40 AM	_____
9:00 AM	_____
9:20 AM	_____
9:40 AM	_____
10:00 AM	_____
10:20 AM	_____
10:40 AM	_____
11:00 AM	_____
11:20 AM	_____
11:40 AM	_____
12:00 PM	_____

Anticipated Schedule Friday Lunch, October 26

When	_____
Where	_____
With	_____

NOTES

Friday Morning, October 26, 2018

2D Materials Focus Topic		Actinides and Rare Earths Focus Topic
Room 201B - Session 2D+EM+MN+NS-FrM		Room 202C - Session AC+MI+SA-FrM
Nanostructures including Heterostructures and Patterning of 2D Materials		Actinide and Rare Earth Theory and Related Measurements
Moderator: Xiang Zhang, University of California, Berkeley		Moderators: Paul S. Bagus, University of North Texas, David Shuh, Lawrence Berkeley National Laboratory
8:20am	2D+EM+MN+NS-FrM1 Interfacial Strength and Surface Damage Characteristics of Two-dimensional h-BN, MoS ₂ and Graphene, <i>Frank DelRio</i> , National Institute of Standards and Technology; <i>B.C. Tran Khac, K.H. Chung</i> , University of Ulsan, South Korea	INVITED: AC+MI+SA-FrM1 Periodic Boundary Condition and Embedded Cluster DFT Calculations of Water Adsorption on AnO ₂ (An = U, Pu) Surfaces, <i>Nikolas Kaltsoyannis</i> , University of Manchester, UK, United Kingdom of Great Britain and Northern Ireland
8:40am	2D+EM+MN+NS-FrM2 Optical and Optoelectronic Properties in 2D Homo- and Hetero-junctions, <i>Juan Xia</i> , Nanyang Technological University, Singapore	Invited talk continues.
9:00am	INVITED: 2D+EM+MN+NS-FrM3 Sequential Edge-epitaxy: Towards Two-dimensional Multi-junctions Heterostructures and Superlattices, <i>Humberto Rodriguez Gutierrez</i> , University of South Florida	INVITED: AC+MI+SA-FrM3 Understanding the Role of Oxidation States on the Chemistry of Actinides through Integration of Theory and Experiment, <i>Wibe de Jong, J.K. Gibson</i> , Lawrence Berkeley National Laboratory; <i>R.J. Abergel</i> , Lawrence Berkeley Lab, University of California, Berkeley
9:20am	Invited talk continues.	Invited talk continues.
9:40am	2D+EM+MN+NS-FrM5 Interpretation of π -band Replicas Observed for Mono- and Multi-layer Graphene Grown on 4H SiC(0001), <i>T.B. Balasubramanian, M. Leandersson, J. Adell, C. Polley</i> , Lund University, Sweden; <i>Leif Johansson, R. Yakimova, C. Jacobi</i> , Linkoping University, Sweden	AC+MI+SA-FrM5 An Experimentalist's Viewpoint: The Tremendous Strengths and Occasional Weaknesses of Actinide Cluster Calculations, <i>James G. Tobin</i> , University of Wisconsin-Oshkosh
10:00am	2D+EM+MN+NS-FrM6 Effect of SiC(0001) Substrate Morphology and Termination on Multilayer Hexagonal Boron Nitride Epitaxy by Plasma-Enhanced CBE, <i>Daniel J. Pennachio, N.S. Wilson, E.C. Young, A.P. McFadden, T.L. Brown-Heft</i> , University of California at Santa Barbara; <i>K.M. Daniels, R.L. Myers-Ward, D.K. Gaskill, C.R. Eddy, Jr.</i> , U.S. Naval Research Laboratory; <i>C.J. Palmström</i> , University of California at Santa Barbara	AC+MI+SA-FrM6 Ligand and Metal XAS Edges In Heavy Metal Compounds, <i>Paul S. Bagus</i> , University of North Texas; <i>C.J. Nelin</i> , Consultant
10:20am	2D+EM+MN+NS-FrM7 Nanoelectromechanical Drumhead Resonators from 2D Material Bimorphs, <i>Sun Phil Kim, J. Yu, E. Ertekin, A.M. van der Zande</i> , University of Illinois at Urbana-Champaign	AC+MI+SA-FrM7 Thermal Expansion and Conductivity of Th and Ac from First Principles Calculations, <i>Dominik Legut, L. Kyvala</i> , VSB-Technical University of Ostrava, Czech Republic; <i>U.D. Wdowik</i> , Pedagogical University, Poland
10:40am	2D+EM+MN+NS-FrM8 Atomically-precise Graphene Etch Masks for 3D Integrated Systems from 2D Material Heterostructures, <i>Jangyup Son</i> , University of Illinois at Urbana-Champaign; <i>A.M. van der Zande</i> , University of Illinois at Urbana Champaign	AC+MI+SA-FrM8 XANES Investigation into the Electronic Structure of Ce Coordination Complexes, <i>Liane Moreau, C.H. Booth</i> , Lawrence Berkeley National Laboratory; <i>Y. Qiao, E. Schelter</i> , University of Pennsylvania
11:00am	2D+EM+MN+NS-FrM9 Insights into the O Atom Adsorption and O ₂ Dissociation on Halogenated Graphene Surfaces, <i>Reynaldo Geronia</i> , University of the Philippines Diliman; <i>A.A.B. Padama</i> , University of the Philippines Los Baños, Philippines; <i>J.D. Ocon</i> , University of the Philippines Diliman, Philippines; <i>P.-Y. A. Chuang</i> , University of California, Merced	AC+MI+SA-FrM9 Structure and Properties of Reactively Deposited Uranium Hydride Coatings Studied by the X-ray Scattering Methods, <i>Milan Dopita, L. Havela, L. Horák, E. Chitrova</i> , Charles University, Prague, Czech Republic; <i>D. Legut</i> , VSB-Technical University of Ostrava, Czech Republic; <i>M. Cieslar</i> , Charles University, Prague, Czech Republic; <i>Z. Matěj</i> , MAX-IV, Lund, Sweden
11:20am		AC+MI+SA-FrM10 Ligand Induced Shape Transformation of Thorium Dioxide Nanocrystals, <i>Gaoxue Wang, E. Batista, P. Yang</i> , Los Alamos National Laboratory
11:40am		AC+MI+SA-FrM11 Perspectives on the Synthesis, Characterization and Applications of Upconversion and Downconversion Nanomaterials, <i>Martin Ntwaeaborwa</i> , University of the Witwatersrand, South Africa
12:00pm		

Friday Morning, October 26, 2018

Biomaterial Interfaces Division Room 101B - Session BI+AS+NS-FrM Characterization of Biological and Biomaterial Surfaces Moderator: Bill Theilacker, Medtronic		Magnetic Interfaces and Nanostructures Division Room 203A - Session MI+EM-FrM Magnetism and Spin-Orbit Coupling at Surfaces, Interfaces and Thin Films Moderator: Valeria Lauter, Oak Ridge National Laboratory
8:20am	INVITED: BI+AS+NS-FrM1 Novel Insights into Skin Biology and Permeation of Actives using ToF-SIMS and 3D OrbiSIMS., <i>David Scurr</i> , The University of Nottingham, UK	INVITED: MI+EM-FrM1 Interfacial Spin-orbitronics: Spin-charge Current Conversion in Topological Insulators and Rashba Interfaces, <i>Juan Carlos Rojas Sánchez</i> , Institut Jean Lamour, Universite de Lorraine, France
8:40am	Invited talk continues.	Invited talk continues.
9:00am	BI+AS+NS-FrM3 Multivariate Analysis of ToF-SIMS Data using Mass Segmented Data Matrices: Polymers and Biointerfaces, <i>R.M.T. Madiona</i> , La Trobe University, Australia; <i>N.G. Welch</i> , CSIRO Manufacturing, Australia; <i>D.A. Winkler</i> , La Trobe University, Australia; <i>J.A. Scoble</i> , CSIRO, Australia; <i>B.W. Muir</i> , CSIRO, Australia; <i>Paul Pigram</i> , La Trobe University, Australia	MI+EM-FrM3 Spin-orbit Coupling in Ion-surface Collisions Observed by a Polarized $^4\text{He}^+$ Ion Beam, <i>Taku Suzuki</i> , <i>O. Sakai</i> , National Institute for Materials Science, Japan
9:20am	BI+AS+NS-FrM4 Can you dig it? ToF-SIMS Tissue Depth Profiling, <i>Daniel Graham</i> , <i>T.B. Angerer</i> , <i>L.J. Gamble</i> , University of Washington	MI+EM-FrM4 Transport and Magnetic Properties of $\text{LaAlO}_3/\text{SrTiO}_3$ Heterostructure during Cooling and Warming, <i>Zengming Zhang</i> , <i>X.Q. Wang</i> , <i>M. Zhang</i> , <i>A. Rahman</i> , <i>R.C. Dai</i> , <i>Z.P. Wang</i> , <i>Z.J. Ding</i> , <i>L. Cheng</i> , University of Science and Technology of China
9:40am	BI+AS+NS-FrM5 Characterization of Biologic Release and Transformation Processes of Clay-sorbed Ammonia using ToF-SIMS and XPS, <i>Liuqin Huang</i> , <i>W. Liu</i> , State Key Laboratory of Biogeology and Environmental Geology, China University of Geosciences, China; <i>Z.H. Zhu</i> , Pacific Northwest National Laboratory; <i>H. Dong</i> , Miami University	INVITED: MI+EM-FrM5 Engineering the Magnetic Properties of Complex Oxide Heterostructures, <i>Yayoi Takamura</i> , University of California at Davis
10:00am	BI+AS+NS-FrM6 Novel Insights into Drug Release by a Functionalized Biomaterial and Dispersion into Bone using Surface Analytical Techniques, <i>Marcus Rohrke</i> , <i>C. Kern</i> , <i>B. Mogwitz</i> , <i>S. Ray</i> , Justus-Liebig University Giessen, Germany; <i>J. Thomas</i> , IFW Dresden, Germany	Invited talk continues.
10:20am	BI+AS+NS-FrM7 Spatial Distributions of Epithelial Growth Factors in Hydrogels Studied by ToF-SIMS and TIRF Microscopy for the Development of Biocompatible Multiple-protein Delivery Systems for Wound Healing, <i>Shohini Sen-Britain</i> , State University of New York, Buffalo; <i>W. Hicks</i> , Roswell Park Comprehensive Cancer Center; <i>J.A. Gardella Jr.</i> , State University of New York, Buffalo	MI+EM-FrM7 Location of the Valence Band Maximum in the Band Structure of Anisotropic $1\text{T}'\text{-ReSe}_2$, <i>Markus Donath</i> , <i>P. Eickholt</i> , <i>J. Noky</i> , Westfälische Wilhelms-Universität Münster, Germany; <i>E. Schwier</i> , <i>K. Shimada</i> , <i>K. Miyamoto</i> , <i>T. Okuda</i> , Hiroshima University, Japan; <i>C. Datzer</i> , <i>M. Drüppel</i> , <i>P. Krüger</i> , <i>M. Rohlfing</i> , Westfälische Wilhelms-Universität Münster, Germany
10:40am		MI+EM-FrM8 Controlling Antiferromagnetic Order at the Surface of La doped BiFeO_3 , <i>Hendrik Ohldag</i> , SLAC National Accelerator Laboratory; <i>B.-K. Jang</i> , Korea Advanced Institute of Science and Technology; <i>J.H. Lee</i> , <i>K.-E. Kim</i> , Korea Advanced Institute of Science and Technology, Republic of Korea; <i>H. Jang</i> , SLAC National Accelerator Laboratory; <i>K.-T. Ko</i> , Max Planck Institute for Chemical Physics of Solids; <i>M.H. Jung</i> , Pohang University of Science and Technology, Republic of Korea; <i>T.Y. Koo</i> , Pohang Light Source; <i>Y.H. Jeong</i> , Pohang University of Science and Technology, Republic of Korea; <i>J.-S. Lee</i> , SLAC National Accelerator Laboratory; <i>C-H. Yang</i> , Korea Advanced Institute of Science and Technology, Republic of Korea
11:00am		INVITED: MI+EM-FrM9 Control of Magnetism at the Antiperovskite/Perovskite Interface, <i>D.-F. Shao</i> , <i>T.R. Paudel</i> , <i>Evgeny Tsymbal</i> , University of Nebraska-Lincoln
11:20am		Invited talk continues.
11:40am		
12:00pm		

Friday Morning, October 26, 2018

Nanometer-scale Science and Technology Division		Plasma Science and Technology Division
Room 102B - Session NS+AM+AS+MN+PC+PS+SS+TR-FrM		Room 104A - Session PS-FrM
SPM – Probing Chemical Reactions at the Nanoscale		Plasma Modeling
Moderators: Phillip First, Georgia Institute of Technology, An-Ping Li, Oak Ridge National Laboratory		Moderators: Venkatraman Ayyaswamy, University of California Merced, Premkumar Panneerchelvam, KLA-Tencor
8:20am	INVITED: NS+AM+AS+MN+PC+PS+SS+TR-FrM1 Using Self-Assembly to Engineer Electronic Properties in 1D and 2D Molecular Nanostructures, <i>Michael F. Crommie</i> , University of California at Berkeley Physics Dept.	PS-FrM1 Investigation of Electrical Asymmetric Effect in Very High Frequency Plasma Source using Electromagnetic Plasma Model, <i>Xiaopu Li, K. Bera, S. Rauf, K.S. Collins</i> , Applied Materials
8:40am	Invited talk continues.	PS-FrM2 Simulation of Pulsed Inductively Coupled Plasmas, <i>Jun-Chieh Wang, W. Tian, S. Rauf, S. Sadighi, J.A. Kenney, P.J. Stout, V. Vidyarthi, J. Guo, K. Delfin, N. Lundy</i> , Applied Materials
9:00am	NS+AM+AS+MN+PC+PS+SS+TR-FrM3 Chemical and Electronic Structure of Aniline Films on Silica Surfaces, <i>Christopher Goodwin</i> , University of Delaware; <i>A.J. Maynes</i> , Virginia Polytechnic Institute and State University; <i>Z.E. Voras</i> , University of Delaware; <i>S.A. Tenney</i> , Center for Functional Nanomaterials Brookhaven National Laboratory; <i>T.P. Beebe</i> , University of Delaware	INVITED: PS-FrM3 The Important Role of Metal Vapour in Arc Welding: New Insights from Modelling, <i>Anthony Murphy, J. Xiang, H. Park, F.F. Chen</i> , CSIRO, Australia
9:20am	NS+AM+AS+MN+PC+PS+SS+TR-FrM4 Electric Field Driven Chemical Reaction of Individual Molecular Subunits by Scanning Tunneling Microscopy, <i>Tomasz Michnowicz</i> , Max Planck Institute for Solid State Research, Germany, Deutschland; <i>B. Borca</i> , Max Planck Institute for Solid State Research, Germany; <i>R. Pétrúa</i> , Donostia International Physics Centre, Spain; <i>M. Pristl, R. Gutzler, V. Schendel, I. Pentegov, U. Kraft, H. Klauk</i> , Max Planck Institute for Solid State Research, Germany; <i>P. Wahl</i> , University of St Andrews, UK; <i>A. Arnau</i> , Donostia International Physics Centre, Spain; <i>U. Schlickum, K. Kern</i> , Max Planck Institute for Solid State Research, Germany	Invited talk continues.
9:40am	NS+AM+AS+MN+PC+PS+SS+TR-FrM5 Characterising Conjugated Polymers for Organic Electronics by High-resolution Scanning Probe Microscopy, <i>Giovanni Costantini</i> , University of Warwick, UK	PS-FrM5 Molecular Dynamics Study on Collision Cascade Dynamics for Sputtering of Lennard-Jones Particles, <i>Nicolas Mauchamp, M. Isobe, S. Hamaguchi</i> , Osaka University, Japan
10:00am	NS+AM+AS+MN+PC+PS+SS+TR-FrM6 Probing Electrical Degradation of Lithium Ion Battery Electrodes with Nanoscale Resolution, <i>Seong Heon Kim</i> , Samsung Advanced Institute of Technology, Republic of Korea; <i>S.Y. Park, H. Jung</i> , Samsung Advanced Institute of Technology, Republic of Korea	PS-FrM6 Surface Reaction Analysis by Molecular Dynamics (MD) Simulation for SiO ₂ Atomic Layer Etching (ALE), <i>Satoshi Hamaguchi, Y. Okada, M. Isobe, T. Ito, K. Karahashi</i> , Osaka University, Japan
10:20am		PS-FrM7 Atomistic Simulations of He Plasma Modification of SiO ₂ Thin Films for Advanced Etch Processes, <i>Florian Pinzan, R. Blanc, F. Leverd</i> , STMicroelectronics, France; <i>E. Despiau-Pujo</i> , LTM, Univ. Grenoble Alpes, CEA-LETI, France
10:40am		PS-FrM8 Plasma Characteristics in a Capacitively Coupled System at Moderately High Pressure: Model and Experiment Comparison, <i>David J. Peterson, S. Shannon</i> , North Carolina State University; <i>W. Tian, P. Kraus, K. Bera, S. Rauf, T. Chua, T. Koh</i> , Applied Materials Inc.
11:00am		PS-FrM9 Numerical Modeling of Capacitively Coupled Plasma Process Chamber using CCPFoam, <i>Abhishek Kumar Verma¹</i> , University of California Merced; <i>K. Bera, S. Rauf</i> , Applied Materials; <i>A. Venkatraman</i> , University of California Merced
11:20am		PS-FrM10 Silicon Carbide Nanoparticles for Thermoelectric Composites and Graphene Coatings for Plasmonics, <i>Devin Coleman</i> , University California, Riverside; <i>A. Hosseini, A. Greaney</i> , University of California, Riverside; <i>S. Bux, J.P. Fleurial</i> , Jet Propulsion Laboratory, California Institute of Technology; <i>L. Mangolini</i> , University of California, Riverside
11:40am		PS-FrM11 Electromagnetic Effects in Wide Area Very High Frequency Linear Plasma Source, <i>Kalol Bera, X. Li, S. Rauf, K.S. Collins</i> , Applied Materials
12:00pm		PS-FrM12 External Circuitry Models for PIC Simulations of Cylindrical Magnetron Sputtering Chamber, <i>Nate Crossette, T.G. Jenkins, D.N. Smithe, J.R. Cary</i> , Tech-X Corporation

¹ Coburn & Winters Student Award Finalist

Friday Morning, October 26, 2018

Surface Science Division

Room 203C - Session SS+AS+HC-FrM

Near/Ambient Pressure and Bridging Gaps between Surface Science and Catalysis

Moderators: Donna Chen, University of South Carolina, Janice Reutt-Robey, University of Maryland College Park

8:20am	INVITED: SS+AS+HC-FrM1 Ambient Pressure Electron Spectroscopy (XPS, XAS) and Electron Microscopy Studies of the Structure and Chemistry of Nanostructured Model Catalysts, <i>John Hemminger</i> , University of California Irvine	
8:40am	Invited talk continues.	
9:00am	SS+AS+HC-FrM3 <i>In-operando</i> Investigation of the Initial Oxidation Stages for NiCr-(W) Alloys with X-ray Photoelectron Spectroscopy, <i>Cameron Volders, V. Angelici Avincola, P. Reinke</i> , University of Virginia	
9:20am	SS+AS+HC-FrM4 Surface Hydroxylation of Polar (000-1) and Non-polar (11-20) ZnO Probed with AP-XPS, <i>Sana Rani, A. Broderick, J.T. Newberg</i> , University of Delaware	
9:40am	SS+AS+HC-FrM5 Reason of High Stability and Reactivity of Ni/silicalite-1 Catalyst for Dry Reforming of Methane, <i>Evgeny Vovk, X. Zhou, Z. Liu, C. Guan, Y. Yang</i> , ShanghaiTech University, China; <i>W. Kong</i> , Shanghai Advanced Research Institute, China; <i>R. Si</i> , Shanghai Synchrotron Radiation Facility, Shanghai Institute of Applied Physics, China	
10:00am	SS+AS+HC-FrM6 Recent Development in XPS and Ambient Pressure XPS Techniques, <i>Lukasz Walczak</i> , PREVAC sp. z o.o., Poland	
10:20am	SS+AS+HC-FrM7 Quantum Mechanics and Reaction Kinetics Study on SiO ₂ and SiN Dry Isotropic Chemical Etching Process, <i>Taiki Kato, M. Matsukuma, K. Matsuzaki, L. Chen</i> , Tokyo Electron Technology Solutions Limited, Japan	
10:40am	SS+AS+HC-FrM8 Viscosity and Surface Tension Effects on Metal Sputtered onto Low Vapor Pressure Liquids, <i>Mark De Luna, M. Gupta</i> , University of Southern California	
11:00am		
11:20am		
11:40am		
12:00pm		

Author Index

Bold page numbers indicate presenter

— A —

Abadizaman, F.: EL+AS+EM-MoM4, 82;
EL+EM-MoA4, **90**; EL-TuP4, 118
Abbas, A.: TF-MoA5, 95
Abbasi, K.: AS+NS-ThA11, **153**
Abdo, B.: MP+EM+MN+NS-MoM5, **84**
Abdulagatov, A.I.: PS-TuP3, **119**
Abdulislam, A.: SS+EM+PS+TF-ThA3, 159
Abe, Y.: TF-ThP2, 163; TF-ThP7, 163
Abelson, A.: EM+2D+AN+MI+MP+NS-TuA12,
110
Abelson, J.R.: TF1-MoM5, 87
Abergel, R.J.: AC+MI+SA-FrM3, 167; AC-ThA1,
152; BI+AC+AS+HC+NS+SS+TF-WeA10, **136**
Abraha, P.: PS-TuP29, 119; PS-TuP30, 119;
SE+PS-TuM1, **104**
Abraham, B.: SS+AS+EM-WeA8, 141
Abraham, M.: EM+AM+NS+PS-MoA8, 91
Abrahami, S.T.: SE+NS+TF-MoM1, **86**
Abudayyeh, O.K.: EM-ThP9, 161; SE-TuA3,
114
Acharya, S.R.: TF+AS+EL+PS-ThM4, **151**
Acosta, A.: EM-ThP10, 161; TF+EM+MI+PS-
MoA2, **95**
Adam, G.: MN+NS+PS-WeM13, **127**; RM-
TuP2, 120
Adams, D.P.: VT-TuM12, 106
Adamsen, K.C.: SS+HC+MI-MoM4, **86**
Adderley, P.A.: VT-MoM11, 88
Addou, R.: EM-ThP14, 161
Adeli, M.: 2D+MN+NS+SS-WeA7, 134
Adell, J.: 2D+EM+MN+NS-FrM5, 167
Adhikari, E.R.: PS+PB-TuM2, **103**
Adiga, V.P.: MP+AM+EM+NS-MoA10, 92;
MP+AM+EM+NS-MoA5, 92
Adjeroud, N.: PC+AS+BI+EM+PB+SS-WeM10,
128
Afshar, A.: SE-TuA4, **114**; TF-ThP12, 163
Agarwal, A.: PS+TF-MoM6, 85
Agarwal, S.: MS+MI+RM-TuM1, 101; RM-
TuP3, 120
Agnew, L.: SE-TuP7, 120
Agrawal, A.: NS+AN+EM+MN+MP+RM-TuM3,
102
Ahles, C.F.: EM+AM+NS+PS-MoA2, **91**
Ah-Leung, V.: PS+EM-WeM10, 129
Ahmadi, M.: HI+AS-ThM4, 147
Ahmed, M.: PC+AS+BI+NS+PB+SS-TuM12,
102
Ahmed, Z.: VT-MoA1, 96; VT-MoA3, 96
Ahn, C.: AS-MoA6, 89; PS+EM+NS+SS-TuA10,
113; PS+TF-MoM1, 85
Ahn, J.-H.: 2D-ThP3, 160; NS-ThP21, 162; TF-
ThP13, 163
Ahn, S.J.: HI-ThA4, 155
Ahn, Y.: NS-ThP20, 162
Ahyi, A.: EM-ThP18, 161
Aifer, E.: 2D+MN+NS+SS-WeA11, 134
Aimez, V.: PS+EM+SE-TuM2, 103
Ajayan, P.M.: 2D+EM+MI+NS-TuM1, 99
Akaishi, A.: SS+HC-WeM13, 130
Akbar, N.: TF+EM+MI-WeA12, 141
Akçakaya, M.: BI-TuP11, 118
Akey, A.J.: AS+NS-ThA3, **153**
Aksoy, M.: AS+BI-TuM12, 99
Aksyuk, V.A.: NS+2D+AN+MN+MP+SE-WeM2,
128
Alam, M.: TF+EM+MI-WeA12, 141
Alam, M.K.: VT-TuM12, 106
Alatalo, M.: SS+HC-MoA3, 94
Albertin, S.: HC+SS-ThA7, 154; HC+SS-ThM4,
146; HC+SS-WeM11, 126

Albrecht, T.: EM+MP+PS-MoM11, **82**;
NS+2D+AS+PC-MoA9, 93
Albrecht-Schmitt, T.E.: AC-ThA3, 152
Alcantar, N.: BI-TuP3, 118
Aleksandrov, A.B.: SS+HC+MI-TuA10, 115
Aleman, A.: SE+NS+TF-MoM3, 86; SE-MoA3,
94
Alessio Verni, G.: TF+EM+MI-WeM12, 131
Alexander, A.: MP+EM+NS-TuM1, 101
Alexander, M.R.: AS+NS-ThA10, 153
Alexandrova, A.: HC+SS-TuM4, 100
Alfonso Garcia, A.: IPF+AS+BI+MN-TuM3, **100**
Alhalaili, B.H.: TF+EM+MI-WeA9, **141**
Ali, A.: TF+EM+MI-WeA12, **141**
Ali, A.M.: AS+NS+SA-WeM6, 125
Ali, W.: HI-ThP1, **161**
Alia, S.M.: AS-ThP4, 160
Alias, M.S.: AS-ThP3, 160
Aliman, M.: TF+AS+EL+PS-ThM12, 151
Al-Jassim, M.: AS-MoA1, 89
Allain, J.P.: BI-WeA10, 136
Allain, P.: MN+NS+PS-WeM10, 127
Allen, F.I.: HI-WeA1, **138**
Allerman, A.A.: EM+2D+SS-WeA11, 137; EM-
ThP11, 161; EM-ThP13, 161
Alles, M.L.: MN+2D+AN+NS-ThA3, 156
Allison, W.: HI-ThA3, 155
Allred, D.D.: EL+AS+EM-MoM10, 82;
TF+AS+EL+PS-ThM5, 151; TF+PS-ThM4, 151;
TF-ThP24, 163
Almeida, K.: 2D+EM+MI+NS+TF-MoM2, **81**
Almualem, Z.: HC+SS-TuM10, 100
Alsem, D.H.: MM+AS+NS+PC+SS-MoA8, **92**
Alsharif, N.: BI+AS+IPF+NS-TuA10, **110**;
NS+2D+AN+MN+MP+SE-WeM12, 128
Altieri, N.D.: PS+EM-WeA12, 140
Altman, A.: AC+AS-SA-ThM10, 144
Altman, E.I.: 2D+EM+MI+MN+NS+SS-ThM2,
144; AS-MoA6, 89; NS+2D+AS+PC-MoA8,
93; SS+HC-WeM12, 130
Alvarez Barragan, A.:
NS+2D+AN+EM+MN+MP+PC+RM-MoM6,
84
Alvarez Jr., D.: TF1-MoM9, 87
Alvarez, D.: EM+AM+NS+PS-MoA10, 91; TF1-
MoM4, **87**
Alvarez, H.S.: PS-TuP18, **119**
Alvaro, E.: TF-ThP33, **163**
Aly, M.M.S.: MS+MI+RM-TuM10, 101
Amani, J.A.: AM+NS+SS-WeM12, 125
Amati, M.: MM+AS+NS+PC+SS-MoA1, 92
Ambat, R.: SE+NS+TF-MoM1, 86
Ambrogio, S.: MS+MI+RM-TuM5, 101
Andachi, K.: TF1-MoM4, 87
Anders, A.: SE+PS-TuM12, **104**; SE+PS-TuM6,
104
Anderson, B.: 2D+EM+MI+NS-TuM3, 99
Anderson, D.Z.: VT-TuA7, 116
Anderson, S.: HC+SS-TuM4, 100
Anderson, T.J.: EM+2D+SS-WeA12, 137
Anderson, V.R.: PS+EM+TF-ThA8, 157; PS+TF-
MoM11, 85
Anderton, C.R.: AS-MoA10, 89
Andreev, A.V.: AC-ThP5, 160
Anfuso, C.D.: BI-ThM5, 145
Angelici Avincola, V.: SS+AS+HC-FrM3, 170
Angerer, T.B.: AS-MoA10, **89**; BI+AS+NS-
FrM4, 168
Anjum, D.H.: AS-ThP3, 160
Anselmetti, D.: 2D+EM+MI+MN+NS+SS-
ThM11, 144
Ansermet, J.-P.: SS-TuP4, 120
Antoni, M.: TF+AS+EL+PS-ThM12, 151

Aouadi, S.M.: SE-MoA10, 94
Appelhans, D.: BI-ThA11, 153
Arai, K.: VT-TuP7, 121; VT-TuP8, **121**
Argoud, M.A.: PS+EM-WeM3, 129
Argyropoulos, C.: EL+AS+EM-MoM3, 82
Arias, P.: SE+NS+TF-MoM3, 86;
SS+EM+PS+TF-ThA3, **159**
Aristov, V.Y.: 2D+EM+MI+NS-TuM4, **99**
Ark, F.J.: AS+SE-ThM13, 145; BI+AS+IPF+MN-
MoA10, 90
Arl, D.: PC+AS+BI+EM+PB+SS-WeM10, **128**;
PS+PB-MoA5, 93
Arlinghaus, H.: AS+NS-ThA6, 153; AS+SE-
WeA1, 135
Armenise, V.: PS+PB-MoA9, 93
Armes, S.P.: BI-ThM4, 145
Armini, S.: PS-TuP22, 119; SE+PS-TuM3, **104**;
TF+AM+EM+PS-TuM12, 105
Armstrong, A.M.: EM+2D+SS-WeA11, 137;
EM-ThP11, 161; EM-ThP13, 161
Arnadottir, L.: BI+AC+AS+HC+NS+SS+TF-
WeA11, **136**
Árnadóttir, L.: SS+AS+EM-WeA10, 141
Arnau, A.: NS+AM+AS+MN+PC+PS+SS+TR-
FrM4, 169
Arnold, C.: 2D+EM+MI+MN+NS-TuA8, 109
Arora, P.: PS-ThA6, **157**; PS-ThM6, 149
Arts, K.: PS+TF-MoM2, 85; TF-TuM5, 106
Artyushkova, K.: AS+NS+SA-WeM12, 125;
AS+NS+SA-WeM6, 125; AS+SE-WeA11, **135**
Arutt, C.N.: MN+2D+AN+NS-ThA3, 156
Aryal, B.: NS+AN+EM+MI+MN+MP+PS+RM-
ThM5, 148
Asakukra, K.: AS+NS-ThA9, 153
Asselberghs, I.: 2D+AM+EM+NS-WeM10,
124; EM+MP+PS-MoM3, **82**
Assender, H.E.: TF+AS+EL+EM+NS+PS+SS-
ThA11, 159; TF+AS+EL+EM+NS+PS+SS-ThA7,
159
Asthagiri, A.: HC+SS-WeA1, 137; HC+SS-
WeM10, 126
Atanassov, P.: AS+NS+SA-WeM12, 125;
AS+SE-WeA11, 135
Atiganyanun, S.: EM+MI+MN+NS-ThM4, 146;
EM-ThP9, **161**
Attenkofer, K.: SA+AS+HC+SS-ThA1, **158**
Audi, M.: VT-MoA5, **96**
Audinot, J.-N.: HI+AS-ThM3, 147
Avidaj, S.: VT-MoA6, **96**
Avery, E.: NS+AM+MI+MN+SS+TR-TuA11, 112
Avila, J.: TF-TuM4, **106**
Avishai, A.A.: AS+NS-ThA11, 153
Avval, T.G.: HI+AS-ThM11, **147**
Aydil, E.S.: TF-MoA8, **95**
Aydogan Gokturk, P.: AS+NS+SA-WeM11, **125**
Aydogmus, H.: MN+2D+AN+NS-WeA3, 138
— B —
Babaei Gavan, K.: PS+EM-WeA9, 140
Baber, A.: BI+AC+AS+HC+NS+SS+TF-WeA7,
136
Baca, A.G.: EM+2D+SS-WeA11, 137; EM-
ThP11, 161; EM-ThP13, 161
Baca, E.: MN+NS+PS-WeM4, 127;
MN+NS+PS-WeM5, **127**; MN+NS+PS-
WeM6, 127
Bachmann, J.: SS+AS+EM-WeA9, 141
Backer, M.: TF+AS-TuM5, 105
Baczewski, A.: AM+MP+NS-WeA3, 135
Baddorf, A.P.: MS-TuB2, **107**
Bae, J.H.: EM+2D+SS-WeA4, **137**; EM-ThP5,
161
Bae, J.-S.: HC-ThP1, 161
Bae, J.Y.: TF-ThP15, 163

Author Index

Baek, I.-H.: TF-TuM3, 106
 Baer, D.R.: AS-MoM3, **81**
 Baeumer, C.: SA+AS+HC+SS-ThA7, 158
 Bagge-Hansen, M.: SA+AS+HC+SS-ThA11, 158; SA-ThP2, 162
 Bagus, P.S.: AC+MI+SA-FrM6, **167**; AS-MoM8, 81
 Bai, S.: SS+AS+EM-WeA8, 141
 Baik, S.J.: PS+PB+SE-TuA2, **113**
 Bailey, A.P.: AS+BI-TuM5, 99
 Bailey, C.: 2D+EM+MI+NS-TuM12, 99
 Baio, J.E.: BI+AS+IPF+MN-MoA3, **90**
 Baker, B.: AS-ThP10, **160**
 Baker, J.G.: TF-TuM11, **106**
 Baker, J.N.: TF+AS+EL+PS-ThM1, 151
 Bal, M.: MP+AM+EM+NS-MoA6, 92; MP+EM+NS-TuM3, 101; MP+EM+NS-TuM12, 101; MP+EM+NS-TuM6, 101
 Balakrishna, A.: TF+AS-TuM3, 105
 Balasubramanian, T.B.: 2D+EM+MN+NS-FrM5, 167
 Balder, E.: TF2-MoM4, 87
 Baldwin, A.: AC+AS+SA-ThM5, 144
 Balke, N.: 2D+EM+MN+NS-ThA6, 152
 Ballard, A.: MP+EM+NS-TuM5, 101
 Ballesteros, C.: AS+NS-ThA7, 153
 Balmes, O.: HC+SS-ThA2, 154
 Balogh-Michels, Z.: MI+2D-ThM13, 147
 Bamiedakis, N.A.: EM-ThP1, 160
 Banerjee, P.: EM+AN+MI+SS-WeM1, **126**
 Baneton, J.: PS+EM+NS+SS-TuA7, **113**; PS+TF-MoM9, 85
 Bangert, U.: AM+NS+SS-WeM12, 125
 Banks, H.B.: EM+2D+AN+MI+MP+NS-TuA10, 110; EM+2D+AN+MI+MP+NS-TuA11, 110; EM+2D+AN+MI+MP+NS-TuA9, 110
 Bannister, J.: PS+EM+TF-ThA10, 157
 Banquy, X.: BI-ThA1, **153**
 Bao, D.L.: NS-ThP13, 162
 Bao, L.H.: NS-ThP13, 162
 Bao, Z.: AC+MI+SA-WeM3, 124
 Barimah, E.K.: EM-ThP1, **160**
 Barker, D.S.: NS+AN+EM+MN+MP+RM-TuM12, 102
 Barla, K.: TF+AM+EM+PS-TuM10, 105
 Barlaz, D.: SS+EM+PS+TF-ThA9, 159
 Barlaz, E.: PS+EM+NS+SS-TuA10, 113; PS+PB-TuM3, **103**; PS-TuP19, 119
 Barlow, A.J.: AS+NS-ThA1, 153
 Barnaby, H.J.: MS+MI+RM-TuM1, 101
 Barnat, E.V.: AS+NS+SA-WeM13, 125
 Barnes, J.-P.: AS+BI-TuM13, 99; AS+NS-ThA2, **153**; PS+EM+TF-ThM13, 149; PS+EM-WeM6, 129
 Barnola, S.: PS+EM+SE-TuM1, 103; PS+EM+SE-TuM12, 103; PS+EM-WeM10, 129; PS+EM-WeM3, 129
 Barona, M.D.: TF-ThP24, 163
 Barquest, B.: VT-WeM6, 131
 Barra, A.: MI+2D-ThM12, 147
 Barraza-Valdez, E.: VT-TuP11, **121**
 Barroso, D.: 2D+EM+MI+MN+NS-TuA11, 109
 Barry, S.: TF1-MoM3, 87
 Bartels, L.: 2D+AM+EM+NS-WeM2, 124; 2D+EM+MI+MN+NS+SS-ThM5, 144; 2D+EM+MI+MN+NS-TuA11, 109; 2D+EM+MI+NS+TF-MoM2, 81; 2D+EM+MI+NS+TF-MoM6, 81; 2D+EM+MI+NS-TuM11, 99; HC-ThP4, 161
 Barth, K.L.: TF-MoA5, 95
 Bartha, A.: AC+MI+SA-WeM12, **124**
 Bartl, J.D.: BI+AS+IPF+NS-TuA3, **110**
 Bartlett, B.M.: TF-TuM12, 106
 Bartolo Perez, C.: TF+EM+MI-WeA10, 141
 Bartosik, M.: SE+NS+TF-MoM6, 86
 Bartynski, R.A.: SS+EM+PS+TF-ThA7, 159
 Basaran, A.: MI+2D+EM+NS-MoA5, 91
 Baše, T.: NS+AM+MI+MN+SS+TR-TuA11, 112
 Basher, A.H.: PS+EM+TF-ThA1, **157**
 Bassani, F.: AS+BI-TuM13, 99
 Basu, R.: TF+AS+EL+PS-ThM6, **151**
 Bateman, N.: EL+EM-MoA9, **90**
 Batista, E.: AC+AS+SA-WeA7, 134; AC+MI+SA-FrM10, 167; AC-ThA1, 152; AC-ThA3, 152
 Batista, E.R.: AC+AS+SA-WeA1, 134
 Batlle, X.: MI+2D+EM+NS-MoA5, 91
 Batra, A.K.: MN-ThP5, 162
 Batra, V.: MN-ThP6, **162**
 Batzill, M.: 2D+AM+EM+NS-WeM6, 124
 Bauer, S.: BI-WeA9, 136
 Baumann, T.F.: SA-ThP2, 162
 Baxter, E.: HC+SS-TuM4, 100
 Bayindir, Z.: AS+SE-WeA12, 135
 Baykara, M.Z.: TR+AS+NS+SS-MoM1, **88**
 Bayley, C.: RM-TuP3, 120
 Bechu, S.: AS+SE-ThM3, 145
 Bednar, R.M.: BI+AS+IPF+NS-TuA9, **110**
 Beebe, M.: EM+2D+NS+PS+RM+TF-ThA3, 154
 Beebe, T.P.: NS+AM+AS+MN+PC+PS+SS+TR-FrM3, 169
 Beers, W.: MS-TuP5, 118
 Behrens, S.H.: EM+MI+MN+NS-ThM3, 146
 belahcen, S.: TF+AM+EM+PS-TuM3, 105
 Belianinov, A.: HI+AS-ThM1, **147**; HI+AS-ThM4, 147; MM+AS+NS+PC-MoM8, 83
 Bell, D.C.: AS+NS-ThA3, 153
 Bell, L.D.: EM+2D+SS-WeA10, **137**
 Belling, J.: NS-ThP15, 162
 Belu, A.: PC+AS+BI+EM+NS+PB+SS-TuA3, 112
 Bencivenga, F.: SA+MI-ThM5, 150
 Bendikov, T.: AS+SE-ThM4, **145**
 Benjamin, D.I.: PS+PB-TuM10, 103; PS+PB-TuM12, 103
 Benjamin, E.: NS+2D+AN+MN+MP+SE-WeM6, 128
 Benndorf, C.: SS-TuP11, 120
 Bennett, J.: AS-MoM10, 81
 Bennett-Kennett, R.B.: SS-TuP9, 120
 Bent, S.F.: SS+AS+EM-WeA1, **141**; TF+PS-TuA10, 115; TF+PS-TuA3, 115; TF+SS-TuA9, 116; TF1-MoM2, 87; TF-TuM11, 106
 Bera, K.: PS-FrM1, 169; PS-FrM11, **169**; PS-FrM8, 169; PS-FrM9, 169
 Berg, M.: EM+2D+AN+MI+MP+NS-TuA3, 110; MN+NS+PS-WeM12, 127
 Berg, Y.: NS+AN+EM+MI+MN+MP+PS+RM-ThM1, 148
 Bergevin, J.: TF+AS+EL+EM+NS+PS+SS-ThA8, 159
 Bergin, M.: HI-ThA3, 155
 Bergsman, D.S.: TF+PS-TuA10, **115**; TF+SS-TuA9, 116
 Berman, D.: TR+AS+NS+SS-MoM10, **88**
 Bernholc, J.: NS+AM+MI+MN+SS+TR-TuA9, 112
 Berry, I.L.: PS+EM+TF-ThA4, 157
 Bertão, G.L.: PS-TuP18, 119
 Bertram, M.E.: AS+SE-ThM13, 145
 Berwanger, J.: 2D-ThP6, 160
 Beyer, A.: 2D+EM+MI+MN+NS+SS-ThM11, 144; HI+AS-ThM10, **147**
 Bhakta, A.: PS-ThM11, 149
 Bhargava, R.: IPF+AS+BI+MN-TuM1, **100**
 Bhattarai, A.: NS+MN+PC+SS-WeA11, 139
 Bhattarai, G.: PS+EM-WeA11, **140**; PS+EM-WeA2, 140
 Bhatti, A.S.: TF+EM+MI-WeA12, 141
 Biacchi, A.: EM+2D+NS+PS+RM+TF-ThA4, 154
 Bielefeld, J.D.: SE-TuP3, 120
 Bielejec, E.S.: EM+2D+AN+MI+MP+NS-TuA10, 110; MS+MI+RM-TuM1, 101
 Bielinski, A.R.: TF-TuM12, 106
 Biere, N.: 2D+EM+MI+MN+NS+SS-ThM11, 144
 Billard, A.: SE-TuA9, 114
 Biolsi, P.: PS+EM+SE-TuM5, 103; PS-TuP1, 119
 Bischoff, L.: HI-ThA8, 155
 Bisio, F.: EL+AS+EM-MoM6, 82
 Bissell, L.: EM+AN+MI+SS-WeM12, 126
 Bitou, Y.: VT-TuP7, 121
 Bittle, E.G.: SS+AS+BI+MI+NS-ThA8, 158
 Bittrich, E.: BI-ThA11, **153**
 Biyikli, N.: PS+EM+NS+SS-TuA1, **113**
 Björk, J.: SS+EM+PS+TF-ThA11, 159
 Black, F.: IPF+AS+BI+NS-WeM5, **127**
 Blackburn, J.L.: 2D-ThP5, 160
 Blades, W.H.: SS+EM+PS+TF-ThA8, **159**
 Blaisdell-Pijuan, P.: NS+2D+AN+EM+MN+MP+PC+RM-MoM8, 84
 Blakeney, J.: PS-ThM2, 149
 Blanc, R.: PS-FrM7, 169
 Blanchard, P.: TF+AM+EM+PS-TuM4, 105
 Blankenship, S.R.: 2D-ThP6, 160
 Blanton, E.W.: EM-ThP3, 161
 Blatz, J.: PS+PB-TuM10, 103; PS+PB-TuM12, **103**; PS-TuP22, 119
 Blomberg, S.: HC+SS-ThA7, 154; HC+SS-WeM11, 126; HC+SS-WeM5, **126**
 Blomfield, C.J.: AS+NS-ThA10, 153; AS-MoM9, 81
 Bluhm, H.: TF+SS-TuA1, 116
 Blumenschein, F.: SS-TuP4, 120
 Boblil, E.: AC+AS+SA-ThM3, 144
 Bogart, J.A.: AC+AS+SA-WeA1, 134
 Bohara, B.: MN-ThP5, **162**; TF-ThP25, 163
 Boixaderas, C.: PS+EM+SE-TuM12, 103
 Bol, A.A.: SS+EM+NS-ThM12, 150
 Boland, T.: IPF+AS+BI+NS-MoM5, **83**
 Bone, S.E.: AC+AS+SA-WeA7, 134
 Bonifacio, C.S.: SS+HC-WeM3, 130
 Bonn, M.: BI+AS+IPF+MN-MoA5, 90
 Bonova, L.: PS+PB+SE-TuA9, **113**; PS+TF-MoM1, 85
 Bonvalot, M.: TF+AM+EM+PS-TuM3, **105**; TF+AM+EM+PS-TuM5, 105
 Booth, C.: AC+AS+SA-WeA1, 134
 Booth, C.H.: AC+MI+SA-FrM8, 167; AC+MI+SA-WeM1, **124**; AC-ThA1, 152; BI+AC+AS+HC+NS+SS+TF-WeA10, 136
 Booth, J.-P.: PS-ThA9, 157
 Borca, B.: NS+AM+AS+MN+PC+PS+SS+TR-FrM4, 169
 Borchers, J.A.: MI+2D-ThM12, 147
 Boreman, G.D.: EL+AS+EM-MoM11, 82; NS-ThP8, 162
 Boris, D.R.: PS+EM+TF-ThM1, **149**; PS+PB+SE-TuA1, 113; PS+PB+SE-TuA7, 113; PS+TF-MoM11, 85; PS+TF-MoM6, 85; PS-TuP16, 119; TF+EM+MI-WeM4, 131; TF-ThP22, **163**; TF-ThP38, 163; TF-TuM4, 106
 Borovsky, B.P.: TR-TuP1, **120**
 Boscher, N.D.: PS+PB-MoA3, 93
 Boscoboinik, J.A.: SS+HC-WeM12, 130
 Bose, R.: EM+AN+MI+SS-WeM10, **126**
 Botman, A.: HI-ThA6, 155
 Bottari, G.: SS+EM+PS+TF-ThA11, 159
 Bouchiat, V.: 2D+MN+NS+SS-WeA2, 134
 Bougerol, C.: AS+NS-ThA2, 153
 Boyle, D.T.: BI+AC+AS+HC+NS+SS+TF-WeA7, 136
 Bozack, M.J.: EM-ThP18, 161

Author Index

Bracker, A.S.: EM+2D+AN+MI+MP+NS-TuA10, 110
 Brancho, J.J.: TF-TuM12, 106
 Brand, O.: MN+2D+AN+NS-WeA9, 138
 Brandon, J.: PS-ThM5, 149
 Brandt, A.J.: HC-ThP3, 161
 Branecky, M.: TF+SS-TuA7, 116
 Braueniger-Weimer, P.: 2D+MI+NS-MoA10, 89
 Braun, T.: SA-ThP2, 162
 Breckenridge, M.H.: TF+AS+EL+PS-ThM1, 151
 Breedon, M.: EM+AM+NS+PS-MoA10, 91
 Breedveld, V.: EM+MI+MN+NS-ThM3, 146
 Brehm, J.: 2D+EM+MN+NS-ThA6, 152
 Brennan, B.: AS-MoA8, 89
 Brenner, D.: AS-TuA4, 109
 Breuer, L.: AS-TuA10, 109
 Brim, J.: PS-TuP26, 119
 Brimhall, A.: SS-TuP9, 120
 Brink, M.: MP+AM+EM+NS-MoA10, 92; MP+EM+MN+NS-MoM5, 84
 Bristow, A.: SA+MI-ThM2, 150
 Broderick, A.: PC+AS+BI+NS+PB+SS-TuM10, 102; SS+AS+HC-FrM4, 170
 Brohan, L.: AS+SE-ThM3, 145
 Brongersma, H.H.: HI+AS-ThM11, 147; SS+HC+MI-TuA8, 115
 Bronn, N.T.: MP+AM+EM+NS-MoA10, 92; MP+AM+EM+NS-MoA5, 92; MP+EM+MN+NS-MoM5, 84
 Broqvist, P.: HC+SS-ThM12, 146
 Brown, K.A.: BI+AC+AS+HC+NS+SS+TF-WeA3, 136; BI+AS+IPF+NS-TuA10, 110; NS+2D+AN+MN+MP+SE-WeM12, 128
 Brown, R.D.: PC+AS+BI+EM+NS+PB+SS-TuA12, 112; SS+HC+MI-MoM5, 86
 Brown, S.: SS+AS+BI+MI+NS-ThA2, 158
 Brown-Heft, T.L.: 2D+EM+MN+NS-FrM6, 167
 Bruce, J.P.: AC-ThP3, 160; HC+SS-TuA1, 111; MM+AS+NS+PC+SS-MoA3, 92
 Bruce, R.L.: PS+EM+TF-ThM12, 149
 Brucker, G.: VT-MoM3, 88
 Bruggeman, P.J.: PS+AS+EL+EM+SE-WeM12, 129
 Brumbach, M.T.: AS+NS+SA-WeM13, 125
 Brummel, O.: SS+AS+EM-WeA9, 141
 Brundle, C.R.: AS-MoM8, 81
 Bsiesy, A.: TF+AM+EM+PS-TuM3, 105; TF+AM+EM+PS-TuM5, 105
 Bu, C.: AS+NS+SA-WeM1, 125; AS+NS+SA-WeM5, 125
 Buck, E.C.: AC+AS+SA-ThM1, 144
 Budak, S.: TF-ThP25, 163; TF-ThP26, 163
 Buks, E.B.: MN+2D+AN+MP+NS-ThM12, 148; MP+EM+MN+NS-MoM6, 84
 Bunch, J.: IPF+AS+BI+MN-TuM10, 100
 Bunk, R.J.: TF+EM+MI-WeA9, 141
 Burke, D.C.: VT-TuM4, 106
 Burke, R.A.: 2D+EM+MI+MN+NS+SS-ThM5, 144
 Burnham, N.A.: NS+2D+AS+PC-MoA3, 93
 Burr, G.W.: MS+MI+RM-TuM5, 101
 Burriel, M.B.: SA+AS+MI-WeA9, 140
 Burzynski, K.M.: EM-ThP3, 161, EM+2D+NS+PS+RM+TF-ThA3, 154
 Busby, Y.: PS+EM+NS+SS-TuA7, 113
 Butch, N.P.: AC-ThA8, 152
 Butts, M.: MS-TuP5, 118
 Bux, S.: PS-FrM10, 169
 — C —
 Cabrera, A.: PC+AS+BI+EM+NS+PB+SS-TuP1, 119
 Cabrera, G.B.: AC+MI+SA-WeM13, 124; SA+MI-ThM2, 150
 Cabrera, Y.: TF+SS-TuA8, 116
 Cabrera-Codony, A.: HC-ThP7, 161
 Cabrera-German, D.: AS-ThP5, 160; AS-ThP9, 160
 Caciuffo, R.: AC+MI+SA-WeM3, 124
 Cady, N.: MS+MI+RM-TuM3, 101
 Cagomoc, C.M.: PS+AS+EM+SS-MoM1, 85
 Cahen, D.: NS+2D+AS+MN+PC-ThA3, 156
 Caldarella, G.: PS+EM+NS+SS-TuA7, 113
 Calegari, E.J.: AC+MI+SA-WeM5, 124
 Calhoun, T.R.: HI+AS-ThM4, 147
 Calzolai, L.: BI-ThM3, 145
 Camden, J.P.: MM+AS+NS+PC-MoM5, 83; TF+EM+MI-WeA11, 141
 Campbell, C.T.: HC+SS-ThA3, 154; HC+SS-TuM10, 100; HC+SS-TuM6, 100
 Campbell, D.: AM+MP+NS-WeA3, 135
 Campo, A.: PS+EM+SE-TuM1, 103
 Canavan, H.E.: BI-ThA8, 153; BI-TuP8, 118
 Candler, R.: MN+2D+AN+NS-WeA7, 138
 Canepa, M.: EL+AS+EM-MoM6, 82
 Cano, A.M.: TF+PS-TuA11, 115
 Cansizoglu, H.: TF+EM+MI-WeA10, 141; TF+EM+MI-WeA9, 141
 Cansizoglu, M.F.: TF+EM+MI-WeA10, 141
 Canvel, Y.: PS+EM+SE-TuM12, 103
 Cao, C.H.: 2D+EM+MI+NS-TuM1, 99
 Cao, H.J.: AC-ThP4, 160
 Cao, K.: SS-TuP5, 120
 Cao, Y.: IPF+AS+BI+NS-WeM3, 127
 Capomaccio, R.: BI-ThM3, 145
 Capotondi, F.: SA+MI-ThM5, 150
 Capuano, C.: AS+SE-WeA11, 135
 Cardos, K.L.: EM-ThP8, 161
 Carey, P.: EM-ThP11, 161
 Carlin, J.: EL-TuP3, 118
 Carlsson, P.A.: HC+SS-ThA2, 154
 Carman, G.P.: MI+2D-ThM12, 147
 Carolan, D.: PS+EM+NS+SS-TuA4, 113
 Carr, D.M.: AS+SE-ThM11, 145
 Carraro, C.: 2D+EM+MI+NS+TF-MoM10, 81
 Carraro, G.: SS+EM+NS-ThM3, 150
 Carrasco, E.: SS+HC-WeM6, 130
 Carrasco, R.: EL+AS+EM-MoM4, 82; EL-TuP3, 118; EL-TuP4, 118
 Carroll, N.J.: BI-TuP13, 118
 Carroll, P.J.: AC+AS+SA-WeA1, 134
 Carter, S.G.: EM+2D+AN+MI+MP+NS-TuA10, 110; EM+2D+AN+MI+MP+NS-TuA11, 110; EM+2D+AN+MI+MP+NS-TuA9, 110
 Cartron, M.L.: BI-ThM4, 145
 Caruso, A.N.: PS+EM-WeA11, 140; SE-TuP3, 120
 Caruso, V.C.L.: BI-ThM11, 145
 Carver, A.G.: TF+EM+MI-WeA3, 141
 Cary, J.R.: PS-FrM12, 169
 Cary, S.K.: AC+AS+SA-WeA7, 134; AC-ThA3, 152
 Casalnuovo, D.A.: AS+NS+SA-WeM13, 125
 Cass, A.: HC+SS-TuM4, 100
 Castner, D.G.: BI+AC+AS+HC+NS+SS+TF-WeA1, 136; BI+AS+IPF+MN-MoA4, 90
 Castro, G.R.: SA+AS+HC+SS-ThA10, 158
 Cattani-Scholz, A.: BI+AS+IPF+NS-TuA3, 110
 Cauchies, S.: PS+EM+NS+SS-TuA7, 113
 Caulton, K.G.: SS+EM+PS+TF-ThA4, 159
 Cavanagh, A.S.: TF+AM+EM+PS-TuM4, 105; TF+PS-TuA4, 115; TF+PS-TuA9, 115; TF-TuM2, 106
 Cavezza, F.: SS+AS+EM-WeA7, 141
 Ceccone, G.: BI-ThM3, 145
 Cech, V.: TF+SS-TuA7, 116
 Celasco, E.: SS+EM+NS-ThM3, 150
 Centeno, A.: AS-MoA8, 89
 Cermak, P.: AC+MI+SA-WeM12, 124
 Cerrato, J.M.: AS+NS+SA-WeM6, 125; AS-MoA3, 89
 Chabal, Y.J.: EM+AN+MI+SS-WeM10, 126; TF+SS-TuA8, 116
 Chae, J.: 2D+EM+MN+NS-ThA10, 152
 Chae, S.D.: PS-TuP1, 119
 Chaffin, K.: MS+MN-TuA9, 111
 Chagarov, E.: EM+MP+PS-MoM6, 82
 Chaika, N.: 2D+EM+MI+NS-TuM4, 99
 Chainani, A.: SA+AS+HC+SS-ThA10, 158
 Chaker, A.: TF+AM+EM+PS-TuM5, 105
 Chalupa, Z.: PS+EM-WeM3, 129
 Chambers, J.: TF+EM+MI-WeM13, 131
 Champlay, K.: SA+AS+HC+SS-ThA11, 158
 Chan, C.: EM+2D+AN+MI+MP+NS-TuA3, 110
 Chan, L.: NS+AN+EM+MI+MN+MP+PS+RM-ThM13, 148; PS+MN-WeM3, 130
 Chan, L.L.: 2D+EM+MI+NS+TF-MoM10, 81
 Chance, S.: NS-ThP6, 162
 Chandrashekhar, M.: EM+2D+SS-WeA3, 137
 Chang, H.: NS+2D+AS+PC-MoA4, 93
 Chang, J.: EM-ThP10, 161; TF+EM+MI+PS-MoA2, 95
 Chang, J.P.: EM-ThP10, 161; MI+2D-ThM12, 147; PS+EM-WeA12, 140; TF+EM+MI+PS-MoA2, 95; TF2-MoM3, 87
 Chang, L.: TF-ThP32, 163
 Chang, M.H.: NS+AM+MI+MN+SS+TR-TuA10, 112
 Chang, T.: TF-ThP29, 163
 Chang, W.S.: TF+PS-TuA12, 115
 Chang, Y.H.: NS+AM+MI+MN+SS+TR-TuA10, 112
 Chanson, R.: PS+EM-WeA9, 140
 Chao, W.: SA+AS+HC+SS-ThA3, 158
 Chapleski, R.: HC+SS-ThA10, 154; SS+HC-MoA8, 94
 Chattopadhyay, S.: EL+EM-MoA5, 90
 Chaudhuri, S.: PS+PB+SE-TuA9, 113; PS+TF-MoM1, 85
 Chava, V.: EM+2D+SS-WeA3, 137
 Chavez, M.S.: NS-ThP7, 162
 Chavez-Garcia, J.: MP+AM+EM+NS-MoA10, 92
 Cheisson, T.: AC+AS+SA-WeA1, 134
 Chen, B.: TF1-MoM3, 87
 Chen, C.: MN+2D+AN+NS-ThA1, 156
 Chen, C.C.: MN-ThP1, 162; MN-ThP2, 162; PS-TuP25, 119
 Chen, C.-C.: PS-TuP22, 119; PS-TuP23, 119
 Chen, C.-M.: TF+AS+EL+EM+NS+PS+SS-ThA7, 159
 Chen, D.A.: HC-ThP3, 161; SS+HC+MI-TuA7, 115
 Chen, E.: PS+EM-WeA12, 140
 Chen, F.F.: PS-FrM3, 169
 Chen, F.Z.: PS-TuP25, 119
 Chen, G.: TF+PS-ThM11, 151
 Chen, H.L.: MN+2D+AN+NS-ThA3, 156
 Chen, H.-P.: TF-ThP16, 163
 Chen, J.: EM-ThP16, 161; NS+2D+AN+EM+MN+MP+PC+RM-MoM8, 84; NS-ThP11, 162
 Chen, J.K.: SE-MoA5, 94
 Chen, L.: SS+AS+HC-FrM7, 170
 Chen, M.: 2D+EM+MI+NS-TuM12, 99; SE-MoA3, 94
 Chen, P.-S.: 2D-ThP1, 160
 Chen, P.Y.: EM+AM+NS+PS-MoA1, 91
 Chen, Q.: PS+EM+NS+SS-TuA9, 113
 Chen, V.: 2D+EM+MI+NS-TuM12, 99
 Chen, W.-C.: TF-ThP16, 163
 Chen, W.-L.: TF-ThP32, 163

Author Index

Chen, X.: PS+AS+EM+SS-MoM4, 85; PS-TuP2, 119; TF-ThP11, 163

Chen, X.G.: EL+AS+EM-MoM8, 82

Chen, X.Y.: NS-ThP13, 162

Chen, Y.: AS+NS+SA-WeM12, **125**; EM-ThP16, **161**; SS+AS+BI+MI+NS-ThA6, 158

Chen, Y.L.: SA+AS+HC+SS-ThA8, **158**

Chen, Y.-M.: PS-ThA8, **157**; PS-TuP21, 119

Chen, Z.: PS-ThM2, **149**

Cheng Liu, J.: HC+SS-WeM2, 126

Cheng, C.: SS+AS+BI+MI-NS-ThA9, **158**

Cheng, F.: BI+AS+IPF+NS-TuA1, **110**; BI+AS+IPF+NS-TuA8, 110

Cheng, H.: PS-TuP22, 119; PS-TuP23, 119

Cheng, H.-W.: BI-ThA4, 153

Cheng, L.: EM-ThP14, 161; MI+EM-FrM4, 168

Cheol Jin, C.: TF+EM+MI+PS-MoA3, 95

Cheol Seong, H.: TF+EM+MI+PS-MoA3, 95

Cheung, W.S.: VT-TuP5, **121**

Chevalier, N.: AS+BI-TuM13, 99

Chi, D.: 2D+EM+MI+NS+TF-MoM11, **81**; SS+EM+NS-ThM6, 150

Chi, M.: PC+AS+BI+EM+PB+SS-WeM5, **128**

Chiang, N.: NS-ThP15, **162**

Chiappe, D.: 2D+AM+EM+NS-WeM10, 124

Childers, D.: NS-ThP8, 162

Chin, G.: EL+EM-MoA8, **90**

Chini, C.E.: AS+BI-TuM3, 99

Chirita, V.: SE+NS+TF-MoM10, **86**; SE+NS+TF-MoM11, 86

Chitrova, E.: AC+MI+SA-FrM9, 167

Chiu, J.: PS+AS+EM+SS-MoM4, 85; PS-TuP2, 119

Chiu, K.A.: TF-ThP32, 163

Chiu, W.: BP-SuA3, **78**

Chiu, W.T.: PS-TuP28, **119**

Cho, B.: HI-ThA4, 155

Cho, E.Y.: HI-WeA11, 138

Cho, G.: PS+PB-TuM4, 103

Cho, H.S.: TF+EM+MI-WeM6, 131

Cho, M.H.: SS-TuP14, **120**

Cho, N.-J.: NS-ThP15, 162

Cho, T.: PS-TuP5, **119**

Choi, B.J.: RM-TuP1, 120; TF+EM+MI-WeM11, 131

Choi, E.H.: PS+PB-TuM4, 103

Choi, J.H.: 2D-ThP3, 160; TF-ThP13, **163**; TF-ThP37, 163

Choi, J.Y.: EM+AM+NS+PS-MoA2, 91

Choi, K.S.: TF+PS-TuA12, 115

Choi, N.: EM-ThP5, **161**

Choi, S.: EM+AN+MI+SS-WeM3, 126

Choi, S.J.: HI-ThA4, 155

Choi, T.: MS-TuP1, 118; TF-ThP3, **163**

Choubey, B.: TF+AS+EL+EM+NS+PS+SS-ThA7, 159

Choudhury, D.: TF+EM+MI+PS-MoA9, **95**; TF+PS-ThM3, 151

Choudhury, F.A.: PS+PB-TuM10, **103**; PS+PB-TuM12, 103

Choudhury, T.H.: 2D+EM+MI+NS+TF-MoM1, 81; TF+AM+EM+PS-TuM6, 105

Chow, J.M.: MP+AM+EM+NS-MoA10, 92; MP+AM+EM+NS-MoA5, 92; MP+AM+EM+NS-MoA8, 92; MP+EM+MN+NS-MoM5, 84

Chowdhury, S.C.: EM+2D+SS-WeA7, **137**

Christensen, B.G.: MP+EM+NS-TuM5, **101**

Christopher W., B.: TF+EM+MI+PS-MoA3, 95

Chu, G.B.: EL+EM-MoA6, 90

Chu, J.P.: SE-MoA5, **94**

Chu, N.C.: MN-ThP2, 162

Chu, N.N.: MN-ThP1, 162

Chua, T.: PS-FrM8, 169

Chuang, H.-J.: 2D+EM+MN+NS-ThA1, 152; NS-ThP18, **162**

Chuang, P.-Y. A.: 2D+EM+MN+NS-FrM9, 167

Chuang, Y.-D.: AC-ThA8, 152

Chubarov, M.: 2D+EM+MI+NS+TF-MoM1, **81**; TF+AM+EM+PS-TuM6, 105

Chueh, W.C.: MM+AS+NS+PC+SS-MoA8, 92

Chun, D.H.: HC-ThP1, **161**

Chung, C.W.: PS-TuP10, 119; PS-TuP11, 119

Chung, C.W.: MS-TuP2, 118

Chung, H.-Y.: TF+AS+EL+PS-ThM12, 151

Chung, K.: 2D+EM+MI+MN+NS-TuA7, 109

Chung, K.H.: 2D+EM+MN+NS-FrM1, 167

Chung, N.-K.: TF-ThP40, **163**

Chung, T.: VT-TuP12, 121

Chung, T.-M.: TF-TuM3, 106

Ciacotich, N.: SE-MoA9, **94**

Ciarnelli, V.: AS+NS-ThA10, 153

Cieslar, M.: AC+MI+SA-FrM9, 167

Cima, M.J.: BI+AS+IPF+MN-MoA1, **90**

Ciobanu, C.V.: SS+EM+PS+TF-ThA3, 159

Ciodin, F.H.: PS-TuP18, 119

Cirera, B.: SS+EM+PS+TF-ThA11, **159**; SS+HC-WeM6, 130

Ciszek, J.W.: NS-ThP11, 162; TF+AS+EL+EM+NS+PS+SS-ThA3, **159**

Civale, K.: SS+AS+EM-WeA9, 141

Civantos, A.F.: BI-WeA10, 136

Clancey, J.W.: TF+PS-TuA11, 115; TF+PS-TuA4, **115**; TF+PS-TuA9, 115

Clare, A.S.: BI-WeA9, 136

Claridge, S.A.: AS+NS+SA-WeM3, **125**

Clark, R.D.: EM+MP+PS-MoM8, **82**

Clements, H.: HC+SS-TuA2, 111

Cleveland, E.: 2D+MN+NS+SS-WeA11, **134**

Closser, R.G.: TF+PS-TuA10, 115; TF+SS-TuA9, **116**

Coilite, A.M.: PS+PB-MoA6, 93; PS+TF-MoM8, 85; TF+SS-TuA3, **116**

Coelho, P.M.: 2D+AM+EM+NS-WeM6, **124**

Coetsee, E.: TF+AS-TuM3, 105

Coffey, D.: AM+MP+NS-WeA9, **135**

Coffey, K.R.: SS-TuP7, 120

Coffey, M.: EM+AM+NS+PS-MoA1, **91**

Cohen, H.: EM+AN+MI+SS-WeM6, **126**

Cohen, S.R.: NS+2D+AS+MN+PC-ThA3, **156**

Coimbatore Balram, K.: NS+2D+AN+MN+MP+SE-WeM3, **128**

Cole, B.E.: AC+AS+SA-WeA1, 134

Coleman, D.: PS-FrM10, **169**

Coley, W.: HC-ThP4, 161

Colineau, E.: AC+AS+SA-WeA10, 134

Collazo, R.: TF+AS+EL+PS-ThM1, 151

Collette, R.: TF+EM+MI-WeA11, **141**

Collins, K.S.: PS-FrM1, 169; PS-FrM11, 169; PS-ThM1, 149

Collins, L.: HI+AS-ThM4, 147

Colpo, P.: BI-ThM3, 145

Colvin, J.: EM+AN+MI+SS-WeM11, 126

Comi, T.: IPF+AS+BI+MN-TuM1, 100

Conley, Jr., J.F.: TF1-MoM10, 87

Consiglio, S.: EM+MP+PS-MoM8, 82

Cook-Chennault, K.: EM+MI+MN+NS-ThM13, **146**

Cooke, M.J.: PS+EM+TF-ThA6, **157**

Cooley, K.A.: EM+AM+NS+PS-MoA8, 91

Coombes, K.R.: VT-TuM12, 106

Corbey, J.F.: AC+AS+SA-ThM1, 144

Corcelli, S.: PC+AS+BI+EM+NS+PB+SS-TuA12, 112

Corcoles, A.: MP+EM+MN+NS-MoM5, 84

Cordill, M.J.: SE+NS+TF-MoM4, 86

Cormier, C.R.: EM-ThP14, 161

Cornejo, C.E.: AS+SE-ThM13, 145

Corrie, S.: BI+AS+IPF+NS-TuA2, 110; IPF+AS+BI+NS-WeM10, **127**; NS+MN+PC+SS-WeA4, 139

Cortazar-Martinez, O.: AS-ThP5, 160

Cosnahan, T.: TF+AS+EL+EM+NS+PS+SS-ThA11, 159

Costantini, G.: NS+AM+AS+MN+PC+PS+SS+TR-FrM5, **169**; SS+EM+PS+TF-ThA1, **159**

Coultas, S.J.: AS+NS-ThA10, 153; AS-MoM9, **81**

Council-Troche, M.: AC+AS+SA-WeA9, 134

Counsell, J.D.P.: AS+NS-ThA10, **153**; AS-MoM9, 81; EW-TuL4, 108

Coy Diaz, H.: 2D+AM+EM+NS-WeM6, 124

Coyle, J.: TF1-MoM3, 87

Creatore, M.C.: PS+PB-MoA3, 93; PS+TF-MoM2, 85; TF2-MoM1, 87; TF-MoA3, 95; TF-TuM10, 106; TF-TuM13, 106; TF-TuM5, 106

Creus, J.: SE-TuA9, 114

Cristaldo, V.: AS+BI-TuM5, 99

Crommie, M.F.: NS+AM+AS+MN+PC+PS+SS+TR-FrM1, **169**

Cronin, S.B.: EM-ThP17, 161; PS+PB+SE-TuA4, 113

Crooks, R.: SS+HC-WeM3, 130

Crossette, N.P.: PS-FrM12, **169**

Cradden, C.M.: TF+PS-TuA1, **115**

Crumlin, E.J.: HC+SS-ThA2, 154; PC+AS+BI+EM+PB+SS-WeM1, **128**; SS-TuP8, 120

Cucci, L.M.: BI-ThM11, 145; BI-ThM5, 145

Cui, S.: NS+AM+MI+MN+SS+TR-TuA4, **112**

Cui, T.: 2D+EM+MI+NS-TuM1, **99**

Culbertson, R.J.: AS+SE-ThM13, 145; AS-ThP10, 160; BI+AS+IPF+MN-MoA10, 90

Cullen, P.J.: PS+PB+SE-TuA10, 113

Cullen, W.G.: 2D-ThP6, 160

Culp, K.J.: TF-ThP12, 163

Cunge, G.: 2D+MN+NS+SS-WeA2, 134; PS+EM+TF-ThM13, 149; PS+EM-WeM1, 129; PS+EM-WeM6, 129

Curnan, M.T.: HC+SS-ThA11, 154

Currie, R.: MN-ThP5, 162

Custers, J.: AC+MI+SA-WeM12, 124

Cuylear, D.: BI-ThA8, 153; BI-TuP8, 118

Cybart, S.A.: HI-WeA11, **138**

Cyanik, P.: TF+SS-TuA2, 116

Czaplewski, D.A.: MN+2D+AN+NS-ThA1, 156; MN+2D+AN+NS-ThA8, **156**

— D —

Da Cunha, T.: PC+AS+BI+EM+PB+SS-WeM10, 128

Da, H.: EM+2D+AN+MI+MP+NS-TuA4, 110

Dagdeviren, O.E.: AS-MoA6, **89**; NS+2D+AS+PC-MoA8, 93

Dagel, D.: MN+NS+PS-WeM4, 127

d'Agostino, R.: PS+PB-MoA9, 93

Dahal, A.: HC+SS-ThA1, 154; SS+AS+EM-WeA12, 141

Dahiya, V.: EL-TuP3, 118

Dahlke, C.: VT-MoA4, 96

Dahotre, N.B.: SE-MoA10, 94

Dai, R.C.: EL+AS+EM-MoM9, **82**; EM+2D+AN+MI+MP+NS-TuA4, 110; MI+EM-FrM4, 168

Dalke, S.: NS-ThP11, 162

Dameron, A.A.: TF2-MoM8, **87**

D'Angeli, F.: BI-ThM5, 145

Dangerfield, A.D.: EM+AN+MI+SS-WeM10, 126

Dangi, S.: BI-ThM10, **145**

Daniels, K.M.: 2D+EM+MN+NS-FrM6, 167; EM+2D+AN+MI+MP+NS-TuA11, 110

Author Index

Danilovic, N.: AS+SE-WeA11, 135
 Darakchieva, V.: EL+AS+EM-MoM1, **82**;
 EL+EM-MoA1, 90
 Darnon, M.: PS+EM+SE-TuM2, 103
 Darveau, S.A.: EL-TuP2, 118
 Dasgupta, N.P.: TF-TuM12, 106
 Datye, A.: SS+HC+MI-TuA8, 115
 Datye, I.: 2D+EM+MI+NS-TuM12, 99
 Datz, M.: TF+EM+MI-WeM13, 131
 Datzer, C.: MI+EM-FrM7, 168
 Dau, M.T.: 2D+AM+EM+NS-WeM12, 124
 David, L.: BI-ThA1, 153
 Davies, M.C.: AS+NS-ThA10, 153
 Davis, A.C.: MN+2D+AN+NS-WeA11, **138**
 Davis, J.P.: MN+2D+AN+MP+NS-ThM1, **148**
 Davis, K.: EM-ThP7, 161; NS-ThP6, 162; TF-ThP30, **163**
 Davis, R.: EM+2D+SS-WeA3, 137; MS-TuP5, 118
 Davis, R.C.: 2D+EM+MI+NS-TuM3, 99;
 MN+2D+AN+NS-WeA11, 138;
 NS+AN+EM+MI+MN+MP+PS+RM-ThM5, 148;
 TF+PS-ThM1, 151; TF+PS-ThM11, 151;
 TF+PS-ThM4, 151
 Davydov, A.: EM+MP+PS-MoM6, 82
 Day, C.: VT-MoA4, 96
 Day, J.M.: AS+SE-ThM13, 145; AS-ThP10, 160;
 BI+AS+IPF+MN-MoA10, 90; SS-TuP9, 120
 Day, P.: TF-TuM6, 106
 De Alba, R.: NS+2D+AN+MN+MP+SE-WeM2, 128;
 NS+2D+AN+MN+MP+SE-WeM5, **128**
 de Alwis, C.: SS+EM+NS-ThM10, 150
 De Buttet, C.: PS+EM-WeM1, 129
 De Castro, O.: HI+AS-ThM3, 147
 De Gendt, S.: 2D+AM+EM+NS-WeM10, 124;
 TF+AM+EM+PS-TuM12, 105
 de Jong, W.A.: AC+MI+SA-FrM3, **167**;
 BI+AC+AS+HC+NS+SS+TF-WeA10, 136
 de Kok, J.M.M.: SE+NS+TF-MoM1, 86
 de la Venta, J.: MI+2D+EM+NS-MoA5, 91
 de Lafontaine, M.: PS+EM+SE-TuM2, **103**
 De Luca, A.: NS-ThP10, **162**
 De Luna, M.: SS+AS+HC-FrM8, **170**
 de Marneffe, J.-F.: 2D+AM+EM+NS-WeM10, 124;
 PS+EM-WeA9, **140**; PS-TuP22, 119
 de Paula, C.: TF+PS-TuA3, **115**
 De Yoreo, J.J.: PC+AS+BI+NS+PB+SS-TuM3, **102**
 Debaillé, V.: PS+EM+NS+SS-TuA7, 113
 DeBenedetti, W.J.I.: SS+AS+BI+MI+NS-ThA10, **158**
 Deblonde, G.: AC-ThA1, **152**;
 BI+AC+AS+HC+NS+SS+TF-WeA10, 136
 Debucquo, M.: TF2-MoM1, 87
 Dedoncker, R.: SE+NS+TF-MoM4, 86
 Defoort, M.: MN+2D+AN+NS-ThA4, **156**
 Degueldre, C.: AC+AS+SA-ThM10, 144
 DeJarl, M.T.: EM+2D+AN+MI+MP+NS-TuA10, 110;
 PS+AS+EL+EM+SE-WeM3, 129
 del Campo, A.: IPF+AS+BI+NS-WeM12, **127**
 del Hoyo, J.: TF-ThP22, 163
 Delabie, A.: TF+AM+EM+PS-TuM10, **105**
 Delachat, F.: PS+EM-WeM3, 129
 Delair, T.: BI-ThA1, 153
 Delcorte, A.D.: AS-TuA1, **109**
 Delfin, K.: PS-FrM2, 169
 DelRio, F.W.: 2D+EM+MN+NS-FrM1, **167**
 Deluna, M.M.: SE-TuP2, 120
 Demaude, A.: PS-TuP15, **119**
 Dementyev, P.: 2D+EM+MI+MN+NS+SS-ThM11, 144
 DenBaars, S.P.: EM+MI+MN+NS-ThM5, 146;
 EM+MI+MN+NS-ThM6, 146;
 NS+AN+EM+MI+MN+MP+PS+RM-ThM13, 148;
 PS+MN-WeM3, 130
 Deng, G.: MN+2D+AN+MP+NS-ThM3, **148**
 Deng, S.: EM-ThP16, 161
 Deng, X.: SS+HC+NS+PS-TuM10, 104;
 SS+HC+NS+PS-TuM6, **104**
 Denlinger, J.D.: AC-ThA8, 152
 Depla, D.J.M.G.: SE+NS+TF-MoM4, 86; SE+PS-TuM10, **104**
 Derpmann, V.: TF+AS+EL+PS-ThM12, 151
 Despiau-Pujo, E.: PS-FrM7, 169
 Devaraj, A.: SE-TuA7, 114
 Deye, G.: NS-ThP11, **162**
 Dezelah, C.L.: TF1-MoM10, 87
 Dhar, B.: SS-TuP10, **120**
 Dhayal, M.D.: BI+AS+IPF+NS-TuA7, **110**; MN-ThP3, 162
 Dhungana, S.: PS+EM-WeA11, 140
 Di Palma, V.: TF-TuM13, **106**
 Dianat, G.: BI-TuP7, 118; SE-TuP2, **120**
 Diaz, T.C.: AS+SE-ThM13, 145
 Dick, N.: NS+2D+AN+MN+MP+SE-WeM2, 128
 Dictus, D.: TF+EM+MI-WeM12, 131
 Diebold, A.C.: EL+EM-MoA3, **90**
 Diebold, U.: SS+HC+MI-TuA3, 115
 Dietrich, P.: 2D+EM+MI+MN+NS+SS-ThM10, **144**; PC+AS+BI+EM+NS+PB+SS-TuA1, 112
 Diez, T.D.P.: BI-TuP13, **118**
 Dimond, T.: AS+SE-ThM5, 145
 Dinescu, A.: MN+NS+PS-WeM13, 127
 Ding, F.: 2D+EM+MI+NS+TF-MoM5, 81
 Ding, S.: EM-ThP2, **161**
 Ding, Z.J.: AS+NS+SA-WeM10, 125;
 EL+AS+EM-MoM9, 82;
 EM+2D+AN+MI+MP+NS-TuA4, 110; MI+EM-FrM4, 168; SS-TuP6, 120
 Diniz, J.A.: 2D-ThP4, **160**; EM-ThP6, 161; NS-ThP4, 162; PS-TuP18, 119; PS-TuP20, 119
 Dippel, A.: HC+SS-ThA7, 154
 Dittmann, R.: SA+AS+HC+SS-ThA7, 158
 Diulus, J.T.: SS+AS+EM-WeA10, **141**
 Divan, R.: NS+2D+AN+EM+MN+MP+PC+RM-MoM8, 84
 Divis, M.: AC+MI+SA-WeM10, 124
 Divitt, S.: NS+AN+EM+MN+MP+RM-TuM3, 102
 Doan, H.: EM+MI+MN+NS-ThM12, 146
 Dodson, B.D.: TF+PS-ThM11, **151**
 Doerr, M.: AC-ThP5, 160
 Doh, W.H.: HC-ThP2, 161; SS-TuP3, **120**
 Dohnalek, Z.: HC+SS-ThA1, **154**; HC+SS-WeM1, 126; SS+AS+EM-WeA12, 141
 Dohnálek, Z.: HC+SS-WeM2, 126
 Domask, A.C.: EM+AM+NS+PS-MoA8, 91
 Donald, S.B.: AC+AS+SA-ThM11, 144
 Donath, M.: MI+EM-FrM7, **168**
 Dong, H.: BI+AS+NS-FrM5, 168
 Dong, J.: 2D+EM+MI+NS+TF-MoM5, 81
 Dong, L.: NS-ThP13, 162
 Donnelly, V.M.: PS+AS+EM+SS-MoM4, 85; PS-ThA6, 157; PS-ThA8, 157; PS-ThM6, 149; PS-TuP2, 119; PS-TuP21, 119
 Donskyi, E.: 2D+MN+NS+SS-WeA7, 134
 Dopita, M.: AC+MI+SA-FrM9, **167**; AC+MI+SA-WeM10, 124; AC+MI+SA-WeM3, 124
 Doppel, M.: PS-ThM2, 149
 Döpper, T.: SS+AS+EM-WeA9, 141
 Dorf, L.: PS-ThM1, 149
 Dorsett, L.: SE-TuP3, 120
 Doudin, N.: HC+SS-WeM1, 126; HC+SS-WeM2, **126**
 Doughty, B.L.: HI+AS-ThM4, 147
 Douglas, E.A.: EM+2D+SS-WeA11, **137**; EM-ThP11, 161; EM-ThP13, 161; MN+NS+PS-ThM12, 127
 Douglass, K.O.: VT-MoM3, 88; VT-MoM5, **88**
 Dowben, P.A.: 2D+AM+EM+NS-WeM2, 124
 Downey, B.P.: TF+EM+MI-WeM1, 131;
 TF+EM+MI-WeM4, 131
 DRAHI, E.: PS+AS+EM+SS-MoM2, 85
 Draper, B.L.: MS+MI+RM-TuM1, 101
 Dravid, V.: 2D+EM+MI+NS-ThM2, 99
 Dreznar, Y.: HI-ThP2, 161
 Driessen, F.P.G.: VT-MoM10, 88
 Drnovšek, A.: SE-TuA11, **114**
 Druce, J.W.: AS+SE-ThM1, 145
 Drüppel, M.: MI+EM-FrM7, 168
 Du, S.X.: NS-ThP13, 162
 Du, X.: TF+AS+EL+EM+NS+PS+SS-ThA8, 159
 Duan, Y.: TF1-MoM3, 87
 Duan, Z.: SS+HC-WeM3, 130
 Duanmu, K.: HC+SS-WeA10, 137
 Dubey, M.: 2D+EM+MI+MN+NS+SS-ThM5, 144
 Dubois, J.: 2D+MN+NS+SS-WeA2, 134
 Duchon, T.: MM+AS+NS+PC+SS-MoA4, **92**
 Dukes, C.A.: AS+NS+SA-WeM1, **125**;
 AS+NS+SA-WeM5, 125
 Duncan, Z.: EM-ThP7, 161; NS-ThP6, 162; TF-ThP30, 163
 Dunn, B.: TF2-MoM3, 87
 Duong, N.: 2D+EM+MI+MN+NS-TuA11, 109
 Durakiewicz, T.: MS+MI+RM-TuM12, **101**
 Durand, C.: AS+NS-ThA2, 153
 Dürr, S.: SA+MI-ThM3, **150**
 Duscher, G.: MM+AS+NS+PC-MoM5, 83
 Dutoi, A.D.: AS-MoM6, 81
 Dutta, P.: TF-MoA4, 95
 Duvenhage, M.M.: TF+AS-TuM3, 105
 Dyck, O.: AM+NS+SS-WeM10, 125
 Dzarasova, A.: PS-TuP14, 119
 — E —
 E. Elsayed-Ali, H.: AS-ThP11, 160
 Ebnognasir, A.: SS+EM+PS+TF-ThA3, 159
 Ecija, D.: SS+EM+PS+TF-ThA11, 159; SS+HC-WeM6, 130
 Eckel, S.: NS+AN+EM+MN+MP+RM-TuM12, **102**
 Economou, D.J.: PS-ThA8, 157; PS-TuP21, 119
 Eddy Jr., C.R.: TF+EM+MI-WeM4, 131; TF-TuM4, 106
 Eddy, C.R.: EM+2D+SS-WeA12, 137; PS+TF-MoM11, **85**; TF-ThP38, 163
 Eddy, Jr., C.R.: 2D+EM+MN+NS-FrM6, 167;
 PS+EM+TF-ThA8, 157
 Edel, R.: SS+EM+PS+TF-ThA6, **159**
 Edmondson, B.: EM+AM+NS+PS-MoA1, 91
 Edström, D.: SE+NS+TF-MoM10, 86;
 SE+NS+TF-MoM11, **86**
 Edwards, P.J.:
 NS+2D+AN+EM+MN+MP+PC+RM-MoM10, **84**; NS-ThP7, 162
 Ehler, C.: 2D+MN+NS+SS-WeA7, 134
 Eich, M.: 2D+EM+MI+MN+NS-ThA3, 109
 Eichhorn, K.-J.: BI-ThA11, 153
 Eichler, J.E.: HC+SS-TuM6, 100
 Eickholt, P.: MI+EM-FrM7, 168
 Eilon, M.: VT-TuA1, 116
 Einstein, T.L.: SS+HC-MoA5, **94**
 Ekerdt, J.G.: EM+AM+NS+PS-MoA1, 91;
 TF+EM+MI+PS-MoA4, **95**
 Eklund, P.: SE+NS+TF-MoM11, 86
 Ekuma, C.E.: 2D+AM+EM+NS-WeM5, 124
 El Khouri, P.Z.: NS+MN+PC+SS-WeA11, 139
 Elam, J.W.: TF+EM+MI+PS-MoA9, 95; TF+PS-ThM3, 151; TF-ThP31, 163
 Elike, J.: EM-ThP7, 161
 Eliseev, E.A.: 2D+EM+MN+NS-ThA6, 152
 Ellis, J.: HI-ThA3, 155
 Ellsworth, A.A.: AS+SE-ThM11, **145**
 El-Naggar, M.Y.: NS-ThP7, 162
 ElRefaei, A.F.: TF+EM+MI-WeA10, 141

Author Index

Elzer, R.D.: MS-TuP4, **118**
 Emminger, C.: EL+AS+EM-MoM4, 82
 Emmrich, D.: 2D+EM+MI+MN+NS+SS-ThM11, 144; HI+AS-ThM10, 147
 Empante, T.A.: 2D+EM+MI+NS+TF-MoM6, **81**
 Engelhard, M.H.: AS-MoM3, 81; AS-ThP1, **160**; SS+AS+BI+MI+NS-ThA11, 158
 Engelmann, H.-J.: HI-ThA8, 155
 Engelmann, S.U.: PS+EM+TF-ThM12, 149
 English, C.: 2D+EM+MI+NS-TuM12, 99
 Engstrom, J.R.: EM+AM+NS+PS-MoA3, **91**
 Ensslin, K.: 2D+EM+MI+MN+NS-TuA3, **109**
 Eom, B.: TF-TuM6, 106
 Erbil, S.O.: MN+2D+AN+NS-ThA9, 156
 Ercius, P.: AC-ThA1, 152;
 BI+AC+AS+HC+NS+SS+TF-WeA10, 136
 Erdemir, A.: SE-TuA1, **114**; TR+AS+NS+SS-MoM10, 88
 Eremeev, G.: AS-ThP11, 160
 Eric S., L.: TF+EM+MI+PS-MoA3, 95
 Erickson, J.E.: TF+PS-ThM10, 151
 Eriksson, A.M.: MN+2D+AN+NS-ThA8, 156
 Eriksson, S.: EW-WeB2, **132**; SA+MI-ThM12, 150
 Ertekin, E.: 2D+EM+MI+NS-TuM10, 99;
 2D+EM+MN+NS-FrM7, 167
 Eryilmaz, O.L.: SE-TuA1, 114
 Esarey, S.L.: TF-TuM12, 106
 Escher, M.: MM-TuP2, 118
 Escudero, C.: PC+AS+BI+EM+NS+PB+SS-TuP2, 119
 Esplandiu, M.J.: PC+AS+BI+EM+NS+PB+SS-TuP2, 119
 Esteves, G.: MN+NS+PS-WeM12, **127**
 Etzkorn, M.: NS+2D+AS+MN+PC-ThA8, 156
 Euchner, H.: SE+NS+TF-MoM6, 86
 Evans, G.: PS-TuP14, 119
 Evans, J.W.: SS+EM+NS-ThM4, 150
 Evans, P.: 2D+AM+EM+NS-WeM2, 124
 Evans, W.: AC-ThP3, 160
 Exstrom, C.: EL-TuP2, 118
 Eymery, J.: AS+NS-ThA2, 153
 Eytan, G.: VT-TuA1, 116
 Ezzat, S.: SS-TuP7, 120
 — F —
 Facsko, S.: HI+AS-ThM12, 147; HI-ThA8, 155
 Fadley, C.S.: SA+AS+MI-WeA1, 140
 Fafard, S.: PS+EM+SE-TuM2, 103
 Fahey, A.J.: AS+SE-ThM5, **145**
 Fainozi, D.: SA-ThP4, **162**
 Fairley, N.: AS+SE-ThM3, 145
 Faivre, J.: BI-ThA1, 153
 Fan, H.: SS+AS+EM-WeA8, 141
 Fan, Q.H.: PS+EM+NS+SS-TuA11, 113
 Fanelli, F.: PS+PB-MoA9, 93
 Fang, C.K.: PC+AS+BI+NS+PB+SS-TuM11, 102
 Fang, H.: AC+AS+SA-WeA1, 134
 Fang, M.S.: EL+AS+EM-MoM8, 82
 Fang, T.-H.: 2D-ThP7, **160**
 Fang, Y.S.: TF-ThP32, 163
 Fantner, E.J.: AM-TuP1, 118
 Fantner, G.E.: NS+MN+PC+SS-WeA9, **139**
 Faraz, T.F.: PS+TF-MoM2, **85**; TF-TuM5, 106
 Farber, R.G.: HC+SS-TuA7, 111; HC-ThP6, 161;
 SS-TuP15, **120**
 Fares, C.: EM+2D+SS-WeA9, **137**
 Farrokhpanah, A.: PS+PB+SE-TuA9, 113
 Farzandh, S.: HC-ThP3, 161
 Fassett, J.D.: AS+BI-TuM10, 99
 Faucher, M.: MN+NS+PS-WeM10, 127
 Favero, I.: MN+NS+PS-WeM10, 127
 Favia, P.: PS+PB-MoA1, 93; PS+PB-MoA2, **93**
 Fears, K.P.: BI-WeA7, **136**
 Fears, T.M.: SA-ThP2, **162**
 Fedchak, J.A.: NS+AN+EM+MN+MP+RM-TuM12, 102; VT-MoA1, 96; VT-MoA3, **96**
 Feder, R.: EL+AS+EM-MoM3, **82**
 Fedosenko, G.: TF+AS+EL+PS-ThM12, **151**
 Felici, R.: HC+SS-ThM4, 146
 Felts, J.R.: TR+AS+NS+SS-MoM5, **88**
 Feng, L.: SS+HC+NS+PS-TuM4, 104
 Feng, P.X.-L.: MN+2D+AN+MP+NS-ThM11, 148; MN+2D+AN+NS-ThA3, 156
 Feng, X.: AC+AS+SA-WeA9, **134**
 Feng, Y.: IPF+AS+BI+NS-WeM3, 127
 Fenner, M.: NS-ThP12, 162
 Fenton, J.: PC+AS+BI+EM+NS+PB+SS-TuA3, **112**
 Fernandes, E.: BI-ThM6, 145
 Fernandez, V.: AS+SE-ThM3, **145**
 Fernandez-Bolaños, M.: MN+NS+PS-WeM13, 127
 Fernandez-Pacheco, A.: AM+NS+SS-WeM3, 125
 Ferrah, D.: 2D+MN+NS+SS-WeA2, 134
 Ferrah, D.F.: HC+SS-TuA1, **111**; SS+HC+MI-TuA9, 115
 FERRAND, S.: PS+MN-WeM4, 130
 Ferrera, M.: EL+AS+EM-MoM6, 82
 Ferrier, M.G.: AC-ThA3, 152
 Fester, J.: HC+SS-TuM11, 100; SS+HC-WeM6, 130
 Feyer, V.: SA+AS+HC+SS-ThA7, 158
 Fiducia, T.A.M.: TF-MoA5, 95
 Filler, M.A.: EM+MI+MN+NS-ThM3, **146**;
 EM+MP+PS-MoM10, 82
 Filleter, T.: 2D+EM+MI+NS-TuM1, 99
 FILONOVICH, S.A.: PS+AS+EM+SS-MoM2, 85
 Finck, R.: AS+BI-TuM12, 99
 Finlay, J.: BI-WeA9, 136
 Finstad, T.G.: TF-ThP23, **163**
 Fischer, G.: PS+AS+EM+SS-MoM2, **85**
 Fisher, E.R.:
 NS+2D+AN+EM+MN+MP+PC+RM-MoM5, 84; PS+AS+EM+SS-MoM8, 85; PS+MN-WeM13, 130; PS+PB-MoA8, **93**
 Fisher, G.L.: AS+BI-TuM3, **99**; AS+SE-ThM11, 145
 Fisher, M.: NS+2D+AS+PC-MoA4, 93
 Fishman, Z.: 2D+EM+MI+MN+NS+SS-ThM2, 144
 Fitzell, K.: EM-ThP10, 161; MI+2D-ThM12, **147**
 Fitz-Gerald, J.M.: AM-TuP2, 118; SE-TuP7, **120**
 Flaherty, D.W.: HC+SS-ThA6, 154; HC+SS-TuA11, **111**; HC+SS-TuA8, 111
 Flege, J.I.: HC+SS-TuM12, **100**
 Fletcher, J.S.: AS+BI-TuM4, **99**
 Fleurial, J.P.: PS-FrM10, 169
 Floro, J.A.: AM-TuP2, 118
 Fockaert, L.-L.: SS+AS+EM-WeA7, 141; TF+SS-TuA1, 116
 Foglia, L.: SA+MI-ThM5, **150**
 Foley, B.M.: PS+PB+SE-TuA7, 113
 Fong, S.W.: PS+EM-WeA12, 140
 Forbes, T.P.: AS+BI-TuM10, 99
 Ford, K.: PS-ThM5, 149
 Forien, J.B.: SA-ThP2, 162
 Foster, J.E.: NS+AN+EM+MN+MP+RM-TuM1, **102**
 Foster, J.E.: PB+BI+PC+PS-WeA9, **139**
 Fourkas, J.T.: PS+AS+EM+SS-MoM10, 85
 Fowlkes, J.D.: AM+NS+SS-WeM1, 125;
 AM+NS+SS-WeM3, **125**
 Fracassi, F.: PS+PB-MoA9, **93**
 Francesko, A.: BI-ThM6, 145
 Franchini, C.: SS+HC+MI-TuA3, 115
 Franz, R.: SE+NS+TF-MoM4, 86; SE+PS-TuM6, **104**; SE-TuA11, 114
 Fraxedas, J.: PC+AS+BI+EM+NS+PB+SS-TuP2, **119**
 Frederick, R.T.: SS+AS+EM-WeA10, 141
 Freedy, K.M.: EM-ThP19, 161
 Frees, B.: TF+EM+MI-WeM12, 131
 Freitas, J.A.: EM+2D+SS-WeA12, 137; TF-TuM4, 106
 Frenkel, A.I.: SS+HC-WeM3, 130
 Freund, H.J.: SA+AS+HC+SS-ThA6, 158
 Frevel, L.: PC+AS+BI+EM+NS+PB+SS-TuA7, 112
 Fridman, A.: PS+PB-TuM5, 103
 Friedman, A.L.: 2D+EM+MI+MN+NS-TuA1, **109**
 Friend, C.: HC+SS-WeA10, 137
 Frijters, C.: TF+AS+EL+EM+NS+PS+SS-ThA9, 159
 Froech, J.: AM-TuP1, 118
 Fu, C.: SS+AS+BI+MI+NS-ThA6, 158
 Fu, W.: EL+EM-MoA6, 90
 Fuchs, E.: AM+MP+NS-WeA8, 135; VT-MoM3, 88
 Führer, A.: AM+MP+NS-WeA11, **135**
 Fujikama, M.: PS+EM-WeA9, 140
 Fukasawa, M.: PS+EM+NS+SS-TuA12, 113
 Fukunaga, Y.: PS+AS+EM+SS-MoM11, **85**
 Fukushima, A.: RM+EM+NS-TuA11, 114
 Fullager, D.B.: EL+AS+EM-MoM11, 82; NS-ThP8, 162
 Fuller, E.J.: RM-TuP3, **120**; SA-ThP3, 162
 Fullerton, E.E.: MI+2D-ThM10, **147**
 Fung, H.-S.: PS-TuP23, 119
 Funke, S.: 2D+MI+NS-MoA10, **89**
 Furukawa, M.: SS+HC+NS+PS-TuM13, 104
 — G —
 Gabourie, A.: 2D+EM+MI+NS-TuM12, 99
 Gagliardi, L.: TF-MoA8, 95
 Gahlaut, S.K.: BI+AS+IPF+NS-TuA4, **110**
 Galhenage, R.P.: HC+SS-TuA1, 111;
 SS+HC+MI-TuA7, 115
 Gall, D.: EM+AM+NS+PS-MoA5, **91**
 Gallagher, J.C.: EM+2D+SS-WeA12, 137
 Gallagher, M.C.: SS+AS+BI+MI+NS-ThA6, 158
 Galley, S.S.: AC-ThA3, 152
 Gallup, N.M.: NS+AM+MI+MN+SS+TR-TuA11, 112
 Galoppini, E.: SS+AS+EM-WeA8, 141
 Gamble, E.: TF-ThP26, 163
 Gamble, L.J.: AS-MoA10, 89; BI+AS+IPF+MN-MoA6, 90; BI+AS+NS-FrM4, 168
 Gammer, C.: MM+AS+NS+PC-MoM6, 83
 Ganta, D.: NS+AN+EM+MI+MN+MP+PS+RM-ThM12, **148**
 Gao, H.J.: NS-ThP13, 162
 Gao, J.: AS+SE-WeA12, 135
 Gao, J.T.: TF-ThP11, 163
 Gao, Y.: TF+EM+MI-WeA10, 141; TF-MoA4, 95
 Gao, Z.Y.: NS-ThP13, 162
 Garcia, R.: AM+MP+NS-WeA1, **135**
 Garcia, X.: PC+AS+BI+EM+NS+PB+SS-TuP2, 119
 Gardella Jr., J.A.: BI+AS+NS-FrM7, 168
 Garfinkel, D.: MM+AS+NS+PC-MoM5, 83
 Garfitt, J.M.: AS+NS-ThA10, 153
 Garfunkel, E.L.: SS+AS+EM-WeA10, 141
 Gaskill, D.K.: 2D+EM+MN+NS-FrM6, 167;
 EM+2D+AN+MI+MP+NS-TuA10, 110;
 EM+2D+AN+MI+MP+NS-TuA11, 110;
 EM+2D+AN+MI+MP+NS-TuA9, 110;
 PS+AS+EL+EM+SE-WeM3, 129
 Gassilouid, R.: TF+AM+EM+PS-TuM5, 105
 Gau, M.R.: AC+AS+SA-WeA1, 134
 Gaus, K.: IPF+AS+BI+MN-TuM5, **100**
 Gautier, B.: AS+BI-TuM13, 99

Author Index

Gay, G.: PS+EM+SE-TuM2, 103
 Gay, M.: 2D+AM+EM+NS-WeM12, **124**
 Gebhard, M.: TF+PS-ThM3, **151**
 Geelen, D.: 2D+MI+NS-MoA8, 89
 Gehlmann, M.: SA+AS+MI-WeA1, 140
 Geiger, PC+AS+BI+NS+PB+SS-TuM5, 102
 Gelb, L.D.: AS+SE-ThM12, 145; AS-MoM11, **81**
 Gelinck, G.: TF+AS+EL+EM+NS+PS+SS-ThA9, 159
 Gély, M.: MN+2D+AN+NS-ThA4, 156
 Geohegan, D.B.: 2D+EM+MI+NS+TF-MoM5, 81
 George, S.M.: PS+EM+TF-ThA2, **157**; PS-TuP3, 119; TF+AM+EM+PS-TuM4, 105; TF+PS-TuA11, 115; TF+PS-TuA4, 115; TF+PS-TuA9, 115; TF-TuM2, 106
 Gerard, M.: PC+AS+BI+EM+PB+SS-WeM10, 128
 Gerber, C.: SS+HC+MI-MoM11, 86
 Gere, S.: TF-ThP25, 163; TF-ThP26, 163
 Geronia, M.: 2D+EM+MN+NS-FrM9, **167**
 Getz, P.: MN+2D+AN+NS-WeA9, 138
 Ghaderzadeh, S.: HI-WeA9, 138
 Ghahari Kermani, F.: 2D-ThP2, **160**
 Ghahari, F.: 2D-ThP6, 160; NS+2D+AS+MN+PC-ThA4, 156
 Ghandiparsi, S.: TF+EM+MI-WeA10, 141
 Gharbi, A.: HI-ThA8, 155; PS+EM-WeM3, 129
 Ghavami, M.: MN+2D+AN+NS-ThA9, 156
 Ghimire, B.: PS+PB-TuM4, 103
 Ghorbani-Asl, M.: HI-WeA9, 138
 Giangrisostomi, E.: SS+AS+BI+MI+NS-ThA8, 158
 Giannuzzi, L.A.: AS-TuA9, **109**
 Gibson, J.K.: AC+MI+SA-FrM3, 167
 Giddings, A.D.: TF+AS+EL+EM+NS+PS+SS-ThA6, 159
 Giegerich, T.: VT-MoA4, 96
 Giessibl, F.J.: 2D-ThP6, 160
 Gigax, J.: PS+EM-WeA2, 140
 Giles, A.J.: EM+2D+AN+MI+MP+NS-TuA11, 110
 Gill, D.: VT-TuM1, 106
 Gillen, G.J.: AS+SE-ThM10, **145**
 Gilliland, D.: BI-ThM3, 145
 Gilmore, I.S.: AS+BI-TuM5, **99**
 Girard-Lauriault, P.L.: 2D+MN+NS+SS-WeA7, 134
 Giri, A.: PS+PB+SE-TuA7, 113
 Girolami, G.S.: TF1-MoM5, **87**
 Glaser, E.R.: EM+2D+AN+MI+MP+NS-TuA10, 110; EM+2D+AN+MI+MP+NS-TuA11, 110
 Glass, J.: IPF+AS+BI+NS-WeM3, 127
 Glavin, N.R.: 2D+EM+MI+MN+NS-TuA8, 109; EM+2D+NS+PS+RM+TF-ThA3, 154; EM+AN+MI+SS-WeM12, 126; EM-ThP3, 161; PS-TuP16, 119
 Gleason, K.K.: PS+PB-MoA3, **93**
 Gleeson, M.A.: HC+SS-WeA2, 137
 Glenn, M.: EM-ThP7, 161
 Glezakou, V.-A.: HC+SS-WeM2, 126
 Gliebe, K.: EM+2D+NS+PS+RM+TF-ThA3, 154; EM+AN+MI+SS-WeM12, 126
 Godet, S.: PS+EM+NS+SS-TuA7, 113
 Goeke, R.S.: VT-TuM12, **106**
 Gofryk, K.: AC+AS+SA-WeA10, **134**
 Gokturk, P.: PC+AS+BI+EM+PB+SS-WeM4, 128
 Golbek, T.W.: BI+AS+IPF+MN-MoA3, 90
 Goldsmith, R.H.: NS+AN+EM+MN+MP+RM-TuM5, 102
 Gölzhäuser, A.: 2D+EM+MI+MN+NS+SS-ThM11, **144**; 2D+MN+NS+SS-WeA12, 134; HI+AS-ThM10, 147
 Gomez, M.J.: 2D+EM+MI+MN+NS+SS-ThM5, 144
 Gong, C.: 2D+EM+MN+NS-ThA8, 152
 Gong, Y.: NS-ThP15, 162
 Gonon, P.: TF+AM+EM+PS-TuM3, 105
 Goodwin, C.M.: NS+AM+AS+MN+PC+PS+SS+TR-FrM3, **169**
 Goorsky, M.S.: SE+NS+TF-MoM3, 86
 Gorbulov, D.: AC-ThP5, 160
 Gordon, M.J.: EM+MI+MN+NS-ThM5, 146; EM+MI+MN+NS-ThM6, 146; NS+AN+EM+MI+MN+MP+PS+RM-ThM13, **148**; PS+EM+NS+SS-TuA7, 113; PS+MN-WeM3, 130; PS-TuP15, 119; PS-TuP17, 119
 Gorey, T.: HC+SS-ThuM4, **100**
 Gorkhovet, L.: TF+AS+EL+PS-ThM12, 151
 Görling, A.: SS+AS+EM-WeA9, 141
 Goronzy, D.P.: NS+AM+MI+MN+SS+TR-TuA11, **112**
 Goto, K.: EL+EM-MoA1, 90
 Goto, S.: SS+AS+EM-WeA4, **141**
 Goto, T.: PS+AS+EM+SS-MoM3, 85; PS-ThM10, **149**
 Gottscho, R.A.: PS+EM+TF-ThA4, 157
 Gouder, T.: AC+MI+SA-WeM10, 124; AC+MI+SA-WeM3, 124
 Gould, A.P.: AS+BI-TuM5, 99
 Grabnic, T.: SS+EM+PS+TF-ThA6, 159
 Grabow, L.C.: SS+HC-WeM10, **130**
 Grabowski, K.S.: AC+AS+SA-ThM12, 144
 Grady, R.: 2D+EM+MI+NS-TuM12, 99
 Graham, D.J.: AS-MoA10, 89; BI+AS+IPF+MN-MoA6, 90; BI+AS+NS-FrM4, **168**
 Graham, J.: SS+HC+MI-MoM10, **86**
 Gram, L.: SE-MoA9, 94
 Granados-Focil, S.: NS+2D+AS+PC-MoA3, 93
 Grantham, Z.: TF-ThP12, 163
 Graur Martin, I.A.: VT-MoM6, **88**
 Graves, D.B.: PS+PB-TuM1, **103**
 Gray Be, A.: PC+AS+BI+NS+PB+SS-TuM5, **102**
 Gray, A.X.: SA+AS+MI-WeA10, **140**
 Greaney, A.: PS-FrM10, 169
 Greczynski, G.: SE+PS-TuM5, 104; SE-MoA4, **94**
 Greene, J.: SE+NS+TF-MoM10, 86; SE+NS+TF-MoM11, 86
 Greene, J.E.: SE+PS-TuM5, 104
 Greenzweig, Y.: HI-ThP2, 161
 Greer, F.: TF-TuM6, **106**
 Gregoratti, L.: MM+AS+NS+PC+SS-MoA1, **92**
 Gregorczyk, K.: TF2-MoM5, 87
 Grehl, T.: HI+AS-ThM11, 147; SS+HC+MI-TuA8, **115**
 Gremmo, S.: BI+AS+IPF+NS-TuA3, 110
 Grenet, G.A.: AS+NS+SA-WeM2, 125
 Greuel, S.R.: VT-TuA3, **116**
 Gridchin, D.: AC+AS+SA-ThM3, 144
 Griffin, B.A.: MN+NS+PS-WeM12, 127
 Grillet, A.M.: AS+NS+SA-WeM13, 125
 Grillo, F.: TF+AM+EM+PS-TuM10, 105
 Grinberg, E.: AC+AS+SA-ThM3, 144
 Grindstaff, Q.: VT-MoA10, **96**
 Grinter, D.: HC+SS-TuM3, 100
 Griveau, J.-C.: AC+AS+SA-WeA10, 134
 Grob, F.: TF2-MoM4, 87
 Groden, K.: SS+HC-MoA1, 94
 Groebe, J.R.: PB+BI+PC+PS-WeA9, 139
 Grollier, J.: RM+EM+NS-TuA11, 114
 Gronbeck, H.: HC+SS-WeM10, 126
 Grönbeck, H.: HC+SS-ThM2, 146; HC+SS-WeA8, **137**
 Grondahl, L.: NS+MN+PC+SS-WeA4, 139
 Groopman, E.E.: AC+AS+SA-ThM12, 144
 Grosse, C.: NS+2D+AS+MN+PC-ThA8, 156
 Grovenor, C.R.M.: TF-MoA5, 95
 Grumelli, D.: HC+SS-TuM11, 100
 Grunze, M.: BI-WeA3, **136**
 Grutter, K.: NS+AN+EM+MN+MP+RM-TuM10, **102**
 Grutzik, S.: NS+2D+AN+MN+MP+SE-WeM2, 128
 Gryczynski, I.: EM+MI+MN+NS-ThM12, 146
 Gryczynski, Z.: EM+MI+MN+NS-ThM12, 146
 Gryka, M.: IPF+AS+BI+MN-TuM1, 100
 Grzeskowiak, J.: SS+AS+BI+MI+NS-ThA7, **158**
 Gu, H.G.: EL+AS+EM-MoM8, 82
 Gu, J.: TF-ThP41, 164
 Gu, J.J.: SE-MoA10, **94**
 Gua, C.: NS+2D+AS+MN+PC-ThA3, 156
 Guan, A.: 2D+EM+MI+MN+NS+SS-ThM5, 144
 Guan, C.: HC+SS-TuA10, 111; SS+AS+HC-FrM5, 170
 Gudla, V.C.: SE+NS+TF-MoM1, 86
 Guedj, C.: 2D+MN+NS+SS-WeA1, 134
 Guerreiro, J.R.: BI-ThM6, 145
 Guerrero, J.: NS-ThP10, 162
 Gulam, M.: PS+PB+SE-TuA10, 113
 Gunasekeran, R.: BI-TuP11, 118
 Gundersen, M.: PS+PB+SE-TuA4, 113
 Gundimeda, A.: EM+AN+MI+SS-WeM4, 126
 Gundlach, L.: SS+AS+EM-WeA8, 141
 Gunlycke, D.: 2D+AM+EM+NS-WeM5, **124**
 Gunnarsson, O.: NS+2D+AS+MN+PC-ThA8, 156
 Guo, H.X.: MM+AS+NS+PC+SS-MoA10, **92**; MM+AS+NS+PC+SS-MoA4, 92
 Guo, J.: PS-FrM2, 169
 Guo, J.-H.: SA+AS+HC+SS-ThA3, 158
 Guo, T.: VT-WeM5, **131**
 Gupta, G.: EM+AN+MI+SS-WeM4, 126
 Gupta, M.: BI-TuP7, 118; NS+AN+EM+MI+MN+MP+PS+RM-ThM2, 148; SE-TuP2, 120; SS+AS+BI+MI+NS-ThA9, 158; SS+AS+HC-FrM8, 170
 Gupta, T.: MM+AS+NS+PC-MoM10, **83**
 Gusmao-Cacho, M.-G.: PS+EM-WeM3, 129
 Gustafson, J.: HC+SS-ThA2, **154**; HC+SS-ThA7, 154; HC+SS-ThM2, 146; HC+SS-WeM10, 126; HC+SS-WeM11, 126; HC+SS-WeM5, 126
 Guthrey, H.: AS-MoA1, 89
 Gutierrez Razo, S.A.: PS+AS+EM+SS-MoM10, 85
 Gutierrez, C.: NS+2D+AS+MN+PC-ThA4, 156
 Gutierrez, C.: 2D-ThP2, 160
 Gutowski, O.: HC+SS-ThA7, 154
 Gutzler, R.: HC+SS-TuM11, 100; NS+AM+AS+MN+PC+PS+SS+TR-FrM4, 169
 Guzman, C.: NS+AN+EM+MI+MN+MP+PS+RM-ThM12, 148
— H —
 Ha, H.: HC-ThP2, 161
 Haag, R.: 2D+MN+NS+SS-WeA7, 134
 Hacker, C.A.: SS+AS+BI+MI+NS-ThA8, 158
 Hackl, J.: MM+AS+NS+PC+SS-MoA4, 92; SA+AS+HC+SS-ThA7, 158
 Hackler, R.: TF1-MoM1, **87**
 Haehnlein, I.: SS+EM+PS+TF-ThA9, 159
 Hage, F.: AM+NS+SS-WeM12, 125
 Hagan, B.: HC+SS-ThA2, 154; HC+SS-ThM2, 146
 Hagmann, J.: AM+MP+NS-WeA7, 135
 Hahn, R.: SE+NS+TF-MoM6, 86
 Haikin, N.: AC+AS+SA-ThM3, 144
 Haines, A.: HC+SS-TuA1, 111; SS+HC+MI-TuA9, **115**
 Hajzus, J.: EM+2D+NS+PS+RM+TF-ThA4, **154**
 Hakamata, T.: EM+MP+PS-MoM8, 82
 Halevy, I.: AC+AS+SA-ThM3, **144**

Author Index

HaLevy, O.: NS+2D+AN+MN+MP+SE-WeM6, 128

Hallstein, R.M.: HI-ThP1, 161; HI-ThP2, **161**

Ham, U.: NS+AM+MI+MN+SS+TR-TuA4, 112

Hamaguchi, S.: PS+EM+NS+SS-TuA12, 113

Hamaguchi, S.: PS+AS+EM+SS-MoM1, 85; PS+EM+TF-ThA1, 157; PS+EM+TF-ThM4, 149; PS+PB-MoA4, 93; PS-FrM5, 169; PS-FrM6, **169**

Hamlyn, R.: HC+SS-TuM3, **100**

Hammer, B.: SS+HC+MI-MoM4, 86

Hammons, J.A.: SA+AS+HC-ThA11, 158; SA-ThP2, 162

Han, D.-H.: TF-ThP15, **163**

Han, D.W.: PS+EM-WeM11, 129

Han, J.H.: TF-TuM3, 106

Han, K.S.: PC+AS+BI+EM+NS+PB+SS-TuP5, 119

Han, M.: MN-ThP7, **162**; MN-ThP8, 162

Han, S.E.: EM+MI+MN+NS-ThM4, 146; EM-ThP9, 161

Han, S.M.: EM+MI+MN+NS-ThM4, **146**; EM-ThP9, 161; SE-TuA3, 114; VT-TuP1, 120

Han, SW.: BI-TuP4, 118

Han, T.: AS+SE-WeA12, 135

Han, T.H.: SS-TuP14, 120

Han, T.Y.: SA-ThP2, 162

Han, Y.: SS+EM+NS-ThM4, 150

Hanay, M.S.: MN+2D+AN+NS-ThA9, **156**

Hanay, S.: MN+2D+AN+NS-WeA3, **138**

Hanbicki, A.T.: 2D+EM+MN+NS-ThA1, **152**; 2D+EM+MN+NS-ThA2, 152; NS-ThP18, 162

Handa, Y.: PS-TuP30, **119**

Hanna, A.R.: PS+AS+EM+SS-MoM8, **85**

Hanna, C.: TF+SS-TuA11, **116**

Hans, M.: SE-MoA4, 94

Hansen, R.: AS-ThP1, 160

Hao, S.: 2D+EM+MI+NS-TuM2, 99

Harb, J.: NS+AN+EM+MI+MN+MP+PS+RM-ThM5, 148

Hardcastle, T.: AM+NS+SS-WeM12, 125

Hardy, M.T.: TF+EM+MI-WeM1, 131

Harmer, R.: SS+AS+EM-WeA8, 141

Harp, J.: AC+AS+SA-ThM10, 144

Harris, J.S.: TF+AS+EL+PS-ThM1, 151

Harrison, J.A.: TR+AS+NS+SS-MoM3, **88**

Hartings, M.: VT-MoA1, **96**; VT-MoA3, 96

Hartmann, G.: PS+AS+EM+SS-MoM11, 85; PS+TF-MoM5, **85**

Hartmann, J.M.: PS+EM+SE-TuM1, 103

Harville, L.K.: SS+AS+BI+MI+NS-ThA1, 158

Hasabeldaim, E.: TF+AS-TuM3, 105

Hasan, N.: 2D+EM+MI+MN+NS-TuA12, **109**

Hashizume, T.: HI-ThA1, 155

Hatipoğlu, U.: MN+2D+AN+NS-ThA9, 156

Hauffman, T.: SE+NS+TF-MoM1, 86; SS+AS+EM-WeA7, **141**; TF+SS-TuA1, 116

Havela, L.: AC+MI+SA-FrM9, 167; AC+MI+SA-WeM10, **124**; AC+MI+SA-WeM11, 124; AC+MI+SA-WeM3, 124; AC-ThP5, 160

Havelund, R.: AS+BI-TuM5, 99

Havercroft, N.J.: AS+NS-ThA6, 153; AS+SE-WeA1, 135

Haverkate, L.A.: TF2-MoM4, **87**

Hazendonk, L.: TF-MoA3, 95

He, C.H.: SS+AS+EM-WeA8, **141**; SS-TuP11, 120

He, H.: AC-ThA8, 152

He, L.: AC+AS+SA-ThM10, 144

He, W.: BI+AS+IPF+NS-TuA1, 110; BI+AS+IPF+NS-TuA8, **110**

He, X.: BI-ThM1, **145**

Headley, C.V.: AM-TuP2, 118

Heckman, E.M.: EM-ThP3, 161

Hedhili, M.: AS-ThP3, **160**

Hedlund, J.K.: AS+SE-ThM12, 145

Heinig, K.-H.: HI-ThA8, 155

Heinze, K.: PS+PB-MoA3, 93

Hejral, U.: HC+SS-ThA7, **154**; HC+SS-ThM4, 146; HC+SS-WeM10, 126

Hellberg, C.S.: 2D+EM+MN+NS-ThA1, 152; NS-ThP18, 162

Heller, E.R.: EM-ThP3, 161

Heller, R.: HI+AS-ThM12, 147

Hellgren, N.: SE+PS-TuM5, **104**

Hemminger, J.C.: AC-ThP3, 160; HC+SS-TuA1, 111; MM+AS+NS+PC+SS-MoA3, 92; SS+AS+HC-FrM1, **170**; SS+HC+MI-TuA9, 115

Henderson, A.: EM-ThP7, **161**; NS-ThP6, 162

Henderson, R.M.: MI+2D-ThM12, 147

Hendricks, J.: VT-MoM3, **88**; VT-MoM5, 88; VT-TuA11, 116

Henkelman, G.: SS+HC-WeM3, 130

Hennessy, J.: PS+EM+TF-ThA9, **157**

Henry, M.D.: MN+NS+PS-WeM12, 127; TF+EM+MI+PS-MoA8, **95**; VT-TuP1, 120

Hensley, A.J.R.: SS+HC-MoA1, 94

Henß, A.: AS+NS-ThA6, 153

Hentz, S.: MN+2D+AN+NS-ThA4, 156; MN+NS+PS-WeM10, 127

Herbots, N.: AS+SE-ThM13, 145; AS-ThP10, 160; BI+AS+IPF+MN-MoA10, 90; SS-TuP9, 120

Herman, G.S.: SS+AS+EM-WeA10, 141; TF+AS+EL+EM+NS+PS+SS-ThA8, **159**

Hermansson, K.: HC+SS-ThM12, **146**

Hermes, D.: TF2-MoM4, 87

Herrera-Gomez, A.: AS-MoM6, **81**; AS-ThP5, 160; AS-ThP9, 160

Hershcovitch, A.I.: VT-TuA9, **116**

Hertzberg, J.B.: MP+AM+EM+NS-MoA10, 92

Herzinger, C.M.: EL+AS+EM-MoM11, 82

Hetzl, C.: VT-TuM10, 106

Hetzl, M.: EM+AN+MI+SS-WeM13, 126

Heylman, K.D.: NS+AN+EM+MN+MP+RM-TuM5, 102

Hicks, W.: BI+AS+NS-FrM7, 168

Hidayat, R.: TF-ThP41, 164

Higashiwaki, M.: EL+EM-MoA1, 90

High, E.A.: SS+HC+MI-MoM3, **86**

Hight Walker, A.: EM+2D+NS+PS+RM+TF-ThA4, 154

Hilfiker, M.: EL+AS+EM-MoM3, 82

Hill, S.: SE-TuA4, 114; TF-ThP12, 163

Hines, M.A.: SS+AS+BI+MI+NS-ThA10, 158; SS+HC+MI-TuA1, **115**

Hinkle, C.L.: EM-ThP14, 161; PS+AS+EL+EM+SE-WeM4, **129**

Hinze, P.: 2D+MN+NS+SS-WeA12, 134

Hirata, A.: PS+EM+NS+SS-TuA12, 113

Hirose, M.: TF+EM+MI-WeM3, 131

Hirsch, A.: SS+AS+EM-WeA9, 141

Hirtzlin, T.: RM+EM+NS-TuA11, 114

Hisamatsu, H.: VT-TuP4, 121; VT-TuP6, 121

Hite, D.A.: MP+EM+MN+NS-MoM8, **84**

Hite, J.K.: EM+2D+SS-WeA12, **137**

Hiyoto, K.: NS+2D+AN+EM+MN+MP+PC+RM-MoM5, **84**

Hla, S.W.: NS+2D+AS+PC-MoA4, 93

Hlawacek, G.: HI+AS-ThM12, 147; HI-ThA8, 155; HI-WeA9, **138**

Ho, NS+2D+AN+EM+MN+MP+PC+RM-MoM1, **84**

Ho, J.: BI-TuP9, 118

Ho, L.W.: EL+EM-MoA6, 90

Ho, W.: SS+HC+MI-MoM1, **86**

Ho, Y.-S.: SE-MoA10, 94

Hobart, K.: EM+2D+AN+MI+MP+NS-TuA11, 110

Hodgin, R.: SA+AS+HC+SS-ThA11, 158

Hodgson, G.: VT-WeM6, **131**

Hoen, M.E.: TF+EM+MI-WeA3, 141

Hoffman, A.N.: 2D+MN+NS+SS-WeA9, **134**

Hoffmann, M.: NS-ThP16, 162

Hoffmann, T.: EM+AN+MI+SS-WeM13, 126

Hofmann, S.: 2D+EM+MI+NS+TF-MoM3, **81**; 2D+MI+NS-MoA10, 89

Hofmann, T.: EL+AS+EM-MoM11, 82; NS-ThP8, 162; PS+AS+EL+EM+SE-WeM2, **129**

Hofsaess, H.: AM+NS+SS-WeM12, 125

Hogan, L.T.: NS+AN+EM+MN+MP+RM-TuM5, 102

Holcomb, M.B.: AC+MI+SA-WeM13, 124; MI+2D-ThM2, **147**; SA+MI-ThM2, 150

Holden, K.: TF1-MoM10, **87**

Holec, D.: SE+NS+TF-MoM6, 86; SE+PS-TuM6, 104

Holic, A.T.: VT-TuM4, 106

Holland, G.: NS+2D+AN+MN+MP+SE-WeM5, 128

Hollevoet, S.: TF2-MoM1, 87

Holloway, P.H.: TF+AS-TuM3, 105

Hollowell, A.E.: MN+NS+PS-WeM4, **127**; MN+NS+PS-WeM5, 127; MN+NS+PS-WeM6, 127

Honari, S.: EM-ThP14, 161

Hong, K.: NS+AM+MI+MN+SS+TR-TuA9, 112

Hong, S.: SS+HC-MoA3, 94

Hong, S.S.: PS+EM-WeM11, 129

Hong, Y.J.: PS+PB-TuM4, 103

Hong, Y.L.: EL+AS+EM-MoM8, 82

Hood, M.: BI+AS+IPF+MN-MoA5, 90

Hooshmand, Z.: 2D+AM+EM+NS-WeM2, 124; SS+EM+NS-ThM11, **150**

Hopkins, P.E.: PS+PB+SE-TuA7, 113

Hopwood, J.: PS+PB+SE-TuA11, **113**

Horak, E.H.: NS+AN+EM+MN+MP+RM-TuM5, 102

Horak, L.: AC+MI+SA-WeM10, 124

Horák, L.: AC+MI+SA-FrM9, 167

Hori, M.: PS+AS+EM+SS-MoM11, 85; PS+EM+SE-TuM13, 103; PS+EM+TF-ThM3, 149; PS+PB-TuM11, 103

Hosemann, P.: SE-TuA11, 114

Hoskins, B.: RM+EM+NS-TuA11, 114; RM-TuP2, **120**

Hosoi, Y.: PS+PB-TuM11, 103

Hosseini, A.: PS-FrM10, 169

Hou, B.: 2D+EM+MI+MN+NS-TuA12, 109

Hou, V.: EM+MP+PS-MoM5, 82

Houdkova, J.: TF+SS-TuA7, 116

Houk, K.N.: NS+AM+MI+MN+SS+TR-TuA11, 112

House, S.: SS+HC-WeM3, 130

Howard, M.: EM-ThP7, 161; TF-ThP30, 163

Howell, C.: BI-ThA9, **153**

Hoy, J.: EW-TuAB2, **117**

Hrebik, J.: EW-TuB2, **107**; SE+PS-TuM13, **104**

Hsiao, C.N.: PS-TuP25, 119

Hsiao, C.-N.: 2D-ThP1, 160

Hsiao, C.-N.: MN-ThP1, 162

Hsiao, C.-N.: MN-ThP2, 162

Hsieh, J.H.: BI+AS+IPF+NS-TuA11, 110; PB+BI+PC+PS-WeA11, 139; SE-MoA8, **94**; SE-TuP1, 120

Hsu, C.C.: SE-MoA8, 94

Hsu, C.-C.: PB-TuP1, 118

Hsu, C.-C.: PS-TuP7, 119

Hsu, C.-C.: PS-TuP8, 119

Hsu, C.-C.: PS-TuP9, 119

Hsu, K.: EM+MI+MN+NS-ThM4, 146

Hu, B.H.: HI+AS-ThM4, 147

Hu, S.: 2D+EM+MI+MN+NS+SS-ThM2, 144

Hu, X.: PS+EM-WeA3, **140**

Huan, Q.: NS-ThP13, **162**

Author Index

Huang, C.-Y.: AC+MI+SA-WeM13, 124;
SA+MI-ThM2, 150

Huang, F.-H.: PS-TuP7, 119

Huang, J.: HI+AS-ThM4, 147

Huang, J.M.: SS+HC+NS+PS-TuM4, 104

Huang, L.: BI+AS+NS-FrM5, 168

Huang, S.: PS+EM+SE-TuM4, 103

Huang, Y.L.: SS+EM+NS-ThM6, 150

Huang, Y.Y.: AC-ThP4, 160

Huber, F.: AC+MI+SA-WeM10, 124

Huber, J.: MN+2D+AN+NS-ThA6, 156

Hübner, R.: HI-ThA8, 155

Huerfano, I.J.: SS+EM+PS+TF-ThA4, 159

Huestis, P.L.: SS+HC+MI-TuA10, 115

Hughart, D.R.: MS+MI+RM-TuM1, 101

Hughes, S.: VT-TuA7, 116

Huh, D.: AC-ThP3, 160

Huh, J.-E.: TF-ThP8, 163; TF-ThP9, 163

Huli, L.: PS-TuP1, 119

Hultman, L.: SE+NS+TF-MoM10, 86;
SE+NS+TF-MoM11, 86; SE+PS-TuM5, 104;
SE-MoA4, 94

Hulva, J.: SS+HC+MI-TuA3, 115

Humphrey, S.: SS+HC-WeM3, 130

Hung, C.-W.: 2D-ThP7, 160

Hung, P.: MN+2D+AN+NS-ThA3, 156

Hung, T.Y.: SE-MoA10, 94

Hunt, M.S.: HI+AS-ThM13, 147

Hunter, N.C.: BI-ThM4, 145

Hurard, C.: PS+EM+SE-TuM4, 103

Hussain, R.: BI-ThM3, 145

Hutchings, G.S.: 2D+EM+MI+MN+NS+SS-
ThM2, 144; SS+HC-WeM12, 130

Hutchison, D.C.: SS+AS+EM-WeA10, 141

Huth, M.: AM+NS+SS-WeM5, 125

Hutton, S.J.: AS+NS-ThA10, 153

Huynh, C.: BI+AS+IPF+MN-MoA9, 90

Hwang, G.S.: PS-TF-MoM5, 85

Hwang, I.S.: PC+AS+BI+NS+PB+SS-TuM11,
102

Hwang, S.: TF1-MoM9, 87

Hwang, S.H.: PS+EM+NS+SS-TuA8, 113

Hwang, S.Y.: MN-ThP4, 162

Hwang, T.Y.: SS-TuP13, 120

Hwang, W.: MS+MI+RM-TuM10, 101

Hybertsen, M.S.: SA+AS+HC+SS-ThA1, 158

Hytönen, V.P.: BI-ThM6, 145

Hyun, C.M.: 2D-ThP3, 160; TF-ThP13, 163
— | —

Ianno, N.J.: EL-TuP2, 118

Iesaka, K.: TF-ThP19, 163

Ilevlev, A.V.: HI+AS-ThM1, 147; HI+AS-ThM4,
147

Ihlefeld, J.: TF+EM+MI+PS-MoA8, 95

Ihn, T.: 2D+EM+MI+MN+NS-TuA3, 109

Ikeda, N.: TF+EM+MI-WeM3, 131

Ikeno, N.: SA-ThP1, 162

Ilic, B.R.: NS+2D+AN+MN+MP+SE-WeM2,
128; NS+2D+AN+MN+MP+SE-WeM5, 128

Ilgen, R.: 2D+MN+NS+SS-WeA7, 134

Illiberi, A.: TF+AS+EL+EM+NS+PS+SS-ThA9,
159

Im, C.I.: TF-ThP39, 163; TF-ThP8, 163; TF-
ThP9, 163

Imabayashi, T.: HC+SS-WeA7, 137

In, J.H.: TF-ThP37, 163

Ingram, W.: EM-ThP13, 161

Inlek, I.V.: MP+EM+MN+NS-MoM9, 84

Inoue, M.: TF+EM+MI-WeM3, 131

Ionescu, A.M.: MN+NS+PS-WeM13, 127

Irving, D.L.: TF+AS+EL+PS-ThM1, 151

Isaacs-Smith, T.: EM-ThP18, 161

Isarraraz, M.: 2D+EM+MI+NS-TuM11, 99

Isbill, S.: HC+SS-TuA7, 111; HC+SS-WeM6,
126

Ishibashi, K.: PS+TF-MoM5, 85; PS-ThA7, 157;
PS-ThA9, 157

Ishibashi, T.: VT-TuP4, 121; VT-TuP6, 121

Ishihara, T.: VT-TuP2, 121

Ishii, Y.: PS+EM-WeM5, 129

Ishikawa, K.: PS+AS+EM+SS-MoM11, 85;
PS+EM+SE-TuM13, 103; PS+EM+TF-ThM3,
149; PS+PB-TuM11, 103

Ishikawa, M.: PS+EM-WeM12, 129

Ishimura, H.: PS+EM-WeM5, 129

Ishizaka, K.: TF-ThP20, 163

Iski, E.V.: HC+SS-TuA7, 111; SS+AS+BI+MI+NS-
ThA1, 158

Islam, M.S.: TF+EM+MI-WeA10, 141;
TF+EM+MI-WeA9, 141

Islam, R.: AS+SE-ThM13, 145; AS-ThP10, 160

Ismail-Beigi, S.: 2D+EM+MI+MN+NS+SS-
ThM2, 144

Isobe, M.: PS+AS+EM+SS-MoM1, 85;
PS+EM+NS+SS-TuA12, 113; PS+EM+TF-
ThA1, 157; PS-FrM5, 169; PS-FrM6, 169

Ista, L.: BI-ThA8, 153

Itagaki, N.: PS+EM+NS+SS-TuA8, 113

Ito, K.: TF+EM+MI-WeM3, 131

Ito, T.: PS+EM+NS+SS-TuA12, 113;
PS+EM+TF-ThA1, 157; PS+EM+TF-ThM4,
149; PS-FrM6, 169

Ivanon, I.: 2D+MN+NS+SS-WeA9, 134

Ivanov, L.: AC-ThP5, 160

Ivelev, A.V.: 2D+MN+NS+SS-WeA10, 134

Iwao, T.: PS+TF-MoM5, 85; PS-ThA7, 157; PS-
ThA9, 157

Iwasaki, K.: TF-ThP21, 163

Iwashita, S.: PS+TF-MoM10, 85

Iyer, S.: PS+MN-WeM1, 130

Izawa, M.: PS+EM+TF-ThA3, 157; PS+EM+TF-
ThM3, 149
— | —

Jackson, L.E.: SS+AS+BI+MI+NS-ThA1, 158

Jackson, T.N.: TF+AM+EM+PS-TuM6, 105

Jacobi, C.: 2D+EM+MN+NS-FrM5, 167

Jacobsen, D.J.: TF+PS-ThM10, 151

Jacobs-Gedrim, R.B.: MS+MI+RM-TuM1, 101;
RM-TuP3, 120

Jäger, W.: MM+AS+NS+PC-MoM6, 83

Jaillet, L.: 2D+MN+NS+SS-WeA1, 134

Jain, V.: AS+SE-ThM6, 145; AS-MoM5, 81

Jaiswal, J.: MN-ThP3, 162

Jakub, Z.: SS+HC+MI-TuA3, 115

Jamer, M.E.: MI+2D-ThM12, 147

James, C.D.: MS+MI+RM-TuM1, 101

Jamet, M.: 2D+AM+EM+NS-WeM12, 124

Jang, B.K.: AS-ThP12, 160

Jang, B.-K.: MI+EM-FrM8, 168

Jang, H.: MI+EM-FrM8, 168

Jang, H.S.: TF-ThP10, 163

Jang, J.: PS+PB+SE-TuA2, 113

Jang, Y.: PS-ThA10, 157; PS-ThA11, 157

Janjua, B.: AS-ThP3, 160

Jankowski, M.: HC+SS-ThA2, 154; HC+SS-
ThM4, 146

Jansen, R.: VT-MoM10, 88

Jansson, C.J.: BI+AS+IPF+MN-MoA8, 90

Jaouad, A.: PS+EM+SE-TuM2, 103

Jaramillo, C.: BI-WeA10, 136

Jardine, A.: HI-ThA3, 155

Jarvis, K.L.: SE-TuP5, 120

Javier, A.: HC+SS-TuA1, 111

Jawaid, A.: EM+AN+MI+SS-WeM12, 126

Jayawardena, I.: NS+MN+PC+SS-WeA4, 139

Jeckell, Z.K.: PS+PB+SE-TuA9, 113

Jenkins, T.G.: PS-FrM12, 169

Jensen, B.D.: MN+2D+AN+NS-WeA11, 138

Jeon, H.: 2D+EM+MN+NS-ThA10, 152

Jeon, U.S.: NS+AM+MI+MN+SS+TR-TuA10,
112

Jeong, C.Y.: TF-ThP7, 163

Jeong, G.-H.: PS-TuP27, 119; TF-ThP36, 163

Jeong, H.: HC-ThP1, 161

Jeong, H.H.: PS+EM-WeM11, 129

Jeong, S.I.: MS-TuP1, 118

Jeong, W.H.: RM-TuP1, 120

Jeong, Y.H.: MI+EM-FrM8, 168

Jeremiason, J.D.: TF-MoA8, 95

Jernigan, G.: 2D+MN+NS+SS-WeA11, 134

Jesse, S.: AM+NS+SS-WeM10, 125; HI+AS-
ThM4, 147; MM+AS+NS+PC-MoM8, 83; NS-
ThP19, 162

Jevric, M.: SS+AS+EM-WeA9, 141

Jewell, A.D.: TF+EM+MI-WeA3, 141

Jhang, J.-H.: 2D+EM+MI+MN+NS+SS-ThM2,
144; SS+HC-WeM12, 130

Ji, A.R.: PS+EM-WeM11, 129

Jia, H.: MN+2D+AN+NS-ThA3, 156

Jia, M.: PC+AS+BI+NS+PB+SS-TuM10, 102

Jia, Z.: MP+EM+MN+NS-MoM9, 84

Jiang, H.: EL+EM-MoA10, 90

Jiang, N.: NS+AM+MI+MN+SS+TR-TuA3, 112;
NS-ThP1, 162

Jiang, T.: HC+SS-TuM2, 100

Jiang, Z.T.: SE+NS+TF-MoM5, 86; SE+PS-
TuM4, 104

Jimenez, C.J.: SA+AS+MI-WeA9, 140

Jinka, O.: MP+AM+EM+NS-MoA5, 92;
MP+EM+MN+NS-MoM5, 84

Jo, C.: HC-ThP2, 161

Jo, S.-I.: PS-TuP27, 119; TF-ThP36, 163

Job, N.: PS+EM+NS+SS-TuA7, 113

Jobst, J.: 2D+MI+NS-MoA8, 89

Joe, G.: SS+HC+MI-TuA12, 115

Johansson, L.I.: 2D+EM+MN+NS-FrM5, 167

Johansson, M.V.: VT-MoM6, 88

Johansson, P.K.: BI+AS+IPF+MN-MoA4, 90

John, S.: TF+AS+EL+EM+NS+PS+SS-ThA8, 159

Johnson, A.: BI-ThM4, 145

Johnson, B.: AS+BI-TuM3, 99

Johnson, B.I.: TF+AS+EL+PS-ThM5, 151

Johnson, C.P.: BI+AS+IPF+MN-MoA3, 90

Johnson, E.V.: PS+AS+EM+SS-MoM2, 85

Johnson, G.E.: SS+AS+BI+MI+NS-ThA11, 158

Johnson, J.W.: EM+2D+SS-WeA9, 137

Johnson, M.: AS-ThP10, 160

Johnson, M.J.: PS+PB+SE-TuA1, 113;
PS+PB+SE-TuA7, 113; PS-TuP16, 119

Johnson, S.D.: PS+EM+TF-ThA8, 157; TF-
ThP38, 163

Johnson, W.: VT-WeM1, 131

Johnston, S.: AS-MoA1, 89

Johs, B.: EL-TuP2, 118

Joi, A.: TF+EM+MI-WeM12, 131

Jochi, A.: TF-ThP28, 163

Jonas, S.: NS-ThP15, 162

Jones, A.: EM-ThP13, 161

Jones, T.E.: PC+AS+BI+EM+NS+PB+SS-TuA7,
112

Jong, C.-A.: 2D-ThP1, 160

Jonker, B.T.: 2D+EM+MI+MN+NS-TuA1, 109;
2D+EM+MN+NS-ThA1, 152;

Jardine, A.: HI-ThA3, 155

Jarvis, K.L.: SE-TuP5, 120

Javier, A.: HC+SS-TuA1, 111

Jawaid, A.: EM+AN+MI+SS-WeM12, 126

Jayawardena, I.: NS+MN+PC+SS-WeA4, 139

Jeckell, Z.K.: PS+PB+SE-TuA9, 113

Jenkins, T.G.: PS-FrM12, 169

Jensen, B.D.: MN+2D+AN+NS-WeA11, 138

Jeon, H.: 2D+EM+MN+NS-ThA10, 152

Jeong, C.Y.: TF-ThP7, 163

Jeong, G.-H.: PS-TuP27, 119; TF-ThP36, 163

Jeong, H.: HC-ThP1, 161

Jeong, H.H.: PS+EM-WeM11, 129

Jeong, S.I.: MS-TuP1, 118

Jeong, W.H.: RM-TuP1, 120

Jeong, Y.H.: MI+EM-FrM8, 168

Jeremiason, J.D.: TF-MoA8, 95

Jernigan, G.: 2D+MN+NS+SS-WeA11, 134

Jesse, S.: AM+NS+SS-WeM10, 125; HI+AS-
ThM4, 147; MM+AS+NS+PC-MoM8, 83; NS-
ThP19, 162

Jevric, M.: SS+AS+EM-WeA9, 141

Jewell, A.D.: TF+EM+MI-WeA3, 141

Jhang, J.-H.: 2D+EM+MI+MN+NS+SS-ThM2,
144; SS+HC-WeM12, 130

Ji, A.R.: PS+EM-WeM11, 129

Jia, H.: MN+2D+AN+NS-ThA3, 156

Jia, M.: PC+AS+BI+NS+PB+SS-TuM10, 102

Jia, Z.: MP+EM+MN+NS-MoM9, 84

Jiang, H.: EL+EM-MoA10, 90

Jiang, N.: NS+AM+MI+MN+SS+TR-TuA3, 112;
NS-ThP1, 162

Jiang, T.: HC+SS-TuM2, 100

Jiang, Z.T.: SE+NS+TF-MoM5, 86; SE+PS-
TuM4, 104

Jimenez, C.J.: SA+AS+MI-WeA9, 140

Jinka, O.: MP+AM+EM+NS-MoA5, 92;
MP+EM+MN+NS-MoM5, 84

Jo, C.: HC-ThP2, 161

Jo, S.-I.: PS-TuP27, 119; TF-ThP36, 163

Job, N.: PS+EM+NS+SS-TuA7, 113

Jobst, J.: 2D+MI+NS-MoA8, 89

Joe, G.: SS+HC+MI-TuA12, 115

Johansson, L.I.: 2D+EM+MN+NS-FrM5, 167

Johansson, M.V.: VT-MoM6, 88

Johansson, P.K.: BI+AS+IPF+MN-MoA4, 90

John, S.: TF+AS+EL+EM+NS+PS+SS-ThA8, 159

Johnson, A.: AS+BI-TuM3, 99

Johnson, B.I.: TF+AS+EL+PS-ThM5, 151

Johnson, C.P.: BI+AS+IPF+MN-MoA3, 90

Johnson, E.V.: PS+AS+EM+SS-MoM2, 85

Johnson, G.E.: SS+AS+BI+MI+NS-ThA11, 158

Johnson, J.W.: EM+2D+SS-WeA9, 137

Johnson, M.: AS-ThP10, 160

Johnson, M.J.: PS+PB+SE-TuA1, 113;
PS+PB+SE-TuA7, 113; PS-TuP16, 119

Johnson, S.D.: PS+EM+TF-ThA8, 157; TF-
ThP38, 163

Johnson, W.: VT-WeM1, 131

Johnston, S.: AS-MoA1, 89

Johs, B.: EL-TuP2, 118

Joi, A.: TF+EM+MI-WeM12, 131

Jochi, A.: TF-ThP28, 163

Jonas, S.: NS-ThP15, 162

Jones, A.: EM-ThP13, 161

Jones, T.E.: PC+AS+BI+EM+NS+PB+SS-TuA7,
112

Jong, C.-A.: 2D-ThP1, 160

Jonker, B.T.: 2D+EM+MI+MN+NS-TuA1, 109;
2D+EM+MN+NS-ThA1, 152;

Jardine, A.: HI-ThA3, 155

Jarvis, K.L.: SE-TuP5, 120

Javier, A.: HC+SS-TuA1, 111

Jawaid, A.: EM+AN+MI+SS-WeM12, 126

Jayawardena, I.: NS+MN+PC+SS-WeA4, 139

Jeckell, Z.K.: PS+PB+SE-TuA9, 113

Jenkins, T.G.: PS-FrM12, 169

Jensen, B.D.: MN+2D+AN+NS-WeA11, 138

Jeon, H.: 2D+EM+MN+NS-ThA10, 152

Jeong, C.Y.: TF-ThP7, 163

Jeong, G.-H.: PS-TuP27, 119; TF-ThP36, 163

Jeong, H.: HC-ThP1, 161

Jeong, H.H.: PS+EM-WeM11, 129

Jeong, S.I.: MS-TuP1, 118

Jeong, W.H.: RM-TuP1, 120

Jeong, Y.H.: MI+EM-FrM8, 168

Jeremiason, J.D.: TF-MoA8, 95

Jernigan, G.: 2D+MN+NS+SS-WeA11, 134

Jesse, S.: AM+NS+SS-WeM10, 125; HI+AS-
ThM4, 147; MM+AS+NS+PC-MoM8, 83; NS-
ThP19, 162

Jevric, M.: SS+AS+EM-WeA9, 141

Jewell, A.D.: TF+EM+MI-WeA3, 141

Jhang, J.-H.: 2D+EM+MI+MN+NS+SS-ThM2,
144; SS+HC-WeM12, 130

Ji, A.R.: PS+EM-WeM11, 129

Jia, H.: MN+2D+AN+NS-ThA3, 156

Jia, M.: PC+AS+BI+NS+PB+SS-TuM10, 102

Jia, Z.: MP+EM+MN+NS-MoM9, 84

Jiang, H.: EL+EM-MoA10, 90

Jiang, N.: NS+AM+MI+MN+SS+TR-TuA3, 112;
NS-ThP1, 162

Jiang, T.: HC+SS-TuM2, 100

Jiang, Z.T.: SE+NS+TF-MoM5, 86; SE+PS-
TuM4, 104

Jimenez, C.J.: SA+AS+MI-WeA9, 140

Jinka, O.: MP+AM+EM+NS-MoA5, 92;
MP+EM+MN+NS-MoM5, 84

Jo, C.: HC-ThP2, 161

Jo, S.-I.: PS-TuP27, 119; TF-ThP36, 163

Job, N.: PS+EM+NS+SS-TuA7, 113

Jobst, J.: 2D+MI+NS-MoA8, 89

Joe, G.: SS+HC+MI-TuA12, 115

Johansson, L.I.: 2D+EM+MN+NS-FrM5, 167

Johansson, M.V.: VT-MoM6, 88

Johansson, P.K.: BI+AS+IPF+MN-MoA4, 90

John, S.: TF+AS+EL+EM+NS+PS+SS-ThA8, 159

Johnson, A.: AS+BI-TuM3, 99

Johnson, B.I.: TF+AS+EL+PS-ThM5, 151

Johnson, C.P.: BI+AS+IPF+MN-MoA3, 90

Johnson, E.V.: PS+AS+EM+SS-MoM2, 85

Johnson, G.E.: SS+AS+BI+MI+NS-ThA11, 158

Johnson, J.W.: EM+2D+SS-WeA9, 137

Johnson, M.: AS-ThP10, 160

Johnson, M.J.: PS+PB+SE-TuA1, 113;
PS+PB+SE-TuA7, 113; PS-TuP16, 119

Johnson, S.D.: PS+EM+TF-ThA8, 157; TF-
ThP38, 163

Johnson, W.: VT-WeM1, 131

Johnston, S.: AS-MoA1, 89

Johs, B.: EL-TuP2, 118

Joi, A.: TF+EM+MI-WeM12, 131

Jochi, A.: TF-ThP28, 163

Jonas, S.: NS-ThP15, 162

Jones, A.: EM-ThP13, 161

Jones, T.E.: PC+AS+BI+EM+NS+PB+SS-TuA7,
112

Jong, C.-A.: 2D-ThP1, 160

Jonker, B.T.: 2D+EM+MI+MN+NS-TuA1, 109;
2D+EM+MN+NS-ThA1, 152;

Jardine, A.: HI-ThA3, 155

Jarvis, K.L.: SE-TuP5, 120

Javier, A.: HC+SS-TuA1, 111

Jawaid, A.: EM+AN+MI+SS-WeM12, 126

Jayawardena, I.: NS+MN+PC+SS-WeA4, 139

Jeckell, Z.K.: PS+PB+SE-TuA9, 113

Jenkins, T.G.: PS-FrM12, 169

Jensen, B.D.: MN+2D+AN+NS-WeA11, 138

Jeon, H.: 2D+EM+MN+NS-ThA10, 152

Jeong, C.Y.: TF-ThP7, 163

Jeong, G.-H.: PS-TuP27, 119; TF-ThP36, 163

Jeong, H.: HC-ThP1, 161

Jeong, H.H.: PS+EM-WeM11, 129

Jeong, S.I.: MS-TuP1, 118

Jeong, W.H.: RM-TuP1, 120

Jeong, Y.H.: MI+EM-FrM8, 168

Jeremiason, J.D.: TF-MoA8, 95

Jernigan, G.: 2D+MN+NS+SS-WeA11, 134

Jesse, S.: AM+NS+SS-WeM10, 125; HI+AS-
ThM4, 147; MM+AS+NS+PC-MoM8, 83; NS-
ThP19, 162

Jevric, M.: SS+AS+EM-WeA9, 141

Jewell, A.D.: TF+EM+MI-WeA3, 141

Jhang, J.-H.: 2D+EM+MI+MN+NS+SS-ThM2,
144; SS+HC-WeM12, 130

Ji, A.R.: PS+EM-WeM11, 129

Jia, H.: MN+2D+AN+NS-ThA3, 156

Jia, M.: PC+AS+BI+NS+PB+SS-TuM10, 102

Jia, Z.: MP+EM+MN+NS-MoM9, 84

Jiang, H.: EL+EM-MoA10, 90

Jiang, N.: NS+AM+MI+MN+SS+TR-TuA3, 112;
NS-ThP1, 162

Jiang, T.: HC+SS-TuM2, 100

Jiang, Z.T.: SE+NS+TF-MoM5, 86; SE+PS-
TuM4, 104

Jimenez, C.J.: SA+AS+MI-WeA9, 140

Jinka, O.: MP+AM+EM+NS-MoA5, 92;
MP+EM+MN+NS-MoM5, 84

Jo, C.: HC-ThP2, 161

Jo, S.-I.: PS-TuP27, 119; TF-ThP36, 163

Job, N.: PS+EM+NS+SS-TuA7, 113

Jobst, J.: 2D+MI+NS-MoA8, 89

Joe, G.: SS+HC+MI-TuA12, 115

Johansson, L.I.: 2D+EM+MN+NS-FrM5, 167

Johansson, M.V.: VT-MoM6, 88

Johansson, P.K.: BI+AS+IPF+MN-MoA4, 90

John, S.: TF+AS+EL+EM+NS+PS+SS-ThA8, 159

Johnson, A.: AS+BI-TuM3, 99

Johnson, B.I.: TF+AS+EL+PS-ThM5, 151

Johnson, C.P.: BI+AS+IPF+MN-MoA3, 90

Johnson, E.V.: PS+AS+EM+SS-MoM2, 85

Johnson, G.E.: SS+AS+BI+MI+NS-ThA11, 158

Johnson, J.W.: EM+2D+SS-WeA9, 137

Johnson, M.: AS-ThP10, 160

Johnson, M.J.: PS+PB+SE-TuA1, 113;
PS+PB+SE-TuA7, 113; PS-TuP16, 119

Johnson, S.D.: PS+EM+TF-ThA8, 157; TF-
ThP38, 163

Johnson, W.: VT-WeM1, 131

Johnston, S.: AS-MoA1, 89

Johs, B.: EL-TuP2, 118

Joi, A.: TF+EM+MI-WeM12, 131

Jochi, A.: TF-ThP28, 163

Jonas, S.: NS-ThP15, 162

Jones, A.: EM-ThP13, 161

Jones, T.E.: PC+AS+BI+EM+NS+PB+SS-TuA7,
112

Jong, C.-A.: 2D-ThP1, 160

Jonker, B.T.: 2D+EM+MI+MN+NS-TuA1, 109;
2D+EM+MN+NS-ThA1, 152;

Jardine, A.: HI-ThA3, 155

Jarvis, K.L.: SE-TuP5, 120

Javier, A.: HC+SS-TuA1, 111

Jawaid, A.: EM+AN+MI+SS-WeM12, 126

Jayawardena, I.: NS+MN+PC+SS-WeA4, 139

Jeckell, Z.K.: PS+PB+SE-TuA9, 113

Jenkins, T.G.: PS-FrM12, 169

Jensen, B.D.: MN+2D+AN+NS-WeA11, 138

Jeon, H.: 2D+EM+MN+NS-ThA10, 152

Jeong, C.Y.: TF-ThP7, 163

Jeong, G.-H.: PS-TuP27, 119; TF-ThP36, 163

Jeong, H.: HC-ThP1, 161

Jeong, H.H.: PS+EM-WeM11, 129

Jeong, S.I.: MS-TuP1, 118

Jeong, W.H.: RM-TuP1, 120

Jeong, Y.H.: MI+EM-FrM8, 168

Jeremiason, J.D.: TF-MoA8, 95

Jernigan, G.: 2D+MN+NS+SS-WeA11, 134

Jesse, S.: AM+NS+SS-WeM10, 125; HI+AS-
ThM4, 147; MM+AS+NS+PC-MoM8, 83; NS-
ThP19, 162

Jevric, M.: SS+AS+EM-WeA9, 141

Jewell, A.D.: TF+EM+MI-WeA3, 141

Jhang, J.-H.: 2D+EM+MI+MN+NS+SS-ThM2,
144; SS+HC-WeM12, 130

Ji, A.R.: PS+EM-WeM11, 129

Jia, H.: MN+2D+AN+NS-ThA3, 156

Jia, M.: PC+AS+BI+NS+PB+SS-TuM10, 102

Jia, Z.: MP+EM+MN+NS-MoM9, 84

Jiang, H.: EL+EM-MoA10, 90

Jiang, N.: NS+AM+MI+MN+SS+TR-TuA3, 112;
NS-ThP1, 162

Jiang, T.: HC+SS-TuM2, 100

Jiang, Z.T.: SE+NS+TF-MoM5, 86; SE+PS-
TuM4, 104

Jimenez, C.J.: SA+AS+MI-WeA9, 140

Jinka, O.: MP+AM+EM+NS-MoA5, 92;
MP+EM+MN+NS-MoM5, 84

Jo, C.: HC-ThP2, 161

Jo, S.-I.: PS-TuP27, 119; TF-ThP36, 163

Job, N.: PS+EM+NS+SS-TuA7, 113

Jobst, J.: 2D+MI+NS-MoA8, 89

Joe, G.: SS+HC+MI-TuA12, 115

Johansson, L.I.: 2D+EM+MN+NS-FrM5, 167

Johansson, M.V.: VT-MoM6, 88

Johansson, P.K.: BI+AS+IPF+MN-MoA4, 90

John, S.: TF+AS+EL+EM+NS+PS+SS-ThA8, 159

Johnson, A.: AS+BI-TuM3, 99

Johnson, B.I.: TF+AS+EL+PS-ThM5, 151

Johnson, C.P.: BI+AS+IPF+MN-MoA3, 90

Johnson, E.V.: PS+AS+EM+SS-MoM2, 85

Johnson, G.E.: SS+AS+BI+MI+NS-ThA11, 158

Johnson, J.W.: EM+2D+SS-WeA9, 137

Johnson, M.: AS-ThP10, 160

Johnson, M.J.: PS+PB+SE-TuA1, 113;
PS+PB+SE-TuA7, 113; PS-TuP16, 119

Johnson, S.D.: PS+EM+TF-ThA8, 157; TF-
ThP38, 163

Johnson, W.: VT-WeM1, 131

Johnston, S.: AS-MoA1, 89

Johs, B.: EL-TuP2, 118

Joi, A.: TF+EM+MI-WeM12, 131

Jochi, A.: TF-ThP28, 163

Jonas, S.: NS-ThP15, 162

Jones, A.: EM-ThP13, 161

Jones, T.E.: PC+AS+BI+EM+NS+PB+SS-TuA7,
112

Jong, C.-A.: 2D-ThP1, 160

Jonker, B.T.: 2D+EM+MI+MN+NS-TuA1, 10

Author Index

Jourdan, G.: MN+2D+AN+NS-ThA4, 156; MN+NS+PS-WeM10, 127

Julien, S.: SS+EM+NS-ThM4, 150

Julsgaard, B.: TF-ThP34, 163

Juluri, R.: TF-ThP34, 163

Jung Hwan, Y.: TF+EM+MI+PS-MoA3, 95

Jung, C.H.: HC-ThP2, 161

Jung, D.: MN-ThP7, 162; MN-ThP8, **162**

Jung, H.: HC-ThP1, 161; NS+AM+AS+MN+PC+PS+SS+TR-FrM6, 169; TF-ThP41, 164

Jung, H.Y.: TF-ThP37, 163

Jung, M.H.: MI+EM-FrM8, 168

Jung, S.H.: MN-ThP4, 162

Jung, Y.: HC+SS-TuA9, 111; SS+HC-MoA6, **94**

Jur, J.S.: TF+AS+EL+EM+NS+PS+SS-ThA10, **159**

Jurczyk, B.E.: SS+EM+PS+TF-ThA9, 159

Juurlink, L.B.F.: HC+SS-WeA2, 137; SS-TuP5, **120**

— K —

Kaden, W.E.: SS-TuP10, 120; SS-TuP7, 120

Kahng, S.-J.: NS+AM+MI+MN+SS+TR-TuA10, 112

Kalanyan, B.: TF1-MoM8, 87

Kalinin, S.V.: 2D+AM+EM+NS-WeM11, 124; AM+NS+SS-WeM10, 125; HI+AS-ThM4, 147; NS-ThP19, **162**

Kalscheue, J.L.: BI-TuP9, 118

Kaltsoyannis, N.: AC+MI+SA-FrM1, **167**

Kamataki, K.: PS+EM+NS+SS-TuA8, 113

Kambham, A.: PS+AS+EL+EM+SE-WeM6, **129**

Kaminsky, J.: PS+EM-WeA1, 140

Kampen, T.U.: 2D+EM+MI+MN+NS+SS-ThM10, 144

Kanarik, K.J.: PS+EM+TF-ThA4, **157**

Kanatzidis, M.: 2D+EM+MI+NS-TuM2, 99

Kanazawa, K.: VT-TuP4, 121; VT-TuP6, 121

Kandel, A.S.A.: SS+HC+MI-MoM5, 86

Kandel, S.A.: PC+AS+BI+EM+NS+PB+SS-TuA12, 112

Kane, D.: TF+PS-ThM1, **151**

Kaneko, T.: PS+EM+SE-TuM10, 103

Kang, C.-Y.: TF-TuM3, 106

Kang, G.: TF1-MoM1, 87

Kang, I.H.: EM+2D+SS-WeA4, 137

Kang, J.H.: HC+SS-TuA2, **111**

Kang, J.J.: SS-TuP13, 120

Kang, M.: AS-ThP8, 160

Kang, M.S.: TF-ThP14, 163

Kang, S.W.: HC-ThP1, 161

Kang, T.-H.: 2D+MN+NS+SS-WeA3, **134**

Kanno, D.: PS+PB-TuM11, 103

Kapadia, R.: EM+MP+PS-MoM2, 82; RM+EM+NS-TuA9, 114; SS+AS+EM-WeA11, 141

Kaplar, R.J.: EM+2D+SS-WeA11, 137; EM-ThP11, 161

Kapoor, A.: AS+NS-ThA2, 153

Karabashi, K.: PS+EM+NS+SS-TuA12, **113**; PS+EM+TF-ThA1, 157; PS+EM+TF-ThM4, 149; PS-FrM6, 169

Karandikar, P.: NS+AN+EM+MI+MN+MP+PS+RM-ThM2, **148**

Karar, N.: AS-MoA5, **89**

Karki, K.: MM+AS+NS+PC+SS-MoA8, 92

Karwal, S.: PS+TF-MoM2, 85; TF-TuM5, 106

Kasai, H.: SS+HC-MoA4, 94

Kashid, R.: AM+MP+NS-WeA7, **135**

Kaspar, T.C.: PC+AS+BI+EM+NS+PB+SS-TuP5, **119**

Kato, T.: PS+EM+SE-TuM10, **103**; SS+AS+HC-FrM7, **170**

Kats, M.: SS+HC+MI-TuA12, 115

Katsouras, I.: TF+AS+EL+EM+NS+PS+SS-ThA9, 159

Kattel, S.: HC+SS-TuM3, 100

Katz, M.: EM+MP+PS-MoM6, 82

Katzer, D.S.: TF+EM+MI-WeM1, 131

Kaufman, G.: EL-TuP2, 118

Kavanagh, K.L.: AS+SE-ThM13, 145; SS-TuP9, 120

Kavrik, M.: EM+AM+NS+PS-MoA10, 91; EM+MP+PS-MoM1, 82; EM+MP+PS-MoM5, **82**; EM+MP+PS-MoM6, 82

Kawai, M.: BI-ThM12, 145

Kawakami, R.: 2D+EM+MN+NS-ThA3, **152**

Kawamura, K.: PS+EM+TF-ThA3, 157; PS+EM+TF-ThM3, 149

Kawamura, M.: TF-ThP2, 163; TF-ThP7, 163

Kawano, T.: AC+AS+SA-ThM5, 144

Kawasaki, J.: PS+AS+EL+EM+SE-WeM5, **129**

Kay, B.D.: HC+SS-WeM1, 126

Kaya, I.: AS+BI-TuM4, 99

Kayser, B.: NS+2D+AS+MN+PC-ThA3, 156

Kayser, S.: AS+SE-WeA1, 135

Kazemi, A.: EL-TuP3, 118

Ke, W.: HC+SS-ThM10, 146

Keene, S.T.: RM-TuP3, 120

Kelloci, M.: MN+2D+AN+NS-WeA3, 138

Kelley, M.: AC-ThA1, 152

Kellogg, S.: HI-ThA6, 155

Kelly, D.: EW-WeL4, **133**

Kenney, J.A.: PS-FrM2, 169

Kenny, J.: PS+EM+SE-TuM3, 103

Kent, A.: MI+2D+EM+NS-MoA3, **91**

Kepaptsoglou, D.: AM+NS+SS-WeM12, **125**

Kephart, J.: EM+2D+AN+MI+MP+NS-TuA3, 110

Kerlin, M.G.: AC+AS+SA-WeA7, 134

Kern, C.: BI+AS+NS-FrM6, 168

Kern, K.: HC+SS-TuM11, 100; NS+2D+AS+MN+PC-ThA8, 156; NS+AM+AS+MN+PC+PS+SS+TR-FrM4, 169

Kerstetter, L.: EM+AM+NS+PS-MoA8, 91

Kessels, W.M.M.: PS+TF-MoM2, 85; SS+EM+NS-ThM12, 150; TF+AS+EL+EM+NS+PS+SS-ThA6, **159**; TF2-MoM1, 87; TF-MoA3, 95; TF-TuM10, 106; TF-TuM13, 106; TF-TuM5, 106

Kessler, Y.: NS+2D+AN+MN+MP+SE-WeM6, 128

Khalaf, A.: BI-TuP11, 118

Khan, A.A.: BI+AS+IPF+NS-TuA7, 110

Khanal, M.P.: EM-ThP18, **161**

Khaniya, A.: SS-TuP7, **120**

Khatiwada, D.: TF-MoA4, **95**

Kiba, T.: TF-ThP2, 163; TF-ThP7, 163

Kibel, M.H.: AS+NS-ThA1, **153**

Kikkawa, F.: PS+PB-TuM11, 103

Kikuchi, T.: PS+TF-MoM10, 85

Kikuchi, Y.: PS+EM-WeA10, 140

Kikuchi, Y.K.: SS+HC+NS+PS-TuM11, **104**

Kilcoyne, A.L.D.: AC+AS+SA-ThM10, 144

Kilic, U.: EL+AS+EM-MoM3, **82**

Killelea, D.R.: HC+SS-TuA17, 111; HC-ThP6, 161

Kilner, J.A.: AS+SE-ThM1, **145**

Kim, C.S.: HC-ThP1, 161

Kim, E.: MP+EM+MN+NS-MoM8, 84

Kim, G.-H.: PS-ThA10, 157; PS-ThA11, 157

Kim, H.: 2D+EM+MI+MN+NS-TuA7, 109; NS+2D+AS+MN+PC-ThA6, 156; NS+AM+MI+MN+SS+TR-TuA10, 112; PS+PB+SE-TuA11, 113

Kim, H.J.: EM+AN+MI+SS-WeM3, **126**

Kim, H.-L.: TF-ThP41, 164

Kim, H.S.: TF+AS+EL+PS-ThM13, **151**; TF1-MoM9, 87

Kim, H.T.: AS-ThP12, 160

Kim, H.W.: EM+2D+SS-WeA4, 137

Kim, H.Y.: HC-ThP2, 161

Kim, I.: TF+AS+EL+EM+NS+PS+SS-ThA10, **159**

Kim, I.T.: 2D+MN+NS+SS-WeA4, 134

Kim, J.: EM+2D+AN+MI+MP+NS-TuA11, 110; EM-ThP14, 161; MP+EM+MN+NS-MoM10, **84**; MP+EM+MN+NS-MoM9, 84; MS-TuP2, 118; PS+AS+EL+EM+SE-WeM3, 129; SS-TuP3, 120; TF+AS+EL+PS-ThM13, 151; TF1-MoM9, 87; TF-ThP41, **164**

Kim, J.H.: EM+2D+SS-WeA4, 137; EM+2D+SS-WeA9, 137; SS-TuP13, 120; TF-ThP14, **163**

Kim, J.K.: MN-ThP7, 162; MN-ThP8, 162

Kim, J.S.: NS+2D+AS+MN+PC-ThA6, 156

Kim, J.T.: TF-ThP40, 163

Kim, J.Y.: BI-TuP10, **118**

Kim, K.B.: MS-TuP1, **118**; SS-TuP13, 120

Kim, K.H.: BI-TuP2, **118**; TF-ThP2, 163; TF-ThP7, 163

Kim, K.I.: HI-ThA4, **155**

Kim, K.S.: MS-TuP1, 118

Kim, K.E.: MI+EM-FrM8, 168

Kim, M.: HC+SS-WeA1, **137**; HC+SS-WeM10, 126; MN+2D+AN+NS-WeA9, 138

Kim, M.J.: EM-ThP14, 161

Kim, N.Y.: NS+AM+MI+MN+SS+TR-TuA10, 112

Kim, P.K.: SS+EM+PS+TF-ThA7, 159

Kim, R.: EM+2D+NS+PS+RM+TF-ThA3, 154; EM+AN+MI+SS-WeM12, 126

Kim, S.: 2D+EM+MN+NS-FrM7, **167**; 2D-ThP6, 160; HI+AS-ThM1, 147; HI+AS-ThM4, 147; TF-ThP40, 163; TF-ThP41, 164

Kim, S.G.: PS-TuP12, **119**; TF+EM+MI-WeM11, 131

Kim, S.H.: NS+AM+AS+MN+PC+PS+SS+TR-FrM6, **169**; TF-ThP37, 163

Kim, S.-H.: PS-TuP22, 119

Kim, S.J.: TF+AS+EL+PS-ThM13, 151

Kim, S.K.: TF-TuM3, **106**

Kim, T.H.: VT-TuP5, 121

Kim, T.-H.: NS+AM+MI+MN+SS+TR-TuA4, 112

Kim, TH.: PS+EM+NS+SS-TuA3, **113**

Kim, Y.: EM+2D+AN+MI+MP+NS-TuA11, 110; PS+AS+EL+EM+SE-WeM3, 129; RM-TuP1, **120**; TF+EM+MI-WeM11, 131

Kim, Y.H.: HI-ThA4, 155

Kim, Y.-H.: NS+AM+MI+MN+SS+TR-TuA10, 112

Kim, Y.K.: HC-ThP2, 161

Kim, Y.S.: MS-TuP1, 118; MS-TuP2, **118**; TF-ThP39, 163; TF-ThP8, 163; TF-ThP9, 163

Kimbrough, J.: EM-ThP7, 161; NS-ThP6, **162**

Kimmel, G.A.: SS+AS+EM-WeA12, 141; SS+HC+MI-TuA10, **115**

Kindlund, H.: SE+NS+TF-MoM8, **86**

Kindsmüller, A.: SA+AS+HC+SS-ThA7, 158

King, S.T.: EM-ThP20, **161**

King, S.W.: PS+EM-WeA11, 140; PS+EM-WeA2, 140; SE-TuP3, 120

Kintz, J.: AS-ThP10, 160

Kirby, B.J.: MI+2D-ThM12, 147

Kirilin, A.V.: HC+SS-TuA2, 111

Kishi, Y.: PS+AS+EM+SS-MoM3, 85

Kiskinova, M.: SA-ThP5, **163**

Kitamoto, S.: PS-TuP29, **119**

Kiuchi, M.: PS+EM+TF-ThA1, 157

Kivuti, E.M.: MS+MN-TuA3, **111**

Kjaer Kristensen, P.: TF-ThP34, 163

Kjaervik, M.: PC+AS+BI+EM+NS+PB+SS-TuA1, 112

Klauck, H.: NS+AM+AS+MN+PC+PS+SS+TR-FrM4, 169

Klein, B.: EM+2D+SS-WeA11, 137; EM-ThP11, 161; EM-ThP13, 161

Author Index

Klein, P.: EM+2D+AN+MI+MP+NS-TuA10, 110
 Klein, P.B.: EM+2D+AN+MI+MP+NS-TuA11, 110
 Klemberg-Sapieha, J.: PS+PB-MoA10, **93**
 Klicpera, M.: AC+MI+SA-WeM12, 124
 Klimov, N.N.: NS+AN+EM+MN+MP+RM-TuM12, 102
 Klinger, C.: BI-ThA3, 153
 Klingner, N.: HI+AS-ThM12, **147**
 Knapper, K.A.: NS+AN+EM+MN+MP+RM-TuM5, 102
 Knight, K.B.: AC+AS+SA-ThM12, 144
 Knight, S.: EL+EM-MoA1, 90
 Knisely, K.E.: MS+MI+RM-TuM1, 101
 Knoops, H.C.M.: PS+TF-MoM2, 85; TF-TuM5, **106**
 Knope, K.: AC-ThA6, **152**
 Knop-Gericke, A.: PC+AS+BI+EM+NS+PB+SS-TuA7, **112**
 Knuffman, A.B.J.: HI-ThP2, 161
 Knuffman, B.J.: HI-ThP2, 161
 Ko, A.: PS-TuP1, 119
 Ko, H.C.: PC+AS+BI+NS+PB+SS-TuM11, 102
 Ko, K.-T.: MI+EM-FrM8, 168
 Ko, W.: NS+2D+AS+MN+PC-ThA6, **156**; PS+EM+SE-TuM4, 103
 Kobata, T.: VT-TuP7, 121
 Kobayashi, H.: PS+EM+TF-ThA3, 157; PS+EM+TF-ThM3, 149
 Koch, S.: 2D+EM+MI+MN+NS+SS-ThM11, 144
 Kodambaka, S.: SE+NS+TF-MoM3, 86; SE-MoA3, **94**; SS+EM+PS+TF-ThA3, 159
 Kodan, N.: HC-ThP5, **161**
 Koebel, J.: NS-ThP12, 162
 Koehl, M.: AC+AS+SA-ThM5, 144
 Koel, B.E.: SS+AS+EM-WeA3, 141; SS+HC+MI-TuA4, **115**
 Koenraad, P.M.: TF+AS+EL+EM+NS+PS+SS-ThA6, 159
 Kofuji, N.: PS+EM-WeM12, 129
 Koga, K.: PS+EM+NS+SS-TuA8, **113**
 Kogan, A.: AC+AS+SA-ThM3, 144
 Koh, T.: PS-FrM8, 169
 Kohse-Höninghaus, K.: HI+AS-ThM10, 147
 Kolagani, S.H.: NS-ThP14, 162
 Kölking, S.: TF+AS+EL+EM+NS+PS+SS-ThA6, 159
 Kollmer, F.: AS+NS-ThA6, 153
 Kolmakov, A.: MM+AS+NS+PC+SS-MoA10, 92; MM+AS+NS+PC+SS-MoA4, 92; MM+AS+NS+PC-MoM10, 83; RM-TuP2, 120
 Kolomiets, A.: AC+MI+SA-WeM11, 124
 Kolozsvári, S.: SE-TuA11, 114
 Kolsbjergr, E.L.: SS+HC+MI-MoM4, 86
 Komorek, R.: BI+AS+IPF+MN-MoA8, 90; BI-WeA11, 136; PC+AS+BI+EM+PB+SS-WeM3, **128**
 Komsa, H.: 2D+AM+EM+NS-WeM6, 124
 Kondo, H.: PS+AS+EM+SS-MoM11, 85; PS+EM+SE-TuM13, 103
 Kondo, T.: HC+SS-WeA7, 137
 Konduusamy, A.L.N.: TF1-MoM9, **87**
 Kong, W.: SS+AS+HC-FrM5, 170
 Konh, M.: SS+AS+EM-WeA8, 141; SS-TuP2, **120**
 Koo, J.: PS-ThA11, 157
 Koo, T.Y.: MI+EM-FrM8, 168
 Koo, Y.: TF-ThP15, 163
 Kooi, S.E.: NS-ThP5, **162**
 Korde, M.: EL+EM-MoA3, 90
 Korlacki, R.: EL+AS+EM-MoM3, 82; EL+EM-MoA1, 90
 Korzett, R.: 2D+EM+MI+MN+NS+SS-ThM11, 144
 Koster, N.B.: VT-MoM10, 88
 Köster, S.A.: AM+MP+NS-WeA11, 135
 Kostko, O.: PC+AS+BI+NS+PB+SS-TuM12, 102
 Kotakoski, J.: AM+NS+SS-WeM12, 125
 Kotler, Z.: NS+AN+EM+MI+MN+MP+PS+RM-ThM1, 148
 Kotru, S.: MN-ThP6, 162
 Koury, M.: AS-ThP10, 160
 Koushik, D.: TF-MoA3, **95**
 Koust, S.: SS+HC+MI-MoM4, 86
 Kouzuma, Y.: PS+EM+TF-ThA3, 157
 Kozarashi, T.: HC+SS-WeA7, 137
 Kozen, A.C.: PS+EM+TF-ThA8, 157; PS+TF-MoM11, 85; PS-TuP16, 119; TF+EM+MI-WeM6, **131**; TF-ThP22, 163; TF-ThP38, 163
 Kozimor, S.A.: AC+AS+SA-WeA7, 134; AC-ThA3, 152
 Kraft, M.L.: AS+BI-TuM3, 99
 Kraft, U.: NS+AM+AS+MN+PC+PS+SS+TR-FrM4, 169
 Kragh, K.N.: SE-MoA9, 94
 Krakover, N.: NS+2D+AN+MN+MP+SE-WeM6, 128
 Krasheninnikov, A.V.: 2D+AM+EM+NS-WeM6, 124; HI-WeA9, 138
 Kraus, P.: PS-FrM8, 169
 Kraut, M.: EM+AN+MI+SS-WeM13, 126
 Kresin, V.V.: NS+2D+AN+EM+MN+MP+PC+RM-MoM10, 84; NS-ThP7, 162
 Kretschmer, S.: HI-WeA9, 138
 Kreuzer, H.J.: BI-WeA3, 136
 Krim, J.: AS-TuA4, 109
 Krishna, S.: EL-TuP3, 118
 Krishnan, A.: SS-TuP9, 120
 Krishnan, K.M.: MI+BI-ThA8, **155**
 Krogstad, D.V.: PS+PB+SE-TuA9, 113; PS+TF-MoM1, 85
 Krogstad, E.: AS+SE-WeA9, 135
 Krogstrup, P.: MM+AS+NS+PC-MoM6, 83
 Kroon, R.E.: TF+AS-TuM3, 105
 Kropman, D.: EM+AN+MI+SS-WeM5, **126**
 Krüger, P.: MI+EM-FrM7, 168
 Kruit, P.: HI-ThA6, 155
 Kruppe, C.M.: HC+SS-ThM3, 146
 Krylov, S.: NS+2D+AN+MN+MP+SE-WeM2, 128; NS+2D+AN+MN+MP+SE-WeM5, 128; NS+2D+AN+MN+MP+SE-WeM6, **128**; NS+AN+EM+MI+MN+MP+PS+RM-ThM1, 148
 Krzykawska, A.: TF+SS-TuA2, **116**
 Ku, H.S.: MP+AM+EM+NS-MoA6, 92; MP+EM+NS-TuM12, 101; MP+EM+NS-TuM3, 101; MP+EM+NS-TuM6, 101
 Kub, F.J.: EM+2D+AN+MI+MP+NS-TuA11, 110
 Kubota, H.: RM+EM+NS-TuA11, 114
 Kucheyev, S.O.: SA-ThP2, 162
 Kuchuk, K.: NS+MN+PC+SS-WeA7, 139
 Kucukgok, B.: TF-ThP31, 163
 Kuhlenbeck, H.: SA+AS+HC+SS-ThA6, 158
 Kühn, T.-J.: MM-TuP2, 118
 Kuhnke, K.: NS+2D+AS+MN+PC-ThA8, 156
 Kuk, Y.: 2D+EM+MN+NS-ThA10, 152; 2D-ThP6, 160
 Kullgren, J.: HC+SS-ThM12, 146
 Kumagai, Y.: EL+EM-MoA1, 90
 Kumah, D.P.: PS+AS+EL+EM+SE-WeM10, **129**
 Kumar, A.: TF+AS-TuM3, 105
 Kumar, P.: MP+EM+NS-TuM5, 101
 Kumari, S.: AC+MI+SA-WeM13, 124; SA+MI-ThM2, 150
 Kummel, A.C.: EM+2D+AN+MI+MP+NS-TuA12, 110; EM+AM+NS+PS-MoA10, 91; EM+AM+NS+PS-MoA2, 91; EM+MP+PS-MoM1, 82; EM+MP+PS-MoM6, **82**
 Kunal, P.: SS+HC-WeM3, 130
 Kunwar, D.: SS+HC+MI-TuA8, 115
 Kuo, C.-T.: SA+AS+MI-WeA1, 140
 Kuo, Y.: EM+AM+NS+PS-MoA6, **91**
 Kurahashi, M.: SS-TuP5, 120
 Kuramata, A.: EM+2D+SS-WeA2, 137
 Kurdi, G.: SA+MI-ThM5, 150
 Kurihara, M.: PS+EM+TF-ThA3, 157; PS+EM-WeM12, 129
 Kuroda, R.: TF+EM+MI-WeM5, 131
 Kurokawa, Y.: PS+PB-TuM11, 103
 Kushner, M.J.: PS+EM+SE-TuM4, **103**; PS+EM+SE-TuM6, 103; PS-ThM6, 149
 Kushto, G.: PS-TuP16, **119**
 Kuwahara, K.: PS+EM-WeM2, 129
 Kwan, I.J.: EM+2D+AN+MI+MP+NS-TuA12, **110**
 Kwak, S.-Y.: NS-ThP20, **162**
 Kwon, J.: NS-ThP21, **162**
 Kwon, J.: 2D+EM+MI+MN+NS-TuA2, **109**
 Kwon, J.-W.: PS-ThA10, 157
 Kwon, O.S.: BI-TuP1, 118
 Kwon, S.: VT-TuM1, 106
 Kwon, S.-H.: NS-ThP21, 162
 Kwon, T.S.: PS+EM-WeM11, 129
 Kyvala, L.: AC+MI+SA-FrM7, 167
— L —
 L. Raja, L.: PS+AS+EM+SS-MoM11, 85
 La Mendola, D.: BI-ThM11, 145; BI-ThM5, **145**
 Laas, T.: EM+AN+MI+SS-WeM5, 126
 Labyedh, N.: TF2-MoM1, 87
 Lagrasta, S.: PS+EM+SE-TuM12, 103; PS+EM-WeM1, 129
 Lai, J.C.Y.: PB+BI+PC+PS-WeA9, 139
 Lake, R.: MP+AM+EM+NS-MoA6, 92; MP+EM+MN+NS-MoM5, 84; MP+EM+NS-TuM12, **101**; MP+EM+NS-TuM3, 101; MP+EM+NS-TuM6, 101
 Lake, W.: EL-TuP1, **118**
 Lam, V.: BI+AC+AS+HC+NS+SS+TF-WeA7, 136
 Lamblin, G.: PS+PB-MoA5, 93
 Lambrick, S.: HI-ThA3, 155
 Lancaster, D.K.: TF+PS-TuA11, 115; TF-TuM2, 106
 Lanceros-Mendez, S.: BI-ThM6, 145
 Landälv, L.: SE+NS+TF-MoM11, 86
 Lane, B.: PS+AS+EM+SS-MoM11, 85; PS-ThA7, 157; PS-ThA9, 157; PS-ThM11, **149**
 Lanford, W.: PS+EM-WeA11, 140; PS+EM-WeA2, 140
 Lanham, S.J.: PS-ThM6, 149
 Lanza, G.: VT-TuM1, 106
 Laroussi, M.: PS+PB+SE-TuA12, 113
 Larrabee, T.J.: TF+EM+MI-WeM6, 131
 Larrude, D.G.: 2D-ThP4, 160
 Larsen, K.G.: 2D+EM+MI+NS-TuM3, **99**
 Larson, D.J.: TF+AS+EL+EM+NS+PS+SS-ThA6, 159
 Larson, S.: NS+2D+AN+EM+MN+MP+PC+RM-MoM4, **84**
 Larsson, K.M.E.: EM+AN+MI+SS-WeM13, **126**
 LaRue, J.L.: SS+HC+MI-MoM6, **86**
 Laschewsky, A.: BI-WeA9, 136
 Laturia, A.: EM-ThP14, 161
 Lau, J.: TF2-MoM3, 87
 Lauderbach, L.M.: SA+AS+HC+SS-ThA11, 158
 Laue, A.: TF+AS+EL+PS-ThM12, 151
 Lauritsen, J.V.: HC+SS-TuM11, **100**; SS+HC+MI-MoM4, 86; SS+HC+NS+PS-TuM5, 104; SS+HC-WeM6, 130

Author Index

Lauwaet, K.: SS+HC-WeM6, 130

LaVerne, J.A.: SS+HC+MI-TuA10, 115

Law, M.: EM+2D+AN+MI+MP+NS-TuA12, 110; SE+NS+TF-MoM2, 86

Lawrence, C.: EM+AM+NS+PS-MoA8, 91

Lawton, T.: BI+AS+IPF+NS-TuA10, 110

Lazzarino, F.: PS+EM-WeA9, 140

Le, D.: 2D+AM+EM+NS-WeM2, **124**; HC+SS-TuM2, 100; SS+EM+NS-ThM11, 150; SS+HC+MI-TuA7, 115

Le, S.: EM+2D+NS+PS+RM+TF-ThA4, 154

Lea, A.S.: NS+MN+PC+SS-WeA11, **139**

Leandersson, M.: 2D+EM+MN+NS-FrM5, 167

Leary, D.H.: BI-WeA7, 136

LeBlanc, G.: SS+AS+BI+MI+NS-ThA1, 158

Leduc, H.: TF-TuM6, 106

Lee,: SA+MI-ThM10, **150**

Lee, B.-J.: 2D+MN+NS+SS-WeA8, **134**

Lee, C.: HC+SS-TuM5, **100**

Lee, C.H.: 2D+EM+MI+MN+NS-TuA2, 109

Lee, C.-T.: MN-ThP2, 162; TF-ThP16, **163**

Lee, D.: TF-ThP15, 163

Lee, D.G.: AC-ThP2, **160**

Lee, E.G.: TF-ThP39, **163**; TF-ThP8, 163; TF-ThP9, 163

Lee, G.H.: 2D+AM+EM+NS-WeM3, **124**; 2D+EM+MI+MN+NS-TuA2, 109

Lee, H.: HC+SS-TuA9, 111; NS-ThP2, **162**

Lee, H.C.: PS-ThM3, **149**

Lee, H.S.: SS-TuP13, 120

Lee, H.-T.: HC-ThP1, 161

Lee, H.Y.: MS-TuP1, 118

Lee, J.: AS-ThP8, 160; BI-TuP5, **118**; SE-TuP4, **120**; SS+HC+NS+PS-TuM10, **104**; SS+HC+NS+PS-TuM6, 104; TF-ThP15, 163; TF-ThP8, 163; TF-ThP9, 163

LEE, J.B.: VT-TuP5, 121

Lee, J.H.: MI+EM-FrM8, 168; TF-ThP39, 163

Lee, J.K.: MS-TuP1, 118; TF-ThP18, **163**

Lee, J.M.: PS-ThA11, 157

Lee, J.-S.: MI+EM-FrM8, 168

Lee, J.W.: PS+EM-WeM11, **129**

Lee, J.Y.: 2D+EM+MI+MN+NS-TuA2, 109; BI-TuP2, 118; MN-ThP7, 162; MN-ThP8, 162; PS+EM-WeM11, 129

Lee, J.B.: BI-TuP4, **118**

Lee, K.: 2D+EM+MI+MN+NS-TuA7, 109

Lee, M.: 2D+EM+MN+NS-ThA10, **152**; EM+MP+PS-MoM6, 82

Lee, M.-S.: PC+AS+BI+EM+NS+PB+SS-TuP5, 119

LEE, N.K.: VT-TuP5, 121

Lee, P.: PS+EM-WeA3, 140

Lee, S.: BI-TuP6, **118**; EL+AS+EM-MoM11, 82; EM-ThP12, **161**; HC+SS-TuA9, 111; TF+AM+EM+PS-TuM6, 105; TF-TuM12, **106**

Lee, S.B.: TF2-MoM5, 87

Lee, S.-E.: TF-ThP39, 163; TF-ThP8, **163**; TF-ThP9, 163

Lee, S.G.: AC-ThP1, **160**

Lee, S.W.: 2D-ThP3, 160; HC+SS-TuA9, **111**; TF-ThP13, 163

Lee, SW.: PS+EM+NS+SS-TuA3, 113

Lee, T.-L.: SA+AS+MI-WeA1, 140

Lee, W.-J.: TF-ThP41, 164

Lee, W.-L.: AS-ThP10, 160

Lee, W.-S.: HC+SS-TuA2, 111

Lee, Y.: AS+NS-ThA8, 153; AS-ThP8, **160**; PS+EM+TF-ThA2, 157

Lee, Y.-J.: PS+EM-WeM5, 129

Leech, P.W.: AS+NS-ThA1, 153

Leem, J.: EM+2D+NS+PS+RM+TF-ThA3, 154

Leftwich, T.R.: SS+EM+NS-ThM10, 150

Leggett, G.J.: BI-ThM4, **145**

Legrand, B.: MN+NS+PS-WeM10, **127**

Legut, D.: AC+MI+SA-FrM7, **167**; AC+MI+SA-FrM9, 167; AC+MI+SA-WeM10, 124

Lehnardt, S.: 2D+EM+MI+NS-TuM3, 99

Lei, M.K.: SE+NS+TF-MoM5, 86; SE+PS-TuM4, 104; SE-TuA8, **114**

Lei, W.: NS+2D+AN+EM+MN+MP+PC+RM-MoM11, **84**

Leighton, C.: TF-MoA8, 95

Leite, M.: NS+AM+MI+MN+SS+TR-TuA7, **112**

Lenoble, D.: PC+AS+BI+EM+PB+SS-WeM10, 128; PS+PB-MoA5, 93

Leon, C.C.: NS+2D+AS+MN+PC-ThA8, 156

Leonard, D.: AS-ThP6, 160

Leou, K.C.: PS-TuP28, 119

Lercher, J.A.: HC+SS-WeM12, **126**

Leskela, M.A.: TF+AS-TuM12, **105**

Letourneau, S.: TF+PS-ThM3, 151; TF-ThP31, 163

Letton, J.: EM+2D+SS-WeA3, 137

Leusink, G.J.: EM+MP+PS-MoM8, 82

Leverd, F.: PS-FrM7, 169

Levitov, L.: 2D-ThP2, 160; NS+2D+AS+MN+PC-ThA4, 156

Lewandowski, C.: 2D-ThP2, 160; NS+2D+AS+MN+PC-ThA4, 156

Lewis, B.B.: AM+NS+SS-WeM3, 125; HI-WeA10, 138

Lewis, J.: TF+AS-TuM2, **105**

Lewis, R.: TF+EM+MI+PS-MoA8, 95

Ley, R.T.: EM+MI+MN+NS-ThM5, **146**

Lezama Pacheco, J.: AC+AS+SA-WeA7, 134

Lezec, H.J.: NS+AN+EM+MN+MP+RM-TuM3, 102

Li, A.-P.: NS+2D+AS+MN+PC-ThA6, 156; NS+AM+MI+MN+SS+TR-TuA9, 112

Li, B.: TF-ThP11, 163

Li, C.: BI+AS+IPF+NS-TuA11, 110; PB+BI+PC+PS-WeA11, 139; PS+EM+TF-ThM12, 149; SE-MoA8, 94; SS-TuP6, 120

Li, D.L.: TF-ThP11, 163

Li, F.: PS-TuP26, **119**

Li, H.: HI-WeA11, 138; MS+MI+RM-TuM10, 101; PS+AS+EM+SS-MoM4, **85**; PS+EM+NS+SS-TuA12, 113; PS-TuP2, 119; SS+HC-WeM3, 130

Li, J.: HC+SS-WeM2, 126

Li, J.P.H.: SS+HC+MI-TuA11, **115**

Li, J.-T.: PS-ThA3, 157

Li, K.: TF-MoA5, 95

Li, L.: NS+2D+AN+MN+MP+SE-WeM12, **128**; PS+EM-WeA2, 140

Li, L.J.: AS-ThP3, 160

Li, M.: HC+SS-ThA11, **154**; SS+AS+EM-WeA10, 141

Li, Q.: NS+2D+AN+EM+MN+MP+PC+RM-MoM11, **84**

Li, T.: SS+EM+NS-ThM5, 150

Li, X.: 2D+EM+MI+NS+TF-MoM5, 81; EM-ThP10, 161; PS-FrM1, **169**; PS-FrM11, 169

Li, Y.: EL+AS+EM-MoM11, 82; NS-ThP8, **162**; TF-MoA4, 95; VT-TuM4, **106**; VT-TuM5, 106

Li, Y.G.: SE+NS+TF-MoM5, **86**; SE-TuA8, 114

Li, Z.: EM-ThP16, 161; SS+AS+EM-WeA8, 141

Liang, L.: 2D+MN+NS+SS-WeA9, 134; NS+AM+MI+MN+SS+TR-TuA9, 112

Liang, X.: 2D+EM+MI+MN+NS+SS-ThM2, 144

Liang, Y.N.: AS+NS-ThA7, 153

Liao, I.: 2D+EM+MI+MN+NS-TuA11, 109

Liao, M.E.: SE+NS+TF-MoM3, 86

Liao, W.: MN+2D+AN+NS-ThA3, 156

Libuda, J.: SS+AS+EM-WeA9, **141**

Liddle, J.A.: NS+AN+EM+MI+MN+MP+PS+RM-ThM3, **148**

Ligaud, C.: NS-ThP10, 162

Lii-Rosales, A.: SS+EM+NS-ThM4, 150; SS-TuP1, **120**

Lill, T.B.: PS+EM+TF-ThA4, 157; PS+EM-WeA12, 140

Lillethorup, M.: TF+SS-TuA9, 116

Lilly, C.: BI-ThA9, 153

Lim, B.R.: PS+EM-WeM11, 129

Lim, D.M.: TF-ThP14, 163

Lim, E.T.: PS-TuP10, 119; PS-TuP11, **119**

Lim, J.: VT-TuP5, 121

Lim, J.Y.: VT-TuP12, **121**

Lim, K.-H.: TF-ThP39, 163; TF-ThP8, 163; TF-ThP9, 163

Lim, W.S.: MN-ThP4, **162**

Lin, A.: PS+PB-TuM5, 103

Lin, C.P.: PS-TuP25, **119**

Lin, C.-P.: 2D-ThP1, **160**

Lin, E.: EM+AM+NS+PS-MoA1, 91

Lin, H.: 2D+EM+MI+MN+NS+SS-ThM3, **144**

Lin, J.: SE-TuA12, **114**

Lin, K.Y.: PS+EM+TF-ThM12, **149**

Lin, P.: BI+AS+IPF+NS-TuA11, **110**

Lin, S.J.: SE-TuP1, **120**

Lin, S.-Y.: PS-TuP7, **119**; PS-TuP8, 119; PS-TuP9, 119

Lin, Y.: SE-TuP4, 120

Lin, Y.C.: AM+NS+SS-WeM12, 125

Lin, Y.H.: PS-TuP25, 119

Lin, Y.-H.: PS-TuP22, 119; PS-TuP23, 119

Lin, Y.-H.: MN-ThP1, **162**

Lin, Y.-H.: MN-ThP2, 162

Linford, M.R.: AS+SE-ThM6, 145; AS-MoM5, **81**; HI+AS-ThM11, 147; TF+AS+EL+PS-ThM5, 151; TF+PS-ThM10, 151; TF+SS-TuA10, 116

Liong, L.C.: EL+EM-MoA6, 90

Lippitz, A.: 2D+MN+NS+SS-WeA7, 134

Lishan, D.: PS+MN-WeM4, 130

List, T.: PS-ThA6, 157; PS-ThM6, 149

Litwin, P.: EM-ThP19, 161

Liu, C.: MM+AS+NS+PC-MoM5, 83

Liu, D.R.: EM-ThP4, **161**

Liu, F.: BI-WeA11, 136

Liu, J.: AS+SE-WeA12, 135; EL+EM-MoA10, **90**

Liu, M.: SA+AS+HC+SS-ThA1, 158

Liu, P.: HC+SS-TuM3, 100

Liu, R.: SS+AS+BI+MI+NS-ThA6, **158**

Liu, S.Y.: EL+AS+EM-MoM8, 82; EL+EM-MoA10, 90

Liu, T.: PS+PB+SE-TuA3, 113

Liu, T.-L.: TF+PS-TuA10, 115; TF1-MoM2, 87

Liu, W.: BI+AS-NS-FrM5, 168

Liu, X.: VT-TuM4, 106; VT-TuM5, **106**

Liu, Y.: MP+EM+NS-TuM5, 101; TF+EM+MI-WeA8, **141**

Liu, Y.L.: HI+AS-ThM4, **147**

Liu, Y.Y.: SE-MoA10, 94

Liu, Z.: HC+SS-TuA10, 111; SS+AS+HC-FrM5, 170; SS+HC+MI-TuA11, 115

Lively, R.: TF+SS-TuA12, 116

Livengood, R.H.: HI-ThP1, 161; HI-ThP2, 161

Llorca, J.: PC+AS+BI+EM+NS+PB+SS-TuP2, 119

Lloyd, K.G.: AS-ThP7, **160**

Lo Porto, C.: PS+PB-MoA2, 93

Lo, C.F.: EM+2D+SS-WeA9, 137

Locatelli, A.: SA+AS+HC+SS-ThA7, 158

Lockyer, N.P.: AS+BI-TuM1, **99**

Long, J.: MP+AM+EM+NS-MoA6, 92; MP+EM+NS-TuM3, 101; MP+EM+NS-TuM6, 101

Lopez, D.: MN+2D+AN+NS-ThA1, **156**; MN+2D+AN+NS-ThA8, 156

Lopez, G.P.: BI-TuP13, 118

Lorenz, M.: HI+AS-ThM1, 147

Author Index

Losego, M.D.: BI+AC+AS+HC+NS+SS+TF-WeA4, **136**; TF+SS-TuA12, **116**
 Lou, Q.: PS+EM-WeA1, 140
 Loup, V.: PS+EM+SE-TuM1, 103
 Louwagie, N.: VT-TuP3, 121
 Lovric, J.: HI+AS-ThM3, 147
 Lu, D.: SA+AS+HC+SS-ThA1, 158
 Lu, H.: BI+AS+IPF+MN-MoA5, 90
 Lu, I.: 2D+EM+MI+MN+NS+SS-ThM5, 144
 Lu, J.: MS-TuP5, 118; SE-MoA4, 94
 Lu, T.-M.: AM+MP+NS-WeA3, 135
 Lu, W.: NS+AM+MI+MN+SS+TR-TuA9, 112
 Lu, Y.: 2D+AM+EM+NS-WeM1, **124**
 Lu, Y.H.: PC+AS+BI+NS+PB+SS-TuM11, 102
 Lu, Y.-T.: PS+EM-WeA10, 140
 Luan, P.: PS+PB-TuM13, **103**
 Lubomirsky, D.: PS-TuP5, 119
 Lubomirsky, I.:
 NS+AN+EM+MI+MN+MP+PS+RM-ThM1, 148
 Lucero, A.T.: TF+AS+EL+PS-ThM13, 151; TF1-MoM9, 87
 Ludwig, J.: 2D+AM+EM+NS-WeM10, 124
 Ludwig, K.F.: PS+EM+TF-ThA8, 157; TF-ThP38, 163
 Luna, L.E.: EM+2D+AN+MI+MP+NS-TuA11, 110; EM+2D+SS-WeA12, 137
 Lundgren, E.: HC+SS-ThA2, 154; HC+SS-ThA7, 154; HC+SS-ThM2, 146; HC+SS-ThM4, 146; HC+SS-WeM10, 126; HC+SS-WeM11, 126; HC+SS-WeM5, 126
 Lundsgaard Hansen, J.: TF-ThP34, 163
 Lundy, N.: PS-FrM2, 169
 Luo, J.J.: TF-ThP11, 163
 Luo, S.: HC+SS-TuM3, 100
 Lupo, G.: BI-ThM5, 145
 Luria, K.: VT-TuA1, 116
 Luth, C.: EL-TuP2, 118
 Lutker-Lee, K.: PS+EM-WeA10, 140
 Lutz, H.: BI+AS+IPF+MN-MoA5, 90
 Lv, H.F.: SS+HC+NS+PS-TuM4, 104
 Ly, M.P.: HI-ThP2, 161
 Lyle, L.A.M.: EM+2D+SS-WeA3, **137**
 Lyndaker, A.: VT-TuM4, 106; VT-TuM5, 106
 Lyubinetsky, I.: HC+SS-ThA1, 154; SS+AS+EM-WeA10, 141; SS+AS+EM-WeA12, 141
— M —
 Ma, C.: NS+AM+MI+MN+SS+TR-TuA9, **112**
 Ma, H.: EM-ThP10, 161
 Ma, Q.: TF1-MoM3, 87
 Ma, R.S.: NS-ThP13, 162
 Ma, T.: PS-ThA6, 157; PS-ThM6, 149
 Ma, Y.: 2D+AM+EM+NS-WeM6, 124
 Ma, Z.: TF-ThP29, 163
 Maasilta, I.J.: HI+AS-ThM5, **147**
 Määttä, J.A.E.: BI-ThM6, 145
 Maboudian, R.: 2D+EM+MI+NS+TF-MoM10, 81
 Macco, B.: TF+AS+EL+EM+NS+PS+SS-ThA6, 159
 Macháček, J.: NS+AM+MI+MN+SS+TR-TuA11, 112
 Maciullis, N.A.: SS+EM+PS+TF-ThA4, 159
 Mack, P.: AS-MoA2, **89**; AS-MoA8, 89; EW-TuL3, 108
 Mackus, A.J.: TF-TuM11, 106
 Mackus, A.J.M.: TF+AM+EM+PS-TuM1, **105**
 Maddumapatabandi, T.D.: HC-ThP3, 161
 Madhavan, A.: RM+EM+NS-TuA11, 114
 Madiona, R.M.T.: BI+AS+NS-FrM3, 168
 Madix, R.: HC+SS-WeA10, 137
 Madsen, J.P.: BI-ThM4, 145
 Maeda, E.: TF+EM+MI-WeM3, 131
 Maeda, K.: PS+EM-WeM5, 129
 Magalhaes, S.G.: AC+MI+SA-WeM5, 124
 Magel, G.A.: MM+AS+NS+PC-MoM5, 83
 Magesan, E.: MP+AM+EM+NS-MoA10, 92
 Magnozzi, M.: EL+AS+EM-MoM6, **82**
 Magnus, M.: AS-ThP10, 160
 Magrì, A.: BI-ThM5, 145
 Maguire, P.: PS+EM+NS+SS-TuA4, 113
 Mahalingam, K.: SS+HC+MI-TuA12, 115
 Mahapatra, M.: HC+SS-ThM1, **146**; HC+SS-ThM3, 100
 Mahne, N.: SA+MI-ThM5, 150
 Mahoney, C.: AS+SE-WeA2, **135**
 Maibach, J.: SA+AS+MI-WeA3, **140**
 Maier, M.: EW-WeL3, **133**; NS-ThP12, **162**
 Maindron, T.: TF+AS+EL+EM+NS+PS+SS-ThA4, **159**
 Maira, N.: PB+BI+PC+PS-WeA7, **139**
 Maksymovych, P.: 2D+EM+MI+MN+NS+SS-ThM6, **144**; 2D+EM+MN+NS-ThA6, 152
 Malik, S.: SE-TuP3, 120
 Malko, A.V.: EM+AN+MI+SS-WeM10, 126
 Mallouk, T.E.: HC+SS-TuM6, 100
 Malmstadt, N.M.: BI-TuP7, 118
 Malterre, D.: SA+AS+HC+SS-ThA10, 158
 Malviya, Y.H.: MS+MI+RM-TuM10, 101
 Mamta, H.H.: TF+EM+MI-WeA10, 141
 Manassero, P.: VT-MoA5, 96
 Mandia, D.J.: TF+PS-ThM3, 151; TF-ThP31, **163**
 Mandrus, D.G.: 2D+MN+NS+SS-WeA10, 134; 2D+MN+NS+SS-WeA9, 134
 Mane, A.U.: TF+EM+MI+PS-MoA9, 95; TF+PS-ThM3, 151
 Manfredda, M.: SA+MI-ThM5, 150
 Mangolini, L.:
 NS+2D+AN+EM+MN+MP+PC+RM-MoM6, 84; PS-FrM10, 169; PS-ThA2, 157; TF2-MoM10, 87
 Mangus, M.: AS+SE-ThM13, 145; BI+AS+IPF+MN-MoA10, 90
 Mann, J.E.: AS+SE-WeA10, 135
 Manning, M.: BI-ThA10, 153
 Manno, M.: TF-MoA8, 95
 Manor, B.C.: AC+AS+SA-WeA1, 134
 Mao, H.: TF+EM+MI-WeA9, 141
 Mao, Z.: HC+SS-TuM10, **100**
 Marc, S.: BI-TuP11, 118
 Marcinkowski, M.D.: HC+SS-WeM1, **126**; HC+SS-WeM2, 126
 Marcoen, K.: SE+NS+TF-MoM1, 86; SS+AS+EM-WeA7, 141
 Marcu, L.: IPF+AS+BI+MN-TuM3, 100
 Margalith, T.: PS+MN-WeM3, 130
 Mariano, W.C.: 2D-ThP4, 160
 Mariantoni, M.: MP+AM+EM+NS-MoA3, **92**
 Marina, O.A.: SE-TuA7, 114
 Marinella, M.J.: MS+MI+RM-TuM1, 101; RM-TuP3, 120
 Marinov, D.: 2D+AM+EM+NS-WeM10, **124**
 Mariotti, D.: PS+EM+NS+SS-TuA4, 113
 Marques, E.: TF+AM+EM+PS-TuM10, 105
 Marszewski, E.: 2D+MN+NS+SS-WeA12, 134
 Marsh, J.R.: AS-ThP7, 160
 Marshall, M.: AM+MP+NS-WeA3, 135
 Martin, J.: HC-ThP7, 161
 Martin, N.M.: HC+SS-ThA2, 154; HC+SS-ThM2, 146
 Martin, R.: HC+SS-ThM4, 146
 Martin, T.: BI-ThA8, 153
 Martinez, A.: PC+AS+BI+EM+NS+PB+SS-TuP5, 119; SE-TuA7, 114; SS+AS+BI+MI+NS-ThA11, 158
 Martinez, E.: PS+EM+SE-TuM12, 103; SA+AS+MI-WeA9, **140**
 Martinez, N.J.: MS+MI+RM-TuM1, 101
 Martinis, J.: MP+EM+MN+NS-MoM3, **84**
 Martinson, A.B.F.: TF+PS-ThM5, **151**
 Martinu, J.: PS+PB-MoA10, 93; SE-MoA1, **94**
 Marusak, K.E.: IPF+AS+BI+NS-WeM3, 127
 Mascarenho, A.: SS-TuP9, 120
 Masciovecchio, C.: SA+MI-ThM5, 150
 Maskova, S.: AC+AS+SA-ThM3, 144; AC+MI+SA-WeM11, **124**
 Maslar, J.E.: TF1-MoM8, 87
 Maslov, M.: HI-WeA9, 138
 Mason, L.: AS+NS-ThA10, 153
 Mastro, M.A.: EM+2D+SS-WeA12, 137
 Matěj, Z.: AC+MI+SA-FrM9, 167
 Matheson, B.: BI-ThA8, 153; BI-TuP8, 118
 Mathur, A.: EL+EM-MoA5, 90
 Matjacic, L.: AS+BI-TuM5, 99
 Matsubara, K.: PS+AS+EM+SS-MoM9, 85; PS-TuP4, 119
 Matsubara, S.: HI-ThA1, **155**
 Matsuda, I.: 2D+EM+MI+MN+NS+SS-ThM12, **144**
 Matsudo, T.: PS+TF-MoM10, 85
 Matsui, M.: PS+EM-WeM2, **129**
 Matsukuma, M.: SS+AS+HC-FrM7, 170
 Matsunaga, S.: BI-ThM12, 145
 Matsuzaki, K.: SS+AS+HC-FrM7, 170
 Matthew Tittensor, M.T.: BI-TuP7, 118
 Mattson, E.: TF+SS-TuA8, 116
 Matyjaszewski, K.: BI-ThA1, 153
 Mauchamp, N.: PS-FrM5, **169**
 Mauger, S.: AS-ThP4, 160
 Maurer, L.: AM+MP+NS-WeA3, 135
 Maynes, A.J.: NS+AM+AS+MN+PC+PS+SS+TR-FrM3, 169
 Mayrhofer, P.H.: SE+NS+TF-MoM6, **86**
 Mazin, I.: 2D+EM+MN+NS-ThA1, 152; NS-ThP18, 162
 McAndrews, G.R.: TR-TuP1, 120
 McArthur, S.L.: SE-TuP5, 120
 McBreen, P.H.: NS-ThP3, 162
 McCall, R.: VT-WeM2, **131**
 McChesney, J.L.: SA+MI-ThM1, **150**
 McClain, J.: MN+NS+PS-WeM4, 127
 McClellan, C.: 2D+EM+MI+NS-TuM12, 99
 McClelland, J.: RM+EM+NS-TuA11, 114; RM-TuP2, 120; SA-ThP3, 162
 McCreary, K.M.: 2D+EM+MI+MN+NS-TuA1, 109; 2D+EM+MN+NS-ThA1, 152; 2D+EM+MN+NS-ThA2, **152**; NS-ThP18, 162
 McCurdy, M.L.: MN+2D+AN+NS-ThA3, 156
 McDermott, R.: MP+EM+NS-TuM5, 101
 McDonnell, S.: EM-ThP19, **161**
 McDonough, J.: AS+NS-ThA7, 153
 McEwen, J.-S.: SS+HC-MoA1, **94**
 McEwen, K.A.: AC+AS+SA-WeA10, 134
 McFadden, A.P.: 2D+EM+MN+NS-FrM6, 167
 McGehee, W.: SA-ThP3, 162
 McGhee, E.: TF-ThP25, **163**; TF-ThP26, 163
 McGlynn, R.: PS+EM+NS+SS-TuA4, 113
 McGuinness, E.K.: TF+SS-TuA12, 116
 McGuire, G.: TF+AS-TuM1, **105**; TF+AS-TuM5, 105
 McGuire, M.A.: 2D+EM+MI+MN+NS+SS-ThM6, 144; 2D+EM+MN+NS-ThA6, 152
 McIntyre, P.C.: EM+MP+PS-MoM5, 82
 McKay, K.S.: MP+EM+MN+NS-MoM8, 84
 Mckenney, L.: BI-ThA8, 153
 McLaren, J.: EW-TuL6, **108**
 McLean, W.: AC+AS+SA-ThM11, 144
 McMillan, A.: SS+HC+MI-MoM10, 86
 McRae, C.R.: MP+EM+NS-TuM12, 101; MP+EM+NS-TuM3, 101; MP+EM+NS-TuM6, 101
 McSkimming, A.: AC+AS+SA-WeA1, 134
 Meadows, T.Q.: AC+AS+SA-ThM1, 144
 Mecklenburg, M.: SS+HC+MI-TuA12, 115

Author Index

Medeiros, D.: PS+EM-WeA3, 140
 Medlin, J.W.: SS+HC-WeM1, **130**
 Medvids, A.: EM+AN+MI+SS-WeM5, 126
 Meeusen, M.: TF+SS-TuA1, 116
 Mefford, J.T.: MM+AS+NS+PC+SS-MoA8, 92
 Mehar, V.: HC+SS-WeM10, 126
 Mehedi, H.A.: 2D+MN+NS+SS-WeA2, **134**
 Mehl, R.A.: BI+AS+IPF+NS-TuA9, 110
 Mehn, D.: BI-ThM3, 145
 Mehta, B.R.: HC-ThP5, 161
 Mei, T.: MN+2D+AN+MP+NS-ThM5, 148
 Meier, D.A.: AC+AS+SA-ThM1, 144
 Meier, M.: SS+HC+MI-TuA3, 115
 Mele, F.: BI-ThA11, 153
 Meli, L.: PS+EM-WeA1, 140
 Melia, M.A.: SE-TuP7, 120
 Melianas, A.: RM-TuP3, 120
 Meng, D.: SE-TuA8, 114
 Meng, X.: TF1-MoM9, 87
 Meng, Y.S.: PC+AS+BI+NS+PB+SS-TuM1, **102**
 Menguelti, K.: PC+AS+BI+EM+PB+SS-WeM10, 128; PS+PB-MoA5, 93
 Menk, L.: MN+NS+PS-WeM4, 127; MN+NS+PS-WeM5, 127
 Mentes, O.T.: SA+AS+HC+SS-ThA7, 158
 Menyhard, M.: AS+NS+SA-WeM10, 125
 Menzies, C.: HC+SS-TuA2, 111
 Merche, D.: PS+PB+SE-TuA8, 113
 Merida, C.S.: 2D+EM+MI+MN+NS+SS-ThM5, 144
 Merino, P.: NS+2D+AS+MN+PC-ThA8, 156
 Merkel, M.: MM-TuP2, 118
 Merrill, D.: SE-TuP3, 120
 Merte, L.: HC+SS-ThA2, 154; HC+SS-WeM10, 126
 Mertens, J.: PS+EM+NS+SS-TuA7, 113; PS+TF-MoM9, **85**
 Meshik, A.P.: AC+AS+SA-ThM12, 144
 Mettler, J.: PS+PB-TuM3, 103
 Metzler, D.: PS+EM+TF-ThM12, 149
 Meunier, BM.: SA+AS+MI-WeA9, 140
 Meyer, D.J.: TF+EM+MI-WeM1, **131**; TF+EM+MI-WeM4, 131
 Meyer, H.M.: AS-ThP6, **160**
 Meyer, J.: AM+NS+SS-WeM12, 125
 Meyer, M.: AC+AS+SA-ThM10, 144
 Meyyappan, M.: PS+MN-WeM10, **130**
 Mezger, M.: BI-ThA4, 153
 Miao, L.: AC-ThA8, 152
 Michael, C.: MN+NS+PS-WeM6, 127
 Michaelides, A.: SS+HC+NS+PS-TuM1, **104**
 Michely, W.: SS+EM+NS-ThM1, **150**
 Michlincek, M.: PS+PB-MoA4, 93
 Michnowicz, T.: NS+AM+AS+MN+PC+PS+SS+TR-FrM4, **169**
 Mihut, D.: SE-TuA4, 114; TF-ThP12, **163**
 Mikkelsen, A.: EM+AN+MI+SS-WeM11, 126
 Mikkelsen, M.H.: EM+MI+MN+NS-ThM1, **146**
 Miliyanchuk, K.: AC+MI+SA-WeM11, 124
 Miller, PS+PB-TuM5, **103**
 Miller, E.M.: 2D-ThP5, 160
 Miller, S.M.: MS+MN-TuA1, **111**
 Milosavljević, V.: PS+PB+SE-TuA10, **113**
 Milosevic, E.: EM+AM+NS+PS-MoA5, 91
 Min, K.-S.: RM-TuP1, 120
 Minar, J.: SA+AS+MI-WeA1, 140
 Minarik, P.: AC+MI+SA-WeM10, 124
 Minasian, S.G.: AC+AS+SA-ThM10, 144
 Mincigrucci, R.: SA+MI-ThM5, 150
 Minkoff, B.B.: PS+PB-TuM10, 103; PS+PB-TuM12, 103
 Minor, A.M.: AC-ThA1, 152; BI+AC+AS+HC+NS+SS+TF-WeA10, 136; MM+AS+NS+PC-MoM6, 83
 Miracle, C.: VT-MoA10, 96
 Miranda, R.: SS+EM+PS+TF-ThA11, 159; SS+HC-WeM6, 130
 Mirkhani, V.: EM-ThP18, 161
 Mishra, A.: AS+NS-ThA7, 153
 Mishra, M.: EM+AN+MI+SS-WeM4, **126**
 Mishra, P.: AS-ThP3, 160
 Mishuk, E.: NS+AN+EM+MI+MN+MP+PS+RM-ThM1, 148
 Misra, S.: AM+MP+NS-WeA3, **135**
 Mitev, P.: HC+SS-ThM12, 146
 Mitra, S.: MS+MI+RM-TuM10, 101
 Mitterer, C.: TR-TuP2, 120
 Miyamoto, K.: MI+EM-FrM7, 168
 Miyoshi, N.: PS+EM+TF-ThA3, **157**; PS+EM+TF-ThM3, 149
 Mizotani, K.: PS+EM+NS+SS-TuA12, 113
 Mizrahi, A.: RM+EM+NS-TuA11, **114**
 Mizuno, M.: PS+PB-TuM11, 103
 Mleczko, M.: 2D+EM+MI+NS-TuM12, 99
 Mochiki, H.: PS+EM+TF-ThA10, 157
 Mock, A.: EL+AS+EM-MoM3, 82; EL+EM-MoA1, 90
 Mocko, V.: AC-ThA3, 152
 Moellers, R.: AS+SE-WeA1, 135
 Moffitt, C.: AS+NS-ThA10, 153; AS-MoM9, 81; EW-TuL4, 108
 Mogi, T.: HC+SS-WeA7, 137
 Mogwitz, B.: BI+AS+NS-FrM6, 168
 Mohabir, A.T.: EM+MP+PS-MoM10, **82**
 Mohades, M.: PS+EM+SE-TuM6, **103**
 Mohammad, A.: PS+EM+NS+SS-TuA1, 113
 Mohheimeri, S.O.R.: NS+2D+AS+PC-MoA1, **93**
 Mohnay, S.E.: EM+AM+NS+PS-MoA8, **91**; TF+AM+EM+PS-TuM6, 105
 Mohr, S.: PS-TuP14, **119**; SS+AS+EM-WeA9, 141
 Moilanen, A.: MI-ThP1, 161
 Moisseev, A.G.: SS+AS+BI+MI+NS-ThA6, 158
 Mol, J.M.C.: SE+NS+TF-MoM1, 86; SS+AS+EM-WeA7, 141; TF+SS-TuA1, 116
 Molkenboer, F.T.: VT-MoM10, **88**
 Møller, P.: SE-MoA9, 94
 Möller, W.: HI-ThA8, 155
 Molodtsova, O.V.: 2D+EM+MI+NS-TuM4, 99
 Mom, R.: PC+AS+BI+EM+NS+PB+SS-TuA7, 112
 Monemar, B.: EL+EM-MoA1, 90
 Montembault, A.: BI-ThA1, 153
 Moon, S.Y.: HC-ThP2, 161
 Moore, A.L.: 2D+EM+MI+MN+NS-TuA12, 109
 Moore, T.M.: MM+AS+NS+PC-MoM5, 83
 Moore, W.: TF-MoA8, 95
 Moraes, V.: SE+NS+TF-MoM6, 86
 More, K.: MM+AS+NS+PC-MoM8, 83
 Moreau, L.: AC+AS+SA-WeA1, 134; AC+MI+SA-FrM8, **167**
 Moreno Ostertag, L.: BI-ThA3, **153**
 Moreno Villavicencio, M.A.: AS+BI-TuM13, **99**
 Morgan, H.R.: SS+AS+BI+MI+NS-ThA1, 158
 Morgan, T.W.: PS+AS+EM+SS-MoM5, **85**
 Morgenstern, A.L.: AC+AS+SA-WeA7, 134
 Morita, Y.: PS+TF-MoM10, 85
 Moriya, T.: PS+TF-MoM10, 85
 Moroz, P.: TF+AS+EL+PS-ThM3, **151**
 Morozovska, A.N.: 2D+EM+MN+NS-ThA6, 152
 Morris, A.: TF+PS-TuA7, **115**
 Morris, J.R.: AC+AS+SA-WeA9, 134
 Morris, T.W.: SS+EM+PS+TF-ThA4, **159**
 Mosden, A.: PS+EM+SE-TuM6, 103
 Moth-Poulsen, K.: SS+AS+EM-WeA9, 141
 Mottaghi, N.: AC+MI+SA-WeM13, **124**; SA+MI-ThM2, 150
 Mouton, I.: AS+BI-TuM13, 99
 Movsesian, N.M.: BI-TuP7, **118**
 Mraz, S.: SE-MoA4, 94
 Mu, R.: SS+AS+EM-WeA12, 141
 Mueller, A.: BI+AC+AS+HC+NS+SS+TF-WeA10, 136
 Mueller, D.N.: MM+AS+NS+PC+SS-MoA4, 92; SA+AS+HC+SS-ThA7, 158
 Muench, F.: AS+SE-ThM4, 145
 Muir, B.W.: BI+AS+NS-FrM3, 168
 Muira, M.: PS+EM-WeM5, 129
 Mujica, M.: EM+MI+MN+NS-ThM3, 146
 Mujovic, S.M.: PB+BI+PC+PS-WeA9, 139
 Mukherjee, S.: 2D+EM+MI+NS-TuM1, 99
 Mulato-Gomez, D.: AS-MoM6, 81
 Mulato-Gómez, D.F.: AS-ThP9, **160**
 Müller, A.: AC-ThA1, 152
 Müller, B.: EL+AS+EM-MoM5, **82**
 Muller, E.A.: NS+MN+PC+SS-WeA11, 139
 Münch, A.: BI-ThA11, 153
 Munger, M.: PS+EM+TF-ThA8, 157
 Munigeti, R.: AS+SE-WeA7, 135
 Muñoz Rojo, M.: 2D+EM+MI+NS-TuM12, 99
 Muñoz-Espí, R.: BI+AS+IPF+MN-MoA5, 90
 Munshi, A.: EM+2D+AN+MI+MP+NS-TuA3, 110; TF-MoA5, 95
 Murakami, H.: EL+EM-MoA1, 90
 Muramoto, S.: AS+SE-ThM10, 145; AS-MoM10, **81**
 Muratore, C.: EM+2D+NS+PS+RM+TF-ThA3, 154; EM+AN+MI+SS-WeM12, 126; EM-ThP3, 161; PS-TuP16, 119
 Murdzek, J.A.: TF-TuM2, 106
 Murphy, A.B.: PS-FrM3, **169**
 Murphy, J.: MS-TuP5, 118
 Murphy, P.: EL+EM-MoA6, 90
 Murugesan, V.: PC+AS+BI+EM+NS+PB+SS-TuP5, 119; SE-TuA7, 114; SS+AS+BI+MI+NS-ThA11, 158
 Music, D.: TR-TuP2, 120
 Musick, K.: MN+NS+PS-WeM4, 127; MN+NS+PS-WeM5, 127
 Mutunga, E.: AM+NS+SS-WeM3, 125
 Myers, T.J.: TF+PS-TuA11, **115**
 Myers-Ward, R.L.: 2D+EM+MN+NS-FrM6, 167; EM+2D+AN+MI+MP+NS-TuA11, **110**; EM+2D+AN+MI+MP+NS-TuA9, 110; PS+AS+EL+EM+SE-WeM3, **129**
 Myung, Y.: TF-ThP41, 164
 — N —
 Na, D.H.: VT-TuP10, **121**
 Naaman, R.: MI+BI-ThA3, **155**
 Naas, C.: BI-ThA11, 153
 Nabatame, T.N.: TF+EM+MI-WeM3, **131**
 Nagaseki, K.: PS-ThM11, 149; PS-ThM2, 149
 Nagata, M.: VT-TuP2, 121
 Naghibi Alvillar, S.A.: 2D+EM+MI+NS+TF-MoM6, 81
 Naghibi, S.: HC-ThP4, 161
 Nagumo, K.: TF+EM+MI-WeM5, 131
 Naik, M.: EM+AM+NS+PS-MoA10, 91
 Nair, R.: EW-WeB3, **132**
 Naitou, Y.: HI-WeA11, 138; HI-WeA3, **138**
 Nakada, H.: PS+EM-WeM12, 129
 Nakamura, J.: HC+SS-WeA7, **137**; SS+HC+NS+PS-TuM13, 104
 Nakamura, J.N.: SS+AS+EM-WeA4, 141; SS+HC+NS+PS-TuM11, 104; SS+HC-WeM13, **130**
 Nakanishi, H.: SS+HC-MoA4, 94
 Nakatani, T.: PS+EM+NS+SS-TuA8, 113
 Nalam, P.: TR+AS+NS+SS-MoM8, **88**
 Naletova, I.: BI-ThM11, 145; BI-ThM5, 145
 Nam, S.: EM+2D+NS+PS+RM+TF-ThA3, 154; PS+EM+SE-TuM4, 103; PS-ThA6, 157
 Nam, S.K.: PS-ThM5, 149

Author Index

Namboodiri,: AM+MP+NS-WeA7, 135
 Namihira, T.: PB+BI+PC+PS-WeA3, 139
 Nanayakkara, S.U.: 2D-ThP5, **160**
 Narayan, S.R.: AS+SE-ThM13, 145; AS-ThP10, 160; BI+AS+IPF+MN-MoA10, 90; SS-TuP9, **120**
 Narayanan, P.: MS+MI+RM-TuM5, 101
 Nash, J.A.: BI-ThA10, 153
 Nash, K.L.: BI-ThA6, **153**
 Nasser, S.: TF+EM+MI-WeA12, 141
 Nastasi, M.: PS+EM-WeA2, 140
 Naumenko, D.: SA+MI-ThM5, 150
 Nava, G.: TF2-MoM10, **87**
 Navarro, C.: PS+EM-WeM3, 129
 Nazin, G.V.: NS+2D+AS+MN+PC-ThA7, 156
 Nealey, P.F.: NS+AN+EM+MI+MN+MP+PS+RM-ThM10, **148**
 Neels, A.: MI+2D-ThM13, 147
 Nelin, C.J.: AC+MI+SA-FrM6, 167
 Nellis, W.J.: AC+AS+SA-WeA10, 134
 Nelson Weker, J.: AS-MoA1, 89
 Nelson, A.J.: AC+AS+SA-ThM11, **144**
 Nelson, C.M.: SE-TuA3, **114**
 Nelson, J.J.: MP+EM+NS-TuM5, 101
 Nemsak, S.: MM+AS+NS+PC+SS-MoA4, 92; SA+AS+HC+SS-ThA7, 158; SA+AS+MI-WeA1, **140**; SS-TuP8, 120
 Nepal, N.: PS+EM+TF-ThA8, 157; PS+TF-MoM11, 85; TF+EM+MI-WeM1, 131; TF+EM+MI-WeM4, 131; TF-ThP38, 163
 Neumann, C.M.: PS+EM-WeA12, 140
 Neumayer, S.: 2D+EM+MN+NS-ThA6, **152**
 Neupane, S.: MI-ThP1, 161
 Newberg, J.T.: PC+AS+BI+NS+PB+SS-TuM10, 102; SS+AS+HC-FrM4, 170
 Newell, C.: AS+BI-TuM5, 99
 Newman, J.: AS+SE-WeA10, 135; EW-TuL7, **108**
 Neyerlin, K.C.: AS-ThP4, 160
 Nezich, D.A.: 2D+EM+MN+NS-ThA7, 152
 Ng, P.S.: MN+2D+AN+NS-WeA11, 138
 Ng, S.: EL+EM-MoA6, 90
 Ng, T.K.: AS-ThP3, 160
 Ngaboyamahina, E.: IPF+AS+BI+NS-WeM3, **127**
 Ngo, C.: AS-ThP4, 160
 Nguyen, A.E.: 2D+EM+MI+MN+NS+SS-ThM5, 144; 2D+EM+MI+MN+NS-TuA11, 109
 Nguyen, G.D.: NS+2D+AS+MN+PC-ThA6, 156
 Nguyen, H.M.: PS-TuP22, 119
 Nguyen, M.-T.: HC+SS-WeM2, 126
 Nguyen, N.: 2D+MI+NS-MoA3, **89**
 Nguyen, P.A.: BI-ThA8, 153; BI-TuP8, **118**
 Ni, Y.: PC+AS+BI+EM+NS+PB+SS-TuP3, **119**
 Nicolas, J.-D.: IPF+AS+BI+MN-TuM12, **100**
 Nicolas, N.: TF+AM+EM+PS-TuM5, 105
 Nicolet, C.: PS+EM-WeM3, 129
 Nicora, C.: AS-MoA10, 89
 Nie, X.: SE+PS-TuM2, 104
 Niehuis, E.: AS+NS-ThA6, **153**; AS+SE-WeA1, 135
 Nielsen, M.H.: SA+AS+HC+SS-ThA11, 158; SA-ThP2, 162
 Nihil, K.: SS+HC+MI-MoM10, 86
 Niino, R.: PS+EM-WeA9, 140
 Nikzad, S.: EM+2D+SS-WeA10, 137; TF+EM+MI-WeA3, 141
 Niroula, J.: RM-TuP3, 120
 Nishi, Y.: TF-ThP29, 163
 Niu, S.: SS+HC+MI-TuA12, **115**; TF+EM+MI-WeA8, 141
 Noble, A.: AC+AS+SA-WeA9, 134
 Noky, J.: MI+EM-FrM7, 168
 Nolde, J.: 2D+MN+NS+SS-WeA11, 134
 Nordell, B.J.: PS+EM-WeA11, 140
 Nordin, G.P.: MN+NS+PS-WeM1, **127**
 Nordqvist, T.: MM+AS+NS+PC-MoM6, 83
 Norrgard, E.: NS+AN+EM+MN+MP+RM-TuM12, 102
 Notte, J.A.: BI+AS+IPF+MN-MoA9, 90; HI-WeA10, **138**
 Novosad, V.: MI+BI-ThA6, 155
 Nowack, K.C.: NS+2D+AS+MN+PC-ThA1, **156**
 Nowak, D.: 2D+MI+NS-MoA4, 89; EM+MP+PS-MoM11, 82; NS+2D+AS+PC-MoA9, **93**; NS+MN+PC+SS-WeA3, 139
 Nozawa, S.: PS+EM-WeA9, 140
 Ntwaeborwa, O.M.: AC+MI+SA-FrM11, **167**
 Nunn, N.J.: TF+AS-TuM5, 105
 Nunney, T.S.: EW-TuL3, **108**
 Nunomura, S.: PS+AS+EM+SS-MoM9, **85**; PS-TuP4, 119
 Nyakiti, L.O.: TF+EM+MI-WeM4, 131
 Nyman, M.: SS+AS+EM-WeA10, 141
 — O —
 O'Meara, D.: PS+EM-WeA10, 140
 O'Callahan, B.T.: NS+MN+PC+SS-WeA11, 139
 O'Carroll, D.M.: EM+2D+AN+MI+MP+NS-TuA1, **110**
 Ocepel, A.: VT-MoM3, 88
 Ochoa Guaman, S.L.: VT-MoA4, **96**
 Ocola, L.E.: NS+2D+AN+EM+MN+MP+PC+RM-MoM8, **84**
 Ocon, J.D.: 2D+EM+MN+NS-FrM9, 167; SS+HC-MoA4, 94
 Oehrlein, G.S.: PS+AS+EM+SS-MoM10, 85; PS+EM+TF-ThM12, 149; PS+PB-TuM13, 103
 Ogasawara, H.: SS+AS+EM-WeA10, 141
 Ogawa, S.: HI-WeA11, 138; HI-WeA3, 138
 Ogawa, T.: HI-ThA4, 155
 Oh, H.-J.: PS+PB+SE-TuA2, 113
 Oh, J.S.: PS-TuP6, **119**
 Oh, M.: 2D+EM+MN+NS-ThA10, 152
 Oh, S.: HC-ThP2, **161**
 Oh, S.Y.: EM+2D+SS-WeA4, 137
 Oh, Y.M.: PS+EM-WeM11, 129
 Ohi, A.: TF+EM+MI-WeM3, 131
 Ohishi, T.: TF+EM+MI-WeM3, 131
 Ohldag, H.: MI+EM-FrM8, **168**
 Ohmori, T.: PS+EM-WeM12, **129**
 Ohno, T.: TF+EM+MI-WeM10, 131
 Ohori, D.: NS-ThP9, **162**
 Ohta, T.: EM+2D+AN+MI+MP+NS-TuA3, **110**
 Otake, A.: SS+AS+EM-WeA4, 141
 Ohya, Y.: PS+EM+SE-TuM13, 103
 Ojea-Jimenez, I.: BI-ThM3, 145
 Oji, H.: SA-ThP1, 162
 Okada, Y.: PS-FrM6, 169
 Okuda, T.: MI+EM-FrM7, 168
 Okuno, H.: 2D+MN+NS+SS-WeA2, 134
 Okur, S.: EM+2D+SS-WeA3, 137
 Olander, K.W.: MS-TuP4, 118
 Olivadese, S.B.: MP+AM+EM+NS-MoA5, 92; MP+EM+MN+NS-MoM5, 84
 Oliver, W.D.: MP+AM+EM+NS-MoA1, **92**
 Olsen, M.R.: SS+AS+EM-WeA10, 141
 Olsson, E.: MM+AS+NS+PC-MoM6, 83; MP+EM+NS-TuM10, **101**
 Olszewski, M.: BI-ThA1, 153
 Omolayo, S.: VT-TuM3, **106**
 Ong, P.: EL+EM-MoA6, **90**
 Ooi, B.S.: AS-ThP3, 160
 Ookuma, K.: PS+EM+TF-ThA3, 157
 O'Reilly, P.: 2D+MI+NS-MoA4, **89**
 Orihuela, B.: BI-WeA7, 136
 Orion, I.: AC+AS+SA-ThM3, 144
 Orlando, T.M.: SS+HC+MI-TuA10, 115
 Orlowski, J.: AS+SE-WeA7, 135
 Oropeza, B.: IPF+AS+BI+NS-MoM5, 83
 Orvis, T.: TF+EM+MI-WeA7, **141**; TF+EM+MI-WeA8, 141
 Osburn, C.: AS+NS+SA-WeM6, 125
 Osmani, B.: EL+AS+EM-MoM5, 82
 Ossowski, J.: TF+SS-TuA2, 116
 Otte, A.F.: AM+MP+NS-WeA9, 135
 Otter, G.C.J.: VT-MoM10, 88
 Ouladdiaf, B.: AC+MI+SA-WeM12, 124
 Ovchinnikova, O.S.: 2D+MN+NS+SS-WeA10, 134; BI+AC+AS+HC+NS+SS+TF-WeA9, **136**; HI+AS-ThM1, 147; HI+AS-ThM4, 147; MM+AS+NS+PC-MoM8, 83
 Overweg, H.: 2D+EM+MI+MN+NS-TuA3, 109
 Ovsyannikov, R.: SS+AS+BI+MI+NS-ThA8, 158
 Owen, J.H.G.: AM+MP+NS-WeA8, **135**
 Oyedele, A.D.: 2D+MN+NS+SS-WeA10, 134; 2D+MN+NS+SS-WeA9, 134
 Oyekan, K.: TF+SS-TuA8, 116
 Ozdol, B.: MM+AS+NS+PC-MoM6, 83
 Ozkan, A.: PS+PB+SE-TuA8, 113; PS+TF-MoM9, 85
 Öztürk, O.: MI+2D-ThM13, 147
 — P —
 Pacholski, M.L.: AS+SE-WeA8, 135
 Pachuta, S.J.: AS+SE-WeA3, **135**
 Pacold, J.I.: AC+AS+SA-ThM10, 144
 Padama, A.A.B.: 2D+EM+MN+NS-FrM9, 167; SS+HC-MoA4, **94**
 Padmanaban, D.: PS+EM+NS+SS-TuA4, **113**
 Paik, H.: MP+AM+EM+NS-MoA10, 92
 Painter, O.J.: HI+AS-ThM13, 147
 Pal, D.: EL+EM-MoA5, 90
 Pal, J.: SS+HC-MoA3, 94
 Palisaitis, J.P.: SE+PS-TuM5, 104
 Palmer, G.M.: TF+AS-TuM5, 105
 Palmstrøm, C.J.: 2D+EM+MN+NS-FrM6, 167; PS+EM+TF-ThA8, 157; TF+EM+MI+PS-MoA5, **95**
 Palomino, R.: HC+SS-TuM3, 100
 Palumbo, F.: PS+PB-MoA2, 93
 Pan, F.: NS+AN+EM+MN+MP+RM-TuM5, 102
 Pan, N.: SE+NS+TF-MoM5, 86
 Pan, T.-T.: PS-TuP8, **119**
 Pan, Y.: PS+EM+TF-ThA4, 157
 Panina, Y.: AS+BI-TuM5, 99
 Panjan, M.: PS+AS+EL+EM+SE-WeM11, **129**
 Panneerchelvam, P.: PS+TF-MoM6, **85**
 Pantelides, S.: 2D+EM+MN+NS-ThA6, 152
 Paolini, C.: VT-MoA5, 96
 Pappas, D.P.: MP+AM+EM+NS-MoA5, 92; MP+AM+EM+NS-MoA6, 92; MP+EM+MN+NS-MoM5, 84; MP+EM+MN+NS-MoM8, 84; MP+EM+NS-TuM12, 101; MP+EM+NS-TuM3, **101**; MP+EM+NS-TuM6, 101
 Paquet, A.: PS+EM-WeM3, 129
 Paquette, M.M.: PS+EM-WeA11, 140; PS+EM-WeA2, 140; SE-TuP3, **120**
 Paradis, P.: EL-TuP3, **118**
 Pargon, E.: PS+EM+SE-TuM2, 103; PS+EM+TF-ThM13, 149; PS+EM-WeM6, **129**
 Park, D.: PS-ThA11, 157
 Park, D.W.: PS-TuP10, 119
 Park, H.: PS-FrM3, 169
 Park, I.-Y.: HI-ThA4, 155
 Park, J.: TF-ThP8, 163; TF-ThP9, **162**
 Park, J.B.: 2D+EM+MI+MN+NS-TuA7, 109
 Park, J.C.: HC-ThP1, 161; PS+EM-WeM11, 129
 Park, J.H.: MN-ThP7, 162; TF+PS-TuA12, 115
 Park, J.S.: TF-ThP18, 163
 Park, J.T.: TF-ThP39, 163
 Park, J.W.: BI-TuP12, 118

Author Index

Park, J.Y.: 2D+EM+MI+MN+NS-TuA7, 109; HC+SS-TuA9, 111; HC-ThP2, 161; NS-ThP2, 162; SS-TuP3, 120

Park, K.-D.: NS+MN+PC+SS-WeA11, 139

Park, M.: EM-ThP18, 161; TF-ThP15, 163

Park, S.: 2D+MI+NS-MoA4, 89; EL+AS+EM-MoM11, 82; NS+2D+AS+PC-MoA9, 93; NS+MN+PC+SS-WeA3, 139; NS-ThP8, 162; PS-TuP5, 119

Park, S.J.: BI-TuP10, 118; BI-TuP6, 118

Park, S.Y.: BI-TuP5, 118; NS+AM+AS+MN+PC+PS+SS+TR-FrM6, 169

Park, T.H.: SS-TuP13, 120

Park, T.J.: VT-TuP5, 121

Park, W.: HC+SS-TuA9, 111; PS-TuP1, 119

Park, W.Y.: TF+EM+MI-WeM11, 131

Park, Y.K.: MS-TuP1, 118

Parkinson, G.S.: BI+AC+AS+HC+NS+SS+TF-WeA8, 136; HC+SS-WeM2, 126; SS+HC+MI-TuA3, 115; SS+HC+NS+PS-TuM3, 104

Pascher, N.: AM+MP+NS-WeA11, 135

Pascon, A.M.: 2D-ThP4, 160

Pashaei, V.: MN+2D+AN+NS-ThA3, 156

Patanwala, H.: BI-ThA9, 153

Patel, D.: PS+TF-MoM1, 85

Patel, D.A.: SS+HC+NS+PS-TuM12, 104

Patel, D.I.: TF+PS-ThM10, 151; TF+SS-TuA10, 116

Patt, M.: MM-TuP2, 118

Pattanaik, G.: EM+MP+PS-MoM8, 82

Paudel, T.R.: MI+EM-FrM9, 168

Paukov, M.: AC+MI+SA-WeM10, 124; AC-ThP5, 160

Paul, R.: MN-ThP6, 162

Pavelec, J.: SS+HC+MI-TuA3, 115

Pavunny, S.P.: EM+2D+AN+MI+MP+NS-TuA10, 110; EM+2D+AN+MI+MP+NS-TuA11, 110; EM+2D+AN+MI+MP+NS-TuA9, 110; PS+AS+EL+EM+SE-WeM3, 129

Payton, C.: TF-ThP25, 163

Peak, J.: VT-MoA10, 96

Pearse, A.: TF2-MoM5, 87

Pearton, S.J.: EM+2D+SS-WeA2, 137; EM+2D+SS-WeA9, 137; EM-ThP11, 161

Pecht, I.: NS+2D+AS+MN+PC-ThA3, 156

Pedersen, K.: TF-ThP34, 163

Pedersoli, E.: SA+MI-ThM5, 150

Pelissier, B.: TF+AM+EM+PS-TuM5, 105

Peng, Q.: TF+PS-ThM12, 151; TF-MoA10, 95; TF-MoA9, 95

Peng, T.L.: EM+MI+MN+NS-ThM4, 146

Pennachio, D.J.: 2D+EM+MN+NS-FrM6, 167; PS+EM+TF-ThA8, 157

Penner, P.: 2D+MN+NS+SS-WeA12, 134

Pentegov, I.: NS+AM+AS+MN+PC+PS+SS+TR-FrM4, 169

Penty, R.V.: EM-ThP1, 160

Perepichka, D.F.: SS+AS+BI+MI+NS-ThA6, 158

Perez, M.A.: VT-TuA7, 116

Perez-Dieste, V.: PC+AS+BI+EM+NS+PB+SS-TuP2, 119

Perrier, P.: VT-MoM6, 88

Perrine, K.A.: SS+EM+NS-ThM10, 150; SS-TuP8, 120

Perrotta, A.: PS+PB-MoA3, 93; PS+PB-MoA6, 93; PS+TF-MoM8, 85

Persson, O.: EM+AN+MI+SS-WeM11, 126

Persson, P.O.A.: SE+PS-TuM5, 104

Pesce, V.: TF+AM+EM+PS-TuM3, 105; TF+AM+EM+PS-TuM5, 105

Petersen, J.: PC+AS+BI+EM+NS+PB+SS-TuA12, 112

Peterson, D.: PS-FrM8, 169

Petford Long, A.K.: TF+EM+MI+PS-MoA9, 95

Petit-Etienne, C.: 2D+MN+NS+SS-WeA2, 134; PS+EM+SE-TuM2, 103; PS+EM+TF-ThM13, 149; PS+EM-WeM1, 129; PS+EM-WeM6, 129

Petrik, N.G.: SS+AS+EM-WeA12, 141; SS+HC+MI-TuA10, 115

Petroni, N.: BI-TuP11, 118

Petrov, I.: SE+NS+TF-MoM10, 86; SE+NS+TF-MoM11, 86; SE+PS-TuM5, 104

Petrov, V.A.: NS-ThP17, 162

Petrova, L.: PS+PB+SE-TuA1, 113

Petrova, Tz.B.: PS+PB+SE-ThA7, 113

Petrovych, D.Y.: BI-ThM6, 145

Pétuya, R.: NS+AM+AS+MN+PC+PS+SS+TR-FrM4, 169

Pfaff, S.: HC+SS-ThA7, 154; HC+SS-WeM11, 126

Phatak, C.M.: TF+EM+MI+PS-MoA9, 95

Phillips, J.A.: SS+AS+BI+MI+NS-ThA1, 158

Piao, H.: AS+NS-ThA7, 153

Pigram, P.J.: BI+AS+NS-FrM3, 168

Pillars, J.: MN+NS+PS-WeM6, 127

Pilloux, Y.: PS+MN-WeM4, 130

Pilz, J.: PS+PB-MoA6, 93; PS+TF-MoM8, 85

Pimenta Barros, P.: PS+EM-WeM3, 129

Pinzan, F.: PS-FrM7, 169

Pirannej, S.: NS-ThP11, 162

Pireaux, J.-J.: PS+EM+NS+SS-TuA7, 113

Piriou, A.: NS-ThP12, 162

Pirkl, A.: AS+SE-WeA1, 135

Pisheh, H.S.: MN+2D+AN+NS-WeA3, 138

Pisoni, R.: 2D+EM+MI+MN+NS-TuA3, 109

Pistillo, B.R.: PS+PB-MoA5, 93

Pivovar, B.S.: AS-ThP4, 160

Pla, D.P.: SA+AS+MI-WeA9, 140

Plank, H.: AM+NS+SS-WeM1, 125; AM+NS+SS-WeM3, 125; AM-TuP1, 118

Platt, H.: AS-MoA1, 89

Pletincx, S.: SS+AS+EM-WeA7, 141; TF+SS-TuA1, 116

Plichta, T.: TF+SS-TuA7, 116

Plodinec, M.: PC+AS+BI+EM+NS+PB+SS-TuA7, 112

Plourde, B.L.T.: MP+EM+NS-TuM5, 101

Plucinski, L.: SA+AS+MI-WeA1, 140

Plumley, J.: EM+MI+MN+NS-ThM4, 146

Pluym, T.: MN+NS+PS-WeM4, 127

Po, G.: SE-MoA3, 94

Poelker, M.: VT-MoM11, 88

Poirier, D.M.: AS+SE-WeA3, 135

Polat, K.G.: TF+EM+MI-WeA10, 141

Polesel-Maris, J.: PS+PB-MoA5, 93

Pollard, A.J.: AS-MoA8, 89

Pollet, O.: PS+EM-WeM10, 129

Polley, C.: 2D+EM+MN+NS-FrM5, 167

Ponizovskaya Devine, E.: TF+EM+MI-WeA10, 141

Poodt, P.: TF+AS+EL+EM+NS+PS+SS-ThA9, 159; TF2-MoM4, 87

Pookpanratana, S.: SS+AS+BI+MI+NS-ThA8, 158

Pop, P.: 2D+EM+MI+NS-TuM12, 99

Porter, L.: EM+2D+NS+PS+RM+TF-ThA4, 154

Porter, L.M.: EM+2D+SS-WeA3, 137

Posada-Borbón, A.: HC+SS-ThM2, 146

Posseme, N.: PS+EM+SE-TuM1, 103; PS+EM-WeM3, 129

Possémé, N.: PS+EM-WeM10, 129

Postawa, Z.: AS-TuA7, 109

Potapenko, D.V.: SS+AS+EM-WeA3, 141

Potyrailo, R.: MS+MN-TuA7, 111

Pouladi, S.: TF-MoA4, 95

Pourtois, G.: TF+AM+EM+PS-TuM10, 105

Prabhakaran, V.: SS+AS+BI+MI+NS-ThA11, 158

Pranda, A.: PS+AS+EM+SS-MoM10, 85

Prasad, N.M.: TF-ThP35, 163

Pravdivtseva, O.V.: AC+AS+SA-ThM12, 144

Prevost, E.: PS+EM-WeM1, 129

Pristl, M.: NS+AM+AS+MN+PC+PS+SS+TR-FrM4, 169

Prokes, S.M.: TF+EM+MI-WeM6, 131

Proksch, R.: HI+AS-ThM4, 147

Prosa, T.J.: TF+AS+EL+EM+NS+PS+SS-ThA6, 159

Prüfer, T.: HI-ThA8, 155

Prünte, S.: TR-TuP2, 120

Prytz, O.: TF-ThP23, 163

Ptasinska, S.: PC+AS+BI+EM+NS+PB+SS-TuP1, 119; PS+PB-TuM2, 103

Pu, Y.-K.: PS-ThA3, 157

Pudasaini, P.R.: 2D+MN+NS+SS-WeA10, 134

Pudasaini, U.: AS-ThP11, 160

Purektzy, A.: 2D+EM+MI+NS+TF-MoM5, 81

Purektzy, A.A.: NS+AM+MI+MN+SS+TR-TuA9, 112

Purushotham, K.: VT-TuP9, 121

Put, B.: TF2-MoM1, 87

Pyeon, J.J.: TF-TuM3, 106

Pylpenko, S.: AS-MoA1, 89; AS-ThP4, 160

Pynn, C.D.: EM+MI+MN+NS-ThM5, 146; NS+AN+EM+MI+MN+MP+PS+RM-ThM13, 148; PS+MN-WeM3, 130

— Q —

Qadri, S.B.: TF-TuM4, 106

Qian, C.: EM+2D+AN+MI+MP+NS-TuA12, 110

Qian, F.: SA-ThP2, 162

Qiao, K.: EM+2D+AN+MI+MP+NS-TuA11, 110; PS+AS+EL+EM+SE-WeM3, 129

Qiao, R.: SA+AS+HC+SS-ThA3, 158

Qiao, Y.: AC+AS+SA-WeA1, 134; AC+MI+SA-FrM8, 167

Qin, X.: HC+SS-ThM10, 146

Qiu, J.: PS-ThA3, 157

Qu, C.: PS-ThM6, 149

Qu, J.: BI+AS+IPF+NS-TuA1, 110; BI+AS+IPF+NS-TuA8, 110

Quadrelli, E.A.: TF+AS+EL+PS-ThM10, 151

Quan, J.M.: HC+SS-WeA7, 137

Quardokus, R.: SS+HC+MI-MoM11, 86

Querlioz, D.: RM+EM+NS-TuA11, 114

Quijada, M.A.: TF-ThP22, 163

— R —

Raab, N.: SA+AS+HC+SS-ThA7, 158

Rachidi, S.: PS+EM+SE-TuM1, 103

Rack, P.D.: 2D+MN+NS+SS-WeA10, 134; 2D+MN+NS+SS-WeA9, 134; AM+NS+SS-WeM1, 125; AM+NS+SS-WeM3, 125; MM+AS+NS+PC-MoM5, 83; TF+AS-TuM10, 105; TF+EM+MI-WeA11, 141

Radadia, A.D.: 2D+EM+MI+MN+NS-TuA12, 109

Rading, D.: AS+NS-ThA6, 153; AS+SE-WeA1, 135

Radovanov, S.: VT-MoM8, 88

Radu, I.: EM+MP+PS-MoM3, 82

Radus, R.: AC+AS+SA-ThM3, 144

Raff, J.: AS-ThP1, 160

Rahman, A.: MI+EM-FrM4, 168

Rahman, T.S.: 2D+AM+EM+NS-WeM2, 124; HC+SS-TuM2, 100; SS+EM+NS-ThM11, 150; SS+HC+MI-TuA7, 115; SS+HC-MoA3, 94; TF+AS+EL+PS-ThM4, 151

Rai, R.H.: EM+2D+NS+PS+RM+TF-ThA3, 154; EM+AN+MI+SS-WeM12, 126; PS-TuP16, 119

Raimondi, L.: SA+MI-ThM5, 150

Rak, Z.: AS-TuA4, 109

Rakhimova, T.: 2D+AM+EM+NS-WeM10, 124

Raley, A.: EM+MP+PS-MoM8, 82; PS+EM-WeA1, 140; PS+EM-WeA10, 140

Author Index

Ram, S.: AS+SE-ThM13, **145**
 Ramanathan, S.: MI+2D+EM+NS-MoA8, **91**
 Ramasse, Q.: AM+NS+SS-WeM12, 125
 Ramirez, G.: SE-TuA1, 114
 Ramirez, J.G.: MI+2D+EM+NS-MoA5, 91
 Rampulla, D.: MS+MI+RM-TuM13, **101**
 Ran, S.: AC-ThA8, 152
 Rand, R.H.: NS+2D+AN+MN+MP+SE-WeM2, 128
 Randall, J.N.: AM+MP+NS-WeA8, 135
 Rangan, S.: SS+EM+PS+TF-ThA7, **159**
 Rani, S.: SS+AS+HC-FrM4, **170**
 Ranieri, P.: PS+PB-TuM5, 103
 Ranjan, A.: PS+AS+EM+SS-MoM11, 85; PS+EM+SE-TuM5, 103; PS+EM+TF-ThA10, 157; PS-ThM11, 149; PS-ThM2, 149
 Rao, M.R.: SS+AS+BI+MI+NS-ThA6, 158
 Rao, R.: EM+2D+NS+PS+RM+TF-ThA3, 154
 Raschke, M.B.: NS+MN+PC+SS-WeA11, 139
 Rasmussen, J.B.: SE-MoA9, 94
 Rathi, M.: TF-MoA4, 95
 Rathssack, B.: PS+EM+TF-ThA10, **157**
 Ratner, B.D.: IPF+AS+BI+NS-MoM1, **83**
 Rauf, S.: PS+EM+SE-TuM3, 103; PS-FrM1, 169; PS-FrM11, 169; PS-FrM2, 169; PS-FrM8, 169; PS-FrM9, 169; PS-ThM1, **149**
 Raut, S.: EM+MI+MN+NS-ThM12, 146
 Ravichandran, J.: RM+EM+NS-TuA10, 114; SS+HC+MI-TuA12, 115; TF+EM+MI-WeA8, 141
 Rawal, T.B.: 2D+AM+EM+NS-WeM2, 124; HC+SS-TuM2, 100; SS+HC+MI-TuA7, 115; SS+HC-MoA3, **94**
 Ray, D.: TF-MoA8, 95
 Ray, S.: BI+AS+NS-FrM6, 168
 Razavi, H.: PS+PB+SE-TuA12, **113**
 Rea, M.T.: NS+AN+EM+MN+MP+RM-TuM5, 102
 Rebelo de Figueiredo, M.: SE-TuA11, 114
 Reddy, P.: TF+AS+EL+PS-ThM1, 151
 Redon, S.: 2D+MN+NS+SS-WeA1, **134**
 Redwing, J.M.: 2D+EM+MI+NS+TF-MoM1, 81; TF+AM+EM+PS-TuM6, 105
 Redzheb, M.: PS-TuP22, 119
 Reed, E.J.: 2D+EM+MI+NS+TF-MoM6, 81
 Reed, R.A.: MN+2D+AN+NS-ThA3, 156
 Reese, J.: EL+AS+EM-MoM11, 82
 Regan, D.: BI-ThA9, 153
 Regoutz, A.: SA+MI-ThM12, **150**
 Reilly, D.R.: AC+AS+SA-ThM1, 144
 Reinke, P.: SS+AS+HC-FrM3, 170; SS+EM+PS+TF-ThA8, 159
 Rementer, C.R.: MI+2D-ThM12, 147
 Remy, A.: PS-TuP17, **119**
 Ren, F.R.: EM+2D+SS-WeA2, 137; EM+2D+SS-WeA9, 137; EM-ThP11, 161
 Ren, J.H.: NS-ThP13, 162
 Ren, W.C.: EL+AS+EM-MoM8, 82
 Ren, Y.: PS+EM-WeA3, 140
 Renaud, V.: PS+EM+TF-ThM13, **149**; PS+EM-WeM6, 129
 Renault, O.J.: 2D+AM+EM+NS-WeM12, 124; 2D+MN+NS+SS-WeA2, 134; AS+NS+SA-WeM2, **125**; SA+AS+MI-WeA9, 140
 Reniers, F.: PB+BI+PC+PS-WeA7, 139; PS+EM+NS+SS-TuA7, 113; PS+PB+SE-TuA8, 113; PS+TF-MoM9, 85; PS-TuP15, 119; PS-TuP17, 119
 Repetto, L.: SS-TuP6, 120
 Requena, S.: EM+MI+MN+NS-ThM12, 146
 Retterer, S.: HI+AS-ThM4, 147
 Reuter, R.: TF+AS+EL+PS-ThM12, 151
 Reutt-Robey, J.E.: SS+AS+BI+MI+NS-ThA3, **158**
 Reza, S.: EM+2D+SS-WeA11, 137
 Rezaifar, F.: SS+AS+EM-WeA11, **141**
 Rezvanov, A.: PS+EM-WeA9, 140
 Rhim, G.B.: HC-ThP1, 161
 Rhodes, K.: AS+SE-WeA7, 135
 Richard-Plouet, M.: AS+SE-ThM3, 145
 Richardson, C.J.K.: MP+EM+NS-TuM1, **101**
 Richardson, J.G.: TF-ThP24, **163**
 Richter, C.: AM+MP+NS-WeA7, 135; EM+2D+NS+PS+RM+TF-ThA4, 154
 Rickard, A.: TF+AS-TuM5, 105
 Ricker, J.E.: VT-MoM3, 88; VT-MoM5, 88; VT-TuA11, **116**
 Rickhaus, P.: 2D+EM+MI+MN+NS-TuA3, 109
 Riedl, H.: SE+NS+TF-MoM6, 86
 Riedl, T.J.: TF-MoA1, **95**
 Riendeau, J.: AS+SE-WeA12, 135
 Rigby-Singleton, S.: AS+NS-ThA10, 153
 Riis, H.G.: TF-ThP23, 163
 Riseborough, P.S.: AC+MI+SA-WeM5, **124**
 Ritala, M.K.: TF+AS-TuM12, 105
 Rittschof, D.: BI-WeA7, 136
 Rivolta, N.: TF+EM+MI-WeM13, 131
 Roberts, A.J.: AS-MoM9, 81; EW-TuL4, **108**
 Roberts, D.J.: AC+AS+SA-ThM11, 144
 Robey, S.W.: SS+AS+BI+MI+NS-ThA8, 158
 Robinson Brown, D.: AS+NS+SA-WeM13, 125
 Robinson, J.T.: 2D+EM+MI+MN+NS-TuA1, 109
 Robinson, K.: BI+AS+IPF+NS-TuA2, **110**
 Robinson, Z.R.: PS+EM+TF-ThA8, 157; TF+EM+MI-WeM6, 131; TF-ThP38, 163
 Robledo, R.: BI-ThA6, 153
 Rocca, M.: SS+EM+NS-ThM3, **150**; SS+HC-MoA3, 94
 Rocco, E.: EM+2D+SS-WeA10, 137
 Rochat, N.: PS+EM+TF-ThM13, 149; PS+EM-WeM6, 129
 Rodolakis, F.: SA+MI-ThM1, 150
 Rodrigues, W.N.: AS+SE-ThM11, 145
 Rodriguez Gutierrez, H.: 2D+EM+MN+NS-FrM3, **167**
 Rodriguez Lopez, G.: AS+NS+SA-WeM1, 125
 Rodriguez, J.A.: HC+SS-ThM1, 146; HC+SS-TuM3, 100
 Rodriguez, J.C.: SS-TuP11, 120
 Rodriguez-Fernandez, J.: SS+HC-WeM6, 130
 Rodríguez-Fernandez, J.: HC+SS-TuM11, 100
 Rodríguez-Fernández, J.: SS+HC+NS+PS-TuM5, **104**
 Rodriguez-Lamas, R.R.: SA+AS+MI-WeA9, 140
 Rodriguez-Nieva, J.: 2D-ThP2, 160; NS+2D+AS+MN+PC-ThA4, 156
 Roeters, S.: BI+AS+IPF+MN-MoA5, 90
 Rogge, S.: NS+AM+MI+MN+SS+TR-TuA1, **112**
 Roh, H.-J.: PS-ThA10, 157; PS-ThA11, 157
 Rohlfing, M.: MI+EM-FrM7, 168
 Rohnke, M.: BI+AS+NS-FrM6, **168**
 Rojas Sánchez, J.C.: MI+EM-FrM1, **168**
 Roldan Cuenya, B.: HC+SS-ThM5, **146**
 Romero, A.: AC+MI+SA-WeM13, 124
 Roozeboom, F.: TF+AS+EL+EM+NS+PS+SS-ThA6, 159; TF2-MoM4, 87
 Rosa, A.M.: PS-TuP20, 119
 Rosa, A.M.Rosa.: NS-ThP4, **162**
 Rose, V.: NS+2D+AS+PC-MoA4, **93**
 Rosen, J.: SE+PS-TuM5, 104
 Rosenberg, R.A.: MI+BI-ThA2, **155**
 Rosenberg, S.G.: PS+EM+TF-ThA8, **157**; PS+TF-MoM11, 85; TF-ThP38, 163
 Rosenberger, M.: 2D+EM+MN+NS-ThA1, 152; NS-ThP18, 162
 Rosenblatt, S.: MP+AM+EM+NS-MoA10, **92**
 Rosenhahn, A.: BI-WeA9, **136**
 Roshko, A.: TF+AM+EM+PS-TuM4, 105
 Roslawska, A.: NS+2D+AS+MN+PC-ThA8, **156**
 Ross, F.M.: MM+AS+NS+PC-MoM3, **83**
 Roth, T.: NS-ThP12, 162
 Rothemund, P.W.K.: BP-SuA1, **78**
 Rothschild, M.: 2D+EM+MN+NS-ThA7, 152
 Rouleau, C.: 2D+EM+MI+NS+TF-MoM5, 81
 Rousse, F.: 2D+MN+NS+SS-WeA1, 134
 Rousseau, R.: HC+SS-WeM2, 126
 Roussel, C.: SS-TuP4, 120
 Roussel, P.: EL-TuP1, 118
 Routkevitch, D.: TF+PS-ThM2, **151**
 Rowley, A.H.: TF+EM+MI-WeM6, 131
 Rowley, J.T.: 2D+EM+MI+NS-ThM3, 99
 Roy, S.: HC+SS-ThA10, **154**; HC+SS-TuA7, 111; HC+SS-WeM6, 126; SS+HC-MoA8, 94
 Roychowdhury, T.R.: TF+SS-TuA10, **116**
 Rozhkova, E.A.: MI+BI-ThA6, **155**
 Ruach Nir, I.: VT-TuA1, **116**
 Rubinstein, I.: AS+SE-ThM4, 145
 Rubio Zuazo, J.: SA+AS+HC+SS-ThA10, 158
 Rubloff, G.: TF2-MoM5, **87**
 Ruchhoeft, P.: PS-ThA8, 157; PS-TuP21, 119
 Rueff, J.-P.: AS+NS+SA-WeM2, 125
 Rueff, J.P.R.: SA+AS+MI-WeA9, 140
 Rufino, F.C.: 2D-ThP4, 160
 Ruggieri, C.: SS+EM+PS+TF-ThA7, 159
 Ruiz, C.S.: PS-TuP20, **119**
 Ruiz, D.: EM-ThP8, 161
 Rumaiz, A.K.: SA+AS+MI-WeA12, 140
 Rummel, B.: VT-TuP1, **120**
 Rundberg, R.: AC+AS+SA-ThM5, 144
 Rupich, S.M.: EM+AN+MI+SS-WeM10, 126
 Rupp, R.: RM+EM+NS-TuA3, **114**
 Ruwe, L.: HI+AS-ThM10, 147
 Ruzic, D.N.: PS+EM+NS+SS-TuA10, 113; PS+PB+SE-TuA9, 113; PS+PB-TuM3, 103; PS+TF-MoM1, 85; PS-TuP19, 119; SS+EM+PS+TF-ThA9, **159**
 Ryoo, R.: HC-ThP2, 161
 Ryou, H.: BI-WeA7, 136
 Ryou, J.-H.: TF-MoA4, 95
 Ryu, H.: 2D+EM+MI+MN+NS-TuA2, 109
 Ryu, J.S.: PS-TuP10, **119**; PS-TuP11, 119
 Ryu, J.R.: BI-ThM13, **145**
 Ryu, S.: PS-ThA10, 157; PS-ThA11, **157**
 Ryu, S.Y.: RM-TuP1, 120; TF+EM+MI-WeM11, **131**
 Rziga, G.: BI+AS+IPF+NS-TuA3, 110
 — S —
 S. Hwang, G.: PS+AS+EM+SS-MoM11, 85
 Sabau, A.: AS-ThP6, 160
 Sadeghpour, H.R.: MP+EM+MN+NS-MoM8, 84
 Sadighi, S.: PS+EM+SE-TuM3, 103; PS-FrM2, 169
 Saeed, A.: TF+EM+MI-WeA12, 141
 Saerbeck, T.: MI+2D+EM+NS-MoA5, 91
 Saidi, W.A.: HC+SS-ThA11, 154
 Saito, M.: TF+EM+MI-WeM5, **131**
 Sakai, O.: MI+EM-FrM3, 168
 Sakar, B.: MI+2D-ThM13, **147**
 Sakata, I.: PS+AS+EM+SS-MoM9, 85; PS-TuP4, **119**
 Salamanca, M.: HI+AS-ThM10, 147
 Salditt, T.: IPF+AS+BI+MN-TuM12, 100
 Salim, E.A.: VT-TuA7, **116**
 Salleo, A.: RM-TuP3, 120
 Salmeron, M.B.: HC+SS-WeA10, 137
 Salmon, N.J.: MM+AS+NS+PC+SS-MoA8, 92
 Salvetat, J.P.: MN+NS+PS-WeM10, 127
 Samano, E.C.: EM-ThP8, **161**
 Samara, V.: PS+PB-TuM2, 103
 Samarasingha, N.: EL+AS+EM-MoM4, 82; EL+EM-MoA5, **90**; EL-TuP4, 118
 Sambur, J.B.: 2D-ThP5, 160

Author Index

Sampath, A.: HC+SS-TuA8, **111**
 Sampath, W.S.: EM+2D+AN+MI+MP+NS-TuA3, 110; TF-MoA5, 95
 Samuha, S.: AC+AS+SA-ThM3, 144
 Samukawa, S.: NS-ThP9, 162; TF+EM+MI-WeM10, 131
 Sanchette, F.: SE-TuA9, **114**
 Sanchez-Grande, A.: SS+HC-WeM6, **130**
 Sandberg, M.O.: MP+AM+EM+NS-MoA10, 92
 Sander, D.: MI+2D-ThM5, **147**
 Sandoval, T.E.: TF1-MoM2, **87**
 Sandrez, S.M.: TF+AS+EL+EM+NS+PS+SS-ThA4, 159
 Sanford, N.: EM+MP+PS-MoM6, 82
 Sang, X.: 2D+EM+MI+NS+TF-MoM5, 81; MM+AS+NS+PC-MoM8, 83
 Sangely, L.: AC+AS+SA-ThM12, 144
 Sangiovanni, D.: SE+NS+TF-MoM10, 86; SE+NS+TF-MoM11, 86
 Sangiovanni, D.G.: SE-MoA3, 94
 Sangtae, K.: TF+EM+MI+PS-MoA3, 95
 Sankaran, R.M.: MN+NS+PS-WeM3, 127; PS+EM+NS+SS-TuA7, 113; PS+PB+SE-TuA3, **113**
 Sansa, M.: MN+2D+AN+NS-ThA4, 156
 Santos-Clotas, E.: HC-ThP7, 161
 Sanz-Hernandez, D.: AM+NS+SS-WeM3, 125
 Sapkota, P.S.: PC+AS+BI+EM+NS+PB+SS-TuP1, **119**
 Saraf, S.: VT-TuM1, **106**
 Sarafian, A.R.: AS+SE-ThM5, 145
 Sarkar, D.: EM+MP+PS-MoM2, **82**; RM+EM+NS-TuA9, 114
 Sato, N.: PS+EM-WeA9, 140
 Satriano, C.: BI-ThM11, **145**; BI-ThM5, 145
 Sattelkow, J.: AM+NS+SS-WeM1, 125; AM-TuP1, 118
 Sautet, P.: HC+SS-WeA10, 137
 Savio, L.: SS+EM+NS-ThM3, 150; SS+HC-MoA3, 94
 Sawadichai, R.: PS-ThA8, 157; PS-TuP21, **119**
 Sawant, S.Y.: SS-TuP14, 120
 Sayed, M.S.: SS-TuP14, 120
 Sayeed, M.N.: AS-ThP11, **160**
 Sayler, J.D.: SS+AS+BI+MI+NS-ThA2, **158**
 Scally, L.: PS+PB+SE-TuA10, 113
 Scarabelli, L.: NS-ThP15, 162
 Scarbolo, P.: BI+AS+IPF+NS-TuA3, 110
 Schaefer, A.: HC+SS-ThA2, 154; HC+SS-ThM2, 146
 Schäfer, A.: BI+AS+IPF+MN-MoA5, 90
 Schatz, G.C.: TF1-MoM1, 87
 Schauble, K.: 2D+EM+MI+NS-TuM12, 99
 Schauermann, S.: HC+SS-WeM3, **126**
 Schelter, E.: AC+AS+SA-WeA1, **134**; AC+MI+SA-FrM8, 167
 Schendel, V.: NS+AM+AS+MN+PC+PS+SS+TR-FrM4, 169
 Scherschligt, J.: NS+AN+EM+MN+MP+RM-TuM12, 102; VT-MoA1, 96; VT-MoA3, 96; VT-MoM4, **88**
 Schilling, A.C.: HC+SS-TuM1, **100**; SS+HC-MoA1, 94
 Schlesinger, I.: NS+MN+PC+SS-WeA7, 139
 Schlickum, U.: NS+AM+AS+MN+PC+PS+SS+TR-FrM4, 169
 Schlögl, R.: PC+AS+BI+EM+NS+PB+SS-TuA7, 112
 Schlosser, D.: BI+AC+AS+HC+NS+SS+TF-WeA7, 136
 Schmid, M.: SS+HC+MI-TuA3, 115
 Schmidt, B.W.: AS+SE-ThM11, 145; AS+SE-WeA10, **135**
 Schmidt, S.B.: SS+HC+NS+PS-TuM5, 104
 Schmitz, C.: SA+AS+HC+SS-ThA7, 158
 Schmucker, S.W.: AM+MP+NS-WeA7, 135
 Schneider, C.M.: MM+AS+NS+PC+SS-MoA4, 92; SA+AS+HC+SS-ThA7, **158**; SA+AS+MI-WeA1, 140
 Schneider, J.M.: SE-MoA4, 94; TR-TuP2, 120
 Schneider, J.R.: TF-TuM11, 106
 Schneider, W.F.: HC+SS-ThA8, **154**
 Schnepf, P.: MN+2D+AN+NS-WeA11, 138
 Schoeneck, B.: EM-ThP18, 161
 Schoenemann, E.: BI-WeA9, 136
 Schöllkopf, W.: SA+AS+HC+SS-ThA6, 158
 Schowalter, S.J.: VT-MoA8, **96**
 Schrimpf, R.D.: MN+2D+AN+NS-ThA3, 156
 Schroeder, C.: PS+PB+SE-TuA4, 113
 Schroeder, W.: PS+PB+SE-TuA4, 113
 Schubert, E.: EL+AS+EM-MoM3, 82
 Schubert, M.: EL+AS+EM-MoM3, 82; EL+EM-MoA1, **90**
 Schuck, P.J.: EM+MI+MN+NS-ThM10, **146**
 Schuelke, T.: PS+EM+NS+SS-TuA11, 113
 Schuller, I.K.: MI+2D+EM+NS-MoA5, **91**
 Schulmeyer, T.: MM-TuP1, **118**
 Schultz, J.: NS+AM+MI+MN+SS+TR-TuA3, **112**; NS-ThP1, 162
 Schultzhaus, J.: BI-WeA7, 136
 Schulze, S.: HI-ThA3, **155**
 Schuschke, C.: SS+AS+EM-WeA9, 141
 Schwab, L.: MN+NS+PS-WeM10, 127
 Schwalb, C.: AM-TuP1, 118
 Schwan, J.: TF2-MoM10, 87
 Schwantes, J.M.: AC+AS+SA-ThM1, 144
 Schwarz, M.: SS+AS+EM-WeA9, 141
 Schwarz, U.D.: 2D+EM+MI+MN+NS+SS-ThM2, 144; AS-MoA6, 89; NS+2D+AS+PC-MoA8, **93**
 Schwenk, J.: 2D-ThP6, **160**
 Schwier, E.: MI+EM-FrM7, 168
 Schwind, G.A.: HI-ThA6, **155**
 Schöche, S.: EL+AS+EM-MoM11, 82
 Scoble, J.A.: BI+AS+NS-FrM3, 168
 Scott, B.L.: AC-ThA3, 152
 Scully, J.R.: SE-TuP7, 120
 Scurr, D.J.: AS+NS-ThA10, 153; BI+AS+NS-FrM1, **168**
 Secme, A.: MN+2D+AN+NS-WeA3, 138
 Seddon, P.: PS+MN-WeM5, **130**
 Seehra, S.: AC+MI+SA-WeM13, 124
 Segato, T.: PS+EM+NS+SS-TuA7, 113
 Segawa, T.: TF-ThP17, **163**
 Segers, M.: PS+MN-WeM4, **130**
 Segovia Miranda, A.: VT-MoM11, 88
 Seibert, A.: AC+MI+SA-WeM10, 124
 Seibert, R.: AC+AS+SA-ThM13, 144
 Seidel, S.: SE-TuP2, 120
 Seify, O.: VT-TuM13, **106**
 Seitzman, N.: AS-MoA1, **89**
 Sekine, M.: PS+AS+EM+SS-MoM11, 85; PS+EM+SE-TuM13, 103; VT-TuP2, **121**
 Sekora, D.: EL+AS+EM-MoM3, 82
 Selmi, L.: BI+AS+IPF+NS-TuA3, 110
 Selvamanickam, V.: TF-MoA4, 95
 Senanayake, S.: HC+SS-TuM3, 100
 Sen-Britain, S.: BI+AS+NS-FrM7, **168**
 Seo, M.W.: TF-ThP37, 163
 Seo, S.E.: BI-TuP1, **118**
 Seong Keun, K.: TF+EM+MI+PS-MoA3, 95
 Seong, K.J.: PS+EM-WeM11, 129
 Sepulveda, B.: PC+AS+BI+EM+NS+PB+SS-TuP2, 119
 Serov, A.: AS+SE-WeA11, 135
 Serrano Rubio, A.: SA+AS+HC+SS-ThA10, 158
 Servis, M.: AC+AS+SA-ThM5, 144
 Setlur, A.: MS-TuP5, 118
 Setvin, M.: SS+HC+MI-TuA3, 115
 Sgammato, W.S.: AS-ThP2, **160**
 Shacham-Diamond, Y.: NS+AN+EM+MI+MN+MP+PS+RM-ThM1, 148
 Shafer, J.: AC+AS+SA-ThM5, **144**
 Shah, D.S.: TF+PS-ThM10, **151**
 Shahariar, H.: TF+AS+EL+EM+NS+PS+SS-ThA10, 159
 Shahedipour-Sandvik, F.: EM+2D+SS-WeA10, 137
 Shakya, D.: HC-ThP3, 161
 Shalaev, P.: VT-MoM1, **88**
 Shan, D.: NS+2D+AS+MN+PC-ThA9, **156**
 Shan, X.Y.: EL+AS+EM-MoM9, 82
 Shannon, S.: PS-FrM8, 169; PS-ThA6, 157; PS-ThM5, **149**
 Shao, D.: AS+SE-WeA12, 135
 Shao, D.-F.: MI+EM-FrM9, 168
 Shao, L.: PS+EM-WeA2, 140
 Shapiro, D.A.: PC+AS+BI+EM+NS+PB+SS-TuP5, 119
 Shapturenka, P.: EM+MI+MN+NS-ThM6, **146**; PS+MN-WeM3, 130
 Sharan, C.: BI+AS+IPF+NS-TuA4, 110
 Shard, A.G.: AS-MoM1, **81**
 Sharma, A.: NS+2D+AN+EM+MN+MP+PC+RM-MoM3, **84**; SS+EM+NS-ThM12, 150
 Sharma, E.: EL+AS+EM-MoM11, 82
 Sharma, R.: MM+AS+NS+PC-MoM11, 83
 Sharma, S.: 2D+MN+NS+SS-WeA4, 134; TF+PS-TuA9, 115
 Shaw, S.: MN+2D+AN+NS-ThA1, 156
 Shaw, S.W.: MN+2D+AN+NS-ThA8, 156
 Shaw, W.: SA+AS+HC+SS-ThA11, 158
 Shayestehaminzadeh, S.: TF+EM+MI-WeM13, 131
 She, J.: EM-ThP16, 161
 Shearer, J.C.: PS+EM-WeA1, **140**
 Sheil, R.: TF2-MoM3, **87**
 Shekhawat, G.: 2D+EM+MI+NS-TuM2, 99
 Shelby, R.M.: MS+MI+RM-TuM5, 101
 Shen, M.: PS+EM-WeA12, 140
 Shen, S.: AS+SE-WeA9, 135
 Shen, Y.: SE-TuA3, 114
 Shenderova, O.A.: TF+AS-TuM5, **105**
 Sherwood, P.M.: AS-MoM4, **81**
 Sheves, M.: NS+2D+AS+MN+PC-ThA3, 156
 Shi, J.: TF+SS-TuA9, 116
 Shiba, Y.: PS+AS+EM+SS-MoM3, 85; TF+EM+MI-WeM5, 131
 Shibata, K.: VT-TuP4, 121; VT-TuP6, **121**
 Shichi, H.: HI-ThA1, 155
 Shigeno, S.: PS+EM+NS+SS-TuA12, 113
 Shih, C.-Y.: AS-TuA3, 109
 Shim, J.-J.: SS-TuP14, 120
 Shim, S.: PS+EM+SE-TuM4, 103
 Shimada, K.: MI+EM-FrM7, 168
 Shimizu, H.: BI-ThM12, 145
 Shimizu, R.: PS+EM-WeA7, **140**
 Shimoyama, Y.: SS+HC+NS+PS-TuM13, 104
 Shin, E.J.: BI-TuP12, **118**
 Shin, hss.: VT-TuP12, 121
 Shin, K.S.: TF-ThP14, 163
 Shin, Y.: PC+AS+BI+EM+NS+PB+SS-TuP5, 119
 Shin, Y.J.: PS-TuP12, 119
 Shindo, T.: PS+TF-MoM10, 85
 Shinoda, K.: PS+EM+TF-ThA3, 157; PS+EM+TF-ThM3, **149**
 Shipilin, M.: HC+SS-ThA2, 154; HC+SS-ThA7, 154; HC+SS-ThM2, 146; HC+SS-WeM10, 126; HC+SS-WeM11, 126
 Shirahata, N.: TF+EM+MI-WeA1, **141**
 Shirai, M.: VT-TuP4, 121; VT-TuP6, 121
 Shiratani, M.: PS+EM+NS+SS-TuA8, 113
 Shirato, N.: NS+2D+AS+PC-MoA4, 93

Author Index

Shiawku, H.: AC+AS+SA-WeA3, 134

Shklovsky, J.:
NS+AN+EM+MI+MN+MP+PS+RM-ThM1,
148

Shohet, J.L.: PS+PB-TuM10, 103; PS+PB-TuM12, 103; PS-TuP22, **119**; PS-TuP23, 119; TF-ThP29, 163

Shoshani, O.: MN+2D+AN+NS-ThA8, 156

Shrestha, M.: PS+EM+NS+SS-TuA11, 113

Shrestha, R.: BI-ThA1, 153

Shu, J.: AS+SE-WeA12, 135

Shugaev, M.: AS-TuA3, 109

Shuh, D.K.: AC+AS+SA-ThM10, **144**

Shukla, A.K.: PC+AS+BI+EM+NS+PB+SS-TuP4, 119

Shukla, D.: PS+EM+NS+SS-TuA1, 113

Shulda, S.: AS-ThP4, 160

Shutthanandan, V.: SE-TuA7, **114**

Si, R.: SS+AS+HC-FrM5, 170

Si, S.: NS-ThP16, **162**

Sibener, S.J.: SS+AS+BI+MI+NS-ThA2, 158; SS+EM+PS+TF-ThA6, 159; SS+HC+MI-MoM10, 86; SS-TuP15, 120

Siddique, H.: EL+AS+EM-MoM9, 82; EM+2D+AN+MI+MP+NS-TuA4, **110**

Siligardi, G.: BI-ThM3, 145

Silski, A.: PC+AS+BI+EM+NS+PB+SS-TuA12, **112**

Silva Quiñones, D.: SS-TuP11, **120**

Silva, A.R.: EM-ThP6, 161; PS-TuP18, 119

Silver, R.M.: AM+MP+NS-WeA7, 135

Simanjuntak, F.M.: TF+EM+MI-WeM10, **131**

Simchi, H.: EM+AM+NS+PS-MoA8, 91

Simon, G.: AS-MoA6, 89

Simoncig, A.: SA+MI-ThM5, 150

Simonovis Santamaría, J.P.: HC+SS-ThM11, **146**

Simons, D.S.: AS+BI-TuM10, 99

Simpson, R.E.: AS-ThP2, 160; EW-TuL3, 108

Simpson, S.C.: VT-TuM12, 106

Sinclair, N.: SA+AS+HC+SS-ThA11, 158

Singh, A.: EL+EM-MoA5, 90

Singh, A.P.: HC-ThP5, 161

Singh, B.: AS-MoA9, 89

Singh, C.V.: 2D+EM+MI+NS-TuM1, 99

Singh, J.A.: TF-TuM11, 106

Singh, J.P.: BI+AS+IPF+NS-TuA4, 110

Singh, R.: EL+EM-MoA5, 90

Singh, S.: SS+HC+NS+PS-TuM13, 104

Singh, S.K.: AS-MoA5, 89

Singhal, S.I.: PC+AS+BI+EM+NS+PB+SS-TuP4, **119**

Singleton, D.: PS+PB+SE-TuA4, 113

Sinnott, S.: 2D+AM+EM+NS-WeM1, 124

Sirota, B.: 2D+EM+MI+MN+NS-TuA8, **109**

Sisco, E.: AS+SE-ThM10, 145

Sitar, Z.: TF+AS+EL+PS-ThM1, 151

Sivan, U.: NS+MN+PC+SS-WeA7, **139**

Sivaram, S.V.: 2D+EM+MN+NS-ThA1, 152; 2D+EM+MN+NS-ThA2, 152; NS-ThP18, 162

Skelton, J.M.: AM-TuP2, **118**; SE-TuP7, 120

Skeren, T.: AM+MP+NS-WeA11, 135

Skibinski, E.S.: SS+AS+BI+MI+NS-ThA10, 158

Skoric, L.: AM+NS+SS-WeM3, 125

Skvarla, M.: MS-TuB1, **107**

Smentkowski, V.S.: MS-TuP5, **118**

Smerieri, M.: SS+EM+NS-ThM3, 150; SS+HC-MoA3, 94

Smieska, L.: VT-TuM5, 106

Smiles, D.E.: AC+AS+SA-ThM10, 144

Smiljanic, M.: PS+EM+NS+SS-TuA7, 113

Smith, C.: BI-ThA6, 153; HC-ThP6, **161**; PS-ThM5, 149

Smith, C.R.: NS-ThP19, 162

Smith, D.: VT-TuP3, **121**

Smith, J.: EM+MP+PS-MoM8, 82

Smith, J.L.: AC+AS+SA-WeA10, 134

Smith, R.S.: HC+SS-WeM1, 126

Smith, S.: TF+EM+MI+PS-MoA8, 95

Smith, D.N.: PS-FrM12, 169

Smith, K.: 2D+EM+MI+NS-TuM12, **99**

Smolenski, K.: VT-TuM5, 106

Smolin, J.: MP+AM+EM+NS-MoA10, 92

Smyth, C.M.: EM-ThP14, 161

Snook, A.: PS+PB-TuM5, 103

Snow, C.S.: AS+NS+SA-WeM13, 125

Snure, M.: EM-ThP3, 161

So, C.R.: BI-WeA7, 136

Sobolewski, M.A.: PS-ThA1, **157**

Soeda, M.: VT-TuP2, 121

Soethoudt, J.: TF+AM+EM+PS-TuM10, 105

Sohi, U.: RM-TuP3, 120

Solis, L.H.: IPF+AS+BI+NS-MoM5, 83

Solot, A.: MN+NS+PS-WeM13, 127

Soltis, J.A.: AC+AS+SA-ThM1, 144

Someya, T.: TF+AS+EL+EM+NS+PS+SS-ThA1, 159

Somnath, S.: NS-ThP19, 162

Somorjai, G.A.: PC+AS+BI+EM+NS+PB+SS-TuA9, **112**

Son, J.: 2D+EM+MN+NS-FrM8, **167**

Song, B.K.: EL+AS+EM-MoM8, **82**

Song, D.H.: TF-ThP18, 163

Song, E.-J.: NS-ThP21, 162

Song, G.: TF-ThP23, 163

Song, M.S.: 2D+EM+MI+MN+NS-TuA7, 109

Song, X.: EM-ThP16, 161

Song, Z.: SS+EM+NS-ThM6, 150

Sorescu, D.C.: SS+HC+NS+PS-TuM10, 104; SS+HC+NS+PS-TuM6, 104

Soria, M.: HC+SS-TuA1, 111

Sornakdanuphap, J.: PS+PB-TuM4, 103

Sortica, M.: SE+PS-TuM5, 104

Soykal, O.: EM+2D+AN+MI+MP+NS-TuA9, 110

Spanopoulos, I.: 2D+EM+MI+NS-TuM2, 99

Spatz, J.P.: IPF+AS+BI+NS-MoM3, **83**

Sperling, B.: 2D+MI+NS-MoA3, 89

Sperling, B.A.: TF1-MoM8, **87**

Spiegelman, J.: EM+AM+NS+PS-MoA10, 91; TF1-MoM4, 87; TF1-MoM9, 87

Spillmann, C.M.: BI-WeA7, 136

Spivey, R.: MP+EM+MN+NS-MoM9, 84

Sprenger, J.K.: TF+AM+EM+PS-TuM4, **105**

Sprowl, L.H.: BI+AC+AS+HC+NS+SS+TF-WeA11, 136

Sridhar, S.: PS+EM+SE-TuM5, **103**

Stacchiola, D.J.: HC+SS-TuM3, 100; SA+AS+HC+SS-ThA1, 158

Stafford, L.: PS+TF-MoM3, **85**

Stahl, D.: NS-ThP12, 162

Stair, P.C.: HC+SS-TuA3, **111**; TF1-MoM1, 87

Stanek, J.: NS+AM+MI+MN+SS+TR-TuA11, 112

Stanford, M.G.: 2D+MN+NS+SS-WeA9, 134; AM+NS+SS-WeM3, 125; MM+AS+NS+PC-MoM5, 83

Stanwyck, S.: MP+EM+NS-TuM2, **101**

Stavitski, E.: SA+AS+HC+SS-ThA1, 158

Staykov, A.: AS+SE-ThM1, 145

Stecklein, G.: 2D+EM+MI+MN+NS-TuA11, 109; 2D+EM+MI+NS+TF-MoM2, 81

Steele, A.V.: HI-ThP2, 161

Stein, B.W.: AC+AS+SA-WeA7, **134**; AC-ThA3, 152

Steirer, K.X.: EM+AN+MI+SS-WeM6, 126

Stene, R.: EW-TuB3, **107**

Stephani, K.: SS-TuP12, 120

Sternbisky, G.E.: SA+AS+MI-WeA12, 140

Steven, R.: IPF+AS+BI+MN-TuM10, **100**

Stevens, E.: SE-TuA7, 114

Stiles, M.D.: RM+EM+NS-TuA11, 114

Stohmann, P.: 2D+EM+MI+MN+NS+SS-ThM11, 144

Storm, D.F.: TF+EM+MI-WeM1, 131

Stout, P.J.: PS-FrM2, 169

Stoyanov, P.: SE-TuP6, **120**

Strandwitz, N.C.: TF-MoA6, **95**

Strelcov, E.: MM+AS+NS+PC+SS-MoA10, 92; MM+AS+NS+PC+SS-MoA4, 92; RM-TuP2, 120; SA-ThP3, **162**

Strikovski, M.D.: NS-ThP14, **162**

Strohmeier, B.: AS+SE-WeA7, **135**

Strong, R.: BI+AC+AS+HC+NS+SS+TF-WeA10, 136

Stroscio, J.A.: 2D-ThP2, 160; 2D-ThP6, 160; NS+2D+AS+MN+PC-ThA4, 156

Strukov, D.: RM-TuP2, 120

Strzemechny, Y.M.: EM+MI+MN+NS-ThM12, **146**

Stuart, B.W.: TF+AS+EL+EM+NS+PS+SS-ThA11, **159**

Stucchi-Zucchi, L.: EM-ThP6, **161**

Stumbo, D.: AS+BI-TuM12, 99

Stutzman, M.L.: VT-MoM11, **88**

Stutzmann, M.: BI+AS+IPF+NS-TuA3, 110; EM+AN+MI+SS-WeM13, 126

Su, NS+2D+AS+PC-MoA5, **93**

Su, C.-Y.: PS-TuP9, **119**

Su, J.: AC+AS+SA-WeA1, 134; AC-ThA1, 152; AC-ThA3, 152

Su, J.S.: MN-ThP2, 162

Su, L.: AS-TuA4, 109

Su, Q.: PS+EM-WeA2, **140**

Suanpoot, P.: PS+PB-TuM4, **103**

Subramanian, S.: PS+PB+SE-TuA4, 113

Sudeep, P.M.: 2D+EM+MI+NS-ThM1, 99

Sudre, G.: BI-ThA1, 153

Suenaga, K.: 2D+MI+NS-MoA5, **89**; AM+NS+SS-WeM12, 125

Suetsugu, Y.: VT-TuP4, **121**; VT-TuP6, 121

Sugawa, S.: PS+AS+EM+SS-MoM3, 85; PS-ThM10, 149; TF+EM+MI-WeM5, 131

Sui, Y.: MN+NS+PS-WeM3, 127

Sulas, D.: AS-MoA1, 89

Sullivan, P.: VT-MoM3, 88

Sulyok, A.: AS+NS+SA-WeM10, 125

Sumant, A.V.: TR+AS+NS+SS-MoM10, 88

Sumpter, B.G.: 2D+MN+NS+SS-WeA9, 134; HI+AS-ThM4, 147

Sun, B.: BI+AS+IPF+NS-TuA1, 110; BI+AS+IPF+NS-TuA8, 110

Sun, H.: TF+AM+EM+PS-TuM4, 105

Sun, S.: TF-MoA4, 95

Sun, X.: PS+EM-WeA10, **140**

Sun, Y.: 2D+EM+MI+NS-ThM1, 99

Sun, Z.: AS+SE-WeA12, 135; HC+SS-TuM11, 100

Sung, D.I.: PS-TuP12, 119

Surman, D.: EW-TuL4, 108

Suryavanshi, S.: 2D+EM+MI+NS-ThM12, 99

Sushko, P.V.: SE-TuA7, 114

Susi, T.: AM+NS+SS-WeM12, 125

Susman, M.D.: AS+SE-ThM4, 145

Susner, M.A.: 2D+EM+MI+MN+NS+SS-ThM6, 144; 2D+EM+MN+NS-ThA6, 152

Sussman, M.R.: PS+PB-TuM10, 103; PS+PB-TuM12, 103

Suwa, T.: TF+EM+MI-WeM5, 131

Suzer, S.: AS+NS+SA-WeM11, 125; PC+AS+BI+EM+PB+SS-WeM4, **128**

Suzuki, A.: PS+TF-MoM10, 85

Suzuki, S.: AC+AS+SA-WeA3, 134

Suzuki, T.: MI+EM-FrM3, **168**

Author Index

Sverdlov, Y.: NS+AN+EM+MI+MN+MP+PS+RM-ThM1, 148

Swaminathan-Gopalan, K.: SS-TuP12, 120

Swart, H.C.: SS+HC-WeM5, 130; TF+AS-TuM3, 105

Swartz, L.: AS+SE-WeA10, 135

Swenor, J.: BI-TuP9, 118

Switzer, J.: EM+2D+NS+PS+RM+TF-ThA1, 154

Sykes, E.C.H.: HC+SS-TuM1, 100; SS+HC+NS+PS-TuM12, 104; SS+HC-MoA1, 94; SS+HC-WeM4, 130

Szakal, C.: AS+BI-TuM10, 99

Szwed, M.: TF+SS-TuA2, 116

— T —

Taber, B.N.: NS+2D+AS+MN+PC-ThA7, 156

Tadjer, M.J.: EM+2D+AN+MI+MP+NS-TuA11, 110; EM+2D+SS-WeA2, 137

Taguchi, M.: SA+AS+HC+SS-ThA10, 158

Tai, Y.-C.: MN+2D+AN+NS-WeA1, 138

Tait, S.L.: SS+EM+PS+TF-ThA4, 159

Takagi, Y.: SA+AS+MI-WeA7, 140

Takahashi, M.: TF+EM+MI-WeM3, 131

Takaki, K.: PB+BI+PC+PS-WeA1, 139

Takakusagi, S.: AS+NS-ThA9, 153

Takamura, Y.: MI+EM-FrM5, 168

Takano, I.: TF-ThP17, 163; TF-ThP19, 163; TF-ThP20, 163; TF-ThP21, 163; TF-ThP28, 163

Takeda, S.: PC+AS+BI+EM+NS+PB+SS-TuA11, 112

Takei, Y.: VT-TuP7, 121

Takeuchi, T.: PS+EM+TF-ThA1, 157

Takeyasu, K.: HC+SS-WeA7, 137; SS+HC+NS+PS-TuM13, 104

Talin, A.: RM+EM+NS-TuA1, 114; RM-TuP3, 120; SA-ThP3, 162

Talin, A.A.: TF2-MoM5, 87

Tam, J.: 2D+EM+MI+NS-TuM1, 99

Tamaoka, T.: PC+AS+BI+EM+NS+PB+SS-TuA11, 112

Tamkun, M.M.: AS+BI-TuM3, 99

Tamski, M.: SS-TuP4, 120

Tan, S.: HI-ThP1, 161; HI-WeA7, 138; PS+EM+TF-ThA4, 157

Tanaka, H.: PS+PB-TuM11, 103

Tanaka, K.: SE+NS+TF-MoM3, 86

Tang, K.: EM+MP+PS-MoM5, 82

Tangi, M.: AS-ThP3, 160

Taniguchi, T.: 2D-ThP2, 160; NS+2D+AS+MN+PC-ThA4, 156

Tannenbaum, R.: 2D+MN+NS+SS-WeA4, 134

Tao, J.: RM+EM+NS-TuA9, 114

Tao, M.: NS+2D+AS+PC-MoA3, 93

Tapily, K.: EM+MP+PS-MoM8, 82

Tarolli, J.: AS+BI-TuM12, 99

Tatsumi, T.: PS+EM+NS+SS-TuA12, 113

Taur, Y.: EM+MP+PS-MoM5, 82

Tavakoli, A.: PS-TuP26, 119

Taylor, M.J.: BI+AS+IPF+MN-MoA6, 90

Tchoe, Y.: 2D+EM+MI+MN+NS-TuA7, 109

Tek, S.: BI-ThA6, 153

Telada, S.: VT-TuP7, 121

Tellez, H.: AS+SE-ThM1, 145

Tenney, S.A.: NS+AM+AS+MN+PC+PS+SS+TR-FrM3, 169

Telyakov, A.V.: SS+AS+EM-WeA8, 141; SS-TuP11, 120; SS-TuP2, 120; TF1-MoM3, 87

ter Veen, R.: SS+HC+MI-TuA8, 115

Teramoto, A.: PS+AS+EM+SS-MoM3, 85; TF+EM+MI-WeM5, 131

Terblans, J.J.: SS+HC-WeM5, 130; TF+AS-TuM3, 105

Tereshina, I.: AC-ThP5, 160

Tereshina-Chitrova, E.A.: AC+MI+SA-WeM10, 124; AC+MI+SA-WeM3, 124; AC-ThP5, 160

Terlier, T.: AS+NS-ThA8, 153; AS-ThP8, 160

Terrones, M.: 2D+AM+EM+NS-WeM1, 124

Terry, J.: AC+AS+SA-ThM13, 144

Terry, S.: MS+MN-TuA9, 111

Terry, H.: SE+NS+TF-MoM1, 86; SS+AS+EM-WeA7, 141; TF+SS-TuA1, 116

Terui, S.: VT-TuP4, 121; VT-TuP6, 121

Terziyska, V.L.: TR-TuP2, 120

Thapa, R.: SE-TuP3, 120

Theilacker, B.: BI-TuP9, 118; PC+AS+BI+EM+NS+PB+SS-TuA3, 112

Théron, D.: MN+NS+PS-WeM10, 127

Therrien, A.J.: SS+HC-MoA1, 94

Thevuthasan, S.: PC+AS+BI+EM+NS+PB+SS-TuP5, 119; SE-TuA7, 114; SS+AS+BI+MI+NS-ThA11, 158

Thiel, P.A.: SS+EM+NS-ThM4, 150; SS-TuP1, 120

Thier, G.: MS-TuP3, 118

Thiesen, P.H.: 2D+MI+NS-MoA10, 89

Thimsen, E.: PS+EM+NS+SS-TuA9, 113; PS+MN-WeM12, 130; PS-TuP13, 119

Thinakaran, H.: BI+AS+IPF+MN-MoA10, 90

Thinamany, S.: BI-TuP9, 118

Thissen, A.: 2D+EM+MI+MN+NS+SS-ThM10, 144; PC+AS+BI+EM+NS+PB+SS-TuA1, 112

Thomas, C.R.: AS-MoA9, 89

Thomas, J.: BI+AS+NS-FrM6, 168

Thomson, E.: EM+MP+PS-MoM1, 82; EM+MP+PS-MoM5, 82

Thörnberg, J.: SE+PS-TuM5, 104

Thurecht, K.: BI+AS+IPF+NS-TuA2, 110

Tian, H.: AS+BI-TuM6, 99

Tian, S.: PS-ThA8, 157; PS-TuP21, 119

Tian, W.: PS+EM+SE-TuM3, 103; PS-FrM2, 169; PS-FrM8, 169

Timm, R.: EM+AN+MI+SS-WeM11, 126

Timoshenko, J.: SS+HC-WeM3, 130

Tinney, D.G.: SS+HC+MI-MoM3, 86

Tiron, R.: HI-ThA8, 155; PS+EM-WeM3, 129

Tischendorf, B.: PC+AS+BI+EM+NS+PB+SS-TuA3, 112

Tiwald, T.: SS+HC+MI-TuA12, 115

Tobin, J.G.: AC+MI+SA-FrM5, 167

Todd, R.: VT-TuM10, 106

Todt, M.A.: 2D-ThP5, 160

Tokei, Z.: PS+EM-WeA9, 140

Tokesi, K.: AS+NS+SA-WeM10, 125; SS-TuP6, 120

Tomachot, G.: PS+EM-WeM6, 129

Tomko, J.: PS+PB+SE-TuA7, 113

Tompa, G.S.: EM+2D+SS-WeA3, 137

Tongay, T.: 2D+EM+MI+NS+TF-MoM8, 81

Tonner, R.: TF1-MoM2, 87

Toomey, R.: BI-TuP3, 118

Töpper, T.: EL+AS+EM-MoM5, 82

Topsakal, M.: SA+AS+HC+SS-ThA1, 158

Torelli, M.D.: TF+AS-TuM5, 105

Tornow, M.: BI+AS+IPF+NS-TuA3, 110

Torres Ochoa, J.A.: AS-ThP9, 160

Torres, T.: SS+EM+PS+TF-ThA11, 159

Torres-Ochoa, J.A.: AS-ThP5, 160

Tougaard, S.: AS+NS+SA-WeM2, 125

Toyoda, N.: PS+EM+TF-ThM10, 149

Tracy, L.: AM+MP+NS-WeA3, 135

Tran Khac, B.C.: 2D+EM+MN+NS-FrM1, 167

Tran, I.: SE+NS+TF-MoM2, 86

Trapani, G.: BI-ThM11, 145

Trappen, R.: AC+MI+SA-WeM13, 124; SA+MI-ThM2, 150

Treglia, A.: PS+PB-MoA2, 93

Trenary, M.: HC+SS-ThM3, 146

Trofimov, A.: HI+AS-ThM1, 147

Troian, A.: EM+AN+MI+SS-WeM11, 126

Troksa, A.L.: SA-ThP2, 162

Tromp, R.M.: 2D+MI+NS-MoA8, 89

Trotocaud, L.: TF+SS-TuA1, 116

Trought, M.: SS+EM+NS-ThM10, 150; SS-TuP8, 120

Tsai, D.S.: 2D+EM+MI+NS+TF-MoM10, 81

Tsal, H.: MS+MI+RM-TuM5, 101

Tsampas, M.N.: TF-TuM13, 106

Tsleev, A.: 2D+EM+MN+NS-ThA6, 152; MM+AS+NS+PC+SS-MoA10, 92

Tseng, C.C.: AS-ThP3, 160

Tsia, C.J.: MN-ThP1, 162

Tsutsumi, T.: PS+AS+EM+SS-MoM11, 85; PS+EM+SE-TuM13, 103

Tsymbol, Y.: MI+EM-FrM9, 168

Tu, Q.: 2D+EM+MI+NS-TuM2, 99

Tuchman, Y.: RM-TuP3, 120

Tulodziecki, M.: TF2-MoM4, 87

Turano, M.E.: HC+SS-TuA7, 111; HC-ThP6, 161

Turek, I.: AC+MI+SA-WeM10, 124

Turley, R.S.: EL+AS+EM-MoM10, 82; TF+AS+EL+PS-ThM5, 151; TF-ThP24, 163

Turner, E.: AS+NS-ThA7, 153

Tutuncuoglu, G.: EM+MI+MN+NS-ThM3, 146; EM+MP+PS-MoM10, 82

Twigg, M.E.: TF+EM+MI-WeM6, 131

Tyliszczak, T.: AC+AS+SA-ThM10, 144

— U —

Ubl, S.: BI-TuP9, 118

Ueda, S.: AS+NS+SA-WeM2, 125; EM+2D+AN+MI+MP+NS-TuA12, 110; SA+AS+MI-WeA2, 140; SA+AS+MI-WeA9, 140

Uedono, A.: PS+TF-MoM10, 85

Ueyama, T.: PS+EM+SE-TuM13, 103

Uhlig, J.: PS-TuP19, 119

Uhlmann, P.: BI-ThA11, 153

Ulgiat, B.: AS+NS+SA-WeM11, 125; PC+AS+BI+EM+PB+SS-WeM4, 128

Uner, N.B.: PS+MN-WeM12, 130; PS-TuP13, 119

Unger, W.E.S.: 2D+MN+NS+SS-WeA7, 134; PC+AS+BI+EM+NS+PB+SS-TuA1, 112

Unnikrishnan, S.: TF2-MoM4, 87

Unocic, R.R.: 2D+EM+MI+NS+TF-MoM5, 81; MM+AS+NS+PC-MoM8, 83

Upadhyay, R.: PS+AS+EM+SS-MoM11, 85

Uppuluri, R.: HC+SS-TuM6, 100

Uprety, S.: EM-ThP18, 161

Uricchio, A.: PS+PB-MoA9, 93

Usui, T.: PS+EM-WeM12, 129

Utz, A.L.: HC+SS-WeA3, 137; SS+HC+MI-MoM3, 86

Utzig, T.: BI-ThA3, 153

Uzarski, J.: BI+AS+IPF+NS-TuA10, 110

— V —

Valentin, M.D.: 2D+EM+MI+MN+NS+SS-ThM5, 144

Valeriano, W.W.: AS+SE-ThM11, 145

Vallée, C.: TF+AM+EM+PS-TuM3, 105; TF+AM+EM+PS-TuM5, 105

Vallier, L.: PS+EM+TF-ThM13, 149; PS+EM-WeM1, 129; PS+EM-WeM6, 129

Valmianski, I.: MI+2D+EM+NS-MoA5, 91

Valtiner, M.: BI-ThA3, 153; BI-ThA4, 153

van den Bossche, M.: HC+SS-WeM10, 126

van der Molen, S.J.: 2D+MI+NS-MoA8, 89

van der Zande, A.M.: 2D+EM+MI+NS-TuM10, 99; 2D+EM+MN+NS-FrM7, 167; 2D+EM+MN+NS-FrM8, 167

Van Drie, A.: VT-TuP11, 121

Van Duyne, R.P.: TF1-MoM1, 87

Van Elshocht, S.: TF+AM+EM+PS-TuM10, 105

van Kouwen, L.: HI-ThA6, 155

van Lent, R.: HC+SS-WeA2, 137

Author Index

van Ommeren, J.R.: TF+AM+EM+PS-TuM10, 105
 van Rooij, G.: PS-ThM12, 149
 van Spronsen, M.: HC+SS-WeA10, 137
 van Straaten, G.: TF-TuM10, 106
 Van Surksum, T.L.: PS+MN-WeM13, 130
 van 't Erve, O.M.J.: 2D+EM+MI+MN+NS-TuA1, 109
 van Werkhoven, W.P.: VT-MoM10, 88
 Vandalon, V.: SS+EM+NS-ThM12, 150
 Vandana, V.: EM+AN+MI+SS-WeM4, 126
 Vandenberghe, W.G.: EM-ThP14, 161
 Vandersmissen, K.: TF+EM+MI-WeM12, 131
 Vanfleet, R.: TF+PS-ThM4, 151
 Vanfleet, R.R.: 2D+EM+MI+NS-TuM3, 99; MN+2D+AN+NS-WeA11, 138; TF+PS-ThM1, 151; TF+PS-ThM11, 151; TF+PS-ThM4, 151
 Varga, T.: PC+AS+BI+EM+NS+PB+SS-TuP5, 119
 Varghese, J.O.: 2D+EM+MN+NS-ThA7, 152
 Vaskevich, A.: AS+SE-ThM4, 145
 Vasudevan, R.: NS-ThP19, 162
 Vattuone, L.: SS+EM+NS-ThM3, 150; SS+HC-MoA3, 94
 Vaxelaire, N.V.: TF+AS+EL+EM+NS+PS+SS-ThA4, 159
 Vázquez, G.: AS-ThP5, 160
 Veisi, Z.: BI-TuP3, 118
 Veit, D.R.: SS-TuP15, 120
 Velasco, C.A.: AS+NS+SA-WeM6, 125
 Velasco-Velez, J.J.: PC+AS+BI+EM+NS+PB+SS-TuA7, 112
 Velickovic, D.: AS-MoA10, 89
 Velusamy, T.: PS+EM+NS+SS-TuA4, 113
 Vengerovsky, N.: NS+AN+EM+MI+MN+MP+PS+RM-ThM1, 148
 Venkatesan, S.: VT-MoM3, 88
 Venkatraman, A.: PS-FrM9, 169; PS-TuP24, 119
 Ventrice, Jr., C.A.: SS+AS+BI+MI+NS-ThA7, 158
 Ventzek, P.L.G.: PS+AS+EM+SS-MoM11, 85; PS+EM+TF-ThA10, 157; PS+TF-MoM5, 85; PS-ThA7, 157; PS-ThA9, 157; PS-ThM11, 149; PS-ThM2, 149
 Veraar, R.G.: VT-MoM10, 88
 Verbovsek, T.: VT-WeM4, 131
 Verduzco, R.: AS+NS-ThA8, 153
 Vereecken, P.M.: TF2-MoM1, 87
 Vergnaud, C.: 2D+AM+EM+NS-WeM12, 124
 Verheijen, M.A.: TF+AS+EL+EM+NS+PS+SS-ThA6, 159
 Verkouteren, J.: AS+SE-ThM10, 145
 Verma, A.K.: PS-FrM9, 169; PS-TuP24, 119
 Vicente, J.: NS-ThP11, 162
 Vickerman, J.C.: AS+BI-TuM1, 99
 Vidy, R.: TF+EM+MI-WeA9, 141
 Vidyarthi, V.: PS-FrM2, 169
 Vieker, H.: HI+AS-ThM10, 147
 Villanueva, R.: NS+AN+EM+MI+MN+MP+PS+RM-ThM12, 148
 Vincent, B.: BI-ThA6, 153
 Vine, D.: AC+AS+SA-ThM10, 144
 Virdee, M.: PS-TuP14, 119
 Virushabaddoss, N.: MI+2D-ThM12, 147
 Vishwakarma, S.K.: BI+AS+IPF+NS-TuA7, 110
 Vitale, S.A.: 2D+EM+MN+NS-ThA7, 152
 Vizkelethy, G.: MS+MI+RM-TuM1, 101
 Vladar, A.E.: VT-TuP9, 121
 Vlasak, P.R.: AS+SE-WeA8, 135; HC+SS-TuA2, 111
 Vlassiouk, I.: MM+AS+NS+PC+SS-MoA4, 92
 Vo, H.: SE-TuA11, 114
 Voevodin, A.A.: 2D+EM+MI+MN+NS-TuA8, 109
 Vogel, E.M.: EM+MP+PS-MoM10, 82
 Voigt, B.: TF-MoA8, 95
 Voit, B.: BI-ThA11, 153
 Volatier, M.: PS+EM+SE-TuM2, 103
 Volders, C.: SS+AS+HC-FrM3, 170
 von Borany, J.: HI+AS-ThM12, 147; HI-ThA8, 155
 Von Ehr, J.R.: AM+MP+NS-WeA8, 135
 Voras, Z.E.: NS+AM+AS+MN+PC+PS+SS+TR-FrM3, 169
 Voronin, S.A.: PS+EM+SE-TuM5, 103
 Voronina, E.: 2D+AM+EM+NS-WeM10, 124
 Vovk, E.I.: HC+SS-TuA10, 111; SS+AS+HC-FrM5, 170
 Vrijen, G.: MP+EM+MN+NS-MoM9, 84
 Vuckovic, J.: EM+2D+AN+MI+MP+NS-TuA7, 110
 — W —
 Wagenbach, C.: PS+EM+TF-ThA8, 157; TF-ThP38, 163
 Wagner, S.: SE-TuP3, 120
 Wahl, K.J.: BI-WeA7, 136
 Wahl, P.: NS+AM+AS+MN+PC+PS+SS+TR-FrM4, 169
 Waidhas, F.: SS+AS+EM-WeA9, 141
 Wajda, C.S.: EM+MP+PS-MoM8, 82
 Walczak, L.: EW-TuL5, 108; SS+AS+HC-FrM6, 170
 Walker, A.V.: AS+SE-ThM12, 145; AS-MoM11, 81
 Walker, F.J.: AS-MoA6, 89
 Walkosz, W.: HC-ThP6, 161
 Walkup, D.: 2D-ThP2, 160; NS+2D+AS+MN+PC-ThA4, 156
 Wallace, R.M.: EM-ThP14, 161
 Wallas, J.M.: TF-TuM2, 106
 Wallin, C.B.: NS+2D+AN+MN+MP+SE-WeM2, 128; NS+2D+AN+MN+MP+SE-WeM5, 128
 Walls, J.M.: TF-MoA5, 95
 Walsh, A.J.: HC+SS-WeA2, 137
 Walter, B.: MN+NS+PS-WeM10, 127
 Walter, J.: TF-MoA8, 95
 Walter, T.N.: EM+AM+NS+PS-MoA8, 91; TF+AM+EM+PS-TuM6, 105
 Walton, S.G.: PS+PB+SE-TuA1, 113; PS+PB+SE-TuA7, 113; PS+TF-MoM11, 85; PS+TF-MoM6, 85; PS-TuP16, 119; TF+EM+MI-WeM4, 131; TF-ThP22, 163; TF-ThP38, 163; TF-TuM4, 106
 Waluyo, I.: HC+SS-TuM3, 100
 Wan, H.: SS+HC-WeM3, 130
 Wan, K.-T.: SS+EM+NS-ThM4, 150
 Wan, W.: MS+MI+RM-TuM10, 101
 Wand, J.Y.: SS+HC-WeM5, 130
 Wang, A.W.: NS-ThP13, 162
 Wang, B.: EM-ThP17, 161; NS+2D+AN+EM+MN+MP+PC+RM-MoM11, 84
 Wang, C.: BI-WeA7, 136; MM+AS+NS+PC-MoM11, 83
 Wang, C.Y.: PB-TuP1, 118
 Wang, D.: PB+BI+PC+PS-WeA3, 139
 Wang, G.: AC+MI+SA-FrM10, 167
 Wang, H.: 2D+EM+MI+MN+NS-TuA9, 109; BI+AS+IPF+NS-TuA1, 110; SS+HC+MI-TuA12, 115; TF+EM+MI-WeA8, 141
 Wang, J.-C.: PS+EM+SE-TuM3, 103; PS-FrM2, 169
 Wang, K.L.: EM-ThP10, 161; PS+EM+NS+SS-TuA11, 113
 Wang, M.: PS+EM+SE-TuM6, 103; PS+PB-MoA3, 93
 Wang, M.K.: PS-TuP25, 119
 Wang, M.-K.: MN-ThP1, 162
 Wang, M.-K.: MN-ThP2, 162
 Wang, M.-K.: TF-ThP16, 163
 Wang, N.: 2D+EM+MI+NS-TuM12, 99
 Wang, Q.: EM-ThP14, 161
 Wang, R.: AS-MoA9, 89
 Wang, S.: EM-ThP18, 161
 Wang, S.Y.: TF+EM+MI-WeA10, 141
 Wang, T.: PS+EM-WeA2, 140; SS+HC+NS+PS-TuM4, 104
 Wang, X.: AM+MP+NS-WeA7, 135; AS+SE-WeA12, 135; NS+2D+AN+EM+MN+MP+PC+RM-MoM11, 84; TF-TuM1, 106
 Wang, X.Q.: EL+AS+EM-MoM9, 82; EM+2D+AN+MI+MP+NS-TuA4, 110; MI+EM-FrM4, 168
 Wang, Y.: EM-ThP16, 161; NS+2D+AN+EM+MN+MP+PC+RM-MoM8, 84; SE+NS+TF-MoM3, 86; TF+SS-TuA8, 116
 Wang, Y.L.: NS-ThP13, 162
 Wang, Z.: 2D+EM+MI+NS+TF-MoM10, 81; MN+2D+AN+MP+NS-ThM11, 148; RM-TuP3, 120; TF-ThP29, 163
 Wang, Z.P.: EL+AS+EM-MoM9, 82; EM+2D+AN+MI+MP+NS-TuA4, 110; MI+EM-FrM4, 168
 Wang, Z.-T.: SS+AS+EM-WeA12, 141
 Ward, D.: AM+MP+NS-WeA3, 135
 Ward, D.J.: HI-ThA3, 155
 Ward, M.J.: TF-ThP31, 163
 Ward, T.Z.: 2D+MN+NS+SS-WeA10, 134
 Warren, M.: AC+AS+SA-ThM13, 144; VT-TuM11, 106
 Waser, R.: SA+AS+HC+SS-ThA7, 158
 Washiyama, S.: TF+AS+EL+PS-ThM1, 151
 Watanabe, K.: 2D-ThP2, 160; NS+2D+AS+MN+PC-ThA4, 156
 Watson, B.R.: HI+AS-ThM4, 147
 Watt, A.A.R.: TF+AS+EL+EM+NS+PS+SS-ThA11, 159
 Wattanatorn, N.: NS-ThP15, 162
 Watznabe, Y.: AS-ThP10, 160
 Wdowik, U.D.: AC+MI+SA-FrM7, 167
 Weatherup, R.S.: 2D+MI+NS-MoA1, 89
 Weaver, J.F.: HC+SS-ThM4, 146; HC+SS-TuM5, 100; HC+SS-WeM10, 126
 Weber, N.B.: MM-TuP2, 118
 Weck, P.F.: MP+EM+MN+NS-MoM8, 84
 Weddle, C.: MP+EM+NS-TuM1, 101
 Wee, A.T.S.: SS+EM+NS-ThM6, 150
 Wei, B.W.: SE-MoA10, 94
 Wei, D.: BI+AS+IPF+MN-MoA9, 90
 Wei, N.: AS-ThP3, 160
 Wei, W.: BI-WeA11, 136
 Wei, Y.J.: PB+BI+PC+PS-WeA11, 139
 Weidner, T.: BI+AS+IPF+MN-MoA3, 90; BI+AS+IPF+MN-MoA5, 90
 Weig, E.M.: MN+2D+AN+NS-ThA6, 156
 Weigang, A.: BI-ThA9, 153
 Weiland, C.: SA+AS+MI-WeA12, 140
 Weimann, T.: 2D+MN+NS+SS-WeA12, 134
 Weiss, A.: AC+AS+SA-ThM3, 144
 Weiss, C.: SS+AS+EM-WeA9, 141
 Weiss, H.: BI-ThA4, 153
 Weiss, P.S.: NS+AM+MI+MN+SS+TR-TuA11, 112; NS-ThP15, 162
 Weiss, T.: EM+MP+PS-MoM10, 82
 Weisz, D.G.: AC+AS+SA-ThM12, 144
 Welch, N.G.: BI+AS+NS-FrM3, 168
 Wen, H.J.: MN-ThP1, 162
 Wen, R.: AS+NS-ThA7, 153
 Wen, Y.: EL+EM-MoA6, 90
 Wendt, S.: SS+HC+MI-MoM4, 86
 Weng, C.-J.: EM-ThP4, 161

Author Index

Wentworth, I.: SS+EM+NS-ThM10, 150
 Westly, D.A.: NS+2D+AN+MN+MP+SE-WeM2, 128
 Westover, T.: NS+AN+EM+MI+MN+MP+PS+RM-ThM5, 148
 Whaley, S.D.: SS-TuP9, 120
 Wheeler, J.M.: SE-MoA3, 94
 Wheeler, R.: EM+AN+MI+SS-WeM12, 126
 Wheeler, V.D.: PS-TF-MoM11, 85; TF+EM+MI-WeM4, 131; TF-TuM4, 106
 Whitaker, B.: NS-ThP6, 162
 White, F.D.: AC-ThA3, 152
 White, I.H.: EM-ThP1, 160
 Whitelam, S.: SS+EM+PS+TF-ThA7, 159
 Whiteman, P.: NS+AM+MI+MN+SS+TR-TuA3, 112; NS-ThP1, 162
 Wiame, H.: TF+EM+MI-WeM13, 131
 Wieser, R.J.: TR-TuP1, 120
 Wietstruk, M.: 2D+EM+MI+MN+NS+SS-ThM10, 144
 Wiggins, B.: SS+EM+PS+TF-ThA6, 159
 Wilke, J.: BI+AC+AS+HC+NS+SS+TF-WeA7, 136
 Wilkens, B.: BI+AS+IPF+MN-MoA10, 90
 Willey, T.M.: SA+AS+HC+SS-ThA11, 158
 Willingham, D.: AC+AS+SA-ThM12, 144
 Wilson, N.S.: 2D+EM+MN+NS-FrM6, 167
 Wimbley, T.: EM-ThP7, 161; TF-ThP30, 163
 Winkler, D.A.: BI+AS+NS-FrM3, 168
 Winkler, K.: NS-ThP12, 162
 Winkler, R.: AM+NS+SS-WeM1, 125; AM+NS+SS-WeM3, 125; AM-TuP1, 118
 Winograd, N.: AS+BI-TuM6, 99; AS-TuA10, 109
 Winsett, J.: MI-ThP1, 161
 Winter, C.H.: PS+EM+TF-ThM5, 149
 Winters, C.: AS+NS+SA-WeM13, 125
 Wirtz, T.: HI+AS-ThM3, 147
 Wisman, D.L.: SS+EM+PS+TF-ThA4, 159
 Witzke, M.: HC+SS-ThA6, 154
 Woicik, J.C.: SA+AS+MI-WeA12, 140
 Wolf, J.: VT-TuM6, 106
 Wolf, M.F.: BI-TuP9, 118
 Wolf, S.: EM+AM+NS+PS-MoA10, 91
 Wolfe, K.M.: TF-ThP24, 163
 Woll, A.: VT-TuM5, 106
 Wöll, C.: SS+HC+MI-MoM8, 86
 Wolverton, C.: 2D+EM+MI+NS-TuM2, 99
 Wong, H.-S.: PS+EM-WeA12, 140
 Wong, H.-S.P.: MS+MI+RM-TuM10, 101
 Wong, M.: EM+MI+MN+NS-ThM5, 146
 Wong, S.L.: 2D+EM+MI+NS+TF-MoM11, 81
 Woo Chul, L.: TF+EM+MI+PS-MoA3, 95
 Wood, R.: MI+2D+EM+NS-MoA1, 91
 Wood, S.A.: HI+AS-ThM13, 147
 Woodard, A.: PS-ThA2, 157
 Woodward, J.M.: PS+EM+TF-ThA8, 157; TF-ThP38, 163
 Woolley, A.: NS+AN+EM+MI+MN+MP+PS+RM-ThM5, 148
 Wray, L.A.: AC-ThA8, 152
 Wu, B.: SS+EM+PS+TF-ThA9, 159
 Wu, D.: AC+AS+SA-ThM5, 144
 Wu, G.: SE-TuP4, 120
 Wu, H.-C.: 2D+EM+MI+NS-TuM4, 99
 Wu, J.: NS+2D+AN+EM+MN+MP+PC+RM-MoM11, 84
 Wu, L.M.: NS-ThP13, 162
 Wu, R.T.: NS-ThP13, 162
 Wu, T.F.: MS+MI+RM-TuM10, 101
 Wu, W.-F.: PS+EM-WeM5, 129
 Wu, X.: MP+AM+EM+NS-MoA5, 92; MP+AM+EM+NS-MoA6, 92; MP+EM+NS-TuM12, 101; MP+EM+NS-TuM6, 101
 Wu, X.J.: SS+HC+NS+PS-TuM4, 104
 Wu, Y.: MM+AS+NS+PC-MoM5, 83; PS-TuP22, 119; PS-TuP23, 119; TF+AS+EL+EM+NS+PS+SS-ThA6, 159; TF+EM+MI-WeA11, 141
 Wu, Z.: SA+AS+HC+SS-ThA6, 158
 Wu, Z.B.: NS-ThP13, 162
 Wucher, A.: AS-TuA10, 109
 Wuest, M.: VT-MoM6, 88
 Wug, Y.: EL+AS+EM-MoM10, 82
 Wurch, M.: 2D+EM+MI+NS+TF-MoM2, 81
 Wyrick, J.: AM+MP+NS-WeA7, 135
 — X —
 Xia, A.: SE+NS+TF-MoM4, 86; SE-TuA11, 114
 Xia, J.: 2D+EM+MI+NS-TuM5, 99; 2D+EM+MN+NS-FrM2, 167
 Xia, Q.: RM+EM+NS-TuA7, 114
 Xiang, J.: PS-FrM3, 169
 Xiao, K.: 2D+EM+MI+NS+TF-MoM5, 81; 2D+MN+NS+SS-WeA10, 134; 2D+MN+NS+SS-WeA9, 134; HI+AS-ThM4, 147
 Xiao, Z.: EM-ThP7, 161; NS+AM+MI+MN+SS+TR-TuA9, 112; NS-ThP6, 162; TF-ThP30, 163
 Xie, G.: BI-ThA1, 153
 Xing, Y.Q.: NS-ThP13, 162
 Xu, F.: HC+SS-TuM3, 100
 Xu, H.: AS+NS+SA-WeM10, 125
 Xu, J.: NS+2D+AS+MN+PC-ThA9, 156
 Xu, N.: EM-ThP16, 161
 Xu, X.: HI-ThA8, 155
 Xu, Y.: MN+2D+AN+MP+NS-ThM5, 148
 Xue, P.: PS-TuP22, 119; TF-ThP29, 163
 — Y —
 Yaita, T.: AC+AS+SA-WeA3, 134
 Yakimova, R.: 2D+EM+MN+NS-FrM5, 167
 Yalon, E.: 2D+EM+MI+NS-TuM12, 99
 Yamada, T.: BI-ThM12, 145; TF+EM+MI-WeA10, 141
 Yamaguchi, H.: NS+2D+AN+MN+MP+SE-WeM10, 128
 Yamaguchi, K.Y.: HC-ThP4, 161
 Yamaguchi, T.: PS+EM-WeA9, 140
 Yamamura, T.: PS+EM-WeA10, 140
 Yamashita, Y.: AS+NS+SA-WeM2, 125; SA+AS+MI-WeA9, 140
 Yan, H.: SS+HC+MI-TuA7, 115
 Yan, H.M.: TF+PS-ThM12, 151; TF-MoA10, 95; TF-MoA9, 95
 Yan, J.H.: NS-ThP13, 162
 Yan, L.H.: NS-ThP13, 162
 Yan, X.-L.: SS+HC-WeM5, 130
 Yanez, M.: IPF+AS+BI+NS-MoM5, 83
 Yang, C.: BI-WeA11, 136
 Yang, C.W.: PC+AS+BI+NS+PB+SS-TuM11, 102
 Yang, C.-H.: MI+EM-FrM8, 168
 Yang, G.S.: EM+2D+SS-WeA4, 137; EM+2D+SS-WeA9, 137
 Yang, H.: EM-ThP2, 161; NS-ThP13, 162
 Yang, J.: HI+AS-ThM13, 147; TF+SS-TuA11, 116
 Yang, J.C.: EM+2D+SS-WeA2, 137; HC+SS-ThA11, 154; SS+HC-WeM3, 130
 Yang, J.-I.: HC-ThP1, 161
 Yang, J.J.: RM-TuP3, 120
 Yang, K.C.: PS-TuP12, 119
 Yang, L.H.: AS+NS+SA-WeM10, 125
 Yang, P.: AC+AS+SA-WeA1, 134; AC+AS+SA-WeA7, 134; AC+MI+SA-FrM10, 167; AC-ThA1, 152; AC-ThA3, 152
 Yang, R.: MN+2D+AN+MP+NS-ThM11, 148
 Yang, S.: EM-ThP17, 161; PS+PB+SE-TuA4, 113
 Yang, W.: PS+EM+TF-ThA4, 157
 Yang, W.-C.: MM+AS+NS+PC-MoM11, 83
 Yang, X.: SS+AS+EM-WeA3, 141
 Yang, Y.: 2D+EM+MI+MN+NS+SS-ThM11, 144; HC+SS-TuA10, 111; PC+AS+BI+NS+PB+SS-TuM1, 102; SS+AS+HC-FrM5, 170; SS+HC+MI-TuA11, 115
 Yanguas-Gil, A.: TF-ThP31, 163; TF-ThP33, 163
 Yanik, C.: MN+2D+AN+NS-ThA9, 156
 Yano, A.: AS-ThP10, 160
 Yao, J.: AS+SE-WeA9, 135
 Yao, Y.: TF1-MoM3, 87; TF-MoA4, 95
 Yapabandara, K.: EM-ThP18, 161
 Yarmoff, J.A.: SS+EM+NS-ThM5, 150; SS+EM+PS+TF-ThA10, 159
 Yasuno, S.: SA-ThP1, 162
 Yau, J.B.: MP+AM+EM+NS-MoA10, 92
 Yeh, I.N.: PS-TuP28, 119
 Yeh, P.: MN+NS+PS-WeM5, 127
 Yeom, G.Y.: MN-ThP4, 162; PS-TuP12, 119; PS-TuP6, 119
 Yezdi, Y.: TF+EM+MI-WeM12, 131
 Yi, C.: SE+NS+TF-MoM2, 86
 Yi, G.-C.: 2D+EM+MI+MN+NS-TuA7, 109
 Yi, J.B.: MI+2D-ThM3, 147
 Yi, S.: 2D+EM+MN+NS-ThA10, 152
 Yi, S.S.: AC-ThP1, 160; AC-ThP2, 160
 Yi, X.R.: BI-TuP11, 118
 Yingling, A.: BI-ThA8, 153
 Yingling, Y.G.: BI-ThA10, 153
 Yokoiwa, Y.: TF-ThP2, 163
 Yokota, T.: TF+AS+EL+EM+NS+PS+SS-ThA1, 159
 Yonemaru, T.: SS+HC-WeM13, 130
 Yoo, J.: IPF+AS+BI+NS-MoM10, 83
 Yoo, Y.: VT-TuP12, 121
 Yook, Y.G.: TF+PS-TuA12, 115
 Yoon, R.-H.: AC+AS+SA-WeA9, 134
 Yoshida, H.: PC+AS+BI+EM+NS+PB+SS-TuA11, 112; VT-TuP7, 121; VT-TuP8, 121
 You, D.H.: TF+PS-TuA12, 115
 You, H.S.: TF+PS-TuA12, 115
 You, L.: IPF+AS+BI+NS-WeM3, 127
 Youn, M.H.: HC-ThP1, 161
 Young, E.C.: 2D+EM+MN+NS-FrM6, 167
 Yousefi Sarraf, S.: SA+MI-ThM2, 150
 Yousefi, S.F.: AC+MI+SA-WeM13, 124
 Yu, C.C.: SE-MoA5, 94
 Yu, J.: 2D+EM+MI+NS-TuM10, 99; 2D+EM+MN+NS-FrM7, 167
 Yu, J.-S.: 2D+MN+NS+SS-WeA3, 134; 2D+MN+NS+SS-WeA8, 134
 Yu, K.-H.: EM+MP+PS-MoM8, 82
 Yu, X.: NS+2D+AS+PC-MoA3, 93
 Yu, X.: TF-MoA9, 95
 Yu, X.F.: PC+AS+BI+EM+PB+SS-WeM3, 128
 Yu, X.Z.: TF+PS-ThM12, 151; TF-MoA10, 95
 Yu, X.Y.: AS+SE-WeA9, 135; BI+AS+IPF+MN-MoA8, 90; BI-WeA11, 136; PC+AS+BI+EM+PB+SS-WeM3, 128
 Yualev, A.: MM+AS+NS+PC+SS-MoA4, 92
 Yuan, H.: SE+NS+TF-MoM5, 86
 Yuan, Q.: NS-ThP6, 162
 Yuasa, S.: RM+EM+NS-TuA11, 114
 Yue, R.: EM-ThP14, 161
 Yuge, K.: TF+EM+MI-WeM3, 131
 Yulaev, A.: MM+AS+NS+PC+SS-MoA10, 92
 Yun, J.Y.: TF-ThP40, 163
 Yun, M.H.: BI-TuP11, 118
 Yuneva, M.: AS+BI-TuM5, 99
 Yurek, Q.: 2D+EM+MI+MN+NS-TuA11, 109

Author Index

Yusuf, S.: HC+SS-TuA2, 111

— Z —

Zabeida, O.: PS+PB-MoA10, 93

Zaccarine, S.F.: AS-ThP4, **160**

Zaera, F.: HC+SS-ThM10, **146**;

PC+AS+BI+EM+NS+PB+SS-TuP3, 119; TF1-MoM3, 87

Zafeiropoulos, G.: TF-TuM13, 106

Zaid, H.: SE+NS+TF-MoM3, 86; SE-MoA3, 94

Zajickova, L.: PS+PB-MoA4, **93**

Zakel, J.: AS+NS-ThA6, 153; AS+SE-WeA1, **135**

Zamarripa, C.: EL-TuP4, **118**

Zandkarimi, B.: HC+SS-TuM4, 100

Zanette, D.: MN+2D+AN+NS-ThA1, 156

Zangrando, M.: SA+MI-ThM5, 150

Zardetto, V.: TF-MoA3, 95

Zauscher, S.: IPF+AS+BI+NS-WeM3, **127**

Zborowski, C.: AS+NS+SA-WeM2, 125

Zebarjadi, M.: EM-ThP19, 161

Zehnder, A.T.: NS+2D+AN+MN+MP+SE-WeM2, 128

Zeller, P.: MM+AS+NS+PC+SS-MoA1, 92

Zemek, J.: TF+SS-TuA7, 116

Zeng, L.: TF+PS-TuA3, 115

Zeng, L.J.: MM+AS+NS+PC-MoM6, **83**

Zeng, Y.: NS-ThP3, **162**

Zetterberg, J.: HC+SS-ThA7, 154; HC+SS-WeM11, 126; HC+SS-WeM5, 126

Zha, W.: SE+PS-TuM2, **104**

Zhang, C.: 2D+EM+MN+NS-ThA10, 152;

2D+MN+NS+SS-WeA10, **134**; HC+SS-ThA2, 154; HC+SS-ThM2, 146;

NS+AN+EM+MN+MP+RM-TuM3, 102

Zhang, F.: 2D+AM+EM+NS-WeM1, 124;

TF+SS-TuA12, 116

Zhang, H.: 2D-ThP5, 160; TF+EM+MI-WeA8, 141

Zhang, K.: PC+AS+BI+EM+NS+PB+SS-TuP2, 119; TF+AS+EL+EM+NS+PS+SS-ThA7, **159**

Zhang, M.: MI+EM-FrM4, 168

Zhang, Q.: 2D+MI+NS-MoA3, 89

Zhang, R.: SS+HC-MoA1, 94

Zhang, S.: 2D+MI+NS-MoA3, 89

Zhang, T.: NS-ThP3, 162

Zhang, W.: HC+SS-TuM6, **100**

Zhang, X.: 2D+EM+MN+NS-ThA8, **152**;

NS+2D+AN+EM+MN+MP+PC+RM-MoM11,

84; TF+AM+EM+PS-TuM6, 105

Zhang, X.H.: 2D+EM+MI+MN+NS+SS-ThM11, 144; 2D+MN+NS+SS-WeA12, **134**

Zhang, Y.: AS+SE-WeA12, **135**; AS-TuA11, 109; TF+PS-ThM3, 151

Zhang, Y.Z.: BI-TuP11, 118

Zhang, Z.: EM+AM+NS+PS-MoA1, 91; EM-ThP16, 161; TF+EM+MI+PS-MoA4, 95

Zhang, Z.M.: EL+AS+EM-MoM9, 82; EM+2D+AN+MI+MP+NS-TuA4, 110; MI+EM-FrM4, **168**

Zhao, B.: RM+EM+NS-TuA10, **114**

Zhao, C.: NS-ThP15, 162; SE+PS-TuM2, 104

Zhao, H.: SS+HC+MI-TuA12, 115

Zhao, J.: SS-TuP2, 120

Zhao, J.P.: PS-ThA7, 157; PS-ThA9, **157**

Zhao, W.: 2D+EM+MI+NS+TF-MoM5, 81; HC+SS-TuM10, 100

Zhao, Y.: NS+2D+AN+EM+MN+MP+PC+RM-MoM4, 84

Zheng, B.C.: PS+EM+NS+SS-TuA11, **113**

Zheng, P.Y.: EM+AM+NS+PS-MoA5, 91

Zheng, Y.: IPF+AS+BI+NS-MoM8, **83**

Zheng, Z.S.: TF-ThP11, **163**

Zhigilei, L.: AS-TuA3, **109**

Zhirkov, I.: SE+PS-TuM5, 104

Zhitenev, N.B.: 2D-ThP2, 160; 2D-ThP6, 160;

NS+2D+AS+MN+PC-ThA4, 156; RM+EM+NS-TuA11, 114; RM-TuP2, 120; SA-ThP3, 162

Zhng, C.: 2D+MN+NS+SS-WeA9, 134

Zhou, C.: 2D+EM+MI+MN+NS+SS-ThM2, **144**;

NS+2D+AS+PC-MoA8, 93

Zhou, G.: EM-ThP14, **161**

Zhou, J.: HC+SS-ThA7, 154; HC+SS-WeM11, 126; HC+SS-WeM5, 126

Zhou, T.: EM+AM+NS+PS-MoA5, 91

Zhou, W.: SS+EM+PS+TF-ThA10, 159

Zhou, X.: HC+SS-TuA10, 111; SS+AS+HC-FrM5, 170

Zhou, Y.: 2D+EM+MI+NS+TF-MoM6, 81; PS+AS+EM+SS-MoM4, 85; PS-TuP2, **119**

Zhu, C.: BI+AS+IPF+NS-TuA8, 110

Zhu, H.: SS+EM+PS+TF-ThA10, **159**

Zhu, H.P.: TF-ThP11, 163

Zhu, J.F.: SS+HC+NS+PS-TuM4, **104**

Zhu, M.: AS+SE-WeA12, 135

Zhu, T.: EM-ThP19, 161

Zhu, W.: NS+AN+EM+MN+MP+RM-TuM3, 102; PS+PB+SE-TuA9, 113

Zhu, Z.: NS+2D+AN+EM+MN+MP+PC+RM-MoM11, 84

Zhu, Z.H.: AS+SE-WeA9, 135; AS-TuA11, **109**; BI+AS+IPF+MN-MoA8, 90; BI+AS+NS-FrM5, 168; BI-WeA11, 136; PC+AS+BI+EM+PB+SS-WeM3, 128

Ziarko, M.W.: EM-ThP1, 160

Ziatdinov, M.: 2D+AM+EM+NS-WeM11, **124**

Zoh, I.: 2D+EM+MN+NS-ThA10, 152

Zöhrer, S.: SE+PS-TuM6, 104

Zollner, S.: EL+AS+EM-MoM4, 82; EL+EM-MoA4, 90; EL+EM-MoA5, 90; EL-TuP3, 118; EL-TuP4, 118

Zorman, C.A.: MN+NS+PS-WeM3, **127**

Zorro, F.: TF2-MoM4, 87

Zou, K.: AS-MoA6, 89

Zurutuza, A.: AS-MoA8, 89

Zyulkov, I.: TF+AM+EM+PS-TuM12, **105**

AVS 65

EXHIBIT PROGRAM



Exhibit Hall Special Events • Exhibitor Profiles • Exhibitor Product Locator • Exhibit Schedule
Sponsors • Corporate Members • Free Attractions



EXHIBIT HALL EVENTS

Welcome to the AVS International Symposium and Exhibition! The Symposium will address cutting-edge issues associated with materials, processing and interfaces in the research and manufacturing communities.

Visit the exhibits where you will find an extensive display of tools, equipment, services and consulting for film deposition, surface and interface measurements and analysis, materials, chemicals, supplies, vacuum production & measurement and related instrumentation for surface, interface and film measurements as well as professional literature and publications.

Exhibit Entry is FREE !

EXHIBIT HALL ATTRACTI0NS & EVENTS

150 Exhibitors Showcasing their Latest Technology

Ask The Experts - *Hosted by the AVS Vacuum Technology Division*

AVS Career Center

Exhibitor Technology Spotlight Sessions

AVS Membership & Education Booth

AVS Store: Gifts & Souvenirs

Free Morning Coffee • Lunch • Afternoon Refreshments

Art Zone Display & Competition

Daily Raffle Drawings

Free Internet Access & Printing Station

Caricatures & Foosball Tournament

Competitions & Networking Events

2018 Exhibit Schedule

Oct. 23 Tuesday 10am - 5:00pm

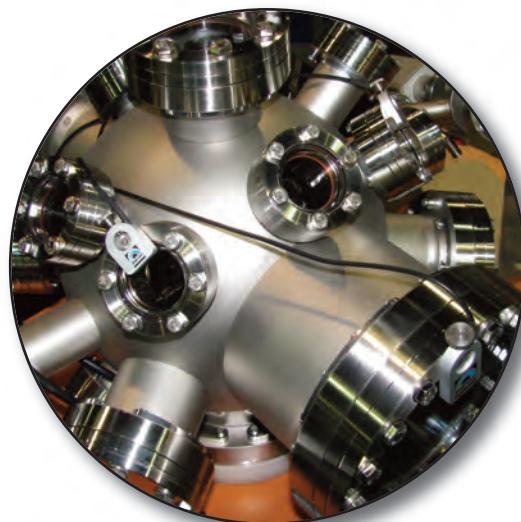
Oct. 24 Wednesday 10am - 4:30pm

Oct. 25 Thursday 10am - 2:30pm



TABLE OF CONTENTS

Special Events & Attractions.....	195
Sponsors & Corporate Members....	197
Exhibitor Quick Reference Guide...	198
Exhibit Hall Floor Plan	199
Product Locator	200
Exhibitor Profiles	212





Special Events & Attractions

Welcome Mixer - Monday 7:00pm - 8:00pm

Long Beach Convention Center - Hall B



Monday, October 22

6:30 - 8:00

NETWORKING at its best! The Welcome Mixer offers food and refreshments and the opportunity to casually interface with fellow AVS attendees and exhibitors from around the world. Everyone is welcome at the Mixer! **Sponsored in part by AIP Journal of Applied Physics.**

Ask The Experts (ATE) BOOTH 362

Hosted by the AVS Vacuum Technology Division. An unbiased, open forum staffed by experts in various aspects of vacuum technology to discuss and help solve vacuum related issues.



Challenge our experts and receive a free souvenir while supplies last!!

Sponsored by: SAES Getters & Duniway Stockroom

Career Center

BOOTH 162

Make the right connections at AVS. Post job openings or search available positions. The AVS Career Center provides the opportunity for attendees and exhibitors to find a perfect match.



Interview Rooms Available



8th Annual Foosball Tournament

Join the competition in Booth 465. Great Prizes!! Sign up begins at Tuesday morning, October 22 in the Exhibit Hall at booth 463. Hosted and Sponsored by Gamma Vacuum.



Daily Raffle Prizes

Find your daily raffle tickets in your registration kit. Enter your tickets into the raffle drum in **Booth 563** in the Exhibit Hall Tuesday, Wednesday & Thursday mornings. Come back in the afternoons to see if you are a winner! The **Grand Prize Raffle** drawing will take place on Thursday during the Exhibit Finale. Make sure you get your ticket stamped at the R.D. Mathis booth before you drop your ticket in the drum! Great prizes including FitBits, BlueTooth Speakers, Head Phones; Amazon Echo and so much more!

E-Mail Pavilion

BOOTH 146



A convenient place for attendees to keep in touch with the outside world. Check your e-mail, flights, print boarding passes, etc.

New this year... Charging Station for your phones and laptops !!

Generously sponsored by
Agilent, Vacuum Products Division



Special Events & Attractions

Caricaturists



must be validated by our generous sponsor MKS.

BOOTH 427

Visit the Special Events booth for your FREE AVS-65 Souvenir. Our caricature artists will be available during all Exhibit Hall hours. You will find your ticket in your registration kit. Ticket

AVS Store

BOOTH 559

Membership Information - learn about the many advantages of AVS Membership, also browse through Educational Materials and AVS logo items.

- Videos
- Books
- Monographs
- Membership Services
- AVS Logo Items



Art Zone/Contest

BOOTH 543

See graphic designs in the form of art from fellow AVS attendees who will compete in our annual art contest. Take a look at this amazing display and don't forget to vote! Prizes will be announced at the Exhibit Finale on Thursday. CASH PRIZES !!!



Exhibitor Technology Spotlight Sessions

BOOTH 168

Keep up with the latest technology! Exhibitors showcase new products, services and applications. Sessions are scheduled during the technical session breaks in the stage area in the exhibit hall.



**Exhibitor Technology
Spotlight Sessions**

Need to charge
your cell phone or laptop ?

Stop by the E-Mail Pavilion
in the exhibit hall where you will
find a comfortable charging
lounge for your convenience!

Generously Sponsored by
Agilent,
Vacuum Products Division



Sponsors & Corporate Members

AVS wishes to thank the following companies for their generous support

AVS-65 SPONSORS

Agilent Technologies - Vacuum Products Div.
AIP - Journal of Chemical Physics
AIPP - American Institute of Physics, Publishing
American Institute of Physics (AIP)
Bruker
Duniway Stockroom Corporation
Elettra
Gamma Vacuum
Heidelberg Instruments, Inc.
Hiden Analytical
Ionoptika
Ion-Tof USA
Kimball Physics Inc.
Kratos Analytical
Kurt J. Lesker Company
Lam Research Corporation
McAllister Technical Services
Mantis Sigma
MDC Vacuum Products, LLC
MKS Instruments
NT-MDT Spectrum Instruments
Park Systems
PHPK Technologies
Physical Electronics
Physics Today
Physics World
Protochips
R.D. Mathis Company
RBD Instruments, Inc.
RF VII Inc.
SAES Group
Scienta Omicron
Scientific Instrument Services, Inc.
SPECS Surface Nano Analysis, Inc.
Staib Instruments
Super Conductor Materials
TEL (Tokyo Electron)
Teledyne Hastings Instruments
The Journal of Physical Chemistry
The Journal of Vacuum Technology & Coating
UC Components
Vacuum Research Corporation
VAT
Zeiss

2018 CORPORATE MEMBERS

ABBESS Instruments
AJA International, Inc.
American Institute of Physics
Applied Vacuum Technology, LLC
Busch Vacuum Pumps and Systems
CeramTec North America
Challentech International Corp.
COSMOTEC, Inc.
Denton Vacuum LLC
Duniway Stockroom Corp
Edwards Vacuum, Inc.
EP Laboratories, Inc.
FMG Enterprises, Inc.
Gamma Vacuum
Helium Leak Testing, Inc.
Hiden Analytical, Inc.
HIS Vacuum Solutions
Horiba Instruments
HVA, LLC
ION-TOF USA Inc.
Kratos Analytical
Kurt J. Lesker Company
Mack Vacuum Technologies, Inc.
MDC Vacuum Products, LLC
MKS Instruments Inc
Nor-Cal Products
Nordiko Technical Services Limited
Pfeiffer Vacuum Technology
Physical Electronics
Plasmaterials Inc
Plasma-Therm
Precision Plus Vacuum Parts
Process Materials Inc
Quantum Innovations, Inc.
R.D. Mathis Company
RBD Instruments, Inc.
Reynard Corporation
RF VII Inc.
SAES Getters USA, Inc.
SPI Supplies
Staib Instruments, Inc.
Sumitomo (SHI) Cryogenics of America, Inc.
Super Conductor Materials Inc
SynSysCo
Thermo Fisher Scientific
UC Components Inc
Vacuum Plus Manufacturing Inc.
Vacuum Research Corp.
XEI Scientific, Inc.



Exhibitor Quick Reference Guide

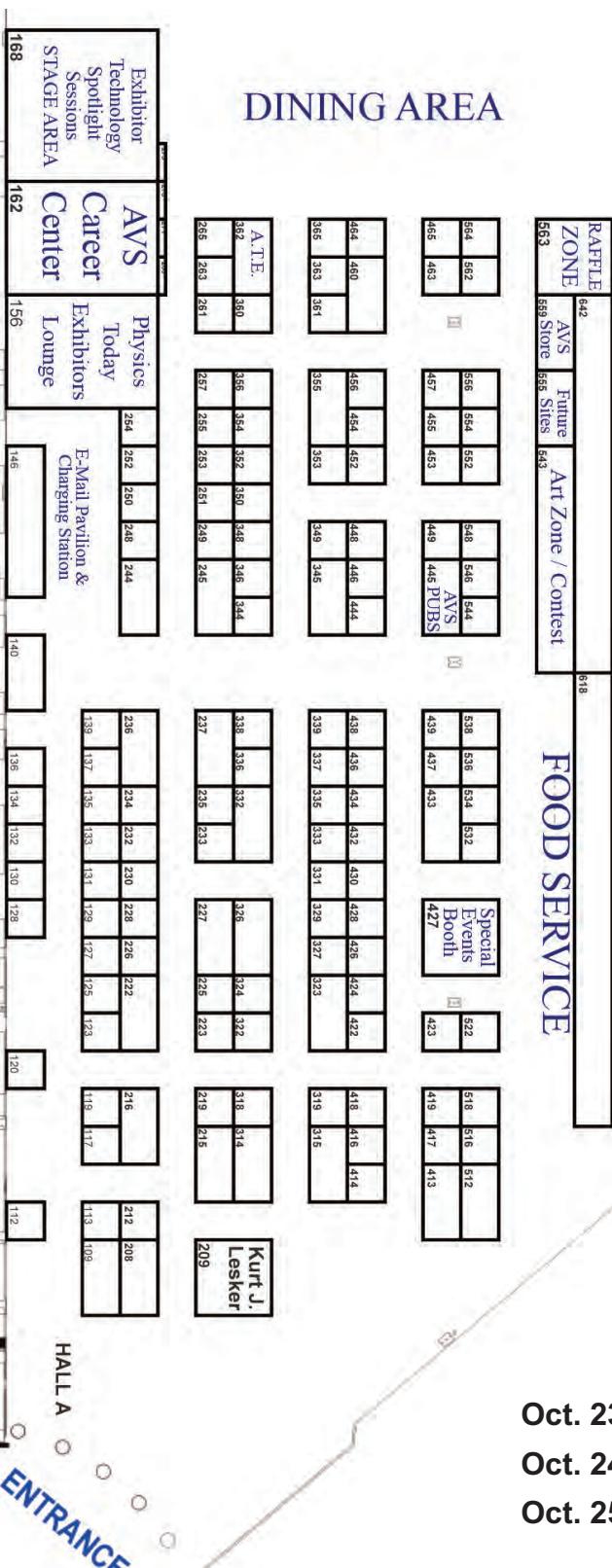
Booth	Company	Booth	Company	Booth	Company
254	Across International	522	GNB King Lai Group	426	Plasma Process Group, Inc.
548	AdValue Technology	350	HeatWave Labs Inc.	453	Precision Plus Vacuum Parts
333	Advanced HiVac Application Co.,LTD	448	Heidelberg Instruments, Inc.	319	Prevac sp. z o.o.
413	Agilent Technologies, Vacuum Products Div.	449	Helium Leak Testing, Inc.	437	QEI Corporation
318	AIP Publishing	345	Hidden Analytical, Inc.	216	R.D. Mathis Company
455	Air Liquide Electronics-Balazs	464	Hine Automation	125	RASIRC
	NanoAnalysis	137	HORIBA	322	RBD Instruments, Inc.
338	AJA International, Inc.	250	HS-Group GmbH	234	Refining Systems
113	American Institute of Physics	416	HVA, LLC	356	RF VII Inc.
329	Amuneal Mfg Corporation	422	INFICON	120	RHK Technology Inc.
324	ANCORP	417	InRedox LLC	233	SAES Group
123	Anderson Dahlen-Applied Vacuum Div.	414	Instrument Technology Research	326	ScientaOmicron, Inc.
219	Anton Paar USA	354	Center, NARLabs	237	Scientific Instrument Services, Inc.
424	Applied Surface Technologies	269	InstruTech, Inc.	136	Semicore Equipment, Inc.
423	Atlas Technologies	222	ION-TOF USA	456	Semilab
433	Attocube Systems, Inc.	332	J.A. Woollam Co., Inc.	133	SiO2 Innovates LLC/SiO2 NanoTech LLC
362	AVS-Ask The Experts-Vac Tech Div.	235	Kashiyama-USA Inc.	251	Solberg Manufacturing
543	AVS Art Zone/Contest	112	Kaufman & Robinson, Inc.	532	Solecon Laboratories, Inc.
162	AVS Career Center	223	Kimball Physics Inc.	331	Solid Sealing Technology, Inc.
146	AVS E-Mail Pavilion	227	Kratos Analytical, Inc.	314	SPECS-TII, Inc.
168	AVS Exhibitor Technology Sessions	336	Kurdex Corporation	444	SPI Supplies
465	AVS Foosball Tournament	209	Kurt J. Lesker Company	344	Staib Instruments
555	AVS Future Sites	457	Kyungwon Tech Co., Ltd.	434	Strem Chemicals, Inc.
445	AVS Publications	139	Lawrence Livermore National Labs	355	Super Conductor Materials
563	AVS Raffle Zone	225	Leybold USA Inc.	129	Surface Science Integration
427	AVS Special Events Booth	109	MANTIS-SIGMA	518	SynSysCo
559	AVS Store	428	Matheson Tri-Gas, Inc.	339	TDK-Lambda Americas HP Division
361	BellowsTech, LLC	134	McAllister Technical Services, Inc.	348	Technetics Group
261	BihurCrystal S.L.	512	MDC Vacuum Products, LLC	365	Tech-X Corporation
460	Brooks Automation	127	MeiVac, Inc.	232	Teledyne Hastings Instruments
212	Bruker Nano Surfaces	337	Micro Photonics	436	Thermionics Laboratory, Inc.
432	Centrotherm Clean Solutions	215	MKS Instruments	245	Thermo Fisher Scientific
117	Cosmotec, Inc.	248	MODION®	130	Torreyvac Inc.
265	CryoWorks, Inc.	433	Neaspec GmbH	236	UC Components
352	CS Clean Solutions, Inc.	544	NIST	209	UHV Design Ltd.
446	Delcom Instruments	119	Nonsequitur Technologies	249	ULVAC, Technologies, Inc.
556	Denton Vacuum LLC	438	Nor-Cal Products, Inc.	419	United Mineral and Chemical Corp.
315	Duniway Stockroom Corp.	454	Omley Industries, Inc.	128	VACGEN Ltd.
452	Ebara Technologies	257	Osaka Vacuum USA, Inc.	244	Vacuum Research Corporation
327	Edwards Vacuum	418	Park Systems, Inc.	323	VAT
430	EP Laboratories, Inc.	439	Pfeiffer Vacuum Technology, Inc.	226	Veeco Instruments
538	Extrel	353	PHPK Technologies	346	Williamsburg Scientific Instruments LLC
349	Ferrovac GmbH	208	Physical Electronics	230	Yugyokuen Ceramics Co., Ltd.
360	Fischer Technology, Inc.	156	Physics Today Exhibitor Lounge	228	zeroK NanoTech
463	Gamma Vacuum	335	Picosun USA, LLC		



Exhibit Hall Floor Plan

Long Beach Convention Centr
Hall A

DINING AREA



2018 Exhibit Schedule

Oct. 23 Tuesday 10am - 5:00pm
Oct. 24 Wednesday 10am - 4:30pm
Oct. 25 Thursday 10am - 2:30pm



PRODUCT LOCATOR

Not sure where to find what you're looking for?

The Product Locator will help you find the vendors you need.

Product categories are listed alphabetically followed by the supplier(s) and their corresponding booth location.



ANALYTICAL

	<u>BOOTH</u>
Anton Paar USA	219
Applied Surface Technologies	424
Brooks Automation	460
EP Laboratories, Inc.	430
Fischer Technology, Inc.	360
Heidelberg Instruments, Inc.	448
Helium Leak Testing, Inc.	449
InRedox LLC	417
ION-TOF USA	222
J.A. Woollam Co., Inc.	332
McAllister Technical Services, Inc.	134
MKS Instruments	215
NIST	544
Pfeiffer Vacuum Technology, Inc.	439
Physical Electronics	208
Prevac sp. z o.o.	319
RASIRC	125
RHK Technology Inc.	120
SiO2 Innovates LLC/SiO2 NanoTech LLC	133
Solecon Laboratories, Inc.	532
SPECS Surface Nano Analysis, Inc.	314
SPI Supplies	444
Staib Instruments	344
VACGEN Ltd.	128
Williamsburg Scientific Instruments LLC	346

ANALYTICAL INSTRUMENTATION

Anton Paar USA	219
Brooks Automation	460
Bruker Nano Surfaces	212
Cosmotec, Inc.	117
Extrel	538
Fischer Technology, Inc.	360
Heidelberg Instruments, Inc.	448
Helium Leak Testing, Inc.	449
Hidden Analytical, Inc.	345
INFICON	422
ION-TOF USA	222
J.A. Woollam Co., Inc.	332
Kimball Physics Inc.	223
Kratos Analytical, Inc.	227
Matheson Tri-Gas, Inc.	428
Micro Photonics	337
MKS Instruments	215
NIST	544
Nonsequitur Technologies	119
Park Systems, Inc.	418
Pfeiffer Vacuum Technology, Inc.	439
Physical Electronics	208

BOOTHANALYTICAL INSTRUMENTATION (CONTINUED)

Prevac sp. z o.o.	319
RASIRC	125
RBD Instruments, Inc.	322
RF VII Inc.	356
RHK Technology Inc.	120
ScientiaOmicron, Inc.	326
Scientific Instrument Services, Inc.	237
SiO2 Innovates LLC/SiO2 NanoTech LLC	133
Solid Sealing Technology, Inc.	331
SPECS Surface Nano Analysis, Inc.	314
Staib Instruments	344
SynSysCo	518
TDK-Lambda Americas HP Division	339
Teledyne Hastings Instruments	232
Thermo Fisher Scientific	245
Torreyvac Inc.	130
ULVAC, Technologies, Inc.	249
VACGEN Ltd.	128
Williamsburg Scientific Instruments LLC	346
Yugyokuen Ceramics Co., Ltd.	230
zeroK NanoTech	228

BOOTHATOMIC LAYER DEPOSITION SYSTEMS

Hidden Analytical, Inc.	345
InRedox LLC	417
Kurdex Corporation	336
Kurt J. Lesker Company	209
McAllister Technical Services, Inc.	134
Micro Photonics	337
NIST	544
Picosun USA, LLC	335
RASIRC	125
Strem Chemicals, Inc.	434
United Mineral and Chemical Corp.	419
VACGEN Ltd.	128
Veeco Instruments	226

AUGER ELECTRON SPECTROMETERS

Kratos Analytical, Inc.	227
Physical Electronics	208
Prevac sp. z o.o.	319
RASIRC	125
RBD Instruments, Inc.	322
ScientiaOmicron, Inc.	326
SPECS Surface Nano Analysis, Inc.	314
Staib Instruments	344
Thermo Fisher Scientific	245
Williamsburg Scientific Instruments LLC	346



Product Locator



BELLOWS CONTACTS

	BOOTH
ANCORP	324
BellowsTech, LLC	361
McAllister Technical Services, Inc.	134
Torreyvac Inc.	130

BELLOWS: MINIATURE METAL

	BOOTH
ANCORP	324
BellowsTech, LLC	361
MDC Vacuum Products, LLC	512
Torreyvac Inc.	130

BONDING TECHNIQUES

	BOOTH
Cosmotec, Inc.	117
Kurt J. Lesker Company	209
NIST	544
Omley Industries, Inc.	454
Scientific Instrument Services, Inc.	237
Solid Sealing Technology, Inc.	331
Super Conductor Materials	355
Yugyokuen Ceramics Co., Ltd.	230

CALIBRATION SERVICES

	BOOTH
Anton Paar USA	219
Applied Surface Technologies	424
Helium Leak Testing, Inc.	449
Instrument Tech. Research Ctr, NARLabs	414
MKS Instruments	215
Semicore Equipment, Inc.	136
SiO2 Innovates LLC/SiO2 NanoTech LLC	133
Teledyne Hastings Instruments	232
Torreyvac Inc.	130

CHEMICAL: SURFACE TREATING SERVICES

	BOOTH
Centrotherm Clean Solutions	432
NIST	544
RASIRC	125
Scientific Instrument Services, Inc.	237
SiO2 Innovates LLC/SiO2 NanoTech LLC	133

CHILLERS, COOLING SYSTEMS

	BOOTH
Brooks Automation	460
Helium Leak Testing, Inc.	449
RF VII Inc.	356
SPI Supplies	444
SynSysCo	518

CLEANING SERVICES

	BOOTH
ANCORP	324
Applied Surface Technologies	424
Ebara Technologies	452
RASIRC	125
Scientific Instrument Services, Inc.	237
SiO2 Innovates LLC/SiO2 NanoTech LLC	133
Thermionics Laboratory, Inc.	436
Torreyvac Inc.	130

CONSULTING

	BOOTH
Amuneal Mfg Corporation	329
Anderson Dahlen-Applied Vacuum Div.	123
AVS - Ask The Experts - Vac Tech Div.	362
Centrotherm Clean Solutions	432
EP Laboratories, Inc.	430
Ferrovac GmbH	349
GNB King Lai Group	522
Helium Leak Testing, Inc.	449
ION-TOF USA	222
Kurdex Corporation	336
McAllister Technical Services, Inc.	134
NIST	544
PHPK Technologies	353
RASIRC	125
Semicore Equipment, Inc.	136
SiO2 Innovates LLC/SiO2 NanoTech LLC	133
SynSysCo	518
Tech-X Corporation	365

COUPLINGS: FLEXIBLE SHAFT

	BOOTH
ANCORP	324
Anderson Dahlen-Applied Vacuum Division	123
BellowsTech, LLC	361
Kurt J. Lesker Company	209
MDC Vacuum Products, LLC	512
Torreyvac Inc.	130

CRYOGENIC FILLING AND TRANSFER SYSTEMS

CryoWorks, Inc.	265
-----------------	-----

CRYOGENIC LN2 SYSTEMS

CryoWorks, Inc.	265
-----------------	-----

CRYOGENIC MANIFOLDS

CryoWorks, Inc.	265
-----------------	-----

CRYOGENIC PIPING

CryoWorks, Inc.	265
-----------------	-----



Product Locator



CUSTOM VACUUM SYSTEMS

	<u>BOOTH</u>
Agilent Technologies, Vacuum Products Div.	413
AJA International, Inc.	338
ANCORP	324
Anderson Dahlen - Applied Vacuum Div.	123
Atlas Technologies	423
Cosmotec, Inc.	117
Edwards Vacuum	327
Extrel	538
Ferrovac GmbH	349
GNB King Lai Group	522
HeatWave Labs Inc.	350
Helium Leak Testing, Inc.	449
Hidden Analytical, Inc.	345
Hine Automation	464
HVA, LLC	416
Instrument Technology Research Ctr, NARLabs	414
Kimball Physics Inc.	223
Kurdex Corporation	336
Kurt J. Lesker Company	209
Leybold USA Inc.	225
MANTIS-SIGMA	109
McAllister Technical Services, Inc.	134
MDC Vacuum Products, LLC	512
MeiVac, Inc.	127
MKS Instruments	215
MODION®	248
Nor-Cal Products, Inc.	438
Omley Industries, Inc.	454
PHPK Technologies	353
Prevac sp. z o.o.	319
RF VII Inc.	356
RHK Technology Inc.	120
Semicore Equipment, Inc.	136
Staib Instruments	344
SynSysCo	518
Thermionics Laboratory, Inc.	436
Torreyvac Inc.	130
VACGEN Ltd.	128

DETECTORS / MULTIPLIERS

Extrel	538
Helium Leak Testing, Inc.	449
Hidden Analytical, Inc.	345
Micro Photonics	337
RBD Instruments, Inc.	322
Scientific Instrument Services, Inc.	237
SPECS Surface Nano Analysis, Inc.	314
SPI Supplies	444
Torreyvac Inc.	130

E-BEAM GUN POWER SUPPLIES

INFICON	422
Kaufman & Robinson, Inc.	112
Kimball Physics Inc.	223
Kurt J. Lesker Company	209
McAllister Technical Services, Inc.	134
MDC Vacuum Products, LLC	512
MeiVac, Inc.	127
Micro Photonics	337
Prevac sp. z o.o.	319
Staib Instruments	344
Thermionics Laboratory, Inc.	436
Torreyvac Inc.	130
Williamsburg Scientific Instruments LLC	346

E-BEAM GUN SWEEPS

Kimball Physics Inc.	223
MDC Vacuum Products, LLC	512
MeiVac, Inc.	127
Prevac sp. z o.o.	319
Thermionics Laboratory, Inc.	436
Torreyvac Inc.	130

E-BEAM GUNS

Cosmotec, Inc.	117
HeatWave Labs Inc.	350
Kimball Physics Inc.	223
Kurt J. Lesker Company	209
MANTIS-SIGMA	109
McAllister Technical Services, Inc.	134
MDC Vacuum Products, LLC	512
MeiVac, Inc.	127
Micro Photonics	337
Prevac sp. z o.o.	319
Staib Instruments	344
Super Conductor Materials	355
Thermionics Laboratory, Inc.	436
Torreyvac Inc.	130
Williamsburg Scientific Instruments LLC	346
Yugyokuen Ceramics Co., Ltd.	230

ELECTROFORMING SERVICES

BellowsTech, LLC	361
------------------	-----

ELECTROFORMS: CUSTOM

BellowsTech, LLC	361
------------------	-----

EMPLOYMENT SERVICES / RECRUITING

AVS Career Center	162
-------------------	-----



Product Locator



EQUIPMENT, USED

	BOOTH
Duniway Stockroom Corp.	315
Ebara Technologies	452
Helium Leak Testing, Inc.	449
Hine Automation	464
Kurdex Corporation	336
Pfeiffer Vacuum Technology, Inc.	439
RBD Instruments, Inc.	322
RF VII Inc.	356
Semicore Equipment, Inc.	136
SynSysCo	518
Torreyvac Inc.	130

FITTINGS, GASKETS, FLANGES, SEALS

ANCORP	324
Anderson Dahlen - Applied Vacuum Div.	123
Atlas Technologies	423
BellowsTech, LLC	361
Cosmotec, Inc.	117
Duniway Stockroom Corp.	315
Ebara Technologies	452
Ferrovac GmbH	349
GNB King Lai Group	522
Helium Leak Testing, Inc.	449
HVA, LLC	416
INFICON	422
Kimball Physics Inc.	223
Kurt J. Lesker Company	209
Leybold USA Inc.	225
McAllister Technical Services, Inc.	134
MDC Vacuum Products, LLC	512
MKS Instruments	215
MODION®	248
Nonsequitur Technologies	119
Nor-Cal Products, Inc.	438
Omley Industries, Inc.	454
Pfeiffer Vacuum Technology, Inc.	439
Precision Plus Vacuum Parts	453
RBD Instruments, Inc.	322
Scientific Instrument Services, Inc.	237
Solid Sealing Technology, Inc.	331
Technetics Group	348
Thermionics Laboratory, Inc.	436
Torreyvac Inc.	130
UC Components	236
VACGEN Ltd.	128
Yugyokuen Ceramics Co., Ltd.	230

BOOTH

FT-IR

MKS Instruments	215
Prevac sp. z o.o.	319
Thermo Fisher Scientific	245

BOOTH

GAS CONTROL SYSTEMS

Anderson Dahlen - Applied Vacuum Div.	123
CENTROTHERM CLEAN SOLUTIONS	432
COSMOTEC, INC.	117
HIDEN ANALYTICAL, INC.	345
MATHESON TRI-GAS, INC.	428
MDC VACUUM PRODUCTS, LLC	512
MKS INSTRUMENTS	215
RASIRC	125
TELEDYNE HASTINGS INSTRUMENTS	232

GAUGES, TUBES

AdValue Technology	548
Agilent Technologies, Vacuum Products Div.	413
Duniway Stockroom Corp.	315
Edwards Vacuum	327
Helium Leak Testing, Inc.	449
Hidden Analytical, Inc.	345
INFICON	422
Instrutech, Inc.	354
Kurt J. Lesker Company	209
MDC Vacuum Products, LLC	512
MKS Instruments	215
Pfeiffer Vacuum Technology, Inc.	439
Precision Plus Vacuum Parts	453
RBD Instruments, Inc.	322
Scientific Instrument Services, Inc.	237
Thermionics Laboratory, Inc.	436
ULVAC, Technologies, Inc.	249
VACGEN Ltd.	128
Vacuum Research Corporation	244

GC-MS / LC-MS

Hidden Analytical, Inc.	345
INFICON	422
Scientific Instrument Services, Inc.	237
Yugyokuen Ceramics Co., Ltd.	230

GLASSWARE

AdValue Technology	548
ANCORP	324
RBD Instruments, Inc.	322
Scientific Instrument Services, Inc.	237

GLOVE BOXES

Across International
Physical Electronics

BOOTH

254
208

ION / ELECTRON GUNS

Cosmotec, Inc.
HeatWave Labs Inc.
Hiden Analytical, Inc.
ION-TOF USA
Kaufman & Robinson, Inc.
Kimball Physics Inc.
Kratos Analytical, Inc.
Kurt J. Lesker Company
MANTIS-SIGMA
Micro Photonics
NIST
Nonsequitur Technologies
Physical Electronics
Plasma Process Group, Inc.
Prevac sp. z o.o.
RBD Instruments, Inc.
ScientaOmicron, Inc.
SPECS Surface Nano Analysis, Inc.
Staib Instruments
Torreyvac Inc.
Veeco Instruments
Williamsburg Scientific Instruments LLC
Yugyokuen Ceramics Co., Ltd.
zeroK NanoTech

ION BEAM DEPOSITION SYSTEMS/GUNS

AJA International, Inc.
Cosmotec, Inc.
HeatWave Labs Inc.
Hiden Analytical, Inc.
Kaufman & Robinson, Inc.
Kurdex Corporation
Kurt J. Lesker Company
MANTIS-SIGMA
McAllister Technical Services, Inc.
MDC Vacuum Products, LLC
Micro Photonics
NIST
Physical Electronics
Plasma Process Group, Inc.
Prevac sp. z o.o.
Semicore Equipment, Inc.
Veeco Instruments

LEAK DETECTORS

Agilent Technologies, Vacuum Products Div.
Duniway Stockroom Corp.
Edwards Vacuum
GNB King Lai Group
Helium Leak Testing, Inc.
Hiden Analytical, Inc.
INFICON
Leybold USA Inc.
MKS Instruments
Pfeiffer Vacuum Technology, Inc.
Prevac sp. z o.o.
Scientific Instrument Services, Inc.
SynSysCo
Torreyvac Inc.
ULVAC, Technologies, Inc.
Yugyokuen Ceramics Co., Ltd.

BOOTH

413
315
327
522
449
345
422
225
215
439
319
237
518
130
249
230

LITHOGRAPHY SYSTEMS

Heidelberg Instruments, Inc.
NIST
ScientaOmicron, Inc.
Torreyvac Inc.

MACHINING (BULK AND SPECIAL)

ANCORP
Anderson Dahlen - Applied Vacuum Division
Atlas Technologies
Ferrovac GmbH
Kurt J. Lesker Company
Matheson Tri-Gas, Inc.
McAllister Technical Services, Inc.
MDC Vacuum Products, LLC
MODION®
Scientific Instrument Services, Inc.
Super Conductor Materials
Torreyvac Inc.
UC Components

MACHINING (REPAIR, REFURB, MODS)

Anderson Dahlen - Applied Vacuum Division
Atlas Technologies
McAllister Technical Services, Inc.
MODION®
Precision Plus Vacuum Parts
Scientific Instrument Services, Inc.
Super Conductor Materials
Torreyvac Inc.
VAT



Product Locator



MAGNETRON SPUTTERING CATHODES

	BOOTH
AJA International, Inc.	338
Kurdex Corporation	336
Kurt J. Lesker Company	209
MANTIS-SIGMA	109
MDC Vacuum Products, LLC	512
MeiVac, Inc.	127
Refining Systems	234
SPI Supplies	444
Super Conductor Materials	355
Torreyvac Inc.	130

MAGNETRON SPUTTERING EQUIPMENT

	BOOTH
AJA International, Inc.	338
Kurdex Corporation	336
Kurt J. Lesker Company	209
MANTIS-SIGMA	109
MDC Vacuum Products, LLC	512
MeiVac, Inc.	127
Prevac sp. z o.o.	319
SPI Supplies	444
Torreyvac Inc.	130

MASS FLOW CONTROLLER/ACCESSORIES

	BOOTH
Cosmotec, Inc.	117
MDC Vacuum Products, LLC	512
MKS Instruments	215
Nor-Cal Products, Inc.	438
Prevac sp. z o.o.	319
RASIRC	125
Teledyne Hastings Instruments	232
Torreyvac Inc.	130

MATERIALS / STANDARDS

	BOOTH
AdValue Technology	548
AJA International, Inc.	338
Amuneal Mfg Corporation	329
ANCORP	324
Anton Paar USA	219
BihurCrystal S.L.	261
Fischer Technology, Inc.	360
InRedox LLC	417
Kurt J. Lesker Company	209
MDC Vacuum Products, LLC	512
NIST	544
R.D. Mathis Company	216
RASIRC	125
Refining Systems	234
Scientific Instrument Services, Inc.	237
SPI Supplies	444

MATERIALS / STANDARDS (CONTINUED)

	BOOTH
Super Conductor Materials	355
Torreyvac Inc.	130
United Mineral and Chemical Corp.	419
Yugyokuen Ceramics Co., Ltd.	230

MATERIALS TESTING

	BOOTH
Amuneal Mfg Corporation	329
Anton Paar USA	219
Applied Surface Technologies	424
Bruker Nano Surfaces	212
Cosmotec, Inc.	117
Delcom Instruments	446
EP Laboratories, Inc.	430
Fischer Technology, Inc.	360
Helium Leak Testing, Inc.	449
InRedox LLC	417
ION-TOF USA	222
J.A. Woollam Co., Inc.	332
Kimball Physics Inc.	223
NIST	544
RASIRC	125
RHK Technology Inc.	120
SiO2 Innovates LLC/SiO2 NanoTech LLC	133
Solecon Laboratories, Inc.	532
SPECS Surface Nano Analysis, Inc.	314
SPI Supplies	444
Staib Instruments	344
Torreyvac Inc.	130

MICROSCOPY

	BOOTH
AdValue Technology	548
Anton Paar USA	219
Attocube Systems, Inc.	433
Bruker Nano Surfaces	212
InRedox LLC	417
NIST	544
Park Systems, Inc.	418
Pfeiffer Vacuum Technology, Inc.	439
Refining Systems	234
RHK Technology Inc.	120
ScientaOmicron, Inc.	326
SPECS Surface Nano Analysis, Inc.	314
SPI Supplies	444
Thermo Fisher Scientific	245
Torreyvac Inc.	130
Yugyokuen Ceramics Co., Ltd.	230
zeroK NanoTech	228



Product Locator



NANO FABRICATION SYSTEMS

Hidden Analytical, Inc.
Hine Automation
InRedox LLC
NIST
Prevac sp. z o.o.
RHK Technology Inc.
ScientaOmicron, Inc.
Torreyvac Inc.
zeroK NanoTech

BOOTH

345
464
417
544
319
120
326
130
228

PUMPS, EQUIPMENT, SERVICES & SUPPLIES

Across International
Agilent Technologies, Vacuum Products Div.
Anderson Dahlen - Applied Vacuum Division
Brooks Automation
CS Clean Solutions, Inc.
Duniway Stockroom Corp.
Ebara Technologies
Edwards Vacuum
Extrel
Gamma Vacuum
GNB King Lai Group
HeatWave Labs Inc.
Helium Leak Testing, Inc.
Kashiyama-USA Inc.
Kurt J. Lesker Company
Leybold USA Inc.
MDC Vacuum Products, LLC
MODION®
Omley Industries, Inc.
Osaka Vacuum USA, Inc.
Pfeiffer Vacuum Technology, Inc.
PHPK Technologies
Precision Plus Vacuum Parts
RBD Instruments, Inc.
SAES Group
Scientific Instrument Services, Inc.
Semicore Equipment, Inc.
Solberg Manufacturing
SPI Supplies
SynSysCo
Thermionics Laboratory, Inc.
Torreyvac Inc.
ULVAC, Technologies, Inc.
Vacuum Research Corporation

BOOTH

254
413
123
460
352
315
452
327
538
463
522
350
449
235
209
225
512
248
454
257
439
353
453
322
233
237
136
251
444
518
436
130
249
244

OVENS, VACUUM

Across International
Anderson Dahlen - Applied Vacuum Division
HeatWave Labs Inc.
Helium Leak Testing, Inc.
Hidden Analytical, Inc.
Prevac sp. z o.o.
RBD Instruments, Inc.
Torreyvac Inc.
ULVAC, Technologies, Inc.
VACGEN Ltd.

254
123
350
449
345
319
322
130
249
128

PARTICLE MONITORING

Horiba Scientific

137

PLANAR MAGNETRON CATHODES

AJA International, Inc.
Kurdex Corporation
Kurt J. Lesker Company
MDC Vacuum Products, LLC
MeiVac, Inc.
NIST
Refining Systems
Super Conductor Materials

338
336
209
512
127
544
234
355

PROCESS CONTROLLERS/MONITORS

Extrel
INFICON
Kurt J. Lesker Company
MeiVac, Inc.
MKS Instruments
Prevac sp. z o.o.
RASIRC
Solecon Laboratories, Inc.

538
422
209
127
215
319
125
532

PURIFICATION SYSTEMS

CS Clean Solutions, Inc.
Matheson Tri-Gas, Inc.
R.D. Mathis Company
RASIRC

352
428
216
125

PUBLISHERS

AIP Publishing
American Institute of Physics
AVS Publications
Physics Today

318
113
445
156

RAMAN SPECTROSCOPY

Anton Paar USA
Bruker Nano Surfaces
NIST
Thermo Fisher Scientific

219
212
544
245



Product Locator



RECRUITER/JOB PLACEMENT/CAREER SERVICES

American Institute of Physics
AVS Career Center

BOOTH

113
162

SOFTWARE

Kyungwon Tech Co., Ltd.
MKS Instruments
Prevac sp. z o.o.
RBD Instruments, Inc.
Scientific Instrument Services, Inc.
SiO2 Innovates LLC/SiO2 NanoTech LLC
Tech-X Corporation

BOOTH

457
215
319
322
237
133
365

RF SYSTEMS/GENERATORS/POWER SUPPLIES

Extrel
Kurt J. Lesker Company
MANTIS-SIGMA
MDC Vacuum Products, LLC
MeiVac, Inc.
Micro Photonics
MKS Instruments
MODION®
Plasma Process Group, Inc.
QEI Corporation
RF VII Inc.
Semicore Equipment, Inc.
SPI Supplies
TDK-Lambda Americas HP Division

538
209
109
512
127
337
215
248
426
437
356
136
444
339

SPECTROMETER ACCESSORIES

AdValue Technology
Cosmotec, Inc.
Extrel
Ferrovac GmbH
Helium Leak Testing, Inc.
Hiden Analytical, Inc.
Kratos Analytical, Inc.
Prevac sp. z o.o.
RBD Instruments, Inc.
SAES Group
Scientific Instrument Services, Inc.
Thermo Fisher Scientific
Torreyvac Inc.

548
117
538
349
449
345
227
319
322
233
237
245
130

SAMPLE MANIPULATION & HEATING

AdValue Technology
Anderson Dahlen - Applied Vacuum Division
Ferrovac GmbH
Kurt J. Lesker Company
McAllister Technical Services, Inc.
MDC Vacuum Products, LLC
Prevac sp. z o.o.
SPI Supplies
UHV Design Ltd.
VACGEN Ltd.

548
123
349
209
134
512
319
444
209
128

SPUTTERING DEPOSITION SYSTEM

AJA International, Inc.
Brooks Automation
Cosmotec, Inc.
Hiden Analytical, Inc.
Kaufman & Robinson, Inc.
Kurdex Corporation
Kurt J. Lesker Company
Leybold USA Inc.
MANTIS-SIGMA
McAllister Technical Services, Inc.
MDC Vacuum Products, LLC
MeiVac, Inc.
Micro Photonics
NIST
Nor-Cal Products, Inc.
Plasma Process Group, Inc.
Prevac sp. z o.o.
RASIRC
RF VII Inc.
Semicore Equipment, Inc.
SPECS Surface Nano Analysis, Inc.
SPI Supplies
Torreyvac Inc.
VACGEN Ltd.

338
460
117
345
112
336
209
225
109
134
512
127
337
544
438
426
319
125
356
136
314
444
130
128

SCANNING PROBE MICROSCOPY SYSTEMS

Attocube Systems, Inc.
Bruker Nano Surfaces
ION-TOF USA
MANTIS-SIGMA
Park Systems, Inc.
Prevac sp. z o.o.
RHK Technology Inc.
ScientaOmicron, Inc.
SPECS Surface Nano Analysis, Inc.
Torreyvac Inc.

433
212
222
109
418
319
120
326
314
130



Product Locator



<u>TESTING LABORATORY</u>	<u>BOOTH</u>	<u>THIN FILM VACUUM COATING (CONTINUED)</u>	<u>BOOTH</u>
EP Laboratories, Inc.	430	Super Conductor Materials	355
SiO2 Innovates LLC/SiO2 NanoTech LLC	133	Technetics Group	348
 <u>THICKNESS MONITORS/MEASUREMENT</u>		Thermionics Laboratory, Inc.	436
ANCORP	324	Torreyvac Inc.	130
Anton Paar USA	219	ULVAC, Technologies, Inc.	249
Bruker Nano Surfaces	212	VACGEN Ltd.	128
Delcom Instruments	446	 <u>ToF SIMS INSTRUMENTS</u>	
Fischer Technology, Inc.	360	Hidden Analytical, Inc.	345
Hidden Analytical, Inc.	345	ION-TOF USA	222
INFICON	422	Physical Electronics	208
J.A. Woollam Co., Inc.	332	SPECS Surface Nano Analysis, Inc.	314
Kurt J. Lesker Company	209	 <u>TUBING/PIPING/BELLOWS ASSEMBLIES</u>	
Micro Photonics	337	AdValue Technology	548
NIST	544	ANCORP	324
Prevac sp. z o.o.	319	Anderson Dahlen - Applied Vacuum Division	123
RASIRC	125	Atlas Technologies	423
RBD Instruments, Inc.	322	BellowsTech, LLC	361
Solecon Laboratories, Inc.	532	Duniway Stockroom Corp.	315
SPI Supplies	444	Ebara Technologies	452
ULVAC, Technologies, Inc.	249	McAllister Technical Services, Inc.	134
Veeco Instruments	226	MDC Vacuum Products, LLC	512
 <u>THIN FILM VACUUM COATING</u>		MKS Instruments	215
ADVALUE TECHNOLOGY	548	Nor-Cal Products, Inc.	438
BIHURCRYSTAL S.L.	261	Omley Industries, Inc.	454
BRUKER NANO SURFACES	212	Scientific Instrument Services, Inc.	237
COSMOTEC, INC.	117	Thermionics Laboratory, Inc.	436
HIDDEN ANALYTICAL, INC.	345	Vacuum Research Corporation	244
HINE AUTOMATION	464	 <u>VACUUM SYSTEM ACCESSORIES</u>	
INSTRUMENT TECH RESEARCH CTR, NARLABS	414	Agilent Technologies, Vacuum Products Div.	413
KAUFMAN & ROBINSON, INC.	112	ANCORP	324
KURDEX CORPORATION	336	Anderson Dahlen - Applied Vacuum Division	123
KURT J. LESKER COMPANY	209	Atlas Technologies	423
LEYBOLD USA INC.	225	BellowsTech, LLC	361
MANTIS-SIGMA	109	Brooks Automation	460
MDC VACUUM PRODUCTS, LLC	512	Cosmotec, Inc.	117
MICRO PHOTONICS	337	CS Clean Solutions, Inc.	352
NIST	544	Delcom Instruments	446
NOR-CAL PRODUCTS, INC.	438	Duniway Stockroom Corp.	315
PICOSUN USA, LLC	335	Ebara Technologies	452
PREVAC SP. Z O.O.	319	Edwards Vacuum	327
RBD INSTRUMENTS, INC.	322	Extrel	538
RF VII INC.	356	Ferrovac GmbH	349
SCIENTAOMICRON, INC.	326	GNB King Lai Group	522
SPECS SURFACE NANO ANALYSIS, INC.	314	HeatWave Labs Inc.	350
SPI SUPPLIES	444	Helium Leak Testing, Inc.	449
Strem Chemicals, Inc.	434	Hidden Analytical, Inc.	345

Continued...

Continued...



Product Locator



VACUUM SYSTEM ACCESSORIES (CONTINUED)

Hine Automation
HVA, LLC
INFICON
Instrutech, Inc.
Kaufman & Robinson, Inc.
Kimball Physics Inc.
Kurdex Corporation
Kurt J. Lesker Company
Leybold USA Inc.
McAllister Technical Services, Inc.
MDC Vacuum Products, LLC
MeiVac, Inc.
Micro Photonics
MKS Instruments
MODION®
Nonsequitur Technologies
Nor-Cal Products, Inc.
Omley Industries, Inc.
Osaka Vacuum USA, Inc.
Pfeiffer Vacuum Technology, Inc.
PHPK Technologies
Precision Plus Vacuum Parts
Prevac sp. z o.o.
R.D. Mathis Company
RBD Instruments, Inc.
RF VII Inc.
RHK Technology Inc.
SAES Group
Scientific Instrument Services, Inc.
Semicore Equipment, Inc.
Solberg Manufacturing
Solid Sealing Technology, Inc.
SPI Supplies
Staib Instruments
SynSysCo
Thermionics Laboratory, Inc.
Torreyvac Inc.
UC Components
ULVAC, Technologies, Inc.
VACGEN Ltd.
Vacuum Research Corporation
VAT
Yugyokuen Ceramics Co., Ltd.

BOOTH

464
416
422
354
112
223
336
209
225
134
512
127
337
215
248
119
438
454
257
439
353
453
319
216
322
356
120
233
237
136
251
331
444
344
518
436
130
236
249
128
244
323
230

VACUUM SYSTEM ACCESSORIES

Agilent Technologies, Vacuum Products Div.
ANCORP
Anderson Dahlen - Applied Vacuum Division
Atlas Technologies
BellowsTech, LLC
Brooks Automation
Cosmotec, Inc.
Ebara Technologies
Edwards Vacuum
Extrel
Ferrovac GmbH
GNB King Lai Group
HeatWave Labs Inc.
Hine Automation
Kurdex Corporation
Leybold USA Inc.
MDC Vacuum Products, LLC
Micro Photonics
MODION®
Nor-Cal Products, Inc.
Precision Plus Vacuum Parts
Prevac sp. z o.o.
R.D. Mathis Company
RBD Instruments, Inc.
RF VII Inc.
SAES Group
Scientific Instrument Services, Inc.
Solberg Manufacturing
SynSysCo
Torreyvac Inc.
UC Components
VACGEN Ltd.
VAT

VALVES

Agilent Technologies, Vacuum Products Div.
ANCORP
Anderson Dahlen - Applied Vacuum Division
Duniway Stockroom Corp.
Ebara Technologies
Edwards Vacuum
GNB King Lai Group
Hiden Analytical, Inc.
HVA, LLC
Kurt J. Lesker Company
Leybold USA Inc.
McAllister Technical Services, Inc.
MDC Vacuum Products, LLC
MeiVac, Inc.

X-RAY PHOTOELECTRON SPECTROMETERS

	BOOTH
Cosmotec, Inc.	117
Kratos Analytical, Inc.	227
MANTIS-SIGMA	109
NIST	544
Physical Electronics	208
Prevac sp. z o.o.	319
RBD Instruments, Inc.	322
ScientaOmicron, Inc.	326
SPECS Surface Nano Analysis, Inc.	314
Thermo Fisher Scientific	245
Torreyvac Inc.	130
VACGEN Ltd.	128



Across International

111 Dorsa Ave
Livingston, NJ 07039
Phone: 888-988-0899

www.acrossinternational.com

Industry leader in heat treatment and laboratory and material processing equipment manufacture. Our company's mission is as simple as it is profound, to empower those advancing science by offering innovative and high quality equipment, along with the best customer support. As such, we're fully committed to providing uncompromising reliability, innovation, and value to our customers. Our formula must be working. We've had the privilege of providing equipment to the top universities, research centers, distributors, and corporations all across the globe. These include Tesla, NASA, GM, GE, Lockheed Martin, and many others. Founded and based in New Jersey, in order to better serve the needs of our ever-growing customer base, we've established a West Coast center in Nevada, and another location in Victoria, Australia. In the future, we aim to build more partnerships, while also providing 100% customer satisfaction.

AdValue Technology

3158 S Chrysler Ave
Tucson, AZ 85713
Phone: 520-514-1100

www.advaluetech.com

AdValue Technology specializes in areas of Alumina, Fused Quartz, Sapphire and Zirconia. Products vary from Crucibles, Tubes & Rods, Plates & Discs, DTA&DSC Sample Pans, Ceramic Membranes to custom components. Laser machining and metallization coating services are available. We also sell high purity powders including Alumina Powders, Quartz Sands, Tellurium Dioxide Powders and Cerium Oxide Polishing Powders. We strive to be your valuable partner in Material Science!



254

Advanced HiVac Application Co.,LTD

NO. 45-2, 11th Neighborhood
Dapuding Zhunan Township
Miaoli Country, 35057 • Taiwan
Phone: 886-37-620170

www.hivac.com.tw/index.php

Vacuum Products - Helium Leak Detector with Air Operated Valves, > 20 Liter/Sec; Helium Pumping Speed with 2nd Turbo pump for Test Objective; Helium Leak Detectors; 990 CLD/DCLD/DCLD2 Upgrade to C15 with signal & I/O converter; Turbo Pump Pumping Station/Cart/System with multi Gauges & Recordable Pressure, Auto on/off, multi-Relay; Dry Surgical suture Cryogenics-Vacuum Water-Free Equipment; CTI Cryogenic Compressor of frequency converter, above 20% Power Saving; Multi gauges and Turbo pump controller to fit most Gauges and TMP pumps.

333

**Agilent Technologies,
Vacuum Products Division**

121 Hartwell Avenue
Lexington, MA 02421
Phone: 781-860-5489

www.agilent.com/chem/vacuum

413

SPONSOR

Agilent Technologies, Vacuum Products Division (formerly Varian) is a world leader providing total vacuum solutions for science and industry for over sixty years. We provide dry vacuum from the ground up, from rough vacuum to UHV, as well as the vacuum measurement instrumentation and leak detection you need to stay up and running. Visit us at Booth 413 to see our new HLD leak detectors, TwisTorr turbos, IDP dry scroll pumps, TPS turbo pumping systems, Vaclon ion pumps and more. Talk to an Agilent representative about our extensive vacuum technology and leak detection training.



Free caricatures in the Speical Events Booth. Get your ticket validated at MKS

AIP Publishing
1305 Walt Whitman Road
Suite 300
Melville, NY 11747
Phone: 516-576-2279

scitation.aip.org/content/aip

AIP Publishing is a wholly owned not-for-profit subsidiary of the American Institute of Physics (AIP). AIP Publishing's mission is to support the charitable, scientific and educational purposes of AIP through scholarly publishing activities in the fields of the physical and related sciences on its own behalf, on behalf of Member Societies of AIP, and on behalf of other publishing partners to help them proactively advance their missions. AIP Publishing's portfolio comprises 19 highly regarded, peer-reviewed journals, including the flagship journals Applied Physics Letters, Journal of Applied Physics, and The Journal of Chemical Physics, in addition to the AIP Conference Proceedings. Stop by booth # 433 to find out what is new at AIP Publishing

Air Liquide Electronics-Balazs NanoAnalysis 455
46409 Landing Parkway
Fremont, CA 94538
Phone: 214-880-22147
www.balazs.com

The world leader in gases, technologies and services for Industry and Health, Air Liquide is present in 80 countries with approximately 65,000 employees and serves more than 3.5 million customers and patients. Oxygen, nitrogen and hydrogen are essential small molecules for life, matter and energy. They embody Air Liquide's scientific territory and have been at the core of the company's activities since its creation in 1902.

AJA International, Inc. 338
P.O. Box 246
North Scituate, MA 02060
Phone: 781-545-7365
www.ajaint.com

Sputtering, E-beam, Ion Milling, and Hybrid Deposition Systems for R&D and Pilot Production. Static and Rotating Magnetron Sputter Sources for HV and UHV, Substrate Holders with Rotation, RF Biasing, Heating, Cooling, and Tilting; Sputter Targets, Microwave, RF and DC Power Supplies, Microwave Components and Plasma Sources, RF Ion/Plasma Sources.

318

SPONSOR

American Institute of Physics

1 Physics Ellipse
College Park, MD 20740
Phone: 301-209-3034
www.aip.org

SPONSOR

The American Institute of Physics, advances, promotes and serves the physical sciences for the benefit of humanity. AIP adds value to your AVS membership through our commitment to the preservation of physics for future generations, the success of physics students, and the promotion of a more scientifically literate society. You probably know that AIP has been sending Physics Today magazine to AVS members since 1976. Come by the booth to learn about free email alerts for AIP resources like employment statistics, the History newsletter, Inside Science, and FYI, the AIP Bulletin of Science Policy News

Amuneal Mfg Corporation
4737 Darrah Street
Philadelphia, PA 19124
Phone: 215-535-3000
www.amuneal.com

Since 1965, Amuneal has been dedicated to designing, engineering and fabricating the highest quality magnetic shielding for a wide array of the most demanding applications. Today, with over 120 employees in over 120,000 square feet we are the largest and most respected provider of magnetic shielding solutions in the country. Our 50-year focus on magnetic shielding theory and design has made us a chosen partner for technology-based businesses looking to enhance the performance of their products. Our team of in-house magnetics experts combines with a cutting edge approach to engineering and fabrication to offer fully developed magnetic shielding strategies from initial concepts through high-volume production.

113



ANCORP
707 SW 19th Avenue
Williston, FL 32696
Phone: 352-528-4100
ancorp.com

Manufacturer of high and ultra-high vacuum components since 1965, ANCOPR offers an extensive line of vacuum flanges, fittings, valves, chambers, and custom fabrications to researchers, OEM's, and industrial users around the world. ANCOPR products are designed to meet or exceed the standards required by our customers, such as those involved with thin film deposition, surface analysis, laser devices, cryogenics and the aerospace industry. ANCOPR has a network of independent sales agents and distributors throughout North America, Europe, and Asia. Visit us at www.ancorp.com.

**ANDERSON DAHLEN -
APPLIED VACUUM DIVISION**
6850 Sunwood Dr NW
Ramsey, MN 55303
Phone: 888-780-4314

www.andersondahlen.com/applied-vacuum-division
4 decades of experience in custom metal fabrication. Our in-house capabilities for metal forming, large capacity machining, and critical welding are ideal for manufacturing chambers and related products for vacuum process equipment. ADI customers represent a wide spectra of vacuum applications: Vacuum Coating & Thin Film Processes Semiconductor Processing Vacuum Furnaces Space Simulation Nuclear & Particle Physics Research Anderson Dahlen's Applied Vacuum Division (AD-AV) specializes in custom chambers, welded assemblies, flanges and precision components for HV / UHV / XHV requirements. AD-AV's products tend to be smaller in scale, and are typically designed for higher vacuum ranges.

324 **Anton Paar USA** **219**

10215 Timber Ridge Dr
Ashland, VA 23005
Phone: 804-550-1051
www.anton-paar.com

Anton Paar is the leader in the development of instruments for surface mechanical properties characterization with over 30 years' experience in both research and industrial fields. Our product line includes: •Nano and micro indentation: For hardness and modulus. Most stable on the market •Revetest, nano and micro scratch: For thin film adhesion, fracture, and deformation. For research and QC applications •Tribometers: High temperature and linear reciprocating options •Calotest: Fast coating thickness measurements

Applied Surface Technologies **424**

15 Hawthorne Drive
New Providence, NJ 07974
Phone: 908-464-6675
www.co2clean.com

The CO₂ Snow Jet Cleaning System will be demonstrated. The cleaning process is simple, removing particles of all sizes (to below 5 nanometers), hydrocarbons, and organic residues from surfaces. This cleaning process works well on many substrates, vacuum parts and components, analytical samples (AFM, XPS), optics, and many other applications. We now have a nozzle for blind threads. The Snow Jet process is, nondestructively, residue-free with no environmental limitations. Bring test samples!

Atlas Technologies **423**

305 Glen Cove Road
Port Townsend, WA 98368
Phone: 360-385-3123
www.atlasuhv.com

Atlas is the world leader in aluminum & titanium vacuum. Most vacuum companies rely solely on stainless steel, a poor material for many applications & particularly for UHV & XHV. Atlas has brought much improvement to the vacuum industry by applying our knowledge of vacuum, materials science & advanced manufacturing to provide aluminum & titanium vacuum vessels, components, dissimilar metal joining, engineering services & turn-key vacuum systems that enable you to achieve better performance.





EXHIBITOR PROFILES



Attocube Systems, Inc.
2020 Stuart Street
Berkeley, CA 94703
Phone: 510-649-9245
www.attocube.com

attocube is the technology leader for ultra precise motion and sensing solutions compatible with extreme environmental conditions such as UHV, magnetic field, radiation exposure, as well as cryogenic to elevated operating temperatures. The portfolio includes linear, goniometric, rotational piezo stages, hexapods, and customized precision positioning solutions, as well as a modular interferometer with a broad range of sensor heads, all working with nanometer accuracy.

AVS - ASK THE EXPERTS
Vacuum Technology Division
www.av.org

Have questions? We have answers! The Vacuum Technology Division is pleased to again host Ask the Experts during the AVS-64 exhibit. We will help you solve issues with vacuum system specifications, troubleshooting, process control, contamination and more!. Ask the Experts is an unbiased, open forum with the resources to discuss and help solve vacuum related issues. Sponsored by SAES Getters and Kimball Physics. Archives and online discussion forum year round at <http://www.av.org/forum.aspx>

AVS ART ZONE & CONTEST
www.av.org

Often members of the AVS community use scientific images to convey information—sometimes these images contain aesthetic qualities that evoke a personal, intellectual, emotional, or spiritual response transforming them into objects of art. The question then is where does the science end and the art begin? Let your fellow colleagues be the judge or your artistic interpretations of science as art. Stop by to cast your vote for your favorite images.

AVS CAREER CENTER
www.av.org

The AVS Professional Leadership Committee will be hosting the AVS Career Center, open to all attendees, at the International Symposium for the purpose of connecting job seekers with potential employers. The goal is to facilitate contact and networking during the Symposium and to assist employers to connect with potential candidates for job openings.

433

AVS E-Mail Pavilion & Charging Station **146**

Visit the AVS Email Pavilion in the Exhibit Hall to check your emails, flights, research companies in the hall.. even print your boarding pass. Our new charging station lounge will help you keep your phone and laptop ready to go all week long!

AVS Exhibitor Technology Sessions **168**

20 minute presentations featuring exhibitor's products/services and/or applications and are featured during the session breaks in the stage area of the exhibit hall. Come learn about the latest technology from the vendors exhibiting at AVS !

AVS Foosball Tournament **465**

Ready for some physical competition? Join the AVS Foosball Tournament sponsored and hosted by Gamma Vacuum. Great prizes and so much fun !! Sign up Tuesday morning to enter the tournament as soon as the show opens.

AVS Future Sites **555**

The AVS future sites booth will show you where the road leads AVS to next year! Stop by, pick up a free gift and find out where next year's venue will be.

AVS Publications **445**

51 Kilmayne Drive Suite 104
Cary, NC 27511

Phone: 919-361-2787

www.av.org

AVS Publications (JVST A, JVST B, Surface Science Spectra and Biointerphases) will feature recent journal highlights and "Meet the Editors"! Come learn about how to get published in the AVS journals and what editors look for in quality publications. AVS Journals published many special issues in 2018. Interesting Special Topic Collections as well exciting new growth plans are lined up for AVS Publications in 2019. JVST B is featuring a Special Topic Collection: Honoring Paul Holloway for Contributions in Luminescent Materials Growth, Synthesis and Characterization in conjunction with this year's special session. Biointerphases is publishing an In-Focus Issue on Women in Biointerface Science, a preview flyer of this issue will be at this special symposium session. See eSpectra demos in the Exhibit Hall. Learn how easy it is to access and evaluate spectroscopic digital data with this easy to use data tool. Learn about other new and exciting AVS publishing products coming your way soon!



EXHIBITOR PROFILES



AVS RAFFLE ZONE

563

Visit the Raffle Zone in the Exhibit Hall for the chance to win AWSOME prizes!! The raffles are sponsored by the AVS Exhibitors so please make sure you visit as many exhibitors as you can. Find your daily raffle tickets in your registration kit and follow the instructions on the ticket !!

AVS SPECIAL EVENTS BOOTH

427

Visit our sponsoring exhibitor, MKS Instruments, to get your ticket validated for a Free Caricature! in the Exhibit Hall. Your ticket is in your registration kit !

AVS STORE

559

Official AVS logo items including polos, graphic tees, the ever popular "No Vacuum" shirt, as well as other merchandise will be available for purchase throughout the week. Learn about the advantages and benefits of AVS membership and find out how to get more involved in AVS events and activities. Educational materials also available.

BellowsTech, LLC

361

1289 N. US Highway 1 Suite #1

Ormond Beach, FL 32174

Phone: 386-615-7530

www.bellowstech.com

BellowsTech ultra high vacuum edge welded bellows are able to withstand high vacuum applications with low leak rates to ensure a hermetic seal. Edge welded metal bellows provide the most flex in one or more directions within the smallest amount of space of any bellows technology on the market by reaching a 90% stroke length, and are flexible in design to accommodate round, oval and rectangular shapes. OD's from 0.358 to 26 inch (9.09 to 660 mm). Lifter bellows can be customized to the size and shape required of new design or retrofit applications. BellowsTech high vacuum bellows can be configured with a variety of end pieces including end plates for welding, CF flanges, KF flanges, ISO flanges as well as custom designs. Our expertise in design, machining capability, material options, proprietary stamping and welding technologies allow us to meet industry specific needs. To learn about edge welded bellows technology and BellowsTech edge welded metal bellows, visit www.bellowstech.com.

BihurCrystal S.L.

261

Paseo Mikeletegi, 83 3^a Planta

Local 7 20009 Donostia San Sebastián, Spain

Phone: 34 943041816

www.bihurcrystal.com

BihurCrystal is a manufacturer of equipment for vacuum deposition and of crystals for surface science. The key products offered include: - ALI-1000, a source for the deposition of large or delicate molecules at room temperature, compatible with UHV conditions - Lurrun-1000, a bench-top thermal evaporation system - Flat and curved single crystals - Topological insulators - Scintillating crystals - Graphene grown on SiC

Brooks Automation

460

15 Elizabeth Drive

Chelmsford, MA 01824

Phone: 978-262-2400

www.brooks.com

Brooks is a leading worldwide provider of automation and cryogenic solutions for multiple markets including semiconductor manufacturing, life sciences, and clean energy. Our technologies, engineering competencies and global service capabilities provide customers speed to market, and ensure high uptime and rapid response, which equate to superior value in their mission-critical controlled environments. Since 1978, we have been a leading partner to the global semiconductor manufacturing market and through product development initiatives and strategic business acquisitions; we have expanded our reach to meet the needs of customers in the life sciences industry, analytical & research markets and clean energy solutions. Brooks is headquartered in Chelmsford, MA, with direct operations in North America, Europe and Asia. For more information, please visit www.brooks.com.

Bruker Nano Surfaces

212

112 Robin Hill Rd

San Barbara, CA 93117

Phone: 952-905-8775

www.bruker.com/nano



Bruker's industry-leading technologies include atomic force microscopes (AFMs), stylus and optical profilers, mechanical testers, and nanoindenters. We have led the expansion of AFM capabilities since the beginning, and our AFMs are the most cited in the world. Featuring proprietary PeakForce Tapping®, our high-resolution AFMs enable new research with unique nanomechanical, electrical, and chemical measurements.



EXHIBITOR PROFILES



Centrotherm Clean Solutions
216-E Mt Hermon Rd. Suite 107
Scotts Valley, CA 95066
Phone: 831-601-3000
www.centrotherm-cs.de/de/

Centrotherm Clean Solutions is a leading global supplier of equipment and technology for the treatment of gaseous, liquid and solid pollutants with the goal to protect the environmental health and safety of others. Customer satisfaction is the most important benchmark for us. We successfully treat the most difficult abatement processes worldwide. With more than 60 years of providing our customers with sustainable exhaust gas solutions, new abatement challenges are a welcome opportunity. From large volume VOC treatment to PoU treatment for Semiconductor, PV, FPD, LED and R&D, we have the perfect solution.

Cosmotec, Inc.
229 Polaris Ave. Suite 3
Mountain View, CA 94043
Phone: 408-428-9741
www.cosmotec.us

THE HIGHEST QUALITY CERAMIC-TO-METAL Over 25 Years of Excellence, Now in Silicon Valley Because cutting corners isn't an option. We, at Cosmotec, design the highest quality feedthroughs available on the market today. Our ceramic-to-metal feedthroughs are 100% He leak tested for UHV applications. Rest assured that our feedthroughs are resistant to: high pressure, destructive chemicals, cryogenic temperatures, and excessive temperatures. Our exceptional feedthroughs are ideal for these conditions as well as for applications that require both hermiticity (vacuum tightness) and electrical insulation.

CryoWorks, Inc.
3309 Grapevine Street
Jurupa Valley, CA 91752
Phone: 951-360-0920
www.cryoworks.net

From a simple flex hose to an entire complex piping system, CryoWorks provides a wide range of new and used products for the storage, distribution and transfer of cryogenic fluids. CryoWorks specializes in "complex" system design, engineering services, project management, repairs, service and turnkey installations.

432 **CS Clean Solutions, Inc.**
26 Commerce Drive 26 Commerce Drive
Danbury, CT 06810
Phone: 203-797-8155
www.cs-clean-usa.com

CS CLEAN SOLUTIONS® is the global leader in dry-bed abatement systems for hazardous gas streams using passive, chemisorption-based technology to treat gas streams to outlet levels below TLV. Using proprietary granulate formulations, the systems operate at ambient temperature to abate toxic, corrosive and pyrophoric chemistries. Fuel gas, high voltage electrical power, water and acid waste neutralization are not required, providing extremely low operating cost with minimal maintenance and downtime compared to other abatement technologies

117 **Delcom Instruments**
1325 Winter St. NE Unit 106
Minneapolis, MN 55413
Phone: 715-262-4466
www.delcominst.com

Delcom Instruments Inc. is the leading manufacturer of noncontact instrumentation for evaluating conductive thin films or glass panels. We produce instrumentation that can measure the sheet resistance of materials for the thin film, glass, flat panel, and other related industries. We offer bench-top and inline instruments with high precision, ease of use, and specialized sensors. We also offer process control and real-time sheet resistance monitoring instrumentation. Many of our instruments are specifically designed for use in vacuum chamber applications.

265 **CS Clean Solutions, Inc.**
26 Commerce Drive 26 Commerce Drive
Danbury, CT 06810
Phone: 203-797-8155
www.cs-clean-usa.com

CS CLEAN SOLUTIONS® is the global leader in dry-bed abatement systems for hazardous gas streams using passive, chemisorption-based technology to treat gas streams to outlet levels below TLV. Using proprietary granulate formulations, the systems operate at ambient temperature to abate toxic, corrosive and pyrophoric chemistries. Fuel gas, high voltage electrical power, water and acid waste neutralization are not required, providing extremely low operating cost with minimal maintenance and downtime compared to other abatement technologies

Delcom Instruments 1325 Winter St. NE Unit 106 Minneapolis, MN 55413 Phone: 715-262-4466 www.delcominst.com	446	Ebara Technologies 51 Main Avenue Sacramento, CA 95838 Phone: 916-920-5451 www.ebaratech.com	452
<p>Delcom Instruments Inc. is the leading manufacturer of noncontact instrumentation for evaluating conductive thin films or glass panels. We produce instrumentation that can measure the sheet resistance of materials for the thin film, glass, flat panel, and other related industries. We offer bench-top and inline instruments with high precision, ease of use, and specialized sensors. We also offer process control and real-time sheet resistance monitoring instrumentation. Many of our instruments are specifically designed for use in vacuum chamber applications.</p>		<p>EBARA Technologies, Inc. is a global innovator/local provider of vacuum pumps and advanced exhaust management solutions for semiconductor, photovoltaic, thin films and R&D. EBARA's products are backed by a superior global service network. EBARA continues to expand its role by bringing to the market: Dry Vacuum Pumps, Turbomolecular Pumps, Point-of-Use Abatement and EBARAClean -Outsourced Parts Cleaning Services.</p>	
Denton Vacuum LLC 1259 N. Church Street Moorestown, NJ 08057 Phone: 856-439-9100 www.dentonvacuum.com	556	Edwards Vacuum 6416 Inducon Drive West Sanborn, NY 14132 Phone: 800-848-9800 www.edwardsvacuum.com	327
<p>Denton Vacuum enables innovation. Denton designs and develops systems that precision-coat aerospace components, advanced optics, medical implants, solar cells, semiconductor devices and much more. Denton's technology portfolio includes thermal evaporation, e-beam evaporation, ion-beam-assisted evaporation, magnetron sputtering (including reactive sputtering), plasma-enhanced-chemical-vapor deposition (PECVD), ion etch and ion-beam-assisted deposition (IBAD). As a leading source for thin-film technology, Denton also provides value-added services and lifetime support that set new industry standards.</p>		<p>Edwards is a world leader in the manufacture and supply of vacuum and abatement solutions serving the most advanced and demanding applications and industries including: research and development, high energy physics, analytical instrumentation, scientific, solar, semiconductor, LED, pharmaceutical and metallurgical sectors. Edwards offers innovative products, first class service, a single source of technological expertise and customized systems.</p>	
Duniway Stockroom Corp. 48501 Milmont Drive Fremont, CA 94538 Phone: 650-969-8811 www.duniway.com	315	EP Laboratories, Inc. 196 Technology Drive Suite A Irvine, CA 92618 Phone: 949-387-6555 www.ep-labs.com	430
<p>Duniway Stockroom specializes in vacuum equipment and supplies; ion pumps and controls; flanges, gaskets, bolts and nuts; vacuum gauges and controls; mechanical pumps and rebuild kits; supplies (oils, greases, hoses, bell jars) diffusion pumps and leak detectors. Equipment rebuilding services and a variety of reconditioned equipment. Free Catalog.</p>		<p>EP Laboratories, Inc. is an independent testing laboratory that specializes in surface mechanical testing at the nano and micro levels. Services include: * nanoindentation for hardness, modulus, creep and fracture toughness * nano scratch testing for adhesion and scratch resistance * coefficient of friction * wear and abrasion * low load "push-pull" testing (tension, compression, flexural etc) * Vickers, Mohs, Shore/Durometer and Rockwell hardness * Indentation fracture toughness EP Laboratories, Inc. is committed to providing confidential, professional and detail-oriented services at competitive prices. With us as your lab service provider, you can expect: * Professional and attentive services. * Precise and reliable results. * Easy to understand, customized reports.</p>	



Extrel
575 Epsilon Drive
Pittsburgh, PA 15238
Phone: 412-967-5738
www.extrel.com

Extrel is the world's leading manufacturer of Research and Process Mass Spectrometers, Residual Gas Analyzers (RGA's), Quadrupole Mass Spectrometry Systems and Components. We have been providing quadrupole mass spectrometry solutions to our Research and Industrial customers for over 45 years. Our instruments are known for their high performance, reliability and flexibility. We offer equipment for Basic Research, QA/QC Laboratories, Process Development and Process Control. Extrel's global customers receive the most comprehensive application, technical and on-site support in the industry.

Ferrovac GmbH
Thurgauerstrasse 72
Zurich 8050 Switzerland
Phone: 41 44 273 16 38
www.ferrovac.com

Swiss UHV Technology since 1996 Since more than two decades, Ferrovac defines the benchmark for magnetically driven UHV manipulators such as wobble-sticks, linear-/rotary feedthroughs and sample transporters. With a vast amount of sample handling accessories, we provide tailored solutions, not just off the shelf products. Tell us what you would like to do and our engineers will figure out the best solution in close collaboration with you. Our range of UHV and cryo-UHV suitcases provide a perfectly controlled environment for your valuable samples and can greatly expand the experimental possibilities of your existing equipment. From simple load lock systems to complex turnkey UHV systems, Ferrovac is a reliable partner for your projects. Ferrovac fully commits to Swiss quality as well as to fast and efficient customer support. . Contact us, you won't regret it...



Grand Prize Raffle -
HP Spectre 2 in 1 Laptop/Tablet with Microsoft Office.
 Find your ticket in your registration kit for your chance to win ! Sponsored by R.D. Mathis

538 **Fischer Technology, Inc.** **360**

750 Marshall Phelps Road
Windsor, CT 06095
Phone: 860-683-0781
www.fischer-technology.com

High demands of today's surfaces and coatings that are engineered to be hard, thin or visco-elastic require correspondingly powerful measurement tools to characterize their Mechanical Behavior. Fischer's Nanoin-dentation and Scratch Testers primary focus has been on reduced measuring time and higher throughput while measuring extremely accurate hardness, modulus, creep, scratch resistance and adhesion of coatings.

463 **Gamma Vacuum**

2915 133rd Street West
Shakopee, MN 55379
Phone: 952-445-4841

SPONSOR

www.gammavacuum.com Specializes in the design, manufacture and distribution of ion and titanium sublimation pumps, serving customers across a diverse range of scientific applications, including R&D and High Energy Physics. Our people are committed to be the foremost source in Ultra High Vacuum knowledge and expertise globally, delivering consistent superior quality, at a low initial and operational cost.

522 **GNB King Lai Group**

3200 Dwight Road Suite 100
Elk Grove, CA 95758

Phone: 916-395-3003 • www.gnbvac.com

GNB King Lai Group has a proven track record of manufacturing high quality, reliable vacuum products since 1968 and is known as America's leading manufacturer of large vacuum valves. In addition, GNB King Lai Group offers a diverse range of vacuum products and services, including: inline chambers, angle valves, ball valves, gate valves, slit valves, pendulum valves, specialty valves, vacuum chambers, pumps, helium leak detectors, heaters, Nanopure products, liquid nitrogen traps, custom flanges and fittings, viewports, bellows, multi-coolant baffles, throttle plates, and many other standard components. Check out our new website at www.gnbvac.com and stop by the booth to find out more. Given our expert group of engineers, GNB King Lai Group can efficiently customize our clients' products. With extensive experience combined with an outstanding reputation for high quality products and customer service, GNB King Lai Group is the valued resource for your next vacuum system.

HeatWave Labs Inc.

195 Aviation Way Suite 100
Watsonville, CA 95076-2069
Phone: 831-722-9081

HeatWave Labs specializes in the vacuum tube and vacuum equipment industries. Our expertise includes thermionic cathodes and ion emitters and guns, Ion Sources and ionizers, Ion pumps and controllers, vacuum tube design, processing, specialized refractory materials, UHV sample heating and filament products, temperature controllers and related products.

Heidelberg Instruments, Inc.
2807 Oregon Court Unit E2
Torrance, CA 90503
Phone: 310-212-5071
www.himt.de

Heidelberg Instruments is a world leader in the production of high precision photolithography systems and maskless aligners. We have more than thirty years of experience in maskless photolithography and are proud of our ever-expanding installation base of over 850 systems in more than 50 countries. Heidelberg Instruments systems are installed in academic and industrial sites and are used in research, development and production. Applications include MEMS, Bio-MEMS, Nanotechnology, ASICS, TFT, Micro Optics and others.

Helium Leak Testing, Inc.
3910 Royal Ave Suite A
Simi Valley, CA 93063
Phone: 818-349-5690
www.heliumleaktesting.com

Helium Leak Testing, Inc. provides equipment sales and services nationally to multiple industries that require leak detection, test fixtures, production testing, leak standards, vacuum gauge calibration, vacuum pump, and leak detector maintenance. HLT designs, builds and installs commercial and customer leak detection systems for applications in aerospace, automotive, military, medical, food packaging, semiconductors, and power generation. Qualified test inspectors are certified according to guidelines embodied in ASNT-TC-1A, NDT, ASME, and NIST.

350

Hidden Analytical, Inc.

37699 Schoolcraft Road
Livonia, MI 48150
Phone: 734-542-6666
www.hidenanalytical.com

SPONSOR

345

Hidden Analytical manufactures an extensive range of high performance quadrupole mass spectrometers for plasma characterization studies, surface science applications, precision gas analysis and vacuum diagnostics. Introducing the Hidden Compact SIMS; designed for fast and easy characterization of layer structures, surface contamination and impurities with sensitive detection of positive ions being assisted by an oxygen primary ion beam and providing isotopic sensitivity across the entire periodic table. The ion gun geometry is optimized to be ideal for nano-meter depth resolution and near surface analysis. Showcasing the QGA, our fast response, capillary inlet system for process gas analysis, bio-gas and fermentation monitoring, catalysis studies, TGA and reaction kinetics. Hidden Analytical extends the pressure range for plasma monitoring with our HPR60-EQP Atmospheric Plasma Monitor. The HPR60-EQP is configured specifically for measurement of atmospheric and near-atmospheric plasma.

Hine Automation

12495 34th St N STE B
St. Petersburg, FL 33716
Phone: 813-749-7519
www.hineautomation.com

464

What does Hine Automation do? Hine Automation designs and manufactures cost effective, customized automation solutions in vacuum and atmospheric robotics. We serve the Original Equipment Manufacturers (OEMs) in the semiconductor, solar, flat panel display and related industries around the world where cost of ownership is an important factor. The quality and reliability of our robotic components satisfy a wide range of needs; from the most flexible research and development facility to the most stringent manufacturing environment. We service, refurbish and repair robotics for legacy systems, providing an economical alternative for those who are not quite ready to upgrade their systems. Hine provides what YOU need to move YOUR technology. For further information, please contact us at sales@hineautomation.com.



EXHIBITOR PROFILES



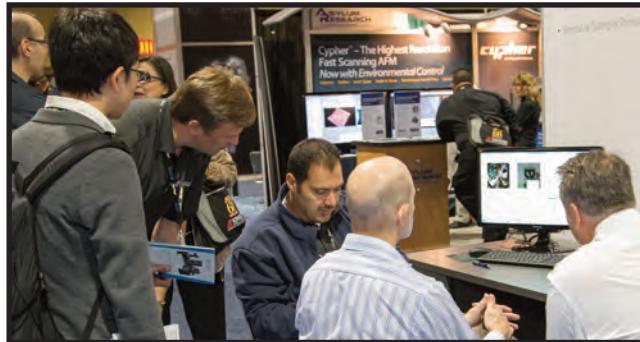
HORIBA 430 Indio Way Sunnyvale, CA 94085 Phone: 512-965-3553 www.horiba.com/en_en/ Manufactures and sells automotive emission measurement systems, environmental measuring instruments, wide range of scientific analyzers, and medical diagnostic analyzers, and measuring equipment used in the semi-conductor industry. HORIBA also manufactures and markets peripheral measuring and analysis devices. Moreover, the Company equips such facilities as laboratories with measuring and analytical equipment for R&D, production, and other applications.	137	INFICON Two Technology Place East Syracuse, NY 13057-9714 Phone: 315-434-1100 www.inficon.com INFICON offers a wide range of vacuum gauge measurement technologies spanning over 15 decades of vacuum pressure measurement, enabling users in a variety of vacuum applications to reliably monitor gas pressures during manufacturing or research processes. As manufacturing technologies advance and quality standards change, the need to understand your process and maintain product quality is more important than ever. Transpector MPS helps optimize your process by monitoring process conditions, detecting contaminants, and checking for leaks.	422
HS-Group GmbH Porschestraße 12 Hainburg, Hessen 93510 Germany Phone: 49 6182 93510 www.hs-group-gmbh.de The HS-Group specializes in supplying the vacuum and thin-film industry with high-quality components, services and complete vacuum systems. Our ability to integrate your special wishes and requirements, the high-quality of our products and our many years of expertise in this field will ensure you the best solution for your problem	250	InRedox LLC 1840 Skyway Drive Unit F Longmont, CO 80504 Phone: 720-294-9105 www.inredox.com InRedox develops and manufactures products from nanoporous Anodic Aluminum Oxide (AAO) and nanotubular Anodic Titanium Oxide (ATO) – unique self-organized materials resembling nanoscale honeycombs. Our exhibit will a selection of AAO and ATO materials (membranes, templates, films) and accessories designed to facilitate discoveries and speed-up product and/or process development. Of special interest to AVS attendees are nanoporous reference substrates for development of Atomic Layer Deposition on high aspect ratio, high surface area substrates.	417
HVA, LLC 12880 Moya Blvd. Reno, NV 89506 Phone: 775-359-4442 www.highvac.com HVA is the premier manufacturer and supplier of high and ultra high vacuum valves to the world's leading vacuum technology innovators. Our world class manufacturing facility in Nevada, USA supports our global sales and service network for the semiconductor, solar, scientific research, BioPharm, vacuum coating, and LED industries. We can offer you the perfect valve for your application at the best price. High Quality Precision Stainless Steel and Aluminum Vacuum Valves/Components, Gate Valves, Rectangular Valves MESC, Angle/Inline Valves, Custom Components, Low Particulate Valves, Large Rectangular Valves, Solar/FPD Valves, Harsh Process Valves, 3-Position Valves, Integrated Solutions and Valves with a Lock-out/Tagout (LOTO) option.	416	Instrument Technology Research Center, NARLabs 20 R&D Rd. VI, Hsinchu Hsinchu 30076 Taiwan Phone: 886-3-5779911 www.itrc.narl.org.tw/index-e.php Since its establishment in 1974, Instrument Technology Research Center (ITRC) has been known as a pioneer in vacuum and optics technology and is now dedicated to the development of frontier instrument technology platforms for fulfilling the goals of national technology policy and the requirements for industrial economic growth. With a sophisticated service platform for advanced instrument applications, ITRC aims to bridge the academia and industry, providing innovative engineering, prototyping, and customization. ITRC is constantly pursuing the ideal of "Local Impact, Global Excellence."	414

Instrutech, Inc.
1475 South Fordham Street
Longmont, CO 80503
Phone: 303-651-0551-105
www.instrutechinc.com

InstruTech's vacuum gauges utilize the most recent advances in vacuum gauge designs offering measurement capabilities from 2.00E-11 Torr to 1,000 Torr. Our product portfolio of vacuum gauges and vacuum gauge controllers includes convection enhanced pirani, hot cathode Bayard-Alpert ionization, cold cathode ionization, capacitance diaphragm gauges and vacuum switches. InstruTech's vacuum measurement products are offered with built-in or rack mount controllers with displays.

Intel Corporation
3100 NE Shute Rd. MS: RS5-103
Hillsboro, OR 97124
Phone: 503-613-1956
www.intel.com/jobs

At Intel, our vision is to create a continuum of computing experiences, which means endless opportunities with global impact for you. As an intern or recent college graduate, you will have access to unmatched manufacturing, technology, expertise and brand strength to make your mark on the exciting world of computing. Join our culture of innovation and exploration and enjoy the many perks we have to offer, all while delivering pioneering advances in hardware, software, education, energy and everything else our technology impacts. We are Intel. Sponsors of Tomorrow.



354

ION-TOF USA
100 Red School House Road
Building A8
Chestnut Ridge, NY 10977
Phone: 845-352-8082
www.iontof.com

SPONSOR

222

ION-TOF is the leading European manufacturer of Time-of-Flight Secondary Ion Mass Spectrometers (TOF-SIMS). Our TOF.SIMS 5, the most successful TOF-SIMS instrument ever, provides detailed elemental and molecular information about surfaces, thin layers, and interfaces, with full 3D characterization. It's unique design guarantees optimum performance in all fields of SIMS applications. Utilizing our Argon Gas Cluster Ion Beam 3D characterization of organic materials is now possible. Recent developments include in-situ AFM for true 3D analyses and our hybrid SIMS system that offers mass resolutions over 200,000 and full MS/MS capability. Our Qtac100 is a high sensitivity Low Energy Ion Scattering system for true atomic layer characterization. For the ultimate resolution in Magnetic Force Microscopy check out our range of NanoScan products.

J.A. Woollam Co., Inc.
645 M Street Suite 102
Lincoln, NE 68508
Phone: 402-477-7501
www.jawoollam.com

3 32

For all of your ellipsometry needs, from measuring your thin film sample to installing and training of your very own ellipsometer, the J.A. Woollam Company is here for you every step of the way. We provide a wide variety of ellipsometers to help you characterize your thin films, covering spectral ranges from vacuum ultra-violet to far infrared, along with over 25 years of personal support. To learn more about our variety of ellipsometers and unmatched personal support contact us today at sales@jawoollam.com or visiting us on the web at www.jawoollam.com.



Kashiyama-USA Inc.
41432 Christy Street
Fremont, CA 94538
Phone: 510-979-0070
www.kashiyama.com

The Dry Screw Pump innovator provides tough, durable and reliable vacuum pumps for the semiconductor, FPD and solar panel manufacturing market. Over 150,000 sq. ft. facility & 550 employees are ISO9001-2000 & 14001 certified to ensure quality and reliability. We are specialized in harsh process where corrosive gases and/or heavy particles present, in large volume, high speed vacuuming process and high vacuum stage process in which the pumps minimize down time, energy and space efficiently. Kashiyama has dominated many years in the dry vacuum pump market.

Kaufman & Robinson, Inc.
1330 Blue Spruce Drive
Fort Collins, CO 80524
Phone: 970-495-0187
www.ionsources.com

KRI can assist you with your film depositions, etching processes, and material modifications. We manufacture a wide range of ion/plasma sources, electron neutralizers and power supply controllers. KRI's product technology includes high current gridless plasma sources, filamentless RFICP gridded sources, low energy electron sources and automated power supply controllers. Over 40 years of experience, makes us the source you can trust.

Kimball Physics Inc.
311 Kimball Hill Road
Wilton, NH 03086
Phone: 603-878-1616
www.kimballphysics.com

Compact, modular UHV/HV vacuum chambers and fittings designed for ease of access with internal/external mounting facilitators (Groove Grabbers, eV parts) enabling experimental setups with off-the-shelf components. Electron and ion guns with high-performance cathodes producing small spots to flood beams. Matching power supplies of 1 eV to 100 keV. Featuring modular optics, compact fiber-optic control, LabView, USB RS-232/422, energy sweeping, rastering, pulsing, feedback stabilization.

235

Kratos Analytical, Inc.
100 Red School House Road
Building A
Chestnut Ridge, NY 10977
Phone: 845-426-6700
www.kratos.com

227

SPONSOR

Kratos Analytical, a wholly owned subsidiary of Shimadzu Corporation, proudly exhibits & demonstrates our leading X-ray Photoelectron Spectroscopy (XPS) systems. We offer a full range of XPS solutions, from high end, multi-technique research systems combining XPS with additional surface analytical techniques to simple, high-throughput systems. Our latest Ar Gas Cluster Ion Source now gives users the ability to sputter depth profile organic systems whilst retaining chemical information.

112

Kurdex Corporation
343 Gibraltar Drive
Sunnyvale, CA 94089
Phone: 408-734-8181
www.kurdex.com

336

Supplier of Vacuum Deposition and Etch Systems for High Volume Production, R&D, and Pilot. Products include PVD, EVAP, PECVD, ALD, Arc Vacuum Deposition and Etch/Strip Tools. Available in In-Line, Cluster with Full Automation for any substrate size upto 2300MM. Supplying Equipment to Solar Cell, Semiconductor (Packaging), FPD, HDI, Hard Disc, Automotive, Thin Film Battery, OLED, and Lighting. Turn Key Automation. Discrete Pieces and Roll to Roll. Equipment is available in Standard and Custom Configurations. Kurdex Applications Lab with Deposition and Metrology Systems is available for Technology Development, Proof of Concept and Coating Services.

223

SPONSOR

Kurt J. Lesker Company
1925 Route 51
Jefferson Hills, PA 15025-3681
Phone: 412-387-9200
www.lesker.com

209

SPONSOR

The Kurt J. Lesker Company® (KJLC®) is a global manufacturer and distributor of vacuum components and systems for the high- and ultra-high vacuum equipment market. KJLC operates world-class manufacturing and logistics facilities from six global offices, providing you with quick access to high quality vacuum products and systems that include: vacuum hardware and components, pumps and oils, custom manufactured vacuum chambers, vacuum and thin film deposition systems, and thin film deposition materials.

Kyungwon Tech Co., Ltd. 457
Rm505, Amigo Tower
Yatap-ro 81 beon-gil 10 Bundang
Seongnam, Gyeonggi, Korea, Gyeonggi 463-828
Korea (South)
Phone: 82-31-706-2886
www.kw-tech.co.kr

Since Kyungwon Tech was established in 1998, we have been providing comprehensive consulting services in the field of computational fluid analysis and plasma processing. We have developed our engineering software K-SPEED (3D feature profile simulator for plasma process).

LAWRENCE LIVERMORE NATIONAL LABS 139
7000 East Ave
Livermore, CA 94566
Phone: 925-422-7511
careers.llnl.gov

Recruiting for various positions available within LLNL.

Leybold USA Inc. 225
5700 Mellon Road
Export, PA 15632
Phone: 724-327-5700
www.leybold.com

Leybold is an ISO 9001 certified manufacturer of vacuum pumps, pumping systems, coating systems, leak detectors and related products for use in rough, medium, high and ultra-high vacuum applications in the Analytical, Industrial and R&D sectors. Our vacuum technologies and services include oil sealed rotary vane pumps, dry compressing and oil-free pumps, boosters, turbo-molecular pumps, diffusion and cryogenic vacuum pumps, thin-film deposition systems as well as repair & remanufacturing of all brands of vacuum pumps.



MANTIS-SIGMA
10200 E. Girard Ave.
Bldg. A, Ste. 300
Denver, CO 80231
Phone: 720-833-7730
www.mantisdeposition.com



109

MANTIS Deposition and our partner SIGMA Surface Science are dedicated to the development and manufacture of high-quality systems and components for cutting-edge applications in nanotechnology, thin film deposition, and surface analysis. We enable researchers to both create and analyze the latest materials for advanced materials and device development. MANTIS specializes in nanoparticle deposition, UHV sputtering, e-beam, MBE, and PLD. We offer a range of nanoparticle technology, RF atom and ion sources, sputter cathodes with optional in-situ tilt, mini e-beam evaporators, and organic evaporators as well as modular R&D deposition systems that can be customized for your application. Our highly skilled team of physicists, engineers, and designers will be happy to work with you on your next materials deposition and analysis challenges.

Matheson Tri-Gas, Inc. 428
150 Allen Road Suite 302
Basking Ridge, NJ 07920
Phone: 908-991-9340
www.mathesongas.com

MATHESON, as part of the TNSC Group, is uniquely qualified to provide end-to-end solutions for the MOCVD industry. TNSC's world class MOCVD equipment systems are at the heart of the MOCVD solution, and MATHESON combines technology support and supply from TNSC with its own competencies in materials, equipment, and site service to provide comprehensive offerings for specialized customer requirements. Offerings include systems engineering, installation services, materials and gases, all applicable gas handling equipment, analysis and monitoring systems, specialized Cl₂ dry cleaning system, purification and exhaust gas abatement solutions. Consequently, the TNSC Group has delivered a large quantity of MOCVD equipment worldwide for numerous applications, ranging from R&D to large systems for mass production. This unique position allows MATHESON to team effectively with customers to help optimize processes and materials, providing safe, low cost solutions with minimized environmental impact.

McAllister Technical Services, Inc.
1124 E Sherman Avenue
Coeur d'Alene, ID 83814
Phone: 208-772-9527
www.mcallister.com

McAllister Technical Services was founded in Berkeley, California in 1981. The move to beautiful Coeur d'Alene, Idaho in 1990 has kept us rooted in our core values and we continue to provide the scientific community with top quality, innovative scientific equipment, and custom devices at an affordable price. Our specialty is providing one-on-one contact and collaborations between end users and our top engineering team to design and manufacture UHV devices and systems. We take pride in our ability to create solutions for our customers' engineering and design needs. McAllister will maintain our commitment and ability to customize equipment in a way most manufacturers are not able to do. Browse our key UHV products like multi-axis manipulators, heated/cooled sample stages, and much more at www.mcallister.com

MDC Vacuum Products, LLC
30962 Santana Street
Hayward, CA 94544
Phone: 510-305-3504
www.mdcvacuum.com

MDC Vacuum Products, LLC an ISO 9001:2008 registered company, was founded in 1975 to serve a rapidly expanding vacuum industry and to satisfy the increasing demand for high quality vacuum components with fast delivery and reasonable prices. MDC now consists of three unique product divisions which include MDC Vacuum Products, Insulator Seal Inc. (ISI™), and MDC Gas Delivery Products. Our customer base is as varied as our product offering. Some of MDC's customers include national laboratories, colleges and universities, original equipment manufacturers, and domestic as well as international commercial accounts. We stock thousands of off-the-shelf vacuum components as well as custom components. From the simplest of airtight seals to complex ultra-high vacuum chambers for surface science analysis, MDC's product line provides a comprehensive solution to the world's scientific and industrial markets. Let MDC drive your vacuum, ceramic seal, and gas delivery processes forward!

134

MeiVac, Inc.

5830 Hellyer Avenue
San Jose, CA 95138-1004
Phone: 408-362-1000
www.meivac.com

127

We offer a full line of thin film deposition components, including e-Vap(R) e-beam evaporation sources, MAK sputter sources, power supplies, controllers and accessories. These coupled with our VQ throttle valves and high temperature substrate heaters provide a strong tool set to develop a variety thin film deposition applications.

Micro Photonics

1550 Pond Rd Suite 110
Allentown, PA 18104
Phone: 610-366-7103
www.microphtonics.com

337

Micro Photonics offers the latest Thermal CVD systems for Graphene & 2D materials from Graphene Square, along with HV and UHV systems / components from Oxford Applied Research, such as RF atom source, ion sources, leak valves, thermal gas crackers, nanocluster systems, e-beam, and etching systems. Micro Photonics is instrumental to your success, supplying high-quality instruments to fit your scientific and budgetary needs!



512

MKS Instruments

2 Tech Drive Suite 201
Andover, MA 01810
Phone: 978-645-5500
www.mksinst.com

215



MKS Instruments, Inc. the worldwide leader in vacuum and control solutions for the environmental monitoring, defense & security, life sciences & research, process & industrial manufacturing and thin film industries. Newport leads the world in sophisticated light & motion solutions for highly demanding industrial & research customers. By bringing the two companies together, we will enable our customers to bring new solutions to market faster and more predictably.

MODION®
115 Railroad Street
Irwin, PA 15642
Phone: 724-523-9610
www.modionvacuum.com

Innovative manufacturing solutions since 1941. We manufacture commercial and custom MODION® ion pumps, power supplies, and TVC thermal vacuum chambers. In addition to our vacuum product lines, JBA is a full service manufacturing and design company, producing machined and welded parts, as well as mechanical assemblies to customer specification.

Neaspec GmbH 433
Bunsenstrasse 5
Martinsried, Bavaria
Germany
Phone: 00498945242060
www.neaspec.com

See the nanoworld: Neaspec introduces the new nanoFTIR imaging and spectroscopy tool, with a wavelength-independent spatial resolution of 10 nm throughout the VIS and IR spectrum. This cutting edge technology allows you to gain new insights into your samples by e.g. plasmon interference mapping, chemical nano-identification, electron mobility mapping, or many more amazing phenomena.

NIST 544
100 Bureau Drive MS6201 Bldg. 216/Rm. A157
Gaithersburg, MD 20899
Phone: 301-975-2096
www.nist.gov/cnst

The NIST Center for Nanoscale Science and Technology (CNST) supports the U.S. nanotechnology enterprise from discovery to production by providing industry, academia, NIST, and other government agencies with access to world-class nanoscale measurement and fabrication methods and technology. The CNST's shared-use NanoFab gives researchers economical access to and training on a state-of-the-art tool set required for cutting-edge nanotechnology development. The simple application process is designed to get projects started in a few weeks. Looking beyond the current state of the art, CNST research is creating the next generation of nanoscale measurement instruments and methods, which are made available through collaboration. Contact Vince Luciani, vincent.luciani@nist.gov.

248 **Nonsequitur Technologies**
20664 Carmen Loop #3
Bend, OR 97702
Phone: 541-312-2410
www.nonsequitur-tech.com

Specializes in the development, design and manufacture of electron and ion sources for a range of applications: Sample cleaning and depth profiling ion guns for surface analysis instruments; Primary focused ion sources for SIMS; High resolution focused ion columns for micromachining applications; Low energy ion sources for surface charge stabilization and sample cleaning. Standard products include ion sources and focusing columns with energies to 50kV. Higher energies are available on a custom basis. New products include a 30kV gas ion column with submicron resolution and a 160kV Proton source.

Nor-Cal Products, Inc. 438
1967 South Oregon Street
Yreka, CA 96097
Phone: 530-842-4457
www.n-c.com

Our custom design and manufacturing capabilities are complemented by over 6000 competitively-priced standard components. Innovative engineers, master welders and master machinists. Precision welding and fabrication. In-house electropolish and chem clean. Quality assurance with on-site CMM, XRF and RGA analysis. Class 1000 clean room assembly and packaging. Complete system and sub-assembly Integration. ISO 9001-2015 and ASME U Stamp certified. 3D Models on-line. Prototype and production quantities. Exceptional global sales, service and technical support teams.

Omley Industries, Inc. 454
150 Corporate Way
Grants Pass, OR 97526
Phone: 541-955-9415
www.omley.com

Omley Industries specializes in a wide variety of vacuum brazed components including specialty hermetic feedthroughs and stand-offs; sapphire, diamond and beryllium windows; optical and infrared probes. Omley focuses exclusively on prototype and OEM production vacuum brazing. We braze specifically for your designs and applications. Limited quantities are no problem.

Osaka Vacuum USA, Inc.
48000 Fremont Blvd.
Fremont, CA 94538
Phone: 510-770-0100
www.osakavacuum.co.jp/en

Osaka Vacuum is a proven one-stop shop for all your vacuum process applications ranging from Solar Cells, Storage/Semiconductor, Microscopy/Metrology, general vacuum to vacuum instrumentation. Osaka Turbopump/Dry Pump offerings: 1) Introducing Osaka newest TGkine Maglev Turbopump series featuring on-board controller designed for the standard vacuum pumping to the very harsh heavy duty vacuum processes <1650-2200-3300-4200 L/S> 2) Digital Maglev Compound Turbopumps, high speed/throughput, free orientation <340-400-900-1300-2400 L/S> 3) TG-F series: Affordable wide range turbopumps <220-350-450-800-1100-2400 L/S> 4) TG/TS series: High throughout, rugged industrial version <200-440-550-1000-1300-1800-3400-5500 L/S> 5) Analytical series: High performance turbopump <60-70-240 L/S> 6) Small Footprint/Energy Saving Dry Pumps for general vacuum <8-18 CFM> 7) Energy Saving Light Duty Dry Pumps: FR060D & ER100D series offering fast pump-down from Atmosphere to base offering reduced footprint and Energy/Utility Saving for standard to Light Duty processes <36 - 59 CFM>

Park Systems, Inc.
3040 Olcott Street
Santa Clara, CA 95054
Phone: 408-986-1110

parksystems.com

Park Systems is a world leading manufacturer of atomic force microscopy (AFM) systems, with a complete range of products for researchers and industry engineers in the biological science, materials research, semiconductor, and storage industries. Park's AFM provides the highest data accuracy, superior productivity, and the lowest operating cost. See our Park NX10 and Park NX20, the premier choices for nanotechnology research, at <http://www.parksystems.com>.



257 Pfeiffer Vacuum Technology, Inc.

24 Trafalgar Square
Nashua, NH 03063
Phone: 603-578-6500
www.pfeiffer-vacuum.com

For over 125 years, Pfeiffer Vacuum has set the standard of excellence in vacuum technology. We are happy to announce the addition of Nor-Cal Products, a leader in vacuum hardware, valves and chambers to the Pfeiffer Vacuum Group. We are now a true solution provider, offering customers everything they need to create, enable and measure vacuum. Products include: turbomolecular, fore vacuum, and Roots pumps, turbopump stations, residual gas analyzers, helium leak detectors, gauging and custom vacuum chambers and vacuum hardware.

PHPK Technologies

2111 Builders Place
Columbus, OH 43204
Phone: 614-486-4750
www.phpk.com

SPONSOR

CVI Torr Master® cryopumps meet today's need for fast, contamination-free, ultra-high vacuum at competitive costs. Benefits include higher capacities for gas cryoabsorption, increased pumping speeds, acceptance of higher radiant heat loads and shorter cooldown and regeneration times. The Torr Master line is used in fields such as vacuum coating, semiconductor production, particle accelerators, sputter deposition systems and Molecular Beam Epitaxy.

Physical Electronics

18725 Lake Drive East
Chanhassen, MN 55317
Phone: 952-828-6100
www.phi.com

SPONSOR

Physical Electronics is a subsidiary of ULVAC-PHI the world's largest supplier of surface chemical analysis instrumentation. To learn about the latest innovations in our XPS, AES, and TOF-SIMS instruments, use the "AVS Program Guide Search Tool" at www.av.org to view the times and locations of the many technical talks being presented or co-authored by Physical Electronics staff. We hope you plan to attend! Please visit us at Booth #101 in the Exhibition Hall or on the web at www.phi.com.



EXHIBITOR PROFILES



Physics Today
One Physics Ellipse
College Park, MD 20740
Phone: 301-209-3003
www.physicstoday.org

Tomorrow's vacuum and solar innovations start with the 120,000 researchers who read Physics Today magazine. Records show that more than 56,000 Physics Today readers buy vacuum & cryogenic systems in a year. Each of their labs spends more than \$156,000 per year on this equipment. When you visit the exhibitor lounge for a refreshing drink or snack, consider sharing with readers the offerings of your company by advertising in Physics Today. We look forward to seeing you!

Picosun USA, LLC
1651 N. Collins Blvd. Suite 224
Richardson, TX 75080
Phone: 214-790-0844
www.picosun.com

Picosun is a leading ALD (Atomic Layer Deposition) technology provider for microelectronics and other industries. PICOSUN™ product portfolio ranges from fully automated, SEMI compatible 300 mm industrial ALD systems to smaller scale research and pre-pilot tools, with special dedication in cost-efficient, turn-key production solutions for up to 200 mm wafer markets. Picosun offers you the best-in-class thin film technology for conventional IC, compound and power semiconductors, LEDs, MEMS, sensors, and 3D components, with the leading process quality, agile and innovative equipment design, and the most comprehensive after-sales support and services. For more information please visit www.picosun.com!

Plasma Process Group, Inc.
7330 Greendale Road
Windsor, CO 80550
Phone: 970-663-6988
www.plasmaprocessgroup.com

Plasma Process Group manufactures the top quality ion beam equipment in the industry. From RF and DC Ion Sources to Power Supplies to complete IBS Systems, PPG has the products your process requires. Our customer service and technical support are second to none, with real people answering your phone calls and e-mails as they arrive. Contact us today to configure your next Ion Source, replace your old power supplies, optimize your process with a new grid set, or expand your coating capabilities!



156 **Precision Plus Vacuum Parts** **453**

6416 Inducon Drive W
Sanborn, NY 14132
Phone: 716-297-2039
www.precisionplus.com

Precision Plus is the recognized leader in providing high-quality, low-cost vacuum pump replacement parts. Over 50,000 stocked parts, including oil, filters, rotors, shafts, plates, fittings, repair kits and more for 650+ OEM models. Alcatel, Becker, Busch, Ebara, Edwards, Fisher Scientific, Galileo, Kinney, Leybold, Pfeiffer, Precision Scientific, Rietschle, Stokes, Ulvac, Varian & Welch. Right Parts. Right Price. Right Now. Contact us at info@precisionplus.com or visit us online at www.precisionplus.com for schematics, msds, technical support and more!

335

Prevac sp. z o.o. **319**
Raciborska 61
Rogow, 44362
Poland
Phone: 48-32-459-2000
www.prevac.eu/

PREVAC is a world leading manufacturer of deposition and analysis systems based on vacuum technology dedicated for the investigation of chemical and physical properties of solid state surfaces, thin films and nano-materials. The company designs, manufactures and delivers complete research systems and components, electronic devices and software dedicated to handling PREVAC's products as well as other manufacturers. The company is very well known of custom solutions.

426

QEI Corporation **437**
603 Airport Dr P.O. Box 805
Williamstown, NJ 08094
Phone: 856-728-2020
www.qei-rf.com

Founded in 1971, QEI Corporation innovates, designs, and manufactures radio frequency (RF) industrial power systems used in the Semiconductor, Scientific, Industrial, Laser and Broadcast industries. With QEI's combined technology offering of hybrid based and solid-state systems, QEI has the widest product offering in the RF amplifier industry. QEI, in many cases, offers the only solution to the technological challenges faced by its customers.



EXHIBITOR PROFILES



R.D. Mathis Company
2840 Gundry Avenue
Signal Hill, CA 90755
Phone: 562-426-7049
www.rdmathis.com

The R. D. Mathis Company specializes in the manufacture of Hi-Vacuum evaporation sources and materials and continues to support the thin film coating and metalizing industries as we have since 1963. We offer a comprehensive selection of tungsten, molybdenum and tantalum sources through our catalog as well as custom and modified fabrication to meet your specific coating needs. We offer a full selection of high purity materials such as gold, silver, nickel, titanium, SiO, chromium, etc. On display will be a wide variety of sources, our "LV Series" Low Voltage High Current Power Supplies and our "GP 100" Inert Gas Purifier to compliment your evaporation process. Stop by our booth, visit our website, or call for more information and a copy of a catalog. Ordering online is fast and easy at www.rdmathis.com. As always, we offer free technical support to help you choose the right source for your specific applications. We are ISO9001 and AS9100 certified

RASIRC
7815 Silverton Ave
San Diego, CA 92126
Phone: 858-792-1881
www.rasirc.com

RASIRC offers a line of products designed to deliver high concentration hydrogen peroxide (H₂O₂) gas to semiconductor manufacturing processes. H₂O₂ is well known for its superior oxidizing capabilities. Now H₂O₂ is available in high concentration, with or without water and even without carrier gas. H₂O₂ gas is ideal for next generation materials and 3D architectures that are temperature and water sensitive. The Peroxidizer delivers up to 5% H₂O₂ gas by volume from 30% H₂O₂ liquid solution. BRUTE Peroxide delivers anhydrous H₂O₂ gas for water sensitive processes such as ALD involving new materials and 3D architectures. RASIRC specializes in products that generate & deliver gas to fabrication processes. Each unit is a dynamic gas plant in a box—converting common liquid chemistries into safe & reliable gas flow for most processes. First to generate ultra-high purity steam from de-ionized water, RASIRC technology now delivers hydrogen peroxide gas in controlled, repeatable concentrations.



216

RBD Instruments, Inc.
2437 NE Twin Knolls Dr. Suite 2
Bend, OR 97701
Phone: 541-550-5011
www.rbdinstruments.com



322

RBD Instruments has been advancing materials science with innovative products and exceptional services for over 28 years by providing: Compact, high-performance Auger electron spectrometers Low cost, high-performance sputter ion source packages Water vapor desorption products for faster pump-down Ion and electron current measurement and data logging USB picoammeters Repair, maintenance, software and sales of selected Physical Electronics XPS and AES surface analysis systems and components - visit our blog for tons of free PHI maintenance info at <http://www.rbdinstruments.com/blog/> We also provide refurbished PHI X-ray Photo-electron Spectrometers that include installation, training and a one year warranty. High Flux UV sources High temp IR in-situ sample heaters

Refining Systems
1985 Whitney Mesa Drive
Henderson, NV 89014
Phone: 702-368-0579
www.refiningsystems.com

234

Manufacturer of sputtering targets and evaporation materials both in pure or alloyed form in different dimensions. All products are manufactured to client specifications.

RF VII Inc.
104 Church Street
Newfield, NJ 08344
Phone: 856-875-2121
www.rfvii.com



356

RF VII Inc. manufactures quality RF equipment for use in Semiconductor, Analytical, Medical, Induction Heating, and Coating processes. We manufacture RF Generators and Auto-Tuners with power levels from 100 - 6000 watts with frequency bands from 1 - 40 MHz. All our RF Generators are lightweight and Air Cooled! We offer repair on many different brands of existing RF Equipment with fast turnaround for our production environment customers. Our commitment is to the customer and their requirements in RF related concerns. Offering phone and on-site assistance for RF service, coupling and control for all RF source processes. We offer a full range of RF equipment parts including new power tubes for older RF generators.

RHK Technology Inc.
1050 East Maple Road
Troy, MI 48083
Phone: 248-577-5426
www.rhk-tech.com

RHK - See what you have been missing: Your partner in nanoscale research to explore with confidence and make discoveries that will keep your laboratory first in science. Choose RHK for your application needs: Pan-Scan Freedom LT SPM, Beetle VT SPM, and QuadraProbe SPM. Award winning PanScan Freedom, the world's first cryogen-free UHV system for stable low-temperature performance and exceptional results in a surprisingly compact package. RHK's revolutionary R9plus, a single box AFM-STM ultra-performance Controller, is engineered for the most advanced applications yet easily operated by new users. Keeping your laboratory first in nanoscale science.

SAES Group
1122 East Cheyenne Mountain Blvd
Colorado Springs, CO 80906
Phone: 719-576-3200
www.saesgetters.com

SAES CapaciTorr and NEXTorr pumps continue to be the benchmark in compact and powerful UHV/XHV pumps. The recently developed ZAO alloy has allowed for extending the operational pressure of NEG's to higher pressures with CapaciTorr HV and NexTorr HV pumps as well as for developing the CapaciTorr Z and NexTorr Z pumps that deliver 50 % more pumping speed in the same package as the existing CapaciTorr and NexTorr pumps. The ZAO based pumps also exhibit an even better mechanical stability, allowing them to be used in the cleanest applications without a risk of particulation.

120

ScientaOmicron, Inc.
240 St. Paul Street Suite 301
Denver, CO 80206
Phone: 720-350-5000
www.scientaomicron.com

326

Scienta Omicron is the world's premier supplier of Photoelectron Spectrometers for ARPES, Ambient Pressure XPS, Scanning Probe Microscopy and MBE thin film systems to the scientific community and R&D labs. The Laser ARPES Lab featuring the patented DA 30 spectrometer has emerged as the most powerful tool to map spin resolved electronic band structure and Fermi surfaces. The HiPP-3 Ambient Pressure XPS System provides chemical analysis in up to 30mbar of pressure with 10 micron spatial resolution. Our unique HAXPES-Lab is breaking the limits of conventional XPS by making use of the extended inelastic mean free path and therefore greater depth information from high kinetic energy electrons in matter. The new instrument allows for true bulk property analysis from buried interfaces and surface characterization on real world samples without the need of surface preparation. The Fermi DryCoolTM SPM combines a cryogen-free cooling to <10K with high resolution STM and QPlus imaging and spectroscopy. The new TESLA JT SPM provides access to more than 5 days SPM measurement time at temperatures $T < 1.4K$ with magnetic fields larger than $B > 3T$.

233



Scientific Instrument Services, Inc.

237

1027 Old York Road
Ringoes, NJ 08551
Phone: 908-788-5550
www.sisweb.com



Scientific Instrument Services is a leading global provider of supplies and services for Scientific Instrumentation. SIS specializes in the manufacture of filaments for spectrometers and related instrumentation. Contract Machining. SIS has expanded our machine shop for the manufacture of parts for scientific instruments. Our shop includes ultramodern CNC equipment for the machining of parts from virtually all materials to the high precision standards and cleanliness required by our customers.



Semicore Equipment, Inc.
470 Commerce Way
Livermore, CA 94551
Phone: 925-373-8201
www.semicore.com

Semicore Equipment, Inc., a Silicon Valley based manufacturer, supplies, services and supports Sputtering, Evaporation, Thin Film PVD systems for the electronics, optical, solar energy, medical, military, academic and related high technology industries worldwide. Semicore's products provide quality coatings on a variety of materials including plastic films, glass, ceramics, metals and hybrid substrates and range from R&D to high-performance production level systems at a competitive price.

Semilab
101 Billerica Ave. Bldg. 5, Ste. 105
Billerica, MA 01821
Phone: 813-977-2244
www.semilab.com

Semilab USA Semilab is a leading metrology equipment supplier for characterization of semiconductor materials. The company offers advanced electrical and optical systems, for both R&D and production control in the semiconductor, photovoltaic, and display technology markets. Technologies include world leading sensitivity for contamination, dopant impurity measurements, ellipsometry and IR reflectometry, atomic force microscopy, and CV/IV measurements of dielectrics, and include both contact and non-contact solutions. They are offered in a range of platforms from small, manual type tools to fully automated systems for production control and high-resolution imaging.

136 **SiO2 Innovates LLC/SiO2 NanoTech LLC** **133**

1211 East Balboa Drive
Tempe, AZ 85282
Phone: 480-980-4580
www.sio2nanotech.com

SiO2 Innovates and its sister company SiO2 NanoTech provide permanent, non-toxic, FDA-approved ANTI-FOG VitreOx™ super-hydrophilic coatings for endoscopes, lenses and goggles. Our spin-off MicroDrop Diagnostics provides InnovaDrop™ coatings to solidify small volumes of fluids into uniform Thin Solid Films for UHV analysis. Among various applications of InnovaDrop™, HemaDrop™ is a technology developed & patented by SiO2 & MicroDrop to make Homogeneous Thin Solid Films (HTSF) from a few microliters of blood for electrolyte and blood iron analysis. Our second spin-off AccuAngle Analytics provides quantitative, accurate, and reproducible contact angle, oleo-/hydro-affinity, and surface energy analysis via our web-based/licensed software DROP™ and consulting services. AccuAngle Analytics was founded to provide a Web-based and Computer-based Image Analysis user interface for fast Contact Angles and Surface Energy Analysis between fluids and surfaces with high statistical confidence.

456

Solberg Manufacturing
1151 Ardmore Avenue
Itasca, IL 60143
Phone: 630-773-1363
www.solbergmfg.com

Solberg manufactures inline vacuum filters for medium and high vacuum pump applications. Solberg will be showcasing several new products including vapor condensing traps, ISO flange housings, molecular sieve traps, separators and two-stage discharge filters. Solberg supplies filtration and separation solutions worldwide and is currently used on a wide variety of vacuum pumps and applications. Come and see how Solberg can partner with you!





EXHIBITOR PROFILES



Solecon Laboratories, Inc.
770 Trademark Drive
Reno, NV 89521
Phone: 775-853-5900
www.solecon.com

We provide front-end process engineers and scientist with timely and cost-effective characterization of resistivity and concentration vs. depth profiles in silicon and germanium, with resolutions down to the nanometer range. SRA is especially useful for its depth accuracy (+/-3%) and sensitivity to ultra-low dopant concentrations. SRA can be done at any stage of the wafer fabrication process, We offer SRA as a service (i.e., you send us samples and we send you profiles.) SRA is helpful for checking the results of any resistivity altering process, and is used extensively for : Epitaxial deposition - thickness, resistivity, and auto doping issues, Ion implant verification, Dopant contamination issues, Diffusions in general - deep or shallow. We will be happy to discuss the possibility of running complimentary analyses to demonstrate our capabilities on your samples. Please contact Sheila Loftis at 775-853-5900 or sheila@solecon.com

Solid Sealing Technology, Inc.
44 Dalliba Ave. Watervliet Arsenal
Watervliet, NY 12189
Phone: 518-874-3600
www.solidsealing.com

Solid Sealing Technology specializes in the design and manufacture of hermetic products using metalizing, brazing, glass-ceramic sealing, welding, and critical mechanical assembly. Products include Vacuum Feedthroughs; Coaxial and Multi-Pin Connectors; Thermocouple Connectors; and Isolators. SST provides sealing solutions for high temperature, ultra-high vacuum and high pressure environments and is a Global provider of industry standard and custom designed products.

SPECS Surface Nano Analysis, Inc.
20 Cabot Blvd Suite 300
Mansfield, MA 02048
Phone: 508-618-1292
www.specs.com

SPECS manufactures systems and components for surface analysis, based on electron spectroscopy and imaging techniques such as SPM and LEEM. In customized systems SPECS integrates facilities for thin film preparation and in-situ analysis in vacuum systems from UHV to high pressures.

532

SPI Supplies
206 Garfield Ave.
West Chester, PA 19380
Phone: 610-436-5400 • www.2spi.com

SPI Supplies is a worldwide leading manufacturer/distributor of sample preparation equipment and consumables for electron microscopy and other vacuum laboratory applications. Featured instruments include the Wet Cell II and REBEKA/KARMEN BSE detector for SEMs. Plasma Systems and sputter/carbon coaters popular instruments and we offer a full line of substrates, greases, fluids and wipers for all vacuum applications. New for AVS are Kammrath and Weiss transport and tensile testing modules for SEM.

444

Staib Instruments
101 Stafford Court
Williamsburg, VA 23185
Phone: 757-565-7000
www.staibinstruments.com



STAIB designs & manufactures high performance, reliable instruments for in-situ material analysis and Multi-technique Surface Analysis Chambers: RHEED systems to study structure, film quality in UHV & high pressure; Auger Probe for studying elemental composition in-situ during growth; CMA energy spectrometers (Auger, SAM, XPS, and UPS) for analytical surface studies; Electron Guns for analytical surface studies-flood, microfocus, general purpose, low energy, nano-focus; SEM using Staib microfocus guns; PEEM; X-ray Sources.

344

Strem Chemicals, Inc.
7 Mulliken Way
Newburyport, MA 01950
Phone: 978-499-1600 • www.strem.com

Established in 1964, Strem Chemicals manufactures and markets a wide variety of metals, inorganics, organometallics and nanomaterials for research and commercial scale production for the materials science community including a wide range of MOCVD, CVD and ALD precursors & bubblers, metal-based Nanomaterials (including PURE nanoparticles that are reactant and surfactant-free and functionalized gold), quantum dots including ones in solid form (CdSe, PbS, functionalized iron oxide, graphene) and carbon nanomaterials (nanotubes, fibres, cones, CNT arrays, graphene). We also provide a variety of catalysts and ligands for organic synthesis, rare-earth and electronic grade chemicals for ultra-high purity needs and biocatalysts. Strem is an ISO 9001 certified company.

434



314

Super Conductor Materials
391 Spook Rock Industrial Park
Building F
Suffern, NY 10501
Phone: 845-368-0240

www.scm-inc.com

Celebrating our 31st anniversary, Super Conductor Materials, Inc specializes in sputtering targets, crucible liners, and evaporation materials for semiconductor, thin film, PVD, optical display technology, magnetic media, electronic, solar panel and allied industries. Materials are available from Aluminum to Zirconium including their alloys and compounds. We also provide electron beam evaporation by manufacturing crucible liners in 14 different materials for all major e-gun systems. Custom materials and sizes are available. Contact us today at sales@scm-inc.com for your material needs!

Surface Science Integration
580 Bullard Avenue Suite 69
Goodyear, AZ 85338
Phone: 800-749-7473

www.ssintegration.com

SSI specializes in the development of new technologies and products for the advanced materials, Solar Cell, nanotechnology, MEMs and Compound Semiconductor markets. SSI is reknown for its leadership and innovation in the fields of advanced materials and semiconductor processing. SSI has been very successful with its family of photolithography, etch and Rapid Thermal Processing systems. Custom designs are available.

SynSysCo
2510 N Townsend Ave. PO Box 177
Montrose, CO 81402
Phone: 970-240-9429

synsysco.com/

SynSysCo manufacturers Omni™ Helium Compressors and SDS industrial dry screw pumps. We are the national distributor for Sumitomo Marathon™ Systems, Kashiyama, Anest Iwata, and Scroll Lab dry pumps. We provide rebuild service and support for all the products we sell. This includes CryoPlex™, CryoTorr™, CryoTorr On-Board™ and Marathon™ pumps and related Helium Compressors. CryoPlex™ is a Registered Trademark of Trillium US Inc.; CryoTorr™ and On-Board™ are registered trademarks of Brooks Automation Inc., Marathon™ is a registered trademark of Sumitomo Cryogenics America Inc.



355 DK-Lambda Americas HP Division

405 Essex Road
Neptune, NJ 07753
Phone: 732-922-9300

www.us.tdk-lambda.com/hp

TDK-Lambda (formerly Lambda Americas), High Power Division is a leading manufacturer of High Power AC to DC Programmable, and High Voltage Capacitor Charging Supplies. With power levels from 500W to 90kV and voltaged from 6V to 50,000V our product line is unique in the industry.

339

348 Technetics Group

2791 The Boulevard
Columbia, SC 29209
Phone: 803-783-1880

www.technetics.com

At Technetics Group, our metal sealing solutions are highly engineered products designed to work in critical vacuum applications. We have the capability to prove a design concept before it leaves our factories with state-of-the-art design software and test equipment that can replicate your applications' critical operating environments. Custom solutions include HELICOFLEX® spring-energized metal seals and Quick Disconnect Systems (QDS).

365 Tech-X Corporation

5621 Arapahoe Avenue Suite A
Boulder, CO 80303
Phone: 303-448-0727

www.txcorp.com

Tech-X Corporation provides software and consulting for simulating and modeling electromagnetic, electrostatic, and plasma processes. We provide VSim, a powerful simulation software that raises the standard for electromagnetic and kinetic plasma simulations. Use cutting-edge high-performance algorithms to design and analyze devices up to millions of cubic wavelengths in volume. Include kinetically modeled charged and neutral particles to self-consistent Electromagnetic and Electrostatic field solves. Implicitly model neutral and charged fields and their interactions with kinetically modeled particles.

Teledyne Hastings Instruments
804 Newcombe Avenue
Hampton, VA 23669
Phone: 757-723-6531
www.teledyne-hi.com



Teledyne Hastings Instruments is a trusted manufacturer of a wide range of quality Vacuum Instruments and Gas Mass Flow Instruments. Our vacuum product line includes the original DV-4 and DV-6 thermocouple gauge tubes, along with other vacuum sensors used in combination with meters and controllers that cover a wide range of vacuum pressure from atmosphere to ultra-high vacuum. The gas mass flow line of meters and controllers cover a broad range of flow rates from 5 sccm to 15,000 slm that includes a variety of flexible options for outputs, calibration, and fittings.

Thermionics Laboratory, Inc. 436
1842 Sabre Street
Hayward, CA 94545
Phone: 510-538-3304
www.thermionics.com

Manufactures vacuum components, systems and accessories for production and research applications including: our VE-160 and VE-240 PVD coating system; our line of LHe cooled manipulators; our 1500cc capacity IC series eGun™; our production class HC series of e-Guns™ with dual filament; our research class RC series eGuns™; PyraFlat™ rectangular flange; TriMetl™ (aluminum to stainless and copper to stainless) flanges and fittings; gate and poppet valves; sample handling and transfer systems; ion pumps; maTChed™ thermocouple gauges; mechanical, electrical and fluid feedthroughs

Thermo Fisher Scientific 245
5225 Verona Road
Madison, WI 53711
Phone: 608-276-6100
www.thermofisher.com/surfaceanalysis

Thermo Fisher Scientific will showcase their portfolio of X-ray photoelectron spectroscopy instruments. Come and see the latest enhancements, including fully automated UV photoelectron spectroscopy on the K-Alpha+, co-incident XPS-Raman spectroscopy on the Theta Probe, and the new ESCALAB Xi+. All three instruments are available for live online demonstrations from our UK applications laboratory. Visit Booth 223 to see surface analysis from Thermo Scientific.

232

Torreyvac Inc. 130
4701 Patrick Henry Drive
5556 Edison Ave, Chino CA 91710
Santa Clara, CA 95054
Phone: 626-716-4956
www.torreyvac.com

Torreyvac Inc. was incorporated in 2002 and began fabricating stainless steel chambers, flanges, fittings, and custom chamber/components for the vacuum industry. Torreyvac is located in a 80,000 square foot, state-of-the-art manufacturing facility in Wuxi, Jiangsu, China.

UC Components 236
POB 430
Morgan Hill, CA 95038
Phone: 408-782-1929
www.uccomponents.com

UC Components Inc manufacturer of RediVac® Vented, Coated, Plated, Polished, Vacuum Baked & Cleaned Fasteners as well as RediVac® Cleaned and Vacuum Baked O-Rings for vacuum applications. All RediVac® Products are Precision Cleaned & packaged for immediate vacuum use. Reduce pump-down times & contamination in your UHV system! Download prints, quote, and buy on-line at www.uccomponents.com

UHV Design Ltd. 209
Judges House, Lewes Road
Laughton, East Sussex BN8 6BN
United Kingdom
Phone: 44-(0)1323-811188
www.uhvdesign.com

UHV Design specializes in the design, manufacture and supply of high precision sample heating and manipulation products for use in high and ultra-high vacuum markets for materials research. Products are sold and supported exclusively in North America by the Kurt Lesker Company to a diverse customer base including synchrotrons, universities and government laboratories, OEMs (vacuum system integrators) and the semiconductor and industrial markets. Applications include sample manipulation and heating for deposition and surface analysis techniques.

ULVAC, Technologies, Inc.
401 Griffin Brook Dr.
Methuen, NH 01844
Phone: 978-686-7550
www.ulvac.com

ULVAC is pleased to present our full line of vacuum components that have innovative features in their design. On display will be our Heliot helium Leak Detectors, Qulee RGA, G-Tran vacuum gauges, AxTRAN Extreme High Vacuum Gauge, UHV Ion Pumps, Table-top furnace, Table Top Sputtering system and mechanical pumps. Custom vacuum systems are available, and ULVAC has a complete line coating and etching systems for MEMS. Ask about our foundry service for deep silicon etching.

United Mineral and Chemical Corp.
1050 Wall Street West Suite 660
Lyndhurst, NJ 07071
Phone: 201-507-3300
www.umccorp.com

Key Products: MBE Source Materials; MBE Equipment; Dopants United Mineral and Chemical Corporation is a leading supplier of ultra high purity, MBE grade ingots and metal sources including Arsenic, Red Phosphorus, Indium, Gallium, Aluminum, Antimony, Magnesium, Selenium, Silicon and Tellurium. Compounds of III-V materials are offered as well. UMC also represents Dr. Eberl MBE-Komponenten for MBE effusion cells, crackers, doping and sublimation sources as well as ancillary equipment and components.

VACGEN Ltd.
Unit A, Swallow Business Park
Diamond Drive, Lower Dicker
Hailsham, East Sussex BN27 4EL
United Kingdom
Phone: +44 0 1323 379 379
www.vacgen.com

VACGEN are a leading supplier of vacuum components and manipulation devices to industry, education, research and development and the scientific community. We develop and supply the complete spectrum of UHV products, from sample holders to vacuum chambers to suit our client's demands. Come visit our booth to see what we can offer you!

249

Vacuum Research Corporation
100 Chapel Harbor Dr. #4
Pittsburgh, PA 15238
Phone: 412-261-7630
www.vacuumresearch.com

244


SPONSOR

Manufacturer for 50 years of a broad line of high vacuum valves. Throttle valves, poppet style valves, rectangular port valves, and gate valves from ISO-63 to ISO-800 & CF 2.75 to 14 inch OD. Valves with ANSI and JIS flanges to 32 inch. Also Pirani, convection and diaphragm gauges from 10-5 Torr to 2 atmospheres. Rotary vane pumps from 3 to 64 cfm, 6 to 108 m³/hr. We will have our throttle valve in operation in our booth.

419

VAT
655 River Oaks Pkwy
San Jose, CA 95134
Phone: 408-375-5567
www.vatvalve.com

323


SPONSOR

VAT is the leading global developer, manufacturer and supplier of high-performance, high-end vacuum valves. VAT's vacuum valves are mainly used in semiconductor, display and solar panel manufacturing as well as in a wide range of industry and research applications. The highest-level professional advice and service is our promise to our customers.

128

Veeco Instruments
1 Terminal Drive
Plainview, NY 11803
Phone: 516-677-0200-1057
www.veeco.com

226

Veeco is the world leading provider of process and metrology equipment solutions. Foremost in the design and manufacture of ion beam sources and systems for thin film deposition and etch applications, Veeco offers the broadest line of ion sources. Veeco's Dektak 150 stylus profiler delivers the largest Z-based measurement range and detailed analysis of slope features, the Dektak 150 is an ideal platform for thin and thick film characterization. With its newly acquired ALD division, Veeco | CNT, Veeco is now the leading supplier of Atomic Layer Deposition equipment for R&D and non-semi production.



EXHIBITOR PROFILES



Williamsburg Scientific Instruments LLC
295 McLaws Circle Suite 3
Williamsburg, VA 23185
Phone: 757-345-6588
www.wsscientific.com

WSI offers components and systems for surface analysis at Near Atmospheric Pressure (NAP) working at vacuum pressures much higher than with standard analytical equipment. WSI designs new modular components such as electron, ion sources, energy analyzers and detectors able to operate in environmental conditions allowing the study in-situ and experimentally of surface conditions during processing. The sources and analyzer are built as a module that can be combined to best suit a specific application.

Yugyokuen Ceramics Co., Ltd.
1-46-2 Kamiikedai Otaku
Tokyo 1450064 Japan
Phone: 81-3-3726-4455
www.yugyokuen-ceramics.com/en

Yugyokuen Ceramics Co., Ltd. is a manufacturer of ceramic components. We support non-destructive testing and analysis processes as well as the creation of vacuum environments. We developed various ceramic molded products, ceramic processed item, metallizing and brazing products based on ceramic, welding products, assembled products - electric furnace, electric furnace tube, emitter for the source of electric beam & filaments. Our Products are made of precisely chosen high purity material, and due to its electric property, heat property and excellent low outgassing, widely approved for the parts of vacuum equipment, analysis equipment, and non-destructive inspection equipment.

346

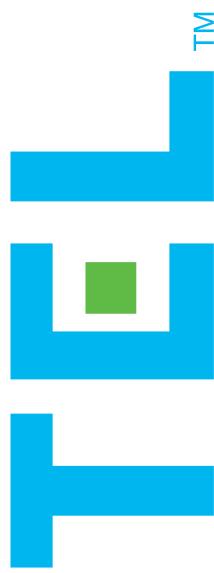
zeroK NanoTech

228

401 Professional Dr Suite 125
Gaithersburg, MD 20879-3468
Phone: 240-702-0081 • www.zerok.com

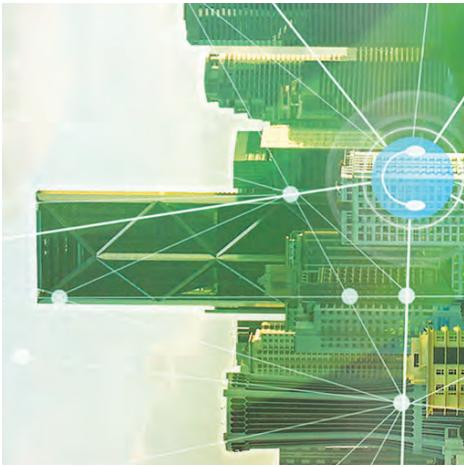
zeroK provides high performance focused ion beam instruments featuring our new Cs+ and Li+ ion source technology. These systems can help you mill smaller features in less time, and with less sample contamination. They can also provide the ultimate in spatially resolved elemental analysis. FIB:RETRO turns yesterday's FIB into tomorrow's cutting edge. Do you have a FIB system that has done some great work but now is languishing? You've already paid to site the tool, keep it running, and promote its availability. With an ion source upgrade you can turn that FIB into one capable of generating new scientific breakthroughs. SIMS:ZERO is the Integrated Solution for Nanomachining and High Resolution Elemental Analysis. Obtain EDX-like spectra without time-consuming trenching and lift-out. Collect SIMS data 100X faster and with ultimate spatial resolution. Machine with resolution better than any other FIB on the market





PROUDLY SPONSORING THE 2018 AVS CONFERENCE

TEL is a leading global company of semiconductor and flat panel display production equipment, that engages in development, manufacturing, and sales worldwide.

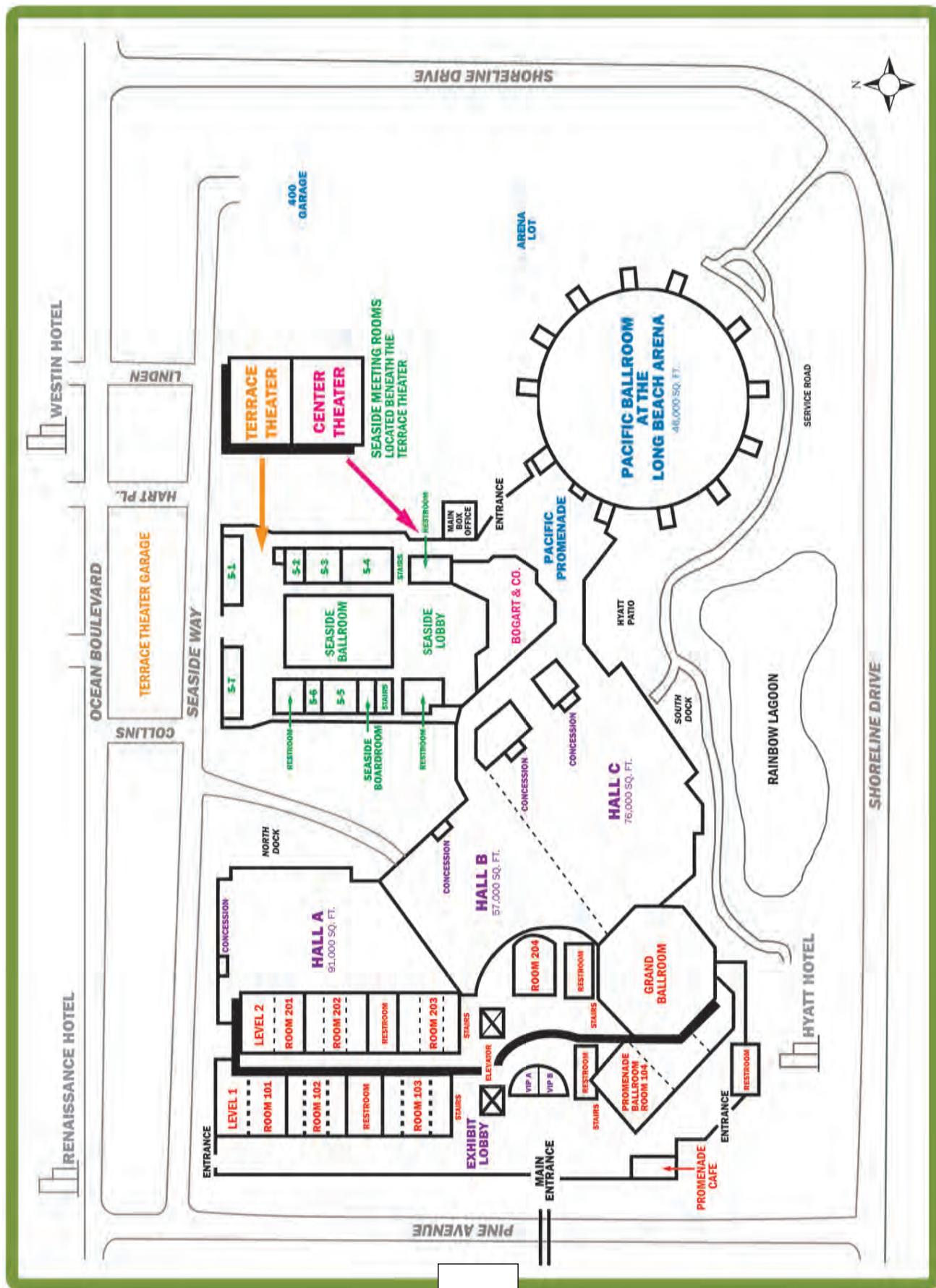


TEL IS TECHNOLOGY ENABLING LIFE



@TokyoElectron | www.tel.com

LONG BEACH CONVENTION CENTER





Events Calendar

Featuring AVS Meetings and Sponsored/Endorsed Topical Conferences

2018

AVS 65th International Symposium & Exhibition
October 21-26, 2018
Long Beach, CA
Web: www.av.org/symposium

40th International Symposium on Dry Process (DPS2018)
November 13-15, 2018
Nagoya-city, Aichi, Japan
Web: www.dry-process.org/2018/

International Joint Symposium of "Interfacial Science for Green Innovation"
November 20, 2018
Kobe, Japan
Contact: kfukui@chem.es.osaka-u.ac.jp

Workshop on Innovative Nanoscale Devices & Systems (WINDS) 2018
November 25-30, 2018
Kohala Coast, Hawaii
Web: www.iue.tuwien.ac.at/winds2018/

2019

The 46th International Conference on the Physics and Chemistry of Semiconductor Interfaces (PCSI-46)
January 13-17, 2019
Santa Fe, New Mexico
Web: www.pcsiconference.org

Frontiers of Characterization and Metrology for Nanoelectronics (FCMN 2019)
April 1-4, 2019
Monterey, California
Web: <http://www2.av.org/conferences/FCMN/index.htm>

ICMCTF 2019
May 19-24, 2019
San Diego, California
Web: <http://www2.av.org/conferences/ICMCTF/>

Atomic Layer Deposition and Etching (ALD/ALE 2019)
July 21-24, 2019
Bellevue, Washington
Web: www.ald2019.av.org

55th North American Molecular Beam Epitaxy Conference (NAMBE 2019)
September 25-29, 2019
Boise, Idaho
Contact: paulsimmonds@boisestate.edu

AVS 66th International Symposium & Exhibition
October 20-25, 2019
Columbus, Ohio
Web: www.av.org/symposium

TACT 2019 International Thin Films Conference
November 17-20, 2019
Taipei, Taiwan
Web: <http://tact2019.conf.tw>



AVS 66TH INTERNATIONAL SYMPOSIUM & EXHIBITION

SYMPOSIUM: OCT. 20-25, 2019 | EXHIBIT: OCT. 22-24, 2019



Greater Columbus Convention Center, Columbus, Ohio, USA

Addressing cutting-edge issues associated with materials, processing, and interfaces in both the research and manufacturing communities. The weeklong Symposium fosters a multidisciplinary environment that cuts across traditional boundaries between disciplines.

1,300+ Technical Presentations

2 Poster Sessions

250+ Exhibits

**Short Courses
and More**



*See Why You
Should Attend
AVS 66*